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Author and Subject Index
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The Computer-Derived 1982 Journal Index

The Publication Committee of the Society recommended the use of a computer-derived index in 1968, and this practice is planned to be continued. These indices refer only to *Journal* articles, reviews, brief communications, discussions, and news and reviews listed in the contents pages. They do not include meeting papers, abstracts, and news items. These indices were prepared for the *Journal* by Amron Information Services, Union, New Jersey.

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1. Given any author, go directly to his name in the author and title index to find the full paper title with a page citation or, if he is a secondary author, to find a cross-reference to a primary author.
2. Given any topic, go to the subject index and search for the key word itself.
3. For a detailed explanation and meaning of symbols and abbreviations, see the sample pages before the individual author and title index and subject index.
4. Chemical formulae cannot be reproduced directly because the conventional computer printout appears in capital letters only. For example, B13 could be three atoms of bismuth or boron triiodide.
5. In the author index, an author is always listed with all available initials, which for lack of space sometimes can mean omission of one or two letters from the end of his last name. This truncation is indicated by a period at the end of the last name.

The Publication Committee will appreciate comments on the usefulness and accuracy of this index.

ROBERT P. FRANKENTHAL
Chairman
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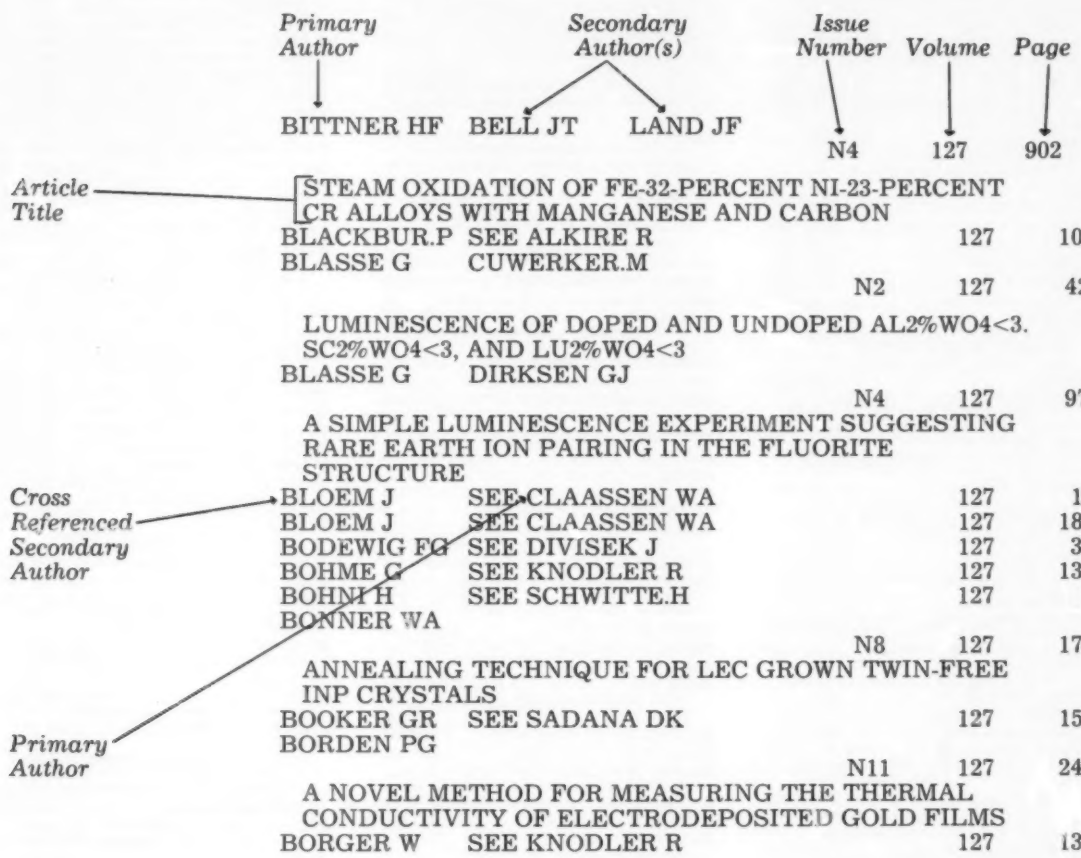
JOURNAL ARTICLE AUTHOR AND TITLE INDEX

To locate a full description of a source item, look up the primary author. Under a given name, journal articles of primary authorship are described first. Items of secondary authorship follow. These are cross-referenced to the primary author whose name follows the word SEE.


Primary Author
Secondary Author(s)
Issue Number
Volume
Page
BITTNER HF BELL JT LAND JF N4 127 902
Article Title
STEAM OXIDATION OF FE-32-PERCENT NI-23-PERCENT CR ALLOYS WITH MANGANESE AND CARBON
BLACKBUR.P SEE ALKIRE R 127 1085
BLASSE G CUWERKER.M N2 127 429
LUMINESCENCE OF DOPED AND UNDOPED AL2%WO4<3. SC2%WO4<3, AND LU2%WO4<3
BLASSE G DIRKSEN GJ N4 127 978
A SIMPLE LUMINESCENCE EXPERIMENT SUGGESTING RARE EARTH ION PAIRING IN THE FLUORITE STRUCTURE
Cross Referenced Secondary Author
BLOEM J SEE CLAASSEN WA 127 194
BLOEM J SEE CLAASSEN WA 127 1836
BODEWIG FG SEE DIVISEK J 127 357
BOHME G SEE KNODLER R 127 1311
BOHNI H SEE SCHWITTE.H 127 15
BONNER WA N8 127 1798
ANNEALING TECHNIQUE FOR LEC GROWN TWIN-FREE INP CRYSTALS
BOOKER GR SEE SADANA DK 127 1589
Primary Author
BORDEN PG N11 127 2454
A NOVEL METHOD FOR MEASURING THE THERMAL CONDUCTIVITY OF ELECTRODEPOSITED GOLD FILMS
BORGER W SEE KNODLER R 127 1311

Author — Title — Issue No. — Vol. No. — Page No.

ABELS LL *see* SALMON DJ 129 2496
ABLOW CM *see* KINOSHITA K 129 2397
ABRAHAM KM, GOLDMAN JL, NATWIG DL N11 129 2404
CHARACTERIZATION OF ETHER ELECTROLYTES FOR RECHARGEABLE LITHIUM CELLS
ABRAHAM KM *see* RUPICH MW 129 1857
ABRUNA HD, BARD AJ N3 129 673
SEMICONDUCTOR ELECTRODES 44. PHOTOELECTROCHEMISTRY AT POLYCRYSTALLINE P-TYPE WSE2 FILMS
ABRUNA HD, HOPE GA, BARD AJ N10 129 2224
SEMICONDUCTOR ELECTRODES XLV. PHOTOELECTROCHEMISTRY OF N- AND P-TYPE MOTE2 IN AQUEOUS SOLUTIONS
ABRUNA HD *see* WHITE HS 129 265
ABYANEH MY, HENDRIKX J, VISSCHER W, BARENDRECE N12 129 2654
THE ELECTROCRYSTALLIZATION OF ZINC FROM ALKALINE MEDIA
ADACHI S N3 129 609
CHEMICAL ETCHING OF INP AND INGAASP/INP
ADACHI S, KAWAGUCHI H, IWANE G N4 129 883
INGAASP/INP PLANAR-STRIPE LASERS WITH CHEMICALLY ETCHED MIRRORS
ADACHI S, NOGUCHI Y, KAWAGUCHI H N5 129 1053
CHEMICAL ETCHING OF INGAASP/INP DH WAFER
ADACHI S, NOGUCHI Y, KAWAGUCHI H N7 129 1524
USE OF HBR-CH3COOH-K2CR2O7 ETCHANT TO ETCHED-MIRROR LASER FABRICATION
ADAMS AC *see* LEVIN RM 129 1588
ADAMS WA *see* GAUTHIER M 129 970
AGARWAL CV *see* SINGH DDN 129 1869
AGIUS B *see* RIGO S 129 867
AKAHOSHI H *see* ITAYA K 129 762
AKAHOSHI H *see* ITAYA K 129 1498
AKITA K *see* NAKAJIMA K 129 2603
ALBERS J N3 129 599
PROBE-SPACING EXPERIMENT SIMULATION AND THE RELATION BETWEEN SPREADING RESISTANCE AND SHEET RESISTANCE
ALBERS J N12 129 2788
SPREADING RESISTANCE PROBE-SPACING EXPERIMENT SIMULATIONS: EFFECTS OF PROBE-CURRENT DENSITY AND LAYER THICKNESS
ALBERY WJ, BARTLETT PN N10 129 2254
THE PHOTOELECTROCHEMICAL KINETICS OF P-TYPE GAP
ALKIRE RC, SIITARI DW N3 129 488
INITIATION OF CREVICE CORROSION II. MATHEMATICAL MODEL FOR ALUMINUM IN SODIUM CHLORIDE SOLUTIONS
ALKIRE RC, TSAI JE N5 129 1157
ELECTROSYNTHESIS OF PROPYLENE OXIDE WITH ALTERNATING CURRENT
ALKIRE RC, CERA GD, STADTHERMA N6 129 1225
OPTIMIZATION OF ELECTROLYTIC CELLS HAVING LARGE NUMBERS OF VARIABLES
ALKIRE RC, CHEN T-J N11 129 2424
HIGH-SPEED SELECTIVE ELECTROPLATING WITH SINGLE CIRCULAR JETS
ALKIRE RC *see* SIITARI DW 129 481
ALLAM A *see* ZAMANZADE M 129 284
ALLEN R, FOSTER M, YEN Y-T N6 129 1379
DEEP U.V. HARDENING OF POSITIVE PHOTORESIST PATTERNS
ALLISON DF *see* STACY WT 129 1128
ALWITT RS, DYER CK, NOBLE B N4 129 711
VOIDS IN ANODIC ALUMINUM OXIDE FILMS
AMADELLI R *see* SCHERSON DA 129 2268
AMICK JA N4 129 864
PURIFICATION OF RICE HULLS AS A SOURCE OF SOLAR GRADE SILICON FORSOLAR CELLS
ANASTOPO.AG, JANNAKOU.DA N11 129 2547
MATHEMATICAL MODELING OF THE LOW FREQUENCY CAPACITANCE CHARACTERISTICS OF THE MOS STRUCTURE WITH VERY THIN SUBSTRATE
ANDERSON AB *see* DEBNATH NC 129 2169
ANDERSON CW, LUNG KR N11 129 2505
CHEMICAL MODIFICATION OF RETICULATED VITREOUS CARBON
ANG PGP, SAMMELLS AF N1 129 233
N-MOSE2 PHOTOELECTROCHEMICAL HALOGEN STORAGE CELL
ANG PGP *see* LIU C-H J 129 1387
ANGELUCCI R *see* SOLMI S 129 1811
ANGILELLO J *see* IRENE EA 129 2594
ANSON FC *see* WILLETT BC 129 1260

ANTONIAD.DA N5 129 1093
OXIDATION-INDUCED POINT DEFECTS IN SILICON
ANTOUN H, HADE A, CAPUANO GA N1 129 40
DISPROPORTIONATION REACTION OF ALKYLBENZENES IN ALUMINUM BROMIDE AND HBR (ELECTROLYTE USED FOR THE ELECTRODEPOSITION OF ALUMINUM)
AOGAKI R N11 129 2442
IMAGE ANALYSIS OF MORPHOLOGICAL INSTABILITY IN GALVANOSTATIC ELECTROCRYSTALLIZATION I. GENERAL EXPRESSION FOR THE GROWTH MODE OF SURFACE IRREGULARITIES
AOGAKI R N11 129 2447
IMAGE ANALYSIS OF MORPHOLOGICAL INSTABILITY IN GALVANOSTATIC ELECTROCRYSTALLIZATION II. EXPERIMENTAL DEMONSTRATION OF CRYSTAL GROWTH BEHAVIOR
APPELBAUM J *see* WEISS R 129 1928
APPERT JR *see* ENSTROM RE 129 2566
ARCHER VD N9 129 2074
METHODS FOR DEFECT EVALUATION OF THIN (100) ORIENTED SILICON EPITAXIAL LAYERS USING A WET CHEMICAL ETCH
ARDIZZONE S, CARUGATI A, LODI G, TRASATTI S N8 129 1689
SURFACE STRUCTURE OF RUTHENIUM DIOXIDE ELECTRODES AND KINETICS OFCHLORINE EVOLUTION
ARENDT RH N5 129 942
THE THERMODYNAMICS OF ELECTROLYTE DISTRIBUTION IN MOLTEN CARBONATE FUEL CELLS
ARENDT RH N5 129 979
ALTERNATE MATRIX MATERIAL FOR MOLTEN CARBONATE FUEL CELL ELECTROLYTE STRUCTURES
ARIMOTO Y *see* IHARA M 129 2569
ARNOLD GW *see* BUTLER MA 129 2735
ARNOTT DR, BAXTER WJ, ROUZE SR N12 129 2660
OXIDE FILM RUPTURE, REANODIZATION, AND STRESS CORROSION CRACKING IN ALUMINUM
ARVIA AJ *see* MACAGNO VA 129 301
ARVIA AJ *see* CARBONIO RE 129 983
ARVIA AJ *see* DELGADO AB 129 1493
ARVIA AJ *see* DE MELE MFL 129 2207
ARVIDSON A *see* SHARP KG 129 2346
ASAI K *see* YAMASAKI K 129 2760
AST DG *see* CUNNINGHA.B 129 1089
ATEYA B *see* ZAMANZADE.M 129 284
ATLUNG S *see* WEST K 129 1480
AUGUSTUS PD, STIRLAND DJ N3 129 614
A STUDY OF INCLUSIONS IN INDIUM PHOSPHIDE
AUGUSTYNS.J *see* KOUDELKA M 129 1186
AURET FD N12 129 2752
AN AES EVALUATION OF CLEANING AND ETCHING METHODS FOR INSB
AUSTIN AE *see* BYKER HJ 129 1982
AVIGAL Y *see* SACKS R 129 726
AWAD MZ *see* KOVACS P 129 695
AYERS WM N7 129 1644
P-TYPE AMORPHOUS SILICON/LIQUID JUNCTION SOLAR CELL
BACEIREDO S *see* MUNOZ-YAG.A 129 2108
BADCOCK CC *see* ZIMMERMA.AH 129 289
BADWAL SPS, DE BRUIN HJ N9 129 1921
ELECTRODE KINETICS AT THE PALLADIUM/CERAMIC OXIDE ELECTROLYTE INTERFACE
BADWAL SPS *see* MCCANN JF 129 551
BAGLIO JA, CALABRES.GS, KAMIENIECE, KERSHAW R, KUBIAK CP, RICCO AJ, WOLD A, WRIGHTON MS, ZOSKI GD N7 129 1461
CHARACTERIZATION OF N-TYPE SEMICONDUCTING TUNGSTEN DISULFIDE PHOTOANODES IN AQUEOUS AND NONAQUEOUS ELECTROLYTE SOLUTIONS. PHOTO-OXIDATION OF HALIDES WITH HIGH EFFICIENCY
BAKER JE *see* OBERSTAR JD 129 1312
BAKER JE *see* OBERSTAR JD 129 1320
BALACHAND.U, EROR NG N5 129 1021
ELECTRICAL CONDUCTIVITY IN LANTHANUM-DOPED STRONTIUM TITANATE
BALAKRISH.S *see* PRASAD A 129 596
BALDI L *see* SOLMI S 129 1811
BALIGA BJ N3 129 665
HIGH LIFETIME SILICON LIQUID PHASE EPITAXY
BALIGA B., N5 129 1078
DEFECT CONTROL DURING SILICON EPITAXIAL GROWTH USING DICHLOROSILANE

BALIGA BJ N12 129 2819
REFILLING SILICON GROOVES BY LIQUID PHASE EPITAXY
BALIGA BJ *see* CHOW TP 129 1040
BALLMAN AA *see* CHU SNG 129 352
BANCROFT EE N8 129 298C
THE COLIN GARFIELD FINK SUMMER FELLOWSHIP REPORT--DETERMINATION OF HETEROGENEOUS ELECTRON TRANSFER KINETIC PARAMETERS BY DERIVATIVE CYCLIC VOLTABSORPTIOMETRY
BANDYOPAD.G, SWAROOP RB, BATTLES JE N10 129 2187
CERAMIC SEPARATORS FOR LI-AL/IRON SULFIDE BATTERIES
BANDYOPAD.G, BATTLES JE N10 129 2265
THERMOMECHANICAL BEHAVIOR OF SIMULATED NEGATIVE ELECTRODES FOR LI-AL/FES BATTERY CELLS
BANKS E *see* SACKS R 129 726
BARANSKI AS, FAWCETT WR N5 129 901
THE FORMATION OF LITHIUM-ALUMINUM ALLOYS AT AN ALUMINUM ELECTRODEIN PROPYLENE CARBONATE
BARD AJ *see* CHEN Y-W D 129 61
BARD AJ *see* WHITE HS 129 265
BARD AJ *see* ABRUNA HD 129 673
BARD AJ *see* BULL RA 129 1009
BARD AJ *see* FAN F-R F 129 1647
BARD AJ *see* NAGASUBRA.G 129 1742
BARD AJ *see* ABRUNA HD 129 2224
BARENDREC.E *see* ABYANEH MY 129 2654
BARGERON CB, GIVENS RB N2 129 340
A SIGNATURE IN THE CURRENT DURING EARLY EVENTS IN THE PITTING CORROSION OF ALUMINUM
BARKER RA *see* MAYER TM 129 585
BARNA GG, FRANK SN, TEHERANI TH N4 129 746
A SCAN RATE DEPENDENT DETERMINATION OF PLATINUM AREAS
BARNA GG, FRANK SN, TEHERANI TH N11 129 2464
OXIDATION OF H2 AT GAS DIFFUSION ELECTRODES IN H2SO4 AND HBR
BARNES JO *see* LEARY DJ 129 1382
BARTLETT PN *see* ALBERY WJ 129 2254
BATTLES JE *see* SMAGA JA 129 496
BATTLES JE *see* BANDYOPAD.G 129 2187
BATTLES JE *see* BANDYOPAD.G 129 2265
BAUDRANT A, SACILOTTI M N5 129 1109
THE LPCVD POLYSILICON PHOSPHORUS DOPED IN SITU AS AN INDUSTRIAL PROCESS
BAUSER E, ROZGONYI GA N8 129 1782
THE FEATHERING OF DOPING STRIATIONS IN SEMICONDUCTOR CRYSTALS
BAXTER WJ *see* ARNOTT DR 129 2660
BEC C *see* HILLEL R 129 1343
BECK F N9 129 1880
A SEMICONDUCTOR MODEL FOR THE CATHODIC PASSIVATION OF LEAD DIOXIDE
BECK TR N11 129 2412
FORMATION OF SALT FILMS DURING PASSIVATION OF IRON
BECK TR N11 129 2500
INITIAL OXIDE GROWTH RATE ON NEWLY GENERATED SURFACES
BECK TR N10 129 395C
JOSEPH C. SCHUMACHER--VITTORIO DE NORA-DIAMOND SHAMROCK ELECTROCHEMICAL ENGINEERING AND TECHNOLOGY MEDALIST
BECKER RS *see* EPPS GF 129 2628
BECLA P, LAGOWSKI J, GATOS HC N5 129 1103
OPTIMIZATION OF ISOTHERMAL GROWTH OF HGCDTE LAYERS
BECLA P, LAGOWSKI J, GATOS HC, JEDRAL L N12 129 2855
ISOTHERMAL GROWTH OF HGCDTE UNDER CONTROLLED HG VAPOR PRESSURE
BELANGER A *see* GAUTHIER M 129 970
BENNETT RS *see* EPHRATH LM 129 1822
BENTON JL, KIMERLIN.C N9 129 2098
CAPACITANCE TRANSIENT SPECTROSCOPY OF TRACE CONTAMINATION IN SILICON
BERGE P, JOVANCICE.V, NOEL D, SAINT-PAU.P N10 129 2194
EFFECT OF SO2 AND PH ON THE ANODIC BEHAVIOR AND PITTING CORROSIONOF ALLOY 600
BERKOWIT.BJ, HOROWITZ HH N3 129 468
THE ROLE OF H2S IN THE CORROSION AND HYDROGEN EMBRITTLEMENT OF STEEL
BERNARD C *see* HILLEL R 129 1343
BERNARD C *see* COLMET R 129 1367

Author Title	Issue No.	Vol. No.	Page No.
BERNT H *see* CHIU T-Y		129	408
BERTHET MP *see* BOUIX J		129	2338
BETHIN JR *see* CHIANG CK		129	2113
BETTELHCI.A, PARASH R, OZER D CATALYSIS OF OXYGEN CATHODIC REDUCTION BY ADSORBED	N10	129	2247
BETTINI M *see* SAKASHITA M		129	739
BETTINI M *see* SAKASHITA M		129	1710
BEVOLO AJ *see* KESTER JJ		129	1716
BEYER KD, KASTL RH IMPACT OF DEIONIZED WATER RINSES ON SILICON SURFACE CLEANING	N5	129	1027
BEYER KD, YEH TH IMPURITY GETTERING OF SILICON DAMAGE GENERATED BY ION IMPLANTATION THROUGH SIO2 LAYERS	N11	129	2527
BEZJIAN KA, SMITH HI, CARTER JM, GEIS MW AN ETCH PIT TECHNIQUE FOR ANALYZING CRYSTALLOGRAPHIC ORIENTATION IN SI FILMS	N8	129	1848
BHATTACH.AB, MANCHANDA L, VASI J ELECTRON TRAPS IN SIO2 GROWN IN PRESENCE OF TRICHLOROETHYLENE	N12	129	2772
BHATTACH.RN, PRAMANIK P SEMICONDUCTOR LIQUID JUNCTION SOLAR CELL BASED ON CHEMICALLY DEPOSITED BI2S3 THIN FILM AND SOME SEMICONDUCTING PROPERTIES OF BISMUTH CHALCOGENIDES	N2	129	332
BHATTACH.RN, PRAMANIK P CHEMICAL METHODS FOR THE DEPOSITION OF THIN FILMS OF SB2SE3 AND SB2O3	N7	129	1642
BIEFELD RM *see* GINLEY DS		129	145
BILENCHI R *see* SOLMI S		129	1811
BINDER M, GILMAN S, WADE,JR W CALCIUM-SULFURYL CHLORIDE PRIMARY CELL	N4	129	897
BLACKBURN G, JANATA J THE SUSPENDED MESH ION SELECTIVE FIELD EFFECT TRANSISTOR	N11	129	2580
BLACKSTON.S, HENRY W, JASTRZEBS.L, FISHER AW MICRODEFECTS DURING PHOSPHORUS DIFFUSION	N3	129	667
BLANDER M *see* NAGY Z		129	2034
BLATTNER RJ *see* MINAGAWA S		129	888
BOCKRIS JO *see* MURPHY OJ		129	2149
BOCKRIS JO *see* DHAR HP		129	2178
BOCKRIS JO *see* OTAGAWA T		129	2391
BONNER WA *see* SINGH S		129	447
BONNER WA *see* MAHAJAN S		129	1556
BONNER WA *see* LEVY-CLEM.C		129	1701
BONNER WA *see* CAMLIBEL I		129	2585
BONOMI A, HADATE M, BREDA F, GENTAZ C EXPLORATORY STUDIES ON ELECTROLYSIS OF AIN DISSOLVED IN MOLTEN SALTS	N1	129	102
BOSIO AC *see* DONAHUE FM		129	717
BOUBEHIRA M *see* BOUIX J		129	2338
BOUIX J, BERTHET MP, BOUBEHIRA M, DAZORD J, VINCENT H DETERMINATION OF TEMPERATURE AND PARTIAL PRESSURE BY RAMAN SCATTERING INSIDE A CVD REACTOR	N10	129	2338
BOUIX J *see* HILLEL R		129	1343
BOURKE MAM *see* MOSELEY PT		129	876
BOUTEVILL.A *see* PAULEAU Y		129	1045
BOWDEN W ELECTROCHEMICAL OXIDATION OF POLYHEDRAL BORON HALIDE ANIONS	N6	129	1249
BOWER DH PLANAR PLASMA ETCHING OF POLYSILICON USING CCL4 AND NF3	N4	129	795
BOYER PK, RITCHIE WH, COLLINS GJ CONFORMAL STEP COVERAGE OF LASER DEPOSITED SILICON DIOXIDE FILMS	N9	129	2155
BRADSHAW RW, ROBERTSO.CR THEORETICAL ANALYSIS OF ELECTROSTATIC EFFECTS ON ION TRANSPORT INULTRATHIN MEMBRANES	N5	129	958
BRATIN P, TOMKIEWIC.M TRANSPORT PROPERTIES OF NAFION MEMBRANES FOR USE IN THREE-ELECTRODE PHOTOELECTROCHEMICAL STORAGE CELLS	N11	129	2469
BRAUNSTEI.J *see* VALLET CE		129	49
BRAUNSTEI.J *see* VALLET CE		129	931
BREDA F *see* BONOMI A		129	102
BREGOLI LJ, KUNZ HR THE EFFECT OF THICKNESS ON THE PERFORMANCE OF MOLTEN CARBONATE FUEL CELL CATHODES	N12	129	2711
BRESSAN J *see* FEUILLADE G		129	2649
BRIANT JL *see* WEININGE.JL		129	2409
BRICE DK *see* BUTLER MA		129	2735
BRIERE T *see* KANNAM PJ		129	656
BRILMYER G, JASINSKI R THE ELECTROCHEMISTRY OF HYDROCARBONS IN HF/SBF5: SOME MECHANISTICCONCLUSIONS CONCERNING THE SUPER ACID 'CATALYZED' CONDENSATION OFHYDROCARBONS	N9	129	1950
BRODD RJ *see* ISTONE WK		129	1853
BRODY JF *see* JOHNSON JW		129	2213
BROPHY JJ *see* HAEMMERLI A		129	2306
BROSSMAN JW *see* GOODWIN CA		129	1066
BROWN AP, KRUMPELT M, LOUTFY RO, YAO NP KINETICS OF THE HYDROGEN EVOLUTION REACTION ON MILD STEEL AND NICKEL CATHODES IN CONCENTRATED SODIUM HYDROXIDE SOLUTIONS	N11	129	2481
BROWN BF *see* NGUYEN TH		129	780
BROWN CW *see* KEISER JT		129	2686
BROWN DK, HU SM, MORRISEY JM FLAWS IN SIDEWALL OXIDES GROWN ON POLYSILICON GATE	N5	129	1084
BROWN DM *see* COHEN SS		129	1335
BRUCE RH, REINBERG AR PROFILE CONTROL WITH D-C BIAS IN PLASMA ETCHING	N2	129	393
BRUCE RH *see* SMITH DL		129	2045
BRUCKENST.S, MILLER B CURRENT-VOLTAGE ANALYSIS OF PHOTOELECTROCHEMICAL CELLS UNDER MASSAND LIGHT FLUX VARIATION	N9	129	2029
BRUCKENST.S *see* SWATHIRAJ.S		129	1202
BRUN TO, JORGENSE.JD, MISAWA M, ROTELLA FJ, SUSMAN S, MILDNER DFR DEFECTS AND DISORDER IN THE FAST-ION ELECTRODE LITHIUM-ALUMINUM	N11	129	2509
BRYANT FJ *see* QADEER A		129	2145
BUCHANAN RC *see* DE L'PRE.AF		129	2562
BUEHLER MG *see* YEN D		129	2313
BULL RA, FAN F-R F, BARD AJ POLYMER FILMS ON ELECTRODES VII. ELECTROCHEMICAL BEHAVIOR AT POLYPYRROLE-COATED PLATINUM AND TANTALUM ELECTRODES	N5	129	1009
BULLOCK KR, LAIRD EC SELF-DISCHARGE IN ACID-STARVED LEAD-ACID BATTERIES	N7	129	1393
BURGE G GOLD-CONTAINING SURFACE STATES ON PHOTOGRAPHIC AGBR GRAINS: ROLESBESIDES PHOTOELECTRON-TRAPPING	N3	129	591
BURILLA CT *see* CLARK TE		129	1540
BURNS JA *see* RATHMAN DD		129	2307
BURRIESCI D *see* RAY GW		129	2152
BURROWS BW *see* SUNU WG		129	688
BURTON RH, SMOLINSKY G CCL4 AND CL2 PLASMA ETCHING OF III-V SEMICONDUCTORS AND THE ROLE OF ADDED O2	N7	129	1599
BUTLER MA, ARNOLD GW, BRICE DK PHOTOELECTROCHEMICAL MEASUREMENTS OF H- AND HE-IMPLANTED GAP	N12	129	2735
BYKER HJ, WOOD VE, AUSTIN AE PHOTOELECTROCHEMISTRY OF N- AND P-TYPE SILICON IN ACETONITRILE	N9	129	1982
BYVIK CE, REICHMAN B, COLEMAN DW PHOTOELECTROCHEMICAL RESPONSE OF SOME LAYERED CHALCOGENOPHOSPHATECOMPOUNDS (MPX3)	N1	129	237
CACHARD A *see* PAULEAU Y		129	1045
CAHAN BD, CHEN C-T THE NATURE OF THE PASSIVE FILM ON IRON II. A-C IMPEDANCE STUDIES	N3	129	474
CAHAN BD, CHEN C-T QUESTIONS ON THE KINETICS OF O2 EVOLUTION ON OXIDE-COVERED METALS	N4	129	700
CAHAN BD, CHEN C-T THE NATURE OF THE PASSIVE FILM ON IRON III. THE CHEMI-CONDUCTOR MODEL AND FURTHER SUPPORTING EVIDENCE	N5	129	921
CAHAN BD *see* CHEN C-T		129	17
CAHAN BD *see* KURODA K		129	2163
CAHEN D *see* TENNE R		129	1506
CALABRES.GS *see* BAGLIO JA		129	1461
CAMLIBEL I, CHIN AK, ERMANIS F, DIGIUSEP.MA, LOURENCO JA, BONNER WA METALLURGICAL BEHAVIOR OF GOLD-BASED OHMIC CONTACTS TO THE INP/INGAASP MATERIAL SYSTEM	N11	129	2585
CAMLIBEL I *see* SINGH S		129	447
CANADAY JD *see* FISCHER CW		129	1016
CAPASSO F, WILLIAMS GF A PROPOSED HYDROGENATION/NITRIDIZATION PASSIVATION MECHANISM FOR GAAS AND OTHER III-V SEMICONDUCTOR DEVICES, INCLUDING INGAAS LONGWAVELENGTH PHOTODETECTORS	N4	129	821
CAPUANO GA *see* ANTOUN H		129	40
CARAMIHA.CA *see* TAYLOR DF		129	2458
CARBONIO RE, MACAGNO VA, GIORDANO MC, VILCHE JR, ARVIA AJ A TRANSITION IN THE KINETICS OF THE NI(OH)2/NIOOH ELECTRODE REACTION	N5	129	983
CARDON F *see* VANMAEKELD		129	546
CARDON F *see* MADOU MJ		129	2749
CARIM A *see* FAIR RB		129	2319
CARLBERG T, KING TB, WITT AF DYNAMIC OXYGEN EQUILIBRIUM IN SILICON MELTS DURING CRYSTAL GROWTHBY THE CZOCHRALSKI TECHNIQUE	N1	129	189
CARLSSON P, HOLMSTROM B HYDROGEN CONCENTRATION GRADIENT AND ASSOCIATED ELECTRIC FIELDS INTIO2 PHOTOANODES	N8	129	1851
CARPENTE.MK *see* STRECKER.HH		129	772
CARROLL KM *see* WARD WJ		129	227
CARTER JM *see* BEZJIAN KA		129	1848
CARUGATI A *see* ARDIZZONE S		129	1689
CARUSO R *see* CHIN AK		129	2386
CASEY JF, MEREDITH JW, OLESZEK GM PIPED EMITTER DELINEATION USING THE WRIGHT ETCH	N2	129	354
CASTRO L.AM *see* DELGADO AB		129	1493
CERA GD *see* ALKIRE RC		129	1225
CERMAK J *see* JUZA J		129	1627
CHAMBERL.MB *see* GINLEY DS		129	2141
CHAMBERS JQ *see* PETERSON JR		129	529
CHANDROS.EA *see* WILKINS,.CW		129	2552
CHANG CC *see* ROBINSON M		129	2858
CHANG CTM *see* PARKER SG		129	423
CHAO CY, LIN LF, MACDONAL.DD A POINT DEFECT MODEL FOR ANODIC PASSIVE FILMS III. IMPEDANCE RESPONSE	N9	129	1874
CHAUDHAR.RS *see* SINGH DDN		129	1869
CHAZALV.J-N ELECTROCHEMICAL TRANSFER VIA SURFACE STATES: A NEW FORMULATION FOR THE SEMICONDUCTOR/ELECTROLYTE INTERFACE	N5	129	963
CHEEK GT, OSTERYOU.RA ELECTROCHEMICAL AND SPECTROSCOPIC STUDIES OF 9,10-ANTHRAQUINONE IN A ROOM-TEMPERATURE MOLTEN SALT	N11	129	2488
CHEN C-T, CAHAN BD THE NATURE OF THE PASSIVE FILM ON IRON I. AUTOMATIC ELLIPSOMETRICSPECTROSCOPY STUDIES	N1	129	17
CHEN C-T *see* CAHAN BD		129	474
CHEN C-T *see* CAHAN BD		129	700
CHEN C-T *see* CAHAN BD		129	921
CHEN C-T *see* WU C-Y		129	1559
CHEN CP MINIMUM SILICON WAFER THICKNESS FOR ID WAFERING	N12	129	2835
CHEN MC, SILVESTR.VJ POST-EPITAXIAL POLYSILICON AND SI3N4 GETTERING IN SILICON	N6	129	1294
CHEN RT, HOLMES DE EFFECT OF MELT STOICHIOMETRY ON TWIN FORMATION IN LEC GAAS	N10	129	2382
CHEN T-J *see* ALKIRE RC		129	2424
CHEN WS *see* GUO SF		129	1592
CHEN Y-W D, SANTHANA.KS, BARD AJ SOLUTION REDOOX COUPLES FOR EELECTROCHEMICAL ENERGY STORAGE II. COBALT(III)-COBALT(II) COMPLEXES WITH O-PHENANTHROLINE AND RELATED LIGANDS	N1	129	61
CHIANG CK, BETHIN JR, DRAGOO AL, FRANKLIN AD, YOUNG KF INHOMOGENEITY CONTRIBUTION TO THE ELECTRICAL PROPERTIES OF Y-DOPED CEO2 CERAMICS: COMPARISON OF A-C AND D-C MEASUREMENTS	N9	129	2113
CHIANG KL *see* KAMINS TI		129	2326
CHIANG KL *see* KAMINS TI		129	2331
CHIN AK EVALUATION OF DEFECTS IN CDTE USING A SIMPLE	N2	129	369
CHIN AK, VON NEID.AR, CARUSO R SPATIALLY RESOLVED CATHODOLUMINESCENCE STUDY OF SEMI-INSULATING GAAS SUBSTRATES	N10	129	2386
CHIN AK *see* CAMLIBEL I		129	2585

Author / Title	Issue No.	Vol. No.	Page No.
CHIN D-T, SETHI R, MCBREEN J ZINC ELECTRODE MORPHOLOGY IN ALKALINE SOLUTIONS I. STUDY OF ALTERNATING VOLTAGE MODULATION ON A ROTATING DISK ELECTRODE	N12	129	2677
CHIN L-Y *see* KALEJS JP		129	1356
CHIU T-Y, BERNT H, RUGE I LOW ENERGY NITROGEN IMPLANTATION INTO SILICON: IT: MATERIAL COMPOSITION, OXIDATION RESISTANCE, AND ELECTRICAL CHARACTERISTICS	N2	129	408
CHOPRA KL *see* KAINTHLA RC		129	99
CHOW TP, GHEZZO M, BALIGA BJ ANTIMONY-DOPED TIN OXIDE FILMS DEPOSITED BY THE OXIDATION OF TETRAMETHYLTIN AND TRIMETHYLANTIMONY	N5	129	1040
CHU SNG, JODLAUK CM, BALLMAN AA NEW DISLOCATION ETCHANT FOR INP	N2	129	352
CHU SNG A SIMPLE DAMAGE-FREE GROOVING METHOD FOR REVEALING THE QUALITY OFINP/INGAASP MULTILAYER STRUCTURE	N9	129	2082
CIPOLLINI.NE VISUAL DETECTION OF HYDRATED ALUMINUM OXIDE BY STAINING WITH FLUORESCING AND NONFLUORESCING DYES	N7	129	1517
CISZEK TF, HURD JL, SCHIETZELM FILAMENT MATERIALS FOR EDGE-SUPPORTED PULLING OF SILICON SHEET CRYSTALS	N12	129	2838
CLAES P *see* WIAUX JP		129	123
CLARK TE, BURILLA CT PREPARATION, OPTIMIZATION, AND CATHODOLUMINESCENT PROPERTIES OF ALINE EMISSION PENETRATION PHOSPHOR	N7	129	1540
CLARKE LM *see* YEAGER HL		129	324
CLELAND JW HEAT-TREATMENT STUDIES OF OXYGEN-DEFECT-IMPURITY INTERACTIONS IN SILICON	N9	129	2127
COCKAYNE B *see* ROBBINS DJ		129	816
COCKE DL *see* MURPHY OJ		129	2149
COHEN SS, GILDENBLA.G, GHEZZO M, BROWN DM AL-0.9PERCENT SI/SI OHMIC CONTACTS TO SHALLOW JUNCTIONS	N6	129	1335
COLEMAN DW *see* BYVIK CE		129	237
COLLINS GJ *see* BOYER PK		129	2155
COLMET R, NASLAIN R, HOGENMULLP, BERNARD C THERMODYNAMIC AND EXPERIMENTAL ANALYSIS OF CHEMICAL VAPOR DEPOSITION OF ALUMINA FROM ALCL3-H2-CO2 GAS PHASE MIXTURES	N6	129	1367
COMNINELL.C, PLATTNER E ELECTROCHEMICAL PRODUCTION OF MANGANIC SULFATE IN CONCENTRATED H2SO4	N4	129	749
CONSTANT G *see* MORANCHO R		129	854
COOK GM *see* LIU M-B		129	239
COOK GM *see* LIU M-B		129	913
COOK GM *see* LIU M-B		129	1390
COOK GM *see* JORGENSE.JD		129	1678
COOK GM *see* LIU M-B		129	1955
COOK,JR CF *see* LAI JH		129	1596
COOPER G, TURNER JA, NOZIK AJ MOTT-SCHOTTKY PLOTS AND FLATBAND POTENTIALS FOR SINGLE CRYSTAL RUTILE ELECTRODES	N9	129	1973
CRAGNOLIN.G *see* SILVERMAN S		129	2419
CREEK G, OSTERYOU.RA AN ELECTROCHEMICAL AND INFRARED STUDY OF CHLORANIL IN N-BUTYLPYRIDINIUM CHLORIDE:ALUMINUM CHLORIDE IONIC LIQUID	N12	129	2739
CRETELLA MC, GREGORY JA HYDROGENATED A-SI(X)GE(1-X): A POTENTIAL SOLAR CELL MATERIAL	N12	129	2850
CRISMAN EE, ERCIL YM, LOFERSKI JJ, STILES PJ THE OXIDATION OF GERMANIUM SURFACES AT PRESSURES MUCH GREATER THAN ONE ATMOSPHERE	N8	129	1845
CROSBIE GM THERMODYNAMIC AND PHYSICAL PROPERTIES OF MOLTEN POTASSIUM POLYSULFIDES FROM OPEN-CIRCUIT VOLTAGE MEASUREMENTS	N12	129	2707
CROWDER BL *see* TING CY		129	2590
CULLEN GW *see* LAGOWSKI J		129	2609
CULLIS AG *see* ROBBINS DJ		129	816
CUMMINGS JR *see* PERKINS J		129	137
CUNNINGHA.B, STRUNK H, AST DG ELECTRON MICROSCOPY OF WEB-DENDRITIC SILICON	N5	129	1089
DABOSI F *see* MORANCHO R		129	854
DALESAND.DM *see* SWITZER JA		129	2232
DALLEK S *see* SZWARC R		129	1168
DAMJANOVI.A, YEH L-S R, WOLF JF FORMATION OF THIN OXIDE FILMS AT PLATINUM ANODES IN ALKALINE SOLUTIONS III. PH DEPENDENCE	N1	129	55
DANDAPANI B, GHALI E THE NATURE OF PASSIVATION OF LEAD SULFIDE DURING ANODIC DISSOLUTION IN HYDROCHLORIC ACID	N2	129	271
DARKEN,J.LS THE MEASUREMENT OF LOW LEVELS OF OXYGEN IN GERMANIUM BY THE LITHIUM PRECIPITATION TECHNIQUE	N1	129	226
DARLINGT.WB, WOO MYC REPORT ON THE ELECTROLYTIC INDUSTRIES FOR THE YEAR 1981	N8	129	275C
DATTA M, LANDOLT D PIT AND FLOW STREAK FORMATION DURING HIGH RATE DISSOLUTION OF NICKEL	N9	129	1889
DAUGHTON WJ, GIVENS FL AN INVESTIGATION OF THE THICKNESS VARIATION OF SPUN-ON THIN FILMSCOMMONLY ASSOCIATED WITH THE SEMICONDUCTOR INDUSTRY	N1	129	173
DAVIES PK F.M. BECKET AWARD REPORT--AN X-RAY POWDER DIFFRACTION STUDY OF PHASES IN THE SYSTEM CUO-NIO-MGO AT 1000 DEGREE C	N2	129	31C
DAZORD J *see* BOUIX J		129	2338
DE ANGELI.L, SCAFE E, GALLUZZI F, FORNARINI L, SCROSATI B LOCAL SPECTRAL RESPONSES OF TRANSITION METAL DICHALCOGENIDES IN PHOTOELECTROCHEMICAL CELLS	N6	129	1237
DE BENI G THERMOCHEMICAL PROCESSES FOR HYDROGEN PRODUCTION BY WATER SPLITTING: FROM THEORY TO PRACTICE	N1	129	67
DE BRUIN HJ *see* BADWAL SPS		129	1921
DE GROOT J *see* KUIPER AET		129	2288
DE JONGH.LC TRANSPORT NUMBER GRADIENTS AND SOLID ELECTROLYTE DEGRADATION	N4	129	752
DE L'PRE.AF, BUCHANAN RC PREPARATION AND PROPERTIES OF CA2V2O7 SINGLE CRYSTALS	N11	129	2562
DE MELE MFL, VIDELA HA, ARVIA AJ POTENTIODYNAMIC STUDY OF GLUCOSE ELECTRO-OXIDATION AT BRIGHT PLATINUM ELECTRODES	N10	129	2207
DEAL BE *see* RAZOUK RR		129	806
DEAL BE *see* LIE LN		129	2828
DEANHARD.ML, STERN KH SOLUBILITY OF YTTRIUM OXIDE IN NA2SO4 AND NACL MELTS	N10	129	2228
DEBNATH NC, ANDERSON AB OPTICAL SPECTRA OF FERROUS AND FERRIC OXIDES AND THE PASSIVE FILM: A MOLECULAR ORBITAL STUDY	N10	129	2169
DECARLO VJ *see* GLUGLA PG		129	1745
DEGENKOL.EO ALUMINUM SPUTTER ETCHING USING SICL4	N5	129	1150
DELFINO M, RAZOUK RR OPTICAL CONSTANTS OF ARSENIC AND BORON IMPLANTS IN SILICON DETERMINED BY A FOUR-PHASE COMPLEX REFRACTIVE INDEX MODEL	N3	129	606
DELGADO AB, CASTRO LAM, TRIACA WE, ARVIA AJ THE ADSORPTION AND THE POTENTIODYNAMIC ELECTRO-OXIDATION OF ACETYLENE ON PLATINIZED PLATINUM	N7	129	1493
DEMCZYK BG, LIU CT POTENTIAL DISTRIBUTION ON A CARBON-BASED BIFUNCTIONAL AIR ELECTRODE	N6	129	1159
DEPP SW *see* SEDGWICK TO		129	2802
DESLOUIS C, GABRIELLI C, SAINTE-R.P, TRIBOLLET B ELECTROHYDRODYNAMICAL IMPEDANCE ON A ROTATING DISK ELECTRODE I. REDOX SYSTEM	N1	129	107
DHAR HP, HOWELL DW, BOCKRIS JO THE USE OF IN SITU ELECTROCHEMICAL REDUCTION OF OXYGEN IN THE DIMINUTION OF ADSORBED BACTERIA ON METALS IN SEAWATER	N10	129	2178
DHOOGE PM, STILWELL DE, PARK S-M ELECTROCHEMICAL STUDIES OF COAL SLURRY OXIDATION MECHANISMS	N8	129	1719
DICKENS PG *see* JARMAN RH		129	2276
DIELEMAN J *see* SANDERS FHM		129	2559
DIGIUSEP.MA *see* CAMLIBEL I		129	2585
DIGNAM MJ *see* WEBER MF		129	2022
DIPAOLO FS *see* IYA SK		129	1531
DOHERTY CJ *see* MURARKA SP		129	293
DOHERTY CJ *see* LEWERENZ HJ		129	418
DOHERTY PE *see* THOMPSON GE		129	1515
DOMINEY RN THE JOSEPH W. RICHARDS SUMMER FELLOWSHIP REPORT--FOURIER TRANSFORM INFRARED STUDIES OF CHEMICALLY MODIFIED	N8	129	300C
DONAHUE FM, SAJKOWSK.DJ, BOSIO AC, SCHAFER LL KINETICS OF ELECTROLESS COPPER PLATING VI. INHIBITION BY ADSORPTION OF LIGAND	N4	129	717
DONG DW *see* IRENE EA		129	1347
DONG DW *see* LAI SK		129	2042
DONNELLY VM, FLAMM DL, TU CW, IBBOTSON DE TEMPERATURE DEPENDENCE OF INP AND GAAS ETCHING IN A CHLORINE PLASMA	N11	129	2533
DOUGIER P *see* GARCIA A		129	2063
DOVE DB *see* TAKAMORI T		129	2638
DRAGOO AL *see* CHIANG CK		129	2113
DRUMMOND TJ *see* MORKOC H		129	824
DUBOW J *see* THOMPSON L		129	1934
DUBOW J *see* THAPAR R		129	2009
DUTTON RW *see* MEI L		129	1791
DYER CK *see* ALWITT RS		129	711
DZIOBA S, ESTE G, NAGUIB HM DECAPSULATION AND PHOTORESIST STRIPPING IN OXYGEN MICROWAVE PLASMAS	N11	129	2537
EDWARDS JG *see* KSHIRSAG.ST		129	1835
ELDRIDGE JM *see* LEE MH		129	2174
ELDRIDGE JM *see* LERNER I		129	2270
ELDRIDGE JM *see* GRIMBLOT J		129	2366
ELDRIDGE JM *see* GRIMBLOT J		129	2369
ELLIS AB *see* STRECKER.HH		129	772
ELVEY TC *see* SHARP KG		129	2346
ELVING PJ *see* MALINSKI T		129	1960
ENSTROM RE, APPERT JR IMPROVING THE ELECTRICAL PROPERTIES OF VAPOR GROWN III-V COMPOUNDS BY COOLING THE HCL LIQUID SOURCE	N11	129	2566
EPHRATH LM DRY ETCHING FOR VLSI--A REVIEW	N3	129	62C
EPHRATH LM, BENNETT RS RIE CONTAMINATION OF ETCHED SILICON SURFACES	N8	129	1822
EPHRATH LM, PETRILLO EJ PARAMETER AND REACTOR DEPENDENCE OF SELECTIVE OXIDE RIE IN CF4 Δ H2	N10	129	2282
EPPS GF, BECKER RS THE PHOTOELECTROCHEMISTRY OF CDIN2S4	N11	129	2628
ERCIL YM *see* CRISMAN EE		129	1845
ERMANIS F *see* CAMLIBEL I		129	2585
ERNST DW X-RAY DIFFRACTION PATTERN AND DSC CURVES OF THE DISCHARGE PRODUCTOF THE LITHIUM/SULFUR DIOXIDE BATTERY	N3	129	565
ERNST DW DSC STUDY OF TWO REACTIONS IN THE LITHIUM-BORON ALLOY SYSTEM	N7	129	1513
EROR NG *see* BALACHAND.U		129	1021
ESASHI M *see* NAKAJIMA H		129	141
ESTE G *see* DZIOBA S		129	2537
FAHIDY TZ DESIGN OF ELECTROLYSIS UNDER COST-OPTIMAL THERMAL CONDITIONS	N5	129	953
FAIR RB, CARIM A ON THE DOPING DEPENDENCE OF OXIDATION-INDUCED STACKING FAULT SHRINKAGE IN SILICON	N10	129	2319
FAN F-R F, HOPE GA, BARD AJ SEMICONDUCTOR ELECTRODES XLVI. STABILIZATION OF N-SILICON ELECTRODES IN AQUEOUS SOLUTION PHOTOELECTROCHEMICAL CELLS BY FORMATION OF PLATINUM SILICIDE LAYERS	N7	129	1647
FAN F-R F *see* BULL RA		129	1009
FAN F-R F *see* NAGASUBRA.G		129	1742
FAN JCC *see* GEIS MW		129	2812
FARIAS MH *see* PENA JL		129	94
FARKAS J *see* KOVACS P		129	695
FAULKNER JK *see* GHANDEHA.MH		129	2666
FAUST,JR JW *see* PALIK ED		129	2051
FAVIER JJ STRIATIONS OF KINETIC ORIGIN INDUCED DURING NON-STEADY-STATE SOLIDIFICATION	N10	129	2355
FAWCETT WR *see* BARANSKI AS		129	901
FELDER EC *see* NAKAHARA S		129	45
FENG XK, MELENDRE.CA ANODIC CORROSION AND PASSIVATION BEHAVIOR OF SOME METALS IN MOLTEN LICL-KCL CONTAINING OXIDE IONS	N6	129	1245

Author / Title	Issue No.	Vol. No.	Page No.
FERRIS SD *see* LEWERENZ HJ		129	418
FEUILLADE G, BRESSAN J, WIART R THE KINETICS OF THE LITHIUM ELECTRODE DURING THE DISCHARGE OF LI/SOCL2 CELLS	N12	129	2649
FICHERA M *see* REVIE RW		129	669
FIELD RJ, GHANDHI SK AN OPEN-TUBE METHOD FOR DIFFUSION OF ZINC INTO GAAS	N7	129	1567
FIELDER WL *see* FRYBURG GC		129	571
FINE S *see* TAKAMORI T		129	2638
FINKLEA HO THE PREPARATION OF TIO2 ELECTRODES WITH MINIMUM MOTT-SCHOTTKY FREQUENCY DISPERSION	N9	129	2003
FISCHER CW, CANADAY JD GALVANOSTATIC ANODIZATION OF GAAS IN METHANOLIC KOH	N5	129	1016
FISCHER R *see* MORKOC H		129	824
FISHER AW *see* BLACKSTON.S		129	667
FISHER GL *see* SCARPELLA.J		129	515
FISHER GL *see* SCARPELLA.J		129	522
FJELDLY TA, JOHANNES.JS STUDY OF AGF-LAF3 REVERSIBLE INTERFACE BY AUGER SPECTROSCOPY AND IMPEDANCE TECHNIQUE	N3	129	660
FLAGELLA RN *see* IYA SK		129	1531
FLAMM DL, WANG DNK, MAYDAN D MULTIPLE-ETCHANT LOADING EFFECT AND SILICON ETCHING IN CIF3 AND RELATED MIXTURES	N12	129	2755
FLAMM DL *see* DONNELLY VM		129	2533
FLOWERS DL, HUGHES HG CHARACTERIZATION OF FUSED GLASS PASSIVATION WITH SELECTED DIODE STRUCTURES	N1	129	154
FLOWERS DL, WU S-Y DIFFUSION IN SILICON FROM A SPIN-ON HEAVILY PHOSPHORUS-DOPED OXIDE SOURCE	N10	129	2299
FOLEY RT, NGUYEN TH THE CHEMICAL NATURE OF ALUMINUM CORROSION V. ENERGY TRANSFER IN ALUMINUM DISSOLUTION	N3	129	464
FOLEY RT *see* NGUYEN TH		129	27
FOLEY RT *see* NGUYEN TH		129	780
FOLLER PC, TOBIAS CW THE ANODIC EVOLUTION OF OZONE	N3	129	506
FOLLER PC, TOBIAS CW THE MECHANISM OF THE DISINTEGRATION OF LEAD DIOXIDE ANODES UNDER CONDITIONS OF OZONE EVOLUTION IN STRONG ACID ELECTROLYTES	N3	129	567
FONSTAD CG *see* TABATABAI.K		129	2085
FORNARINI L, STIRPE F, SCROSATI B ELECTROCHEMICAL SOLAR CELLS WITH LAYER-TYPE SEMICONDUCTOR ANODES.NONAQUEOUS ELECTROLYTE CELLS	N5	129	1155
FORNARINI L *see* DE ANGELIL		129	1237
FOSTER M *see* ALLEN R		129	1379
FOUASSIER C *see* GARCIA A		129	2063
FOULKES FR *see* ITO Y		129	1936
FRANCESC.DR, MACDONAL.JR SMALL-SIGNAL A-C RESPONSE THEORY FOR ELECTROCHROMIC THIN FILMS	N8	129	1754
FRANK SN *see* BARNA GG		129	746
FRANK SN *see* BARNA GG		129	2464
FRANKENT.RP, SICONOLF.DJ THE ANODIC CORROSION OF GOLD IN CONCENTRATED CHLORIDE SOLUTIONS	N6	129	1192
FRANKLIN AD *see* CHIANG CK		129	2113
FRANSEN F *see* MADOU MJ		129	2749
FRANZEN HF *see* SHILO I		129	1608
FRANZEN HF *see* SHILO I		129	2613
FRASER DB *see* MURARKA SP		129	293
FRATESI R *see* MAJA M		129	2695
FRITTS DH THE MECHANICS OF ELECTROCHEMICALLY COPRECIPITATED COBALT HYDROXIDE IN NICKEL HYDROXIDE ELECTRODES	N1	129	118
FRITZER HP *see* GRUBER H		129	365
FRYBURG GC, KOHL PJ, STEARNS CA, FIELDER WL CHEMICAL REACTIONS INVOLVED IN THE INITIATION OF HOT CORROSION OFB-1900 AND NASA-TRW VIA	N3	129	571
FUJIHIRA M *see* MATSUE T		129	1681
FUJIMOTO T *see* ITAYA K		129	663
FUJITSU T *see* YASUAMI S		129	846
FURGALA AJ *see* ST.JOHN MR		129	246
FURMAN BK *see* MINAGAWA S		129	888
FURTAK TE *see* KESTER JJ		129	1716
GABRIELLI C *see* DESLOUIS C		129	107
GADOMSKI ST *see* JONES RL		129	1613
GAL-OR L *see* GELCHINS.MH		129	2433
GALASCO RT *see* LIU CD		129	2502
GALLUZZI F *see* DE ANGELIL		129	1237
GARCIA A, FOUASSIER C, DOUGIER P PHOTO- AND CATHODOLUMINESCENT PROPERTIES OF ERBIUM-DOPED THIOGALLATES	N9	129	2063
GARNER CM *see* SEXTON FW		129	2624
GASIOR W *see* MOSER Z		129	502
GATOS HC *see* YANG XF		129	194
GATOS HC *see* PARSEY JM		129	388
GATOS HC *see* BECLA P		129	1103
GATOS HC *see* OKAMOTO A		129	2095
GATOS HC *see* RAVA P		129	2844
GATOS HC *see* BECLA P		129	2855
GAUTHIER M, VASSORT G, BELANGER A, ADAMS WA ELECTROCHEMICAL STUDIES ON LITHIUM INTERCALATION MATERIALS IN MOLTEN SALTS	N5	129	970
GAW CA *see* SWAMINATH.V		129	1563
GAY EC *see* MARTINO FJ		129	2701
GEIPEL HJ *see* KOBURGER CW		129	1307
GEIPEL HJ *see* WHITE FR		129	1330
GEIS MW, SMITH HI, TSAUR B-Y, FAN JCC, SILVERSM.DJ, MOUNTAIN RW ZONE-MELTING RECRYSTALLIZATION OF SI FILMS WITH A	N12	129	2812
GEIS MW *see* BEZJIAN KA		129	1848
GEISS RH *see* SEDGWICK TO		129	2802
GELCHINS.MH, GAL-OR L, YAHALOM J PULSE PLATING OF CHROMIUM--COBALT ALLOYS CONTAINING A PHASE WITH THE A--15 STRUCTURE	N11	129	2433
GENTAZ C *see* BONOMI A		129	102
GERONOV Y, SCHWAGER F, MULLER RH ELECTROCHEMICAL STUDIES OF THE FILM FORMATION ON LITHIUM IN PROPYLENE CARBONATE SOLUTIONS UNDER OPEN-CIRCUIT CONDITIONS	N7	129	1422
GESMUNDO F, VIANI F PARABOLIC GROWTH OF NONUNIFORMLY DOPED OXIDES CONTAINING ALIOVALENT IMPURITIES ON DILUTE ALLOYS	N3	129	622
GHALI E *see* DANDAPANI B		129	271
GHANDEHA.MH, FAULKNER JK, SCHUSSLER M SELECTIVE DISSOLUTION OF THE BINDER PHASE ALLOY (CO-W) FROM WC-CO CEMENTED CARBIDES IN PARTICULATE BED ELECTRODE SYSTEMS	N12	129	2666
GHANDHI SK, REEP DH THE USE OF S2CL2 FOR DOPING POLY-GAAS FILMS GROWN BY THE ORGANOMETALLIC PROCESS	N12	129	2778
GHANDHI SK *see* WHITELEY JS		129	383
GHANDHI SK *see* FIELD RJ		129	1567
GHEZZO M *see* CHOW TP		129	1040
GHEZZO M *see* COHEN SS		129	1335
GHIDINI G *see* SMITH FW		129	1300
GIAM K-K *see* PRYOR MJ		129	2157
GIBBONS JF *see* MINAGAWA S		129	888
GILDENBLA.G *see* COHEN SS		129	1335
GILING LJ GAS FLOW PATTERNS IN HORIZONTAL EPITAXIAL REACTOR CELLS OBSERVED BY INTERFERENCE HOLOGRAPHY	N3	129	634
GILMAN S *see* BINDER M		129	897
GINLEY DS, BIEFELD RM, PARKINSO.BA, KEUNG-KAM K POLYCRYSTALLINE WSE2 PHOTOELECTRODES	N1	129	145
GINLEY DS, CHAMBERL.MB INTERFACIAL CHEMISTRY AT P-GAP PHOTOELECTRODES	N9	129	2141
GIORDANO MC *see* CARBONIO RE		129	983
GIPSTEIN E, OUANO AC, TOMPKINS T EVALUATION OF PURE NOVOLAK CRESOL-FORMALDEHYDE RESINS FOR DEEP U.V. LITHOGRAPHY	N1	129	201
GISSLER W, MCEVOY AJ, GRAETZEL M THE EFFECT OF SPUTTERED RUO2 OVERLAYERS ON THE	N8	129	1733
GIVENS FL *see* DAUGHTON WJ		129	173
GIVENS RB *see* BARGERON CB		129	340
GLARUM SH, MARSHALL JH THE A-C RESPONSE OF NICKEL OXIDE ELECTRODE FILMS	N3	129	535
GLASPER JL *see* ROBBINS DJ		129	816
GLUGLA PG, DECARLO VJ THE SPECIFIC CONDUCTANCE OF MOLTEN CARBONATE FUEL CELL TILES	N8	129	1745
GOLDMAN JL *see* KOCH VR		129	1
GOLDMAN JL *see* ABRAHAM KM		129	2404
GOLDSTEIN R *see* ROYCE BSH		129	2393
GOMES WP *see* VANMAEKELB		129	546
GOMES WP *see* MADOU MJ		129	2749
GOODEN R, MITCHELL JW PHOTOCHEMICAL PRODUCTION, INFRARED ABSORPTIVITY, AND CHEMICAL REACTIONS OF TRICHLOROSILANOL IN SILICON TETRACHLORIDE	N7	129	1619
GOODWIN CA, BROSSMAN JW MOS GATE OXIDE DEFECTS RELATED TO TREATMENT OF SILICON NITRIDE COATED WAFERS PRIOR TO LOCAL OXIDATION	N5	129	1066
GRAETZEL M *see* GISSLER W		129	1733
GRAF V *see* SEDGWICK TO		129	2802
GRAHAM KJ *see* PERKINS J		129	137
GRANATA RD *see* LEIDHEISE.H		129	1651
GRASSERBA.M *see* GUERRERO E		129	1826
GRAY HF *see* PALIK ED		129	2051
GREBE K *see* TING CY		129	859
GREENE RF *see* PALIK ED		129	2051
GREENSTEI.Y *see* TENNE R		129	1506
GREGORY JA *see* CRETELLA MC		129	2850
GRIFFITH.JE *see* SCHWARTZ GP		129	1361
GRIMBLOT J, ELDRIDGE JM I. INTERACTION OF AL FILMS WITH O2 AT LOW PRESSURES	N10	129	2366
GRIMBLOT J, ELDRIDGE JM II. OXIDATION OF AL FILMS	N10	129	2369
GRUBER H, HESS H, POPITSCH A, FRITZER HP CONDUCTIVITY, PHOTOCONDUCTIVITY, AND LUMINESCENCE STUDIES ON SOME SILVERSULFAMIDES	N2	129	365
GUERCHAI.JE *see* SAVY M		129	1409
GUERRERO E, POTZL H, TIELERT R, GRASSERBA.M, STINGEDER G GENERALIZED MODEL FOR THE CLUSTERING OF AS DOPANTS IN SI	N8	129	1826
GUO SF, CHEN WS A MODEL FOR BORON DEPOSITION IN SILICON USING A B8R3 SOURCE	N7	129	1592
GUPTA KC, KAUR T POLAROGRAPHY OF O-MERCAPTOBENZOIC ACID IN AQUEOUS METHANOL AND DIOXANE	N1	129	90
GUYOMARD D *see* VAN AMERO.G		129	1998
GWYTHER JR *see* HOBDELL MR		129	2746
HAAK R, OGDEN C, TENCH D ELECTROCHEMICAL PHOTOCAPACITANCE SPECTROSCOPY: A NEW METHOD FOR CHARACTERIZATION OF DEEP LEVELS IN SEMICONDUCTORS	N4	129	891
HACKERMAN N *see* KAPUSTA S		129	1866
HADATE M *see* BONOMI A		129	102
HADE A *see* ANTOUN H		129	40
HAEMMERLI A, JANATA J, BROPHY JJ EQUILIBRIUM NOISE IN ION SELECTIVE FIELD EFFECT TRANSISTORS	N10	129	2306
HALL DE POROUS NICKEL-COATED STEEL ANODES FOR ALKALINE WATER ELECTROLYSIS: CORROSION RESISTANCE	N2	129	310
HALL JC *see* SALMON DJ		129	2496
HALLER I POLYMERIZATION OF AROMATIC SILANES IN RF PLASMAS	N1	129	180
HANCHETT VE *see* SEDGWICK TO		129	2802
HANEMAN D *see* MCCANN JF		129	1134
HANTZPER.JJ *see* PAULEAU Y		129	1045
HARADA H *see* MIYAKE M		129	1097
HARADA H *see* SATO Y		129	1635
HARADA K, TAMAMURA T, KOGURE O DETAILED CONTRAST (GAMMA-VALUE) MEASUREMENTS OF POSITIVE ELECTRONRESISTS	N11	129	2576
HARADA S *see* SAIKI A		129	2278
HARMON DL *see* WHITE FR		129	1330
HARRIS LA THIN PALLADIUM FILMS ON SILICON AND TITANIUM	N12	129	2689
HARTMANN HS, SUTULA RA ALUMINA 'FIBER FP' REINFORCED PURE LEAD COMPOSITES FOR BATTERY ELECTRODES	N8	129	1749

Author — Title — Issue No. — Vol. No. — Page No.

HARTNAGE.HL *see* SCHMOLLA W — 129 2636
HARTSTEIN A *see* LAI SK — 129 2042
HASHIMOTO C *see* SHIONO N — 129 1760
HATTORI S *see* YAMADA M — 129 2598
HAYAFUJI Y, KAJIWARA K — N9 129 2102
NITRIDATION OF SILICON AND OXIDIZED-SILICON
HEATH BA — N2 129 396
SELECTIVE REACTIVE ION BEAM ETCHING OF SIO2 OVER
HEATHERL.DE *see* VALLET CE — 129 49
HEATHERL.DE *see* VALLET CE — 129 931
HEIDERSB.RH *see* KEISER JT — 129 2686
HEINDL R *see* VAN AMERO.G — 129 1998
HELLER A *see* LEVY-CLEM.C — 129 1701
HENDRIKX J *see* ABYANEH MY — 129 2654
HENRICKS LL *see* SALMON DJ — 129 2496
HENRY W *see* BLACKSTON.S — 129 667
HEPEL M *see* HEPEL T — 129 2132
HEPEL T, HEPEL M, OSTERYOU.RA — N9 129 2132
THERMODYNAMIC AND PHOTOELECTROCHEMICAL BEHAVIOR OF THE N-TIO2 ELECTRODE IN FLUORIDE-CONTAINING SOLUTIONS
HERLEM M *see* VAN AMERO.G — 129 1998
HERMOLIN J *see* WEBBER A — 129 2725
HESHMATPO.B, STEVENSO.DA — N2 129 430
THE INFLUENCE OF SOLUTE ADDITIONS OF COPPER AND SILVER ON THE DIFFUSIVITY AND THERMODYNAMIC PROPERTIES OF OXYGEN IN LIQUID INDIUM
HESS DW *see* NAGY AG — 129 2530
HESS H *see* GRUBER H — 129 365
HEZEL R, LIESKE N — N2 129 379
ROOM TEMPERATURE FORMATION OF SI-NITRIDE FILMS BY LOW ENERGY NITROGEN ION IMPLANTATION INTO SILICON
HIBBERT DB *see* RASIYAH P — 129 1724
HIGUCHI H *see* MIZUO S — 129 2292
HILL M, LIETZ M, SITTIG R — N7 129 1579
DIFFUSION OF GOLD IN SILICON
HILLEL R, BEC C, BOUIX J, MICHAELID.A, MONTEIL Y, TRANQUARD A, BERNARD C — N6 129 1343
THERMODYNAMICS AND KINETICS OF IODINE CHEMICAL VAPOR TRANSPORT OFGEAS
HINDAM H, WHITTLE DP — N5 129 1147
PEG FORMATION BY SHORT-CIRCUIT DIFFUSION IN AL2O3 SCALES CONTAINING OXIDE DISPERSIONS
HIRABAYAS.K, ITOH Y — N2 129 362
DETERIORATED A-C POWDER EL CELL BRIGHTNESS RECOVERY
HIRABAYAS.K, ITOH Y, MURASE K — N9 129 2059
ETCHING EFFECT ON AC POWDER EL PHOSPHOR BRIGHTNESS AND MAINTENANCE
HIRABAYAS.K *see* ITOH Y — 129 813
HIRAO T *see* ONUMA T — 129 837
HO W-T *see* JORNE J — 129 907
HOARE JP — N7 129 1438
AN ESTIMATE OF THE HEAT OF ADSORPTION OF THE HYDROPEROXYL RADICALON PLATINUM
HOBDELL MR, TREVILLI.EA, GWYTHER JR, TYFIELD SP — N12 129 2746
CALIBRATION TESTS OF AN ELECTROCHEMICAL CARBON METER
HOFFMAN RW *see* TJONG SC — 129 1662
HOGENMULL.P *see* COLMET R — 129 1367
HOLMES DE *see* CHEN RT — 129 2382
HOLMSTROM B *see* CARLSSON P — 129 1851
HOMOLA A *see* LERNER I — 129 1865
HOPE GA *see* FAN F-R F — 129 1647
HOPE GA *see* ABRUNA HD — 129 2224
HOROWITZ HH *see* BERKOWIT.BJ — 129 468
HORWATH RS *see* ZAROWIN CB — 129 2541
HOWELL DW *see* DHAR HP — 129 2178
HSU L-C, SHEIBLEY DW — N2 129 251
INEXPENSIVE CROSS-LINKED POLYMERIC SEPARATORS MADE FROM WATER-SOLUBLE POLYMERS
HU SM *see* BROWN DK — 129 1084
HUANG L *see* YANG XF — 129 194
HUGHES HG *see* FLOWERS DL — 129 154
HURD JL *see* CISZEK TF — 129 2838
HUTCHISO.JL *see* MOSELEY PT — 129 876
HUTH BG *see* SEDGWICK TO — 129 2802
IBBOTSON DE *see* DONNELLY VM — 129 2533
IBRAHIM EM *see* LEIDHEISE.H — 129 1651
IDA M *see* IMAI Y — 129 221

IHARA M, ARIMOTO Y, JIFUKU M, KIMURA T, KODAMA S, YAMAWAKI H, YAMAOKA T — N11 129 2569
VAPOR PHASE EPITAXIAL GROWTH OF MGO.AL2O3
II M *see* KANAI F — 129 2633
ILIEV V, PAVLOV D — N3 129 458
SELF-DISCHARGE AND PASSIVATION PHENOMENA IN LEAD-ACID BATTERIES DURING STORAGE
IMAI Y, ISHIBASHI T, IDA M — N1 129 221
CHARACTERISTICS OF INP MIS SCHOTTKY DIODES PREPARED BY PLASMA OXIDATION
INGANAS O *see* SKOTHEIM T — 129 1737
INOUE N, OSAKA J, WADA K — N12 129 2780
OXIDE MICRO-PRECIPITATES IN AS-GROWN CZ SILICON
IRENE EA — N2 129 413
SILICON OXIDATION STUDIES: MEASUREMENT OF THE DIFFUSION OF OXIDANT IN SIO2 FILMS
IRENE EA, DONG DW — N6 129 1347
ELLIPSOMETRY MEASUREMENTS OF POLYCRYSTALLINE SILICON FILMS
IRENE EA, TIERNEY E, ANGILELLO J — N11 129 2594
A VISCOUS FLOW MODEL TO EXPLAIN THE APPEARANCE OF HIGH DENSITY THERMAL SIO2 AT LOW OXIDATION TEMPERATURES
ISAACS HS, OLMER LJ — N2 129 436
COMPARISON OF MATERIALS AS OXYGEN CATALYTIC ELECTRODES ON ZIRCONIA ELECTROLYTE
ISAACS HS *see* OLMER LJ — 129 345
ISHAQ M *see* KOBURGER CW — 129 1307
ISHIBASHI T *see* IMAI Y — 129 221
ISHIKAWA H *see* ITO T — 129 184
ISHIKAWA Y, SAKINA Y, TANAKA H, MATSUMOTO H, NIIMI T — N3 129 644
THE ENHANCED DIFFUSION OF ARSENIC AND PHOSPHORUS IN SILICON BY THERMAL OXIDATION
ISOZUMI S *see* OKAMOTO A — 129 2095
ISTONE WK, BRODD RJ — N8 129 1853
ON THE MECHANISM OF THIONYL CHLORIDE REDUCTION
ITAYA K, SHIBAYAMA K, FUJIMOTO T — N3 129 663
HIGH RESOLUTION ELECTRON BEAM NEGATIVE RESIST WITH VERY NARROW MOLECULAR WEIGHT DISTRIBUTIONS
ITAYA K, AKAHOSHI H, TOSHIMA S — N4 129 762
POLYMER-MODIFIED ELECTRODES II. SPECTROELECTROCHEMICAL PROPERTIESOF A LIGAND (BATHOPHENANTHROLINE DISULFONIC ACIDD) BOUND TO POLYELECTROLYTES ON ELECTRODES AND THE USE OF THE MODIFIED ELECTRODES FOR AN ELECTROCHROMIC DISPLAY DEVICE
ITAYA K, AKAHOSHI H, TOSHIMA S — N7 129 1498
ELECTROCHEMISTRY OF PRUSSIAN BLUE MODIFIED ELECTRODES: AN ELECTROCHEMICAL PREPARATION METHOD
ITO T, NAKAMURA T, ISHIKAWA H — N1 129 184
EFFECT OF THERMALLY NITRIDED SIO2 (NITROXIDE) ON MOS CHARACTERISTICS
ITO Y, FOULKES FR, YOSHIZAWA S — N9 129 1936
ENERGY ANALYSIS OF A STEADY-STATE ELECTROCHEMICAL REACTOR
ITOH Y, HIRABAYAS.K, MURASE K — N4 129 813
THE ELECTROLUMINESCENCE OF ZNS:CU, BR PHOSPHOR
ITOH Y *see* HIRABAYAS.K — 129 362
ITOH Y *see* HIRABAYAS.K — 129 2059
ITSUMI M, KIYOSUMI F — N4 129 800
IDENTIFICATION AND ELIMINATION OF GATE OXIDE DEFECT ORIGIN PRODUCED DURING SELECTIVE FIELD OXIDATION
IWAMATSU S — N1 129 224
EFFECTS OF PLASMA CLEANING ON THE DIELECTRIC BREAKDOWN IN SIO2 FILM ON SI
IWANE G *see* ADACHI S — 129 883
IYA SK, FLAGELLA RN, DIPAOLO FS — N7 129 1531
HETEROGENEOUS DECOMPOSITION OF SILANE IN A FIXED BED REACTOR
JACOB KT *see* SHIM WW — 129 1116
JACOBSEN T *see* WEST K — 129 1480
JAIN GC *see* PRASAD A — 129 596
JAIN SK *see* PRASAD A — 129 596
JANATA J *see* HAEMMERLI A — 129 2306
JANATA J *see* BLACKBURN G — 129 2580
JANECKI MC *see* ZIMMERMA.AH — 129 289
JANG J, LEE K, LEE C — N12 129 2770
DETERMINATION OF POSITIVE MOBILE ION DENSITY IN SILICON DIOXIDE BY HYDROGENATED AMORPHOUS SILICON FIELD EFFECT TECHNIQUE

JANNAKOU.DA *see* ANASTOPO.AG — 129 2547
JARMAN RH, DICKENS PG — N10 129 2276
ELECTROCHEMICAL INSERTION OF HYDROGEN IN WO3
JASINSKI R *see* BRILMYER G — 129 1950
JASTRZEBS.L, ZANZUCCHI P, THEBAULT D, LAGOWSKI J — N7 129 1638
METHOD TO MEASURE THE PRECIPITATED AND TOTAL OXYGEN CONCENTRATIONIN SILICON
JASTRZEBS.L *see* BLACKSTON.S — 129 667
JASTRZEBS.L *see* LAGOWSKI J — 129 2609
JEDRAL L *see* BECLA P — 129 2855
JIFUKU M *see* IHARA M — 129 2569
JODLAUK CM *see* CHU SNG — 129 352
JOHANNES.JS *see* FJELDLY TA — 129 660
JOHNSON JW, BRODY JF — N10 129 2213
LITHIUM CLOSOBORANE ELECTROLYTES III. PREPARATION AND CHARACTERIZATION
JONES RL, GADOMSKI ST — N7 129 1613
REACTIONS OF SO2(SO3) WITH NIO-NA2SO4 IN NICKEL-SODIUM MIXED SULFATE FORMATION AND LOW TEMPERATURE HOT CORROSION
JORDAN AG *see* LEARY DJ — 129 1382
JORGENSE.JD, VARMA R, ROTELLA FJ, COOK GM, YAO NP — N8 129 1678
LEAD DEFICIENCY AND HYDROGEN CONTENT IN BATTERY ELECTRODE BETA-PBO2
JORGENSE.JD *see* BRUN TO — 129 2509
JORNE J — N4 129 722
THE ANOLYTE DIFFUSION LAYER AND ITS EFFECT ON HYDROXYL TRANSPORT THROUGH NAFION MEMBRANE IN CHLOR-ALKALI CELL
JORNE J, HO W-T — N5 129 907
TRANSFERENCE NUMBERS OF ZINC IN ZINC-CHLORIDE BATTERY ELECTROLYTES
JORNE J — N8 129 1727
MASS TRANSFER IN LAMINAR FLOW CHANNEL WITH POROUS WALL
JORNE J — N10 129 2251
FLOW DISTRIBUTION IN THE ZINC-CHLORIDE BATTERY
JOSQUIN WJM, TAMMINGA Y — N8 129 1803
THE OXIDATION INHIBITION IN NITROGEN-IMPLANTED SILICON
JOVANCICE.V *see* BERGE P — 129 2194
JOW TR, LIANG CC — N7 129 1429
LITHIUM-ALUMINUM ELECTRODES AT AMBIENT TEMPERATURES
JUZA J, CERMAK J — N7 129 1627
PHENOMENOLOGICAL MODEL OF THE CVD EPITAXIAL REACTOR
KAINTHLA RC, PANDYA DK, CHOPRA KL — N1 129 99
STRUCTURAL AND OPTICAL PROPERTIES OF SOLUTION GROWN CDSE(1-X)S(X)FILMS
KAJIWARA K *see* HAYAFUJI Y — 129 2102
KALEJS JP, CHIN L-Y — N6 129 1356
MODELING OF AMBIENT-MENISCUS MELT INTERACTIONS ASSOCIATED WITH CARBON AND OXYGEN TRANSPORT IN EFG OF SILICON RIBBON
KAMIENIEC.E *see* BAGLIO JA — 129 1461
KAMINS TI, CHIANG KL — N10 129 2326
PROPERTIES OF PLASMA-ENHANCED CVD SILICON FILMS I. UNDOPED FILMS DEPOSITED FROM 525 DEGREE TO 725 DEGREE C
KAMINS TI, CHIANG KL — N10 129 2331
PROPERTIES OF PLASMA-ENHANCED CVD SILICON FILMS II. FILMS DOPED DURING DEPOSITION
KANAI F, KURITA S, SUGIOKA S, II M, MITA Y — N11 129 2633
OPTICAL CHARACTERISTICS OF WO3 ELECTROCHROMIC CELLS UNDER HEAVY LI ION INJECTION
KANNAM PJ, MUROSAKO R, BRIERE T — N3 129 656
THE EFFECT OF PROCESSING PARAMETERS ON THE LIFETIME OF (HG,CD)TE MATERIAL
KANNO K-I *see* SUZUKI M — 129 2183
KANO T, KINAMERI K, SEKI S — N10 129 2296
A RED PHOSPHOR OF HIGH LUMEN EQUIVALENT, Y2W3O12:EU(3+)
KANOMATA I *see* SUZUKI K — 129 2764
KAPELNER S *see* SMITH SW — 129 1668
KAPUSTA S, HACKERMAN N — N9 129 1886
OPTICAL STUDIES OF THE ANODIC PASSIVATION OF TIN
KASHIWAGI M *see* SHIBATA K — 129 1527
KASTL RH *see* BEYER KD — 129 1027
KATO C *see* ZAMANZADE.M — 129 284
KATO Z *see* TANABE I — 129 2372
KATZ LE *see* ROBINSON M — 129 2858
KAUR T *see* GUPTA KC — 129 90
KAWAGUCHI H *see* ADACHI S — 129 883

Author Title	Issue No.	Vol. No.	Page No.
KAWAGUCHI H *see* ADACHI S		129	1053
KAWAGUCHI H *see* ADACHI S		129	1524
KAWAMURA T *see* TSUYA H		129	374
KAWATA H, SHIBANO T, MURATA K, NAGAMI K THE RELATION BETWEEN ETCH RATE AND OPTICAL EMISSION INTENSITY IN PLASMA ETCHING	N6	129	1325
KAY E *see* MILLARD MM		129	160
KEISER JT, BROWN CW, HEIDERSB.RH THE ELECTROCHEMICAL REDUCTION OF RUST FILMS ON WEATHERING STEEL SURFACES	N12	129	2686
KELLEY JD, MARTIN BG, SZOFRAN FR, LEHOCZKY SL APPLICATION OF THE REGULAR ASSOCIATED SOLUTION MODEL TO THE CD-TE AND HG-TE BINARY SYSTEMS	N10	129	2360
KELLY JJ, MEMMING R THE INFLUENCE OF SURFACE RECOMBINATION AND TRAPPING ON THE CATHODIC PHOTOCURRENT AT P-TYPE III-V ELECTRODES	N4	129	730
KENEFICK K SELECTIVE ETCHING CHARACTERISTICS OF PEROXIDE/AMMONIUM-HYDROXIDE SOLUTIONS FOR GAAS/AL0.16GA0.84AS	N10	129	2380
KENNEDY JH, KIMURA N, STUBER SM MEASUREMENT OF ELECTRONIC CONDUCTIVITY IN FE-DOPED BETA-ALUMINA	N9	129	1968
KEPPLER U WHITLOCKITE PHASE IN THE LUMINESCENT SYSTEM SRO-LI2O5-P2O5:MN, CE	N6	129	1373
KERBEL H *see* ZAHAVI J		129	1572
KERMAMID.VG *see* MAHAJAN S		129	1556
KERR RL *see* VACCARO AJ		129	677
KERR RL *see* VACCARO AJ		129	682
KERSHAW R *see* BAGLIO JA		129	1461
KERWIN L THE CONSTANT HELPER: STEADFASTNESS AS A KEY INGREDIENT OF R&D	N10	129	393C
KESTER JJ, FURTAK TE, BEVOLO AJ SURFACE ENHANCED RAMAN SCATTERING IN CORROSION SCIENCE: BENZOTRIAZOLE ON COPPER	N8	129	1716
KEUNG-KAM K *see* GINLEY DS		129	145
KIDD LM *see* VALLET CE		129	931
KIDO H *see* TANABE I		129	2372
KIM KM SUPPRESSION OF THERMAL CONVECTION BY TRANSVERSE MAGNETIC FIELD	N2	129	427
KIMERLIN.LC *see* BENTON JL		129	2098
KIMURA N *see* KENNEDY JH		129	1968
KIMURA T *see* IHARA M		129	2569
KINAMERI K *see* KANO T		129	2296
KING C-W *see* WU C-Y		129	1559
KING TB *see* CARLBERG T		129	189
KINOSHITA K, KUCERA GH ANALYSIS OF THE COMPRESSIVE STRENGTH OF LIALO2/MOLTEN CARBONATE STRUCTURES	N1	129	216
KINOSHITA K, LEACH SC SESSILE DROP STUDIES ON POLYBROMIDE/ZINC-BROMINE BATTERY ELECTROLYTE	N8	129	1747
KINOSHITA K, LEACH SC MASS-TRANSFER STUDY OF CARBON FELT, FLOW-THROUGH ELECTRODE	N9	129	1993
KINOSHITA K, LEACH SC, ABLOW CM BROMINE REDUCTION IN A TWO-PHASE ELECTROLYTE	N11	129	2397
KINOSHITA K *see* O'SULLIVA.D		129	811
KIRCHNER GD *see* VYAS HP		129	1757
KIROWA-EI.E *see* RELLER H		129	1473
KIROWA-EI.E *see* WEBBER A		129	2725
KISACKY GA *see* MYERS CE		129	2343
KISS L *see* KOVACS P		129	695
KITA H *see* UOSAKI K		129	1752
KITAHARA K, NAKAI K, SHIBATOMI S ONE-DIMENSIONAL PHOTOLUMINESCENCE DISTRIBUTION IN SEMI-INSULATINGGAAS GROWN BY CZ AND HB METHODS	N4	129	880
KIYOSUMI F *see* ITSUMI M		129	800
KLEMANN LP, NEWMAN GH AMBIENT TEMPERATURE K-TIS2 CELL	N1	129	230
KOBAYASHI A *see* UMEZAWA Y		129	2378
KOBAYASHI K *see* SONG SH		129	841
KOBURGER CW, ISHAQ M, GEIPEL HJ ELECTRICAL PROPERTIES OF COMPOSITE EVAPORATED	N6	129	1307
KOBURGER CW *see* WHITE FR		129	1330
KOCH VR, GOLDMAN JL, MATTOS CJ, MULVANEY M SPECULAR LITHIUM DEPOSITS FROM LITHIUM HEXAFLUOROARSENATE/DIETHYLETHER ELECTROLYTES	N1	129	1
KODAMA S *see* IHARA M		129	2569
KOGURE O *see* HARADA K		129	2576
KOHL FJ *see* FRYBURG GC		129	571
KOHL PA THE HIGH SPEED ELECTRODEPOSITION OF SN/PB ALLOYS	N6	129	1196
KOIZUMI H *see* MIYAZAWA S		129	2335
KOLODNEY M PREPARATION OF THE FIRST ELECTROLYTIC PLUTONIUM AND OF URANIUM FROM FUSED CHLORIDES	N11	129	2438
KOLTHOFF IM OLIN PALLADIUM MEDAL ADDRESS--ELECTRO(ANALYTICAL) CHEMISTRY EARLYTHIS CENTURY	N3	129	59C
KONAGAI M *see* MASU K		129	1623
KOPP W *see* MORKOC H		129	824
KORDESCH KV *see* OLENDER H		129	135
KOROTKINA O *see* ZAHAVI J		129	1572
KOSTLIN H *see* SCHAPER H		129	1289
KOUDELKA M, SANCHEZ J, AUGUSTYNS.J ON THE NATURE OF SURFACE FILMS FORMED ON IRON IN AGGRESSIVE AND INHIBITING POLYPHOSPHATE SOLUTIONS	N6	129	1186
KOVACS P, FARKAS J, TAKACS L, AWAD MZ, VERTES A, KISS L, LOVAS A EFFECT OF COMPOSITION AND THE PROCESSING PARAMETERS ON THE ELECTROCHEMICAL CORROSION OF IRON-BORON METALLIC GLASSES	N4	129	695
KROGER FA *see* LEE CH		129	936
KRUMPELT M *see* BROWN AP		129	2481
KSHIRSAG.ST, THOMPSON HB, EDWARDS JG VAPORIZATION CHEMISTRY AND THERMODYNAMICS OF SOLID SOLUTIONS IN THE CADMIUM-INDIUM-SULFIDE, INDIUM-SULFIDE SYSTEM	N8	129	1835
KUBIAK CP *see* BAGLIO JA		129	1461
KUCERA GH *see* KINOSHITA K		129	216
KUDO K *see* SONG SH		129	841
KUIPER AET, VAN DEN .CJ, DE ROOT J, VELTKAMP GW MODELING OF LOW-PRESSURE CVD PROCESSES	N10	129	2288
KUNZ HR *see* BREGOLI LJ		129	2711
KUO KN, MURRAY RW ACTIVATION OF RUO2 AND PTO ELECTRODE SURFACES FOR IMMOBILIZATION REACTIONS USING THIONYL CHLORIDE	N4	129	756
KURITA S *see* KANAI F		129	2633
KURODA K, CAHAN BD, NAZRI G, YEAGER E, MITCHELL TE ELECTRON DIFFRACTION STUDY OF THE PASSIVE FILM ON IRON	N10	129	2163
KUROKAWA H P-DOPED POLYSILICON FILM GROWTH TECHNOLOGY	N11	129	2620
KWARK Y, SWANSON RM OPTICAL ABSORPTION OF THIN SIPOS FILMS	N1	129	197
KWARK Y *see* MEI L		129	1791
KWIATKOW.JH *see* LAI JH		129	1596
LAGOWSKI J, JASTRZEBS.L, CULLEN GW MICROSCALE CHARACTERIZATION OF HETEROEPITAXIAL SILICON ON SAPPHIRE BY SCANNING PHOTOVOLTAGE MEASUREMENTS	N11	129	2609
LAGOWSKI J *see* PARSEY JM		129	388
LAGOWSKI J *see* BECLA P		129	1103
LAGOWSKI J *see* JASTRZEBS.L		129	1638
LAGOWSKI J *see* OKAMOTO A		129	2095
LAGOWSKI J *see* RAVA P		129	2844
LAGOWSKI J *see* BECLA P		129	2855
LAI JH, KWIATKOW.JH, COOK.JR CF STUDIES OF METHACRYLONITRILE AND TRICHLOROETHYL METHACRYLATE COPOLYMERS AS ELECTRON SENSITIVE POSITIVE RESISTS	N7	129	1596
LAI SK, DONG DW, HARTSTEIN A EFFECTS OF AMMONIA ANNEAL ON ELECTRON TRAPPINGS IN SILICON DIOXIDE	N9	129	2042
LAIRD EC *see* BULLOCK KR		129	1393
LANDOLT D *see* SAUTEBIN R		129	946
LANDOLT D *see* DATTA M		129	1889
LANGMUIR ME, PARKER MA, RAUH RD ELECTROCHEMICAL PHOTOVOLTAIC CELLS BASED ON N-GAAS AND THE TRIIODIDE/IODIDE REDOX COUPLE IN ACETONITRILE	N8	129	1705
LARRICK BF *see* SZWARC R		129	1168
LATANISI.RM *see* TSURU T		129	1402
LEACH SC *see* KINOSHITA K		129	1747
LEACH SC *see* KINOSHITA K		129	1993
LEACH SC *see* KINOSHITA K		129	2397
LEAMY HJ *see* LEWERENZ HJ		129	418
LEARY DJ, BARNES JO, JORDAN AG CALCULATION OF CARRIER CONCENTRATION IN POLYCRYSTALLINE FILMS AS A FUNCTION OF SURFACE ACCEPTOR STATE DENSITY: APPLICATION FOR ZNOGAS SENSORS	N6	129	1382
LEE C *see* JANG J		129	2770
LEE CH, KROGER FA CATHODIC DEPOSITION OF AMORPHOUS ALLOYS OF SILICON, CARBON, AND FLUORINE	N5	129	936
LEE CH HEAT-TREATMENT EFFECT ON BORON IMPLANTATION IN POLYCRYSTALLINE SILICON	N7	129	1604
LEE J, SELMAN JR EFFECTS OF SEPARATOR AND TERMINAL ON THE CURRENT DISTRIBUTION IN PARALLEL-PLATE ELECTROCHEMICAL FLOW REACTORS	N8	129	1670
LEE K *see* JANG J		129	2770
LEE M-K *see* WU C-Y		129	1559
LEE MH, ELDRIDGE JM, LICLICAN L, RICHARDS.RE ELECTROCHEMICAL TEST TO EVALUATE PASSIVATION LAYERS: OVERCOATS OFSI IN INK	N10	129	2174
LEE MH *see* LERNER I		129	1865
LEE SJ *see* VYAS HP		129	1757
LEHOCZKY SL *see* KELLEY JD		129	2360
LEIDHEISE.H, RAUCH AF, IBRAHIM EM, GRANATA RD THE EFFECT OF ANTIMONY ON THE CORROSION OF TIN IN DEAERATED CITRIC ACID	N8	129	1651
LEIDHEISE.H, SIMMONS GW, NAGY S, MUSIC S MOSSBAUER SPECTROSCOPIC STUDY OF THE CORROSION INHIBITION OF ZINCBY COBALT IONS	N8	129	1658
LERNER I, LEE MH, HOMOLA A AN ELECTROCHEMICALLY SEALED AL2O3 PASSIVATION LAYER FOR ALUMINUM ALLOYS	N9	129	1865
LERNER I, ELDRIDGE JM EFFECTS OF SEVERAL PARAMETERS ON THE CORROSION RATES OF AL CONDUCTORS IN INTEGRATED CIRCUITS	N10	129	2270
LEVIN RM, ADAMS AC LOW PRESSURE DEPOSITION OF PHOSPHOSILICATE GLASS FILMS	N7	129	1588
LEVIN RM WATER ABSORPTION AND DENSIFICATION OF PHOSPHOSILICATE GLASS FILMS	N8	129	1765
LEVINE SN *see* LIOU F-T		129	342
LEVY AV *see* NAGARAJAN V		129	782
LEVY AV *see* NAGARAJAN V		129	789
LEVY-CLEM.C, HELLER A, BONNER WA, PARKINSO.BA SPONTANEOUS PHOTOELECTROLYSIS OF HBR AND HL	N8	129	1701
LEWERENZ HJ, FERRIS SD, DOHERTY CJ, LEAMY HJ CHARGE COLLECTION MICROSCOPY ON P-WSE2: RECOMBINATION SITES AND MINORITY CARRIER DIFFUSION LENGTH	N2	129	418
LI P-C, TSANG PJ CVD HYDROPHOBIC LEAD SILICATE FILMS	N1	129	165
LIANG CC *see* JOW TR		129	1429
LICHTMAN D *see* WANG X		129	851
LICLICAN L *see* LEE MH		129	2174
LIE LN, RAZOUK RR, DEAL BE HIGH PRESSURE OXIDATION OF SILICON IN DRY OXYGEN	N12	129	2828
LIESKE N *see* HEZEL R		129	379
LIETZ M *see* HILL M		129	1579
LIGHT RW, SEE FC REACTIVE ION ETCHING OF SILICON DIOXIDE	N5	129	1152
LIN LF *see* CHAO CY		129	1874
LIN P *see* MARCUS RB		129	1282
LING I *see* TOMKIEWIC.M		129	2016
LINHOLM LW *see* YEN D		129	2313
LIOU F-T, YANG CY, LEVINE SN PHOTOELECTROLYSIS AT FE2O3/TIO2 HETEROJUNCTION ELECTRODE	N2	129	342
LIU C-H J, WANG JH SPRAY-PYROLYZED THIN FILM CDSE PHOTOELECTROCHEMICAL CELLS	N4	129	719
LIU C-H J, ANG PGP, SAMMELLS AF SURFACE-MODIFIED P-INP PHOTOCATHODES IN SULFIDE/POLYSULFIDE ELECTROLYTE	N6	129	1387
LIU CC *see* POLISENA C		129	2720

Author — Title — Issue No. — Vol. No. — Page No.

LIU CD, GALASCO RT, SAVINELL RF — OPERATING PERFORMANCE OF AN FE-TI STATIONARY REDOX BATTERY IN THEPRESENCE OF LEAD — N11 — 129 — 2502
LIU CT *see* DEMCZYK BG — 129 — 1159
LIU E-D *see* RAY GW — 129 — 2152
LIU M-B, COOK GM, YAO NP — TRANSIENT CURRENT DISTRIBUTIONS IN POROUS ZINC ELECTRODES IN KOH ELECTROLYTE — N2 — 129 — 239
LIU M-B, COOK GM, YAO NP, SELMAN JR — VIBRATING ZINC ELECTRODES IN NI/ZN BATTERIES — N5 — 129 — 913
LIU M-B, COOK GM, YAO NP — THE RELATIONSHIP BETWEEN ELECTROLYTE CONDUCTANCE AND CURRENT DISTRIBUTION IN POROUS ZINC ELECTRODES IN KOH ELECTROLYTE — N6 — 129 — 1390
LIU M-B, RUDNICK EM, COOK GM, YAO NP — MASS TRANSFER AT LONGITUDINALLY VIBRATING VERTICAL ELECTRODES — N9 — 129 — 1955
LODI G *see* ARDIZZONE S — 129 — 1689
LOFERSKI JJ *see* CRISMAN EE — 129 — 1845
LOTZ U *see* SYDBERGER T — 129 — 276
LOURENCO JA *see* CAMLIBEL I — 129 — 2585
LOUTFY RO *see* BROWN AP — 129 — 2481
LOVAS A *see* KOVACS P — 129 — 695
LUNDSTROM I *see* SKOTHEIM T — 129 — 894
LUNDSTROM I *see* PREJZA J — 129 — 1685
LUNDSTROM I *see* SKOTHEIM T — 129 — 1737
LUNG KR *see* ANDERSON CW — 129 — 2505
LUTHRA KL, SPACIL HS — IMPURITY DEPOSITS IN GAS TURBINES FROM FUELS CONTAINING SODIUM AND VANADIUM — N3 — 129 — 649
LUTHRA KL *see* SPACIL HS — 129 — 2119
MACAGNO VA, VILCHE JR, ARVIA AJ — THE ELECTROCHEMICAL RESPONSE OF NICKEL HYDROXIDE FORMED BY COLLOIDAL PRECIPITATION ON DIFFERENT CONDUCTING SUBSTRATES — N2 — 129 — 301
MACAGNO VA *see* CARBONIO RE — 129 — 983
MACDONAL.DD *see* TSURUTA T — 129 — 1221
MACDONAL.DD *see* CHAO CY — 129 — 1874
MACDONAL.DD *see* SILVERMAN S — 129 — 2419
MACDONAL.JR *see* FRANCESC.DR — 129 — 1754
MACIVER BA — HIGH RESOLUTION PHOTOMASKS WITH ION-BOMBARDED POLYMETHYL METHACRYLATE MASKING MEDIUM — N4 — 129 — 827
MACIVER BA, PUZIO LC — A METHOD FOR OBSERVING MICROMETER-SIZE DEFECTS IN RESISTS — N10 — 129 — 2384
MADOU MJ, GOMES WP, FRANSEN F, CARDON F — ANODIC OXIDATION OF P-TYPE SILICON IN METHANOL AS COMPARED TO GLYCOL — N12 — 129 — 2749
MAGEE TJ *see* MINAGAWA S — 129 — 888
MAHAJAN S, KERMAMID.VG, BONNER WA — THE INFLUENCE OF INTERMITTENT GROWTH PROCEDURES ON DISLOCATION DENSITIES IN INP EPI-LAYERS — N7 — 129 — 1556
MAJA M, PENAZZI N, FRATESI R, ROVENTI G — ZINC ELECTROCRYSTALLIZATION FROM IMPURITY-CONTAINING SULFATE BATHS — N12 — 129 — 2695
MAKIMURA T *see* YAMASAKI K — 129 — 2760
MALINSKI T, ELVING PJ — ELECTROCHEMICAL REDUCTION OF NICOTINAMIDE ADENINE DINUCLEOTIDE INDIMETHYLSULFOXIDE: ION-PAIR, PROTONATION, AND ADSORPTION EFFECTS — N9 — 129 — 1960
MALM DL, RILEY,JR JE — CHARACTERIZATION OF NEAR SURFACE COMPOSITION OF BOROSILICATE GLASSES (BSG) BY SECONDARY ION MASS SPECTROMETRY (SIMS) — N8 — 129 — 1819
MALOY JT *see* VACCARO AJ — 129 — 677
MALOY JT *see* VACCARO AJ — 129 — 682
MALPAS RE — THE ELECTROCHEMISTRY AND PHOTOELECTROCHEMISTRY OF AN AQUEOUS FERROCENE/FERRICENIUM REDOX COUPLE AT PLATINUM, N-SILICON AND N-INDIUM PHOSPHIDE ELECTRODES — N9 — 129 — 1987
MAMANTOV CB *see* TANEMOTO K — 129 — 2237
MAMANTOV G *see* TANEMOTO K — 129 — 2237
MANCHANDA L *see* BHATTACH.AB — 129 — 2772
MAO K-W *see* WANG Y-Y — 129 — 347
MAR KM *see* SAMUELSO.GM — 129 — 1773
MARASSI R *see* TANEMOTO K — 129 — 2237
MARCUS RB, SHENG TT — THE OXIDATION OF SHAPED SILICON SURFACES — N6 — 129 — 1278
MARCUS RB, SHENG TT, LIN P — POLYSILICON/SIO2 INTERFACE MICROTEXTURE AND DIELECTRIC BREAKDOWN — N6 — 129 — 1282
MARCUS RB *see* ROBINSON M — 129 — 2858
MARINACE JC, MCGIBBON RC — TITANIUM DIOXIDE FILMS TO IMPROVE PHOTORESIST ADHESION — N10 — 129 — 2389
MARKUNAS RJ *see* TABATABALK — 129 — 2085
MARSHALL JH *see* GLARUM SH — 129 — 535
MARTIN BG *see* KELLEY JD — 129 — 2360
MARTINEL.MR *see* ZIMMERMA.AH — 129 — 289
MARTINO FJ, GAY EC, MOORE WE — STATUS CELLS: A DEMONSTRATION OF PERFORMANCE REPRODUCIBILITY, CAPACITY RETENTION, AND CYCLE LIFE FOR LIAL/FES CELLS — N12 — 129 — 2701
MASU K, NAKATSU.S-I, KONAGAI M, TAKAHASHI K — THE ROLE OF BE IN (GAAL)AS/GAAS SOLAR CELLS — N7 — 129 — 1623
MATSUE T, FUJIHIRA M, OSA T — SELECTIVE ELECTROSYNTHESES ON CHEMICALLY MODIFIED ELECTRODE IV. SELECTIVE REDUCTION OF O-NITROPHENOL IN THE PRESENCE OF P-NITROPHENOL WITH ALPHA-CYCLODEXTRIN IN SOLUTION AND ON ELECTRODE SURFACES — N8 — 129 — 1681
MATSUMOTO H, SUGANO T — CHARACTERIZATION OF REACTIVE ION ETCHED SILICON SURFACE BY DEEP LEVEL TRANSIENT SPECTROSCOPY — N12 — 129 — 2823
MATSUMOTO H *see* ISHIKAWA Y — 129 — 644
MATSUNAGA M *see* TANEMOTO K — 129 — 2237
MATSUO T *see* NAKAJIMA H — 129 — 141
MATSUURA T *see* TAKETANI Y — 129 — 1485
MATTOS CJ *see* KOCH VR — 129 — 1
MAYDAN D *see* SMOLINSKY G — 129 — 1036
MAYDAN D *see* FLAMM DL — 129 — 2755
MAYER TM, BARKER RA — REACTIVE ION BEAM ETCHING WITH CF4: CHARACTERIZATION OF A KAUFMAN ION SOURCE AND DETAILS OF SIO2 ETCHING — N3 — 129 — 585
MAYER TM *see* SMOLINSKY G — 129 — 1770
MCALEER JF, PETER LM — INSTABILITY OF ANODIC OXIDE FILMS ON TITANIUM — N6 — 129 — 1252
MCALLIST.WA — URANIUM-ACTIVATED LITHIUM TUNGSTATE PHOSPHORS — N4 — 129 — 887
MCBREEN J *see* OLENDER H — 129 — 135
MCBREEN J *see* CHIN D-T — 129 — 2677
MCCAFFERT.E, MOORE PG, PEACE GT — EFFECT OF LASER-SURFACE MELTING ON THE ELECTROCHEMICAL BEHAVIOR OF AN AL-1 PERCENT MN ALLOY — N1 — 129 — 9
MCCANN JF, BADWAL SPS — EQUIVALENT CIRCUIT ANALYSIS OF THE IMPEDANCE RESPONSE OF SEMICONDUCTOR/ELECTROLYTE/COUNTERELECTRODE CELLS — N3 — 129 — 551
MCCANN JF, HANEMAN D — RECOMBINATION EFFECTS ON CURRENT-VOLTAGE CHARACTERISTICS OF ILLUMINATED SURFACE BARRIER CELLS — N5 — 129 — 1134
MCCOLL JR — SATURATION OF (ZN, CD)S:CU, AL CATHODOLUMINESCENT PHOSPHORS AT HIGH CURRENT DENSITIES I. EXPERIMENTAL PHENOMENA — N7 — 129 — 1546
MCDONALD RC — SOURCES OF PRESSURE IN LITHIUM THIONYL CHLORIDE BATTERIES — N11 — 129 — 2453
MCEVOY AJ *see* GISSLER W — 129 — 1733
MCGIBBON RC *see* MARINACE JC — 129 — 2389
MCLARNON FR, MULLER RH, TOBIAS CW — INTERFEROMETRIC STUDY OF COMBINED FORCED AND NATURAL CONVECTION — N10 — 129 — 2201
MEI L, RIVIER M, KWARK Y, DUTTON RW — GRAIN-GROWTH MECHANISMS IN POLYSILICON — N8 — 129 — 1791
MEITAV A, PELED E — CALCIUM-CA(ALCL4)2-THIONYL CHLORIDE CELL: PERFORMANCE AND SAFETY — N3 — 129 — 451
MELENDRE.CA *see* FENG XK — 129 — 1245
MEMMING R *see* KELLY JJ — 129 — 730
MEREDITH JW *see* CASEY JF — 129 — 354
MEVORACH RA *see* MYERS CE — 129 — 2343
MICHAELID.A *see* HILLEL R — 129 — 1343
MIERS TH — SCHOTTKY CONTACT FABRICATION FOR GAAS MESFET'S — N8 — 129 — 1795
MIKAMI H *see* YASUAMI S — 129 — 846
MILDNER DFR *see* BRUN TO — 129 — 2509
MILLARD MM, KAY E — DIFLUOROCARBENE EMISSION SPECTRA FROM FLUOROCARBON PLASMAS AND ITS RELATIONSHIP TO FLUOROCARBON POLYMER FORMATION — N1 — 129 — 160
MILLER B *see* SCHNEEME.LF — 129 — 1977
MILLER B *see* BRUCKENST.S — 129 — 2029
MILNES AG *see* YAN ZX — 129 — 1353
MINAGAWA S, GIBBONS JF, MAGEE TJ, ORMOND R, BLATTNER RJ, FURMAN BK — ANOMALOUS LOCAL OXIDATION AND RECRYSTALLIZATION OF — N4 — 129 — 888
MINER RG *see* NAGARAJAN V — 129 — 782
MINER RG *see* NAGARAJAN V — 129 — 789
MIROVSKY Y *see* TENNE R — 129 — 1506
MISAWA M *see* BRUN TO — 129 — 2509
MISRA AK, WHITTLE DP, WORRELL WL — THERMODYNAMICS OF MOLTEN SULFATE MIXTURES — N8 — 129 — 1840
MITA Y *see* KANAI F — 129 — 2633
MITCHELL JW *see* GOODEN R — 129 — 1619
MITCHELL TE *see* KURODA K — 129 — 2163
MIYAKE M, HARADA H — DIFFUSION AND SEGREGATION OF LOW-DOSE IMPLANTED BORON IN SILICON UNDER DRY O2 AMBIENT — N5 — 129 — 1097
MIYAMOTO N *see* TANABE I — 129 — 2372
MIYAZAWA S, KOIZUMI H — EUTECTIC PRECIPITATES IN FE-DOPED INP — N10 — 129 — 2335
MIYOSHI M *see* OKUMURA K — 129 — 1338
MIZUGUCHI J — DEPENDENCE OF THE DIFFUSION CURRENT ON THE DEGREE OF POLYMERIZATION OF NITROCELLULOSE IN ACETONE-ISOPROPYL ALCOHOL — N7 — 129 — 1520
MIZUO S, HIGUCHI H — EFFECT OF BACK-SIDE OXIDATION ON B AND P DIFFUSION IN SI DIRECTLYMASKED WITH SI3N4 FILMS — N10 — 129 — 2292
MIZUSHIMA Y *see* YOSHIKAWA A — 129 — 1074
MOCHIJI K, WADA Y, OBAYASHI H — IMPROVED DRY ETCHING RESISTANCE OF ELECTRON-BEAM RESIST BY ION EXPOSURE PROCESS — N11 — 129 — 2556
MOLENAAR A — AUTOCATALYTIC DEPOSITION OF GOLD-COPPER AALLOYS — N9 — 129 — 1917
MONTEIL Y *see* HILLEL R — 129 — 1343
MOORE PG *see* MCCAFFERT.E — 129 — 9
MOORE WE *see* MARTINO FJ — 129 — 2701
MOOREHEA.EL *see* SWITZER JA — 129 — 2232
MOORJANI K *see* PHILLIPS TE — 129 — 1210
MORANCHO R, PETIT JA, DABOSI F, CONSTANT G — A CORROSION-RESISTANT TITANIUM-RICH DEPOSIT PREPARED BY CHEMICAL VAPOR DEPOSITION AT LOW TEMPERATURE FROM TRIS-(2,2'BIPYRIDINE) TITANIUM — N4 — 129 — 854
MORITA S *see* YAMADA M — 129 — 2598
MORKOC H, DRUMMOND TJ, KOPP W, FISCHER R — INFLUENCE OF SUBSTRATE TEMPERATURE ON THE MORPHOLOGY OF AL(X)GA(1-X)AS GROWN BY MOLECULAR BEAM EPITAXY — N4 — 129 — 824
MORRISEY JM *see* BROWN DK — 129 — 1084
MOSELEY PT, HUTCHISO.JL, BOURKE MAM — THE DEFECT STRUCTURE OF LEAD DIOXIDE — N4 — 129 — 876
MOSER Z, GASIOR W, RZYMAN K — ACTIVITIES AND SURFACE TENSION OF LIQUID AGCL-LICL SOLUTIONS — N3 — 129 — 502
MOUNTAIN RW *see* GEIS MW — 129 — 2812
MULLER RH *see* GERONOV Y — 129 — 1422
MULLER RH *see* MCLARNON FR — 129 — 2201
MULVANEY M *see* KOCH VR — 129 — 1
MUNOZ-YAG.A, BACEIREDO S — GE INCORPORATION IN GAAS GROWN BY MOLECULAR BEAM EPITAXY: A THERMODYNAMIC STUDY — N9 — 129 — 2108
MURARKA SP, READ MH, DOHERTY CJ, FRASER DB — RESISTIVITIES OF THIN FILM TRANSITION METAL SILICIDES — N2 — 129 — 293
MURASE K *see* ITOH Y — 129 — 813
MURASE K *see* SATO Y — 129 — 1635
MURASE K *see* HIRABAYAS.K — 129 — 2059
MURATA K *see* KAWATA H — 129 — 1325
MURATORE R *see* ROYCE BSH — 129 — 2393
MUROSAKO R *see* KANNAM PJ — 129 — 656

Author / Title	Issue No.	Vol. No.	Page No.
MURPHY JC *see* PHILLIPS TE		129	1210
MURPHY OJ, BOCKRIS JO, POU TE, COCKE DL, SPARROW G SIMS EVIDENCE CONCERNING WATER IN PASSIVE LAYERS	N9	129	2149
MURRAY RW *see* KUO KN		129	756
MUSIC S *see* LEIDHEISE.H		129	1658
MYERS CE, KISACKY GA, PATTERSO.EL, MEVORACH RA THE CONGRUENT VAPORIZATION OF MN2P(S)	N10	129	2343
NAGAMI K *see* KAWATA H		129	1325
NAGARAJAN V, MINER RG, LEVY AV THE ROLE OF SILICON ADDITIONS IN THE CORROSION RESISTANCE OF CHROMIA-FORMING ALLOYS IN COAL GASIFICATION ATMOSPHERES	N4	129	782
NAGARAJAN V, MINER RG, LEVY AV THE ROLE OF CHROMIUM IN THE CORROSION RESISTANCE OF ALUMINA-FORMING ALLOYS IN COAL GASIFICATION ATMOSPHERES	N4	129	789
NAGASUBRA.G, WHEELER BL, FAN F-R F, BARD AJ SEMICONDUCTOR ELECTRODES XLII. EVIDENCE FOR FERMI LEVEL PINNING FROM SHIFTS IN THE FLATBAND POTENTIAL OF P-TYPPE SILICON IN ACETONITRILE SOLUTIONS WITH DIFFERENT REDOX COUPLES	N8	129	1742
NAGUIB HM *see* DZIOBA S		129	2537
NAGY AG, HESS DW CHEMICAL PROPERTIES OF POLYMER FILMS FORMED DURING THE ETCHING OFALUMINUM IN CCL4 PLASMAS	N11	129	2530
NAGY S *see* LEIDHEISE.H		129	1658
NAGY Z ERROR ANALYSIS OF THE POTENTIAL AND VOLTAGE STEP RELAXATION TECHNIQUES FOR THE MEASUREMENT OF KINETICS OF ELECTRODE REACTIONS	N9	129	1943
NAGY Z, SETTLE JL, PADOVA J, BLANDER M COMPLEXING OF AL(Δ3) BY S(-2) IONS IN ALKALI HALIDE MELTS	N9	129	2034
NAKAHARA S, FELDER EC DEFECT STRUCTURE IN NICKEL ELECTRODEPOSITS	N1	129	45
NAKAHARA S DIRECT OBSERVATIONS OF INCLUSIONS IN ELECTRODEPOSITED FILMS BY TRANSMISSION ELECTRON MICROSCOPY	N5	129	201C
NAKAI K *see* KITAHARA K		129	880
NAKAJIMA H, ESASHI M, MATSUO T THE CATION CONCENTRATION RESPONSE OF POLYMER GATE ISFET	N1	129	141
NAKAJIMA K, AKITA K SUBSTRATE ORIENTATION DEPENDENCE OF GROWTH RATE OF INGAAS/INP GROWN BY LIQUID PHASE EPITAXY	N11	129	2603
NAKAJIMA O *see* SHIONO N		129	1760
NAKAMURA H *see* SATO M		129	2522
NAKAMURA T *see* ITO T		129	184
NAKATSU.S-I *see* MASU K		129	1623
NANISHI Y *see* PARSEY JM		129	388
NANJUNDIA.C, SHIMIZU K, OSTERYOU.RA ELECTROCHEMICAL STUDIES OF FE(II) AND FE(III) IN AN ALUMINUM CHLORIDE-BUTYLPYRIDINIUM CHLORIDE IONIC LIQUID	N11	129	2474
NARITA T, NISHIDA K, SMELTZER WW COMPUTER SIMULATION OF THE DIFFUSIONAL GROWTH OF TERNARY OXIDE SCALES ON BINARY ALLOYS	N1	129	209
NASLAIN R *see* COLMET R		129	1367
NATWIG DL *see* ABRAHAM KM		129	2404
NAZRI G *see* KURODA K		129	2163
NEWMAN GH *see* KLEMANN LP		129	230
NGUYEN TH, FOLEY RT THE CHEMICAL NATURE OF ALUMINUM CORROSION II. THE INITIAL DISSOLUTION STEP	N1	129	27
NGUYEN TH, BROWN BF, FOLEY RT ALTERATION OF CORRODENT ION SPECIES WITHIN STRESS CORROSION CRACKS	N4	129	780
NGUYEN TH *see* FOLEY RT		129	464
NICHOLAS KH, TREE RJ THE ELECTRICAL MEASUPEMENT OF PATTERN PLACEMENT ERRORS OF MASK MAKERS	N8	129	1800
NIEDRACH LW USE OF A HIGH TEMPERATURE PH SENSOR AS A 'PSEUDO-REFERENCE ELECTRODE' IN THE MONITORING OF CORROSION AND REDOX POTENTIALS AT285DEGREE C	N7	129	1445
NIIMI T *see* ISHIKAWA Y		129	644
NIIMI T *see* SONG SH		129	841
NISHIDA K *see* NARITA T		129	209
NISHIMATS.S *see* SUZUKI K		129	2764
NOBLE B *see* ALWITT RS		129	711
NOEL D *see* BERGE P		129	2194
NOGAMI G CHARACTERIZATION OF SEMICONDUCTOR ELECTRODES WITH A DEEP IMPURITYLEVEL	N10	129	2219
NOGUCHI Y *see* ADACHI S		129	1053
NOGUCHI Y *see* ADACHI S		129	1524
NORDINE PC, VOLPE L KINETICS OF THE F,F2/B4C GASIFICATION REACTIONS	N5	129	1105
NOUFI R, NOZIK AJ, WHITE J, WARREN LF ENHANCED STABILITY OF PHOTOELECTRODES WITH ELECTROGENERATED POLYANILINE FILMS	N10	129	2261
NOZIK AJ *see* COOPER G		129	1973
NOZIK AJ *see* NOUFI R		129	2261
O'BRIEN RN, SANTHANA.KS MAGNETIC FIELD EFFECTS ON THE GROWTH OF THE DIFFUSION LAYER AT VERTICAL ELECTRODES DURING ELECTRODEPOSITION	N6	129	1266
O'DELL B *see* YEAGER HL		129	85
O'DELL B *see* TWARDOWSK.Z		129	328
O'GRADY WE *see* OLENDER H		129	135
O'SULLIVA.D, PRICE PB, KINOSHITA K, WILLSON CG PREDICTING RADIATION SENSITIVITY OF POLYMERS	N4	129	811
O'TOOLE MM *see* RAY GW		129	2152
OBAYASHI H *see* MOCHIJI K		129	2556
OBERSTAR JD, STREETMA.BG, BAKER JE, WILLIAMS P SIMS STUDIES OF 9BE IMPLANTS IN SEMI-INSULATING INP	N6	129	1312
OBERSTAR JD, STREETMA.BG, BAKER JE, WILLIAMS P SIMS STUDIES OF SEMI-INSULATING INP AMORPHIZED BY MG AND SI	N6	129	1320
OCHI O *see* YOSHIKAWA A		129	1074
OGATA Y *see* TANEMOTO K		129	2237
OGAWA K *see* TSUYA H		129	374
OGDEN C *see* HAAK R		129	891
OHNISHI Y *see* SUZUKI M		129	402
OKAMOTO A, ISOZUMI S, LAGOWSKI J, GATOS HC IN SITU MONITORING OF LIQUID PHASE ELECTROEPITAXIAL GROWTH	N9	129	2095
OKUDAIRA S *see* SUZUKI K		129	2764
OKUMURA K, MIYOSHI M A NOVEL METHOD FOR MEASUREMENT OF THE CHANNEL LENGTH OF SHORT CHANNEL MOSFET'S	N6	129	1338
OLDHAM KB SEMI-INFINITE DIFFUSION TO ELECTRODES CONSISTING OF TWO OR MORE INTERSECTING PLANES	N1	129	128
OLENDER H, MCBREEN J, O'GRADY WE, SRINIVASA.S, KORDESCH KV DESIGN OF A CELL FOR ELECTRODE KINETIC INVESTIGATIONS OF FUEL CELL REACTIONS	N1	129	135
OLESZEK GM *see* CASEY JF		129	354
OLMER LJ, ISAACS HS THE EFFECT OF ELECTRODE SURFACE IMPURITIES ON THE OXYGEN ELECTRODE REACTION AT ZIRCONIA ELECTROLYTES	N2	129	345
OLMER LJ *see* ISAACS HS		129	436
ONUMA T, HIRAO T, SUGAWA T STUDY OF ENCAPSULANTS FOR ANNEALING SI-IMPLANTED GAAS	N4	129	837
ORD JL AN ELLIPSOMETRIC STUDY OF ELECTROCHROMISM IN IRIDIUM OXIDE	N2	129	335
ORD JL AN ELLIPSOMETRIC STUDY OF ELECTROCHROMISM IN TUNGSTEN OXIDE	N4	129	767
ORD JL A GALVANOSTATIC TECHNIQUE FOR STUDYING DIELECTRIC CONSTANT VARIATION IN VALVE-METAL OXIDES	N9	129	2038
ORMOND R *see* MINAGAWA S		129	888
ORTEGA C, SIEJKA J A STUDY BY NUCLEAR MICROANALYSIS AND 18O TRACING OF THE GROWTH OFANODIC OXIDE FILMS ON ZIRCONIUM I. INFLUENCE OF FORMATION CONDITIONS ON E-I RELATIONS	N9	129	1895
ORTEGA C, SIEJKA J A STUDY BY NUCLEAR MICROANALYSIS AND 18O TRACING OF THE GROWTH OFANODIC OXIDE FILMS ON ZIRCONIUM II. OXIDE GROWTH MECHANISM	N9	129	1905
OSA T *see* MATSUE T		129	1681
OSAKA J *see* INOUE N		129	2780
OSTERYOU.RA *see* HEPEL T		129	2132
OSTERYOU.RA *see* NANJUNDIA.C		129	2474
OSTERYOU.RA *see* CHEEK GT		129	2488
OSTERYOU.RA *see* CREEK G		129	2739
OSTERYOUN.J *see* WEBBER A		129	2725
OSTERYOUN.J *see* WEBBER A		129	2731
OTAGAWA T, BOCKRIS JO LANTHANUM NICKELATE AS ELECTROCATALYST: OXYGEN EVOLUTION	N10	129	2391
OTTO NC *see* TOMCZUK Z		129	925
OUANO AC *see* GIPSTEIN E		129	201
OZAWA L AN EXPERIMENTAL STUDY OF MOTION OF ELECTRONS AND HOLES IN Y2O2S CRYSTAL AS REVEALED BY CATHODOLUMINESCENCE	N7	129	1535
OZER D *see* BETTELHEI.A		129	2247
PADOVA J *see* NAGY Z		129	2034
PALANISAM.T *see* VACCARO AJ		129	677
PALANISAM.T *see* VACCARO AJ		129	682
PALIK ED, FAUST,JR JW, GRAY HF, GREENE RF STUDY OF THE ETCH-STOP MECHANISM IN SILICON	N9	129	2051
PANDYA DK *see* KAINTHLA RC		129	99
PAPKE BL, RATNER MA, SHRIVER DF VIBRATIONAL SPECTROSCOPIC DETERMINATION OF STRUCTURE AND ION PAIRING IN COMPLEXES OF POLY(ETHYLENE OXIDE) WITH LITHIUM SALTS	N7	129	1434
PAPKE BL, RATNER MA, SHRIVER DF CONFORMATION AND ION-TRANSPORT MODELS FOR THE STRUCTURE AND IONICCONDUCTIVITY IN COMPLEXES OF POLYETHERS WITH ALKALI METAL SALTS	N8	129	1694
PARASH R *see* BETTELHEI.A		129	2247
PARK S-M *see* WILSON JR		129	149
PARK S-M *see* STILWELL DE		129	1501
PARK S-M *see* DHOOGE PM		129	1719
PARKER MA *see* LANGMUIR ME		129	1705
PARKER SG, CHANG CTM PROPERTIES OF GARNET MATERIALS FOR CONTIGUOUS DISK MAGNETIC BUBBLE MEMORY DEVICES	N2	129	423
PARKINSO.BA *see* GINLEY DS		129	145
PARKINSO.BA *see* LEVY-CLEM.C		129	1701
PARSEY JM, NANISHI Y, LAGOWSKI J, GATOS HC BRIDGMAN-TYPE APPARATUS FOR THE STUDY OF GROWTH-PROPERTY RELATIONSHIPS: ARSENIC VAPOR PRESSURE-GAAS PROPERTY RELATIONSHIP	N2	129	388
PARSONS WS *see* TOMKIEWIC.M		129	2016
PATTERSO.EL *see* MYERS CE		129	2343
PAULEAU Y, BOUTEVILLA, HANTZPER.JJ, REMY JC, CACHARD A COMPOSITION, KINETICS, AND MECHANISM OF GROWTH OF CHEMICAL VAPOR-DEPOSITED ALUMINUM NITRIDE FILMS	N5	129	1045
PAULNACK CL *see* ROBINSON M		129	2858
PAVLOV D *see* ILIEV V		129	458
PEACE GT *see* MCCAFFERT.E		129	9
PEDERSON LA STRUCTURAL COMPOSITION OF POLYMERS RELATIVE TO THEIR PLASMA ETCH CHARACTERISTICS	N1	129	205
PELED E *see* MEITAV A		129	451
PEMBERTO.JE THE EDWARD WESTON SUMMER FELLOWSHIP REPORT--QUANTITATION OF ADSORPTION PARAMETERS AND ADSORPTION RATES FOR DITHIOZONE ANION ADSORPTION AT AG USING SURFACE ENHANCED AND RESONANCE ENHANCED RAMAN SPECTROSCOPY	N8	129	295C
PENA JL, FARIAS MH, SANCHEZ-S.F SIMS AND AES ANALYSIS OF H:TIO2 ELECTRODES	N1	129	94
PENAZZI N *see* MAJA M		129	2695
PENG S *see* RAY GW		129	2152
PERKINS J, CUMMINGS JR, GRAHAM KJ MORPHOLOGICAL STUDIES OF OCCLUDED CELLS IN THE PITTING OF DILUTE ALUMINUM ALLOYS IN SEAWATER	N1	129	137
PETER LM *see* MCALEER JF		129	1252
PETERS HJB *see* SANDERS FHM		129	2559
PETERSON JR, CHAMBERS JQ ELECTROCHEMICAL REDUCTION OF THIOPHOSGENE IN ACETONITRILE	N3	129	529
PETERSON ME *see* SALMON DJ		129	2496
PETERSS.L-G *see* SKOTHEIM T		129	1737

Author — Title — Issue No. — Vol. No. — Page No.

PETIT JA *see* MORANCHO R — 129 — 854
PETRILLO EJ *see* EPHRATH LM — 129 — 2282
PHILLIPS TE, MOORJANI K, MURPHY JC, POEHLER TO — N6 — 129 — 1210
TIO2-VO2 ALLOYS--REDUCED BANDGAP EFFECTS IN THE PHOTOELECTROLYSISOF WATER
PICARD G, SEON F, TREMILLON B — N7 — 129 — 1450
REACTIONS OF FORMATION AND STABILITY OF IRON(II) AND (III) OXIDESIN LICL-KCL EUTECTIC MELT AT 470DEGREE C
PICKERIN.HW *see* ZAMANZADE.M — 129 — 284
PILLA AA *see* SCHMUKLER R — 129 — 526
PISTOIA G — N9 — 129 — 1861
SOME RESTATEMENTS ON THE NATURE AND BEHAVIOR OF MNO2 FOR LI BATTERIES
PITTS L *see* RUPICH MW — 129 — 1857
PLATTNER E *see* COMNINELL.C — 129 — 749
POEHLER TO *see* PHILLIPS TE — 129 — 1210
POLISENA C, LIU CC, SAVINELL RF — N12 — 129 — 2720
EXPERIMENTAL STUDY OF ELECTROCHEMICAL FLUORINATION OF TRICHLOROETHYLENE
POPITSCH A *see* GRUBER H — 129 — 365
POTZL H *see* GUERRERO E — 129 — 1826
POU TE *see* MURPHY OJ — 129 — 2149
PRAMANIK P *see* BHATTACH.RN — 129 — 332
PRAMANIK P *see* BHATTACH.RN — 129 — 1642
PRASAD A, BALAKRISH.S, JAIN SK, JAIN GC — N3 — 129 — 596
POROUS SILICON OXIDE ANTI-REFLECTION COATING FOR SOLAR CELLS
PREJZA J, LUNDSTROM I, SKOTHEIM T — N8 — 129 — 1685
ELECTROPOLYMERIZATION OF PYRROLE IN THE PRESENCE OF FLUOBORATE
PRENTICE GA, TOBIAS CW — N1 — 129 — 72
A SURVEY OF NUMERICAL METHODS AND SOLUTIONS FOR CURRENT DISTRIBUTION PROBLEMS
PRENTICE GA, TOBIAS CW — N1 — 129 — 78
SIMULATION OF CHANGING ELECTRODE PROFILES
PRENTICE GA, TOBIAS CW — N2 — 129 — 316
DEPOSITION AND DISSOLUTION ON SINUSOIDAL ELECTRODES
PRICE PB *see* O'SULLIVA.D — 129 — 811
PRYOR MJ, GIAM K-K — N10 — 129 — 2157
THE EFFECT OF ARSENIC ON THE DEALLOYING OF ALPHA-BRASS
PUZIO LC *see* MACIVER BA — 129 — 2384
QADEER A, REED J, BRYANT FJ — N9 — 129 — 2145
ELECTROLYTIC POLISH FOR PB(1-X)SN(X)SE
RABATIN JG — N7 — 129 — 1552
LUMINESCENCE OF RARE EARTH ACTIVATED LUTETIUM OXYHALIDE PHOSPHORS
RAISTRICK D *see* VIENNET R — 129 — 2451
RAJESHWAR K — N5 — 129 — 1003
CHARGE TRANSFER IN PHOTOELECTROCHEMICAL DEVICES VIA INTERFACE STATES: UNIFIED MODEL AND COMPARISON WITH EXPERIMENTAL DATA
RAJESHWAR K *see* THAPAR R — 129 — 560
RAJESHWAR K *see* THOMPSON L — 129 — 1934
RAJESHWAR K *see* THAFAR R — 129 — 2009
RANDIN J-P — N6 — 129 — 1215
ION-CONTAINING POLYMERS AS SEMISOLID ELECTROLYTES IN WO3-BASED ELECTROCHROMIC DEVICES
RANDIN J-P, VIENNET R — N10 — 129 — 2349
PROTON DIFFUSION IN TUNGSTEN TRIOXIDE THIN FILMS
RANDIN J-P *see* VIENNET R — 129 — 2451
RASIYAH P, TSEUNG ACC, HIBBERT DB — N8 — 129 — 1724
A MECHANISTIC STUDY OF OXYGEN EVOLUTION ON NICO2O4
RATHMAN DD, SILVERSM.DJ, BURNS JA — N10 — 129 — 2303
LATERAL EPITAXIAL OVERGROWTH OF SILICON ON SIO2
RATNER MA *see* PAPKE BL — 129 — 1434
RATNER MA *see* PAPKE BL — 129 — 1694
RAUCH AF *see* LEIDHEISE.H — 129 — 1651
RAUH RD *see* LANGMUIR ME — 129 — 1705
RAVA P, GATOS HC, LAGOWSKI J — N12 — 129 — 2844
THERMALLY ACTIVATED OXYGEN DONORS IN SI
RAY GW, PENG S, BURRIESCI D, O'TOOLE MM, LIU E-D — N9 — 129 — 2152
SPIN-ON GLASS AS AN INTERMEDIATE LAYER IN A TRI-LAYER RESIST PROCESS
RAZOUK RR, DEAL BE — N4 — 129 — 806
HYDROGEN ANNEAL EFFECTS ON METAL-SEMICONDUCTOR WORK FUNCTION DIFFERENCE
RAZOUK RR *see* DELFINO M — 129 — 606
RAZOUK RR *see* LIE LN — 129 — 2828
READ MH *see* MURARKA SP — 129 — 293

REED J *see* QADEER A — 129 — 2145
REEP DH *see* GHANDHI SK — 129 — 2778
REICHMAN B *see* BYVIK CE — 129 — 237
REICHMAN J *see* RUSSAK MA — 129 — 542
REICHMANI.E *see* WILKINS,.CW — 129 — 2552
REIF R — N5 — 129 — 1122
PHOSPHORUS INCORPORATION DURING SILICON EPITAXIAL GROWTH IN A CVDREACTOR
REINBERG AR *see* BRUCE RH — 129 — 393
RELLER H, KIROWA-ELE — N7 — 129 — 1473
THE GALVANOSTATIC METHOD: ANALYSIS OF ERROR AND COMPUTATION OF PARAMETERS
REMY JC *see* PAULEAU Y — 129 — 1045
REVESZ AG, SCHAEFFE.HA — N2 — 129 — 357
THE MECHANISM OF OXYGEN DIFFUSION IN VITREOUS SIO2
REVIE RW, FICHERA M — N3 — 129 — 669
AN ELECTRODE DESIGN FOR DUAL MEASUREMENT OF POTENTIALS INSIDE ARTIFICIAL PITS AND ON POLARIZED SURFACES
REYES-MEN.A *see* WANG X — 129 — 851
RICCO AJ *see* BAGLIO JA — 129 — 1461
RICHARDS.RE *see* LEE MH — 129 — 2174
RIGO S, ROCHET F, AGIUS B, STRABONI A — N4 — 129 — 967
AN 18O STUDY OF COOPERATIVE DIFFUSION AND CHEMICAL REACTION DURING THERMAL TREATMENTS OF SILICA FILMS IN WATER VAPOR
RILEY,JR JE *see* MALM DL — 129 — 1819
RITCHIE WH *see* BOYER PK — 129 — 2155
RIVIER M *see* MEI L — 129 — 1791
ROBBINS DJ, COCKAYNE B, CULLIS AG, GLASPER JL — N4 — 129 — 816
SINGLE CRYSTAL Y3AL5O12:TB PHOSPHOR PRODUCED BY ION IMPLANTATION
ROBERTSO.CR *see* BRADSHAW RW — 129 — 958
ROBINSON M, CHANG CC, MARCUS RB, ROZGONYI GA, KATZ LE, PAULNACK CL — N12 — 129 — 2858
LOW DISLOCATION DENSITY RF-HEATED EPITAXIAL SILICON
ROCHE MF *see* TOMCZUK Z — 129 — 925
ROCHET F *see* RIGO S — 129 — 867
RODRIQUE.JL *see* SEXTON FW — 129 — 2624
ROOT DK, SMITH WH — N6 — 129 — 1231
ELECTROCHEMICAL BEHAVIOR OF SELECTED IMINE DERIVATIVES, REDUCTIVECARBOXYLATION, ALPHA-AMINO ACID SYNTHESIS
ROSENTHAL J, WESTERBY B — N9 — 129 — 2147
THE DETERMINATION OF SURFACE STATE ENERGIES AT A
ROTELLA FJ *see* JORGENSE.JD — 129 — 1678
ROTELLA FJ *see* BRUN TO — 129 — 2509
ROUZE SR *see* ARNOTT DR — 129 — 2660
ROVENTI G *see* MAJA M — 129 — 2695
ROYCE BSH, SANCHEZ-S.F, GOLDSTEIN R, MURATORE R, WILLIAMS R, YIM WM — N10 — 129 — 2393
STUDIES OF PHOTOCORROSION AT THE ZNSE-ELECTROLYTE INTERFACE BY PHOTOTHERMAL DEFLECTION SPECTROSCOPY
ROZGONYI GA *see* BAUSER E — 129 — 1782
ROZGONYI GA *see* ROBINSON M — 129 — 2858
RUDNICK EM *see* LIU M-B — 129 — 1955
RUGE I *see* CHIU T-Y — 129 — 408
RUPICH MW, PITTS L, ABRAHAM KM — N9 — 129 — 1857
CHARACTERIZATION OF REACTIONS AND PRODUCTS OF THE DISCHARGE AND FORCED OVERDISCHARGE OF LI/SO2 CELLS
RUSSAK MA, REICHMAN J — N3 — 129 — 542
PHOTOELECTROCHEMICAL PERFORMANCE OF ZNSE/CDSE THIN FILM ELECTRODES IN AQUEOUS POLYSULFIDE ELECTROLYTE
RZYMAN K *see* MOSER Z — 129 — 502
SACHAR KS *see* SILVESTR.VJ — 129 — 1029
SACILOTTI M *see* BAUDRANT A — 129 — 1109
SACKS R, AVIGAL Y, BANKS E — N4 — 129 — 726
NEW SOLID ELECTROLYTES F. ?ED ON CUBIC ZRP2O7
SAIKI A, HARADA S — N10 — 129 — 2278
NEW COUPLING METHOD FOR POLYIMIDE ADHESION TO LSI SURFACE
SAINT-PAU.P *see* BERGE P — 129 — 2194
SAINTE-R .P *see* DESLOUIS C — 129 — 107
SAJKOWSK.DJ *see* DONAHUE FM — 129 — 717
SAKASHITA M, STREHBL.H-H, BETTINI M — N4 — 129 — 739
ANODIC OXIDE FILMS AND ELECTROCHEMICAL REACTIONS ON HGTE

SAKASHITA M, STREHBL.H-H, BETTINI M — N8 — 129 — 1710
ANODIC OXIDE FILMS AND ELECTROCHEMICAL REACTIONS ON CD0.2HG0.8TE
SAKINA Y *see* ISHIKAWA Y — 129 — 644
SALA-PALA J *see* SAVY M — 129 — 1409
SALMON DJ, PETERSON ME, HENRICKS LL, ABELS LL, HALL JC — N11 — 129 — 2496
SPECTROSCOPIC STUDIES OF THE HAZARDS OF LI/SOCL2 BATTERIES DURINGANODE-LIMITED CELL REVERSAL
SALOMON M — N6 — 129 — 1165
CONDUCTANCE STUDIES IN THIONYL CHLORIDE: II
SAMMELLS AF *see* ANG PGP — 129 — 233
SAMMELLS AF *see* ST.JOHN MR — 129 — 246
SAMMELLS AF *see* LIU C-H J — 129 — 1387
SAMUELSO.GM, MAR KM — N8 — 129 — 1773
THE CORRELATIONS BETWEEN PHYSICAL AND ELECTRICAL PROPERTIES OF PECVD SIN WITH THEIR COMPOSITION RATIOS
SANCHEZ J *see* KOUDELKA M — 129 — 1186
SANCHEZ-S.F *see* PENA JL — 129 — 94
SANCHEZ-S.F *see* ROYCE BSH — 129 — 2393
SANDERS FHM, DIELEMAN J, PETERS HJB, SANDERS JAM — N11 — 129 — 2559
SELECTIVE ISOTROPIC DRY ETCHING OF SI3N4 OVER SIO2
SANDERS JAM *see* SANDERS FHM — 129 — 2559
SANTHANA.KS *see* CHEN Y-W D — 129 — 61
SANTHANA.KS *see* O'BRIEN RN — 129 — 1266
SARASWAT KC, SINGH H — N10 — 129 — 2321
THERMAL OXIDATION OF HEAVILY PHOSPHORUS-DOPED THIN FILMS OF POLYCRYSTALLINE SILICON
SATO M, NAKAMURA H — N11 — 129 — 2522
THE EFFECTS OF MIXING N2 IN CCL4 ON ALUMINUM REACTIVE ION ETCHING
SATO N — N2 — 129 — 255
ANODIC BREAKDOWN OF PASSIVE FILMS ON METALS
SATO N — N2 — 129 — 260
THE STABILITY OF PITTING DISSOLUTION OF METALS IN AQUEOUS SOLUTION
SATO N *see* SUZUKI M — 129 — 2183
SATO Y, MURASE K, HARADA H — N7 — 129 — 1635
A NOVEL METHOD TO MEASURE LATERAL DIFFUSION LENGTH IN POLYCRYSTALLINE SILICON
SATO Y *see* SUZUKI M — 129 — 2183
SAUTEBIN R, LANDOLT D — N5 — 129 — 946
ANODIC LEVELING UNDER SECONDARY AND TERTIARY CURRENT DISTRIBUTION CONDITIONS
SAVINELL RF *see* LIU CD — 129 — 2502
SAVINELL RF *see* POLISENA C — 129 — 2720
SAVY M, GUERCHAIJE, SALA-PALA J — N7 — 129 — 1409
EPR INVESTIGATION OF FE, MIXED FE-MO, AND MO NAPHTHALOCYANINES. APPLICATION TO THE ELECTROCATALYSIS OF OXYGEN REACTION
SCAFE E *see* DE ANGELI.L — 129 — 1237
SCARPELL.AJ, FISHER GL — N3 — 129 — 515
THE DEVELOPMENT OF AN ENERGY-EFFICIENT INSOLUBLE ANODE FOR NICKEL ELECTROWINNING I. SINGLE LAYER PRECIOUS METAL COATINGS
SCARPELL.AJ, FISHER GL — N3 — 129 — 522
THE DEVELOPMENT OF AN ENERGY-EFFICIENT INSOLUBLE ANODE FOR NICKEL ELECTROWINNING II. MULTILAYER PRECIOUS METAL COATINGS
SCHAEFFE.HA *see* REVESZ AG — 129 — 357
SCHAFER LL *see* DONAHUE FM — 129 — 717
SCHAPER H, KOSTLIN H, SCHNEDLER E — N6 — 129 — 1289
NEW ASPECTS OF D-C ELECTROCHEMILUMINESCENCE
SCHEPS R — N10 — 129 — 2273
ELLIPSOMETRIC THICKNESS MEASUREMENTS OF PMMA ON GAAS
SCHERSON DA, AMADELLI R, YEAGER EB — N10 — 129 — 2268
COMMENTS ON THE VAN DER BRINK, BARENDRECHT, AND VISSCHER METHOD TO EVALUATE RATE CONSTANTS FOR HYDROGEN PEROXIDE DECOMPOSITION ATROTATING DISK ELECTRODES
SCHIETZEL.M *see* CISZEK TF — 129 — 2838
SCHIFFMA.RA *see* SHILO I — 129 — 1608
SCHLIERR A *see* SINGH S — 129 — 447
SCHMOLLA W, HARTNAGE.HL — N11 — 129 — 2636
LOW TEMPERATURE DOUBLE-PLASMA PROCESS FOR BN FILMS ON SEMICONDUCTORS

Author Title	Issue No.	Vol. No.	Page No.
SCHMUKLER R, PILLA AA A TRANSIENT IMPEDANCE APPROACH TO NONFARADAIC ELECTROCHEMICAL KINETICS AT LIVING CELL MEMBRANES	N3	129	526
SCHNEDLER E *see* SCHAPER H		129	1289
SCHNEEME.LF, MILLER B INP AND CDS PHOTOANODES IN CONCENTRATED AQUEOUS IODIDE ELECTROLYTES	N9	129	1977
SCHUMACH.JC VENTURES IN ELECTROCHEMICAL INDUSTRY	N10	129	397C
SCHUMACH.LC *see* WEBER MF		129	2022
SCHUMAKE.NE *see* SWAMINATH.V		129	1563
SCHUSSLER M *see* GHANDEHA.MH		129	2666
SCHWAGER F *see* GERONOV Y		129	1422
SCHWARTZ GP, SUNDER WA, GRIFFITH.JE THE IN-P-O PHASE DIAGRAM: CONSTRUCTION AND APPLICATIONS	N6	129	1361
SCROSATI B *see* FORNARINI L		129	1155
SCROSATI B *see* DE ANGELI.L		129	1237
SCULFORT JL *see* VAN AMERO.G		129	1998
SEDGWICK TO, GEISS RH, DEPP SW, HANCHETT VE, HUTH BG, GRAF V, SILVESTR.VJ SINGLE CRYSTAL SILICON FILMS ON AMORPHOUS INSULATORS: GROWTH BY LATERAL NUCLEATED EPITAXY USING SCANNING LASER AND ELECTRON BEAMSAND EVALUATION BY ELECTRON BACKSCATTERING CONTRAST	N12	129	2802
SEE FC *see* LIGHT RW		129	1152
SEKI S *see* KANO T		129	2296
SELMAN JR *see* LIU M-B		129	913
SELMAN JR *see* LEE J		129	1670
SEON F *see* PICARD G		129	1450
SETHI R *see* CHIN D-T		129	2677
SETTLE JL *see* NAGY Z		129	2034
SEVERI M *see* SOLMI S		129	1811
SEXTON FW, GARNER CM, RODRIQUE.JL PROCESS FOR HIGH PHOTOCURRENT IN IBC SOLAR CELLS	N11	129	2624
SHARP KG, ARVIDSON A, ELVEY TC HAZARD POTENTIAL OF DICHLOROSILANE	N10	129	2346
SHEIBLEY DW *see* HSU L-C		129	251
SHENG TT *see* MARCUS RB		129	1278
SHENG TT *see* MARCUS RB		129	1282
SHERMAN RL *see* VALLET CE		129	49
SHERMAN RL *see* VALLET CE		129	931
SHEU S-S *see* WANG Y-Y		129	347
SHIBANO T *see* KAWATA H		129	1325
SHIBATA K, SHIMA S, KASHIWAGI M CRYSTALLINE STRUCTURE CHANGES OF MOLYBDENUM SILICIDE FILMS DEPOSITED BY SPUTTERING AND BY COEVAPORATION AFTER ISOCHRONAL ANNEALING	N7	129	1527
SHIBATOMI S *see* KITAHARA K		129	880
SHIBAYAMA K *see* ITAYA K		129	663
SHILO I, FRANZEN HF, SCHIFFMA.RA ENTHALPIES OF FORMATION OF NIOBIUM ALUMINIDES AS DETERMINED BY THE KNUDSEN EFFUSION METHOD	N7	129	1608
SHILO I, FRANZEN HF HIGH TEMPERATURE THERMODYNAMIC STUDY OF THE MOLYBDENUM-RICH REGIONS OF THE MO-AL SYSTEM	N11	129	2613
SHIM WW, JACOB KT POTENTIOMETRIC DETERMINATION OF THE GIBBS ENERGIES OF FORMATION OF LEAD ALUMINATES	N5	129	1116
SHIMA S *see* SHIBATA K		129	1527
SHIMADA K *see* YAMASAKI K		129	2760
SHIMIZU K *see* NANJUNDIA.C		129	2474
SHIMURA F, TSUYA H OXYGEN PRECIPITATION FACTORS IN SILICON	N5	129	1062
SHIMURA F, TSUYA H MULTISTEP REPEATED ANNEALING FOR CZ-SILICON WAFERS: OXYGEN AND INDUCED DEFECT BEHAVIOR	N9	129	2089
SHIMURA F *see* TSUYA H		129	374
SHIONO N, NAKAJIMA O, HASHIMOTO C INTERFACE TRAPPED CHARGE GENERATION AND ELECTRON TRAPPING KINETICS IN MOSFET'S DUE TO SUBSTRATE HOT-ELECTRON INJECTION INTOGATE SIO2	N8	129	1760
SHRIVER DF *see* PAPKE BL		129	1434
SHRIVER DF *see* PAPKE BL		129	1694
SICONOLF.DJ *see* FRANKENT.RP		129	1192
SIDES PJ, TOBIAS CW RESISTANCE OF A PLANAR ARRAY OF SPHERES: GAS BUBBLES ON AN ELECTRODE	N12	129	2715
SIEJKA J *see* ORTEGA C		129	1895
SIEJKA J *see* ORTEGA C		129	1905
SIGMUND H SOLUBILITIES OF MAGNESIUM AND CALCIUM IN SILICON	N12	129	2809
SIITARI DW, ALKIRE RC INITIATION OF CREVICE CORROSION I. EXPERIMENTAL INNVESTIGATIONS ALUMINUM AND IRON	N3	129	481
SIITARI DW *see* ALKIRE RC		129	488
SILVERMAN S, CRAGNOLIN.G, MACDONAL.DD AN ELLIPSOMETRIC INVESTIGATION OF PASSIVE FILMS FORMED ON FE-25NI-XCR ALLOYS IN BORATE BUFFER SOLUTION	N11	129	2419
SILVERSM.DJ *see* RATHMAN DD		129	2303
SILVERSM.DJ *see* GEIS MW		129	2812
SILVESTR.VJ, SACHAR KS DEPOSITION TECHNIQUES AND HEAT TRANSFER PROPERTIES OF POROUS ALUMINUM	N5	129	1029
SILVESTR.VJ *see* CHEN MC		129	1294
SILVESTR.VJ *see* SEDGWICK TO		129	2802
SIMMONS GW *see* LEIDHEISE.H		129	1658
SINCLAIR JD TARNISHING OF SILVER BY ORGANIC SULFUR VAPORS: RATES AND FILM CHARACTERISTICS	N1	129	33
SINGBEIL D, TROMANS D A FRACTURE MECHANICS STUDY OF CAUSTIC CRACKING OF MILD STEEL IN HOT NAOH/NA2S SOLUTIONS	N12	129	2669
SINGH DDN, CHAUDHAR.RS, AGARWAL CV CORROSION CHARACTERISTICS OF SOME ALUMINUM ALLOYS IN NITRIC ACID	N9	129	1869
SINGH H *see* SARASWAT KC		129	2321
SINGH S, WILLIAMS RS, VAN UITE.LG, SCHLIERR A, CAMLIBEL I, BONNER WA ANALYSIS OF INP SURFACE PREPARED BY VARIOUS CLEANING METHODS	N2	129	447
SIRIPALA W, TOMKIEWIC.M INTERACTIONS BETWEEN PHOTOINDUCED AND DARK CHARGE TRANSFER ACROSSN-TIO2-AQUEOUS ELECTROLYTE INTERFACE	N6	129	1240
SITTIG R *see* HILL M		129	1579
SKOTHEIM T, LUNDSTROM I SOLID POLYMER ELECTROLYTE PHOTOVOLTAIC CELL	N4	129	894
SKOTHEIM T, PETERSS.L-G, INGANAS O, LUNDSTROM I PHOTOELECTROCHEMICAL BEHAVIOR OF N-SI ELECTRODES PROTECTED WITH PT-POLYPYRROLE	N8	129	1737
SKOTHEIM T *see* PREJZA J		129	1685
SMAGA JA, BATTLES JE EVALUATION OF NICKEL FOR POSITIVE ELECTRODE COMPONENTS IN LI-AL/FES CELLS	N3	129	496
SMELTZER WW *see* NARITA T		129	209
SMITH DJ, YOUNG L AN EXPERIMENTAL INVESTIGATION OF HIGH FIELD IONIC CONDUCTION IN ANODIC TANTALUM PENTOXIDE FILMS USING THE OPEN-CIRCUIT TRANSIENT METHOD	N11	129	2513
SMITH DJ, YOUNG L AN INVESTIGATION OF HIGH FIELD IONIC CONDUCTION IN ANODIC TANTALUM PENTOXIDE FILMS USING THE STEPPED CURRENT METHOD	N11	129	2518
SMITH DL, BRUCE RH SI AND AL ETCHING AND PRODUCT DETECTION IN A PLASMA BEAM UNDER ULTRAHIGH VACUUM	N9	129	2045
SMITH FW, GHIDINI G REACTION OF OXYGEN WITH SI(111) AND (100): CRITICAL CONDITIONS FOR THE GROWTH OF SIO2	N6	129	1300
SMITH HI *see* BEZJIAN KA		129	1848
SMITH HI *see* GEIS MW		129	2812
SMITH SW, VOGEL WM, KAPELNER S SOLUBILITIES OF OXYGEN IN FUSED LI2CO3-K2CO3	N8	129	1668
SMITH SW *see* VOGEL WM		129	1441
SMITH WH *see* ROCT DK		129	1231
SMOLINSKY G, TRUESDAL.EA, WANG DNK, MAYDAN D REACTIVE ION ETCHING OF SILICON OXIDES WITH AMMONIA AND TRIFLUOROMETHANE. THE ROLE OF NITROGEN IN THE DISCHARGE	N5	129	1036
SMOLINSKY G, MAYER TM, TRUESDAL.EA PLASMA ETCHING OF SILICON AND SILICON DIOXIDE WITH HYDROGEN FLUORIDE MIXTURES	N8	129	1770
SMOLINSKY G *see* BURTON RH		129	1599
SOLMI S, SEVERI M, ANGELUCCI R, BALDI L, BILENCHI R ELECTRICAL PROPERTIES OF THERMALLY AND LASER ANNEALED POLYCRYSTALLINE SILICON FILMS HEAVILY DOPED WITH ARSENIC AND PHOSPHORUS	N8	129	1811
SONG SH, NIIMI T, KOBAYASHI K, KUDO K OBSERVATION OF THE ANOMALOUS CONCENTRATION PROFILES OF ANTIMONY ATOMS DIFFUSED INTO SILICON DUE TO LOCAL PRECIPITATION	N4	129	841
SOPORI BL A SECTIONING TECHNIQUE FOR DEMOUNTABLE SEMICONDUCTOR SAMPLES	N2	129	448
SOURIRAJA.S *see* TAKETANI Y		129	1485
SPACIL HS, LUTHRA KL VOLATILIZATION/CONDENSATION OF ALKALI SALTS IN A PRESSURIZED FLUIDIZED BED COAL COMBUSTOR/GAS TURBINE COMBINED CYCLE	N9	129	2119
SPACIL HS *see* LUTHRA KL		129	649
SPARROW G *see* MURPHY OJ		129	2149
SRINIVASA.S *see* OLENDER H		129	135
ST.JOHN MR, FURGALA AJ, SAMMELLS AF THERMODYNAMIC STUDIES OF LI-GE ALLOYS: APPLICATION TO NEGATIVE ELECTRODES FOR MOLTEN SALT BATTERIES	N2	129	246
STACY WT, ALLISON DF, WU T-C METAL DECORATED DEFECTS IN HEAT-TREATED SILICON WAFERS	N5	129	1128
STADTHER.MA *see* ALKIRE RC		129	1225
STEARNS CA *see* FRYBURG GC		129	571
STEIN HJ HYDROGEN-IMPLANTED SILICON NITRIDE	N8	129	1786
STEINBERG J DUAL HCL THIN GATE OXIDATION PROCESS	N8	129	1778
STERN KH *see* DEANHARD.ML		129	2228
STEVENSO.DA *see* HESHMATPO.B		129	430
STILES PJ *see* CRISMAN EE		129	1845
STILWELL DE, PARK S-M STUDIES ON PHOTOELECTROCHEMICAL PROPERTIES OF SNO2 FILMS PREPARED FROM ORGANIC RESINATE SOLUTION	N7	129	1501
STILWELL DE *see* DHOOGE PM		129	1719
STINGEDER G *see* GUERRERO E		129	1826
STIRLAND DJ *see* AUGUSTUS PD		129	614
STIRPE F *see* FORNARINI L		129	1155
STRABONI A *see* RIGO S		129	867
STRECKER.HH, TONG J-R, CARPENTE.MK, ELLIS AB LUMINESCENT PHOTOELECTROCHEMICAL CELLS VII. PHOTOLUMINESCENT AND ELECTROLUMINESCENT PROPERTIES OF CADMIUM SULFO-SELENIDE ELECTRODES	N4	129	772
STREETMA.BG *see* OBERSTAR JD		129	1312
STREETMA.BG *see* OBERSTAR JD		129	1320
STREHBL.H-H *see* SAKASHITA M		129	739
STREHBL.H-H *see* SAKASHITA M		129	1710
STRUNK H *see* CUNNINGHA.B		129	1089
STUBER SM *see* KENNEDY JH		129	1968
STURGE MD *see* SWAMINATH.V		129	1563
SUGANO T *see* MATSUMOTO H		129	2823
SUGAWA T *see* ONUMA T		129	837
SUGAWARA S *see* TAMAMURA T		129	1831
SUGIOKA S *see* KANAI F		129	2633
SUKEGAWA K *see* TAMAMURA T		129	1831
SUNDER WA *see* SCHWARTZ GP		129	1361
SUNU WG, BURROWS BW MATHEMATICAL MODEL FOR DESIGN OF BATTERY ELECTRODES I. POTENTIAL DISTRIBUTION	N4	129	688
SUSMAN S *see* BRUN TO		129	2509
SUTULA RA *see* HARTMANN HS		129	1749
SUZUKI K, OKUDAIRA S, NISHIMATS.S, USAMI K, KANOMATA I MICROWAVE PLASMA ETCHING OF SI WITH CF4 AND SF6 GAS	N12	129	2764
SUZUKI M, OHNISHI Y FACTORS AFFECTING THE SENSITIVITY OF CROSS-LINKED POSITIVE RESISTS	N2	129	402
SUZUKI M, SATO N, KANNO K-I, SATO Y MEASUREMENT OF ELECTROLESS PLATING RATE FOR COPPER AND NICKEL BATHS BY COULOSTATIC METHOD	N10	129	2183
SWAMINATH.V, STURGE MD, ZILKO JL, SCHUMAKE.NE, WAGNER WR, GAW CA DOPING OF GA(1-X)AL(X)AS GROWN BY LPE WITH SI AND GE	N7	129	1563
SWANSON RM *see* KWARK Y		129	197
SWAROOP RB *see* BANDYOPAD.G		129	2187
SWATHIRAJ.S, BRUCKENST.S INTERPRETATION OF POTENTIOSTATIC TRANSIENT BEHAVIOR DURING THE UNDERPOTENTIAL DEPOSITION OF SILVER ON GOLD USING THE ROTATING RING-DISK ELECTRODE	N6	129	1202

Author / Title — Issue No. — Vol. No. — Page No.

SWITZER JA, MOOREHEA.EL, DALESAND.DM — N10 — 129 — 2232
PHOTOELECTROCHEMISTRY OF THE THALLIC/THALLOUS COUPLE. THE THALLICION CATALYZED PHOTO-OXIDATION OF PROPYLENE

SYDBERGER T, LOTZ U — N2 — 129 — 276
RELATION BETWEEN MASS TRANSFER AND CORROSION IN A TURBULENT PIPE FLOW

SZOFRAN FR *see* KELLEY JD — 129 — 2360

SZWARC R, WALTON RD, DALLEK S, LARRICK BF — N6 — 129 — 1168
DISCHARGE CHARACTERISTICS OF LITHIUM-BORON ALLOY ANODE IN MOLTEN SALT THERMAL CELLS

TABATABAI.K, MARKUNAS RJ, FONSTAD CG — N9 — 129 — 2085
LPE GROWTH TECHNIQUES FOR FABRICATING ABRUPT ZINC- AND MAGNESIUM-DOPED P(A)-N INGAASP/INP HETEROJUNCTIONS

TADA T, — N5 — 129 — 1070
ESR STUDIES OF NEGATIVE ELECTRON RESISTS PGMA AND PST

TAKACS L *see* KOVACS P — 129 — 695

TAKAHASHI K *see* MASU K — 129 — 1623

TAKAMORI T, FINE S, DOVE DB — N11 — 129 — 2638
EFFECT OF V2O3 ADDITION ON THE THERMOLUMINESCENCE AND PHOSPHORESCENCE OF TB-ACTIVATED GARNET PHOSPHORS

TAKEDA A *see* YOSHIKAWA A — 129 — 1074

TAKETANI Y, MATSUURA T, SOURIRAJA.S — N7 — 129 — 1485
USE OF LIQUID CHROMATOGRAPHY FOR STUDYING INTERFACIAL PROPERTIES OF INORGANIC SOLUTES RELEVANT TO REVERSE OSMOSIS SEPARATIONS

TAMAMURA T, SUKEGAWA K, SUGAWARA S — N8 — 129 — 1831
RESOLUTION LIMIT OF NEGATIVE ELECTRON RESIST EXPOSED ON A THIN FILM SUBSTRATE

TAMAMURA T *see* HARADA K — 129 — 2576

TAMMINGA Y *see* JOSQUIN WJM — 129 — 1803

TANABE I, MIYAMOTO N, KIDO H, KATO Z, UNO T — N10 — 129 — 2372
THE SYNTHESIS OF DENSIFIED CMD FROM MN-NH4-CARBAMATE AND ITS DISCHARGE PROPERTIES IN ZNCL2 BATTERIES

TANAKA H *see* ISHIKAWA Y — 129 — 644

TANEMOTO K, MARASSI R, MAMANTOV CB, OGATA Y, MATSUNAGA M, WIAUX JP, MAMANTOV G — N10 — 129 — 2237
OXIDATION OF SULFUR IN CHLOROALUMINATE MELTS OF INTERMEDIATE PCL

TANI B *see* TOMCZUK Z — 129 — 925

TAYLOR DF, CARAMIHA.CA — N11 — 129 — 2458
CREVICE CORROSION IN HIGH-TEMPERATURE AQUEOUS SYSTEMS POTENTIAL/PH MEASUREMENTS IN ALLOY 600 CREVICES AT 288DEGREE C

TEHERANI TH *see* BARNA GG — 129 — 746

TEHERANI TH *see* BARNA GG — 129 — 2464

TENCH D *see* HAAK R — 129 — 891

TENNE R — N1 — 129 — 143
THE EFFECT OF ADDED SALTS ON THE STABILITY OF

TENNE R, MIROVSKY Y, GREENSTEI.Y, CAHEN D — N7 — 129 — 1506
TERNARY CHALCOGENIDE-BASED PHOTOELECTROCHEMICAL CELLS II. THE N-CDIN2SE4/AQUEOUS POLYSULFIDE SYSTEM

THAPAR R, RAJESHWAR K — N3 — 129 — 560
PHOTOELECTROCHEMICAL OXIDATION OF AROMATIC HYDROCARBONS AND DECAMETHYL FERROCENE AT THE N-GAAS/ROOM TEMPERATURE MOLTEN SALT ELECTROLYTE INTERFACE

THAPAR R, DUBOW J, RAJESHWAR K — N9 — 129 — 2009
PHOTOELECTROCHEMICAL CHARACTERIZATION OF THE N-INP/ROOM TEMPERATURE MOLTEN SALT ELECTROLYTE INTERFACE

THEBAULT D *see* JASTRZEBS.L — 129 — 1638

THIEL FA — N7 — 129 — 1570
THE PHASE RELATIONS IN THE CU,IN,S SYSTEM AND THE GROWTH OF CUINS2 CRYSTALS FROM THE MELT

THOMAS JGN *see* TURNBULL A — 129 — 1412

THOMPSON GE, DOHERTY PE, WOOD GC — N7 — 129 — 1515
OBSERVATIONS OF FLAWS ON PRECONDITIONED ALUMINUM SURFACES

THOMPSON HB *see* KSHIRSAG.ST — 129 — 1835

THOMPSON L, DUBOW J, RAJESHWAR K — N9 — 129 — 1934
PHOTOELECTROCHEMICAL GENERATION OF CHLORINE ON CATALYTICALLY MODIFIED N-SILICON/INDIUM TIN OXIDE ANODES

TIELERT R *see* GUERRERO E — 129 — 1826

TIERNEY E *see* IRENE EA — 129 — 2594

TING CY, GREBE K, WALDMAN D — N4 — 129 — 859
CONTROLLED COLLAPSE REFLOW FOR JOSEPHSON CHIP BONDING

TING CY, CROWDER BL — N11 — 129 — 2590
ELECTRICAL PROPERTIES OF AL/TI CONTACT METALLURGY FOR VLSI APPLICATION

TJONG SC, HOFFMAN RW, YEAGER EB — N8 — 129 — 1662
ELECTRON AND ION SPECTROSCOPIC STUDIES OF THE PASSIVE FILM ON IRON-CHROMIUM ALLOYS

TOBIAS CW *see* PRENTICE GA — 129 — 72

TOBIAS CW *see* PRENTICE GA — 129 — 78

TOBIAS CW *see* PRENTICE GA — 129 — 316

TOBIAS CW *see* FOLLER PC — 129 — 506

TOBIAS CW *see* FOLLER PC — 129 — 567

TOBIAS CW *see* MCLARNON FR — 129 — 2201

TOBIAS CW *see* SIDES PJ — 129 — 2715

TOMCZUK Z, TANI B, OTTO NC, ROCHE MF, VISSERS DR — N5 — 129 — 925
PHASE RELATIONSHIPS IN POSITIVE ELECTRODES OF HIGH TEMPERATURE LI-AL/LICL-KCL/FES2 CELLS

TOMKIEWIC.M, LING I, PARSONS WS — N9 — 129 — 2016
MORPHOLOGY, PROPERTIES, AND PERFORMANCE OF ELECTRODEPOSITED N-CDSE IN LIQUID JUNCTION SOLAR CELLS

TOMKIEWIC.M *see* SIRIPALA W — 129 — 1240

TOMKIEWIC.M *see* BRATIN P — 129 — 2469

TOMPKINS T *see* GIPSTEIN E — 129 — 201

TONG CS, WANG SD, WANG Y-Y, WAN C-C — N6 — 129 — 1173
A STUDY OF THE IRON ELECTRODE STRUCTURE OF NI-FE CELL

TONG J-R *see* STRECKER.HH — 129 — 772

TONOMURA S *see* YAMAMOTO N — 129 — 444

TOSHIMA S *see* ITAYA K — 129 — 762

TOSHIMA S *see* ITAYA K — 129 — 1498

TRAINHAM JA, WU J-J — N5 — 129 — 991
THE EFFECT OF MULTIPLE CURRENT COLLECTORS ON THE PERFORMANCE OF FLOW-THROUGH POROUS ELECTRODES

TRANQUARD A *see* HILLEL R — 129 — 1343

TRASATTI S *see* ARDIZZONE S — 129 — 1689

TREE RJ *see* NICHOLAS KH — 129 — 1800

TREMILLON B *see* PICARD G — 129 — 1450

TREVILLI.EA *see* HOBDELL MR — 129 — 2746

TRIACA WE *see* DELGADO AB — 129 — 1493

TRIBOLLET B *see* DESLOUIS C — 129 — 107

TROMANS D *see* SINGBEIL D — 129 — 2669

TRUESDAL.EA *see* SMOLINSKY G — 129 — 1036

TRUESDAL.EA *see* SMOLINSKY G — 129 — 1770

TRUESDEL.JW, VAN DE M.MR — N12 — 129 — 2673
CHELATING-POLYMER ADSORPTION EFFECTS ON CORROSION OF STEEL

TRZASKOM.PP — N7 — 129 — 1398
CORROSION RATES AND ELECTROCHEMICAL STUDIES OF A DEPLETED URANIUMALLOY TUNGSTEN FIBER METAL MATRIX COMPOSITE

TSAI JE *see* ALKIRE RC — 129 — 1157

TSANG PJ *see* LI P-C — 129 — 165

TSAUR B-Y *see* GEIS MW — 129 — 2812

TSEUNG ACC *see* RASIYAH P — 129 — 1724

TSUBOMURA H *see* YAMAMOTO N — 129 — 444

TSURU T, LATANISI.RM — N7 — 129 — 1402
CORROSION RESISTANCE OF MICROCRYSTALLINE STAINLESS STEELS

TSURUTA T, MACDONAL.DD — N6 — 129 — 1221
STABILIZED CERAMIC MEMBRANE ELECTRODES FOR THE MEASUREMENT OF PH AT ELEVATED TEMPERATURES

TSUYA H, SHIMURA F, OGAWA K, KAWAMURA T — N2 — 129 — 374
A STUDY ON INTRINSIC GETTERING IN CZ SILICON CRYSTALS: EVALUATION, THERMAL HISTORY DEPENDENCE, AND ENHANCEMENT

TSUYA H *see* SHIMURA F — 129 — 1062

TSUYA H *see* SHIMURA F — 129 — 2089

TU CW *see* DONNELLY VM — 129 — 2533

TURNBULL A, THOMAS JGN — N7 — 129 — 1412
A MODEL OF CRACK ELECTROCHEMISTRY FOR STEELS IN THE ACTIVE STATE BASED ON MASS TRANSPORT BY DIFFUSION AND ION MIGRATION

TURNER JA *see* COOPER G — 129 — 1973

TWARDOWSK.Z, YEAGER HL, O'DELL B — N2 — 129 — 328
A COMPARISON OF PERFLUORINATED CARBOXYLATE AND SULFONATE ION EXCHANGE POLYMERS II. SORPTION AND TRANSPORT PROPERTIES IN CONCENTRATED SOLUTION ENVIRONMENTS

TWARDOWSK.Z *see* YEAGER HL — 129 — 85

TWARDOWSK.Z *see* YEAGER HL — 129 — 324

TYFIELD SP *see* HOBDELL MR — 129 — 2746

UEMURA C *see* YAMAMOTO A — 129 — 2795

UMEZAWA Y, YAMAMURA T, KOBAYASHI A — N10 — 129 — 2378
VISIBLE LIGHT CONVERSION AT ONE-DIMENSIONAL NICKEL DITHIOLENE COMPLEX ELECTRODE

UNO T *see* TANABE I — 129 — 2372

UOSAKI K, KITA H — N8 — 129 — 1752
PHOTOPOTENTIAL BEHAVIOR OF PLATINIZED TIO2 PARTICLES

URABE K *see* YAMAMOTO H — 129 — 2069

URETA-ZAN.S *see* ZAGAL J — 129 — 2242

USAMI K *see* SUZUKI K — 129 — 2764

VACCARO AJ, PALANISAM.T, KERR RL, MALOY JT — N4 — 129 — 677
ELECTROCHEMICAL INVESTIGATIONS OF ALKALI-METAL INTERCALATION REACTIONS IN TIS2: CYCLIC VOLTAMMETRY AND CHRONOCOULOMETRY OF LIQUID ELECTROLYTE SYSTEMS

VACCARO AJ, PALANISAM.T, KERR RL, MALOY JT — N4 — 129 — 682
ELECTROCHEMICAL INVESTIGATIONS OF ALKALI-METAL INTERCALATION REACTIONS IN TIS2: CHRONOAMPEROMETRIC DETERMINATION OF MASS AND CHARGE TRANSPORT PROPERTIES OF LIQUID ELECTROLYTE SYSTEMS

VALLET CE, HEATHERL.DE, SHERMAN RL, BRAUNSTEI.J — N1 — 129 — 49
CURRENT-INDUCED COMPOSITION GRADIENTS IN MOLTEN AGNO3-NANO3: A MODEL SYSTEM FOR THE LICL-KCL ELECTROLYTE OF AN LI/S BATTERY

VALLET CE, KIDD LM, HEATHERL.DE, SHERMAN RL, BRAUNSTEI.J — N5 — 129 — 931
SEM/EDX AND AA MEASUREMENTS OF CURRENT-INDUCED COMPOSITION GRADIENTS. MOLTEN NANO3-AGNO3 IN POROUS YTTRIA

VAN AMERO.G, GUYOMARD D, HEINDL R, HERLEM M, SCULFORT JL — N9 — 129 — 1998
PHOTOELECTROCHEMICAL BEHAVIOR OF P-TYPE SI SINGLE CRYSTALS IN LIQUID AMMONIA AND IN LIQUID AMMONIATE OF SODIUM IODIDE

VAN DE M.MR *see* TRUESDEL.JW — 129 — 2673

VAN DEN .CJ *see* KUIPER AET — 129 — 2288

VAN DER .CJ — N4 — 129 — 706
THE EFFECT OF CATHODIC POLARIZATION ON THE CREEP RATE OF GOLD

VAN DER .ET — N11 — 129 — 2617
IMPEDANCE MEASUREMENTS ON LITHIUM-ELECTROLYZED BOROSILICATE GLASS

VAN UITE.LG *see* SINGH S — 129 — 447

VANMAEKEL.D, GOMES WP, CARDON F — N3 — 129 — 546
STUDY OF STABILIZATION AND SURFACE RECOMBINATION ON N-GAP PHOTOELECTRODES: MECHANISMS AND INTERRELATION

VARMA R *see* JORGENSE.JD — 129 — 1678

VASI J *see* BHATTACH.AB — 129 — 2772

VASSORT G *see* GAUTHIER M — 129 — 970

VELTKAMP GW *see* KUIPER AET — 129 — 2288

VERTES A *see* KOVACS P — 129 — 695

VIANI F *see* GESMUNDO F — 129 — 622

VIDELA HA *see* DE MELE MFL — 129 — 2207

VIENNET R, RANDIN J-P, RAISTRICK D — N11 — 129 — 2451
EFFECT OF ACTIVE SURFACE AREA ON THE RESPONSE TIME OF ELECTROCHROMIC AND ELECTROLYTIC DISPLAYS

VIENNET R *see* RANDIN J-P — 129 — 2349

VILCHE JR *see* MACAGNO VA — 129 — 301

VILCHE JR *see* CARBONIO RE — 129 — 983

VINCENT H *see* BQUIX J — 129 — 2338

VISSCHER W *see* ABYANEH MY — 129 — 2654

VISSERS DR *see* TOMCZUK Z — 129 — 925

VOGEL WM, SMITH SW — N7 — 129 — 1441
THE EFFECT OF SULFUR ON THE ANODIC H2(NI) ELECTRODE IN FUSED LI2CO3-K2CO3 AT 650DEGREE C

VOGEL WM *see* SMITH SW — 129 — 1668

VOLPE L *see* NORDINE PC — 129 — 1105

VON NEID.AR *see* CHIN AK — 129 — 2386

Author — Title	Issue No.	Vol. No.	Page No.
VYAS HP, KIRCHNER GD, LEE SJ — FIXED CHARGE DENSITY (QSS) AT THE SI-SIO2 INTERFACE FOR THIN OXIDES	N8	129	1757
WADA K *see* INOUE N		129	2780
WADA Y *see* MOCHIJI K		129	2556
WADE,JR W *see* BINDER M		129	897
WAGNER WR *see* SWAMINATH.V		129	1563
WALDMAN D *see* TING CY		129	859
WALTON RD *see* SZWARC R		129	1168
WAN C-C *see* WANG Y-Y		129	347
WAN C-C *see* TONG CS		129	1173
WANG DNK *see* SMOLINSKY G		129	1036
WANG DNK *see* FLAMM DL		129	2755
WANG JH *see* LIU C-H J		129	719
WANG SD *see* TONG CS		129	1173
WANG X, REYES-MEN.A, LICHTMAN D — INTERFACE COMPOSITION STUDIES OF THERMALLY OXIDIZED GAAS USING AUGER DEPTH PROFILING	N4	129	851
WANG Y-Y, SHEU S-S, WAN C-C, MAO K-W — AN EXPERIMENTAL STUDY OF A PACKED BED ELECTROD(WITH COPPER PARTICLES	N2	129	347
WANG Y-Y *see* TONG CS		129	1173
WARD PJ — A SURVEY OF IRON CONTAMINATION IN SILICON SUBSTRATES AND ITS IMPACT ON CIRCUIT YIELD	N11	129	2573
WARD WJ, CARROLL KM — DIFFUSION OF COPPER IN THE COPPER-SILICON SYSTEM	N1	129	227
WARREN LF *see* NOUFI R		129	2261
WEBBER A, KIROWA-ELE, OSTERYOUN.J, HERMOLIN J — POLAROGRAPHY OF 4-CYANO-1-METHYLPYRIDINIUM ION IN ACETONITRILE	N12	129	2725
WEBBER A, OSTERYOUN.J — CONTROLLED POTENTIAL COULOMETRY OF 4-CYANO-1-METHYLPYRIDINIUM IONIN ACETONITRILE	N12	129	2731
WEBER MF, SCHUMACH.LC, DIGNAM MJ — EFFECT OF HYDROGEN ON THE DIELECTRIC AND PHOTOELECTROCHEMICAL PROPERTIES OF SPUTTERED TIO2 FILMS	N9	129	2022
WEININGE.JL, BRIANT JL — STATE-OF-CHARGE INDICATOR FOR LEAD-ACID BATTERIES	N11	129	2409
WEISS R, APPELBAUM J — BATTERY STATE OF CHARGE DETERMINATION IN PHOTOVOLTAIC SYSTEMS	N9	129	1928
WEST K, JACOBSEN T, ATLUNG S — MODELING OF POROUS INSERTION ELECTRODES WITH LIQUID ELECTROLYTE	N7	129	1480
WESTERBY B *see* ROSENTHAL J		129	2147
WHEELER BL *see* NAGASUBRA.G		129	1742
WHITE FR, KOBURGER CW, HARMON DL, GEIPEL HJ — PLASMA ETCHING OF COMPOSITE SILICIDE GATE ELECTRODES	N6	129	1330
WHITE HS, ABRUNA HD, BARD AJ — SEMICONDUCTOR ELECTRODES XLI. IMPROVEMENT OF PERFORMANCE OF N-WSE2 ELECTRODES BY ELECTROCHEMICAL POLYMERIZATION OF	N2	129	265
WHITE J *see* NOUFI R		129	2261
WHITELEY JS, GHANDHI SK — FACTORS INFLUENCING THE GROWTH OF GA0.47IN0.53AS ON INP SUBSTRATES USING THE METALORGANIC PROCESS	N2	129	383
WHITTLE DP *see* HINDAM H		129	1147
WHITTLE DP *see* MISRA AK		129	1840
WIART R *see* FEUILLADE G		129	2649
WIAUX JP, CLAES P — ELECTROCHEMICAL BEHAVIOR OF NITRATE AND NITRITE IONS IN THE MOLTEN NAOH-KOH (49 M/O) EUTECTIC MIXTURE AT 250 DEGREE C	N1	129	123
WIAUX JP *see* TANEMOTO K		129	2237
WILKINS,.CW, REICHMANI.E, CHANDROS.EA — LITHOGRAPHIC EVALUATION OF AN O-NITROBENZYL ESTER BASED DEEP U.V.RESIST SYSTEM	N11	129	2552
WILLETT BC, ANSON FC — ELECTROCHEMISTRY AND ADSORPTION OF BIS 2,-2'-BIPYRIDINECOBALT(I) AND BIS 6,6'-DIMETHYL-2,2'-BIPYRIDINECOBALT(I) IN ACETONITRILE	N6	129	1260
WILLIAMS GF *see* CAPASSO F		129	821
WILLIAMS P *see* OBERSTAR JD		129	1312
WILLIAMS P *see* OBERSTAR JD		129	1320
WILLIAMS R *see* ROYCE BSH		129	2393
WILLIAMS RS *see* ZILKO JL		129	406
WILLIAMS RS *see* SINGH S		129	447
WILLSON CG *see* O'SULLIVA.D		129	811
WILSON JR, PARK S-M — PHOTOANODIC DISSOLUTION OF N-CDS STUDIED BY ROTATING RING-DISK ELECTRODES	N1	129	149
WILSON LO — NUMERICAL SIMULATION OF GATE OXIDE THINNING IN MOS DEVICES	N4	129	831
WITT AF *see* CARLBERG T		129	189
WOLD A *see* BAGLIO JA		129	1461
WOLF JF *see* DAMJANOVI.A		129	55
WOO MYC *see* DARLINGT.WB		129	275C
WOOD GC *see* THOMPSON GE		129	1515
WOOD VE *see* BYKER HJ		129	1982
WORRELL WL *see* MISRA AK		129	1840
WRIGHTON MS *see* BAGLIO JA		129	1461
WU C-Y, KING C-W, LEE M-K, CHEN C-T — GROWTH KINETICS OF SILICON THERMAL NITRIDATION	N7	129	1559
WU J-J *see* TRAINHAM JA		129	991
WU S-Y *see* FLOWERS DL		129	2299
WU T-C *see* STACY WT		129	1128
YAHALOM J *see* ZAHAVI J		129	1181
YAHALOM J *see* GELCHINS.MH		129	2433
YAMADA M, HATTORI S, MORITA S — A DRY DEVELOPMENT MODEL FOR A POSITIVE ELECTRON BEAM RESIST	N11	129	2598
YAMAGUCHI M *see* YAMAMOTO A		129	2795
YAMAGUCHI S — MARTENSITIC TRANSFORMATION OF GD	N5	129	1145
YAMAJI A *see* YAMAKI J-I		129	5
YAMAKI J-I, YAMAJI A — PHTHALOCYANINE CATHODE MATERIALS FOR SECONDARY LITHIUM CELLS	N1	129	5
YAMAMOTO A, YAMAGUCHI M, UEMURA C — PREPARATION AND ELECTRICAL PROPERTIES OF AN ANODIC OXIDE OF INP	N12	129	2795
YAMAMOTO H, URABE K — HOST SENSITIZATION MECHANISM OF EU(3Δ) LUMINESCENCE IN (Y, IN)2O3	N9	129	2069
YAMAMOTO N, TONOMURA S, TSUBOMURA H — TEMPERATURE DEPENDENCE OF THE SENSITIVITIES OF METAL-TIO2 JUNCTIONS TO VARIOUS REDUCING GASES	N2	129	444
YAMAMURA T *see* UMEZAWA Y		129	2378
YAMAOKA T *see* IHARA M		129	2569
YAMASAKI K, ASAI K, SHIMADA K, MAKIMURA T — SPUTTER ETCHING EFFECTS ON GAAS SCHOTTKY JUNCTIONS	N12	129	2760
YAMAWAKI H *see* IHARA M		129	2569
YAN ZX, MILNES AG — DEEP LEVEL TRANSIENT SPECTROSCOPY OF SILVER AND GOLD LEVELS IN LEC GROWN GALLIUM ARSENIDE	N6	129	1353
YANG CY *see* LIOU F-T		129	342
YANG XF, HUANG L, GATOS HC — SELECTIVE EPITAXIAL GROWTH OF GAAS BY LIQUID PHASE ELECTROEPITAXY	N1	129	194
YAO NP *see* LIU M-B		129	239
YAO NP *see* LIU M-B		129	913
YAO NP *see* LIU M-B		129	1390
YAO NP *see* JORGENSE.JD		129	1678
YAO NP *see* LIU M-B		129	1955
YAO NP *see* BROWN AP		129	2481
YASUAMI S, MIKAMI H, FUJITSU T — WIRE BONDING PROCESS CHARACTERIZATION BY X-RAY DIFFRACTION TOPOGRAPHY	N4	129	846
YEAGER E *see* KURODA K		129	2163
YEAGER EB *see* TJONG SC		129	1662
YEAGER EB *see* SCHERSON DA		129	2268
YEAGER HL, O'DELL B, TWARDOWSK.Z — TRANSPORT PROPERTIES OF NAFION(R) MEMBRANES IN CONCENTRATED SOLUTION ENVIRONMENTS	N1	129	85
YEAGER HL, TWARDOWSK.Z, CLARKE LM — A COMPARISON OF PERFLUORINATED CARBOXYLATE AND SULFONATE ION EXCHANGE POLYMERS I. DIFFUSION AND WATER SORPTION	N2	129	324
YEAGER HL *see* TWARDOWSK.Z		129	328
YEH L-S R *see* DAMJANOVI.A		129	55
YEH TH *see* BEYER KD		129	2527
YEN D, LINHOLM LW, BUEHLER MG — A CROSS-BRIDGE TEST STRUCTURE FOR EVALUATING THE LINEWIDTH UNIFORMITY OF AN INTEGRATED CIRCUIT LITHOGRAPHY SYSTEM	N10	129	2313
YEN Y-T *see* ALLEN R		129	1379
YIM WM *see* ROYCE BSH		129	2393
YORIUME Y — DEFORMATION OF SILICON WAFERS BY THERMAL OXIDATION	N9	129	2076
YOSHIKAWA A, OCHI O, TAKEDA A, MIZUSHIMA Y — A NEW DOPING TECHNIQUE WITHOUT SIO2 PATTERNING USING AN INORGANICPHOTORESIST	N5	129	1074
YOSHIZAWA S *see* ITO Y		129	1936
YOUNG KF *see* CHIANG CK		129	2113
YOUNG L *see* SMITH DJ		129	2513
YOUNG L *see* SMITH DJ		129	2518
ZAGAL J, URETA-ZAN.S — ELECTRO-OXIDATION OF HYDRAZINE CATALYZED BY SULFONATED PHTHALOCYANINES ADSORBED ON A GRAPHITE ELECTRODE	N10	129	2242
ZAHAVI J, YAHALOM J — EXFOLIATION CORROSION OF ALMGSI ALLOYS IN WATER	N6	129	1181
ZAHAVI J, KERBEL H, KOROTKINA O — A-C ANODIZING PROCESSES OF ALUMINUM ALLOYS	N7	129	1572
ZAMANZADE.M, ALLAM A, KATO C, ATEYA B, PICKERIN.HW — HYDROGEN ABSORPTION DURING ELECTRODEPOSITION AND HYDROGEN CHARGING OF SN AND CD COATINGS ON IRON	N2	129	284
ZANZUCCHI P *see* JASTRZEBS.L		129	1638
ZAROWIN CB, HORWATH RS — CONTROL OF PLASMA ETCH PROFILES WITH PLASMA SHEATH ELECTRIC FIELDAND RF POWER DENSITY	N11	129	2541
ZILKO JL, WILLIAMS RS — AUGER ELECTRON SPECTROSCOPY STUDY OF GAAS SUBSTRATE CLEANING PROCEDURES	N2	129	406
ZILKO JL *see* SWAMINATH.V		129	1563
ZIMMERMA.AH, MARTINEL.MR, JANECKI MC, BADCOCK CC — IMPEDANCE AND MASS TRANSPORT KINETICS OF NICKEL CADMIUM CELLS	N2	129	289
ZOSKI GD *see* BAGLIO JA		129	1461

JOURNAL ARTICLE SUBJECT INDEX

The Subject Index is in the form of a permuted title index that provides an alphabetical key to subjects and titles, using all significant words from each title. Except for certain nonsignificant words, *e.g.*, articles and prepositions, and some words that are common to many titles, *e.g.*, *technique* or *measurement*, all words of the title are indexed. To enhance meaning and aid searching, the entire title is shown in context with the *index word*. The *index word* is aligned in bold type on a column in the center of the page, as shown by the word CONCENTRATED in the first line below:

TRANSPORT PROPERTIES OF NAFION(R) MEMBRANES IN **CONCENTRATED** SOLUTION ENVIRONMENTS		129	85
LDS IN TIO2 PHOTOANODES	HYDROGEN **CONCENTRATION** GRADIENT AND ASSOCIATED ELECTRIC FIE	129	1851
ON OF SURFACE ACCEPTOR STATE DENSI	CALCULATION OF CARRIER **CONCENTRATION** IN POLYCRYSTALLINE FILMS AS A FUNCTI	129	1382
METHOD TO MEASURE THE PRECIPITATED AND TOTAL OXYGEN **CONCENTRATION** IN SILICON		129	1638
INTO SILICON DUE TO LOCAL PR	OBSERVATION OF THE ANOMALOUS **CONCENTRATION** PROFILES OF ANTIMONY ATOMS DIFFUSED	129	841

In the first line above, the title of the item reads normally from the left to right. In the second line, the title begins with HYDROGEN continues to the right and then picks up the balance on the left, the final word being PHOTOANODES. The third and fifth lines also illustrate this "recirculation" principle. They also show where it has been necessary to break a title because of its length. The missing word in the fifth line, (PR)ECIPITATION, may be found by searching another word in the title, for example, ANTIMONY. Any significant words in the missing segment of a title also appear as index entries with the necessary loss of another part of that title.

The VOLUME NO. and PAGE NO. are given to the right of each listing. The PAGE NO. refers to the page in the *Journal* on which the article containing the index word begins.

		Vol	Page
	— A —		
ATING OF CHROMIUM--COBALT ALLOYS CONTAINING A PHASE WITH THE	**A--15 STRUCTURE** PULSE PL	129	2433
LECTRICAL PROPERTIES OF Y-DOPED CEO2 CERAMICS: COMPARISON OF	**A-C** AND D-C MEASUREMENTS INHOMOGENEITY CONTRIBUTIO	129	2113
	A-C ANODIZING PROCESSES OF ALUMINUM ALLOYS	129	1572
THE NATURE OF THE PASSIVE FILM ON IRON II.	**A-C** IMPEDANCE STUDIES	129	474
DETERIORATED	**A-C** POWDER EL CELL BRIGHTNESS RECOVERY	129	362
THE	**A-C** RESPONSE OF NICKEL OXIDE ELECTRODE FILMS	129	535
SMALL-SIGNAL	**A-C** RESPONSE THEORY FOR ELECTROCHROMIC THIN FILMS	129	1754
HYDROGENATED	**A-SI(X)GE(1-X):** A POTENTIAL SOLAR CELL MATERIAL	129	2850
DIENTS. MOLTEN NANO3-AGNO3 IN POROUS YTTRIA SEM/EDX AND	**AA** MEASUREMENTS OF CURRENT-INDUCED COMPOSITION GRA	129	931
AUTOCATALYTIC DEPOSITION OF GOLD-COPPER	**AALLOYS**	129	1917
P HETEROJUNCTIONS LPE GROWTH TECHNIQUES FOR FABRICATING	**ABRUPT** ZINC- AND MAGNESIUM-DOPED P(+)-N INGAASP/IN	129	2085
ASS FILMS WATER	**ABSORPTION** AND DENSIFICATION OF PHOSPHOSILICATE GL	129	1765
HARGING OF SN AND CD COATINGS ON IRON HYDROGEN	**ABSORPTION** DURING ELECTRODEPOSITION AND HYDROGEN C	129	284
OPTICAL	**ABSORPTION** OF THIN SIPOS FILMS	129	197
ILANOL IN SILICON TETR PHOTOCHEMICAL PRODUCTION, INFRARED	**ABSORPTIVITY,** AND CHEMICAL REACTIONS OF TRICHLOROS	129	1619
ETCHING EFFECT ON	**AC** POWDER EL PHOSPHOR BRIGHTNESS AND MAINTENANCE	129	2059
CENTRATION IN POLYCRYSTALLINE FILMS AS A FUNCTION OF SURFACE	**ACCEPTOR** STATE DENSITY: APPLICATION FOR ZNO GAS SE	129	1382
CURRENT ON THE DEGREE OF POLYMERIZATION OF NITROCELLULOSE IN	**ACETONE-ISOPROPYL** ALCOHOL DEPENDENCE OF THE DIFFUS	129	1520
ECOBALT(I) AND BIS 6,6'-DIMETHYL-2,2'-BIPYRIDINECOBALT(I) IN	**ACETONITRILE** ELECTROCHEMISTRY AND ADSORPTION OF BI	129	1260
LLS BASED ON N-GAAS AND THE TRIIODIDE/IODIDE REDOX COUPLE IN	**ACETONITRILE** ELECTROCHEMICAL PHOTOVOLTAIC CE	129	1705
PHOTOELECTROCHEMISTRY OF N- AND P-TYPE SILICON IN	**ACETONITRILE**	129	1982
ELECTROCHEMICAL REDUCTION OF THIOPHOSGENE IN	**ACETONITRILE**	129	529
POLAROGRAPHY OF 4-CYANO-1-METHYLPYRIDINIUM ION IN	**ACETONITRILE**	129	2725
ED POTENTIAL COULOMETRY OF 4-CYANO-1-METHYLPYRIDINIUM ION IN	**ACETONITRILE** CONTROLL	129	2731
FROM SHIFTS IN THE FLATBAND POTENTIAL OF P-TYPPE SILICON IN	**ACETONITRILE** SOLUTIONS WITH DIFFERENT REDOX COUPLE	129	1742
THE ADSORPTION AND THE POTENTIODYNAMIC ELECTRO-OXIDATION OF	**ACETYLENE** ON PLATINIZED PLATINUM	129	1493
FECT OF ANTIMONY ON THE CORROSION OF TIN IN DEAERATED CITRIC	**ACID** THE EF	129	1651
CORROSION CHARACTERISTICS OF SOME ALUMINUM ALLOYS IN NITRIC	**ACID**	129	1869
ON OF LEAD SULFIDE DURING ANODIC DISSOLUTION IN HYDROCHLORIC	**ACID** THE NATURE OF PASSIVATI	129	271
N HF/SBF5: SOME MECHANISTIC CONCLUSIONS CONCERNING THE SUPER	**ACID** "CATALYZED" CONDENSATION OF HYDROCARBONS THE	129	1950
DIOXIDE ANODES UNDER CONDITIONS OF OZONE EVOLUTION IN STRONG	**ACID** ELECTROLYTES THE MECHANISM OF THE DISINTEGRAT	129	567
POLAROGRAPHY OF O-MERCAPTOBENZOIC	**ACID** IN AQUEOUS METHANOL AND DIOXANE	129	90
CTED IMINE DERIVATIVES, REDUCTIVE CARBOXYLATION, ALPHA-AMINO	**ACID** SYNTHESIS ELECTROCHEMICAL BEHAVIOR OF SELE	129	1231
SELF-DISCHARGE IN	**ACID-STARVED** LEAD-ACID BATTERIES	129	1393
MICAL PROPERTIES OF A LIGAND (BATHOPHENANTHROLINE DISULFONIC	**ACIDD)** BOUND TO POLYELECTROLYTES ON ELECTRODES AND	129	762
INTERACTIONS BETWEEN PHOTOINDUCED AND DARK CHARGE TRANSFER	**ACROSS** N-TIO2-AQUEOUS ELECTROLYTE INTERFACE	129	1240
LUMINESCENCE OF RARE EARTH	**ACTIVATED** LUTETIUM OXYHALIDE PHOSPHORS	129	1552
THERMALLY	**ACTIVATED** OXYGEN DONORS IN SI	129	2844
IMMOBILIZATION REACTIONS USING THIONYL CHLORIDE	**ACTIVATION** OF RUO2 AND PTO ELECTRODE SURFACES FOR	129	756
AND I A MODEL OF CRACK ELECTROCHEMISTRY FOR STEELS IN THE	**ACTIVE** STATE BASED ON MASS TRANSPORT BY DIFFUSION	129	1412
OCHROMIC AND ELECTROLYTIC DISPLAYS EFFECT OF	**ACTIVE** SURFACE AREA ON THE RESPONSE TIME OF ELECTR	129	2451
SOLUTIONS	**ACTIVITIES** AND SURFACE TENSION OF LIQUID AGCL-LICL	129	502
D CL2 PLASMA ETCHING OF III-V SEMICONDUCTORS AND THE ROLE OF	**ADDED** O2 CCL4 AN	129	1599
LYSULFIDE PHOTOELECTROCHEMICAL CELLS THE EFFECT OF	**ADDED** SALTS ON THE STABILITY OF CD-CHALCOGENIDE/PO	129	143
ENCE OF TB-ACTIVATED GARNET PHOSPHORS EFFECT OF V2O3	**ADDITION** ON THE THERMOLUMINESCENCE AND PHOSPHORESC	129	2638
ORMING ALLOYS IN COAL GASIFICATION AT THE ROLE OF SILICON	**ADDITIONS** IN THE CORROSION RESISTANCE OF CHROMIA-F	129	782
AND THERMODYNAMIC PROPERTIES OF O THE INFLUENCE OF SOLUTE	**ADDITIONS** OF COPPER AND SILVER ON THE DIFFUSIVITY	129	430
CENTURY OLIN PALLADIUM MEDAL	**ADDRESS--ELECTRO(ANALYTICAL)** CHEMISTRY EARLY THIS	129	59C
R, PROTONATION, ELECTROCHEMICAL REDUCTION OF NICOTINAMIDE	**ADENINE** DINUCLEOTIDE IN DIMETHYLSULFOXIDE: ION-PAI	129	1960
TITANIUM DIOXIDE FILMS TO IMPROVE PHOTORESIST	**ADHESION**	129	2389
NEW COUPLING METHOD FOR POLYIMIDE	**ADHESION** TO LSI SURFACE	129	2278
ITU ELECTROCHEMICAL REDUCTION OF OXYGEN IN THE DIMINUTION OF	**ADSORBED** BACTERIA ON METALS IN SEAWATER THE USE OF	129	2178
) PORPHYRIN ON CATALYSIS OF OXYGEN CATHODIC REDUCTION BY	**ADSORBED** IRON(111)-TETRA (N,N,N-TRIMETHYLANILINIUM	129	2247
IDATION OF HYDRAZINE CATALYZED BY SULFONATED PHTHALOCYANINES	**ADSORBED** ON A GRAPHITE ELECTRODE ELECTRO-OX	129	2242
ON OF ACETYLENE ON PLATINIZED PLATINUM THE	**ADSORPTION** AND THE POTENTIODYNAMIC ELECTRO-OXIDATI	129	1493
ORPTION PARAMETERS AND ADSORPTION RATES FOR DITHIOZONE ANION	**ADSORPTION** AT AG USING SURFACE ENHANCED AND RESONA	129	295C
INUCLEOTIDE IN DIMETHYLSULFOXIDE: ION-PAIR, PROTONATION, AND	**ADSORPTION** EFFECTS ELECTROCHEMICAL REDUCTION OF NI	129	1960
CHELATING-POLYMER	**ADSORPTION** EFFECTS ON CORROSION OF STEEL	129	2673
6,6'-DIMETHYL-2,2'-BIPYRIDINECOBALT ELECTROCHEMISTRY AND	**ADSORPTION** OF BIS 2,2'-BIPYRIDINECOBALT(I) AND BIS	129	1260
KINETICS OF ELECTROLESS COPPER PLATING VI. INHIBITION BY	**ADSORPTION** OF LIGAND	129	717
AN ESTIMATE OF THE HEAT OF	**ADSORPTION** OF THE HYDROPEROXYL RADICAL ON PLATINUM	129	1438
THE EDWARD WESTON SUMMER FELLOWSHIP REPORT--QUANTITATION OF	**ADSORPTION** PARAMETERS AND ADSORPTION RATES FOR DIT	129	295C
FELLOWSHIP REPORT--QUANTITATION OF ADSORPTION PARAMETERS AND	**ADSORPTION** RATES FOR DITHIOZONE ANION ADSORPTION A	129	295C
SIMS AND	**AES** ANALYSIS OF H:TIO2 ELECTRODES	129	94
INSB AN	**AES** EVALUATION OF CLEANING AND ETCHING METHODS FOR	129	2752
RESISTS FACTORS	**AFFECTING** THE SENSITIVITY OF CROSS-LINKED POSITIVE	129	402
TERS AND ADSORPTION RATES FOR DITHIOZONE ANION ADSORPTION AT	**AG** USING SURFACE ENHANCED AND RESONANCE ENHANCED R	129	295C
GOLD-CONTAINING SURFACE STATES ON PHOTOGRAPHIC	**AGBR** GRAINS: ROLES BESIDES PHOTOELECTRON-TRAPPING	129	591
ACTIVITIES AND SURFACE TENSION OF LIQUID	**AGCL-LICL** SOLUTIONS	129	502
Y AND IMPEDANCE TECHNIQUE STUDY OF	**AGF-LAF3** REVERSIBLE INTERFACE BY AUGER SPECTROSCOP	129	660
ON THE NATURE OF SURFACE FILMS FORMED ON IRON IN	**AGGRESSIVE** AND INHIBITING POLYPHOSPHATE SOLUTIONS	129	1186
ROLYTE OF CURRENT-INDUCED COMPOSITION GRADIENTS IN MOLTEN	**AGNO3-NANO3:** A MODEL SYSTEM FOR THE LICL-KCL ELECT	129	49
EXPLORATORY STUDIES ON ELECTROLYSIS OF	**AIN** DISSOLVED IN MOLTEN SALTS	129	102
POTENTIAL DISTRIBUTION ON A CARBON-BASED BIFUNCTIONAL	**AIR** ELECTRODE	129	1159
NSITIES I. EXPERIMENTAL PHENO SATURATION OF (ZN, CD)S:CU,	**AL** CATHODOLUMINESCENT PHOSPHORS AT HIGH CURRENT DE	129	1546
EFFECTS OF SEVERAL PARAMETERS ON THE CORROSION RATES OF	**AL** CONDUCTORS IN INTEGRATED CIRCUITS	129	2270
UNDER ULTRAHIGH VACUUM SI AND	**AL** ETCHING AND PRODUCT DETECTION IN A PLASMA BEAM	129	2045
II. OXIDATION OF	**AL** FILMS	129	2369
I. INTERACTION OF	**AL** FILMS WITH O2 AT LOW PRESSURES	129	2366
COMPLEXING OF	**AL(+3)** BY S(-2) IONS IN ALKALI HALIDE MELTS	129	2034
INFLUENCE OF SUBSTRATE TEMPERATURE ON THE MORPHOLOGY OF	**AL(X)GA(1-X)AS** GROWN BY MOLECULAR BEAM EPITAXY	129	824
TIONS	**AL-0.9PERCENT** SI/SI OHMIC CONTACTS TO SHALLOW JUNC	129	1335
LASER-SURFACE MELTING ON THE ELECTROCHEMICAL BEHAVIOR OF AN	**AL-1** PERCENT MN ALLOY EFFECT OF	129	9
ELECTRICAL PROPERTIES OF	**AL/TI** CONTACT METALLURGY FOR VLSI APPLICATION	129	2590
MENTAL ANALYSIS OF CHEMICAL VAPOR DEPOSITION OF ALUMINA FROM	**ALCL3-H2-CO2** GAS PHASE MIXTURES THERMODYNAMIC AND	129	1367
REE OF POLYMERIZATION OF NITROCELLULOSE IN ACETONE-ISOPROPYL	**ALCOHOL** DEPENDENCE OF THE DIFFUSION CURRENT ON THE	129	1520
PARABOLIC GROWTH OF NONUNIFORMLY DOPED OXIDES CONTAINING	**ALIOVALENT** IMPURITIES ON DILUTE ALLOYS	129	622

		Vol	Page
COMPLEXING OF AL(+3) BY S(-2) IONS IN	**ALKALI** HALIDE MELTS	129	2034
CTURE AND IONIC CONDUCTIVITY IN COMPLEXES OF POLYETHERS WITH	**ALKALI** METAL SALTS CONFORMATION AND ION-TRANSPORT	129	1694
OMBUSTOR/GAS TURBINE COMBI VOLATILIZATION/CONDENSATION OF	**ALKALI** SALTS IN A PRESSURIZED FLUIDIZED BED COAL C	129	2119
NOAMPEROMETRIC DETERMIN ELECTROCHEMICAL INVESTIGATIONS OF	**ALKALI-METAL** INTERCALATION REACTIONS IN TIS2: CHRO	129	682
IC VOLTAMMETRY AND CHRO ELECTROCHEMICAL INVESTIGATIONS OF	**ALKALI-METAL** INTERCALATION REACTIONS IN TIS2: CYCL	129	677
THE ELECTROCRYSTALLIZATION OF ZINC FROM	**ALKALINE** MEDIA	129	2654
MODULATION ON A ROTATIING D ZINC ELECTRODE MORPHOLOGY IN	**ALKALINE** SOLUTIONS I. STUDY OF ALTERNATING VOLTAGE	129	2677
FORMATION OF THIN OXIDE FILMS AT PLATINUM ANODES IN	**ALKALINE** SOLUTIONS III. PH DEPENDENCE	129	55
POROUS NICKEL-COATED STEEL ANODES FOR	**ALKALINE** WATER ELECTROLYSIS: CORROSION RESISTANCE	129	310
LYTE USED FOR THE ELECTROD DISPROPORTIONATION REACTION OF	**ALKYLBENZENES** IN ALUMINUM BROMIDE AND HBR (ELECTRO	129	40
ELTING ON THE ELECTROCHEMICAL BEHAVIOR OF AN AL-1 PERCENT MN	**ALLOY** EFFECT OF LASER-SURFACE M	129	9
CULATE BED ELEC SELECTIVE DISSOLUTION OF THE BINDER PHASE	**ALLOY** (CO-W) FROM WC-CO CEMENTED CARBIDES IN PARTI	129	2666
DISCHARGE CHARACTERISTICS OF LITHIUM-BORON	**ALLOY** ANODE IN MOLTEN SALT THERMAL CELLS	129	1168
DSC STUDY OF TWO REACTIONS IN THE LITHIUM-BORON	**ALLOY** SYSTEM	129	1513
SION RATES AND ELECTROCHEMICAL STUDIES OF A DEPLETED URANIUM	**ALLOY** TUNGSTEN FIBER METAL MATRIX COMPOSITE CORRO	129	1398
F SO2 AND PH ON THE ANODIC BEHAVIOR AND PITTING CORROSION OF	**ALLOY** 600 EFFECT O	129	2194
IGH-TEMPERATURE AQUEOUS SYSTEMS POTENTIAL/PH MEASUREMENTS IN	**ALLOY** 600 CREVICES AT 288DEGREE C CREVICE CORROSIO	129	2458
LECTROCHEMICALLY SEALED AL203 PASSIVATION LAYER FOR ALUMINUM	**ALLOYS** AN E	129	1865
THE HIGH SPEED ELECTRODEPOSITION OF SN/PB	**ALLOYS**	129	1196
N SPECTROSCOPIC STUDIES OF THE PASSIVE FILM ON IRON-CHROMIUM	**ALLOYS** ELECTRON AND IO	129	1662
A-C ANODIZING PROCESSES OF ALUMINUM	**ALLOYS**	129	1572
OF THE DIFFUSIONAL GROWTH OF TERNARY OXIDE SCALES ON BINARY	**ALLOYS** COMPUTER SIMULATION	129	209
RMLY DOPED OXIDES CONTAINING ALIOVALENT IMPURITIES ON DILUTE	**ALLOYS** PARABOLIC GROWTH OF NONUNIFO	129	622
NATE THE FORMATION OF LITHIUM-ALUMINUM	**ALLOYS** AT AN ALUMINUM ELECTRODE IN PROPYLENE CARBO	129	901
PULSE PLATING OF CHROMIUM--COBALT	**ALLOYS** CONTAINING A PHASE WITH THE A--15 STRUCTURE	129	2433
OMETRIC INVESTIGATION OF PASSIVE FILMS FORMED ON FE-25NI-XCR	**ALLOYS** IN BORATE BUFFER SOLUTION AN ELLIPS	129	2419
CON ADDITIONS IN THE CORROSION RESISTANCE OF CHROMIA-FORMING	**ALLOYS** IN COAL GASIFICATION ATMOSPHERES THE ROLE O	129	782
E OF CHROMIUM IN THE CORROSION RESISTANCE OF ALUMINA-FORMING	**ALLOYS** IN COAL GASIFICATION ATMOSPHERES THE ROL	129	789
CORROSION CHARACTERISTICS OF SOME ALUMINUM	**ALLOYS** IN NITRIC ACID	129	1869
STUDIES OF OCCLUDED CELLS IN THE PITTING OF DILUTE ALUMINUM	**ALLOYS** IN SEAWATER MORPHOLOGICAL	129	137
EXFOLIATION CORROSION OF ALMGSI	**ALLOYS** IN WATER	129	1181
CATHODIC DEPOSITION OF AMORPHOUS	**ALLOYS** OF SILICON, CARBON, AND FLUORINE	129	936
OLYSIS OF WATER TIO2-VO2	**ALLOYS**--REDUCED BANDGAP EFFECTS IN THE PHOTOELECTR	129	1210
TEN SALT BATTERIES THERMODYNAMIC STUDIES OF LI-GE	**ALLOYS**: APPLICATION TO NEGATIVE ELECTRODES FOR MOL	129	246
EXFOLIATION CORROSION OF	**ALMGSI** ALLOYS IN WATER	129	1181
VIOR OF SELECTED IMINE DERIVATIVES, REDUCTIVE CARBOXYLATION,	**ALPHA-AMINO** ACID SYNTHESIS ELECTROCHEMICAL BEHA	129	1231
THE EFFECT OF ARSENIC ON THE DEALLOYING OF	**ALPHA-BRASS**	129	2157
CTION OF O-NITROPHENOL IN THE PRESENCE OF P-NITROPHENOL WITH	**ALPHA-CYCLODEXTRIN** IN SOLUTION AND ON ELECTRODE SU	129	1681
CORROSION CRACKS	**ALTERATION** OF CORRODENT ION SPECIES WITHIN STRESS	129	780
L CELL ELECTROLYTE STRUCTURES	**ALTERNATE** MATRIX MATERIAL FOR MOLTEN CARBONATE FUE	129	979
ELECTROSYNTHESIS OF PROPYLENE OXIDE WITH	**ALTERNATING** CURRENT	129	1157
ZINC ELECTRODE MORPHOLOGY IN ALKALINE SOLUTIONS I. STUDY OF	**ALTERNATING** VOLTAGE MODULATION ON A ROTATIING DISK	129	2677
FOR BATTERY ELECTRODES	**ALUMINA** "FIBER FP" REINFORCED PURE LEAD COMPOSITES	129	1749
IC AND EXPERIMENTAL ANALYSIS OF CHEMICAL VAPOR DEPOSITION OF	**ALUMINA** FROM ALCL3-H2-CO2 GAS PHASE MIXTURES THERM	129	1367
HERES THE ROLE OF CHROMIUM IN THE CORROSION RESISTANCE OF	**ALUMINA-FORMING** ALLOYS IN COAL GASIFICATION ATMOSP	129	789
RIC DETERMINATION OF THE GIBBS ENERGIES OF FORMATION OF LEAD	**ALUMINATES** POTENTIOMET	129	1116
ETHOD ENTHALPIES OF FORMATION OF NIOBIUM	**ALUMINIDES** AS DETERMINED BY THE KNUDSEN EFFUSION M	129	1608
DEPOSITION TECHNIQUES AND HEAT TRANSFER PROPERTIES OF POROUS	**ALUMINUM**	129	1029
ILM RUPTURE, REANODIZATION, AND STRESS CORROSION CRACKING IN	**ALUMINUM** OXIDE F	129	2660
THE CURRENT DURING EARLY EVENTS IN THE PITTING CORROSION OF	**ALUMINUM** A SIGNATURE IN	129	340
A-C ANODIZING PROCESSES OF	**ALUMINUM** ALLOYS	129	1572
AN ELECTROCHEMICALLY SEALED AL203 PASSIVATION LAYER FOR	**ALUMINUM** ALLOYS	129	1865
CORROSION CHARACTERISTICS OF SOME	**ALUMINUM** ALLOYS IN NITRIC ACID	129	1869
HOLOGICAL STUDIES OF OCCLUDED CELLS IN THE PITTING OF DILUTE	**ALUMINUM** ALLOYS IN SEAWATER MORP	129	137
IATION OF CREVICE CORROSION I. EXPERIMENTAL INNVESTIGATIONS	**ALUMINUM** AND IRON INIT	129	481
ELECTROD DISPROPORTIONATION REACTION OF ALKYLBENZENES IN	**ALUMINUM** BROMIDE AND HBR (ELECTROLYTE USED FOR THE	129	40
IQUID ELECTROCHEMICAL STUDIES OF FE(II) AND FE(III) IN AN	**ALUMINUM** CHLORIDE-BUTYLPYRIDINIUM CHLORIDE IONIC L	129	2474
P THE CHEMICAL NATURE OF	**ALUMINUM** CORROSION II. THE INITIAL DISSOLUTION STE	129	27
DISSOLUTION THE CHEMICAL NATURE OF	**ALUMINUM** CORROSION V. ENERGY TRANSFER IN ALUMINUM	129	464
CHEMICAL NATURE OF ALUMINUM CORROSION V. ENERGY TRANSFER IN	**ALUMINUM** DISSOLUTION THE	129	464
THE FORMATION OF LITHIUM-ALUMINUM ALLOYS AT AN	**ALUMINUM** ELECTRODE IN PROPYLENE CARBONATE	129	901
CAL PROPERTIES OF POLYMER FILMS FORMED DURING THE ETCHING OF	**ALUMINUM** IN CCL4 PLASMAS CHEMI	129	2530
INITIATION OF CREVICE CORROSION II. MATHEMATICAL MODEL FOR	**ALUMINUM** IN SODIUM CHLORIDE SOLUTIONS	129	488
INETICS, AND MECHANISM OF GROWTH OF CHEMICAL VAPOR-DEPOSITED	**ALUMINUM** NITRIDE FILMS COMPOSITION, K	129	1045
NFLUORESCING DYES VISUAL DETECTION OF HYDRATED	**ALUMINUM** OXIDE BY STAINING WITH FLUORESCING AND NO	129	1517
VOIDS IN ANODIC	**ALUMINUM** OXIDE FILMS	129	711
THE EFFECTS OF MIXING N2 IN CCL4 ON	**ALUMINUM** REACTIVE ION ETCHING	129	2522
	ALUMINUM SPUTTER ETCHING USING SICL4	129	1150
OBSERVATIONS OF FLAWS ON PREC[illegible]TIONED	**ALUMINUM** SURFACES	129	1515
OMIDE AND HBR (ELECTROLYTE USED FOR THE ELECTRODEPOSITION OF	**ALUMINUM**) DISPROPORTIONATION REACTION OF ALKYLBENZ	129	40
AN ELECTROCHEMICALLY SEALED	**AL203** PASSIVATION LAYER FOR ALUMINUM ALLOYS	129	1865
PEG FORMATION BY SHORT-CIRCUIT DIFFUSION IN	**AL203** SCALES CONTAINING OXIDE DISPERSIONS	129	1147
REGATION OF LOW-DOSE IMPLANTED BORON IN SILICON UNDER DRY O2	**AMBIENT** DIFFUSION AND SEG	129	1097
	AMBIENT TEMPERATURE K-TIS2 CELL	129	230
LITHIUM-ALUMINUM ELECTRODES AT	**AMBIENT** TEMPERATURES	129	1429
CARBON AND OXYGEN TRANSPORT IN EFG OF SILICO MODELING OF	**AMBIENT-MENISCUS** MELT INTERACTIONS ASSOCIATED WITH	129	1356
CTROCHEMICAL BEHAVIOR OF P-TYPE SI SINGLE CRYSTALS IN LIQUID	**AMMONIA** AND IN LIQUID AMMONIATE OF SODIUM IODIDE P	129	1998
IN THE DISCH REACTIVE ION ETCHING OF SILICON OXIDES WITH	**AMMONIA** AND TRIFLUOROMETHANE. THE ROLE OF NITROGEN	129	1036
OXIDE EFFECTS OF	**AMMONIA** ANNEAL ON ELECTRON TRAPPINGS IN SILICON DI	129	2042
OF P-TYPE SI SINGLE CRYSTALS IN LIQUID AMMONIA AND IN LIQUID	**AMMONIATE** OF SODIUM IODIDE PHOTOELECTROCHEMICAL BE	129	1998
SIMS STUDIES OF SEMI-INSULATING INP	**AMORPHIZED** BY MG AND SI	129	1320
CATHODIC DEPOSITION OF	**AMORPHOUS** ALLOYS OF SILICON, CARBON, AND FLUORINE	129	936
EPITAXY USING SCANNING LA SINGLE CRYSTAL SILICON FILMS ON	**AMORPHOUS** INSULATORS: GROWTH BY LATERAL NUCLEATED	129	2802
US LOCAL OXIDATION AND RECRYSTALLIZATION OF VACUUM-DEPOSITED	**AMORPHOUS** SILICON BY CW LASER IRRADIATION ANOMALO	129	888
SITIVE MOBILE ION DENSITY IN SILICON DIOXIDE BY HYDROGENATED	**AMORPHOUS** SILICON FIELD EFFECT TECHNIQUE DETERMINA	129	2770
P-TYPE	**AMORPHOUS** SILICON/LIQUID JUNCTION SOLAR CELL	129	1644
ICONDUCTOR/ELECTROLYTE INTERFACE BY LAPLACE DOMAIN IMPEDANCE	**ANALYSIS** THE DETERMINATION OF SURFACE STATE ENERGI	129	2147
ENERGY	**ANALYSIS** OF A STEADY-STATE ELECTROCHEMICAL REACTOR	129	1936
ROM ALCL3-H2-CO2 GAS PHASE THERMODYNAMIC AND EXPERIMENTAL	**ANALYSIS** OF CHEMICAL VAPOR DEPOSITION OF ALUMINA F	129	1367

	Vol	Page
IN ULTRATHIN MEMBRANES THEORETICAL	129	958
THE GALVANOSTATIC METHOD:	129	1473
SIMS AND AES	129	94
NG METHODS	129	447
ATIC ELECTROCRYSTALLIZATION II. EXPERIMENTAL DEMONS IMAGE	129	2447
ATIC ELECTROCRYSTALLIZATION I. GENERAL EXPRESSION F IMAGE	129	2442
AND LIGHT FLUX VARIATION CURRENT-VOLTAGE	129	2029
TEN CARBONATE STRUCTURES	129	216
R/ELECTROLYTE/COUNTERELECTRODE CELLS EQUIVALENT CIRCUIT	129	551
ION TECHNIQUES FOR THE MEASUREMENT OF KINETICS OF E ERROR	129	1943
OF ADSORPTION PARAMETERS AND ADSORPTION RATES FOR DITHIOZONE	129	295C
ELECTROCHEMICAL OXIDATION OF POLYHEDRAL BORON HALIDE	129	1249
N DIFFERENCE HYDROGEN	129	806
EFFECTS OF AMMONIA	129	2042
ED WITH ARSE ELECTRICAL PROPERTIES OF THERMALLY AND LASER	129	1811
EPOSITED BY SPUTTERING AND BY COEVAPORATION AFTER ISOCHRONAL	129	1527
D DEFECT BEHAVIOR MULTISTEP REPEATED	129	2089
STUDY OF ENCAPSULANTS FOR	129	837
ECIOUS M THE DEVELOPMENT OF AN ENERGY-EFFICIENT INSOLUBLE	129	515
CIOUS ME THE DEVELOPMENT OF AN ENERGY-EFFICIENT INSOLUBLE	129	522
DISCHARGE CHARACTERISTICS OF LITHIUM-BORON ALLOY	129	1168
ROSCOPIC STUDIES OF THE HAZARDS OF LI/SOCL2 BATTERIES DURING	129	2496
HLORINE ON CATALYTICALLY MODIFIED N-SILICON/INDIUM TIN OXIDE	129	1934
RESISTANCE POROUS NICKEL-COATED STEEL	129	310
FORMATION OF THIN OXIDE FILMS AT PLATINUM	129	55
NG AC THE MECHANISM OF THE DISINTEGRATION OF LEAD DIOXIDE	129	567
ELECTROCHEMICAL SOLAR CELLS WITH LAYER-TYPE SEMICONDUCTOR	129	1155
VOIDS IN	129	711
EFFECT OF SO2 AND PH ON THE	129	2194
	129	255
METALS IN MOLTEN LICL-KCL CONTAINING OXIDE IONS	129	1245
SOLUTIONS THE	129	1192
THE NATURE OF PASSIVATION OF LEAD SULFIDE DURING	129	271
THE	129	506
50DEGREE C THE EFFECT OF SULFUR ON THE	129	1441
NT DISTRIBUTION CONDITIONS	129	946
COMPARED TO GLYCOL	129	2749
N HGTE	129	739
N CD0.2HG0.8TE	129	1710
INSTABILITY OF	129	1252
DY BY NUCLEAR MICROANALYSIS AND 180 TRACING OF THE GROWTH OF	129	1895
DY BY NUCLEAR MICROANALYSIS AND 180 TRACING OF THE GROWTH OF	129	1905
PREPARATION AND ELECTRICAL PROPERTIES OF AN	129	2795
OPTICAL STUDIES OF THE	129	1886
A POINT DEFECT MODEL FOR	129	1874
EXPERIMENTAL INVESTIGATION OF HIGH FIELD IONIC CONDUCTION IN	129	2513
CURREN AN INVESTIGATION OF HIGH FIELD IONIC CONDUCTION IN	129	2518
GALVANOSTATIC	129	1016
A-C	129	1572
TRANSPORT THROUGH NAFION MEMBRANE IN CHLOR-ALKALI CE THE	129	722
DIFFUSED INTO SILICON DUE TO LOCAL PR OBSERVATION OF THE	129	841
VACUUM-DEPOSITED AMORPHOUS SILICON BY CW LASER IRRADIATION	129	888
POROUS SILICON OXIDE	129	596
PR OBSERVATION OF THE ANOMALOUS CONCENTRATION PROFILES OF	129	841
IC ACID THE EFFECT OF	129	1651
IDATION OF TETRAMETHYLTIN AND TRIMETHYLANTIMONY	129	1040
NSHIPS: ARSENIC VAPOR PRESSURE-GAAS PROPERT BRIDGMAN-TYPE	129	388
DATION TEMPERATURES A VISCOUS FLOW MODEL TO EXPLAIN THE	129	2594
THE IN-P-O PHASE DIAGRAM: CONSTRUCTION AND	129	1361
N OF N-TYPE SEMICONDUCTING TUNGSTEN DISULFIDE PHOTOANODES IN	129	1461
INUM THE ELECTROCHEMISTRY AND PHOTOELECTROCHEMISTRY OF AN	129	1987
INP AND CDS PHOTOANODES IN CONCENTRATED	129	1977
POLAROGRAPHY OF O-MERCAPTOBENZOIC ACID IN	129	90
TROCHEMICAL PERFORMANCE OF ZNSE/CDSE THIN FILM ELECTRODES IN	129	542
THE STABILITY OF PITTING DISSOLUTION OF METALS IN	129	260
OR ELECTRODES XLVI. STABILIZATION OF N-SILICON ELECTRODES IN	129	1647
CTRODES XLV. PHOTOELECTROCHEMISTRY OF N- AND P-TYPE MOTE2 IN	129	2224
600 CREVICES AT 28 CREVICE CORROSION IN HIGH-TEMPERATURE	129	2458
ECTROLYTIC DISPLAYS EFFECT OF ACTIVE SURFACE	129	2451
A SCAN RATE DEPENDENT DETERMINATION OF PLATINUM	129	746
THE N-GAAS/ROOM TEMPERA PHOTOELECTROCHEMICAL OXIDATION OF	129	560
POLYMERIZATION OF	129	180
RESISTANCE OF A PLANAR	129	2715
Y A FOUR-PHASE COMPLEX REFRACTIVE IN OPTICAL CONSTANTS OF	129	606
ER ANNEALED POLYCRYSTALLINE SILICON FILMS HEAVILY DOPED WITH	129	1811
TION THE ENHANCED DIFFUSION OF	129	644
THE EFFECT OF	129	2157
PE APPARATUS FOR THE STUDY OF GROWTH-PROPERTY RELATIONSHIPS:	129	388
SPECTROSCOPY OF SILVER AND GOLD LEVELS IN LEC GROWN GALLIUM	129	1353
N ELECTRODE DESIGN FOR DUAL MEASUREMENT OF POTENTIALS INSIDE	129	669
OXIDE MICRO-PRECIPITATES IN	129	2790
ION OF GERMANIUM SURFACES AT PRESSURES MUCH GREATER THAN ONE	129	1845
ON RESISTANCE OF CHROMIA-FORMING ALLOYS IN COAL GASIFICATION	129	782
ON RESISTANCE OF ALUMINA-FORMING ALLOYS IN COAL GASIFICATION	129	789
ERVATION OF THE ANOMALOUS CONCENTRATION PROFILES OF ANTIMONY	129	841
TERFACE COMPOSITION STUDIES OF THERMALLY OXIDIZED GAAS USING	129	851
E CLEANING PROCEDURES	129	406
STUDY OF AGF-LAF3 REVERSIBLE INTERFACE BY	129	660
	129	1917

	Vol	Page
ANALYSIS OF ELECTROSTATIC EFFECTS ON ION TRANSPORT	129	958
ANALYSIS OF ERROR AND COMPUTATION OF PARAMETERS	129	1473
ANALYSIS OF H:TIO2 ELECTRODES	129	94
ANALYSIS OF INP SURFACE PREPARED BY VARIOUS CLEANI	129	447
ANALYSIS OF MORPHOLOGICAL INSTABILITY IN GALVANOST	129	2447
ANALYSIS OF MORPHOLOGICAL INSTABILITY IN GALVANOST	129	2442
ANALYSIS OF PHOTOELECTROCHEMICAL CELLS UNDER MASS	129	2029
ANALYSIS OF THE COMPRESSIVE STRENGTH OF LIALO2/MOL	129	216
ANALYSIS OF THE IMPEDANCE RESPONSE OF SEMICONDUCTO	129	551
ANALYSIS OF THE POTENTIAL AND VOLTAGE STEP RELAXAT	129	1943
ANION ADSORPTION AT AG USING SURFACE ENHANCED AND	129	295C
ANIONS	129	1249
ANNEAL EFFECTS ON METAL-SEMICONDUCTOR WORK FUNCTIO	129	806
ANNEAL ON ELECTRON TRAPPINGS IN SILICON DIOXIDE	129	2042
ANNEALED POLYCRYSTALLINE SILICON FILMS HEAVILY DOP	129	1811
ANNEALING CRYSTALLINE STRUCTURE CHANGES OF MOLYBDE	129	1527
ANNEALING FOR CZ-SILICON WAFERS: OXYGEN AND INDUCE	129	2089
ANNEALING SI-IMPLANTED GAAS	129	837
ANODE FOR NICKEL ELECTROWINNING I. SINGLE LAYER PR	129	515
ANODE FOR NICKEL ELECTROWINNING II. MULTILAYER PRE	129	522
ANODE IN MOLTEN SALT THERMAL CELLS	129	1168
ANODE-LIMITED CELL REVERSAL SPECT	129	2496
ANODES PHOTOELECTROCHEMICAL GENERATION OF C	129	1934
ANODES FOR ALKALINE WATER ELECTROLYSIS: CORROSION	129	310
ANODES IN ALKALINE SOLUTIONS III. PH DEPENDENCE	129	55
ANODES UNDER CONDITIONS OF OZONE EVOLUTION IN STRO	129	567
ANODES. NONAQUEOUS ELECTROLYTE CELLS	129	1155
ANODIC ALUMINUM OXIDE FILMS	129	711
ANODIC BEHAVIOR AND PITTING CORROSION OF ALLOY 600	129	2194
ANODIC BREAKDOWN OF PASSIVE FILMS ON METALS	129	255
ANODIC CORROSION AND PASSIVATION BEHAVIOR OF SOME	129	1245
ANODIC CORROSION OF GOLD IN CONCENTRATED CHLORIDE	129	1192
ANODIC DISSOLUTION IN HYDROCHLORIC ACID	129	271
ANODIC EVOLUTION OF OZONE	129	506
ANODIC H2(NI) ELECTRODE IN FUSED LI2CO3-K2CO3 AT 6	129	1441
ANODIC LEVELING UNDER SECONDARY AND TERTIARY CURRE	129	946
ANODIC OXIDATION OF P-TYPE SILICON IN METHANOL AS	129	2749
ANODIC OXIDE FILMS AND ELECTROCHEMICAL REACTIONS O	129	739
ANODIC OXIDE FILMS AND ELECTROCHEMICAL REACTIONS O	129	1710
ANODIC OXIDE FILMS ON TITANIUM	129	1252
ANODIC OXIDE FILMS ON ZIRCONIUM I. INFLUENCE OF FO	129	1895
ANODIC OXIDE FILMS ON ZIRCONIUM II. OXIDE GROWTH M	129	1905
ANODIC OXIDE OF INP	129	2795
ANODIC PASSIVATION OF TIN	129	1886
ANODIC PASSIVE FILMS III. IMPEDANCE RESPONSE	129	1874
ANODIC TANTALUM PENTOXIDE FILMS USING THE OPEN-CIR	129	2513
ANODIC TANTALUM PENTOXIDE FILMS USING THE STEPPED	129	2518
ANODIZATION OF GAAS IN METHANOLIC KOH	129	1016
ANODIZING PROCESSES OF ALUMINUM ALLOYS	129	1572
ANOLYTE DIFFUSION LAYER AND ITS EFFECT ON HYDROXYL	129	722
ANOMALOUS CONCENTRATION PROFILES OF ANTIMONY ATOMS	129	841
ANOMALOUS LOCAL OXIDATION AND RECRYSTALLIZATION OF	129	888
ANTI-REFLECTION COATING FOR SOLAR CELLS	129	596
ANTIMONY ATOMS DIFFUSED INTO SILICON DUE TO LOCAL	129	841
ANTIMONY ON THE CORROSION OF TIN IN DEAERATED CITR	129	1651
ANTIMONY-DOPED TIN OXIDE FILMS DEPOSITED BY THE OX	129	1040
APPARATUS FOR THE STUDY OF GROWTH-PROPERTY RELATIO	129	388
APPEARANCE OF HIGH DENSITY THERMAL SIO2 AT LOW OXI	129	2594
APPLICATIONS	129	1361
AQUEOUS AND NONAQUEOUS ELECTROLYTE SOLUTIONS. PHOT	129	1461
AQUEOUS FERROCENE/FERRICENIUM REDOX COUPLE AT PLAT	129	1987
AQUEOUS IODIDE ELECTROLYTES	129	1977
AQUEOUS METHANOL AND DIOXANE	129	90
AQUEOUS POLYSULFIDE ELECTROLYTE PHOTOELEC	129	542
AQUEOUS SOLUTION	129	260
AQUEOUS SOLUTION PHOTOELECTROCHEMICAL CELLS BY FOR	129	1647
AQUEOUS SOLUTIONS SEMICONDUCTOR ELE	129	2224
AQUEOUS SYSTEMS POTENTIAL/PH MEASUREMENTS IN ALLOY	129	2458
AREA ON THE RESPONSE TIME OF ELECTROCHROMIC AND EL	129	2451
AREAS	129	746
AROMATIC HYDROCARBONS AND DECAMETHYL FERROCENE AT	129	560
AROMATIC SILANES IN RF PLASMAS	129	180
ARRAY OF SPHERES: GAS BUBBLES ON AN ELECTRODE	129	2715
ARSENIC AND BORON IMPLANTS IN SILICON DETERMINED B	129	606
ARSENIC AND PHOSPHORUS ELECTRICAL PROPERTIES OF TH	129	1811
ARSENIC AND PHOSPHORUS IN SILICON BY THERMAL OXIDA	129	644
ARSENIC ON THE DEALLOYING OF ALPHA-BRASS	129	2157
ARSENIC VAPOR PRESSURE-GAAS PROPERTY RELATIONSHIP	129	388
ARSENIDE DEEP LEVEL TRANSIENT	129	1353
ARTIFICIAL PITS AND ON POLARIZED SURFACES A	129	669
AS-GROWN CZ SILICON	129	2790
ATMOSPHERE THE OXIDAT	129	1845
ATMOSPHERES THE ROLE OF SILICON ADDITIONS IN THE C	129	782
ATMOSPHERES THE ROLE OF CHROMIUM IN THE CORROSI	129	789
ATOMS DIFFUSED INTO SILICON DUE TO LOCAL PRECIPITA	129	841
AUGER DEPTH PROFILING IN	129	851
AUGER ELECTRON SPECTROSCOPY STUDY OF GAAS SUBSTRAT	129	406
AUGER SPECTROSCOPY AND IMPEDANCE TECHNIQUE	129	660
AUTOCATALYTIC DEPOSITION OF GOLD-COPPER AALLOYS	129	1917

		Vol	Page
THE NATURE OF THE PASSIVE FILM ON IRON I.	**AUTOMATIC** ELLIPSOMETRIC SPECTROSCOPY STUDIES	129	17
PHASES IN THE SYSTEM CUO-NIO-MGO AT 1000 DEG F.M. BECKET	**AWARD** REPORT--AN X-RAY POWDER DIFFRACTION STUDY OF	129	31C
	— B —		
FILMS EFFECT OF BACK-SIDE OXIDATION ON	**B** AND P DIFFUSION IN SI DIRECTLY MASKED WITH SI3N4	129	2292
CAL REACTIONS INVOLVED IN THE INITIATION OF HOT CORROSION OF	**B-1900** AND NASA-TRW VIA CHEMI	129	571
ECTLY MASKED WITH SI3N4 FILMS EFFECT OF	**BACK-SIDE** OXIDATION ON B AND P DIFFUSION IN SI DIR	129	2292
SCANNING LASER AND ELECTRON BEAMS AND EVALUATION BY ELECTRON	**BACKSCATTERING** CONTRAST SINGLE CRYSTAL SILICON FIL	129	2802
ROCHEMICAL REDUCTION OF OXYGEN IN THE DIMINUTION OF ADSORBED	**BACTERIA** ON METALS IN SEAWATER THE USE OF IN SITU	129	2178
TIO2-VO2 ALLOYS--REDUCED	**BANDGAP** EFFECTS IN THE PHOTOELECTROLYSIS OF WATER	129	1210
CONSTANTS FOR HYDROGEN PER COMMENTS ON THE VAN DER BRINK,	**BARENDRECHT,** AND VISSCHER METHOD TO EVALUATE RATE	129	2268
TS ON CURRENT-VOLTAGE CHARACTERISTICS OF ILLUMINATED SURFACE	**BARRIER** CELLS RECOMBINATION EFFEC	129	1134
LITHOGRAPHIC EVALUATION OF AN O-NITROBENZYL ESTER	**BASED** DEEP U.V. RESIST SYSTEM	129	2552
SOME SEMICONDUCT SEMICONDUCTOR LIQUID JUNCTION SOLAR CELL	**BASED** ON CHEMICALLY DEPOSITED BI2S3 THIN FILM AND	129	332
NEW SOLID ELECTROLYTES	**BASED** ON CUBIC ZRP2O7	129	726
DEL OF CRACK ELECTROCHEMISTRY FOR STEELS IN THE ACTIVE STATE	**BASED** ON MASS TRANSPORT BY DIFFUSION AND ION MIGRA	129	1412
PLE IN ACETONITRILE ELECTROCHEMICAL PHOTOVOLTAIC CELLS	**BASED** ON N-GAAS AND THE TRIIODIDE/IODIDE REDOX COU	129	1705
ELECTRODES II. SPECTROELECTROCHEMICAL PROPERTIES OF A LIGAND	**(BATHOPHENANTHROLINE** DISULFONIC ACIDD) BOUND TO PO	129	762
ZINC ELECTROCRYSTALLIZATION FROM IMPURITY-CONTAINING SULFATE	**BATHS**	129	2695
EASUREMENT OF ELECTROLESS PLATING RATE FOR COPPER AND NICKEL	**BATHS** BY COULOSTATIC METHOD M	129	2183
CERAMIC SEPARATORS FOR LI-AL/IRON SULFIDE	**BATTERIES**	129	2187
FROM MN-NH4-CARBAMATE AND ITS DISCHARGE PROPERTIES IN ZNCL2	**BATTERIES** THE SYNTHESIS OF DENSIFIED CMD	129	2372
STATE-OF-CHARGE INDICATOR FOR LEAD-ACID	**BATTERIES**	129	2409
SOME RESTATEMENTS ON THE NATURE AND BEHAVIOR OF MNO2 FOR LI	**BATTERIES**	129	1861
SOURCES OF PRESSURE IN LITHIUM THIONYL CHLORIDE	**BATTERIES**	129	2453
VIBRATING ZINC ELECTRODES IN NI/ZN	**BATTERIES**	129	913
SELF-DISCHARGE IN ACID-STARVED LEAD-ACID	**BATTERIES**	129	1393
E ALLOYS: APPLICATION TO NEGATIVE ELECTRODES FOR MOLTEN SALT	**BATTERIES** THERMODYNAMIC STUDIES OF LI-G	129	246
SPECTROSCOPIC STUDIES OF THE HAZARDS OF LI/SOCL2	**BATTERIES** DURING ANODE-LIMITED CELL REVERSAL	129	2496
SELF-DISCHARGE AND PASSIVATION PHENOMENA IN LEAD-ACID	**BATTERIES** DURING STORAGE	129	458
URVES OF THE DISCHARGE PRODUCT OF THE LITHIUM/SULFUR DIOXIDE	**BATTERY** X-RAY DIFFRACTION PATTERN AND DSC C	129	565
FLOW DISTRIBUTION IN THE ZINC-CHLORIDE	**BATTERY**	129	2251
ANO3: A MODEL SYSTEM FOR THE LICL-KCL ELECTROLYTE OF AN LI/S	**BATTERY** CURRENT-INDUCED COMPOSITION GRADIENTS IN M	129	49
ICAL BEHAVIOR OF SIMULATED NEGATIVE ELECTRODES FOR LI-AL/FES	**BATTERY** CELLS THERMOMECHAN	129	2265
LEAD DEFICIENCY AND HYDROGEN CONTENT IN	**BATTERY** ELECTRODE BETA-PBO2	129	1678
ALUMINA "FIBER FP" REINFORCED PURE LEAD COMPOSITES FOR	**BATTERY** ELECTRODES	129	1749
MATHEMATICAL MODEL FOR DESIGN OF	**BATTERY** ELECTRODES I. POTENTIAL DISTRIBUTION	129	688
SESSILE DROP STUDIES ON POLYBROMIDE/ZINC-BROMINE	**BATTERY** ELECTROLYTE	129	1747
TRANSFERENCE NUMBERS OF ZINC IN ZINC-CHLORIDE	**BATTERY** ELECTROLYTES	129	907
OPERATING PERFORMANCE OF AN FE-TI STATIONARY REDOX	**BATTERY** IN THE PRESENCE OF LEAD	129	2502
AIC SYSTEMS	**BATTERY** STATE OF CHARGE DETERMINATION IN PHOTOVOLT	129	1928
A MODEL FOR BORON DEPOSITION IN SILICON USING A	**BBR3** SOURCE	129	1592
THE ROLE OF	**BE** IN (GAAL)AS/GAAS SOLAR CELLS	129	1623
ATURE ON THE MORPHOLOGY OF AL(X)GA(1-X)AS GROWN BY MOLECULAR	**BEAM** EPITAXY INFLUENCE OF SUBSTRATE TEMPER	129	824
GE INCORPORATION IN GAAS GROWN BY MOLECULAR	**BEAM** EPITAXY: A THERMODYNAMIC STUDY	129	2108
SELECTIVE REACTIVE ION	**BEAM** ETCHING OF SIO2 OVER POLYCRYSTALLINE SI	129	396
AN ION SOURCE AND DETAILS OF SIO2 ETCHING REACTIVE ION	**BEAM** ETCHING WITH CF4: CHARACTERIZATION OF A KAUFM	129	585
IGHT DISTRIBUTIONS HIGH RESOLUTION ELECTRON	**BEAM** NEGATIVE RESIST WITH VERY NARROW MOLECULAR WE	129	663
A DRY DEVELOPMENT MODEL FOR A POSITIVE ELECTRON	**BEAM** RESIST	129	2598
SI AND AL ETCHING AND PRODUCT DETECTION IN A PLASMA	**BEAM** UNDER ULTRAHIGH VACUUM	129	2045
LATERAL NUCLEATED EPITAXY USING SCANNING LASER AND ELECTRON	**BEAMS** AND EVALUATION BY ELECTRON BACKSCATTERING CO	129	2802
TUDY OF PHASES IN THE SYSTEM CUO-NIO-MGO AT 1000 DEG F.M.	**BECKET** AWARD REPORT--AN X-RAY POWDER DIFFRACTION S	129	31C
TION/CONDENSATION OF ALKALI SALTS IN A PRESSURIZED FLUIDIZED	**BED** COAL COMBUSTOR/GAS TURBINE COMBINED CYCLE VOLA	129	2119
ASE ALLOY (CO-W) FROM WC-CO CEMENTED CARBIDES IN PARTICULATE	**BED** ELECTRODE SYSTEMS SELECTIVE DISSOLUTION OF THE	129	2666
AN EXPERIMENTAL STUDY OF A PACKED	**BED** ELECTRODE WITH COPPER PARTICLES	129	347
HETEROGENEOUS DECOMPOSITION OF SILANE IN A FIXED	**BED** REACTOR	129	1531
SURFACE ENHANCED RAMAN SCATTERING IN CORROSION SCIENCE:	**BENZOTRIAZOLE** ON COPPER	129	1716
MEASUREMENT OF ELECTRONIC CONDUCTIVITY IN FE-DOPED	**BETA-ALUMINA**	129	1968
LEAD DEFICIENCY AND HYDROGEN CONTENT IN BATTERY ELECTRODE	**BETA-PBO2**	129	1678
PROFILE CONTROL WITH O-C	**BIAS** IN PLASMA ETCHING	129	393
POTENTIAL DISTRIBUTION ON A CARBON-BASED	**BIFUNCTIONAL** AIR ELECTRODE	129	1159
ULATION OF THE DIFFUSIONAL GROWTH OF TERNARY OXIDE SCALES ON	**BINARY** ALLOYS COMPUTER SIM	129	209
THE REGULAR ASSOCIATED SOLUTION MODEL TO THE CD-TE AND HG-TE	**BINARY** SYSTEMS APPLICATION OF	129	2360
IDES IN PARTICULATE BED ELEC SELECTIVE DISSOLUTION OF THE	**BINDER** PHASE ALLOY (CO-W) FROM WC-CO CEMENTED CARB	129	2666
-2,2'-BIPYRIDINECOBALT ELECTROCHEMISTRY AND ADSORPTION OF	**BIS** 2,2'-BIPYRIDINECOBALT(I) AND BIS 6,6'-DIMETHYL	129	1260
CHEMISTRY AND ADSORPTION OF BIS 2,2'-BIPYRIDINECOBALT(I) AND	**BIS** 6,6'-DIMETHYL-2,2'-BIPYRIDINECOBALT(I) IN ACET	129	1260
OSITED BI2S3 THIN FILM AND SOME SEMICONDUCTING PROPERTIES OF	**BISMUTH** CHALCOGENIDES SEMICONDUCTOR LIQUID JUNCTIO	129	332
TOR LIQUID JUNCTION SOLAR CELL BASED ON CHEMICALLY DEPOSITED	**BI2S3** THIN FILM AND SOME SEMICONDUCTING PROPERTIES	129	332
RATION METHOD ELECTROCHEMISTRY OF PRUSSIAN	**BLUE** MODIFIED ELECTRODES: AN ELECTROCHEMICAL PREPA	129	1498
LOW TEMPERATURE DOUBLE-PLASMA PROCESS FOR	**BN** FILMS ON SEMICONDUCTORS	129	2636
CONTROLLED COLLAPSE REFLOW FOR JOSEPHSON CHIP	**BONDING**	129	859
ION TOPOGRAPHY WIRE	**BONDING** PROCESS CHARACTERIZATION BY X-RAY DIFFRACT	129	846
VESTIGATION OF PASSIVE FILMS FORMED ON FE-25NI-XCR ALLOYS IN	**BORATE** BUFFER SOLUTION AN ELLIPSOMETRIC IN	129	2419
A MODEL FOR	**BORON** DEPOSITION IN SILICON USING A BBR3 SOURCE	129	1592
ELECTROCHEMICAL OXIDATION OF POLYHEDRAL	**BORON** HALIDE ANIONS	129	1249
HEAT-TREATMENT EFFECT ON	**BORON** IMPLANTATION IN POLYCRYSTALLINE SILICON	129	1604
SE COMPLEX REFRACTIVE IN OPTICAL CONSTANTS OF ARSENIC AND	**BORON** IMPLANTS IN SILICON DETERMINED BY A FOUR-PHA	129	606
DIFFUSION AND SEGREGATION OF LOW-DOSE IMPLANTED	**BORON** IN SILICON UNDER DRY O2 AMBIENT	129	1097
IMPEDANCE MEASUREMENTS ON LITHIUM-ELECTROLYZED	**BOROSILICATE** GLASS	129	2617
PECTROMET CHARACTERIZATION OF NEAR SURFACE COMPOSITION OF	**BOROSILICATE** GLASSES (BSG) BY SECONDARY ION MASS S	129	1819
ROPERTIES OF A LIGAND (BATHOPHENANTHROLINE DISULFONIC ACIDD)	**BOUND** TO POLYELECTROLYTES ON ELECTRODES AND THE US	129	762
THE ELECTROLUMINESCENCE OF ZNS:CU,	**BR** PHOSPHOR	129	813
POLYSILICON/SIO2 INTERFACE MICROTEXTURE AND DIELECTRIC	**BREAKDOWN**	129	1282
EFFECTS OF PLASMA CLEANING ON THE DIELECTRIC	**BREAKDOWN** IN SIO2 FILM ON SI	129	224
ANODIC	**BREAKDOWN** OF PASSIVE FILMS ON METALS	129	255
OPERTY RELATIONSHIPS: ARSENIC VAPOR PRESSURE-GAAS PROPERTY R	**BRIDGMAN-TYPE** APPARATUS FOR THE STUDY OF GROWTH-PR	129	388
POTENTIODYNAMIC STUDY OF GLUCOSE ELECTRO-OXIDATION AT	**BRIGHT** PLATINUM ELECTRODES	129	2207
ETCHING EFFECT ON AC POWDER EL PHOSPHOR	**BRIGHTNESS** AND MAINTENANCE	129	2059
DETERIORATED A-C POWDER EL CELL	**BRIGHTNESS** RECOVERY	129	362

		Vol	Page
E RATE CONSTANTS FOR HYDROGEN PER	COMMENTS ON THE VAN DER BRINK, BARENDRECHT, AND VISSCHER METHOD TO EVALUAT	129	2268
DISPROPORTIONATION REACTION OF ALKYLBENZENES IN ALUMINUM	BROMIDE AND HBR (ELECTROLYTE USED FOR THE ELECTROD	129	40
	BROMINE REDUCTION IN A TWO-PHASE ELECTROLYTE	129	2397
RIZATION OF NEAR SURFACE COMPOSITION OF BOROSILICATE GLASSES	(BSG) BY SECONDARY ION MASS SPECTROMETRY (SIMS) CH	129	1819
PROPERTIES OF GARNET MATERIALS FOR CONTIGUOUS DISK MAGNETIC	BUBBLE MEMORY DEVICES	129	423
RESISTANCE OF A PLANAR ARRAY OF SPHERES: GAS	BUBBLES ON AN ELECTRODE	129	2715
TION OF PASSIVE FILMS FORMED ON FE-25NI-XCR ALLOYS IN BORATE	BUFFER SOLUTION AN ELLIPSOMETRIC INVESTIGA	129	2419

— C —

LECTROCHEMICAL ENGINEERING AND TECHNOLOGY MEDALIST JOSEPH	C. SCHUMACHER--VITTORIO DE NORA-DIAMOND SHAMROCK E	129	395C
IMPEDANCE AND MASS TRANSPORT KINETICS OF NICKEL	CADMIUM CELLS	129	289
S VII. PHOTOLUMINESCENT AND ELECTROLUMINESCENT PROPERTIES OF	CADMIUM SULFO-SELENIDE ELECTRODES LUMINESCENT PHOT	129	772
ATION CHEMISTRY AND THERMODYNAMICS OF SOLID SOLUTIONS IN THE	CADMIUM-INDIUM-SULFIDE, INDIUM-SULFIDE SYSTEM VAPO	129	1835
SOLUBILITIES OF MAGNESIUM AND	CALCIUM IN SILICON	129	2809
NCE AND SAFETY	CALCIUM-CA(ALCL4)2-THIONYL CHLORIDE CELL: PERFORMA	129	451
	CALCIUM-SULFURYL CHLORIDE PRIMARY CELL	129	897
LLINE FILMS AS A FUNCTION OF SURFACE ACCEPTOR STATE DENSITY:	CALCULATION OF CARRIER CONCENTRATION IN POLYCRYSTA	129	1382
EW	CALIBRATION TESTS OF AN ELECTROCHEMICAL CARBON MET	129	2746
ITH VERY THIN MATHEMATICAL MODELING OF THE LOW FREQUENCY	CAPACITANCE CHARACTERISTICS OF THE MOS STRUCTURE W	129	2547
INATION IN SILICON	CAPACITANCE TRANSIENT SPECTROSCOPY OF TRACE CONTAM	129	2098
TATUS CELLS: A DEMONSTRATION OF PERFORMANCE REPRODUCIBILITY,	CAPACITY RETENTION, AND CYCLE LIFE FOR LIAL/FES CE	129	2701
OLUTION OF THE BINDER PHASE ALLOY (CO-W) FROM WC-CO CEMENTED	CARBIDES IN PARTICULATE BED ELECTRODE SYSTEMS SELE	129	2666
CHEMICAL MODIFICATION OF RETICULATED VITREOUS	CARBON	129	2505
DELING OF AMBIENT-MENISCUS MELT INTERACTIONS ASSOCIATED WITH	CARBON AND OXYGEN TRANSPORT IN EFG OF SILICON RIBB	129	1356
ON(111)-TETRA (N,N,N-TRIMETHYLANILINIUM) PORPHYRIN ON GLASSY	CARBON ELECTRODES CATALYSIS OF OXYGEN CATHODIC RED	129	2247
MASS-TRANSFER STUDY OF	CARBON FELT, FLOW-THROUGH ELECTRODE	129	1993
CALIBRATION TESTS OF AN ELECTROCHEMICAL	CARBON METER	129	2746
POTENTIAL DISTRIBUTION ON A	CARBON-BASED BIFUNCTIONAL AIR ELECTRODE	129	1159
CATHODIC DEPOSITION OF AMORPHOUS ALLOYS OF SILICON,	CARBON, AND FLUORINE	129	936
ITHIUM-ALUMINUM ALLOYS AT AN ALUMINUM ELECTRODE IN PROPYLENE	CARBONATE THE FORMATION OF L	129	901
THE EFFECT OF THICKNESS ON THE PERFORMANCE OF MOLTEN	CARBONATE FUEL CELL CATHODES	129	2711
ALTERNATE MATRIX MATERIAL FOR MOLTEN	CARBONATE FUEL CELL ELECTROLYTE STRUCTURES	129	979
THE SPECIFIC CONDUCTANCE OF MOLTEN	CARBONATE FUEL CELL TILES	129	1745
THE THERMODYNAMICS OF ELECTROLYTE DISTRIBUTION IN MOLTEN	CARBONATE FUEL CELLS	129	942
EMICAL STUDIES OF THE FILM FORMATION ON LITHIUM IN PROPYLENE	CARBONATE SOLUTIONS UNDER OPEN-CIRCUIT CONDITIONS	129	1422
ANALYSIS OF THE COMPRESSIVE STRENGTH OF LIALO2/MOLTEN	CARBONATE STRUCTURES	129	216
DIFFUSION AND WATER SORPT A COMPARISON OF PERFLUORINATED	CARBOXYLATE AND SULFONATE ION EXCHANGE POLYMERS I.	129	324
SORPTION AND TRANSPORT P A COMPARISON OF PERFLUORINATED	CARBOXYLATE AND SULFONATE ION EXCHANGE POLYMERS II	129	328
ROCHEMICAL BEHAVIOR OF SELECTED IMINE DERIVATIVES, REDUCTIVE	CARBOXYLATION, ALPHA-AMINO ACID SYNTHESIS ELECT	129	1231
A FUNCTION OF SURFACE ACCEPTOR STATE DENSI CALCULATION OF	CARRIER CONCENTRATION IN POLYCRYSTALLINE FILMS AS	129	1382
CTION MICROSCOPY ON P-WSE2: RECOMBINATION SITES AND MINORITY	CARRIER DIFFUSION LENGTH CHARGE COLLE	129	418
IRON(111)-TETRA (N,N,N-TRIMETHYLANILINIUM) PORPHYRIN ON GLA	CATALYSIS OF OXYGEN CATHODIC REDUCTION BY ADSORBED	129	2247
COMPARISON OF MATERIALS AS OXYGEN	CATALYTIC ELECTRODES ON ZIRCONIA ELECTROLYTE	129	436
ANODES PHOTOELECTROCHEMICAL GENERATION OF CHLORINE ON	CATALYTICALLY MODIFIED N-SILICON/INDIUM TIN OXIDE	129	1934
N A GRAPHITE ELECTRODE ELECTRO-OXIDATION OF HYDRAZINE	CATALYZED BY SULFONATED PHTHALOCYANINES ADSORBED O	129	2242
TROCHEMISTRY OF THE THALLIC/THALLOUS COUPLE. THE THALLIC ION	CATALYZED PHOTO-OXIDATION OF PROPYLENE PHOTOELEC	129	2232
SBF5: SOME MECHANISTIC CONCLUSIONS CONCERNING THE SUPER ACID	"CATALYZED" CONDENSATION OF HYDROCARBONS THE ELECT	129	1950
PHTHALOCYANINE	CATHODE MATERIALS FOR SECONDARY LITHIUM CELLS	129	5
F THICKNESS ON THE PERFORMANCE OF MOLTEN CARBONATE FUEL CELL	CATHODES THE EFFECT O	129	2711
OF THE HYDROGEN EVOLUTION REACTION ON MILD STEEL AND NICKEL	CATHODES IN CONCENTRATED SODIUM HYDROXIDE SOLUTION	129	2481
CARBON, AND FLUORINE	CATHODIC DEPOSITION OF AMORPHOUS ALLOYS OF SILICON	129	936
A SEMICONDUCTOR MODEL FOR THE	CATHODIC PASSIVATION OF LEAD DIOXIDE	129	1880
THE INFLUENCE OF SURFACE RECOMBINATION AND TRAPPING ON THE	CATHODIC PHOTOCURRENT AT P-TYPE III-V ELECTRODES	129	730
THE EFFECT OF	CATHODIC POLARIZATION ON THE CREEP RATE OF GOLD	129	706
N,N-TRIMETHYLANILINIUM) PORPHYRIN ON CATALYSIS OF OXYGEN	CATHODIC REDUCTION BY ADSORBED IRON(111)-TETRA (N,	129	2247
OTION OF ELECTRONS AND HOLES IN Y2O2S CRYSTAL AS REVEALED BY	CATHODOLUMINESCENCE AN EXPERIMENTAL STUDY OF M	129	1535
SUBSTRATES SPATIALLY RESOLVED	CATHODOLUMINESCENCE STUDY OF SEMI-INSULATING GAAS	129	2386
EVALUATION OF DEFECTS IN CDTE USING A SIMPLE	CATHODOLUMINESCENCE TECHNIQUE	129	369
TIES I. EXPERIMENTAL PHENO SATURATION OF (ZN, CD)S:CU, AL	CATHODOLUMINESCENT PHOSPHORS AT HIGH CURRENT DENSI	129	1546
ENETRATION PHOSPHOR PREPARATION, OPTIMIZATION, AND	CATHODOLUMINESCENT PROPERTIES OF A LINE EMISSION P	129	1540
GALLATES PHOTO- AND	CATHODOLUMINESCENT PROPERTIES OF ERBIUM-DOPED THIO	129	2063
Y THE	CATION CONCENTRATION RESPONSE OF POLYMER GATE ISFE	129	141
LUTIONS A FRACTURE MECHANICS STUDY OF	CAUSTIC CRACKING OF MILD STEEL IN HOT NAOH/NA2S SO	129	2669
PREPARATION AND PROPERTIES OF	CA2V2O7 SINGLE CRYSTALS	129	2562
S AND THE ROLE OF ADDED O2	CCL4 AND CL2 PLASMA ETCHING OF III-V SEMICONDUCTOR	129	1599
PLANAR PLASMA ETCHING OF POLYSILICON USING	CCL4 AND NF3	129	795
THE EFFECTS OF MIXING N2 IN	CCL4 ON ALUMINUM REACTIVE ION ETCHING	129	2522
ES OF POLYMER FILMS FORMED DURING THE ETCHING OF ALUMINUM IN	CCL4 PLASMAS CHEMICAL PROPERTI	129	2530
ION DURING ELECTRODEPOSITION AND HYDROGEN CHARGING OF SN AND	CD COATINGS ON IRON HYDROGEN ABSORPT	129	284
URRENT DENSITIES I. EXPERIMENTAL PHENO SATURATION OF (ZN,	CD)S:CU, AL CATHODOLUMINESCENT PHOSPHORS AT HIGH C	129	1546
ELLS THE EFFECT OF ADDED SALTS ON THE STABILITY OF	CD-CHALCOGENIDE/POLYSULFIDE PHOTOELECTROCHEMICAL C	129	143
APPLICATION OF THE REGULAR ASSOCIATED SOLUTION MODEL TO THE	CD-TE AND HG-TE BINARY SYSTEMS	129	2360
THE PHOTOELECTROCHEMISTRY OF	CDIN2S4	129	2628
ERED RUO2 OVERLAYERS ON THE PHOTOELECTROCHEMICAL BEHAVIOR OF	CDS ELECTRODES THE EFFECT OF SPUTT	129	1733
CTROLYTES INP AND	CDS PHOTOANODES IN CONCENTRATED AQUEOUS IODIDE ELE	129	1977
SPRAY-PYROLYZED THIN FILM	CDSE PHOTOELECTROCHEMICAL CELLS	129	719
STRUCTURAL AND OPTICAL PROPERTIES OF SOLUTION GROWN	CDSE(1-X)S(X) FILMS	129	99
EVALUATION OF DEFECTS IN	CDTE USING A SIMPLE CATHODOLUMINESCENCE TECHNIQUE	129	369
ANODIC OXIDE FILMS AND ELECTROCHEMICAL REACTIONS ON	CDO.2HGO.8TE	129	1710
ITLOCKITE PHASE IN THE LUMINESCENT SYSTEM SRO-LI2O5-P2O5:MN,	CE WH	129	1373
A STUDY OF THE IRON ELECTRODE STRUCTURE OF NI-FE	CELL	129	1173
P-TYPE AMORPHOUS SILICON/LIQUID JUNCTION SOLAR	CELL	129	1644
N-MOSE2 PHOTOELECTROCHEMICAL HALOGEN STORAGE	CELL	129	233
AMBIENT TEMPERATURE K-TIS2	CELL	129	230
CALCIUM-SULFURYL CHLORIDE PRIMARY	CELL	129	897
N HYDROXYL TRANSPORT THROUGH NAFION MEMBRANE IN CHLOR-ALKALI	CELL THE ANOLYTE DIFFUSION LAYER AND ITS EFFECT O	129	722
SOLID POLYMER ELECTROLYTE PHOTOVOLTAIC	CELL	129	894
AND SOME SEMICONDUCT SEMICONDUCTOR LIQUID JUNCTION SOLAR	CELL BASED ON CHEMICALLY DEPOSITED BI2S3 THIN FILM	129	332
DETERIORATED A-C POWDER EL	CELL BRIGHTNESS RECOVERY	129	362

		Vol	Page
ECT OF THICKNESS ON THE PERFORMANCE OF MOLTEN CARBONATE FUEL	**CELL** CATHODES THE EFF	129	2711
ALTERNATE MATRIX MATERIAL FOR MOLTEN CARBONATE FUEL	**CELL** ELECTROLYTE STRUCTURES	129	979
CELL REACTIONS DESIGN OF A	**CELL** FOR ELECTRODE KINETIC INVESTIGATIONS OF FUEL	129	135
HYDROGENATED A-SI(X)GE(1-X): A POTENTIAL SOLAR	**CELL** MATERIAL	129	2850
E APPROACH TO NONFARADAIC ELECTROCHEMICAL KINETICS AT LIVING	**CELL** MEMBRANES A TRANSIENT IMPEDANC	129	526
ESIGN OF A CELL FOR ELECTRODE KINETIC INVESTIGATIONS OF FUEL	**CELL** REACTIONS D	129	135
ES OF THE HAZARDS OF LI/SOCL2 BATTERIES DURING ANODE-LIMITED	**CELL** REVERSAL SPECTROSCOPIC STUDI	129	2496
THE SPECIFIC CONDUCTANCE OF MOLTEN CARBONATE FUEL	**CELL** TILES	129	1745
CALCIUM-CA(ALCL4)2-THIONYL CHLORIDE	**CELL:** PERFORMANCE AND SAFETY	129	451
YNAMICS OF ELECTROLYTE DISTRIBUTION IN MOLTEN CARBONATE FUEL	**CELLS** THE THERMOD	129	942
POSITIVE ELECTRODES OF HIGH TEMPERATURE LI-AL/LICL-KCL/FES2	**CELLS** PHASE RELATIONSHIPS IN	129	925
ION OF NICKEL FOR POSITIVE ELECTRODE COMPONENTS IN LI-AL/FES	**CELLS** EVALUAT	129	496
N OF RICE HULLS AS A SOURCE OF SOLAR GRADE SILICON FOR SOLAR	**CELLS** PURIFICATIO	129	864
SPRAY-PYROLYZED THIN FILM CDSE PHOTOELECTROCHEMICAL	**CELLS**	129	719
DANCE RESPONSE OF SEMICONDUCTOR/ELECTROLYTE/COUNTERELECTRODE	**CELLS** EQUIVALENT CIRCUIT ANALYSIS OF THE IMPE	129	551
POROUS SILICON OXIDE ANTI-REFLECTION COATING FOR SOLAR	**CELLS**	129	596
OF TRANSITION METAL DICHALCOGENIDES IN PHOTOELECTROCHEMICAL	**CELLS** LOCAL SPECTRAL RESPONSES	129	1237
THE ROLE OF BE IN (GAAL)AS/GAAS SOLAR	**CELLS**	129	1623
ERISTICS OF LITHIUM-BORON ALLOY ANODE IN MOLTEN SALT THERMAL	**CELLS** DISCHARGE CHARACT	129	1168
RRENT-VOLTAGE CHARACTERISTICS OF ILLUMINATED SURFACE BARRIER	**CELLS** RECOMBINATION EFFECTS ON CU	129	1134
WITH LAYER-TYPE SEMICONDUCTOR ANODES. NONAQUEOUS ELECTROLYTE	**CELLS** ELECTROCHEMICAL SOLAR CELLS	129	1155
ANES FOR USE IN THREE-ELECTRODE PHOTOELECTROCHEMICAL STORAGE	**CELLS** TRANSPORT PROPERTIES OF NAFION MEMBR	129	2469
AVIOR OF SIMULATED NEGATIVE ELECTRODES FOR LI-AL/FES BATTERY	**CELLS** THERMOMECHANICAL BEH	129	2265
RACTERIZATION OF ETHER ELECTROLYTES FOR RECHARGEABLE LITHIUM	**CELLS** CHA	129	2404
PRODUCTS OF THE DISCHARGE AND FORCED OVERDISCHARGE OF LI/SO2	**CELLS** CHARACTERIZATION OF REACTIONS AND	129	1857
FORMANCE OF ELECTRODEPOSITED N-CDSE IN LIQUID JUNCTION SOLAR	**CELLS** MORPHOLOGY, PROPERTIES, AND PER	129	2016
TABILITY OF CD-CHALCOGENIDE/POLYSULFIDE PHOTOELECTROCHEMICAL	**CELLS** THE EFFECT OF ADDED SALTS ON THE S	129	143
PHTHALOCYANINE CATHODE MATERIALS FOR SECONDARY LITHIUM	**CELLS**	129	5
IMPEDANCE AND MASS TRANSPORT KINETICS OF NICKEL CADMIUM	**CELLS**	129	289
CS OF THE LITHIUM ELECTRODE DURING THE DISCHARGE OF LI/SOCL2	**CELLS** THE KINETI	129	2649
ODUCIBILITY, CAPACITY RETENTION, AND CYCLE LIFE FOR LIAL/FES	**CELLS** STATUS CELLS: A DEMONSTRATION OF PERFORMANCE	129	2701
PROCESS FOR HIGH PHOTOCURRENT IN IBC SOLAR	**CELLS**	129	2624
OX COUPLE IN ACETONITRILE ELECTROCHEMICAL PHOTOVOLTAIC	**CELLS** BASED ON N-GAAS AND THE TRIIODIDE/IODIDE RED	129	1705
-SILICON ELECTRODES IN AQUEOUS SOLUTION PHOTOELECTROCHEMICAL	**CELLS** BY FORMATION OF PLATINUM SILICIDE LAYERS SEM	129	1647
OPTIMIZATION OF ELECTROLYTIC	**CELLS** HAVING LARGE NUMBERS OF VARIABLES	129	1225
M TERNARY CHALCOGENIDE-BASED PHOTOELECTROCHEMICAL	**CELLS** II. THE N-CDIN2SE4/AQUEOUS POLYSULFIDE SYSTE	129	1506
SEAWATER MORPHOLOGICAL STUDIES OF OCCLUDED	**CELLS** IN THE PITTING OF DILUTE ALUMINUM ALLOYS IN	129	137
GAS FLOW PATTERNS IN HORIZONTAL EPITAXIAL REACTOR	**CELLS** OBSERVED BY INTERFERENCE HOLOGRAPHY	129	634
OPTICAL CHARACTERISTICS OF WO3 ELECTROCHROMIC	**CELLS** UNDER HEAVY LI ION INJECTION	129	2633
CURRENT-VOLTAGE ANALYSIS OF PHOTOELECTROCHEMICAL	**CELLS** UNDER MASS AND LIGHT FLUX VARIATION	129	2029
PROPERTIES OF CADMIUM S . LUMINESCENT PHOTOELECTROCHEMICAL	**CELLS** VII. PHOTOLUMINESCENT AND ELECTROLUMINESCENT	129	772
EOUS ELECTROLYTE CELLS ELECTROCHEMICAL SOLAR	**CELLS** WITH LAYER-TYPE SEMICONDUCTOR ANODES. NONAQU	129	1155
ITY, CAPACITY RETENTION, AND CYCLE LIFE FOR LIAL/F STATUS	**CELLS:** A DEMONSTRATION OF PERFORMANCE REPRODUCIBIL	129	2701
TIVE DISSOLUTION OF THE BINDER PHASE ALLOY (CO-W) FROM WC-CO	**CEMENTED** CARBIDES IN PARTICULATE BED ELECTRODE SYS	129	2666
DIUM MEDAL ADDRESS--ELECTRO(ANALYTICAL) CHEMISTRY EARLY THIS	**CENTURY** OLIN PALLA	129	59C
GENEITY CONTRIBUTION TO THE ELECTRICAL PROPERTIES OF Y-DOPED	**CEO2** CERAMICS: COMPARISON OF A-C AND D-C MEASUREME	129	2113
PH AT ELEVATED TEMPERATURES STABILIZED	**CERAMIC** MEMBRANE ELECTRODES FOR THE MEASUREMENT OF	129	1221
S	**CERAMIC** SEPARATORS FOR LI-AL/IRON SULFIDE BATTERIE	129	2187
TY CONTRIBUTION TO THE ELECTRICAL PROPERTIES OF Y-DOPED CEO2	**CERAMICS:** COMPARISON OF A-C AND D-C MEASUREMENTS I	129	2113
PARAMETER AND REACTOR DEPENDENCE OF SELECTIVE OXIDE RIE IN	**CF4 + H2**	129	2282
MICROWAVE PLASMA ETCHING OF SI WITH	**CF4** AND SF6 GAS	129	2764
DETAILS OF SIO2 ETCHING REACTIVE ION BEAM ETCHING WITH	**CF4:** CHARACTERIZATION OF A KAUFMAN ION SOURCE AND	129	585
THE N-CDIN2SE4/AQUEOUS POLYSULFIDE SYSTEM TERNARY	**CHALCOGENIDE-BASED** PHOTOELECTROCHEMICAL CELLS II.	129	1506
I2S3 THIN FILM AND SOME SEMICONDUCTING PROPERTIES OF BISMUTH	**CHALCOGENIDES** SEMICONDUCTOR LIQUID JUNCTION SOLAR	129	332
PHOTOELECTROCHEMICAL RESPONSE OF SOME LAYERED	**CHALCOGENOPHOSPHATE** COMPOUNDS (MPX3)	129	237
SPUTTERING AND BY COEVAPORATION AFT CRYSTALLINE STRUCTURE	**CHANGES** OF MOLYBDENUM SILICIDE FILMS DEPOSITED BY	129	1527
A NOVEL METHOD FOR MEASUREMENT OF THE	**CHANNEL** LENGTH OF SHORT CHANNEL MOSFET'S	129	1338
NOVEL METHOD FOR MEASUREMENT OF THE CHANNEL LENGTH OF SHORT	**CHANNEL** MOSFET'S A	129	1338
MASS TRANSFER IN LAMINAR FLOW	**CHANNEL** WITH POROUS WALL	129	1727
CTURAL COMPOSITION OF POLYMERS RELATIVE TO THEIR PLASMA ETCH	**CHARACTERISTICS** STRU	129	205
ARNISHING OF SILVER BY ORGANIC SULFUR VAPORS: RATES AND FILM	**CHARACTERISTICS** T	129	33
EFFECT OF THERMALLY NITRIDED SIO2 (NITROXIDE) ON MOS	**CHARACTERISTICS**	129	184
S MATERIAL COMPOSITION, OXIDATION RESISTANCE, AND ELECTRICAL	**CHARACTERISTICS** LOW ENERGY NITROGEN IMPLANTATION I	129	408
LS RECOMBINATION EFFECTS ON CURRENT-VOLTAGE	**CHARACTERISTICS** OF ILLUMINATED SURFACE BARRIER CEL	129	1134
D BY PLASMA OXIDATION'	**CHARACTERISTICS** OF INP MIS SCHOTTKY DIODES PREPARE	129	221
LTEN SALT THERMAL CELLS DISCHARGE	**CHARACTERISTICS** OF LITHIUM-BORON ALLOY ANODE IN MO	129	1168
UTIONS FOR GAAS/AL0.16GA0.84AS SELECTIVE ETCHING	**CHARACTERISTICS** OF PEROXIDE/AMMONIUM-HYDROXIDE SOL	129	2380
ACID CORROSION	**CHARACTERISTICS** OF SOME ALUMINUM ALLOYS IN NITRIC	129	1869
N MATHEMATICAL MODELING OF THE LOW FREQUENCY CAPACITANCE	**CHARACTERISTICS** OF THE MOS STRUCTURE WITH VERY THI	129	2547
HEAVY LI ION INJECTION OPTICAL	**CHARACTERISTICS** OF WO3 ELECTROCHROMIC CELLS UNDER	129	2633
LITHIUM CLOSOBORANE ELECTROLYTES III. PREPARATION AND	**CHARACTERIZATION**	129	2213
WIRE BONDING PROCESS	**CHARACTERIZATION** BY X-RAY DIFFRACTION TOPOGRAPHY	129	846
LS OF SIO2 ETCHING REACTIVE ION BEAM ETCHING WITH CF4:	**CHARACTERIZATION** OF A KAUFMAN ION SOURCE AND DETAI	129	585
CTROCHEMICAL PHOTOCAPACITANCE SPECTROSCOPY: A NEW METHOD FOR	**CHARACTERIZATION** OF DEEP LEVELS IN SEMICONDUCTORS	129	891
EABLE LITHIUM CELLS	**CHARACTERIZATION** OF ETHER ELECTROLYTES FOR RECHARG	129	2404
ELECTED DIODE STRUCTURES	**CHARACTERIZATION** OF FUSED GLASS PASSIVATION WITH S	129	154
PHIRE BY SCANNING PHOTOVOLTAGE MEASUREMENTS MICROSCALE	**CHARACTERIZATION** OF HETEROEPITAXIAL SILICON ON SAP	129	2609
DISULFIDE PHOTOANODES IN AQUEOUS AND NONAQUEOUS ELECTROLYTE	**CHARACTERIZATION** OF N-TYPE SEMICONDUCTING TUNGSTEN	129	1461
ROSILICATE GLASSES (BSG) BY SECONDARY ION MASS SPECTROMETRY	**CHARACTERIZATION** OF NEAR SURFACE COMPOSITION OF BO	129	1819
DISCHARGE AND FORCED OVERDISCHARGE OF LI/SO2 CELLS	**CHARACTERIZATION** OF REACTIONS AND PRODUCTS OF THE	129	1857
RFACE BY DEEP LEVEL TRANSIENT SPECTROSCOPY	**CHARACTERIZATION** OF REACTIVE ION ETCHED SILICON SU	129	2823
A DEEP IMPURITY LEVEL	**CHARACTERIZATION** OF SEMICONDUCTOR ELECTRODES WITH	129	2219
TEN SALT ELECTROLYTE INTERFACE PHOTOELECTROCHEMICAL	**CHARACTERIZATION** OF THE N-INP/ROOM TEMPERATURE MOL	129	2009
ION SITES AND MINORITY CARRIER DIFFUSION LENGTH	**CHARGE** COLLECTION MICROSCOPY ON P-WSE2: RECOMBINAT	129	418
THIN OXIDES FIXED	**CHARGE** DENSITY (QSS) AT THE SI-SIO2 INTERFACE FOR	129	1757
BATTERY STATE OF	**CHARGE** DETERMINATION IN PHOTOVOLTAIC SYSTEMS	129	1928
N MOSFET'S DUE TO SUBSTRATE HOT-ELECTRO INTERFACE TRAPPED	**CHARGE** GENERATION AND ELECTRON TRAPPING KINETICS I	129	1760
INTERFACE INTERACTIONS BETWEEN PHOTOINDUCED AND DARK	**CHARGE** TRANSFER ACROSS N-TIO2-AQUEOUS ELECTROLYTE	129	1240
A INTERFACE STATES: UNIFIED MODEL AND COMPARISON WITH EXPERI	**CHARGE** TRANSFER IN PHOTOELECTROCHEMICAL DEVICES VI	129	1003

		Vol	Page
CTIONS IN TIS2: CHRONOAMPEROMETRIC DETERMINATION OF MASS AND	**CHARGE** TRANSPORT PROPERTIES OF LIQUID ELECTROLYTE	129	682
HYDROGEN ABSORPTION DURING ELECTRODEPOSITION AND HYDROGEN	**CHARGING** OF SN AND CD COATINGS ON IRON	129	284
OF STEEL	**CHELATING-POLYMER** ADSORPTION EFFECTS ON CORROSION	129	2673
NCE THE NATURE OF THE PASSIVE FILM ON IRON III. THE	**CHEMI-CONDUCTOR** MODEL AND FURTHER SUPPORTING EVIDE	129	921
OF THIN (100) ORIENTED SILICON EPITAXIAL LAYERS USING A WET	**CHEMICAL** ETCH METHODS FOR DEFECT EVALUATION	129	2074
	CHEMICAL ETCHING OF INGAASP/INP DH WAFER	129	1053
	CHEMICAL ETCHING OF INP AND INGAASP/INP	129	609
OF SB2SE3 AND SB2O3	**CHEMICAL** METHODS FOR THE DEPOSITION OF THIN FILMS	129	1642
ON	**CHEMICAL** MODIFICATION OF RETICULATED VITREOUS CARB	129	2505
IAL DISSOLUTION STEP THE	**CHEMICAL** NATURE OF ALUMINUM CORROSION II. THE INIT	129	27
ANSFER IN ALUMINUM DISSOLUTION THE	**CHEMICAL** NATURE OF ALUMINUM CORROSION V. ENERGY TR	129	464
THE ETCHING OF ALUMINUM IN CCL4 PLASMAS	**CHEMICAL** PROPERTIES OF POLYMER FILMS FORMED DURING	129	2530
ICA FILMS IN WA AN 18O STUDY OF COOPERATIVE DIFFUSION AND	**CHEMICAL** REACTION DURING THERMAL TREATMENTS OF SIL	129	867
OT CORROSION OF B-1900 AND NASA-TRW VIA	**CHEMICAL** REACTIONS INVOLVED IN THE INITIATION OF H	129	571
TETR PHOTOCHEMICAL PRODUCTION, INFRARED ABSORPTIVITY, AND	**CHEMICAL** REACTIONS OF TRICHLOROSILANOL IN SILICON	129	1619
T A CORROSION-RESISTANT TITANIUM-RICH DEPOSIT PREPARED BY	**CHEMICAL** VAPOR DEPOSITION AT LOW TEMPERATURE FROM	129	854
-CO2 GAS PHASE THERMODYNAMIC AND EXPERIMENTAL ANALYSIS OF	**CHEMICAL** VAPOR DEPOSITION OF ALUMINA FROM ALCL3-H2	129	1367
THERMODYNAMICS AND KINETICS OF IODINE	**CHEMICAL** VAPOR TRANSPORT OF GEAS	129	1343
COMPOSITION, KINETICS, AND MECHANISM OF GROWTH OF	**CHEMICAL** VAPOR-DEPOSITED ALUMINUM NITRIDE FILMS	129	1045
CONDUCT SEMICONDUCTOR LIQUID JUNCTION SOLAR CELL BASED ON	**CHEMICALLY** DEPOSITED Bi2S3 THIN FILM AND SOME SEMI	129	332
INGAASP/INP PLANAR-STRIPE LASERS WITH	**CHEMICALLY** ETCHED MIRRORS	129	883
ION OF O-NITROPHENOL IN THE SELECTIVE ELECTROSYNTHESES ON	**CHEMICALLY** MODIFIED ELECTRODE IV. SELECTIVE REDUCT	129	1681
MER FELLOWSHIP REPORT--FOURIER TRANSFORM INFRARED STUDIES OF	**CHEMICALLY** MODIFIED ELECTRODE SURFACES THE JOSEPH	129	300C
THE CADMIUM-INDIUM-SULFIDE, INDIUM-SULFIDE VAPORIZATION	**CHEMISTRY** AND THERMODYNAMICS OF SOLID SOLUTIONS IN	129	1835
INTERFACIAL	**CHEMISTRY** AT P-GAP PHOTOELECTRODES	129	2141
OLIN PALLADIUM MEDAL ADDRESS--ELECTRO(ANALYTICAL)	**CHEMISTRY** EARLY THIS CENTURY	129	59C
CONTROLLED COLLAPSE REFLOW FOR JOSEPHSON	**CHIP** BONDING	129	859
ITS EFFECT ON HYDROXYL TRANSPORT THROUGH NAFION MEMBRANE IN	**CHLOR-ALKALI** CELL THE ANOLYTE DIFFUSION LAYER AND	129	722
HLORIDE IONIC LI AN ELECTROCHEMICAL AND INFRARED STUDY OF	**CHLORANIL** IN N-BUTYLPYRIDINIUM CHLORIDE:ALUMINUM C	129	2739
LECTRODE SURFACES FOR IMMOBILIZATION REACTIONS USING THIONYL	**CHLORIDE** ACTIVATION OF RUO2 AND PTO E	129	756
SOURCES OF PRESSURE IN LITHIUM THIONYL	**CHLORIDE** BATTERIES	129	2453
CALCIUM-CA(ALCL4)2-THIONYL	**CHLORIDE** CELL: PERFORMANCE AND SAFETY	129	451
F FE(II) AND FE(III) IN AN ALUMINUM CHLORIDE-BUTYLPYRIDINIUM	**CHLORIDE** IONIC LIQUID ELECTROCHEMICAL STUDIES O	129	2474
ED STUDY OF CHLORANIL IN N-BUTYLPYRIDINIUM CHLORIDE:ALUMINUM	**CHLORIDE** IONIC LIQUID AN ELECTROCHEMICAL AND INFRA	129	2739
CALCIUM-SULFURYL	**CHLORIDE** PRIMARY CELL	129	897
ON THE MECHANISM OF THIONYL	**CHLORIDE** REDUCTION	129	1853
VICE CORROSION II. MATHEMATICAL MODEL FOR ALUMINUM IN SODIUM	**CHLORIDE** SOLUTIONS INITIATION OF CRE	129	488
THE ANODIC CORROSION OF GOLD IN CONCENTRATED	**CHLORIDE** SOLUTIONS	129	1192
ELECTROCHEMICAL STUDIES OF FE(II) AND FE(III) IN AN ALUMINUM	**CHLORIDE-BUTYLPYRIDINIUM** CHLORIDE IONIC LIQUID	129	2474
CONDUCTANCE STUDIES IN THIONYL	**CHLORIDE:** II	129	1165
HEMICAL AND INFRARED STUDY OF CHLORANIL IN N-BUTYLPYRIDINIUM	**CHLORIDE:ALUMINUM** CHLORIDE IONIC LIQUID AN ELECTRO	129	2739
F THE FIRST ELECTROLYTIC PLUTONIUM AND OF URANIUM FROM FUSED	**CHLORIDES** PREPARATION O	129	2438
CE STRUCTURE OF RUTHENIUM DIOXIDE ELECTRODES AND KINETICS OF	**CHLORINE** EVOLUTION SURFA	129	1689
M TIN OXIDE ANODES PHOTOELECTROCHEMICAL GENERATION OF	**CHLORINE** ON CATALYTICALLY MODIFIED N-SILICON/INDIU	129	1934
TEMPERATURE DEPENDENCE OF INP AND GAAS ETCHING IN A	**CHLORINE** PLASMA	129	2535
OXIDATION OF SULFUR IN	**CHLOROALUMINATE** MELTS OF INTERMEDIATE PCL	129	2237
OF INORGANIC SOLUTES RELEVANT TO REVERSE O USE OF LIQUID	**CHROMATOGRAPHY** FOR STUDYING INTERFACIAL PROPERTIES	129	1485
THE ROLE OF SILICON ADDITIONS IN THE CORROSION RESISTANCE OF	**CHROMIA-FORMING** ALLOYS IN COAL GASIFICATION ATMOSP	129	782
RMING ALLOYS IN COAL GASIFICATION ATMOSPHERES THE ROLE OF	**CHROMIUM** IN THE CORROSION RESISTANCE OF ALUMINA-FO	129	789
E A--15 STRUCTURE PULSE PLATING OF	**CHROMIUM--COBALT** ALLOYS CONTAINING A PHASE WITH TH	129	2433
ESTIGATIONS OF ALKALI-METAL INTERCALATION REACTIONS IN TIS2:	**CHRONOAMPEROMETRIC** DETERMINATION OF MASS AND CHARG	129	682
ETAL INTERCALATION REACTIONS IN TIS2: CYCLIC VOLTAMMETRY AND	**CHRONOCOULOMETRY** OF LIQUID ELECTROLYTE SYSTEMS ELE	129	677
MULTIPLE-ETCHANT LOADING EFFECT AND SILICON ETCHING IN	**CIF3** AND RELATED MIXTURES	129	2755
CONDUCTOR/ELECTROLYTE/COUNTERELECTRODE CELLS EQUIVALENT	**CIRCUIT** ANALYSIS OF THE IMPEDANCE RESPONSE OF SEMI	129	551
URE FOR EVALUATING THE LINEWIDTH UNIFORMITY OF AN INTEGRATED	**CIRCUIT** LITHOGRAPHY SYSTEM A CROSS-BRIDGE TEST STR	129	2313
F IRON CONTAMINATION IN SILICON SUBSTRATES AND ITS IMPACT ON	**CIRCUIT** YIELD A SURVEY O	129	2573
METERS ON THE CORROSION RATES OF AL CONDUCTORS IN INTEGRATED	**CIRCUITS** EFFECTS OF SEVERAL PARA	129	2270
HIGH-SPEED SELECTIVE ELECTROPLATING WITH SINGLE	**CIRCULAR** JETS	129	2424
THE EFFECT OF ANTIMONY ON THE CORROSION OF TIN IN DEAERATED	**CITRIC** ACID	129	1651
IMPACT OF DEIONIZED WATER RINSES ON SILICON SURFACE	**CLEANING**	129	1027
AN AES EVALUATION OF	**CLEANING** AND ETCHING METHODS FOR INSB	129	2752
ANALYSIS OF INP SURFACE PREPARED BY VARIOUS	**CLEANING** METHODS	129	447
ON SI EFFECTS OF PLASMA	**CLEANING** ON THE DIELECTRIC BREAKDOWN IN SIO2 FILM	129	224
AUGER ELECTRON SPECTROSCOPY STUDY OF GAAS SUBSTRATE	**CLEANING** PROCEDURES	129	406
ACTERIZATION LITHIUM	**CLOSOBORANE** ELECTROLYTES III. PREPARATION AND CHAR	129	2213
GENERALIZED MODEL FOR THE	**CLUSTERING** OF AS DOPANTS IN SI	129	1826
ROLE OF ADDED O2 CCL4 AND	**CL2** PLASMA ETCHING OF III-V SEMICONDUCTORS AND THE	129	1599
TIES IN ZNCL2 BATTERIES THE SYNTHESIS OF DENSIFIED	**CMD** FROM MN-NH4-CARBAMATE AND ITS DISCHARGE PROPER	129	2372
BED ELEC SELECTIVE DISSOLUTION OF THE BINDER PHASE ALLOY	**(CO-W)** FROM WC-CO CEMENTED CARBIDES IN PARTICULATE	129	2666
/CONDENSATION OF ALKALI SALTS IN A PRESSURIZED FLUIDIZED BED	**COAL** COMBUSTOR/GAS TURBINE COMBINED CYCLE VOLATILI	129	2119
IUM IN THE CORROSION RESISTANCE OF ALUMINA-FORMING ALLOYS IN	**COAL** GASIFICATION ATMOSPHERES THE ROLE OF CHROM	129	789
ONS IN THE CORROSION RESISTANCE OF CHROMIA-FORMING ALLOYS IN	**COAL** GASIFICATION ATMOSPHERES THE ROLE OF SILICON	129	782
ELECTROCHEMICAL STUDIES OF	**COAL** SLURRY OXIDATION MECHANISMS	129	1719
S GATE OXIDE DEFECTS RELATED TO TREATMENT OF SILICON NITRIDE	**COATED** WAFERS PRIOR TO LOCAL OXIDATION MO	129	1066
POROUS SILICON OXIDE ANTI-REFLECTION	**COATING** FOR SOLAR CELLS	129	596
NODE FOR NICKEL ELECTROWINNING II. MULTILAYER PRECIOUS METAL	**COATINGS** THE DEVELOPMENT OF AN ENERGY-EFFICIENT IN	129	522
ODE FOR NICKEL ELECTROWINNING I. SINGLE LAYER PRECIOUS METAL	**COATINGS** THE DEVELOPMENT OF AN ENERGY-EFFICIENT IN	129	515
DURING ELECTRODEPOSITION AND HYDROGEN CHARGING OF SN AND CD	**COATINGS** ON IRON HYDROGEN ABSORPTION	129	284
THE MECHANICS OF ELECTROCHEMICALLY COPRECIPITATED	**COBALT** HYDROXIDE IN NICKEL HYDROXIDE ELECTRODES	129	118
R SPECTROSCOPIC STUDY OF THE CORROSION INHIBITION OF ZINC BY	**COBALT** IONS MOSSBAUE	129	1658
UTION REDOOX COUPLES FOR EELECTROCHEMICAL ENERGY STORAGE II.	**COBALT(III)-COBALT(II)** COMPLEXES WITH O-PHENANTHRO	129	61
OF MOLYBDENUM SILICIDE FILMS DEPOSITED BY SPUTTERING AND BY	**COEVAPORATION** AFTER ISOCHRONAL ANNEALING CRYSTALLI	129	1527
RMINATION OF HETEROGENEOUS ELECTRON TRANSFER KINETIC THE	**COLIN** GARFIELD FINK SUMMER FELLOWSHIP REPORT--DETE	129	298C
CONTROLLED	**COLLAPSE** REFLOW FOR JOSEPHSON CHIP BONDING	129	859
ES AND MINORITY CARRIER DIFFUSION LENGTH CHARGE	**COLLECTION** MICROSCOPY ON P-WSE2: RECOMBINATION SIT	129	418
US ELECTRODES THE EFFECT OF MULTIPLE CURRENT	**COLLECTORS** ON THE PERFORMANCE F FLOW-THROUGH PORO	129	991
THE ELECTROCHEMICAL RESPONSE OF NICKEL HYDROXIDE FORMED BY	**COLLOIDAL** PRECIPITATION ON DIFFERENT CONDUCTING SU	129	301
TS IN A PRESSURIZED FLUIDIZED BED COAL COMBUSTOR/GAS TURBINE	**COMBINED** CYCLE VOLATILIZATION/CONDENSATION OF ALKA	129	2119
INTERFEROMETRIC STUDY OF	**COMBINED** FORCED AND NATURAL CONVECTION	129	2201

	Vol	Page
ENSATION OF ALKALI SALTS IN A PRESSURIZED FLUIDIZED BED COAL	129	2119
SSCHER METHOD TO EVALUATE RATE CONSTANTS FOR HYDROGEN PEROXI	129	2268
VESTIGATION OF THE THICKNESS VARIATION OF SPUN-ON THIN FILMS	129	173
ISIBLE LIGHT CONVERSION AT ONE-DIMENSIONAL NICKEL DITHIOLENE	129	2378
NIC AND BORON IMPLANTS IN SILICON DETERMINED BY A FOUR-PHASE	129	606
SPECTROSCOPIC DETERMINATION OF STRUCTURE AND ION PAIRING IN	129	1434
TRANSPORT MODELS FOR THE STRUCTURE AND IONIC CONDUCTIVITY IN	129	1694
R EELECTROCHEMICAL ENERGY STORAGE II. COBALT(III)-COBALT(II)	129	61
E MELTS	129	2034
EVALUATION OF NICKEL FOR POSITIVE ELECTRODE	129	496
DIES OF A DEPLETED URANIUM ALLOY TUNGSTEN FIBER METAL MATRIX	129	1398
ES ELECTRICAL PROPERTIES OF	129	1307
PLASMA ETCHING OF	129	1330
ALUMINA "FIBER FP" REINFORCED PURE LEAD	129	1749
LECTROCHEMICAL CORROSION OF IRON-BORON METALLIC EFFECT OF	129	695
EL SYSTEM FOR THE LICL-KCL ELECTROLYTE OF CURRENT-INDUCED	129	49
S YTTRIA SEM/EDX AND AA MEASUREMENTS OF CURRENT-INDUCED	129	931
DARY ION MASS SPECTROMET CHARACTERIZATION OF NEAR SURFACE	129	1819
TCH CHARACTERISTICS STRUCTURAL	129	205
N PHYSICAL AND ELECTRICAL PROPERTIES OF PECVD SIN WITH THEIR	129	1773
NG AUGER DEPTH PROFILING INTERFACE	129	851
CHEMICAL VAPOR-DEPOSITED ALUMINUM NITRIDE FILMS	129	1045
LOW ENERGY NITROGEN IMPLANTATION INTO SILICON: ITS MATERIAL	129	408
ELECTROCHEMICAL RESPONSE OF SOME LAYERED CHALCOGENOPHOSPHATE	129	237
IMPROVING THE ELECTRICAL PROPERTIES OF VAFOR GROWN III-V	129	2566
RUCTURES ANALYSIS OF THE	129	216
THE GALVANOSTATIC METHOD: ANALYSIS OF ERROR AND	129	1473
ERNARY OXIDE SCALES ON BINARY ALLOYS	129	209
INP AND CDS PHOTOANODES IN	129	1977
THE ANODIC CORROSION OF GOLD IN	129	1192
ELECTROCHEMICAL PRODUCTION OF MANGANIC SULFATE IN	129	749
OGEN EVOLUTION REACTION ON MILD STEEL AND NICKEL CATHODES IN	129	2481
N EXCHANGE POLYMERS II. SORPTION AND TRANSPORT PROPERTIES IN	129	328
TRANSPORT PROPERTIES OF NAFION(R) MEMBRANES IN	129	85
LDS IN TIO2 PHOTOANODES HYDROGEN	129	1851
ON OF SURFACE ACCEPTOR STATE DENSI CALCULATION OF CARRIER	129	1382
METHOD TO MEASURE THE PRECIPITATED AND TOTAL OXYGEN	129	1638
INTO SILICON DUE TO LOCAL PR OBSERVATION OF THE ANOMALOUS	129	841
THE CATION	129	141
TRY OF HYDROCARBONS IN HF/SBF5: SOME MECHANISTIC CONCLUSIONS	129	1950
SIMS EVIDENCE	129	2149
LECTROCHEMISTRY OF HYDROCARBONS IN HF/SBF5: SOME MECHANISTIC	129	1950
ECHANISTIC CONCLUSIONS CONCERNING THE SUPER ACID "CATALYZED"	129	1950
C LEVELING UNDER SECONDARY AND TERTIARY CURRENT DISTRIBUTION	129	946
DESIGN OF ELECTROLYSIS UNDER COST-OPTIMAL THERMAL	129	953
LITHIUM IN PROPYLENE CARBONATE SOLUTIONS UNDER OPEN-CIRCUIT	129	1422
REACTION OF OXYGEN WITH SI(111) AND (100): CRITICAL	129	1300
MECHANISM OF THE DISINTEGRATION OF LEAD DIOXIDE ANODES UNDER	129	567
OF ANODIC OXIDE FILMS ON ZIRCONIUM I. INFLUENCE OF FORMATION	129	1895
C ELECTRODES IN KOH THE RELATIONSHIP BETWEEN ELECTROLYTE	129	1390
THE SPECIFIC	129	1745
	129	1165
KEL HYDROXIDE FORMED BY COLLOIDAL PRECIPITATION ON DIFFERENT	129	301
G THE STEPPED CURREN AN INVESTIGATION OF HIGH FIELD IONIC	129	2518
G THE O AN EXPERIMENTAL INVESTIGATION OF HIGH FIELD IONIC	129	2513
RMATION AND ION-TRANSPORT MODELS FOR THE STRUCTURE AND IONIC	129	1694
MEASUREMENT OF ELECTRONIC	129	1968
ELECTRICAL	129	1021
STUDIES ON SOME SILVERSULFAMIDES	129	365
EFFECTS OF SEVERAL PARAMETERS ON THE CORROSION RATES OF AL	129	2270
DIOXIDE FILMS	129	2155
CTURE AND IONIC CONDUCTIVITY IN COMPLEXES OF POLYETHERS WITH	129	1694
THE	129	2343
SEMI-INFINITE DIFFUSION TO ELECTRODES	129	128
OF R&D THE	129	393C
A GALVANOSTATIC TECHNIQUE FOR STUDYING DIELECTRIC	129	2038
DER BRINK, BARENDRECHT, AND VISSCHER METHOD TO EVALUATE RATE	129	2268
DETERMINED BY A FOUR-PHASE COMPLEX REFRACTIVE IN OPTICAL	129	606
THE IN-P-O PHASE DIAGRAM:	129	1361
SCHOTTKY	129	1795
ELECTRICAL PROPERTIES OF AL/TI	129	2590
AL-0.9PERCENT SI/SI OHMIC	129	1335
METALLURGICAL BEHAVIOR OF GOLD-BASED OHMIC	129	2585
CAPACITANCE TRANSIENT SPECTROSCOPY OF TRACE	129	2098
ON CIRCUIT YIELD A SURVEY OF IRON	129	2573
RIE	129	1822
LEAD DEFICIENCY AND HYDROGEN	129	1678
PROPERTIES OF GARNET MATERIALS FOR	129	423
AND ELECTRON BEAMS AND EVALUATION BY ELECTRON BACKSCATTERING	129	2802
ECTRON RESISTS DETAILED	129	2576
ED CEO2 CERAMICS: COMPARISON OF A-C AND D-C INHOMOGENEITY	129	2113
LOROSILANE DEFECT	129	1078
ELECTRIC FIELD AND RF POWER DENSITY	129	2541
PROFILE	129	393
ING	129	859
ISOTHERMAL GROWTH OF HGCDTE UNDER	129	2855
LPYRIDINIUM ION IN ACETONITRILE	129	2731
INTERFEROMETRIC STUDY OF COMBINED FORCED AND NATURAL	129	2201
SUPPRESSION OF THERMAL	129	427

	Vol	Page
COMBUSTOR/GAS TURBINE COMBINED CYCLE VOLATILIZATIO	129	2119
COMMENTS ON THE VAN DER BRINK, BARENDRECHT, AND VI	129	2268
COMMONLY ASSOCIATED WITH THE SEMICONDUCTOR INDUSTR	129	173
COMPLEX ELECTRODE V	129	2378
COMPLEX REFRACTIVE INDEX MODEL OPTICAL CONSTANTS O	129	606
COMPLEXES OF POLY(ETHYLENE OXIDE) WITH LITHIUM SAL	129	1434
COMPLEXES OF POLYETHERS WITH ALKALI METAL SALTS CO	129	1694
COMPLEXES WITH O-PHENANTHROLINE AND RELATED LIGAND	129	61
COMPLEXING OF AL(+3) BY S(-2) IONS IN ALKALI HALID	129	2034
COMPONENTS IN LI-AL/FES CELLS	129	496
COMPOSITE CORROSION RATES AND ELECTROCHEMICAL STU	129	1398
COMPOSITE EVAPORATED SILICIDE/POLYSILICON ELECTROD	129	1307
COMPOSITE SILICIDE GATE ELECTRODES	129	1330
COMPOSITES FOR BATTERY ELECTRODES	129	1749
COMPOSITION AND THE PROCESSING PARAMETERS ON THE E	129	695
COMPOSITION GRADIENTS IN MOLTEN AGNO3-NANO3: A MOD	129	49
COMPOSITION GRADIENTS. MOLTEN NANO3-AGNO3 IN POROU	129	931
COMPOSITION OF BOROSILICATE GLASSES (BSG) BY SECON	129	1819
COMPOSITION OF POLYMERS RELATIVE TO THEIR PLASMA E	129	205
COMPOSITION RATIOS THE CORRELATIONS BETWEE	129	1773
COMPOSITION STUDIES OF THERMALLY OXIDIZED GAAS USI	129	851
COMPOSITION, KINETICS, AND MECHANISM OF GROWTH OF	129	1045
COMPOSITION, OXIDATION RESISTANCE, AND ELECTRICAL	129	408
COMPOUNDS (MPX3) PHOTO	129	237
COMPOUNDS BY COOLING THE HCL LIQUID SOURCE	129	2566
COMPRESSIVE STRENGTH OF LIALO2/MOLTEN CARBONATE ST	129	216
COMPUTATION OF PARAMETERS	129	1473
COMPUTER SIMULATION OF THE DIFFUSIONAL GROWTH OF T	129	209
CONCENTRATED AQUEOUS IODIDE ELECTROLYTES	129	1977
CONCENTRATED CHLORIDE SOLUTIONS	129	1192
CONCENTRATED H2SO4	129	749
CONCENTRATED SODIUM HYDROXIDE SOLUTIONS KINETICS O	129	2481
CONCENTRATED SOLUTION ENVIRONMENTS A COMPARISON OF	129	328
CONCENTRATED SOLUTION ENVIRONMENTS	129	85
CONCENTRATION GRADIENT AND ASSOCIATED ELECTRIC FIE	129	1851
CONCENTRATION IN POLYCRYSTALLINE FILMS AS A FUNCTI	129	1382
CONCENTRATION IN SILICON	129	1638
CONCENTRATION PROFILES OF ANTIMONY ATOMS DIFFUSED	129	841
CONCENTRATION RESPONSE OF POLYMER GATE ISFET	129	141
CONCERNING THE SUPER ACID "CATALYZED" CONDENSATION	129	1950
CONCERNING WATER IN PASSIVE LAYERS	129	2149
CONCLUSIONS CONCERNING THE SUPER ACID "CATALYZED"	129	1950
CONDENSATION OF HYDROCARBONS THE ELECTROCHEMISTRY	129	1950
CONDITIONS ANODI	129	946
CONDITIONS	129	953
CONDITIONS ELECTROCHEMICAL STUDIES OF THE FILM FOR	129	1422
CONDITIONS FOR THE GROWTH OF SIO2	129	1300
CONDITIONS OF OZONE EVOLUTION IN STRONG ACID ELECT	129	567
CONDITIONS ON E-I RELATIONS A STUDY BY NUCLEAR MIC	129	1895
CONDUCTANCE AND CURRENT DISTRIBUTION IN POROUS ZIN	129	1390
CONDUCTANCE OF MOLTEN CARBONATE FUEL CELL TILES	129	1745
CONDUCTANCE STUDIES IN THIONYL CHLORIDE: II	129	1165
CONDUCTING SUBSTRATES THE ELECTROCHEMICAL RESPONSE	129	301
CONDUCTION IN ANODIC TANTALUM PENTOXIDE FILMS USIN	129	2518
CONDUCTION IN ANODIC TANTALUM PENTOXIDE FILMS USIN	129	2513
CONDUCTIVITY IN COMPLEXES OF POLYETHERS WITH ALKAL	129	1694
CONDUCTIVITY IN FE-DOPED BETA-ALUMINA	129	1968
CONDUCTIVITY IN LANTHANUM-DOPED STRONTIUM TITANATE	129	1021
CONDUCTIVITY, PHOTOCONDUCTIVITY, AND LUMINESCENCE	129	365
CONDUCTORS IN INTEGRATED CIRCUITS	129	2270
CONFORMAL STEP COVERAGE OF LASER DEPOSITED SILICON	129	2155
CONFORMATION AND ION-TRANSPORT MODELS FOR THE STRU	129	1694
CONGRUENT VAPORIZATION OF MN2P(S)	129	2343
CONSISTING OF TWO OR MORE INTERSECTING PLANES	129	128
CONSTANT HELPER: STEADFASTNESS AS A KEY INGREDIENT	129	393C
CONSTANT VARIATION IN VALVE-METAL OXIDES	129	2038
CONSTANTS FOR HYDROGEN PEROXIDE DECOMPOSITION AT R	129	2268
CONSTANTS OF ARSENIC AND BORON IMPLANTS IN SILICON	129	606
CONSTRUCTION AND APPLICATIONS	129	1361
CONTACT FABRICATION FOR GAAS MESFET'S	129	1795
CONTACT METALLURGY FOR VLSI APPLICATION	129	2590
CONTACTS TO SHALLOW JUNCTIONS	129	1335
CONTACTS TO THE INP/INGAASP MATERIAL SYSTEM	129	2585
CONTAMINATION IN SILICON	129	2098
CONTAMINATION IN SILICON SUBSTRATES AND ITS IMPACT	129	2573
CONTAMINATION OF ETCHED SILICON SURFACES	129	1822
CONTENT IN BATTERY ELECTRODE BETA-PBO2	129	1678
CONTIGUOUS DISK MAGNETIC BUBBLE MEMORY DEVICES	129	423
CONTRAST SINGLE CRYSTAL SILICON FILMS ON AMORPHOUS	129	2802
CONTRAST (GAMMA-VALUE) MEASUREMENTS OF POSITIVE EL	129	2576
CONTRIBUTION TO THE ELECTRICAL PROPERTIES OF Y-DOP	129	2113
CONTROL DURING SILICON EPITAXIAL GROWTH USING DICH	129	1078
CONTROL OF PLASMA ETCH PROFILES WITH PLASMA SHEATH	129	2541
CONTROL WITH D-C BIAS IN PLASMA ETCHING	129	393
CONTROLLED COLLAPSE REFLOW FOR JOSEPHSON CHIP BOND	129	859
CONTROLLED HG VAPOR PRESSURE	129	2855
CONTROLLED POTENTIAL COULOMETRY OF 4-CYANO-1-METHY	129	2731
CONVECTION	129	2201
CONVECTION BY TRANSVERSE MAGNETIC FIELD	129	427

	Vol	Page
MPLEX ELECTRODE VISIBLE LIGHT	129	2378
THE ELECTRICAL PROPERTIES OF VAPOR GROWN III-V COMPOUNDS BY	129	2566
THERMAL TREATMENTS OF SILICA FILMS IN WA AN 180 STUDY OF	129	867
STUDIES OF METHACRYLONITRILE AND TRICHLOROETHYL METHACRYLATE	129	1596
NCED RAMAN SCATTERING IN CORROSION SCIENCE: BENZOTRIAZOLE ON	129	1716
MEASUREMENT OF ELECTROLESS PLATING RATE FOR	129	2183
AMIC PROPERTIES OF O THE INFLUENCE OF SOLUTE ADDITIONS OF	129	430
DIFFUSION OF	129	227
AN EXPERIMENTAL STUDY OF A PACKED BED ELECTRODE WITH	129	347
\ND KINETICS OF ELECTROLESS	129	717
DIFFUSION OF COPPER IN THE	129	227
E ELECTRODES THE MECHANICS OF ELECTROCHEMICALLY	129	118
RTIES OF PECVD SIN WITH THEIR COMPOSITION RATIOS THE	129	1773
KS ALTERATION OF	129	780
ICKEL-SODIUM MIXED SULFATE FORMATION AND LOW TEMPERATURE HOT	129	1613
THE ROLE OF H2S IN THE	129	468
IN MOLTEN LICL-KCL CONTAINING OXIDE IONS ANODIC	129	1245
ENSOR AS A "PSEUDO-REFERENCE ELECTRODE" IN THE MONITORING OF	129	1445
IN NITRIC ACID	129	1869
OXIDE FILM RUPTURE, REANODIZATION, AND STRESS	129	2660
ALTERATION OF CORRODENT ION SPECIES WITHIN STRESS	129	780
M AND IRON INITIATION OF CREVICE	129	481
ODIUM CHLORIDE SOLUTIONS INITIATION OF CREVICE	129	488
THE CHEMICAL NATURE OF ALUMINUM	129	27
RELATION BETWEEN MASS TRANSFER AND	129	276
NTIAL/PH MEASUREMENTS IN ALLOY 600 CREVICES AT 28 CREVICE	129	2458
MOSSBAUER SPECTROSCOPIC STUDY OF THE	129	1658
EFFECT OF SO2 AND PH ON THE ANODIC BEHAVIOR AND PITTING	129	2194
EXFOLIATION	129	1181
SIGNATURE IN THE CURRENT DURING EARLY EVENTS IN THE PITTING	129	340
CHEMICAL REACTIONS INVOLVED IN THE INITIATION OF HOT	129	571
NS THE ANODIC	129	1192
OSITION AND THE PROCESSING PARAMETERS ON THE ELECTROCHEMICAL	129	695
CHELATING-POLYMER ADSORPTION EFFECTS ON	129	2673
THE EFFECT OF ANTIMONY ON THE	129	1651
EPLETED URANIUM ALLOY TUNGSTEN FIBER METAL MATRIX COMPOSITE	129	1398
CUITS EFFECTS OF SEVERAL PARAMETERS ON THE	129	2270
NICKEL-COATED STEEL ANODES FOR ALKALINE WATER ELECTROLYSIS:	129	310
COAL GASIFICATION ATMOSPHERES THE ROLE OF CHROMIUM IN THE	129	789
COAL GASIFICATION AT THE ROLE OF SILICON ADDITIONS IN THE	129	782
STEELS	129	1402
SURFACE ENHANCED RAMAN SCATTERING IN	129	1716
ON THE CHEMICAL NATURE OF ALUMINUM	129	464
BY CHEMICAL VAPOR DEPOSITION AT LOW TEMPERATURE FROM T A	129	854
DESIGN OF ELECTROLYSIS UNDER	129	953
ETONITRILE CONTROLLED POTENTIAL	129	2731
T OF ELECTROLESS PLATING RATE FOR COPPER AND NICKEL BATHS BY	129	2183
TOELECTROCHEMISTRY OF AN AQUEOUS FERROCENE/FERRICENIUM REDOX	129	1587
VOLTAIC CELLS BASED ON N-GAAS AND THE TRIIODIDE/IODIDE REDOX	129	1705
OF PROPYLEN PHOTOELECTROCHEMISTRY OF THE THALLIC/THALLOUS	129	2232
TYPPE SILICON IN ACETONITRILE SOLUTIONS WITH DIFFERENT REDOX	129	1742
BALT(III)-COBALT(II) COMPLEXES WITH O-PHE SOLUTION REDOOX	129	61
ACE NEW	129	2278
CONFORMAL STEP	129	2155
ATE BASED ON MASS TRANSPORT BY DIFFUSION AND I A MODEL OF	129	1412
OXIDE FILM RUPTURE, REANODIZATION, AND STRESS CORROSION	129	2660
A FRACTURE MECHANICS STUDY OF CAUSTIC	129	2669
ALTERATION OF CORRODENT ION SPECIES WITHIN STRESS CORROSION	129	780
THE EFFECT OF CATHODIC POLARIZATION ON THE	129	706
HY EVALUATION OF PURE NOVOLAK	129	201
ALUMINUM AND IRON INITIATION OF	129	481
NUM IN SODIUM CHLORIDE SOLUTIONS INITIATION OF	129	488
EMS POTENTIAL/PH MEASUREMENTS IN ALLOY 600 CREVICES AT 288DE	129	2458
ATURE AQUEOUS SYSTEMS POTENTIAL/PH MEASUREMENTS IN ALLOY 600	129	2458
REACTION OF OXYGEN WITH SI(111) AND (100):	129	1300
EWIDTH UNIFORMITY OF AN INTEGRATED CIRCUIT LITHOGRAPHY A	129	2313
SOLUBLE POLYMERS INEXPENSIVE	129	251
FACTORS AFFECTING THE SENSITIVITY OF	129	402
EXPERIM.NTAL STUDY OF MOTION OF ELECTRONS AND HOLES IN Y2O2S	129	1535
TIC ELECTROCRYSTALLIZATION II. EXPERIMENTAL DEMONSTRATION OF	129	2447
DYNAMIC OXYGEN EQUILIBRIUM IN SILICON MELTS DURING	129	189
MOTT-SCHOTTKY PLOTS AND FLATBAND POTENTIALS FOR SINGLE	129	1973
WTH BY LATERAL NUCLEATED EPITAXY USING SCANNING LA SINGLE	129	2802
NTATION SINGLE	129	816
DE FILMS DEPOSITED BY SPUTTERING AND BY COEVAPORATION AFTER	129	1527
AN ETCH PIT TECHNIQUE FOR ANALYZING	129	1848
THE FEATHERING OF DOPING STRIATIONS IN SEMICONDUCTOR	129	1782
PREPARATION AND PROPERTIES OF CA2V2O7 SINGLE	129	2562
LAMENT MATERIALS FOR EDGE-SUPPORTED PULLING OF SILICON SHEET	129	2838
ASE RELATIONS IN THE CU,IN,S SYSTEM AND THE GROWTH OF CUINS2	129	1570
OF SOD PHOTOELECTROCHEMICAL BEHAVIOR OF P-TYPE SI SINGLE	129	1998
AND ENHANCEM A STUDY ON INTRINSIC GETTERING IN CZ SILICON	129	374
ROM THE MELT THE PHASE RELATIONS IN THE	129	1570
NEW SOLID ELECTROLYTES BASED ON	129	726
THE PHASE RELATIONS IN THE CU,IN,S SYSTEM AND THE GROWTH OF	129	1570
T--AN X-RAY POWDER DIFFRACTION STUDY OF PHASES IN THE SYSTEM	129	31C
ELECTROSYNTHESIS OF PROPYLENE OXIDE WITH ALTERNATING	129	1157
UGH POROUS ELECTRODES THE EFFECT OF MULTIPLE	129	991
ION OF (ZN, CD)S:CU, AL CATHODOLUMINESCENT PHOSPHORS AT HIGH	129	1546

	Vol	Page
CONVERSION AT ONE-DIMENSIONAL NICKEL DITHIOLENE CO	129	2378
COOLING THE HCL LIQUID SOURCE IMPROVING	129	2566
COOPERATIVE DIFFUSION AND CHEMICAL REACTION DURING	129	867
COPOLYMERS AS ELECTRON SENSITIVE POSITIVE RESISTS	129	1596
COPPER SURFACE ENHA	129	1716
COPPER AND NICKEL BATHS BY COULOSTATIC METHOD	129	2183
COPPER AND SILVER ON THE DIFFUSIVITY AND THERMODYN	129	430
COPPER IN THE COPPER-SILICON SYSTEM	129	227
COPPER PARTICLES	129	347
COPPER PLATING VI. INHIBITION BY ADSORPTION OF LIG	129	717
COPPER-SILICON SYSTEM	129	227
COPRECIPITATED COBALT HYDROXIDE IN NICKEL HYDROXID	129	118
CORRELATIONS BETWEEN PHYSICAL AND ELECTRICAL PROPE	129	1773
CORRODENT ION SPECIES WITHIN STRESS CORROSION CRAC	129	780
CORROSION REACTIONS OF SO2(SO3) WITH NIO-NA2SO4 IN	129	1613
CORROSION AND HYDROGEN EMBRITTLEMENT OF STEEL	129	468
CORROSION AND PASSIVATION BEHAVIOR OF SOME METALS	129	1245
CORROSION AND REDOX POTENTIALS AT 285DEGREE C USE	129	1445
CORROSION CHARACTERISTICS OF SOME ALUMINUM ALLOYS	129	1869
CORROSION CRACKING IN ALUMINUM	129	2660
CORROSION CRACKS	129	780
CORROSION I. EXPERIMENTAL INNVESTIGATIONS ALUMINU	129	481
CORROSION II. MATHEMATICAL MODEL FOR ALUMINUM IN S	129	488
CORROSION II. THE INITIAL DISSOLUTION STEP	129	27
CORROSION IN A TURBULENT PIPE FLOW	129	276
CORROSION IN HIGH-TEMPERATURE AQUEOUS SYSTEMS POTE	129	2458
CORROSION INHIBITION OF ZINC BY COBALT IONS	129	1658
CORROSION OF ALLOY 600	129	2194
CORROSION OF ALMGSI ALLOYS IN WATER	129	1181
CORROSION OF ALUMINUM A	129	340
CORROSION OF B-1900 AND NASA-TRW VIA	129	571
CORROSION OF GOLD IN CONCENTRATED CHLORIDE SOLUTIO	129	1192
CORROSION OF IRON-BORON METALLIC GLASSES EFFECT OF	129	695
CORROSION OF STEEL	129	2673
CORROSION OF TIN IN DEAERATED CITRIC ACID	129	1651
CORROSION RATES AND ELECTROCHEMICAL STUDIES OF A D	129	1398
CORROSION RATES OF AL CONDUCTORS IN INTEGRATED CIR	129	2270
CORROSION RESISTANCE POROUS	129	310
CORROSION RESISTANCE OF ALUMINA-FORMING ALLOYS IN	129	789
CORROSION RESISTANCE OF CHROMIA-FORMING ALLOYS IN	129	782
CORROSION RESISTANCE OF MICROCRYSTALLINE STAINLESS	129	1402
CORROSION SCIENCE: BENZOTRIAZOLE ON COPPER	129	1716
CORROSION V. ENERGY TRANSFER IN ALUMINUM DISSOLUTI	129	464
CORROSION-RESISTANT TITANIUM-RICH DEPOSIT PREPARED	129	854
COST-OPTIMAL THERMAL CONDITIONS	129	953
COULOMETRY OF 4-CYANO-1-METHYLPYRIDINIUM ION IN AC	129	2731
COULOSTATIC METHOD MEASUREMEN	129	2183
COUPLE AT PLATINUM, N-SILICON AND N-INDIUM PHOSPHI	129	1587
COUPLE IN ACETONITRILE ELECTROCHEMICAL PHOTO	129	1705
COUPLE. THE THALLIC ION CATALYZED PHOTO-OXIDATION	129	2232
COUPLES SEMICONDUCTOR ELECTRODES XLII. EVIDENCE FO	129	1742
COUPLES FOR EELECTROCHEMICAL ENERGY STORAGE II. CO	129	61
COUPLING METHOD FOR POLYIMIDE ADHESION TO LSI SURF	129	2278
COVERAGE OF LASER DEPOSITED SILICON DIOXIDE FILMS	129	2155
CRACK ELECTROCHEMISTRY ..R STEELS IN THE ACTIVE ST	129	1412
CRACKING IN ALUMINUM	129	2660
CRACKING OF MILD STEEL IN HOT NAOH/NA2S SOLUTIONS	129	2669
CRACKS	129	780
CREEP RATE OF GOLD	129	706
CRESOL-FORMALDEHYDE RESINS FOR DEEP U.V. LITHOGRAP	129	201
CREVICE CORROSION I. EXPERIMENTAL INNVESTIGATIONS	129	481
CREVICE CORROSION II. MATHEMATICAL MODEL FOR ALUMI	129	488
CREVICE CORROSION IN HIGH-TEMPERATURE AQUEOUS SYST	129	2458
CREVICES AT 288DEGREE C CREVICE CORROSION IN HIGH-	129	2458
CRITICAL CONDITIONS FOR THE GROWTH OF SIO2	129	1300
CROSS-BRIDGE TEST STRUCTURE FOR EVALUATING THE LIN	129	2313
CROSS-LINKED POLYMERIC SEPARATORS MADE FROM WATER-	129	251
CROSS-LINKED POSITIVE RESISTS	129	402
CRYSTAL AS REVEALED BY CATHODOLUMINESCENCE AN	129	1535
CRYSTAL GROWTH BEHAVIOR IMAGE ANALYSIS OF MORPHOLO	129	2447
CRYSTAL GROWTH BY THE CZOCHRALSKI TECHNIQUE	129	189
CRYSTAL RUTILE ELECTRODES	129	1973
CRYSTAL SILICON FILMS ON AMORPHOUS INSULATORS: GRO	129	2802
CRYSTAL Y3AL5O12:TB PHOSPHOR PRODUCED BY ION IMPLA	129	816
CRYSTALLINE STRUCTURE CHANGES OF MOLYBDENUM SILICI	129	1527
CRYSTALLOGRAPHIC ORIENTATION IN SI FILMS	129	1848
CRYSTALS	129	1782
CRYSTALS	129	2562
CRYSTALS FI	129	2838
CRYSTALS FROM THE MELT THE PH	129	1570
CRYSTALS IN LIQUID AMMONIA AND IN LIQUID AMMONIATE	129	1998
CRYSTALS: EVALUATION, THERMAL HISTORY DEPENDENCE,	129	374
CU,IN,S SYSTEM AND THE GROWTH OF CUINS2 CRYSTALS F	129	1570
CUBIC ZRP2O7	129	726
CUINS2 CRYSTALS FROM THE MELT	129	1570
CUO-NIO-MGO AT 1000 DEGREE C F.M. BECKET AWARD REP	129	31C
CURRENT	129	1157
CURRENT COLLECTORS ON THE PERFORMANCE OF FLOW-THRO	129	991
CURRENT DENSITIES I. EXPERIMENTAL PHENOMENA SATURA	129	1546

		Vol	Page
ANODIC LEVELING UNDER SECONDARY AND TERTIARY	**CURRENT** DISTRIBUTION CONDITIONS	129	946
ICAL FLOW REACTO EFFECTS OF SEPARATOR AND TERMINAL ON THE	**CURRENT** DISTRIBUTION IN PARALLEL-PLATE ELECTROCHEM	129	1670
KOH THE RELATIONSHIP BETWEEN ELECTROLYTE CONDUCTANCE AND	**CURRENT** DISTRIBUTION IN POROUS ZINC ELECTRODES IN	129	1390
A SURVEY OF NUMERICAL METHODS AND SOLUTIONS FOR	**CURRENT** DISTRIBUTION PROBLEMS	129	72
KOH ELECTROLYTE TRANSIENT	**CURRENT** DISTRIBUTIONS IN POROUS ZINC ELECTRODES IN	129	239
ON OF ALUMINUM A SIGNATURE IN THE	**CURRENT** DURING EARLY EVENTS IN THE PITTING CORROSI	129	340
DUCTION IN ANODIC TANTALUM PENTOXIDE FILMS USING THE STEPPED	**CURRENT** METHOD AN INVESTIGATION OF HIGH FIELD IONI	129	2518
LLULOSE IN ACETONE-ISOPROPYL DEPENDENCE OF THE DIFFUSION	**CURRENT** ON THE DEGREE OF POLYMERIZATION OF NITROCE	129	1520
NO3-NANO3: A MODEL SYSTEM FOR THE LICL-KCL ELECTROLYTE OF AN	**CURRENT-INDUCED** COMPOSITION GRADIENTS IN MOLTEN AG	129	49
3-AGNO3 IN POROUS YTTRIA SEM/EDX AND AA MEASUREMENTS OF	**CURRENT-INDUCED** COMPOSITION GRADIENTS. MOLTEN NANO	129	931
ELLS UNDER MASS AND LIGHT FLUX VARIATION	**CURRENT-VOLTAGE** ANALYSIS OF PHOTOELECTROCHEMICAL C	129	2029
FACE BARRIER CELLS RECOMBINATION EFFECTS ON	**CURRENT-VOLTAGE** CHARACTERISTICS OF ILLUMINATED SUR	129	1134
FUR DIOXIDE BATTERY X-RAY DIFFRACTION PATTERN AND DSC	**CURVES** OF THE DISCHARGE PRODUCT OF THE LITHIUM/SUL	129	565
PHENOMENOLOGICAL MODEL OF THE	**CVD** EPITAXIAL REACTOR	129	1627
	CVD HYDROPHOBIC LEAD SILICATE FILMS	129	165
MODELING OF LOW-PRESSURE	**CVD** PROCESSES	129	2288
EMPERATURE AND PARTIAL PRESSURE BY RAMAN SCATTERING INSIDE A	**CVD** REACTOR DETERMINATION OF T	129	2338
HOSPHORUS INCORPORATION DURING SILICON EPITAXIAL GROWTH IN A	**CVD** REACTOR P	129	1122
525 DEGREE TO 725 DEGREE C PROPERTIES OF PLASMA-ENHANCED	**CVD** SILICON FILMS I. UNDOPED FILMS DEPOSITED FROM	129	2326
N PROPERTIES OF PLASMA-ENHANCED	**CVD** SILICON FILMS II. FILMS DOPED DURING DEPOSITIO	129	2331
D RECRYSTALLIZATION OF VACUUM-DEPOSITED AMORPHOUS SILICON BY	**CW** LASER IRRADIATION ANOMALOUS LOCAL OXIDATION AN	129	888
RESSURIZED FLUIDIZED BED COAL COMBUSTOR/GAS TURBINE COMBINED	**CYCLE** VOLATILIZATION/CONDENSATION OF ALKALI SALTS	129	2119
TION OF PERFORMANCE REPRODUCIBILITY, CAPACITY RETENTION, AND	**CYCLE** LIFE FOR LIAL/FES CELLS STATUS CELLS: A DEMO	129	2701
ROGENEOUS ELECTRON TRANSFER KINETIC PARAMETERS BY DERIVATIVE	**CYCLIC** VOLTABSORPTOMETRY THE COLIN GARFIELD FINK S	129	298C
ESTIGATIONS OF ALKALI-METAL INTERCALATION REACTIONS IN TIS2:	**CYCLIC** VOLTAMMETRY AND CHRONOCOULOMETRY OF LIQUID	129	677
TOLUMINESCENCE DISTRIBUTION IN SEMI-INSULATING GAAS GROWN BY	**CZ** AND HB METHODS ONE-DIMENSIONAL PHO	129	880
OXIDE MICRO-PRECIPITATES IN AS-GROWN	**CZ** SILICON	129	2780
EPENDENCE, AND ENHANCEM A STUDY ON INTRINSIC GETTERING IN	**CZ** SILICON CRYSTALS: EVALUATION, THERMAL HISTORY D	129	374
IOR MULTISTEP REPEATED ANNEALING FOR	**CZ-SILICON** WAFERS: OXYGEN AND INDUCED DEFECT BEHAV	129	2089
EN EQUILIBRIUM IN SILICON MELTS DURING CRYSTAL GROWTH BY THE	**CZOCHRALSKI** TECHNIQUE DYNAMIC OXYG	129	189

— D —

PROFILE CONTROL WITH	**D-C** BIAS IN PLASMA ETCHING	129	393
NEW ASPECTS OF	**D-C** ELECTROCHEMILUMINESCENCE	129	1289
L PROPERTIES OF Y-DOPED CEO2 CERAMICS: COMPARISON OF A-C AND	**D-C** MEASUREMENTS INHOMOGENEITY CONTRIBUTION TO THE	129	2113
LAYERS IMPURITY GETTERING OF SILICON	**DAMAGE** GENERATED BY ION IMPLANTATION THROUGH SIO2	129	2527
ITY OF INP/INGAASP MULTILAYER STRUCTURE A SIMPLE	**DAMAGE-FREE** GROOVING METHOD FOR REVEALING THE QUAL	129	2082
LYTE INTERFACE INTERACTIONS BETWEEN PHOTOINDUCED AND	**DARK** CHARGE TRANSFER ACROSS N-TIO2-AQUEOUS ELECTRO	129	1240
RFACE STATES: UNIFIED MODEL AND COMPARISON WITH EXPERIMENTAL	**DATA** CHARGE TRANSFER IN PHOTOELECTROCHEMICAL DEVIC	129	1003
NG AND TECHNOLOGY MEDALIST JOSEPH C. SCHUMACHER--VITTORIO	**DE** NORA-DIAMOND SHAMROCK ELECTROCHEMICAL ENGINEERI	129	395C
THE EFFECT OF ANTIMONY ON THE CORROSION OF TIN IN	**DEAERATED** CITRIC ACID	129	1651
THE EFFECT OF ARSENIC ON THE	**DEALLOYING** OF ALPHA-BRASS	129	2157
PHOTOELECTROCHEMICAL OXIDATION OF AROMATIC HYDROCARBONS AND	**DECAMETHYL** FERROCENE AT THE N-GAAS/ROOM TEMPERATUR	129	560
MICROWAVE PLASMAS	**DECAPSULATION** AND PHOTORESIST STRIPPING IN OXYGEN	129	2537
CHER METHOD TO EVALUATE RATE CONSTANTS FOR HYDROGEN PEROXIDE	**DECOMPOSITION** AT ROTATING DISK ELECTRODES COMMENTS	129	2268
HETEROGENEOUS	**DECOMPOSITION** OF SILANE IN A FIXED BED REACTOR	129	1531
METAL	**DECORATED** DEFECTS IN HEAT-TREATED SILICON WAFERS	129	1128
CHARACTERIZATION OF SEMICONDUCTOR ELECTRODES WITH A	**DEEP** IMPURITY LEVEL	129	2219
CHARACTERIZATION OF REACTIVE ION ETCHED SILICON SURFACE BY	**DEEP** LEVEL TRANSIENT SPECTROSCOPY	129	2823
LD LEVELS IN LEC GROWN GALLIUM ARSENIDE	**DEEP** LEVEL TRANSIENT SPECTROSCOPY OF SILVER AND GO	129	1353
PACITANCE SPECTROSCOPY: A NEW METHOD FOR CHARACTERIZATION OF	**DEEP** LEVELS IN SEMICONDUCTORS ELECTROCHEMICAL PHOT	129	891
NS	**DEEP** U.V. HARDENING OF POSITIVE PHOTORESIST PATTER	129	1379
EVALUATION OF PURE NOVOLAK CRESOL-FORMALDEHYDE RESINS FOR	**DEEP** U.V. LITHOGRAPHY	129	201
LITHOGRAPHIC EVALUATION OF AN O-NITROBENZYL ESTER BASED	**DEEP** U.V. RESIST SYSTEM	129	2552
REPEATED ANNEALING FOR CZ-SILICON WAFERS: OXYGEN AND INDUCED	**DEFECT** BEHAVIOR MULTISTEP	129	2089
NG DICHLOROSILANE	**DEFECT** CONTROL DURING SILICON EPITAXIAL GROWTH USI	129	1078
PITAXIAL LAYERS USING A WET CHEMICAL ETCH METHODS FOR	**DEFECT** EVALUATION OF THIN (100) ORIENTED SILICON E	129	2074
CE RESPONSE A POINT	**DEFECT** MODEL FOR ANODIC PASSIVE FILMS III. IMPEDAN	129	1874
ATION IDENTIFICATION AND ELIMINATION OF GATE OXIDE	**DEFECT** ORIGIN PRODUCED DURING SELECTIVE FIELD OXID	129	800
	DEFECT STRUCTURE IN NICKEL ELECTRODEPOSITS	129	45
THE	**DEFECT** STRUCTURE OF LEAD DIOXIDE	129	876
HIUM-ALUMINUM	**DEFECTS** AND DISORDER IN THE FAST-ION ELECTRODE LIT	129	2509
TECHNIQUE EVALUATION OF	**DEFECTS** IN CDTE USING A SIMPLE CATHODOLUMINESCENCE	129	369
METAL DECORATED	**DEFECTS** IN HEAT-TREATED SILICON WAFERS	129	1128
A METHOD FOR OBSERVING MICROMETER-SIZE	**DEFECTS** IN RESISTS	129	2384
OXIDATION-INDUCED POINT	**DEFECTS** IN SILICON	129	1093
ATED WAFERS PRIOR TO LOCAL OXIDATION MOS GATE OXIDE	**DEFECTS** RELATED TO TREATMENT OF SILICON NITRIDE CO	129	1066
DE BETA-PBO2 LEAD	**DEFICIENCY** AND HYDROGEN CONTENT IN BATTERY ELECTRO	129	1678
OCORROSION AT THE ZNSE-ELECTROLYTE INTERFACE BY PHOTOTHERMAL	**DEFLECTION** SPECTROSCOPY STUDIES OF PHOT	129	2393
	DEFORMATION OF SILICON WAFERS BY THERMAL OXIDATION	129	2076
TRANSPORT NUMBER GRADIENTS AND SOLID ELECTROLYTE	**DEGRADATION**	129	752
IMPACT OF	**DEIONIZED** WATER RINSES ON SILICON SURFACE CLEANING	129	1027
PIPED EMITTER	**DELINEATION** USING THE WRIGHT ETCH	129	354
ITY IN GALVANOSTATIC ELECTROCRYSTALLIZATION II. EXPERIMENTAL	**DEMONSTRATION** OF CRYSTAL GROWTH BEHAVIOR IMAGE ANA	129	2447
CITY RETENTION, AND CYCLE LIFE FOR LIAL/F STATUS CELLS: A	**DEMONSTRATION** OF PERFORMANCE REPRODUCIBILITY, CAPA	129	2701
A SECTIONING TECHNIQUE FOR	**DEMOUNTABLE** SEMICONDUCTOR SAMPLES	129	448
WATER ABSORPTION AND	**DENSIFICATION** OF PHOSPHOSILICATE GLASS FILMS	129	1765
RGE PROPERTIES IN ZNCL2 BATTERIES THE SYNTHESIS OF	**DENSIFIED** CMD FROM MN-NH4-CARBAMATE AND ITS DISCHA	129	2372
ZN, CD)S:CU, AL CATHODOLUMINESCENT PHOSPHORS AT HIGH CURRENT	**DENSITIES** I. EXPERIMENTAL PHENOMENA SATURATION OF	129	1546
E INFLUENCE OF INTERMITTENT GROWTH PROCEDURES ON DISLOCATION	**DENSITIES** IN INP EPI-LAYERS TH	129	1556
ETCH PROFILES WITH PLASMA SHEATH ELECTRIC FIELD AND RF POWER	**DENSITY** CONTROL OF PLASMA	129	2541
IDES FIXED CHARGE	**DENSITY** (QSS) AT THE SI-SIO2 INTERFACE FOR THIN OX	129	1757
OBE-SPACING EXPERIMENT SIMULATIONS: EFFECTS OF PROBE-CURRENT	**DENSITY** AND LAYER THICKNESS SPREADING RESISTANCE P	129	2788
US SILICON FIELD EFF DETERMINATION OF POSITIVE MOBILE ION	**DENSITY** IN SILICON DIOXIDE BY HYDROGENATED AMORPHO	129	2770
LOW DISLOCATION	**DENSITY** RF-HEATED EPITAXIAL SILICON	129	2858
A VISCOUS FLOW MODEL TO EXPLAIN THE APPEARANCE OF HIGH	**DENSITY** THERMAL SIO2 AT LOW OXIDATION TEMPERATURES	129	2594
OLYCRYSTALLINE FILMS AS A FUNCTION OF SURFACE ACCEPTOR STATE	**DENSITY:** APPLICATION FOR ZNO GAS SENSORS CALCULATI	129	1382
ETTERING IN CZ SILICON CRYSTALS: EVALUATION, THERMAL HISTORY	**DEPENDENCE**, AND ENHANCEMENT A STUDY ON INTRINSIC G	129	374
A SCAN RATE	**DEPENDENT** DETERMINATION OF PLATINUM AREAS	129	746

		Vol	Page
COMPOSI CORROSION RATES AND ELECTROCHEMICAL STUDIES OF A	DEPLETED URANIUM ALLOY TUNGSTEN FIBER METAL MATRIX	129	1398
OW TEMPERATURE FROM T A CORROSION-RESISTANT TITANIUM-RICH	DEPOSIT PREPARED BY CHEMICAL VAPOR DEPOSITION AT L	129	854
SEMICONDUCTOR LIQUID JUNCTION SOLAR CELL BASED ON CHEMICALLY	DEPOSITED Bi2S3 THIN FILM AND SOME SEMICONDUCTING	129	332
CRYSTALLINE STRUCTURE CHANGES OF MOLYBDENUM SILICIDE FILMS	DEPOSITED BY SPUTTERING AND BY COEVAPORATION AFTER	129	1527
RIMETHYLANTIMONY ANTIMONY-DOPED TIN OXIDE FILMS	DEPOSITED BY THE OXIDATION OF TETRAMETHYLTIN AND T	129	1040
ERTIES OF PLASMA-ENHANCED CVD SILICON FILMS I. UNDOPED FILMS	DEPOSITED FROM 525 DEGREE TO 725 DEGREE C PROP	129	2326
CONFORMAL STEP COVERAGE OF LASER	DEPOSITED SILICON DIOXIDE FILMS	129	2155
OF PLASMA-ENHANCED CVD SILICON FILMS II. FILMS DOPED DURING	DEPOSITION PROPERTIES	129	2331
S	DEPOSITION AND DISSOLUTION ON SINUSOIDAL ELECTRODE	129	316
N-RESISTANT TITANIUM-RICH DEPOSIT PREPARED BY CHEMICAL VAPOR	DEPOSITION AT LOW TEMPERATURE FROM TRIS-(2,2'BIPYR	129	854
A MODEL FOR BORON	DEPOSITION IN SILICON USING A BBr3 SOURCE	129	1592
THERMODYNAMIC AND EXPERIMENTAL ANALYSIS OF CHEMICAL VAPOR	DEPOSITION OF ALUMINA FROM ALCl3-H2-CO2 GAS PHASE	129	1367
AND FLUORINE CATHODIC	DEPOSITION OF AMORPHOUS ALLOYS OF SILICON, CARBON,	129	936
AUTOCATALYTIC	DEPOSITION OF GOLD-COPPER AALLOYS	129	1917
LOW PRESSURE	DEPOSITION OF PHOSPHOSILICATE GLASS FILMS	129	1588
POTENTIOSTATIC TRANSIENT BEHAVIOR DURING THE UNDERPOTENTIAL	DEPOSITION OF SILVER ON GOLD USING THE ROTATING RI	129	1202
CHEMICAL METHODS FOR THE	DEPOSITION OF THIN FILMS OF Sb2Se3 AND Sb2O3	129	1642
OF POROUS ALUMINUM	DEPOSITION TECHNIQUES AND HEAT TRANSFER PROPERTIES	129	1029
THER ELECTROLYTES SPECULAR LITHIUM	DEPOSITS FROM LITHIUM HEXAFLUOROARSENATE/DIETHYL E	129	1
IUM AND VANADIUM IMPURITY	DEPOSITS IN GAS TURBINES FROM FUELS CONTAINING SOD	129	649
E COMPOSITION STUDIES OF THERMALLY OXIDIZED GAAS USING AUGER	DEPTH PROFILING INTERFAC	129	851
LUATE RATE CONSTANTS FOR HYDROGEN PER COMMENTS ON THE VAN	DER BRINK, BARENDRECHT, AND VISSCHER METHOD TO EVA	129	2268
ION OF HETEROGENEOUS ELECTRON TRANSFER KINETIC PARAMETERS BY	DERIVATIVE CYCLIC VOLTABSORPTOMETRY THE COLIN GARF	129	298C
ACID SYNTHESIS ELECTROCHEMICAL BEHAVIOR OF SELECTED IMINE	DERIVATIVES, REDUCTIVE CARBOXYLATION, ALPHA-AMINO	129	1231
RTIFICIAL PITS AND ON POLARIZED SURFACES AN ELECTRODE	DESIGN FOR DUAL MEASUREMENT OF POTENTIALS INSIDE A	129	669
ONS OF FUEL CELL REACTIONS	DESIGN OF A CELL FOR ELECTRODE KINETIC INVESTIGATI	129	135
TION MATHEMATICAL MODEL FOR	DESIGN OF BATTERY ELECTRODES I. POTENTIAL DISTRIBU	129	688
CONDITIONS	DESIGN OF ELECTROLYSIS UNDER COST-OPTIMAL THERMAL	129	953
SITIVE ELECTRON RESISTS	DETAILED CONTRAST (GAMMA-VALUE) MEASUREMENTS OF PO	129	2576
CHING WITH CF4: CHARACTERIZATION OF A KAUFMAN ION SOURCE AND	DETAILS OF SiO2 ETCHING REACTIVE ION BEAM ET	129	585
SI AND AL ETCHING AND PRODUCT	DETECTION IN A PLASMA BEAM UNDER ULTRAHIGH VACUUM	129	2045
ITH FLUORESCING AND NONFLUORESCING DYES VISUAL	DETECTION OF HYDRATED ALUMINUM OXIDE BY STAINING W	129	1517
Y	DETERIORATED A-C POWDER EL CELL BRIGHTNESS RECOVER	129	362
BATTERY STATE OF CHARGE	DETERMINATION IN PHOTOVOLTAIC SYSTEMS	129	1928
LI-METAL INTERCALATION REACTIONS IN TiS2: CHRONOAMPEROMETRIC	DETERMINATION OF MASS AND CHARGE TRANSPORT PROPERT	129	682
A SCAN RATE DEPENDENT	DETERMINATION OF PLATINUM AREAS	129	746
LICON DIOXIDE BY HYDROGENATED AMORPHOUS SILICON FIELD EFFECT	DETERMINATION OF POSITIVE MOBILE ION DENSITY IN SI	129	2770
LEXES OF POLY(ETHYLENE OXIDE) W VIBRATIONAL SPECTROSCOPIC	DETERMINATION OF STRUCTURE AND ION PAIRING IN COMP	129	1434
ONDUCTOR/ELECTROLYTE INTERFACE BY LAPLACE DOMAIN IMPE THE	DETERMINATION OF SURFACE STATE ENERGIES AT A SEMIC	129	2147
BY RAMAN SCATTERING INSIDE A CVD REACTOR	DETERMINATION OF TEMPERATURE AND PARTIAL PRESSURE	129	2338
F LEAD ALUMINATES POTENTIOMETRIC	DETERMINATION OF THE GIBBS ENERGIES OF FORMATION O	129	1116
IST A DRY	DEVELOPMENT MODEL FOR A POSITIVE ELECTRON BEAM RES	129	2598
FOR NICKEL ELECTROWINNING I. SINGLE LAYER PRECIOUS M THE	DEVELOPMENT OF AN ENERGY-EFFICIENT INSOLUBLE ANODE	129	515
FOR NICKEL ELECTROWINNING II. MULTILAYER PRECIOUS ME THE	DEVELOPMENT OF AN ENERGY-EFFICIENT INSOLUBLE ANODE	129	522
USE OF THE MODIFIED ELECTRODES FOR AN ELECTROCHROMIC DISPLAY	DEVICE POLYMER-MODIFIED ELECTRODES II. SPECTROELEC	129	762
NUMERICAL SIMULATION OF GATE OXIDE THINNING IN MOS	DEVICES	129	831
LYMERS AS SEMISOLID ELECTROLYTES IN WO3-BASED ELECTROCHROMIC	DEVICES ION-CONTAINING PO	129	1215
GARNET MATERIALS FOR CONTIGUOUS DISK MAGNETIC BUBBLE MEMORY	DEVICES PROPERTIES OF	129	423
MPARISON WITH EXP CHARGE TRANSFER IN PHOTOELECTROCHEMICAL	DEVICES VIA INTERFACE STATES: UNIFIED MODEL AND CO	129	1003
PASSIVATION MECHANISM FOR GAAS AND OTHER III-V SEMICONDUCTOR	DEVICES, INCLUDING INGAAS LONG WAVELENGTH PHOTODET	129	821
CHEMICAL ETCHING OF INGAASP/INP	DH WAFER	129	1053
THE IN-P-O PHASE	DIAGRAM: CONSTRUCTION AND APPLICATIONS	129	1361
LOCAL SPECTRAL RESPONSES OF TRANSITION METAL	DICHALCOGENIDES IN PHOTOELECTROCHEMICAL CELLS	129	1237
DEFECT CONTROL DURING SILICON EPITAXIAL GROWTH USING	DICHLOROSILANE	129	1078
HAZARD POTENTIAL OF	DICHLOROSILANE	129	2346
SPUTTERED TiO2 FILMS EFFECT OF HYDROGEN ON THE	DIELECTRIC AND PHOTOELECTROCHEMICAL PROPERTIES OF	129	2022
POLYSILICON/SiO2 INTERFACE MICROTEXTURE AND	DIELECTRIC BREAKDOWN	129	1282
EFFECTS OF PLASMA CLEANING ON THE	DIELECTRIC BREAKDOWN IN SiO2 FILM ON SI	129	224
S A GALVANOSTATIC TECHNIQUE FOR STUDYING	DIELECTRIC CONSTANT VARIATION IN VALVE-METAL OXIDE	129	2038
HYDROGEN ANNEAL EFFECTS ON METAL-SEMICONDUCTOR WORK FUNCTION	DIFFERENCE	129	806
E PRODUCT OF THE LITHIUM/SULFUR DIOXIDE BATTERY X-RAY	DIFFRACTION PATTERN AND DSC CURVES OF THE DISCHARG	129	565
MGO AT 1000 DEG F.M. BECKET AWARD REPORT--AN X-RAY POWDER	DIFFRACTION STUDY OF PHASES IN THE SYSTEM CuO-NiO-	129	31C
ELECTRON	DIFFRACTION STUDY OF THE PASSIVE FILM ON IRON	129	2163
WIRE BONDING PROCESS CHARACTERIZATION BY X-RAY	DIFFRACTION TOPOGRAPHY	129	846
ON OF THE ANOMALOUS CONCENTRATION PROFILES OF ANTIMONY ATOMS	DIFFUSED INTO SILICON DUE TO LOCAL PRECIPITATION O	129	841
MICRODEFECTS DURING PHOSPHORUS	DIFFUSION	129	667
ATMENTS OF SILICA FILMS IN WA AN 18O STUDY OF COOPERATIVE	DIFFUSION AND CHEMICAL REACTION DURING THERMAL TRE	129	867
RY FOR STEELS IN THE ACTIVE STATE BASED ON MASS TRANSPORT BY	DIFFUSION AND ION MIGRATION A MODEL OF CRACK ELECT	129	1412
RON IN SILICON UNDER DRY O2 AMBIENT	DIFFUSION AND SEGREGATION OF LOW-DOSE IMPLANTED BO	129	1097
UORINATED CARBOXYLATE AND SULFONATE ION EXCHANGE POLYMERS I.	DIFFUSION AND WATER SORPTION A COMPARISON OF PERFL	129	324
OF NITROCELLULOSE IN ACETONE-ISOPROPYL DEPENDENCE OF THE	DIFFUSION CURRENT ON THE DEGREE OF POLYMERIZATION	129	1520
OXIDATION OF H2 AT GAS	DIFFUSION ELECTRODES IN H2SO4 AND HBR	129	2464
IONS PEG FORMATION BY SHORT-CIRCUIT	DIFFUSION IN Al2O3 SCALES CONTAINING OXIDE DISPERS	129	1147
EFFECT OF BACK-SIDE OXIDATION ON B AND P	DIFFUSION IN SI DIRECTLY MASKED WITH Si3N4 FILMS	129	2292
ORUS-DOPED OXIDE SOURCE	DIFFUSION IN SILICON FROM A SPIN-ON HEAVILY PHOSPH	129	2299
PROTON	DIFFUSION IN TUNGSTEN TRIOXIDE THIN FILMS	129	2349
THE MECHANISM OF OXYGEN	DIFFUSION IN VITREOUS SiO2	129	357
RT THROUGH NAFION MEMBRANE IN CHLOR-ALKALI CE THE ANOLYTE	DIFFUSION LAYER AND ITS EFFECT ON HYDROXYL TRANSPO	129	722
TRODEPOSITION MAGNETIC FIELD EFFECTS ON THE GROWTH OF THE	DIFFUSION LAYER AT VERTICAL ELECTRODES DURING ELEC	129	1266
CROSCOPY ON P-WSe2: RECOMBINATION SITES AND MINORITY CARRIER	DIFFUSION LENGTH CHARGE COLLECTION MI	129	418
A NOVEL METHOD TO MEASURE LATERAL	DIFFUSION LENGTH IN POLYCRYSTALLINE SILICON	129	1635
THERMAL OXIDATION THE ENHANCED	DIFFUSION OF ARSENIC AND PHOSPHORUS IN SILICON BY	129	644
	DIFFUSION OF COPPER IN THE COPPER-SILICON SYSTEM	129	227
	DIFFUSION OF GOLD IN SILICON	129	1579
SILICON OXIDATION STUDIES: MEASUREMENT OF THE	DIFFUSION OF OXIDANT IN SiO2 FILMS	129	413
AN OPEN-TUBE METHOD FOR	DIFFUSION OF ZINC INTO GAAS	129	1567
INTERSECTING PLANES SEMI-INFINITE	DIFFUSION TO ELECTRODES CONSISTING OF TWO OR MORE	129	128
RY ALLOYS COMPUTER SIMULATION OF THE	DIFFUSIONAL GROWTH OF TERNARY OXIDE SCALES ON BINA	129	209
HE INFLUENCE OF SOLUTE ADDITIONS OF COPPER AND SILVER ON THE	DIFFUSIVITY AND THERMODYNAMIC PROPERTIES OF OXYGEN	129	430

		Vol	Page
PLASMAS AND ITS RELATIONSHIP TO FLUOROCARBON POLYMER FORMAT	**DIFLUOROCARBENE** EMISSION SPECTRA FROM FLUOROCARBON	129	160
ONUNIFORMLY DOPED OXIDES CONTAINING ALIOVALENT IMPURITIES ON	**DILUTE** ALLOYS PARABOLIC GROWTH OF N	129	622
MORPHOLOGICAL STUDIES OF OCCLUDED CELLS IN THE PITTING OF	**DILUTE** ALUMINUM ALLOYS IN SEAWATER	129	137
ROCHEMICAL REDUCTION OF NICOTINAMIDE ADENINE DINUCLEOTIDE IN	**DIMETHYLSULFOXIDE**: ION-PAIR, PROTONATION, AND ADSO	129	1960
HE USE OF IN SITU ELECTROCHEMICAL REDUCTION OF OXYGEN IN THE	**DIMINUTION** OF ADSORBED BACTERIA ON METALS IN SEAWA	129	2178
NATION, ELECTROCHEMICAL REDUCTION OF NICOTINAMIDE ADENINE	**DINUCLEOTIDE** IN DIMETHYLSULFOXIDE: ION-PAIR, PROTO	129	1960
CHARACTERIZATION OF FUSED GLASS PASSIVATION WITH SELECTED	**DIODE** STRUCTURES	129	154
CHARACTERISTICS OF INP MIS SCHOTTKY	**DIODES** PREPARED BY PLASMA OXIDATION	129	221
LAROGRAPHY OF O-MERCAPTOBENZOIC ACID IN AQUEOUS METHANOL AND	**DIOXANE** PO	129	90
EFFECTS OF AMMONIA ANNEAL ON ELECTRON TRAPPINGS IN SILICON	**DIOXIDE**	129	2042
THE DEFECT STRUCTURE OF LEAD	**DIOXIDE**	129	876
REACTIVE ION ETCHING OF SILICON	**DIOXIDE**	129	1152
A SEMICONDUCTOR MODEL FOR THE CATHODIC PASSIVATION OF LEAD	**DIOXIDE**	129	1880
IN STRONG AC THE MECHANISM OF THE DISINTEGRATION OF LEAD	**DIOXIDE** ANODES UNDER CONDITIONS OF OZONE EVOLUTION	129	567
ND DSC CURVES OF THE DISCHARGE PRODUCT OF THE LITHIUM/SULFUR	**DIOXIDE** BATTERY X-RAY DIFFRACTION PATTERN A	129	565
F DETERMINATION OF POSITIVE MOBILE ION DENSITY IN SILICON	**DIOXIDE** BY HYDROGENATED AMORPHOUS SILICON FIELD EF	129	2770
ION SURFACE STRUCTURE OF RUTHENIUM	**DIOXIDE** ELECTRODES AND KINETICS OF CHLORINE EVOLUT	129	1689
CONFORMAL STEP COVERAGE OF LASER DEPOSITED SILICON	**DIOXIDE** FILMS	129	2155
TITANIUM	**DIOXIDE** FILMS TO IMPROVE PHOTORESIST ADHESION	129	2389
PLASMA ETCHING OF SILICON AND SILICON	**DIOXIDE** WITH HYDROGEN FLUORIDE MIXTURES	129	1770
TED FILMS BY TRANSMISSION ELECTRON MICROSCOPY	**DIRECT** OBSERVATIONS OF INCLUSIONS IN ELECTRODEPOSI	129	201C
EFFECT OF BACK-SIDE OXIDATION ON B AND P DIFFUSION IN SI	**DIRECTLY** MASKED WITH SI3N4 FILMS	129	2292
TH AMMONIA AND TRIFLUOROMETHANE. THE ROLE OF NITROGEN IN THE	**DISCHARGE** REACTIVE ION ETCHING OF SILICON OXIDES W	129	1036
CHARACTERIZATION OF REACTIONS AND PRODUCTS OF THE	**DISCHARGE** AND FORCED OVERDISCHARGE OF LI/SO2 CELLS	129	1857
NODE IN MOLTEN SALT THERMAL CELLS	**DISCHARGE** CHARACTERISTICS OF LITHIUM-BORON ALLOY A	129	1168
THE KINETICS OF THE LITHIUM ELECTRODE DURING THE	**DISCHARGE** OF LI/SOCL2 CELLS	129	2649
TTERY X-RAY DIFFRACTION PATTERN AND DSC CURVES OF THE	**DISCHARGE** PRODUCT OF THE LITHIUM/SULFUR DIOXIDE BA	129	565
THE SYNTHESIS OF DENSIFIED CMD FROM MN-NH4-CARBAMATE AND ITS	**DISCHARGE** PROPERTIES IN ZNCL2 BATTERIES	129	2372
IONS OF OZONE EVOLUTION IN STRONG AC THE MECHANISM OF THE	**DISINTEGRATION** OF LEAD DIOXIDE ANODES UNDER CONDIT	129	567
NS I. STUDY OF ALTERNATING VOLTAGE MODULATION ON A ROTATING	**DISK** ELECTRODE .. VC ELECTRODE MORPHOLOGY IN ALKALI	129	2677
ELECTROHYDRODYNAMICAL IMPEDANCE ON A ROTATING	**DISK** ELECTRODE .. REDOX SYSTEM	129	107
TE CONSTANTS FOR HYDROGEN PEROXIDE DECOMPOSITION AT ROTATING	**DISK** ELECTRODES COMMENTS ON THE VAN DER BRINK, BAR	129	2268
PROPERTIES OF GARNET MATERIALS FOR CONTIGUOUS	**DISK** MAGNETIC BUBBLE MEMORY DEVICES	129	423
THE INFLUENCE OF INTERMITTENT GROWTH PROCEDURES ON	**DISLOCATION** DENSITIES IN INP EPI-LAYERS	129	1556
LOW	**DISLOCATION** DENSITY RF-HEATED EPITAXIAL SILICON	129	2858
NEW	**DISLOCATION** ETCHANT FOR INP	129	352
M DEFECTS AND	**DISORDER** IN THE FAST-ION ELECTRODE LITHIUM-ALUMINU	129	2509
TION OF TIO2 ELECTRODES WITH MINIMUM MOTT-SCHOTTKY FREQUENCY	**DISPERSION** THE PREPARA	129	2003
BY SHORT-CIRCUIT DIFFUSION IN AL2O3 SCALES CONTAINING OXIDE	**DISPERSIONS** PEG FORMATION	129	1147
AND THE USE OF THE MODIFIED ELECTRODES FOR AN ELECTROCHROMIC	**DISPLAY** DEVICE POLYMER-MODIFIED ELECTRODES II. SPE	129	762
AREA ON THE RESPONSE TIME OF ELECTROCHROMIC AND ELECTROLYTIC	**DISPLAYS** EFFECT OF ACTIVE SURFACE	129	2451
UMINUM BROMIDE AND HBR (ELECTROLYTE USED FOR THE ELECTRODEPO	**DISPROPORTIONATION** REACTION OF ALKYLBENZENES IN AL	129	40
NATURE OF ALUMINUM CORROSION V. ENERGY TRANSFER IN ALUMINUM	**DISSOLUTION** THE CHEMICAL	129	464
THE NATURE OF PASSIVATION OF LEAD SULFIDE DURING ANODIC	**DISSOLUTION** IN HYDROCHLORIC ACID	129	271
THE STABILITY OF PITTING	**DISSOLUTION** OF METALS IN AQUEOUS SOLUTION	129	260
ELECTRODES PHOTOANODIC	**DISSOLUTION** OF N-CDS STUDIED BY ROTATING RING-DISK	129	149
PIT AND FLOW STREAK FORMATION DURING HIGH RATE	**DISSOLUTION** OF NICKEL	129	1889
WC-CO CEMENTED CARBIDES IN PARTICULATE BED ELEC SELECTIVE	**DISSOLUTION** OF THE BINDER PHASE ALLOY (CO-W) FROM	129	2666
DEPOSITION AND	**DISSOLUTION** ON SINUSOIDAL ELECTRODES	129	316
THE CHEMICAL NATURE OF ALUMINUM CORROSION II. THE INITIAL	**DISSOLUTION** STEP	129	27
EXPLORATORY STUDIES ON ELECTROLYSIS OF AIN	**DISSOLVED** IN MOLTEN SALTS	129	102
EMATICAL MODEL FOR DESIGN OF BATTERY ELECTRODES I. POTENTIAL	**DISTRIBUTION** MATH	129	688
ANODIC LEVELING UNDER SECONDARY AND TERTIARY CURRENT	**DISTRIBUTION** CONDITIONS	129	946
THE THERMODYNAMICS OF ELECTROLYTE	**DISTRIBUTION** IN MOLTEN CARBONATE FUEL CELLS	129	942
W REACTO EFFECTS OF SEPARATOR AND TERMINAL ON THE CURRENT	**DISTRIBUTION** IN PARALLEL-PLATE ELECTROCHEMICAL FLO	129	1670
THE RELATIONSHIP BETWEEN ELECTROLYTE CONDUCTANCE AND CURRENT	**DISTRIBUTION** IN POROUS ZINC ELECTRODES IN KOH ELEC	129	1390
ND HB METHODS ONE-DIMENSIONAL PHOTOLUMINESCENCE	**DISTRIBUTION** IN SEMI-INSULATING GAAS GROWN BY CZ A	129	880
FLOW	**DISTRIBUTION** IN THE ZINC-CHLORIDE BATTERY	129	2251
ECTRODE POTENTIAL	**DISTRIBUTION** ON A CARBON-BASED BIFUNCTIONAL AIR EL	129	1159
A SURVEY OF NUMERICAL METHODS AND SOLUTIONS FOR CURRENT	**DISTRIBUTION** PROBLEMS	129	72
CTRON BEAM NEGATIVE RESIST WITH VERY NARROW MOLECULAR WEIGHT	**DISTRIBUTIONS** HIGH RESOLUTION ELE	129	663
CTROLYTE TRANSIENT CURRENT	**DISTRIBUTIONS** IN POROUS ZINC ELECTRODES IN KOH ELE	129	239
ECTROL CHARACTERIZATION OF N-TYPE SEMICONDUCTING TUNGSTEN	**DISULFIDE** PHOTOANODES IN AQUEOUS AND NONAQUEOUS EL	129	1461
OELECTROCHEMICAL PROPERTIES OF A LIGAND (BATHOPHENANTHROLINE	**DISULFONIC** ACIDD) BOUND TO POLYELECTROLYTES ON ELE	129	762
VISIBLE LIGHT CONVERSION AT ONE-DIMENSIONAL NICKEL	**DITHIOLENE** COMPLEX ELECTRODE	129	2378
ANTITATION OF ADSORPTION PARAMETERS AND ADSORPTION RATES FOR	**DITHIOZONE** ANION ADSORPTION AT AG USING SURFACE EN	129	295C
ENERGIES AT A SEMICONDUCTOR/ELECTROLYTE INTERFACE BY LAPLACE	**DOMAIN** IMPEDANCE ANALYSIS THE DETERMINATION OF SUR	129	2147
THERMALLY ACTIVATED OXYGEN	**DONORS** IN SI	129	2844
GENERALIZED MODEL FOR THE CLUSTERING OF AS	**DOPANTS** IN SI	129	1826
PROPERTIES OF PLASMA-ENHANCED CVD SILICON FILMS II. FILMS	**DOPED** DURING DEPOSITION	129	2331
THE LPCVD POLYSILICON PHOSPHORUS	**DOPED** IN SITU AS AN INDUSTRIAL PROCESS	129	1109
ILUTE ALLOYS PARABOLIC GROWTH OF NONUNIFORMLY	**DOPED** OXIDES CONTAINING ALIOVALENT IMPURITIES ON D	129	622
LLY AND LASER ANNEALED POLYCRYSTALLINE SILICON FILMS HEAVILY	**DOPED** WITH ARSENIC AND PHOSPHORUS ELECTRICAL PROPE	129	1811
ULT SHRINKAGE IN SILICON ON THE	**DOPING** DEPENDENCE OF OXIDATION-INDUCED STACKING FA	129	2319
GE	**DOPING** OF GA(1-X)AL(X)AS GROWN BY LPE WITH SI AND	129	1563
PROCESS THE USE OF S2CL2 FOR	**DOPING** POLY-GAAS FILMS GROWN BY THE ORGANOMETALLIC	129	2778
THE FEATHERING OF	**DOPING** STRIATIONS IN SEMICONDUCTOR CRYSTALS	129	1782
INORGANIC PHOTORESIST A NEW	**DOPING** TECHNIQUE WITHOUT SIO2 PATTERNING USING AN	129	1074
RS LOW TEMPERATURE	**DOUBLE-PLASMA** PROCESS FOR BN FILMS ON SEMICONDUCTO	129	2636
LECTROLYTE SESSILE	**DROP** STUDIES ON POLYBROMIDE/ZINC-BROMINE BATTERY E	129	1747
RESIST A	**DRY** DEVELOPMENT MODEL FOR A POSITIVE ELECTRON BEAM	129	2598
	DRY ETCHING FOR VLSI--A REVIEW	129	62C
SELECTIVE ISOTROPIC	**DRY** ETCHING OF SI3N4 OVER SIO2	129	2559
ION EXPOSURE PROCESS IMPROVED	**DRY** ETCHING RESISTANCE OF ELECTRON-BEAM RESIST BY	129	2556
HIGH PRESSURE OXIDATION OF SILICON IN	**DRY** OXYGEN	129	2828
AND SEGREGATION OF LOW-DOSE IMPLANTED BORON IN SILICON UNDER	**DRY** O2 AMBIENT DIFFUSION	129	1097
/SULFUR DIOXIDE BATTERY X-RAY DIFFRACTION PATTERN AND	**DSC** CURVES OF THE DISCHARGE PRODUCT OF THE LITHIUM	129	565
LOY SYSTEM	**DSC** STUDY OF TWO REACTIONS IN THE LITHIUM-BORON AL	129	1513
	DUAL HCL THIN GATE OXIDATION PROCESS	129	1778

	Vol	Page
ITS AND ON POLARIZED SURFACES AN ELECTRODE DESIGN FOR	129	669
UMINUM OXIDE BY STAINING WITH FLUORESCING AND NONFLUORESCING	129	1517
CRYSTAL GROWTH BY THE CZOCHRALSKI TECHNIQUE	129	189
— E —		
E FILMS ON ZIRCONIUM I. INFLUENCE OF FORMATION CONDITIONS ON	129	1895
A SIGNATURE IN THE CURRENT DURING	129	340
OLIN PALLADIUM MEDAL ADDRESS--ELECTRO(ANALYTICAL) CHEMISTRY	129	59C
LUMINESCENCE OF RARE	129	1552
FILAMENT MATERIALS FOR	129	2838
ON OF ADSORPTION PARAMETERS AND ADSORPTION RATES FOR THE	129	295C
BALT(II) COMPLEXES WITH O-PHE SOLUTION REDOOX COUPLES FOR	129	61
IN DIMETHYLSULFOXIDE: ION-PAIR, PROTONATION, AND ADSORPTION	129	1960
TIO2-VO2 ALLOYS--REDUCED BANDGAP	129	1210
SILICON DIOXIDE	129	2042
ION ETCHING THE	129	2522
DOWN IN SIO2 FILM ON SI	129	224
SPREADING RESISTANCE PROBE-SPACING EXPERIMENT SIMULATIONS:	129	2788
ISTRIBUTION IN PARALLEL-PLATE ELECTROCHEMICAL FLOW REACTORS	129	1670
ES OF AL CONDUCTORS IN INTEGRATED CIRCUITS	129	2270
CHELATING-POLYMER ADSORPTION	129	2673
MINATED SURFACE BARRIER CELLS RECOMBINATION	129	1134
SPUTTER ETCHING	129	2760
THEORETICAL ANALYSIS OF ELECTROSTATIC	129	958
RENCE HYDROGEN ANNEAL	129	806
RTICAL ELECTRODES DURING ELECTRODEPOSITION MAGNETIC FIELD	129	1266
ELECTROLYTE SOLUTIONS. PHOTO-OXIDATION OF HALIDES WITH HIGH	129	1461
FORMATION OF NIOBIUM ALUMINIDES AS DETERMINED BY THE KNUDSEN	129	1608
INTERACTIONS ASSOCIATED WITH CARBON AND OXYGEN TRANSPORT IN	129	1356
DETERIORATED A-C POWDER	129	362
ETCHING EFFECT ON AC POWDER	129	2059
CONTROL OF PLASMA ETCH PROFILES WITH PLASMA SHEATH	129	2541
HYDROGEN CONCENTRATION GRADIENT AND ASSOCIATED	129	1851
SILICON: ITS MATERIAL COMPOSITION, OXIDATION RESISTANCE, AND	129	408
UM TITANATE	129	1021
OF MASK MAKERS THE	129	1800
FOR VLSI APPLICATION	129	2590
PREPARATION AND	129	2795
CIDE/POLYSILICON ELECTRODES	129	1307
OSITION RATIOS THE CORRELATIONS BETWEEN PHYSICAL AND	129	1773
LED POLYCRYSTALLINE SILICON FILMS HEAVILY DOPED WITH ARSENIC	129	1811
DS BY COOLING THE HCL LIQUID SOURCE IMPROVING THE	129	2566
MPARISON OF A-C AND D-C INHOMOGENEITY CONTRIBUTION TO THE	129	2113
POTENTIODYNAMIC STUDY OF GLUCOSE	129	2207
NUM THE ADSORPTION AND THE POTENTIODYNAMIC	129	1493
ATED PHTHALOCYANINES ADSORBED ON A GRAPHITE ELECTRODE	129	2242
E, MIXED FE-MO, AND MO NAPHTHALOCYANINES. APPLICATION TO THE	129	1409
LANTHANUM NICKELATE AS	129	2391
NEW ASPECTS OF D-C	129	1289
EFFECT OF ACTIVE SURFACE AREA ON THE RESPONSE TIME OF	129	2451
OPTICAL CHARACTERISTICS OF WO3	129	2633
N-CONTAINING POLYMERS AS SEMISOLID ELECTROLYTES IN WO3-BASED	129	1215
ON ELECTRODES AND THE USE OF THE MODIFIED ELECTRODES FOR AN	129	762
SMALL-SIGNAL A-C RESPONSE THEORY FOR	129	1754
AN ELLIPSOMETRIC STUDY OF	129	335
AN ELLIPSOMETRIC STUDY OF	129	767
LFATE BATHS ZINC	129	2695
IMAGE ANALYSIS OF MORPHOLOGICAL INSTABILITY IN GALVANOSTATIC	129	2442
IMAGE ANALYSIS OF MORPHOLOGICAL INSTABILITY IN GALVANOSTATIC	129	2447
THE	129	2654
STUDY OF ALTERNATING VOLTAGE MODULATION ON A ROTATIING DISK	129	2677
RESISTANCE OF A PLANAR ARRAY OF SPHERES: GAS BUBBLES ON AN	129	2715
IGHT CONVERSION AT ONE-DIMENSIONAL NICKEL DITHIOLENE COMPLEX	129	2378
MASS-TRANSFER STUDY OF CARBON FELT, FLOW-THROUGH	129	1993
TALYZED BY SULFONATED PHTHALOCYANINES ADSORBED ON A GRAPHITE	129	2242
POTENTIAL DISTRIBUTION ON A CARBON-BASED BIFUNCTIONAL AIR	129	1159
PHOTOELECTROLYSIS AT FE203/TIO2 HETEROJUNCTION	129	342
AL DEPOSITION OF SILVER ON GOLD USING THE ROTATING RING-DISK	129	1202
LEAD DEFICIENCY AND HYDROGEN CONTENT IN BATTERY	129	1678
EVALUATION OF NICKEL FOR POSITIVE	129	496
S INSIDE ARTIFICIAL PITS AND ON POLARIZED SURFACES AN	129	669
THE KINETICS OF THE LITHIUM	129	2649
THE A-C RESPONSE OF NICKEL OXIDE	129	535
ELECTROHYDRODYNAMICAL IMPEDANCE ON A ROTATING DISK	129	107
HERMODYNAMIC AND PHOTOELECTROCHEMICAL BEHAVIOR OF THE N-TIO2	129	2132
THE EFFECT OF SULFUR ON THE ANODIC H2(NI)	129	1441
THE FORMATION OF LITHIUM-ALUMINUM ALLOYS AT AN ALUMINUM	129	901
IN THE SELECTIVE ELECTROSYNTHESES ON CHEMICALLY MODIFIED	129	1681
TIONS DESIGN OF A CELL FOR	129	135
ELECTROLYTE INTERFACE	129	1921
DEFECTS AND DISORDER IN THE FAST-ION	129	2509
Y OF ALTERNATING VOLTAGE MODULATION ON A ROTATIING D ZINC	129	2677
SIMULATION OF CHANGING	129	78
A TRANSITION IN THE KINETICS OF THE NI(OH)2/NIOOH	129	983
THE EFFECT OF ELECTRODE SURFACE IMPURITIES ON THE OXYGEN	129	345
TEP RELAXATION TECHNIQUES FOR THE MEASUREMENT OF KINETICS OF	129	1943
A STUDY OF THE IRON	129	1173
DE REACTION AT ZIRCONIA ELECTROLYTES THE EFFECT OF	129	345
T--FOURIER TRANSFORM INFRARED STUDIES OF CHEMICALLY MODIFIED	129	300C
DUAL MEASUREMENT OF POTENTIALS INSIDE ARTIFICIAL P	129	669
DYES VISUAL DETECTION OF HYDRATED AL	129	1517
DYNAMIC OXYGEN EQUILIBRIUM IN SILICON MELTS DURING	129	189
E-I RELATIONS A STUDY BY NUCLEAR MICROANALYSIS AND	129	1895
EARLY EVENTS IN THE PITTING CORROSION OF ALUMINUM	129	340
EARLY THIS CENTURY	129	59C
EARTH ACTIVATED LUTETIUM OXYHALIDE PHOSPHORS	129	1552
EDGE-SUPPORTED PULLING OF SILICON SHEET CRYSTALS	129	2838
EDWARD WESTON SUMMER FELLOWSHIP REPORT--QUANTITATI	129	295C
EELECTROCHEMICAL ENERGY STORAGE II. COBALT(III)-CO	129	61
EFFECTS ELECTROCHEMICAL REDUCTION OF NICOTINAMIDE	129	1960
EFFECTS IN THE PHOTOELECTROLYSIS OF WATER	129	1210
EFFECTS OF AMMONIA ANNEAL ON ELECTRON TRAPPINGS IN	129	2042
EFFECTS OF MIXING N2 IN CCL4 ON ALUMINUM REACTIVE	129	2522
EFFECTS OF PLASMA CLEANING ON THE DIELECTRIC BREAK	129	224
EFFECTS OF PROBE-CURRENT DENSITY AND LAYER THICKNE	129	2788
EFFECTS OF SEPARATOR AND TERMINAL ON THE CURRENT D	129	1670
EFFECTS OF SEVERAL PARAMETERS ON THE CORROSION RAT	129	2270
EFFECTS ON CORROSION OF STEEL	129	2673
EFFECTS ON CURRENT-VOLTAGE CHARACTERISTICS OF ILLU	129	1134
EFFECTS ON GAAS SCHOTTKY JUNCTIONS	129	2760
EFFECTS ON ION TRANSPORT IN ULTRATHIN MEMBRANES	129	958
EFFECTS ON METAL-SEMICONDUCTOR WORK FUNCTION DIFFE	129	806
EFFECTS ON THE GROWTH OF THE DIFFUSION LAYER AT VE	129	1266
EFFICIENCY CHARACTERIZATION OF N-TYPE SEMICONDUCTI	129	1461
EFFUSION METHOD ENTHALPIES OF	129	1608
EFG OF SILICON RIBBON MODELING OF AMBIENT-MENISCUS	129	1356
EL CELL BRIGHTNESS RECOVERY	129	362
EL PHOSPHOR BRIGHTNESS AND MAINTENANCE	129	2059
ELECTRIC FIELD AND RF POWER DENSITY	129	2541
ELECTRIC FIELDS IN TIO2 PHOTOANODES	129	1851
ELECTRICAL CHARACTERISTICS LOW ENERGY NITROGEN IMP	129	408
ELECTRICAL CONDUCTIVITY IN LANTHANUM-DOPED STRONTI	129	1021
ELECTRICAL MEASUREMENT OF PATTERN PLACEMENT ERRORS	129	1800
ELECTRICAL PROPERTIES OF AL/TI CONTACT METALLURGY	129	2590
ELECTRICAL PROPERTIES OF AN ANODIC OXIDE OF INP	129	2795
ELECTRICAL PROPERTIES OF COMPOSITE EVAPORATED SILI	129	1307
ELECTRICAL PROPERTIES OF PECVD SIN WITH THEIR COMP	129	1773
ELECTRICAL PROPERTIES OF THERMALLY AND LASER ANNEA	129	1811
ELECTRICAL PROPERTIES OF VAPOR GROWN III-V COMPOUN	129	2566
ELECTRICAL PROPERTIES OF Y-DOPED CEO2 CERAMICS: CO	129	2113
ELECTRO-OXIDATION AT BRIGHT PLATINUM ELECTRODES	129	2207
ELECTRO-OXIDATION OF ACETYLENE ON PLATINIZED PLATI	129	1493
ELECTRO-OXIDATION OF HYDRAZINE CATALYZED BY SULFON	129	2242
ELECTROCATALYSIS OF OXYGEN REACTION EPR INVESTIGAT	129	1409
ELECTROCATALYST: OXYGEN EVOLUTION	129	2391
ELECTROCHEMILUMINESCENCE	129	1289
ELECTROCHROMIC AND ELECTROLYTIC DISPLAYS	129	2451
ELECTROCHROMIC CELLS UNDER HEAVY LI ION INJECTION	129	2633
ELECTROCHROMIC DEVICES IO	129	1215
ELECTROCHROMIC DISPLAY DEVICE POLYMER-MODIFIED ELE	129	762
ELECTROCHROMIC THIN FILMS	129	1754
ELECTROCHROMISM IN IRIDIUM OXIDE	129	335
ELECTROCHROMISM IN TUNGSTEN OXIDE	129	767
ELECTROCRYSTALLIZATION FROM IMPURITY-CONTAINING SU	129	2695
ELECTROCRYSTALLIZATION I. GENERAL EXPRESSION FOR T	129	2442
ELECTROCRYSTALLIZATION II. EXPERIMENTAL DEMONSTRAT	129	2447
ELECTROCRYSTALLIZATION OF ZINC FROM ALKALINE MEDIA	129	2654
ELECTRODE ZINC ELECTRODE MORPHOLOGY IN ALKALINE SO	129	2677
ELECTRODE	129	2715
ELECTRODE VISIBLE L	129	2378
ELECTRODE	129	1993
ELECTRODE ELECTRO-OXIDATION OF HYDRAZINE CA	129	2242
ELECTRODE	129	1159
ELECTRODE	129	342
ELECTRODE INTERPRETATION OF POTENTIOSTATIC TRANSIE	129	1202
ELECTRODE BETA-PBO2	129	1678
ELECTRODE COMPONENTS IN LI-AL/FES CELLS	129	496
ELECTRODE DESIGN FOR DUAL MEASUREMENT OF POTENTIAL	129	669
ELECTRODE DURING THE DISCHARGE OF LI/SOCL2 CELLS	129	2649
ELECTRODE FILMS	129	535
ELECTRODE I. REDOX SYSTEM	129	107
ELECTRODE IN FLUORIDE-CONTAINING SOLUTIONS T	129	2132
ELECTRODE IN FUSED LI2CO3-K2CO3 AT 650DEGREE C	129	1441
ELECTRODE IN PROPYLENE CARBONATE	129	901
ELECTRODE IV. SELECTIVE REDUCTION OF O-NITROPHENOL	129	1681
ELECTRODE KINETIC INVESTIGATIONS OF FUEL CELL REAC	129	135
ELECTRODE KINETICS AT THE PALLADIUM/CERAMIC OXIDE	129	1921
ELECTRODE LITHIUM-ALUMINUM	129	2509
ELECTRODE MORPHOLOGY IN ALKALINE SOLUTIONS I. STUD	129	2677
ELECTRODE PROFILES	129	78
ELECTRODE REACTION	129	983
ELECTRODE REACTION AT ZIRCONIA ELECTROLYTES	129	345
ELECTRODE REACTIONS ERROR ANALYSIS OF THE POTENTIA	129	1943
ELECTRODE STRUCTURE OF NI-FE CELL	129	1173
ELECTRODE SURFACE IMPURITIES ON THE OXYGEN ELECTRO	129	345
ELECTRODE SURFACES THE JOSEPH W. RICHARDS SUMMER F	129	300C

		Vol	Page
OF P-NITROPHENOL WITH ALPHA-CYCLODEXTRIN IN SOLUTION AND ON	**ELECTRODE** SURFACES SELECTIVE ELECTROSYNTHESES ON C	129	1681
ING THIONYL CHLORIDE ACTIVATION OF RUO2 AND PTO	**ELECTRODE** SURFACES FOR IMMOBILIZATION REACTIONS US	129	756
ALLOY (CO-W) FROM WC-CO CEMENTED CARBIDES IN PARTICULATE BED	**ELECTRODE** SYSTEMS SELECTIVE DISSOLUTION OF THE BIN	129	2666
AN EXPERIMENTAL STUDY OF A PACKED BED	**ELECTRODE** WITH COPPER PARTICLES	129	347
USE OF A HIGH TEMPERATURE PH SENSOR AS A "PSEUDO-REFERENCE	**ELECTRODE**" IN THE MONITORING OF CORROSION AND REDO	129	1445
CROSCOPY DIRECT OBSERVATIONS OF INCLUSIONS IN	**ELECTRODEPOSITED** FILMS BY TRANSMISSION ELECTRON MI	129	201C
ELLS MORPHOLOGY, PROPERTIES, AND PERFORMANCE OF	**ELECTRODEPOSITED** N-CDSE IN LIQUID JUNCTION SOLAR C	129	2016
GROWTH OF THE DIFFUSION LAYER AT VERTICAL ELECTRODES DURING	**ELECTRODEPOSITION** MAGNETIC FIELD EFFECTS ON THE	129	1266
CD COATINGS ON IRON HYDROGEN ABSORPTION DURING	**ELECTRODEPOSITION** AND HYDROGEN CHARGING OF SN AND	129	284
NZENES IN ALUMINUM BROMIDE AND HBR (ELECTROLYTE USED FOR THE	**ELECTRODEPOSITION** OF ALUMINUM) DISPROPORTIONATION	129	40
THE HIGH SPEED	**ELECTRODEPOSITION** OF SN/PB ALLOYS	129	1196
DEFECT STRUCTURE IN NICKEL	**ELECTRODEPOSITS**	129	45
SIMS AND AES ANALYSIS OF H:TIO2	**ELECTRODES**	129	94
EMICALLY COPRECIPITATED COBALT HYDROXIDE IN NICKEL HYDROXIDE	**ELECTRODES** THE MECHANICS OF ELECTROCH	129	118
OTOANODIC DISSOLUTION OF N-CDS STUDIED BY ROTATING RING-DISK	**ELECTRODES** PH	129	149
DEPOSITION AND DISSOLUTION ON SINUSOIDAL	**ELECTRODES**	129	316
HEMICAL BEHAVIOR AT POLYPYRROLE-COATED PLATINUM AND TANTALUM	**ELECTRODES** POLYMER FILMS ON ELECTRODES VII. ELECTR	129	1009
ON AND TRAPPING ON THE CATHODIC PHOTOCURRENT AT P-TYPE III-V	**ELECTRODES** THE INFLUENCE OF SURFACE RECOMBINATI	129	730
AND ELECTROLUMINESCENT PROPERTIES OF CADMIUM SULFO-SELENIDE	**ELECTRODES** LUMINESCENT PHOTOELECTROCHEMICAL CELLS	129	772
CURRENT COLLECTORS ON THE PERFORMANCE OF FLOW-THROUGH POROUS	**ELECTRODES** THE EFFECT OF MULTIPLE	129	991
UMINA "FIBER FP" REINFORCED PURE LEAD COMPOSITES FOR BATTERY	**ELECTRODES** AL	129	1749
RUO2 OVERLAYERS ON THE PHOTOELECTROCHEMICAL BEHAVIOR OF CDS	**ELECTRODES** THE EFFECT OF SPUTTERED	129	1733
PLASMA ETCHING OF COMPOSITE SILICIDE GATE	**ELECTRODES**	129	1330
ICAL PROPERTIES OF COMPOSITE EVAPORATED SILICIDE/POLYSILICON	**ELECTRODES** ELECTR	129	1307
YNAMIC STUDY OF GLUCOSE ELECTRO-OXIDATION AT BRIGHT PLATINUM	**ELECTRODES** POTENTIOD	129	2207
M REDOX COUPLE AT PLATINUM, N-SILICON AND N-INDIUM PHOSPHIDE	**ELECTRODES** THE ELECTROCHEMISTRY AND PHOTOELECTROCH	129	1987
TTKY PLOTS AND FLATBAND POTENTIALS FOR SINGLE CRYSTAL RUTILE	**ELECTRODES** MOTT-SCHO	129	1973
NSTANTS FOR HYDROGEN PEROXIDE DECOMPOSITION AT ROTATING DISK	**ELECTRODES** COMMENTS ON THE VAN DER BRINK, BARENDRE	129	2268
-TETRA (N,N,N-TRIMETHYLANILINIUM) PORPHYRIN ON GLASSY CARBON	**ELECTRODES** CATALYSIS OF OXYGEN CATHODIC REDUCTION	129	2247
MASS TRANSFER AT LONGITUDINALLY VIBRATING VERTICAL	**ELECTRODES**	129	1955
SURFACE STRUCTURE OF RUTHENIUM DIOXIDE	**ELECTRODES** AND KINETICS OF CHLORINE EVOLUTION	129	1689
HENANTHROLINE DISULFONIC ACIDD) BOUND TO POLYELECTROLYTES ON	**ELECTRODES** AND THE USE OF THE MODIFIED ELECTRODES	129	762
LITHIUM-ALUMINUM	**ELECTRODES** AT AMBIENT TEMPERATURES	129	1429
NDUCTOR ELECTRODES XLI. IMPROVEMENT OF PERFORMANCE OF N-WSE2	**ELECTRODES** BY ELECTROCHEMICAL POLYMERIZATION OF O-	129	265
PLANES SEMI-INFINITE DIFFUSION TO	**ELECTRODES** CONSISTING OF TWO OR MORE INTERSECTING	129	128
ELD EFFECTS ON THE GROWTH OF THE DIFFUSION LAYER AT VERTICAL	**ELECTRODES** DURING ELECTRODEPOSITION MAGNETIC FI	129	1266
O POLYELECTROLYTES ON ELECTRODES AND THE USE OF THE MODIFIED	**ELECTRODES** FOR AN ELECTROCHROMIC DISPLAY DEVICE PO	129	762
THERMOMECHANICAL BEHAVIOR OF SIMULATED NEGATIVE	**ELECTRODES** FOR LI-AL/FES BATTERY CELLS	129	2265
ERMODYNAMIC STUDIES OF LI-GE ALLOYS: APPLICATION TO NEGATIVE	**ELECTRODES** FOR MOLTEN SALT BATTERIES TH	129	246
EMPERATURES STABILIZED CERAMIC MEMBRANE	**ELECTRODES** FOR THE MEASUREMENT OF PH AT ELEVATED T	129	1221
MATHEMATICAL MODEL FOR DESIGN OF BATTERY	**ELECTRODES** I. POTENTIAL DISTRIBUTION	129	688
F A LIGAND (BATHOPHENANTHROLINE DISULFON POLYMER-MODIFIED	**ELECTRODES** II. SPECTROELECTROCHEMICAL PROPERTIES O	129	762
PHOTOELECTROCHEMICAL PERFORMANCE OF ZNSE/CDSE THIN FILM	**ELECTRODES** IN AQUEOUS POLYSULFIDE ELECTROLYTE	129	542
SEMICONDUCTOR ELECTRODES XLVI. STABILIZATION OF N-SILICON	**ELECTRODES** IN AQUEOUS SOLUTION PHOTOELECTROCHEMICA	129	1647
OXIDATION OF H2 AT GAS DIFFUSION	**ELECTRODES** IN H2SO4 AND HBR	129	2464
CTROLYTE CONDUCTANCE AND CURRENT DISTRIBUTION IN POROUS ZINC	**ELECTRODES** IN KOH ELECTROLYTE THE RELATIONSHIP BET	129	1390
TRANSIENT CURRENT DISTRIBUTIONS IN POROUS ZINC	**ELECTRODES** IN KOH ELECTROLYTE	129	239
VIBRATING ZINC	**ELECTRODES** IN NI/ZN BATTERIES	129	913
CELLS PHASE RELATIONSHIPS IN POSITIVE	**ELECTRODES** OF HIGH TEMPERATURE LI-AL/LICL-KCL/FES2	129	925
COMPARISON OF MATERIALS AS OXYGEN CATALYTIC	**ELECTRODES** ON ZIRCONIA ELECTROLYTE	129	436
PHOTOELECTROCHEMICAL BEHAVIOR OF N-SI	**ELECTRODES** PROTECTED WITH PT-POLYPYRROLE	129	1737
RROLE-COATED PLATINUM AND TANTALUM ELECT POLYMER FILMS ON	**ELECTRODES** VII. ELECTROCHEMICAL BEHAVIOR AT POLYPY	129	1009
CHARACTERIZATION OF SEMICONDUCTOR	**ELECTRODES** WITH A DEEP IMPURITY LEVEL	129	2219
MODELING OF POROUS INSERTION	**ELECTRODES** WITH LIQUID ELECTROLYTE	129	1480
SPERSION THE PREPARATION OF TIO2	**ELECTRODES** WITH MINIMUM MOTT-SCHOTTKY FREQUENCY DI	129	2003
E2 ELECTRODES BY ELECTROCHEMICAL POLYMERIZA SEMICONDUCTOR	**ELECTRODES** XLI. IMPROVEMENT OF PERFORMANCE OF N-WS	129	265
FROM SHIFTS IN THE FLATBAND POTENTIAL OF P- SEMICONDUCTOR	**ELECTRODES** XLII. EVIDENCE FOR FERMI LEVEL PINNING	129	1742
TYPE MOTE2 IN AQUEOUS SOLUTIONS SEMICONDUCTOR	**ELECTRODES** XLV. PHOTOELECTROCHEMISTRY OF N- AND P-	129	2224
ODES IN AQUEOUS SOLUTION PHOTOELECTROCHEMIC SEMICONDUCTOR	**ELECTRODES** XLVI. STABILIZATION OF N-SILICON ELECTR	129	1647
LLINE P-TYPE WSE2 FILMS SEMICONDUCTOR	**ELECTRODES** 44. PHOTOELECTROCHEMISTRY AT POLYCRYSTA	129	673
ELECTROCHEMISTRY OF PRUSSIAN BLUE MODIFIED	**ELECTRODES**: AN ELECTROCHEMICAL PREPARATION METHOD	129	1498
IN SITU MONITORING OF LIQUID PHASE	**ELECTROEPITAXIAL** GROWTH	129	2095
SELECTIVE EPITAXIAL GROWTH OF GAAS BY LIQUID PHASE	**ELECTROEPITAXY**	129	194
ENHANCED STABILITY OF PHOTOELECTRODES WITH	**ELECTROGENERATED** POLYANILINE FILMS	129	2261
ELECTRODE I. REDOX SYSTEM	**ELECTROHYDRODYNAMICAL** IMPEDANCE ON A ROTATING DISK	129	107
PTION OF LIGAND KINETICS OF	**ELECTROLESS** COPPER PLATING VI. INHIBITION BY ADSOR	129	717
HS BY COULOSTATIC METHOD MEASUREMENT OF	**ELECTROLESS** PLATING RATE FOR COPPER AND NICKEL BAT	129	2183
THE	**ELECTROLUMINESCENCE** OF ZNS:CU, BR PHOSPHOR	129	813
NESCENT PHOTOELECTROCHEMICAL CELLS VII. PHOTOLUMINESCENT AND	**ELECTROLUMINESCENT** PROPERTIES OF CADMIUM SULFO-SEL	129	772
EXPLORATORY STUDIES ON	**ELECTROLYSIS** OF AIN DISSOLVED IN MOLTEN SALTS	129	102
DESIGN OF	**ELECTROLYSIS** UNDER COST-OPTIMAL THERMAL CONDITIONS	129	953
POROUS NICKEL-COATED STEEL ANODES FOR ALKALINE WATER	**ELECTROLYSIS**: CORROSION RESISTANCE	129	310
SIENT CURRENT DISTRIBUTIONS IN POROUS ZINC ELECTRODES IN KOH	**ELECTROLYTE** TRAN	129	239
ISON OF MATERIALS AS OXYGEN CATALYTIC ELECTRODES ON ZIRCONIA	**ELECTROLYTE** COMPAR	129	436
NCE OF ZNSE/CDSE THIN FILM ELECTRODES IN AQUEOUS POLYSULFIDE	**ELECTROLYTE** PHOTOELECTROCHEMICAL PERFORMA	129	542
BROMINE REDUCTION IN A TWO-PHASE	**ELECTROLYTE**	129	2397
SURFACE-MODIFIED P-INP PHOTOCATHODES IN SULFIDE/POLYSULFIDE	**ELECTROLYTE**	129	1387
SESSILE DROP STUDIES ON POLYBROMIDE/ZINC-BROMINE BATTERY	**ELECTROLYTE**	129	1747
CE AND CURRENT DISTRIBUTION IN POROUS ZINC ELECTRODES IN KOH	**ELECTROLYTE** THE RELATIONSHIP BETWEEN ELECTROLYTE C	129	1390
MODELING OF POROUS INSERTION ELECTRODES WITH LIQUID	**ELECTROLYTE**	129	1480
SOLAR CELLS WITH LAYER-TYPE SEMICONDUCTOR ANODES. NONAQUEOUS	**ELECTROLYTE** CELLS ELECTROCHEMICAL	129	1155
N POROUS ZINC ELECTRODES IN KOH THE RELATIONSHIP BETWEEN	**ELECTROLYTE** CONDUCTANCE AND CURRENT DISTRIBUTION I	129	1390
TRANSPORT NUMBER GRADIENTS AND SOLID	**ELECTROLYTE** DEGRADATION	129	752
CELLS THE THERMODYNAMICS OF	**ELECTROLYTE** DISTRIBUTION IN MOLTEN CARBONATE FUEL	129	942
AMETHYL FERROCENE AT THE N-GAAS/ROOM TEMPERATURE MOLTEN SALT	**ELECTROLYTE** INTERFACE PHOTOELECTROCHEMICAL OXIDATI	129	560
PHOTOINDUCED AND DARK CHARGE TRANSFER ACROSS N-TIO2-AQUEOUS	**ELECTROLYTE** INTERFACE INTERACTIONS BETWEEN	129	1240
ELECTRODE KINETICS AT THE PALLADIUM/CERAMIC OXIDE	**ELECTROLYTE** INTERFACE	129	1921
L CHARACTERIZATION OF THE N-INP/ROOM TEMPERATURE MOLTEN SALT	**ELECTROLYTE** INTERFACE PHOTOELECTROCHEMICA	129	2009
IENTS IN MOLTEN AGNO3-NANO3: A MODEL SYSTEM FOR THE LICL-KCL	**ELECTROLYTE** OF AN LI/S BATTERY CURRENT-INDUCED COM	129	49

		Vol	Page
SOLID POLYMER	**ELECTROLYTE** PHOTOVOLTAIC CELL	129	894
ING TUNGSTEN DISULFIDE PHOTOANODES IN AQUEOUS AND NONAQUEOUS	**ELECTROLYTE** SOLUTIONS. PHOTO-OXIDATION OF HALIDES	129	1461
ALTERNATE MATRIX MATERIAL FOR MOLTEN CARBONATE FUEL CELL	**ELECTROLYTE** STRUCTURES	129	979
S IN TIS2: CYCLIC VOLTAMMETRY AND CHRONOCOULOMETRY OF LIQUID	**ELECTROLYTE** SYSTEMS ELECTROCHEMICAL INVESTIGATIONS	129	677
ERMINATION OF MASS AND CHARGE TRANSPORT PROPERTIES OF LIQUID	**ELECTROLYTE** SYSTEMS ELECTROCHEMICAL INVESTIGATIONS	129	682
NATION REACTION OF ALKYLBENZENES IN ALUMINUM BROMIDE AND HBR	(**ELECTROLYTE** USED FOR THE ELECTRODEPOSITION OF ALU	129	40
THIUM DEPOSITS FROM LITHIUM HEXAFLUOROARSENATE/DIETHYL ETHER	**ELECTROLYTES** SPECULAR LI	129	1
FACE IMPURITIES ON THE OXYGEN ELECTRODE REACTION AT ZIRCONIA	**ELECTROLYTES** THE EFFECT OF ELECTRODE SUR	129	345
TRANSFERENCE NUMBERS OF ZINC IN ZINC-CHLORIDE BATTERY	**ELECTROLYTES**	129	907
DE ANODES UNDER CONDITIONS OF OZONE EVOLUTION IN STRONG ACID	**ELECTROLYTES** THE MECHANISM OF THE DISINTEGRATION O	129	567
INP AND CDS PHOTOANODES IN CONCENTRATED AQUEOUS IODIDE	**ELECTROLYTES**	129	1977
NEW SOLID	**ELECTROLYTES** BASED ON CUBIC ZRP2O7	129	726
CHARACTERIZATION OF ETHER	**ELECTROLYTES** FOR RECHARGEABLE LITHIUM CELLS	129	2404
LITHIUM CLOSOBORANE	**ELECTROLYTES** III. PREPARATION AND CHARACTERIZATION	129	2213
ION-CONTAINING POLYMERS AS SEMISOLID	**ELECTROLYTES** IN WO3-BASED ELECTROCHROMIC DEVICES	129	1215
ES OPTIMIZATION OF	**ELECTROLYTIC** CELLS HAVING LARGE NUMBERS OF VARIABL	129	1225
TIVE SURFACE AREA ON THE RESPONSE TIME OF ELECTROCHROMIC AND	**ELECTROLYTIC** DISPLAYS EFFECT OF AC	129	2451
REPORT ON THE	**ELECTROLYTIC** INDUSTRIES FOR THE YEAR 1981	129	275C
HLORIDES PREPARATION OF THE FIRST	**ELECTROLYTIC** PLUTONIUM AND OF URANIUM FROM FUSED C	129	2438
	ELECTROLYTIC POLISH FOR PB(1-X)SN(X)SE	129	2145
IVE FILM ON IRON-CHROMIUM ALLOYS	**ELECTRON** AND ION SPECTROSCOPIC STUDIES OF THE PASS	129	1662
XY USING SCANNING LASER AND ELECTRON BEAMS AND EVALUATION BY	**ELECTRON** BACKSCATTERING CONTRAST SINGLE CRYSTAL SI	129	2802
ECULAR WEIGHT DISTRIBUTIONS HIGH RESOLUTION	**ELECTRON** BEAM NEGATIVE RESIST WITH VERY NARROW MOL	129	663
A DRY DEVELOPMENT MODEL FOR A POSITIVE	**ELECTRON** BEAM RESIST	129	2598
GROWTH BY LATERAL NUCLEATED EPITAXY USING SCANNING LASER AND	**ELECTRON** BEAMS AND EVALUATION BY ELECTRON BACKSCAT	129	2802
IRON	**ELECTRON** DIFFRACTION STUDY OF THE PASSIVE FILM ON	129	2163
IONS OF INCLUSIONS IN ELECTRODEPOSITED FILMS BY TRANSMISSION	**ELECTRON** MICROSCOPY DIRECT OBSERVAT	129	201C
	ELECTRON MICROSCOPY OF WEB-DENDRITIC SILICON	129	1089
RESOLUTION LIMIT OF NEGATIVE	**ELECTRON** RESIST EXPOSED ON A THIN FILM SUBSTRATE	129	1831
DETAILED CONTRAST (GAMMA-VALUE) MEASUREMENTS OF POSITIVE	**ELECTRON** RESISTS	129	2576
ESR STUDIES OF NEGATIVE	**ELECTRON** RESISTS PGMA AND PST	129	1070
HACRYLONITRILE AND TRICHLOROETHYL METHACRYLATE COPOLYMERS AS	**ELECTRON** SENSITIVE POSITIVE RESISTS STUDIES OF MET	129	1596
NING PROCEDURES AUGER	**ELECTRON** SPECTROSCOPY STUDY OF GAAS SUBSTRATE CLEA	129	406
INK SUMMER FELLOWSHIP REPORT--DETERMINATION OF HETEROGENEOUS	**ELECTRON** TRANSFER KINETIC PARAMETERS BY DERIVATIVE	129	298C
TRATE HOT-ELECTRO INTERFACE TRAPPED CHARGE GENERATION AND	**ELECTRON** TRAPPING KINETICS IN MOSFET'S DUE TO SUBS	129	1760
EFFECTS OF AMMONIA ANNEAL ON	**ELECTRON** TRAPPINGS IN SILICON DIOXIDE	129	2042
OROETHYLENE	**ELECTRON** TRAPS IN SIO2 GROWN IN PRESENCE OF TRICHL	129	2772
IMPROVED DRY ETCHING RESISTANCE OF	**ELECTRON-BEAM** RESIST BY ION EXPOSURE PROCESS	129	2556
MEASUREMENT OF	**ELECTRONIC** CONDUCTIVITY IN FE-DOPED BETA-ALUMINA	129	1968
Y CATHODOLUMINESCENCE AN EXPERIMENTAL STUDY OF MOTION OF	**ELECTRONS** AND HOLES IN Y2O2S CRYSTAL AS REVEALED B	129	1535
HIGH-SPEED SELECTIVE	**ELECTROPLATING** WITH SINGLE CIRCULAR JETS	129	2424
F FLUOBORATE	**ELECTROPOLYMERIZATION** OF PYRROLE IN THE PRESENCE O	129	1685
N MEMBRANES THEORETICAL ANALYSIS OF	**ELECTROSTATIC** EFFECTS ON ION TRANSPORT IN ULTRATHI	129	958
IV. SELECTIVE REDUCTION OF O-NITROPHENOL IN THE SELECTIVE	**ELECTROSYNTHESES** ON CHEMICALLY MODIFIED ELECTRODE	129	1681
NG CURRENT	**ELECTROSYNTHESIS** OF PROPYLENE OXIDE WITH ALTERNATI	129	1157
EVELOPMENT OF AN ENERGY-EFFICIENT INSOLUBLE ANODE FOR NICKEL	**ELECTROWINNING** I. SINGLE LAYER PRECIOUS METAL COAT	129	515
EVELOPMENT OF AN ENERGY-EFFICIENT INSOLUBLE ANODE FOR NICKEL	**ELECTROWINNING** II. MULTILAYER PRECIOUS METAL COATI	129	522
ZED CERAMIC MEMBRANE ELECTRODES FOR THE MEASUREMENT OF PH AT	**ELEVATED** TEMPERATURES STABILI	129	1221
URING SELECTIVE FIELD OXIDATION IDENTIFICATION AND	**ELIMINATION** OF GATE OXIDE DEFECT ORIGIN PRODUCED D	129	800
D ON FE-25NI-XCR ALLOYS IN BORATE BUFFER SOLUTION AN	**ELLIPSOMETRIC** INVESTIGATION OF PASSIVE FILMS FORME	129	2419
THE NATURE OF THE PASSIVE FILM ON IRON I. AUTOMATIC	**ELLIPSOMETRIC** SPECTROSCOPY STUDIES	129	17
OXIDE AN	**ELLIPSOMETRIC** STUDY OF ELECTROCHROMISM IN IRIDIUM	129	335
OXIDE AN	**ELLIPSOMETRIC** STUDY OF ELECTROCHROMISM IN TUNGSTEN	129	767
AS	**ELLIPSOMETRIC** THICKNESS MEASUREMENTS OF PMMA ON GA	129	2273
ON FILMS	**ELLIPSOMETRY** MEASUREMENTS OF POLYCRYSTALLINE SILIC	129	1347
THE ROLE OF H2S IN THE CORROSION AND HYDROGEN	**EMBRITTLEMENT** OF STEEL	129	468
THE RELATION BETWEEN ETCH RATE AND OPTICAL	**EMISSION** INTENSITY IN PLASMA ETCHING	129	1325
N, OPTIMIZATION, AND CATHODOLUMINESCENT PROPERTIES OF A LINE	**EMISSION** PENETRATION PHOSPHOR PREPARATIO	129	1540
RELATIONSHIP TO FLUOROCARBON POLYMER FOR DIFLUOROCARBENE	**EMISSION** SPECTRA FROM FLUOROCARBON PLASMAS AND ITS	129	160
PIPED	**EMITTER** DELINEATION USING THE WRIGHT ETCH	129	354
STUDY OF	**ENCAPSULANTS** FOR ANNEALING SI-IMPLANTED GAAS	129	837
BY LAPLACE DOMAIN IMPE THE DETERMINATION OF SURFACE STATE	**ENERGIES** AT A SEMICONDUCTOR/ELECTROLYTE INTERFACE	129	2147
POTENTIOMETRIC DETERMINATION OF THE GIBBS	**ENERGIES** OF FORMATION OF LEAD ALUMINATES	129	1116
REACTOR	**ENERGY** ANALYSIS OF A STEADY-STATE ELECTROCHEMICAL	129	1936
ERIAL COMPOSITION, OXIDATION RESISTANCE, AND ELECTRIC LOW	**ENERGY** NITROGEN IMPLANTATION INTO SILICON: ITS MAT	129	408
ROOM TEMPERATURE FORMATION OF SI-NITRIDE FILMS BY LOW	**ENERGY** NITROGEN ION IMPLANTATION INTO SILICON	129	379
S WITH O-PHE SOLUTION REDOOX COUPLES FOR EELECTROCHEMICAL	**ENERGY** STORAGE II. COBALT(III)-COBALT(II) COMPLEXE	129	61
THE CHEMICAL NATURE OF ALUMINUM CORROSION V.	**ENERGY** TRANSFER IN ALUMINUM DISSOLUTION	129	464
OWINNING I. SINGLE LAYER PRECIOUS M THE DEVELOPMENT OF AN	**ENERGY-EFFICIENT** INSOLUBLE ANODE FOR NICKEL ELECTR	129	515
OWINNING II. MULTILAYER PRECIOUS ME THE DEVELOPMENT OF AN	**ENERGY-EFFICIENT** INSOLUBLE ANODE FOR NICKEL ELECTR	129	522
CHUMACHER--VITTORIO DE NORA-DIAMOND SHAMROCK ELECTROCHEMICAL	**ENGINEERING** AND TECHNOLOGY MEDALIST JOSEPH C. S	129	395C
ON RATES FOR DITHIOZONE ANION ADSORPTION AT AG USING SURFACE	**ENHANCED** AND RESONANCE ENHANCED RAMAN SPECTROSCOPY	129	295C
LICON BY THERMAL OXIDATION THE	**ENHANCED** DIFFUSION OF ARSENIC AND PHOSPHORUS IN SI	129	644
NZOTRIAZOLE ON COPPER SURFACE	**ENHANCED** RAMAN SCATTERING IN CORROSION SCIENCE: BE	129	1716
ANION ADSORPTION AT AG USING SURFACE ENHANCED AND RESONANCE	**ENHANCED** RAMAN SPECTROSCOPY THE EDWARD WESTON SUMM	129	295C
GENERATED POLYANILINE FILMS	**ENHANCED** STABILITY OF PHOTOELECTRODES WITH ELECTRO	129	2261
ILICON CRYSTALS: EVALUATION, THERMAL HISTORY DEPENDENCE, AND	**ENHANCEMENT** A STUDY ON INTRINSIC GETTERING IN CZ S	129	374
ETERMINED BY THE KNUDSEN EFFUSION METHOD	**ENTHALPIES** OF FORMATION OF NIOBIUM ALUMINIDES AS D	129	1608
. SORPTION AND TRANSPORT PROPERTIES IN CONCENTRATED SOLUTION	**ENVIRONMENTS** A COMPARISON OF PERFLUORINATED CARBOX	129	328
T PROPERTIES OF NAFION(R) MEMBRANES IN CONCENTRATED SOLUTION	**ENVIRONMENTS** TRANSPOR	129	85
TERMITTENT GROWTH PROCEDURES ON DISLOCATION DENSITIES IN INP	**EPI-LAYERS** THE INFLUENCE OF IN	129	1556
PHOSPHORUS INCORPORATION DURING SILICON	**EPITAXIAL** GROWTH IN A CVD REACTOR	129	1122
ITAXY SELECTIVE	**EPITAXIAL** GROWTH OF GAAS BY LIQUID PHASE ELECTROEP	129	194
VAPOR PHASE	**EPITAXIAL** GROWTH OF MGO.AL2O3	129	2569
DEFECT CONTROL DURING SILICON	**EPITAXIAL** GROWTH USING DICHLOROSILANE	129	1078
METHODS FOR DEFECT EVALUATION OF THIN (100) ORIENTED SILICON	**EPITAXIAL** LAYERS USING A WET CHEMICAL ETCH	129	2074
LATERAL	**EPITAXIAL** OVERGROWTH OF SILICON ON SIO2	129	2303
PHENOMENOLOGICAL MODEL OF THE CVD	**EPITAXIAL** REACTOR	129	1627
OLOGRAPHY GAS FLOW PATTERNS IN HORIZONTAL	**EPITAXIAL** REACTOR CELLS OBSERVED BY INTERFERENCE H	129	634

		Vol	Page
LOW DISLOCATION DENSITY RF-HEATED	**EPITAXIAL** SILICON	129	2858
REFILLING SILICON GROOVES BY LIQUID PHASE	**EPITAXY**	129	2819
HIGH LIFETIME SILICON LIQUID PHASE	**EPITAXY**	129	665
ON THE MORPHOLOGY OF AL(X)GA(1-X)AS GROWN BY MOLECULAR BEAM	**EPITAXY** INFLUENCE OF SUBSTRATE TEMPERATURE	129	824
EPENDENCE OF GROWTH RATE OF INGAAS/INP GROWN BY LIQUID PHASE	**EPITAXY** SUBSTRATE ORIENTATION D	129	2603
N FILMS ON AMORPHOUS INSULATORS: GROWTH BY LATERAL NUCLEATED	**EPITAXY** USING SCANNING LASER AND ELECTRON BEAMS AN	129	2802
GE INCORPORATION IN GAAS GROWN BY MOLECULAR BEAM	**EPITAXY:** A THERMODYNAMIC STUDY	129	2108
HALOCYANINES. APPLICATION TO THE ELECTROCATALYSIS OF OXYGEN	**EPR** INVESTIGATION OF FE, MIXED FE-MO, AND MO NAPHT	129	1409
BY THE CZOCHRALSKI TECHNIQUE DYNAMIC OXYGEN	**EQUILIBRIUM** IN SILICON MELTS DURING CRYSTAL GROWTH	129	189
ANSISTORS	**EQUILIBRIUM** NOISE IN ION SELECTIVE FIELD EFFECT TR	129	2306
NSE OF SEMICONDUCTOR/ELECTROLYTE/COUNTERELECTRODE CELLS	**EQUIVALENT** CIRCUIT ANALYSIS OF THE IMPEDANCE RESPO	129	551
A RED PHOSPHOR OF HIGH LUMEN	**EQUIVALENT,** Y2W3012:EU(3+)	129	2296
PHOTO- AND CATHODOLUMINESCENT PROPERTIES OF	**ERBIUM-DOPED** THIOGALLATES	129	2063
ELAXATION TECHNIQUES FOR THE MEASUREMENT OF KINETICS OF ELEC	**ERROR** ANALYSIS OF THE POTENTIAL AND VOLTAGE STEP R	129	1943
THE GALVANOSTATIC METHOD: ANALYSIS OF	**ERROR** AND COMPUTATION OF PARAMETERS	129	1473
THE ELECTRICAL MEASUREMENT OF PATTERN PLACEMENT	**ERRORS** OF MASK MAKERS	129	1800
PST	**ESR** STUDIES OF NEGATIVE ELECTRON RESISTS PGMA AND	129	1070
LITHOGRAPHIC EVALUATION OF AN O-NITROBENZYL	**ESTER** BASED DEEP U.V. RESIST SYSTEM	129	2552
OXYL RADICAL ON PLATINUM AN	**ESTIMATE** OF THE HEAT OF ADSORPTION OF THE HYDROPER	129	1438
(100) ORIENTED SILICON EPITAXIAL LAYERS USING A WET CHEMICAL	**ETCH** METHODS FOR DEFECT EVALUATION OF THIN	129	2074
PIPED EMITTER DELINEATION USING THE WRIGHT	**ETCH**	129	354
STRUCTURAL COMPOSITION OF POLYMERS RELATIVE TO THEIR PLASMA	**ETCH** CHARACTERISTICS	129	205
ORIENTATION IN SI FILMS AN	**ETCH** PIT TECHNIQUE FOR ANALYZING CRYSTALLOGRAPHIC	129	1848
D RF POWER DENSITY CONTROL OF PLASMA	**ETCH** PROFILES WITH PLASMA SHEATH ELECTRIC FIELD AN	129	2541
ETCHING THE RELATION BETWEEN	**ETCH** RATE AND OPTICAL EMISSION INTENSITY IN PLASMA	129	1325
STUDY OF THE	**ETCH-STOP** MECHANISM IN SILICON	129	2051
NEW DISLOCATION	**ETCHANT** FOR INP	129	352
USE OF HBR-CH3COOH-K2CR2O7	**ETCHANT** TO ETCHED-MIRROR LASER FABRICATION	129	1524
INGAASP/INP PLANAR-STRIPE LASERS WITH CHEMICALLY	**ETCHED** MIRRORS	129	883
CTROSCOPY CHARACTERIZATION OF REACTIVE ION	**ETCHED** SILICON SURFACE BY DEEP LEVEL TRANSIENT SPE	129	2823
RIE CONTAMINATION OF	**ETCHED** SILICON SURFACES	129	1822
USE OF HBR-CH3COOH-K2CR2O7 ETCHANT TO	**ETCHED-MIRROR** LASER FABRICATION	129	1524
N BETWEEN ETCH RATE AND OPTICAL EMISSION INTENSITY IN PLASMA	**ETCHING** THE RELATIO	129	1325
CHARACTERIZATION OF A KAUFMAN ION SOURCE AND DETAILS OF SIO2	**ETCHING** REACTIVE ION BEAM ETCHING WITH CF4:	129	585
PROFILE CONTROL WITH O-C BIAS IN PLASMA	**ETCHING**	129	393
THE EFFECTS OF MIXING N2 IN CCL4 ON ALUMINUM REACTIVE ION	**ETCHING**	129	2522
ER ULTRAHIGH VACUUM SI AND AL	**ETCHING** AND PRODUCT DETECTION IN A PLASMA BEAM UND	129	2045
XIDE SOLUTIONS FOR GAAS/AL0.16GA0.84AS SELECTIVE	**ETCHING** CHARACTERISTICS OF PEROXIDE/AMMONIUM-HYDRO	129	2380
AND MAINTENANCE	**ETCHING** EFFECT ON AC POWDER EL PHOSPHOR BRIGHTNESS	129	2059
SPUTTER	**ETCHING** EFFECTS ON GAAS SCHOTTKY JUNCTIONS	129	2760
DRY	**ETCHING** FOR VLSI--A REVIEW	129	62C
TEMPERATURE DEPENDENCE OF INP AND GAAS	**ETCHING** IN A CHLORINE PLASMA	129	2533
MULTIPLE-ETCHANT LOADING EFFECT AND SILICON	**ETCHING** IN CIF3 AND RELATED MIXTURES	129	2755
AN AES EVALUATION OF CLEANING AND	**ETCHING** METHODS FOR INSB	129	2752
CHEMICAL PROPERTIES OF POLYMER FILMS FORMED DURING THE	**ETCHING** OF ALUMINUM IN CCL4 PLASMAS	129	2530
PLASMA	**ETCHING** OF COMPOSITE SILICIDE GATE ELECTRODES	129	1330
DED O2 CCL4 AND CL2 PLASMA	**ETCHING** OF III-V SEMICONDUCTORS AND THE ROLE OF AD	129	1599
CHEMICAL	**ETCHING** OF INGAASP/INP DH WAFER	129	1053
CHEMICAL	**ETCHING** OF INP AND INGAASP/INP	129	609
PLANAR PLASMA	**ETCHING** OF POLYSILICON USING CCL4 AND NF3	129	795
MICROWAVE PLASMA	**ETCHING** OF SI WITH CF4 AND SF6 GAS	129	2764
EN FLUORIDE MIXTURES PLASMA	**ETCHING** OF SILICON AND SILICON DIOXIDE WITH HYDROG	129	1770
REACTIVE ION	**ETCHING** OF SILICON DIOXIDE	129	1152
ROMETHANE. THE ROLE OF NITROGEN IN THE DISCH REACTIVE ION	**ETCHING** OF SILICON OXIDES WITH AMMONIA AND TRIFLUO	129	1036
SELECTIVE REACTIVE ION BEAM	**ETCHING** OF SIO2 OVER POLYCRYSTALLINE SI	129	396
SELECTIVE ISOTROPIC DRY	**ETCHING** OF SI3N4 OVER SIO2	129	2559
EXPOSURE PROCESS IMPROVED DRY	**ETCHING** RESISTANCE OF ELECTRON-BEAM RESIST BY ION	129	2556
ALUMINUM SPUTTER	**ETCHING** USING SICL4	129	1150
N SOURCE AND DETAILS OF SIO2 ETCHING REACTIVE ION BEAM	**ETCHING** WITH CF4: CHARACTERIZATION OF A KAUFMAN IO	129	585
LAR LITHIUM DEPOSITS FROM LITHIUM HEXAFLUOROARSENATE/DIETHYL	**ETHER** ELECTROLYTES SPECU	129	1
CHARACTERIZATION OF	**ETHER** ELECTROLYTES FOR RECHARGEABLE LITHIUM CELLS	129	2404
HOST SENSITIZATION MECHANISM OF	**EU(3+)** LUMINESCENCE IN (Y, IN)2O3	129	2069
ATION AND STABILITY OF IRON(II) AND (III) OXIDES IN LICL-KCL	**EUTECTIC** MELT AT 470DEGREE C REACTIONS OF FORM	129	1450
OF NITRATE AND NITRITE IONS IN THE MOLTEN NAOH-KOH (49 M/O)	**EUTECTIC** MIXTURE AT 250 DEGREE C ELECTROCHEMICAL B	129	123
	EUTECTIC PRECIPITATES IN FE-DOPED INP	129	2335
EM A STUDY ON INTRINSIC GETTERING IN CZ SILICON CRYSTALS:	**EVALUATION,** THERMAL HISTORY DEPENDENCE, AND ENHANC	129	374
ELECTRICAL PROPERTIES OF COMPOSITE	**EVAPORATED** SILICIDE/POLYSILICON ELECTRODES	129	1307
A SIGNATURE IN THE CURRENT DURING EARLY	**EVENTS** IN THE PITTING CORROSION OF ALUMINUM	129	340
URE OF RUTHENIUM DIOXIDE ELECTRODES AND KINETICS OF CHLORINE	**EVOLUTION** SURFACE STRUCT	129	1689
LANTHANUM NICKELATE AS ELECTROCATALYST: OXYGEN	**EVOLUTION**	129	2391
INTEGRATION OF LEAD DIOXIDE ANODES UNDER CONDITIONS OF OZONE	**EVOLUTION** IN STRONG ACID ELECTROLYTES THE MECHANIS	129	567
THE ANODIC	**EVOLUTION** OF OZONE	129	506
A MECHANISTIC STUDY OF OXYGEN	**EVOLUTION** ON NICO2O4 I. FORMATION OF HIGHER OXIDES	129	1724
QUESTIONS ON THE KINETICS OF O2	**EVOLUTION** ON OXIDE-COVERED METALS	129	700
ES IN CONCENTRATED SODIUM HYDROX KINETICS OF THE HYDROGEN	**EVOLUTION** REACTION ON MILD STEEL AND NICKEL CATHOD	129	2481
A COMPARISON OF PERFLUORINATED CARBOXYLATE AND SULFONATE ION	**EXCHANGE** POLYMERS I. DIFFUSION AND WATER SORPTION	129	324
A COMPARISON OF PERFLUORINATED CARBOXYLATE AND SULFONATE ION	**EXCHANGE** POLYMERS II. SORPTION AND TRANSPORT PROPE	129	328
	EXFOLIATION CORROSION OF ALMGSI ALLOYS IN WATER	129	1181
EADING RESISTANCE AND SHEET RESISTANCE PROBE-SPACING	**EXPERIMENT** SIMULATION AND THE RELATION BETWEEN SPR	129	599
ENSITY AND LAYER THICK SPREADING RESISTANCE PROBE-SPACING	**EXPERIMENT** SIMULATIONS: EFFECTS OF PROBE-CURRENT D	129	2788
2 AT LOW OXIDATION TEMPERATURES A VISCOUS FLOW MODEL TO	**EXPLAIN** THE APPEARANCE OF HIGH DENSITY THERMAL SIO	129	2594
ED IN MOLTEN SALTS	**EXPLORATORY** STUDIES ON ELECTROLYSIS OF AIN DISSOLV	129	102
RESOLUTION LIMIT OF NEGATIVE ELECTRON RESIST	**EXPOSED** ON A THIN FILM SUBSTRATE	129	1831
PROVED DRY ETCHING RESISTANCE OF ELECTRON-BEAM RESIST BY ION	**EXPOSURE** PROCESS IM	129	2556
STABILITY IN GALVANOSTATIC ELECTROCRYSTALLIZATION I. GENERAL	**EXPRESSION** FOR THE GROWTH MODE OF SURFACE IRREGULA	129	2442

— F —

ION STUDY OF PHASES IN THE SYSTEM CUO-NIO-MGO AT 1000 DEGREE	**F.N.** BECKET AWARD REPORT--AN X-RAY POWDER DIFFRACT	129	31C
KINETICS OF THE	**F,F2/B4C** GASIFICATION REACTIONS	129	1105

		Vol	Page
N INGAASP/INP HETEROJUNCTIONS LPE GROWTH TECHNIQUES FOR	FABRICATING ABRUPT ZINC- AND MAGNESIUM-DOPED P(+)-	129	2085
USE OF HBR-CH3COOH-K2CR2O7 ETCHANT TO ETCHED-MIRROR LASER	FABRICATION	129	1524
SCHOTTKY CONTACT	FABRICATION FOR GAAS MESFET'S	129	1795
POSITIVE RESISTS	FACTORS AFFECTING THE SENSITIVITY OF CROSS-LINKED	129	402
OXYGEN PRECIPITATION	FACTORS IN SILICON	129	1062
N INP SUBSTRATES USING THE METALORGANIC PROCESS	FACTORS INFLUENCING THE GROWTH OF GA0.47IN0.53AS O	129	383
DEFECTS AND DISORDER IN THE	FAST-ION ELECTRODE LITHIUM-ALUMINUM	129	2509
ON THE DOPING DEPENDENCE OF OXIDATION-INDUCED STACKING	FAULT SHRINKAGE IN SILICON	129	2319
RIDINIUM CHLORIDE IONIC LIQUID ELECTROCHEMICAL STUDIES OF	FE(II) AND FE(III) IN AN ALUMINUM CHLORIDE-BUTYLPY	129	2474
LORIDE IONIC LIQUID ELECTROCHEMICAL STUDIES OF FE(II) AND	FE(III) IN AN ALUMINUM CHLORIDE-BUTYLPYRIDINIUM CH	129	2474
MEASUREMENT OF ELECTRONIC CONDUCTIVITY IN	FE-DOPED BETA-ALUMINA	129	1968
EUTECTIC PRECIPITATES IN	FE-DOPED INP	129	2335
E ELECTROCATALYSIS OF OXYG EPR INVESTIGATION OF FE, MIXED	FE-MO, AND MO NAPHTHALOCYANINES. APPLICATION TO TH	129	1409
LEAD OPERATING PERFORMANCE OF AN	FE-TI STATIONARY REDOX BATTERY IN THE PRESENCE OF	129	2502
AN ELLIPSOMETRIC INVESTIGATION OF PASSIVE FILMS FORMED ON	FE-25NI-XCR ALLOYS IN BORATE BUFFER SOLUTION	129	2419
TION TO THE ELECTROCATALYSIS OF OXYG EPR INVESTIGATION OF	FE, MIXED FE-MO, AND MO NAPHTHALOCYANINES. APPLICA	129	1409
RYSTALS THE	FEATHERING OF DOPING STRIATIONS IN SEMICONDUCTOR C	129	1782
ELECTRON TRANSFER KINETIC THE COLIN GARFIELD FINK SUMMER	FELLOWSHIP REPORT--DETERMINATION OF HETEROGENEOUS	129	298C
IES OF CHEMICALLY MODIFIED THE JOSEPH W. RICHARDS SUMMER	FELLOWSHIP REPORT--FOURIER TRANSFORM INFRARED STUD	129	300C
METERS AND ADSORPTION RATES FOR THE EDWARD WESTON SUMMER	FELLOWSHIP REPORT--QUANTITATION OF ADSORPTION PARA	129	295C
MASS-TRANSFER STUDY OF CARBON	FELT, FLOW-THROUGH ELECTRODE	129	1993
TENTIAL OF P- SEMICONDUCTOR ELECTRODES XLII. EVIDENCE FOR	FERMI LEVEL PINNING FROM SHIFTS IN THE FLATBAND PO	129	1742
BITAL STUDY OPTICAL SPECTRA OF FERROUS AND	FERRIC OXIDES AND THE PASSIVE FILM: A MOLECULAR OR	129	2169
ROCHEMICAL OXIDATION OF AROMATIC HYDROCARBONS AND DECAMETHYL	FERROCENE AT THE N-GAAS/ROOM TEMPERATURE MOLTEN SA	129	560
THE ELECTROCHEMISTRY AND PHOTOELECTROCHEMISTRY OF AN AQUEOUS	FERROCENE/FERRICENIUM REDOX COUPLE AT PLATINUM, N-	129	1987
MOLECULAR ORBITAL STUDY OPTICAL SPECTRA OF	FERROUS AND FERRIC OXIDES AND THE PASSIVE FILM: A	129	2169
PHOTOELECTROLYSIS AT	FE2O3/TIO2 HETEROJUNCTION ELECTRODE	129	342
TERY ELECTRODES ALUMINA	"FIBER FP" REINFORCED PURE LEAD COMPOSITES FOR BAT	129	1749
ELECTROCHEMICAL STUDIES OF A DEPLETED URANIUM ALLOY TUNGSTEN	FIBER METAL MATRIX COMPOSITE CORROSION RATES AND	129	1398
SUPPRESSION OF THERMAL CONVECTION BY TRANSVERSE MAGNETIC	FIELD	129	427
CONTROL OF PLASMA ETCH PROFILES WITH PLASMA SHEATH ELECTRIC	FIELD AND RF POWER DENSITY	129	2541
DENSITY IN SILICON DIOXIDE BY HYDROGENATED AMORPHOUS SILICON	FIELD EFFECT TECHNIQUE DETERMINATION OF POSITIVE M	129	2770
THE SUSPENDED MESH ION SELECTIVE	FIELD EFFECT TRANSISTOR	129	2580
EQUILIBRIUM NOISE IN ION SELECTIVE	FIELD EFFECT TRANSISTORS	129	2306
AT VERTICAL ELECTRODES DURING ELECTRODEPOSITION MAGNETIC	FIELD EFFECTS ON THE GROWTH OF THE DIFFUSION LAYER	129	1266
E FILMS USING THE STEPPED CURREN AN INVESTIGATION OF HIGH	FIELD IONIC CONDUCTION IN ANODIC TANTALUM PENTOXID	129	2518
E FILMS USING THE O AN EXPERIMENTAL INVESTIGATION OF HIGH	FIELD IONIC CONDUCTION IN ANODIC TANTALUM PENTOXID	129	2513
NATION OF GATE OXIDE DEFECT ORIGIN PRODUCED DURING SELECTIVE	FIELD OXIDATION IDENTIFICATION AND ELIMI	129	800
HYDROGEN CONCENTRATION GRADIENT AND ASSOCIATED ELECTRIC	FIELDS IN TIO2 PHOTOANODES	129	1851
ILICON SHEET CRYSTALS	FILAMENT MATERIALS FOR EDGE-SUPPORTED PULLING OF S	129	2838
JUNCTION SOLAR CELL BASED ON CHEMICALLY DEPOSITED BI2S3 THIN	FILM AND SOME SEMICONDUCTING PROPERTIES OF BISMUTH	129	332
SPRAY-PYROLYZED THIN	FILM CDSE PHOTOELECTROCHEMICAL CELLS	129	719
TARNISHING OF SILVER BY ORGANIC SULFUR VAPORS: RATES AND	FILM CHARACTERISTICS	129	33
PHOTOELECTROCHEMICAL PERFORMANCE OF ZNSE/CDSE THIN	FILM ELECTRODES IN AQUEOUS POLYSULFIDE ELECTROLYTE	129	542
OLUTIONS UNDER OPEN-CIRCUI ELECTROCHEMICAL STUDIES OF THE	FILM FORMATION ON LITHIUM IN PROPYLENE CARBONATE S	129	1422
P-DOPED POLYSILICON	FILM GROWTH TECHNOLOGY	129	2620
ELECTRON DIFFRACTION STUDY OF THE PASSIVE	FILM ON IRON	129	2163
PY STUDIES THE NATURE OF THE PASSIVE	FILM ON IRON I. AUTOMATIC ELLIPSOMETRIC SPECTROSCO	129	17
THE NATURE OF THE PASSIVE	FILM ON IRON II. A-C IMPEDANCE STUDIES	129	474
RTHER SUPPORTING EVIDENCE THE NATURE OF THE PASSIVE	FILM ON IRON III. THE CHEMI-CONDUCTOR MODEL AND FU	129	921
ELECTRON AND ION SPECTROSCOPIC STUDIES OF THE PASSIVE	FILM ON IRON-CHROMIUM ALLOYS	129	1662
FECTS OF PLASMA CLEANING ON THE DIELECTRIC BREAKDOWN IN SIO2	FILM ON SI EF	129	224
CRACKING IN ALUMINUM OXIDE	FILM RUPTURE, REANODIZATION, AND STRESS CORROSION	129	2660
SOLUTION LIMIT OF NEGATIVE ELECTRON RESIST EXPOSED ON A THIN	FILM SUBSTRATE RE	129	1831
RESISTIVITIES OF THIN	FILM TRANSITION METAL SILICIDES	129	293
OPTICAL SPECTRA OF FERROUS AND FERRIC OXIDES AND THE PASSIVE	FILM: A MOLECULAR ORBITAL STUDY	129	2169
PROTON DIFFUSION IN TUNGSTEN TRIOXIDE THIN	FILMS	129	2349
CONFORMAL STEP COVERAGE OF LASER DEPOSITED SILICON DIOXIDE	FILMS	129	2155
ABILITY OF PHOTOELECTRODES WITH ELECTROGENERATED POLYANILINE	FILMS ENHANCED ST	129	2261
II. OXIDATION OF AL	FILMS	129	2369
DATION ON B AND P DIFFUSION IN SI DIRECTLY MASKED WITH SI3N4	FILMS EFFECT OF BACK-SIDE OXI	129	2292
ECTRIC AND PHOTOELECTROCHEMICAL PROPERTIES OF SPUTTERED TIO2	FILMS EFFECT OF HYDROGEN ON THE DIEL	129	2022
OPTICAL ABSORPTION OF THIN SIPOS	FILMS	129	197
TURAL AND OPTICAL PROPERTIES OF SOLUTION GROWN CDSE(1-X)S(X)	FILMS STRUC	129	99
ION STUDIES: MEASUREMENT OF THE DIFFUSION OF OXIDANT IN SIO2	FILMS SILICON OXIDAT	129	413
CVD HYDRCPHOBIC LEAD SILICATE	FILMS	129	165
LOW PRESSURE DEPOSITION OF PHOSPHOSILICATE GLASS	FILMS	129	1588
WATER ABSORPTION AND DENSIFICATION OF PHOSPHOSILICATE GLASS	FILMS	129	1765
SMALL-SIGNAL A-C RESPONSE THEORY FOR ELECTROCHROMIC THIN	FILMS	129	1754
T TECHNIQUE FOR ANALYZING CRYSTALLOGRAPHIC ORIENTATION IN SI	FILMS AN ETCH PI	129	1848
ELLIPSOMETRY MEASUREMENTS OF POLYCRYSTALLINE SILICON	FILMS	129	1347
ANISM OF GROWTH OF CHEMICAL VAPOR-DEPOSITED ALUMINUM NITRIDE	FILMS COMPOSITION, KINETICS, AND MECH	129	1045
DES 44. PHOTOELECTROCHEMISTRY AT POLYCRYSTALLINE P-TYPE WSE2	FILMS SEMICONDUCTOR ELECTRO	129	673
VOIDS IN ANODIC ALUMINUM OXIDE	FILMS	129	711
THE A-C RESPONSE OF NICKEL OXIDE ELECTRODE	FILMS	129	535
E ANODIC OXIDE	FILMS AND ELECTROCHEMICAL REACTIONS ON CD0.2HG0.8T	129	1710
ANODIC OXIDE	FILMS AND ELECTROCHEMICAL REACTIONS ON HGTE	129	739
I CALCULATION OF CARRIER CONCENTRATION IN POLYCRYSTALLINE	FILMS AS A FUNCTION OF SURFACE ACCEPTOR STATE DENS	129	1382
PH DEPENDENCE FORMATION OF THIN OXIDE	FILMS AT PLATINUM ANODES IN ALKALINE SOLUTIONS III	129	55
SILICON ROOM TEMPERATURE FORMATION OF SI-NITRIDE	FILMS BY LOW ENERGY NITROGEN ION IMPLANTATION INTO	129	379
DIRECT OBSERVATIONS OF INCLUSIONS IN ELECTRODEPOSITED	FILMS BY TRANSMISSION ELECTRON MICROSCOPY	129	201C
AN INVESTIGATION OF THE THICKNESS VARIATION OF SPUN-ON THIN	FILMS COMMONLY ASSOCIATED WITH THE SEMICONDUCTOR I	129	173
AFT CRYSTALLINE STRUCTURE CHANGES OF MOLYBDENUM SILICIDE	FILMS DEPOSITED BY SPUTTERING AND BY COEVAPORATION	129	1527
AND TRIMETHYLANTIMONY ANTIMONY-DOPED TIN OXIDE	FILMS DEPOSITED BY THE OXIDATION OF TETRAMETHYLTIN	129	1040
PROPERTIES OF PLASMA-ENHANCED CVD SILICON FILMS I. UNDOPED	FILMS DEPOSITED FROM 525 DEGREE TO 725 DEGREE C	129	2326
PROPERTIES OF PLASMA-ENHANCED CVD SILICON FILMS II.	FILMS DOPED DURING DEPOSITION	129	2331
FORMATION OF SALT	FILMS DURING PASSIVATION OF IRON	129	2412
4 PLASMAS CHEMICAL PROPERTIES OF POLYMER	FILMS FORMED DURING THE ETCHING OF ALUMINUM IN CCL	129	2530
R SOLUTION AN ELLIPSOMETRIC INVESTIGATION OF PASSIVE	FILMS FORMED ON FE-25NI-XCR ALLOYS IN BORATE BUFFE	129	2419

		Vol	Page
POLYPHOSPHATE SOLUTIONS	ON THE NATURE OF SURFACE	**FILMS** FORMED ON IRON IN AGGRESSIVE AND INHIBITING	129	1186
	THE USE OF S2CL2 FOR DOPING POLY-GAAS	**FILMS** GROWN BY THE ORGANOMETALLIC PROCESS	129	2778
TIES OF THERMALLY AND LASER ANNEALED POLYCRYSTALLINE SILICON		**FILMS** HEAVILY DOPED WITH ARSENIC AND PHOSPHORUS EL	129	1811
O 725 DEGREE C	PROPERTIES OF PLASMA-ENHANCED CVD SILICON	**FILMS** I. UNDOPED FILMS DEPOSITED FROM 525 DEGREE T	129	2326
	PROPERTIES OF PLASMA-ENHANCED CVD SILICON	**FILMS** II. FILMS DOPED DURING DEPOSITION	129	2331
	A POINT DEFECT MODEL FOR ANODIC PASSIVE	**FILMS** III. IMPEDANCE RESPONSE	129	1874
ON AND CHEMICAL REACTION DURING THERMAL TREATMENTS OF SILICA		**FILMS** IN WATER VAPOR AN 18O STUDY OF COOPERATIVE D	129	867
	THERMAL OXIDATION OF HEAVILY PHOSPHORUS-DOPED THIN	**FILMS** OF POLYCRYSTALLINE SILICON	129	2321
	CHEMICAL METHODS FOR THE DEPOSITION OF THIN	**FILMS** OF SB2SE3 AND SB2O3	129	1642
UCLEATED EPITAXY USING SCANNING LA	SINGLE CRYSTAL SILICON	**FILMS** ON AMORPHOUS INSULATORS: GROWTH BY LATERAL N	129	2802
AT POLYPYRROLE-COATED PLATINUM AND TANTALUM ELECT	POLYMER	**FILMS** ON ELECTRODES VII. ELECTROCHEMICAL BEHAVIOR	129	1009
	ANODIC BREAKDOWN OF PASSIVE	**FILMS** ON METALS	129	255
	LOW TEMPERATURE DOUBLE-PLASMA PROCESS FOR BN	**FILMS** ON SEMICONDUCTORS	129	2636
	THIN PALLADIUM	**FILMS** ON SILICON AND TITANIUM	129	2689
	INSTABILITY OF ANODIC OXIDE	**FILMS** ON TITANIUM	129	1252
	THE ELECTROCHEMICAL REDUCTION OF RUST	**FILMS** ON WEATHERING STEEL SURFACES	129	2686
MICROANALYSIS AND 18O TRACING OF THE GROWTH OF ANODIC OXIDE		**FILMS** ON ZIRCONIUM I. INFLUENCE OF FORMATION CONDI	129	1895
MICROANALYSIS AND 18O TRACING OF THE GROWTH OF ANODIC OXIDE		**FILMS** ON ZIRCONIUM II. OXIDE GROWTH MECHANISM A ST	129	1905
	STUDIES ON PHOTOELECTROCHEMICAL PROPERTIES OF SNO2	**FILMS** PREPARED FROM ORGANIC RESINATE SOLUTION	129	1501
	TITANIUM DIOXIDE	**FILMS** TO IMPROVE PHOTORESIST ADHESION	129	2389
OF HIGH FIELD IONIC CONDUCTION IN ANODIC TANTALUM PENTOXIDE		**FILMS** USING THE OPEN-CIRCUIT TRANSIENT METHOD AN E	129	2513
OF HIGH FIELD IONIC CONDUCTION IN ANODIC TANTALUM PENTOXIDE		**FILMS** USING THE STEPPED CURRENT METHOD AN INVESTIG	129	2518
	ZONE-MELTING RECRYSTALLIZATION OF SI	**FILMS** WITH A MOVEABLE-STRIP-HEATER OVEN	129	2812
	I. INTERACTION OF AL	**FILMS** WITH O2 AT LOW PRESSURES	129	2366
TEROGENEOUS ELECTRON TRANSFER KINETIC	THE COLIN GARFIELD	**FINK** SUMMER FELLOWSHIP REPORT--DETERMINATION OF HE	129	298C
USED CHLORIDES	PREPARATION OF THE	**FIRST** ELECTROLYTIC PLUTONIUM AND OF URANIUM FROM F	129	2438
	HETEROGENEOUS DECOMPOSITION OF SILANE IN A	**FIXED** BED REACTOR	129	1531
E FOR THIN OXIDES		**FIXED** CHARGE DENSITY (QSS) AT THE SI-SIO2 INTERFAC	129	1757
ES XLII. EVIDENCE FOR FERMI LEVEL PINNING FROM SHIFTS IN THE		**FLATBAND** POTENTIAL OF P-TYPPE SILICON IN ACETONITR	129	1742
TRODES	MOTT-SCHOTTKY PLOTS AND	**FLATBAND** POTENTIALS FOR SINGLE CRYSTAL RUTILE ELEC	129	1973
		FLAWS IN SIDEWALL OXIDES GROWN ON POLYSILICON GATE	129	1084
	OBSERVATIONS OF	**FLAWS** ON PRECONDITIONED ALUMINUM SURFACES	129	1515
TION BETWEEN MASS TRANSFER AND CORROSION IN A TURBULENT PIPE		**FLOW** RELA	129	276
	MASS TRANSFER IN LAMINAR	**FLOW** CHANNEL WITH POROUS WALL	129	1727
		FLOW DISTRIBUTION IN THE ZINC-CHLORIDE BATTERY	129	2251
TY THERMAL SIO2 AT LOW OXIDATION TEMPERATURES	A VISCOUS	**FLOW** MODEL TO EXPLAIN THE APPEARANCE OF HIGH DENSI	129	2594
S OBSERVED BY INTERFERENCE HOLOGRAPHY	GAS	**FLOW** PATTERNS IN HORIZONTAL EPITAXIAL REACTOR CELL	129	634
N THE CURRENT DISTRIBUTION IN PARALLEL-PLATE ELECTROCHEMICAL		**FLOW** REACTORS EFFECTS OF SEPARATOR AND TERMINAL O	129	1670
OF NICKEL	PIT AND	**FLOW** STREAK FORMATION DURING HIGH RATE DISSOLUTION	129	1889
	MASS-TRANSFER STUDY OF CARBON FELT,	**FLOW-THROUGH** ELECTRODE	129	1993
EFFECT OF MULTIPLE CURRENT COLLECTORS ON THE PERFORMANCE OF		**FLOW-THROUGH** POROUS ELECTRODES THE	129	991
VOLATILIZATION/CONDENSATION OF ALKALI SALTS IN A PRESSURIZED		**FLUIDIZED** BED COAL COMBUSTOR/GAS TURBINE COMBINED	129	2119
	ELECTROPOLYMERIZATION OF PYRROLE IN THE PRESENCE OF	**FLUOBORATE**	129	1685
VISUAL DETECTION OF HYDRATED ALUMINUM OXIDE BY STAINING WITH		**FLUORESCING** AND NONFLUORESCING DYES	129	1517
PLASMA ETCHING OF SILICON AND SILICON DIOXIDE WITH HYDROGEN		**FLUORIDE** MIXTURES	129	1770
AND PHOTOELECTROCHEMICAL BEHAVIOR OF THE N-TIO2 ELECTRODE IN		**FLUORIDE-CONTAINING** SOLUTIONS THERMODYNAMIC	129	2132
	EXPERIMENTAL STUDY OF ELECTROCHEMICAL	**FLUORINATION** OF TRICHLOROETHYLENE	129	2720
HODIC DEPOSITION OF AMORPHOUS ALLOYS OF SILICON, CARBON, AND		**FLUORINE** CAT	129	936
OCARBON POLYMER FOR DIFLUOROCARBENE EMISSION SPECTRA FROM		**FLUOROCARBON** PLASMAS AND ITS RELATIONSHIP TO FLUOR	129	160
ON SPECTRA FROM FLUOROCARBON PLASMAS AND ITS RELATIONSHIP TO		**FLUOROCARBON** POLYMER FORMATION DIFLUOROCARBENE EMI	129	160
ANALYSIS OF PHOTOELECTROCHEMICAL CELLS UNDER MASS AND LIGHT		**FLUX** VARIATION CURRENT-VOLTAGE	129	2029
	INTERFEROMETRIC STUDY OF COMBINED	**FORCED** AND NATURAL CONVECTION	129	2201
RACTERIZATION OF REACTIONS AND PRODUCTS OF THE DISCHARGE AND		**FORCED** OVERDISCHARGE OF LI/SO2 CELLS CHA	129	1857
OCARBON PLASMAS AND ITS RELATIONSHIP TO FLUOROCARBON POLYMER		**FORMATION** DIFLUOROCARBENE EMISSION SPECTRA FROM FL	129	160
S OF SO2(SO3) WITH NIO-NA2SO4 IN NICKEL-SODIUM MIXED SULFATE		**FORMATION** AND LOW TEMPERATURE HOT CORROSION REACTI	129	1613
ES IN LICL-KCL EUTECTIC MELT AT 470DEGREE C	REACTIONS OF	**FORMATION** AND STABILITY OF IRON(II) AND (III) OXID	129	1450
ES CONTAINING OXIDE DISPERSIONS	PEG	**FORMATION** BY SHORT-CIRCUIT DIFFUSION IN AL2O3 SCAL	129	1147
HE GROWTH OF ANODIC OXIDE FILMS ON ZIRCONIUM I. INFLUENCE OF		**FORMATION** CONDITIONS ON E-I RELATIONS A STUDY BY N	129	1895
	PIT AND FLOW STREAK	**FORMATION** DURING HIGH RATE DISSOLUTION OF NICKEL	129	1889
	EFFECT OF MELT STOICHIOMETRY ON TWIN	**FORMATION** IN LEC GAAS	129	2382
	A MECHANISTIC STUDY OF OXYGEN EVOLUTION ON NICO2O4 I.	**FORMATION** OF HIGHER OXIDES	129	1724
	POTENTIOMETRIC DETERMINATION OF THE GIBBS ENERGIES OF	**FORMATION** OF LEAD ALUMINATES	129	1116
M ELECTRODE IN PROPYLENE CARBONATE	THE	**FORMATION** OF LITHIUM-ALUMINUM ALLOYS AT AN ALUMINU	129	901
HE KNUDSEN EFFUSION METHOD	ENTHALPIES OF	**FORMATION** OF NIOBIUM ALUMINIDES AS DETERMINED BY T	129	1608
ELECTRODES IN AQUEOUS SOLUTION PHOTOELECTROCHEMICAL CELLS BY		**FORMATION** OF PLATINUM SILICIDE LAYERS SEMICONDUCTO	129	1647
		FORMATION OF SALT FILMS DURING PASSIVATION OF IRON	129	2412
EN ION IMPLANTATION INTO SILICON	ROOM TEMPERATURE	**FORMATION** OF SI-NITRIDE FILMS BY LOW ENERGY NITROG	129	379
N ALKALINE SOLUTIONS III. PH DEPENDENCE		**FORMATION** OF THIN OXIDE FILMS AT PLATINUM ANODES I	129	55
ONS UNDER OPEN-CIRCUI	ELECTROCHEMICAL STUDIES OF THE FILM	**FORMATION** ON LITHIUM IN PROPYLENE CARBONATE SOLUTI	129	1422
DUCTING	THE ELECTROCHEMICAL RESPONSE OF NICKEL HYDROXIDE	**FORMED** BY COLLOIDAL PRECIPITATION ON DIFFERENT CON	129	301
MAS	CHEMICAL PROPERTIES OF POLYMER FILMS	**FORMED** DURING THE ETCHING OF ALUMINUM IN CCL4 PLAS	129	2530
TION	AN ELLIPSOMETRIC INVESTIGATION OF PASSIVE FILMS	**FORMED** ON FE-25NI-XCR ALLOYS IN BORATE BUFFER SOLU	129	2419
OSPHATE SOLUTIONS	ON THE NATURE OF SURFACE FILMS	**FORMED** ON IRON IN AGGRESSIVE AND INHIBITING POLYPH	129	1186
RFACE	ELECTROCHEMICAL TRANSFER VIA SURFACE STATES: A NEW	**FORMULATION** FOR THE SEMICONDUCTOR/ELECTROLYTE INTE	129	963
NTS OF ARSENIC AND BORON IMPLANTS IN SILICON DETERMINED BY A		**FOUR-PHASE** COMPLEX REFRACTIVE INDEX MODEL OPTICAL	129	606
ECTRODES	ALUMINA "FIBER	**FP"** REINFORCED PURE LEAD COMPOSITES FOR BATTERY EL	129	1749
LD STEEL IN HOT NAOH/NA2S SOLUTIONS	A	**FRACTURE** MECHANICS STUDY OF CAUSTIC CRACKING OF MI	129	2669
TRUCTURE WITH VERY THIN	MATHEMATICAL MODELING OF THE LOW	**FREQUENCY** CAPACITANCE CHARACTERISTICS OF THE MOS S	129	2547
HE PREPARATION OF TIO2 ELECTRODES WITH MINIMUM MOTT-SCHOTTKY		**FREQUENCY** DISPERSION T	129	2003
E EFFECT OF THICKNESS ON THE PERFORMANCE OF MOLTEN CARBONATE		**FUEL** CELL CATHODES TH	129	2711
	ALTERNATE MATRIX MATERIAL FOR MOLTEN CARBONATE	**FUEL** CELL ELECTROLYTE STRUCTURES	129	979
	DESIGN OF A CELL FOR ELECTRODE KINETIC INVESTIGATIONS OF	**FUEL** CELL REACTIONS	129	135
	THE SPECIFIC CONDUCTANCE OF MOLTEN CARBONATE	**FUEL** CELL TILES	129	1745
ERMODYNAMICS OF ELECTROLYTE DISTRIBUTION IN MOLTEN CARBONATE		**FUEL** CELLS THE TH	129	942
	IMPURITY DEPOSITS IN GAS TURBINES FROM	**FUELS** CONTAINING SODIUM AND VANADIUM	129	649
	HYDROGEN ANNEAL EFFECTS ON METAL-SEMICONDUCTOR WORK	**FUNCTION** DIFFERENCE	129	806
ATION OF CARRIER CONCENTRATION IN POLYCRYSTALLINE FILMS AS A		**FUNCTION** OF SURFACE ACCEPTOR STATE DENSITY: APPLIC	129	1382
THE PASSIVE FILM ON IRON III. THE CHEMI-CONDUCTOR MODEL AND		**FURTHER** SUPPORTING EVIDENCE THE NATURE OF	129	921
TION OF THE FIRST ELECTROLYTIC PLUTONIUM AND OF URANIUM FROM		**FUSED** CHLORIDES PREPARA	129	2438

		Vol	Page
URES	CHARACTERIZATION OF **FUSED** GLASS PASSIVATION WITH SELECTED DIODE STRUCT	129	154
	SOLUBILITIES OF OXYGEN IN **FUSED** LI2CO3-K2CO3	129	1668
	THE EFFECT OF SULFUR ON THE ANODIC H2(NI) ELECTRODE IN **FUSED** LI2CO3-K2CO3 AT 650DEGREE C	129	1441
	— G —		
	DOPING OF **GA(1-X)AL(X)AS** GROWN BY LPE WITH SI AND GE	129	1563
	THE ROLE OF BE IN **(GAAL)AS/GAAS** SOLAR CELLS	129	1623
	AN OPEN-TUBE METHOD FOR DIFFUSION OF ZINC INTO **GAAS**	129	1567
	ELLIPSOMETRIC THICKNESS MEAS[illegible]EMENTS OF PMMA ON **GAAS**	129	2273
	EFFECT OF MELT STOICHIOMETRY ON [illegible] FORMATION IN LEC **GAAS**	129	2382
	STUDY OF ENCAPSULANTS FOR [illegible]EALING SI-IMPLANTED **GAAS**	129	837
OPOSED HYDROGENATION/NITRIDIZATION PASSIVATION MECHANISM FOR	**GAAS** AND OTHER III-V SEMICONDUCTOR DEVICES, INCLUD	129	821
	SELECTIVE EPITAXIAL GROWTH OF **GAAS** BY LIQUID PHASE ELECTROEPITAXY	129	194
	TEMPERATURE DEPENDENCE OF INP AND **GAAS** ETCHING IN A CHLORINE PLASMA	129	2533
IMENSIONAL PHOTOLUMINESCENCE DISTRIBUTION IN SEMI-INSULATING	**GAAS** GROWN BY CZ AND HB METHODS ONE-D	129	880
MIC STUDY	GE INCORPORATION IN **GAAS** GROWN BY MOLECULAR BEAM EPITAXY: A THERMODYNA	129	2108
	GALVANOSTATIC ANODIZATION OF **GAAS** IN METHANOLIC KOH	129	1016
	SCHOTTKY CONTACT FABRICATION FOR **GAAS** MESFET'S	129	1795
	SPUTTER ETCHING EFFECTS ON **GAAS** SCHOTTKY JUNCTIONS	129	2760
	AUGER ELECTRON SPECTROSCOPY STUDY OF **GAAS** SUBSTRATE CLEANING PROCEDURES	129	406
TIALLY RESOLVED CATHODOLUMINESCENCE STUDY OF SEMI-INSULATING	**GAAS** SUBSTRATES SPA	129	2386
	INTERFACE COMPOSITION STUDIES OF THERMALLY OXIDIZED **GAAS** USING AUGER DEPTH PROFILING	129	851
CHARACTERISTICS OF PEROXIDE/AMMONIUM-HYDROXIDE SOLUTIONS FOR	**GAAS/ALO.16GAO.84AS** SELECTIVE ETCHING	129	2380
RANSIENT SPECTROSCOPY OF SILVER AND GOLD LEVELS IN LEC GROWN	**GALLIUM** ARSENIDE DEEP LEVEL T	129	1353
H	**GALVANOSTATIC** ANODIZATION OF GAAS IN METHANOLIC KO	129	1016
PRESSION F IMAGE ANALYSIS OF MORPHOLOGICAL INSTABILITY IN	**GALVANOSTATIC** ELECTROCRYSTALLIZATION I. GENERAL EX	129	2442
TAL DEMONS IMAGE ANALYSIS OF MORPHOLOGICAL INSTABILITY IN	**GALVANOSTATIC** ELECTROCRYSTALLIZATION II. EXPERIMEN	129	2447
ATION OF PARAMETERS THE	**GALVANOSTATIC** METHOD: ANALYSIS OF ERROR AND COMPUT	129	1473
NSTANT VARIATION IN VALVE-METAL OXIDES A	**GALVANOSTATIC** TECHNIQUE FOR STUDYING DIELECTRIC CO	129	2038
SISTS DETAILED CONTRAST	**(GAMMA-VALUE)** MEASUREMENTS OF POSITIVE ELECTRON RE	129	2576
THE PHOTOELECTROCHEMICAL KINETICS OF P-TYPE	**GAP**	129	2254
PHOTOELECTROCHEMICAL MEASUREMENTS OF H- AND HE-IMPLANTED	**GAP**	129	2735
ION OF HETEROGENEOUS ELECTRON TRANSFER KINETIC THE COLIN	**GARFIELD** FINK SUMMER FELLOWSHIP REPORT--DETERMINAT	129	298C
LE MEMORY DEVICES PROPERTIES OF	**GARNET** MATERIALS FOR CONTIGUOUS DISK MAGNETIC BUBB	129	423
N THE THERMOLUMINESCENCE AND PHOSPHORESCENCE OF TB-ACTIVATED	**GARNET** PHOSPHORS EFFECT OF V2O3 ADDITION O	129	2638
MICROWAVE PLASMA ETCHING OF SI WITH CF4 AND SF6	**GAS**	129	2764
RESISTANCE OF A PLANAR ARRAY OF SPHERES:	**GAS** BUBBLES ON AN ELECTRODE	129	2715
OXIDATION OF H2 AT	**GAS** DIFFUSION ELECTRODES IN H2SO4 AND HBR	129	2464
CELLS OBSERVED BY INTERFERENCE HOLOGRAPHY	**GAS** FLOW PATTERNS IN HORIZONTAL EPITAXIAL REACTOR	129	634
IS OF CHEMICAL VAPOR DEPOSITION OF ALUMINA FROM ALCL3-H2-CO2	**GAS** PHASE MIXTURES THERMODYNAMIC AND EXPERIMENTAL	129	1367
CTION OF SURFACE ACCEPTOR STATE DENSITY: APPLICATION FOR ZNO	**GAS** SENSORS CALCULATION OF CARRIER CONCENTRATION I	129	1382
DIUM IMPURITY DEPOSITS IN	**GAS** TURBINES FROM FUELS CONTAINING SODIUM AND VANA	129	649
HE SENSITIVITIES OF METAL-TIO2 JUNCTIONS TO VARIOUS REDUCING	**GASES** TEMPERATURE DEPENDENCE OF T	129	444
N THE CORROSION RESISTANCE OF CHROMIA-FORMING ALLOYS IN COAL	**GASIFICATION** ATMOSPHERES THE ROLE OF SILICON ADDIT	129	782
N THE CORROSION RESISTANCE OF ALUMINA-FORMING ALLOYS IN COAL	**GASIFICATION** ATMOSPHERES THE ROLE OF CHROMIUM I	129	789
KINETICS OF THE F,F2/B4C	**GASIFICATION** REACTIONS	129	1105
FLAWS IN SIDEWALL OXIDES GROWN ON POLYSILICON	**GATE**	129	1084
PLASMA ETCHING OF COMPOSITE SILICIDE	**GATE** ELECTRODES	129	1330
THE CATION CONCENTRATION RESPONSE OF POLYMER	**GATE** ISFET	129	141
DUAL HCL THIN	**GATE** OXIDATION PROCESS	129	1778
FIELD OXIDATION IDENTIFICATION AND ELIMINATION OF	**GATE** OXIDE DEFECT ORIGIN PRODUCED DURING SELECTIVE	129	800
NITRIDE COATED WAFERS PRIOR TO LOCAL OXIDATION MOS	**GATE** OXIDE DEFECTS RELATED TO TREATMENT OF SILICON	129	1066
NUMERICAL SIMULATION OF	**GATE** OXIDE THINNING IN MOS DEVICES	129	831
ICS IN MOSFET'S DUE TO SUBSTRATE HOT-ELECTRON INJECTION INTO	**GATE** SIO2 INTERFACE TRAPPED CHARGE GENERATION AND	129	1760
GANIC PROCESS FACTORS INFLUENCING THE GROWTH OF	**GAO.47IN0.53AS** ON INP SUBSTRATES USING THE METALOR	129	383
MARTENSITIC TRANSFORMATION OF	**GD**	129	1145
DOPING OF GA(1-X)AL(X)AS GROWN BY LPE WITH SI AND	**GE**	129	1563
PITAXY: A THERMODYNAMIC STUDY	**GE** INCORPORATION IN GAAS GROWN BY MOLECULAR BEAM E	129	2108
ODYNAMICS AND KINETICS OF IODINE CHEMICAL VAPOR TRANSPORT OF	**GEAS** THERM	129	1343
GICAL INSTABILITY IN GALVANOSTATIC ELECTROCRYSTALLIZATION I.	**GENERAL** EXPRESSION FOR THE GROWTH MODE OF SURFACE	129	2442
IN SI	**GENERALIZED** MODEL FOR THE CLUSTERING OF AS DOPANTS	129	1826
IMPURITY GETTERING OF SILICON DAMAGE	**GENERATED** BY ION IMPLANTATION THROUGH SIO2 LAYERS	129	2527
INITIAL OXIDE GROWTH RATE ON NEWLY	**GENERATED** SURFACES	129	2500
T'S DUE TO SUBSTRATE HOT-ELECTRO INTERFACE TRAPPED CHARGE	**GENERATION** AND ELECTRON TRAPPING KINETICS IN MOSFE	129	1760
-SILICON/INDIUM TIN OXIDE ANODES PHOTOELECTROCHEMICAL	**GENERATION** OF CHLORINE ON CATALYTICALLY MODIFIED N	129	1934
THE MEASUREMENT OF LOW LEVELS OF OXYGEN IN	**GERMANIUM** BY THE LITHIUM PRECIPITATION TECHNIQUE	129	226
ONE ATMOSPHERE THE OXIDATION OF	**GERMANIUM** SURFACES AT PRESSURES MUCH GREATER THAN	129	1845
MAL HISTORY DEPENDENCE, AND ENHANCEM A STUDY ON INTRINSIC	**GETTERING** IN CZ SILICON CRYSTALS: EVALUATION, THER	129	374
POST-EPITAXIAL POLYSILICON AND SI3N4	**GETTERING** IN SILICON	129	1294
NTATION THROUGH SIO2 LAYERS IMPURITY	**GETTERING** OF SILICON DAMAGE GENERATED BY ION IMPLA	129	2527
POTENTIOMETRIC DETERMINATION OF THE	**GIBBS** ENERGIES OF FORMATION OF LEAD ALUMINATES	129	1116
IMPEDANCE MEASUREMENTS ON LITHIUM-ELECTROLYZED BOROSILICATE	**GLASS**	129	2617
ST PROCESS SPIN-ON	**GLASS** AS AN INTERMEDIATE LAYER IN A TRI-LAYER RESI	129	2152
WATER ABSORPTION AND DENSIFICATION OF PHOSPHOSILICATE	**GLASS** FILMS	129	1765
LOW PRESSURE DEPOSITION OF PHOSPHOSILICATE	**GLASS** FILMS	129	1588
CHARACTERIZATION OF FUSED	**GLASS** PASSIVATION WITH SELECTED DIODE STRUCTURES	129	154
TERS ON THE ELECTROCHEMICAL CORROSION OF IRON-BORON METALLIC	**GLASSES** EFFECT OF COMPOSITION AND THE PROCESSING P	129	695
CHARACTERIZATION OF NEAR SURFACE COMPOSITION OF BOROSILICATE	**GLASSES** (BSG) BY SECONDARY ION MASS SPECTROMETRY (	129	1819
RBED IRON(111)-TETRA (N,N,N-TRIMETHYLANILINIUM) PORPHYRIN ON	**GLASSY** CARBON ELECTRODES CATALYSIS OF OXYGEN CATHO	129	2247
RODES POTENTIODYNAMIC STUDY OF	**GLUCOSE** ELECTRO-OXIDATION AT BRIGHT PLATINUM ELECT	129	2207
NODIC OXIDATION OF P-TYPE SILICON IN METHANOL AS COMPARED TO	**GLYCOL** A	129	2749
THE EFFECT OF CATHODIC POLARIZATION ON THE CREEP RATE OF	**GOLD**	129	706
THE ANODIC CORROSION OF	**GOLD** IN CONCENTRATED CHLORIDE SOLUTIONS	129	1192
DIFFUSION OF	**GOLD** IN SILICON	129	1579
DEEP LEVEL TRANSIENT SPECTROSCOPY OF SILVER AND	**GOLD** LEVELS IN LEC GROWN GALLIUM ARSENIDE	129	1353
T BEHAVIOR DURING THE UNDERPOTENTIAL DEPOSITION OF SILVER ON	**GOLD** USING THE ROTATING RING-DISK ELECTRODE INTERP	129	1202
IAL SYSTEM METALLURGICAL BEHAVIOR OF	**GOLD-BASED** OHMIC CONTACTS TO THE INP/INGAASP MATER	129	2585
R GRAINS: ROLES BESIDES PHOTOELECTRON-TRAPPING	**GOLD-CONTAINING** SURFACE STATES ON PHOTOGRAPHIC AGB	129	591
AUTOCATALYTIC DEPOSITION OF	**GOLD-COPPER** AALLOYS	129	1917

		Vol	Page
PURIFICATION OF RICE HULLS AS A SOURCE OF SOLAR	**GRADE** SILICON FOR SOLAR CELLS	129	864
OTOANODES HYDROGEN CONCENTRATION	**GRADIENT** AND ASSOCIATED ELECTRIC FIELDS IN TIO2 PH	129	1851
TRANSPORT NUMBER	**GRADIENTS** AND SOLID ELECTROLYTE DEGRADATION	129	752
R THE LICL-KCL ELECTROLYTE OF CURRENT-INDUCED COMPOSITION	**GRADIENTS** IN MOLTEN AGNO3-NANO3: A MODEL SYSTEM FO	129	49
SEM/EDX AND AA MEASUREMENTS OF CURRENT-INDUCED COMPOSITION	**GRADIENTS**. MOLTEN NANO3-AGNO3 IN POROUS YTTRIA	129	931
	GRAIN-GROWTH MECHANISMS IN POLYSILICON	129	1791
GOLD-CONTAINING SURFACE STATES ON PHOTOGRAPHIC AGBR	**GRAINS**: ROLES BESIDES PHOTOELECTRON-TRAPPING	129	591
RAZINE CATALYZED BY SULFONATED PHTHALOCYANINES ADSORBED ON A	**GRAPHITE** ELECTRODE ELECTRO-OXIDATION OF HYD	129	2242
REFILLING SILICON	**GROOVES** BY LIQUID PHASE EPITAXY	129	2819
NGAASP MULTILAYER STRUCTURE A SIMPLE DAMAGE-FREE	**GROOVING** METHOD FOR REVEALING THE QUALITY OF INP/I	129	2082
IONAL PHOTOLUMINESCENCE DISTRIBUTION IN SEMI-INSULATING GAAS	**GROWN** BY CZ AND HB METHODS ONE-DIMENS	129	880
UBSTRATE ORIENTATION DEPENDENCE OF GROWTH RATE OF INGAAS/INP	**GROWN** BY LIQUID PHASE EPITAXY S	129	2603
DOPING OF GA(1-X)AL(X)AS	**GROWN** BY LPE WITH SI AND GE	129	1563
OF SUBSTRATE TEMPERATURE ON THE MORPHOLOGY OF AL(X)GA(1-X)AS	**GROWN** BY MOLECULAR BEAM EPITAXY INFLUENCE	129	824
TUDY GE INCORPORATION IN GAAS	**GROWN** BY MOLECULAR BEAM EPITAXY: A THERMODYNAMIC S	129	2108
THE USE OF S2CL2 FOR DOPING POLY-GAAS FILMS	**GROWN** BY THE ORGANOMETALLIC PROCESS	129	2778
STRUCTURAL AND OPTICAL PROPERTIES OF SOLUTION	**GROWN** CDSE(1-X)S(X) FILMS	129	99
EVEL TRANSIENT SPECTROSCOPY OF SILVER AND GOLD LEVELS IN LEC	**GROWN** GALLIUM ARSENIDE DEEP L	129	1353
URCE IMPROVING THE ELECTRICAL PROPERTIES OF VAPOR	**GROWN** III-V COMPOUNDS BY COOLING THE HCL LIQUID SO	129	2566
ELECTRON TRAPS IN SIO2	**GROWN** IN PRESENCE OF TRICHLOROETHYLENE	129	2772
FLAWS IN SIDEWALL OXIDES	**GROWN** ON POLYSILICON GATE	129	1084
IN SITU MONITORING OF LIQUID PHASE ELECTROEPITAXIAL	**GROWTH**	129	2095
TROCRYSTALLIZATION II. EXPERIMENTAL DEMONSTRATION OF CRYSTAL	**GROWTH** BEHAVIOR IMAGE ANALYSIS OF MORPHOLOGICAL IN	129	2447
LA SINGLE CRYSTAL SILICON FILMS ON AMORPHOUS INSULATORS:	**GROWTH** BY LATERAL NUCLEATED EPITAXY USING SCANNING	129	2802
DYNAMIC OXYGEN EQUILIBRIUM IN SILICON MELTS DURING CRYSTAL	**GROWTH** BY THE CZOCHRALSKI TECHNIQUE	129	189
PHOSPHORUS INCORPORATION DURING SILICON EPITAXIAL	**GROWTH** IN A CVD REACTOR	129	1122
	GROWTH KINETICS OF SILICON THERMAL NITRIDATION	129	1559
G OF THE GROWTH OF ANODIC OXIDE FILMS ON ZIRCONIUM II. OXIDE	**GROWTH** MECHANISM A STUDY BY NUCLEAR MICROANALYSIS	129	1905
OSTATIC ELECTROCRYSTALLIZATION I. GENERAL EXPRESSION FOR THE	**GROWTH** MODE OF SURFACE IRREGULARITIES IMAGE ANALYS	129	2442
E A STUDY BY NUCLEAR MICROANALYSIS AND 18O TRACING OF THE	**GROWTH** OF ANODIC OXIDE FILMS ON ZIRCONIUM I. INFLU	129	1895
E A STUDY BY NUCLEAR MICROANALYSIS AND 18O TRACING OF THE	**GROWTH** OF ANODIC OXIDE FILMS ON ZIRCONIUM II. OXID	129	1905
E FILMS COMPOSITION, KINETICS, AND MECHANISM OF	**GROWTH** OF CHEMICAL VAPOR-DEPOSITED ALUMINUM NITRID	129	1045
THE PHASE RELATIONS IN THE CU,IN,S SYSTEM AND THE	**GROWTH** OF CUINS2 CRYSTALS FROM THE MELT	129	1570
SELECTIVE EPITAXIAL	**GROWTH** OF GAAS BY LIQUID PHASE ELECTROEPITAXY	129	194
HE METALORGANIC PROCESS FACTORS INFLUENCING THE	**GROWTH** OF GA0.47IN0.53AS ON INP SUBSTRATES USING T	129	383
OPTIMIZATION OF ISOTHERMAL	**GROWTH** OF HGCDTE LAYERS	129	1103
E ISOTHERMAL	**GROWTH** OF HGCDTE UNDER CONTROLLED HG VAPOR PRESSUR	129	2855
VAPOR PHASE EPITAXIAL	**GROWTH** OF MGO.AL2O3	129	2569
OVALENT IMPURITIES ON DILUTE ALLOYS PARABOLIC	**GROWTH** OF NONUNIFORMLY DOPED OXIDES CONTAINING ALI	129	622
F OXYGEN WITH SI(111) AND (100): CRITICAL CONDITIONS FOR THE	**GROWTH** OF SIO2 REACTION O	129	1300
COMPUTER SIMULATION OF THE DIFFUSIONAL	**GROWTH** OF TERNARY OXIDE SCALES ON BINARY ALLOYS	129	209
ES DURING ELECTRODEPOSITION MAGNETIC FIELD EFFECTS ON THE	**GROWTH** OF THE DIFFUSION LAYER AT VERTICAL ELECTROD	129	1266
EPI-LAYERS THE INFLUENCE OF INTERMITTENT	**GROWTH** PROCEDURES ON DISLOCATION DENSITIES IN INP	129	1556
ITAXY SUBSTRATE ORIENTATION DEPENDENCE OF	**GROWTH** RATE OF INGAAS/INP GROWN BY LIQUID PHASE EP	129	2603
INITIAL OXIDE	**GROWTH** RATE ON NEWLY GENERATED SURFACES	129	2500
MAGNESIUM-DOPED P(+)-N INGAASP/INP HETEROJUNCTIONS LPE	**GROWTH** TECHNIQUES FOR FABRICATING ABRUPT ZINC- AND	129	2085
P-DOPED POLYSILICON FILM	**GROWTH** TECHNOLOGY	129	2620
DEFECT CONTROL DURING SILICON EPITAXIAL	**GROWTH** USING DICHLOROSILANE	129	1078
URE-GAAS PROPERT BRIDGMAN-TYPE APPARATUS FOR THE STUDY OF	**GROWTH-PROPERTY** RELATIONSHIPS: ARSENIC VAPOR PRESS	129	388

— H —

PHOTOELECTROCHEMICAL MEASUREMENTS OF	**H-** AND HE-IMPLANTED GAP	129	2735
SIMS AND AES ANALYSIS OF	**H:TIO2** ELECTRODES	129	94
ELECTROCHEMICAL OXIDATION OF POLYHEDRAL BORON	**HALIDE** ANIONS	129	1249
COMPLEXING OF AL(+3) BY S(-2) IONS IN ALKALI	**HALIDE** MELTS	129	2034
OUS AND NONAQUEOUS ELECTROLYTE SOLUTIONS. PHOTO-OXIDATION OF	**HALIDES** WITH HIGH EFFICIENCY CHARACTERIZATION OF N	129	1461
N-MOSE2 PHOTOELECTROCHEMICAL	**HALOGEN** STORAGE CELL	129	233
DEEP U.V.	**HARDENING** OF POSITIVE PHOTORESIST PATTERNS	129	1379
OPTIMIZATION OF ELECTROLYTIC CELLS	**HAVING** LARGE NUMBERS OF VARIABLES	129	1225
	HAZARD POTENTIAL OF DICHLOROSILANE	129	2346
CELL REVERSAL SPECTROSCOPIC STUDIES OF THE	**HAZARDS** OF LI/SOCL2 BATTERIES DURING ANODE-LIMITED	129	2496
ESCENCE DISTRIBUTION IN SEMI-INSULATING GAAS GROWN BY CZ AND	**HB** METHODS ONE-DIMENSIONAL PHOTOLUMIN	129	880
OXIDATION OF H2 AT GAS DIFFUSION ELECTRODES IN H2SO4 AND	**HBR**	129	2464
RTIONATION REACTION OF ALKYLBENZENES IN ALUMINUM BROMIDE AND	**HBR** (ELECTROLYTE USED FOR THE ELECTRODEPOSITION OF	129	40
SPONTANEOUS PHOTOELECTROLYSIS OF	**HBR** AND HL	129	1701
FABRICATION USE OF	**HBR-CH3COOH-K2CR2O7** ETCHANT TO ETCHED-MIRROR LASER	129	1524
CAL PROPERTIES OF VAPOR GROWN III-V COMPOUNDS BY COOLING THE	**HCL** LIQUID SOURCE IMPROVING THE ELECTRI	129	2566
DUAL	**HCL** THIN GATE OXIDATION PROCESS	129	1778
PHOTOELECTROCHEMICAL MEASUREMENTS OF H- AND	**HE-IMPLANTED** GAP	129	2735
PLATINUM AN ESTIMATE OF THE	**HEAT** OF ADSORPTION OF THE HYDROPEROXYL RADICAL ON	129	1438
DEPOSITION TECHNIQUES AND	**HEAT** TRANSFER PROPERTIES OF POROUS ALUMINUM	129	1029
METAL DECORATED DEFECTS IN	**HEAT-TREATED** SILICON WAFERS	129	1128
YCRYSTALLINE SILICON	**HEAT-TREATMENT** EFFECT ON BORON IMPLANTATION IN POL	129	1604
NTERACTIONS IN SILICON	**HEAT-TREATMENT** STUDIES OF OXYGEN-DEFECT-IMPURITY I	129	2127
F THERMALLY AND LASER ANNEALED POLYCRYSTALLINE SILICON FILMS	**HEAVILY** DOPED WITH ARSENIC AND PHOSPHORUS ELECTRIC	129	1811
DIFFUSION IN SILICON FROM A SPIN-ON	**HEAVILY** PHOSPHORUS-DOPED OXIDE SOURCE	129	2299
LINE SILICON THERMAL OXIDATION OF	**HEAVILY** PHOSPHORUS-DOPED THIN FILMS OF POLYCRYSTAL	129	2321
OPTICAL CHARACTERISTICS OF WO3 ELECTROCHROMIC CELLS UNDER	**HEAVY** LI ION INJECTION	129	2633
THE CONSTANT	**HELPER**: STEADFASTNESS AS A KEY INGREDIENT OF R&D	129	393C
OTOVOLTAGE MEASUREMENTS MICROSCALE CHARACTERIZATION OF	**HETEROEPITAXIAL** SILICON ON SAPPHIRE BY SCANNING PH	129	2609
ED REACTOR	**HETEROGENEOUS** DECOMPOSITION OF SILANE IN A FIXED B	129	1531
LIN GARFIELD FINK SUMMER FELLOWSHIP REPORT--DETERMINATION OF	**HETEROGENEOUS** ELECTRON TRANSFER KINETIC PARAMETERS	129	298C
PHOTOELECTROLYSIS AT FE2O3/TIO2	**HETEROJUNCTION** ELECTRODE	129	342
RICATING ABRUPT ZINC- AND MAGNESIUM-DOPED P(+)-N INGAASP/INP	**HETEROJUNCTIONS** LPE GROWTH TECHNIQUES FOR FAB	129	2085
SPECULAR LITHIUM DEPOSITS FROM LITHIUM	**HEXAFLUOROARSENATE/DIETHYL** ETHER ELECTROLYTES	129	1
HE SUPER ACID "CA THE ELECTROCHEMISTRY OF HYDROCARBONS IN	**HF/SBF5**: SOME MECHANISTIC CONCLUSIONS CONCERNING T	129	1950
ISOTHERMAL GROWTH OF HGCDTE UNDER CONTROLLED	**HG** VAPOR PRESSURE	129	2855
ON OF THE REGULAR ASSOCIATED SOLUTION MODEL TO THE CD-TE AND	**HG-TE** BINARY SYSTEMS APPLICATI	129	2360
THE EFFECT OF PROCESSING PARAMETERS ON THE LIFETIME OF	**(HG,CD)TE** MATERIAL	129	656

		Vol	Page
OPTIMIZATION OF ISOTHERMAL GROWTH OF	**HGCDTE** LAYERS	129	1103
ISOTHERMAL GROWTH OF	**HGCDTE** UNDER CONTROLLED HG VAPOR PRESSURE	129	2855
ANODIC OXIDE FILMS AND ELECTROCHEMICAL REACTIONS ON	**HGTE**	129	739
RCULAR JETS	**HIGH-SPEED** SELECTIVE ELECTROPLATING WITH SINGLE CI	129	2424
UREMENTS IN ALLOY 600 CREVICES AT 28 CREVICE CORROSION IN	**HIGH-TEMPERATURE** AQUEOUS SYSTEMS POTENTIAL/PH MEAS	129	2458
RINSIC GETTERING IN CZ SILICON CRYSTALS: EVALUATION, THERMAL	**HISTORY** DEPENDENCE, AND ENHANCEMENT A STUDY ON INT	129	374
SPONTANEOUS PHOTOELECTROLYSIS OF HBR AND	**HL**	129	1701
ESCENCE AN EXPERIMENTAL STUDY OF MOTION OF ELECTRONS AND	**HOLES** IN Y2O2S CRYSTAL AS REVEALED BY CATHODOLUMIN	129	1535
HORIZONTAL EPITAXIAL REACTOR CELLS OBSERVED BY INTERFERENCE	**HOLOGRAPHY** GAS FLOW PATTERNS IN	129	634
ERFERENCE HOLOGRAPHY GAS FLOW PATTERNS IN	**HORIZONTAL** EPITAXIAL REACTOR CELLS OBSERVED BY INT	129	634
E IN (Y, IN)2O3	**HOST** SENSITIZATION MECHANISM OF EU(3+) LUMINESCENC	129	2069
IN NICKEL-SODIUM MIXED SULFATE FORMATION AND LOW TEMPERATURE	**HOT** CORROSION REACTIONS OF SO2(SO3) WITH NIO-NA2SO	129	1613
CHEMICAL REACTIONS INVOLVED IN THE INITIATION OF	**HOT** CORROSION OF B-1900 AND NASA-TRW VIA	129	571
RACTURE MECHANICS STUDY OF CAUSTIC CRACKING OF MILD STEEL IN	**HOT** NAOH/NA2S SOLUTIONS A F	129	2669
AND ELECTRON TRAPPING KINETICS IN MOSFET'S DUE TO SUBSTRATE	**HOT-ELECTRON** INJECTION INTO GATE SIO2 INTERFACE TR	129	1760
CELLS PURIFICATION OF RICE	**HULLS** AS A SOURCE OF SOLAR GRADE SILICON FOR SOLAR	129	864
NG AND NONFLUORESCING DYES VISUAL DETECTION OF	**HYDRATED** ALUMINUM OXIDE BY STAINING WITH FLUORESCI	129	1517
ADSORBED ON A GRAPHITE ELECTRODE ELECTRO-OXIDATION OF	**HYDRAZINE** CATALYZED BY SULFONATED PHTHALOCYANINES	129	2242
USIONS CONCERNING THE SUPER ACID "CATALYZED" CONDENSATION OF	**HYDROCARBONS** THE ELECTROCHEMISTRY OF HYDROCARBONS	129	1950
S/ROOM TEMPERA PHOTOELECTROCHEMICAL OXIDATION OF AROMATIC	**HYDROCARBONS** AND DECAMETHYL FERROCENE AT THE N-GAA	129	560
ONS CONCERNING THE SUPER ACID "CA THE ELECTROCHEMISTRY OF	**HYDROCARBONS** IN HF/SBF5: SOME MECHANISTIC CONCLUSI	129	1950
OF PASSIVATION OF LEAD SULFIDE DURING ANODIC DISSOLUTION IN	**HYDROCHLORIC** ACID THE NATURE	129	271
YDROGEN CHARGING OF SN AND CD COATINGS ON IRON	**HYDROGEN** ABSORPTION DURING ELECTRODEPOSITION AND H	129	284
K FUNCTION DIFFERENCE	**HYDROGEN** ANNEAL EFFECTS ON METAL-SEMICONDUCTOR WOR	129	806
HYDROGEN ABSORPTION DURING ELECTRODEPOSITION AND	**HYDROGEN** CHARGING OF SN AND CD COATINGS ON IRON	129	284
CTRIC FIELDS IN TIO2 PHOTOANODES	**HYDROGEN** CONCENTRATION GRADIENT AND ASSOCIATED ELE	129	1851
LEAD DEFICIENCY AND	**HYDROGEN** CONTENT IN BATTERY ELECTRODE BETA-PBO2	129	1678
THE ROLE OF H2S IN THE CORROSION AND	**HYDROGEN** EMBRITTLEMENT OF STEEL	129	468
EL CATHODES IN CONCENTRATED SODIUM HYDROX KINETICS OF THE	**HYDROGEN** EVOLUTION REACTION ON MILD STEEL AND NICK	129	2481
PLASMA ETCHING OF SILICON AND SILICON DIOXIDE WITH	**HYDROGEN** FLUORIDE MIXTURES	129	1770
ELECTROCHEMICAL INSERTION OF	**HYDROGEN** IN WO3	129	2276
L PROPERTIES OF SPUTTERED TIO2 FILMS EFFECT OF	**HYDROGEN** ON THE DIELECTRIC AND PHOTOELECTROCHEMICA	129	2022
ENDRECHT, AND VISSCHER METHOD TO EVALUATE RATE CONSTANTS FOR	**HYDROGEN** PEROXIDE DECOMPOSITION AT ROTATING DISK E	129	2268
Y TO PRACTICE THERMOCHEMICAL PROCESSES FOR	**HYDROGEN** PRODUCTION BY WATER SPLITTING: FROM THEOR	129	67
	HYDROGEN-IMPLANTED SILICON NITRIDE	129	1786
L MATERIAL	**HYDROGENATED** A-SI(X)GE(1-X): A POTENTIAL SOLAR CEL	129	2850
INATION OF POSITIVE MOBILE ION DENSITY IN SILICON DIOXIDE BY	**HYDROGENATED** AMORPHOUS SILICON FIELD EFFECT TECHNI	129	2770
FOR GAAS AND OTHER III-V SEMICONDUCTOR DEVICES A PROPOSED	**HYDROGENATION/NITRIDIZATION** PASSIVATION MECHANISM	129	821
AN ESTIMATE OF THE HEAT OF ADSORPTION OF THE	**HYDROPEROXYL** RADICAL ON PLATINUM	129	1438
CVD	**HYDROPHOBIC** LEAD SILICATE FILMS	129	165
ELECTROCHEMICALLY COPRECIPITATED COBALT HYDROXIDE IN NICKEL	**HYDROXIDE** ELECTRODES THE MECHANICS OF	129	118
FERENT CONDUCTING THE ELECTROCHEMICAL RESPONSE OF NICKEL	**HYDROXIDE** FORMED BY COLLOIDAL PRECIPITATION ON DIF	129	301
THE MECHANICS OF ELECTROCHEMICALLY COPRECIPITATED COBALT	**HYDROXIDE** IN NICKEL HYDROXIDE ELECTRODES	129	118
ION ON MILD STEEL AND NICKEL CATHODES IN CONCENTRATED SODIUM	**HYDROXIDE** SOLUTIONS KINETICS OF THE HYDROGEN EVOLU	129	2481
R-ALKALI CE THE ANOLYTE DIFFUSION LAYER AND ITS EFFECT ON	**HYDROXYL** TRANSPORT THROUGH NAFION MEMBRANE IN CHLO	129	722
RAMETER AND REACTOR DEPENDENCE OF SELECTIVE OXIDE RIE IN CF4 + H2	PA	129	2282
METER AND REACTOR DEPENDENCE OF SELECTIVE OXIDE RIE IN CF4 + **H2**	PARA	129	2282
OXIDATION OF	**H2** AT GAS DIFFUSION ELECTRODES IN H2SO4 AND HBR	129	2464
E C THE EFFECT OF SULFUR ON THE ANODIC	**H2(NI)** ELECTRODE IN FUSED LI2CO3-K2CO3 AT 650DEGRE	129	1441
STEEL THE ROLE OF	**H2S** IN THE CORROSION AND HYDROGEN EMBRITTLEMENT OF	129	468
ECTROCHEMICAL PRODUCTION OF MANGANIC SULFATE IN CONCENTRATED	**H2SO4** EL	129	749
OXIDATION OF H2 AT GAS DIFFUSION ELECTRODES IN	**H2SO4** AND HBR	129	2464

— I —

THE NATURE OF THE PASSIVE FILM ON IRON	**I.** AUTOMATIC ELLIPSOMETRIC SPECTROSCOPY STUDIES	129	17
RFLUORINATED CARBOXYLATE AND SULFONATE ION EXCHANGE POLYMERS	**I.** DIFFUSION AND WATER SORPTION A COMPARISON OF PE	129	324
INITIATION OF CREVICE CORROSION	**I.** EXPERIMENTAL INNVESTIGATIONS ALUMINUM AND IRON	129	481
U, AL CATHODOLUMINESCENT PHOSPHORS AT HIGH CURRENT DENSITIES	**I.** EXPERIMENTAL PHENOMENA SATURATION OF (ZN, CD)S:	129	1546
A MECHANISTIC STUDY OF OXYGEN EVOLUTION ON NICO2O4	**I.** FORMATION OF HIGHER OXIDES	129	1724
OLOGICAL INSTABILITY IN GALVANOSTATIC ELECTROCRYSTALLIZATION	**I.** GENERAL EXPRESSION FOR THE GROWTH MODE OF SURFA	129	2442
18O TRACING OF THE GROWTH OF ANODIC OXIDE FILMS ON ZIRCONIUM	**I.** INFLUENCE OF FORMATION CONDITIONS ON E-I RELATI	129	1895
S	**I.** INTERACTION OF AL FILMS WITH O2 AT LOW PRESSURE	129	2366
MATHEMATICAL MODEL FOR DESIGN OF BATTERY ELECTRODES	**I.** POTENTIAL DISTRIBUTION	129	688
ELECTROHYDRODYNAMICAL IMPEDANCE ON A ROTATING DISK ELECTRODE	**I.** REDOX SYSTEM	129	107
N ENERGY-EFFICIENT INSOLUBLE ANODE FOR NICKEL ELECTROWINNING	**I.** SINGLE LAYER PRECIOUS METAL COATINGS THE DEVELO	129	515
TATIING D ZINC ELECTRODE MORPHOLOGY IN ALKALINE SOLUTIONS	**I.** STUDY OF ALTERNATING VOLTAGE MODULATION ON A RO	129	2677
DEGREE C PROPERTIES OF PLASMA-ENHANCED CVD SILICON FILMS	**I.** UNDOPED FILMS DEPOSITED FROM 525 DEGREE TO 725	129	2326
PROCESS FOR HIGH PHOTOCURRENT IN	**IBC** SOLAR CELLS	129	2624
MINIMUM SILICON WAFER THICKNESS FOR	**ID** WAFERING	129	2835
T ORIGIN PRODUCED DURING SELECTIVE FIELD OXIDATION	**IDENTIFICATION** AND ELIMINATION OF GATE OXIDE DEFEC	129	800
CONDUCTANCE STUDIES IN THIONYL CHLORIDE:	**II**	129	1165
THE NATURE OF THE PASSIVE FILM ON IRON	**II.** A-C IMPEDANCE STUDIES	129	474
SOLUTION REDOOX COUPLES FOR EELECTROCHEMICAL ENERGY STORAGE	**II.** COBALT(III)-COBALT(II) COMPLEXES WITH O-PHENAN	129	61
OLOGICAL INSTABILITY IN GALVANOSTATIC ELECTROCRYSTALLIZATION	**II.** EXPERIMENTAL DEMONSTRATION OF CRYSTAL GROWTH B	129	2447
PROPERTIES OF PLASMA-ENHANCED CVD SILICON FILMS	**II.** FILMS DOPED DURING DEPOSITION	129	2331
RIDE SOLUTIONS INITIATION OF CREVICE CORROSION	**II.** MATHEMATICAL MODEL FOR ALUMINUM IN SODIUM CHLO	129	488
N ENERGY-EFFICIENT INSOLUBLE ANODE FOR NICKEL ELECTROWINNING	**II.** MULTILAYER PRECIOUS METAL COATINGS THE DEVELOP	129	522
	II. OXIDATION OF AL FILMS	129	2369
18O TRACING OF THE GROWTH OF ANODIC OXIDE FILMS ON ZIRCONIUM	**II.** OXIDE GROWTH MECHANISM A STUDY BY NUCLEAR MICR	129	1905
RFLUORINATED CARBOXYLATE AND SULFONATE ION EXCHANGE POLYMERS	**II.** SORPTION AND TRANSPORT PROPERTIES IN CONCENTRA	129	328
(BATHOPHENANTHROLINE DISULFON POLYMER-MODIFIED ELECTRODES	**II.** SPECTROELECTROCHEMICAL PROPERTIES OF A LIGAND	129	762
THE CHEMICAL NATURE OF ALUMINUM CORROSION	**II.** THE INITIAL DISSOLUTION STEP	129	27
TERNARY CHALCOGENIDE-BASED PHOTOELECTROCHEMICAL CELLS	**II.** THE N-CDIN2SE4/AQUEOUS POLYSULFIDE SYSTEM	129	1506
A POINT DEFECT MODEL FOR ANODIC PASSIVE FILMS	**III.** IMPEDANCE RESPONSE	129	1874
OF THIN OXIDE FILMS AT PLATINUM ANODES IN ALKALINE SOLUTIONS	**III.** PH DEPENDENCE FORMATION	129	55
LITHIUM CLOSOBORANE ELECTROLYTES	**III.** PREPARATION AND CHARACTERIZATION	129	2213
ING EVIDENCE THE NATURE OF THE PASSIVE FILM ON IRON	**III.** THE CHEMI-CONDUCTOR MODEL AND FURTHER SUPPORT	129	921
E C REACTIONS OF FORMATION AND STABILITY OF IRON(II) AND	**(III)** OXIDES IN LICL-KCL EUTECTIC MELT AT 470DEGRE	129	1450
IMPROVING THE ELECTRICAL PROPERTIES OF VAPOR GROWN	**III-V** COMPOUNDS BY COOLING THE HCL LIQUID SOURCE	129	2566

	Vol	Page
BINATION AND TRAPPING ON THE CATHODIC PHOTOCURRENT AT P-TYPE	129	730
ATION/NITRIDIZATION PASSIVATION MECHANISM FOR GAAS AND OTHER	129	821
CCL4 AND CL2 PLASMA ETCHING OF	129	1599
RECOMBINATION EFFECTS ON CURRENT-VOLTAGE CHARACTERISTICS OF	129	1134
VANOSTATIC ELECTROCRYSTALLIZATION II. EXPERIMENTAL DEMONSTRA	129	2447
VANOSTATIC ELECTROCRYSTALLIZATION I. GENERAL EXPRESSION FOR	129	2442
AMINO ACID SYNTHESIS ELECTROCHEMICAL BEHAVIOR OF SELECTED	129	1231
ACTIVATION OF RUO2 AND PTO ELECTRODE SURFACES FOR	129	756
E CLEANING	129	1027
A SURVEY OF IRON CONTAMINATION IN SILICON SUBSTRATES AND ITS	129	2573
S AT A SEMICONDUCTOR/ELECTROLYTE INTERFACE BY LAPLACE DOMAIN	129	2147
DMIUM CELLS	129	289
KINETICS AT LIVING CELL MEMBRANES A TRANSIENT	129	526
OSILICATE GLASS	129	2617
STEM ELECTROHYDRODYNAMICAL	129	107
A POINT DEFECT MODEL FOR ANODIC PASSIVE FILMS III.	129	1874
UNTERELECTRODE CELLS EQUIVALENT CIRCUIT ANALYSIS OF THE	129	551
THE NATURE OF THE PASSIVE FILM ON IRON II. A-C	129	474
Y OF AGF-LAF3 REVERSIBLE INTERFACE BY AUGER SPECTROSCOPY AND	129	660
CTROCHEMICAL POLYMERIZATION OF O-PHENYLENEDIAMINE AT SURFACE	129	265
SINGLE CRYSTAL Y3AL5O12:TB PHOSPHOR PRODUCED BY ION	129	816
HEAT-TREATMENT EFFECT ON BORON	129	1604
URE FORMATION OF SI-NITRIDE FILMS BY LOW ENERGY NITROGEN ION	129	379
N, OXIDATION RESISTANCE, AND ELECTRIC LOW ENERGY NITROGEN	129	408
IMPURITY GETTERING OF SILICON DAMAGE GENERATED BY ION	129	2527
DIFFUSION AND SEGREGATION OF LOW-DOSE	129	1097
SIMS STUDIES OF 9BE	129	1312
PLEX REFRACTIVE IN OPTICAL CONSTANTS OF ARSENIC AND BORON	129	606
TITANIUM DIOXIDE FILMS TO	129	2389
ESIST BY ION EXPOSURE PROCESS	129	2556
ELECTROCHEMICAL POLYMERIZA SEMICONDUCTOR ELECTRODES XLI.	129	265
III-V COMPOUNDS BY COOLING THE HCL LIQUID SOURCE	129	2566
IC GROWTH OF NONUNIFORMLY DOPED OXIDES CONTAINING ALIOVALENT	129	622
CONIA ELECTROLYTES THE EFFECT OF ELECTRODE SURFACE	129	345
INING SODIUM AND VANADIUM	129	649
ION IMPLANTATION THROUGH SIO2 LAYERS	129	2527
CHARACTERIZATION OF SEMICONDUCTOR ELECTRODES WITH A DEEP	129	2219
ZINC ELECTROCRYSTALLIZATION FROM	129	2695
HOST SENSITIZATION MECHANISM OF EU(3+) LUMINESCENCE IN (Y,	129	2069
S THE	129	1361
ON MECHANISM FOR GAAS AND OTHER III-V SEMICONDUCTOR DEVICES,	129	821
ON ELECTRON MICROSCOPY DIRECT OBSERVATIONS OF	129	201C
A STUDY OF	129	614
CVD REACTOR PHOSPHORUS	129	1122
AXY: A THERMODYNAMIC STUDY GE	129	2108
NTS IN SILICON DETERMINED BY A FOUR-PHASE COMPLEX REFRACTIVE	129	606
STATE-OF-CHARGE	129	2409
DIFFUSIVITY AND THERMODYNAMIC PROPERTIES OF OXYGEN IN LIQUID	129	430
A STUDY OF INCLUSIONS IN	129	614
MODYNAMICS OF SOLID SOLUTIONS IN THE CADMIUM-INDIUM-SULFIDE,	129	1835
LTISTEP REPEATED ANNEALING FOR CZ-SILICON WAFERS: OXYGEN AND	129	2089
STRIATIONS OF KINETIC ORIGIN	129	2355
THE LPCVD POLYSILICON PHOSPHORUS DOPED IN SITU AS AN	129	1109
REPORT ON THE ELECTROLYTIC	129	275C
PUN-ON THIN FILMS COMMONLY ASSOCIATED WITH THE SEMICONDUCTOR	129	173
VENTURES IN ELECTROCHEMICAL	129	397C
FROM WATER-SOLUBLE POLYMERS	129	251
RICHLOROSILANOL IN SILICON TETR PHOTOCHEMICAL PRODUCTION,	129	1619
SEPH W. RICHARDS SUMMER FELLOWSHIP REPORT--FOURIER TRANSFORM	129	300C
HLORIDE:ALUMINUM CHLORIDE IONIC LI AN ELECTROCHEMICAL AND	129	2739
SM FOR GAAS AND OTHER III-V SEMICONDUCTOR DEVICES, INCLUDING	129	821
SUBSTRATE ORIENTATION DEPENDENCE OF GROWTH RATE OF	129	2603
CHEMICAL ETCHING OF INP AND	129	609
CHEMICAL ETCHING OF	129	1053
QUES FOR FABRICATING ABRUPT ZINC- AND MAGNESIUM-DOPED P(+)-N	129	2085
TCHED MIRRORS	129	883
THE CONSTANT HELPER: STEADFASTNESS AS A KEY	129	393C
THE NATURE OF SURFACE FILMS FORMED ON IRON IN AGGRESSIVE AND	129	1186
KINETICS OF ELECTROLESS COPPER PLATING VI.	129	717
THE OXIDATION	129	1803
MOSSBAUER SPECTROSCOPIC STUDY OF THE CORROSION	129	1658
RTIES OF Y-DOPED CEO2 CERAMICS: COMPARISON OF A-C AND D-C ME	129	2113
THE CHEMICAL NATURE OF ALUMINUM CORROSION II. THE	129	27
CES	129	2500
NNVESTIGATIONS ALUMINUM AND IRON	129	481
ODEL FOR ALUMINUM IN SODIUM CHLORIDE SOLUTIONS	129	488
VIA CHEMICAL REACTIONS INVOLVED IN THE	129	571
ARACTERISTICS OF WO3 ELECTROCHROMIC CELLS UNDER HEAVY LI ION	129	2633
TRAPPING KINETICS IN MOSFET'S DUE TO SUBSTRATE HOT-ELECTRON	129	1760
ICAL TEST TO EVALUATE PASSIVATION LAYERS: OVERCOATS OF SI IN	129	2174
INITIATION OF CREVICE CORROSION I. EXPERIMENTAL	129	481
A NEW DOPING TECHNIQUE WITHOUT SIO2 PATTERNING USING AN	129	1074
LIQUID CHROMATOGRAPHY FOR STUDYING INTERFACIAL PROPERTIES OF	129	1485
SIMS STUDIES OF 9BE IMPLANTS IN SEMI-INSULATING	129	1312
NEW DISLOCATION ETCHANT FOR	129	352
EUTECTIC PRECIPITATES IN FE-DOPED	129	2335
PREPARATION AND ELECTRICAL PROPERTIES OF AN ANODIC OXIDE OF	129	2795
SIMS STUDIES OF SEMI-INSULATING	129	1320
DIDE ELECTROLYTES	129	1977

	Vol	Page
III-V ELECTRODES THE INFLUENCE OF SURFACE RECOM	129	730
III-V SEMICONDUCTOR DEVICES, INCLUDING INGAAS LONG	129	821
III-V SEMICONDUCTORS AND THE ROLE OF ADDED O2	129	1599
ILLUMINATED SURFACE BARRIER CELLS	129	1134
IMAGE ANALYSIS OF MORPHOLOGICAL INSTABILITY IN GAL	129	2447
IMAGE ANALYSIS OF MORPHOLOGICAL INSTABILITY IN GAL	129	2442
IMINE DERIVATIVES, REDUCTIVE CARBOXYLATION, ALPHA-	129	1231
IMMOBILIZATION REACTIONS USING THIONYL CHLORIDE	129	756
IMPACT OF DEIONIZED WATER RINSES ON SILICON SURFAC	129	1027
IMPACT ON CIRCUIT YIELD	129	2573
IMPEDANCE ANALYSIS THE DETERMINATION OF SURFACE ST	129	2147
IMPEDANCE AND MASS TRANSPORT KINETICS OF NICKEL CA	129	289
IMPEDANCE APPROACH TO NONFARADAIC ELECTROCHEMICAL	129	526
IMPEDANCE MEASUREMENTS ON LITHIUM-ELECTROLYZED BOR	129	2617
IMPEDANCE ON A ROTATING DISK ELECTRODE I. REDOX SY	129	107
IMPEDANCE RESPONSE	129	1874
IMPEDANCE RESPONSE OF SEMICONDUCTOR/ELECTROLYTE/CO	129	551
IMPEDANCE STUDIES	129	474
IMPEDANCE TECHNIQUE STUD	129	660
IMPERFECTIONS SEMICONDUCTOR ELECTRODES XLI. IMPROV	129	265
IMPLANTATION	129	816
IMPLANTATION IN POLYCRYSTALLINE SILICON	129	1604
IMPLANTATION INTO SILICON ROOM TEMPERAT	129	379
IMPLANTATION INTO SILICON: ITS MATERIAL COMPOSITIO	129	408
IMPLANTATION THROUGH SIO2 LAYERS	129	2527
IMPLANTED BORON IN SILICON UNDER DRY O2 AMBIENT	129	1097
IMPLANTS IN SEMI-INSULATING INP	129	1312
IMPLANTS IN SILICON DETERMINED BY A FOUR-PHASE COM	129	606
IMPROVE PHOTORESIST ADHESION	129	2389
IMPROVED DRY ETCHING RESISTANCE OF ELECTRON-BEAM R	129	2556
IMPROVEMENT OF PERFORMANCE OF N-WSE2 ELECTRODES BY	129	265
IMPROVING THE ELECTRICAL PROPERTIES OF VAPOR GROWN	129	2566
IMPURITIES ON DILUTE ALLOYS PARABOL	129	622
IMPURITIES ON THE OXYGEN ELECTRODE REACTION AT ZIR	129	345
IMPURITY DEPOSITS IN GAS TURBINES FROM FUELS CONTA	129	649
IMPURITY GETTERING OF SILICON DAMAGE GENERATED BY	129	2527
IMPURITY LEVEL	129	2219
IMPURITY-CONTAINING SULFATE BATHS	129	2695
IN)203	129	2069
IN-P-O PHASE DIAGRAM: CONSTRUCTION AND APPLICATION	129	1361
INCLUDING INGAAS LONG WAVELENGTH PHOTODETECTORS A	129	821
INCLUSIONS IN ELECTRODEPOSITED FILMS BY TRANSMISSI	129	201C
INCLUSIONS IN INDIUM PHOSPHIDE	129	614
INCORPORATION DURING SILICON EPITAXIAL GROWTH IN A	129	1122
INCORPORATION IN GAAS GROWN BY MOLECULAR BEAM EPIT	129	2108
INDEX MODEL OPTICAL CONSTANTS OF ARSENIC AND BORON	129	606
INDICATOR FOR LEAD-ACID BATTERIES	129	2409
INDIUM THE INFLUENCE OF SOLUTE ADDITIONS OF COPPER	129	430
INDIUM PHOSPHIDE	129	614
INDIUM-SULFIDE SYSTEM VAPORIZATION CHEMISTRY AND T	129	1835
INDUCED DEFECT BEHAVIOR MU	129	2089
INDUCED DURING NON-STEADY-STATE SOLIDIFICATION	129	2355
INDUSTRIAL PROCESS	129	1109
INDUSTRIES FOR THE YEAR 1981	129	275C
INDUSTRY AN INVESTIGATION OF THE THICKNESS VARIATI	129	173
INDUSTRY	129	397C
INEXPENSIVE CROSS-LINKED POLYMERIC SEPARATORS MADE	129	251
INFRARED ABSORPTIVITY, AND CHEMICAL REACTIONS OF T	129	1619
INFRARED STUDIES OF CHEMICALLY MODIFIED ELECTRODE	129	300C
INFRARED STUDY OF CHLORANIL IN N-BUTYLPYRIDINIUM C	129	2739
INGAAS LONG WAVELENGTH PHOTODETECTORS A PROPOSED H	129	821
INGAAS/INP GROWN BY LIQUID PHASE EPITAXY	129	2603
INGAASP/INP	129	609
INGAASP/INP DH WAFER	129	1053
INGAASP/INP HETEROJUNCTIONS LPE GROWTH TECHNI	129	2085
INGAASP/INP PLANAR-STRIPE LASERS WITH CHEMICALLY E	129	883
INGREDIENT OF R&D	129	393C
INHIBITING POLYPHOSPHATE SOLUTIONS ON	129	1186
INHIBITION BY ADSORPTION OF LIGAND	129	717
INHIBITION IN NITROGEN-IMPLANTED SILICON	129	1803
INHIBITION OF ZINC BY COBALT IONS	129	1658
INHOMOGENEITY CONTRIBUTION TO THE ELECTRICAL PROPE	129	2113
INITIAL DISSOLUTION STEP	129	27
INITIAL OXIDE GROWTH RATE ON NEWLY GENERATED SURFA	129	2500
INITIATION OF CREVICE CORROSION I. EXPERIMENTAL I	129	481
INITIATION OF CREVICE CORROSION II. MATHEMATICAL M	129	488
INITIATION OF HOT CORROSION OF B-1900 AND NASA-TRW	129	571
INJECTION OPTICAL CH	129	2633
INJECTION INTO GATE SIO2 INTERFACE TRAPPED CHARGE	129	1760
INK ELECTROCHEM	129	2174
INNVESTIGATIONS ALUMINUM AND IRON	129	481
INORGANIC PHOTORESIST	129	1074
INORGANIC SOLUTES RELEVANT TO REVERSE OSMOSIS SEPA	129	1485
INP	129	1312
INP	129	352
INP	129	2335
INP	129	2795
INP AMORPHIZED BY MG AND SI	129	1320
INP AND CDS PHOTOANODES IN CONCENTRATED AQUEOUS IO	129	1977

		Vol	Page
TEMPERATURE DEPENDENCE OF	**INP** AND GAAS ETCHING IN A CHLORINE PLASMA	129	2533
CHEMICAL ETCHING OF	**INP** AND INGAASP/INP	129	609
F INTERMITTENT GROWTH PROCEDURES ON DISLOCATION DENSITIES IN	**INP** EPI-LAYERS THE INFLUENCE O	129	1556
ON CHARACTERISTICS OF	**INP** MIS SCHOTTKY DIODES PREPARED BY PLASMA OXIDATI	129	221
FACTORS INFLUENCING THE GROWTH OF GAO.47INO.53AS ON	**INP** SUBSTRATES USING THE METALORGANIC PROCESS	129	383
ANALYSIS OF	**INP** SURFACE PREPARED BY VARIOUS CLEANING METHODS	129	447
METALLURGICAL BEHAVIOR OF GOLD-BASED OHMIC CONTACTS TO THE	**INP/INGAASP** MATERIAL SYSTEM	129	2585
PLE DAMAGE-FREE GROOVING METHOD FOR REVEALING THE QUALITY OF	**INP/INGAASP** MULTILAYER STRUCTURE A SIM	129	2082
AN AES EVALUATION OF CLEANING AND ETCHING METHODS FOR	**INSB**	129	2752
MODELING OF POROUS	**INSERTION** ELECTRODES WITH LIQUID ELECTROLYTE	129	1480
ELECTROCHEMICAL	**INSERTION** OF HYDROGEN IN WO3	129	2276
E LAYER PRECIOUS M THE DEVELOPMENT OF AN ENERGY-EFFICIENT	**INSOLUBLE** ANODE FOR NICKEL ELECTROWINNING I. SINGL	129	515
ILAYER PRECIOUS ME THE DEVELOPMENT OF AN ENERGY-EFFICIENT	**INSOLUBLE** ANODE FOR NICKEL ELECTROWINNING II. MULT	129	522
N I. GENERAL EXPRESSION F IMAGE ANALYSIS OF MORPHOLOGICAL	**INSTABILITY** IN GALVANOSTATIC ELECTROCRYSTALLIZATIO	129	2442
N II. EXPERIMENTAL DEMONS IMAGE ANALYSIS OF MORPHOLOGICAL	**INSTABILITY** IN GALVANOSTATIC ELECTROCRYSTALLIZATIO	129	2447
	INSTABILITY OF ANODIC OXIDE FILMS ON TITANIUM	129	1252
ING SCANNING LA SINGLE CRYSTAL SILICON FILMS ON AMORPHOUS	**INSULATORS**: GROWTH BY LATERAL NUCLEATED EPITAXY US	129	2802
TEST STRUCTURE FOR EVALUATING THE LINEWIDTH UNIFORMITY OF AN	**INTEGRATED** CIRCUIT LITHOGRAPHY SYSTEM A CROSS-BRID	129	2313
EVERAL PARAMETERS ON THE CORROSION RATES OF AL CONDUCTORS IN	**INTEGRATED** CIRCUITS EFFECTS OF S	129	2270
THE RELATION BETWEEN ETCH RATE AND OPTICAL EMISSION	**INTENSITY** IN PLASMA ETCHING	129	1325
I.	**INTERACTION** OF AL FILMS WITH O2 AT LOW PRESSURES	129	2366
NSPORT IN EFG OF SILICO MODELING OF AMBIENT-MENISCUS MELT	**INTERACTIONS** ASSOCIATED WITH CARBON AND OXYGEN TRA	129	1356
TRANSFER ACROSS N-TIO2-AQUEOUS ELECTROLYTE INTERFACE	**INTERACTIONS** BETWEEN PHOTOINDUCED AND DARK CHARGE	129	1240
HEAT-TREATMENT STUDIES OF OXYGEN-DEFECT-IMPURITY	**INTERACTIONS** IN SILICON	129	2127
ELECTROCHEMICAL STUDIES ON LITHIUM	**INTERCALATION** MATERIALS IN MOLTEN SALTS	129	970
C DETERMIN ELECTROCHEMICAL INVESTIGATIONS OF ALKALI-METAL	**INTERCALATION** REACTIONS IN TIS2: CHRONOAMPEROMETRI	129	682
Y AND CHRO ELECTROCHEMICAL INVESTIGATIONS OF ALKALI-METAL	**INTERCALATION** REACTIONS IN TIS2: CYCLIC VOLTAMMETR	129	677
D AND DARK CHARGE TRANSFER ACROSS N-TIO2-AQUEOUS ELECTROLYTE	**INTERFACE** INTERACTIONS BETWEEN PHOTOINDUCE	129	1240
STATES: A NEW FORMULATION FOR THE SEMICONDUCTOR/ELECTROLYTE	**INTERFACE** ELECTROCHEMICAL TRANSFER VIA SURFACE	129	963
OCENE AT THE N-GAAS/ROOM TEMPERATURE MOLTEN SALT ELECTROLYTE	**INTERFACE** PHOTOELECTROCHEMICAL OXIDATION OF AROMAT	129	560
ZATION OF THE N-INP/ROOM TEMPERATURE MOLTEN SALT ELECTROLYTE	**INTERFACE** PHOTOELECTROCHEMICAL CHARACTERI	129	2009
LECTRODE KINETICS AT THE PALLADIUM/CERAMIC OXIDE ELECTROLYTE	**INTERFACE** E	129	1921
NIQUE STUDY OF AGF-LAF3 REVERSIBLE	**INTERFACE** BY AUGER SPECTROSCOPY AND IMPEDANCE TECH	129	660
ION OF SURFACE STATE ENERGIES AT A SEMICONDUCTOR/ELECTROLYTE	**INTERFACE** BY LAPLACE DOMAIN IMPEDANCE ANALYSIS THE	129	2147
STUDIES OF PHOTOCORROSION AT THE ZNSE-ELECTROLYTE	**INTERFACE** BY PHOTOTHERMAL DEFLECTION SPECTROSCOPY	129	2393
D GAAS USING AUGER DEPTH PROFILING	**INTERFACE** COMPOSITION STUDIES OF THERMALLY OXIDIZE	129	851
FIXED CHARGE DENSITY (QSS) AT THE SI-SIO2	**INTERFACE** FOR THIN OXIDES	129	1757
POLYSILICON/SIO2	**INTERFACE** MICROTEXTURE AND DIELECTRIC BREAKDOWN	129	1282
H EXP CHARGE TRANSFER IN PHOTOELECTROCHEMICAL DEVICES VIA	**INTERFACE** STATES: UNIFIED MODEL AND COMPARISON WIT	129	1003
RAPPING KINETICS IN MOSFET'S DUE TO SUBSTRATE HOT-ELECTRON I	**INTERFACE** TRAPPED CHARGE GENERATION AND ELECTRON T	129	1760
	INTERFACIAL CHEMISTRY AT P-GAP PHOTOELECTRODES	129	2141
NT TO REVERSE O USE OF LIQUID CHROMATOGRAPHY FOR STUDYING	**INTERFACIAL** PROPERTIES OF INORGANIC SOLUTES RELEVA	129	1485
W PATTERNS IN HORIZONTAL EPITAXIAL REACTOR CELLS OBSERVED-BY	**INTERFERENCE** HOLOGRAPHY GAS FLO	129	634
AL CONVECTION	**INTERFEROMETRIC** STUDY OF COMBINED FORCED AND NATUR	129	2201
SPIN-ON GLASS AS AN	**INTERMEDIATE** LAYER IN A TRI-LAYER RESIST PROCESS	129	2152
OXIDATION OF SULFUR IN CHLOROALUMINATE MELTS OF	**INTERMEDIATE** PCL	129	2237
ITIES IN INP EPI-LAYERS THE INFLUENCE OF	**INTERMITTENT** GROWTH PROCEDURES ON DISLOCATION DENS	129	1556
R DURING THE UNDERPOTENTIAL DEPOSITION OF SILVER ON GOLD USI	**INTERPRETATION** OF POTENTIOSTATIC TRANSIENT BEHAVIO	129	1202
RFACE RECOMBINATION ON N-GAP PHOTOELECTRODES: MECHANISMS AND	**INTERRELATION** STUDY OF STABILIZATION AND SU	129	546
I-INFINITE DIFFUSION TO ELECTRODES CONSISTING OF TWO OR MORE	**INTERSECTING** PLANES SEM	129	128
TION, THERMAL HISTORY DEPENDENCE, AND ENHANCEM A STUDY ON	**INTRINSIC** GETTERING IN CZ SILICON CRYSTALS: EVALUA	129	374
IONS IN TIS2: CYCLIC VOLTAMMETRY AND CHRO ELECTROCHEMICAL	**INVESTIGATIONS** OF ALKALI-METAL INTERCALATION REACT	129	677
IONS IN TIS2: CHRONOAMPEROMETRIC DETERMIN ELECTROCHEMICAL	**INVESTIGATIONS** OF ALKALI-METAL INTERCALATION REACT	129	682
DESIGN OF A CELL FOR ELECTRODE KINETIC	**INVESTIGATIONS** OF FUEL CELL REACTIONS	129	135
CRYSTALS IN LIQUID AMMONIA AND IN LIQUID AMMONIATE OF SODIUM	**IODIDE** PHOTOELECTROCHEMICAL BEHAVIOR OF P-TYPE SI	129	1998
INP AND CDS PHOTOANODES IN CONCENTRATED AQUEOUS	**IODIDE** ELECTROLYTES	129	1977
THERMODYNAMICS AND KINETICS OF	**IODINE** CHEMICAL VAPOR TRANSPORT OF GEAS	129	1343
SELECTIVE REACTIVE	**ION** BEAM ETCHING OF SIO2 OVER POLYCRYSTALLINE SI	129	396
AUFMAN ION SOURCE AND DETAILS OF SIO2 ETCHING REACTIVE	**ION** BEAM ETCHING WITH CF4: CHARACTERIZATION OF A K	129	585
ELECTROCHEMISTRY OF THE THALLIC/THALLOUS COUPLE. THE THALLIC	**ION** CATALYZED PHOTO-OXIDATION OF PROPYLENE PHOTO	129	2232
RPHOUS SILICON FIELD EFF DETERMINATION OF POSITIVE MOBILE	**ION** DENSITY IN SILICON DIOXIDE BY HYDROGENATED AMO	129	2770
SPECTROSCOPY CHARACTERIZATION OF REACTIVE	**ION** ETCHED SILICON SURFACE BY DEEP LEVEL TRANSIENT	129	2823
THE EFFECTS OF MIXING N2 IN CCL4 ON ALUMINUM REACTIVE	**ION** ETCHING	129	2522
REACTIVE	**ION** ETCHING OF SILICON DIOXIDE	129	1152
FLUOROMETHANE. THE ROLE OF NITROGEN IN THE DISCH REACTIVE	**ION** ETCHING OF SILICON OXIDES WITH AMMONIA AND TRI	129	1036
A COMPARISON OF PERFLUORINATED CARBOXYLATE AND SULFONATE	**ION** EXCHANGE POLYMERS I. DIFFUSION AND WATER SORPT	129	324
A COMPARISON OF PERFLUORINATED CARBOXYLATE AND SULFONATE	**ION** EXCHANGE POLYMERS II. SORPTION AND TRANSPORT P	129	328
IMPROVED DRY ETCHING RESISTANCE OF ELECTRON-BEAM RESIST BY	**ION** EXPOSURE PROCESS	129	2556
SINGLE CRYSTAL Y3AL5O12:TB PHOSPHOR PRODUCED BY	**ION** IMPLANTATION	129	816
ERATURE FORMATION OF SI-NITRIDE FILMS BY LOW ENERGY NITROGEN	**ION** IMPLANTATION INTO SILICON ROOM TEMP	129	379
IMPURITY GETTERING OF SILICON DAMAGE GENERATED BY	**ION** IMPLANTATION THROUGH SIO2 LAYERS	129	2527
ONTROLLED POTENTIAL COULOMETRY OF 4-CYANO-1-METHYLPYRIDINIUM	**ION** IN ACETONITRILE C	129	2731
POLAROGRAPHY OF 4-CYANO-1-METHYLPYRIDINIUM	**ION** IN ACETONITRILE	129	2725
L CHARACTERISTICS OF WO3 ELECTROCHROMIC CELLS UNDER HEAVY LI	**ION** INJECTION OPTICA	129	2633
RFACE COMPOSITION OF BOROSILICATE GLASSES (BSG) BY SECONDARY	**ION** MASS SPECTROMETRY (SIMS) CHARACTERIZATION OF N	129	1819
IN THE ACTIVE STATE BASED ON MASS TRANSPORT BY DIFFUSION AND	**ION** MIGRATION A MODEL OF CRACK ELECTROCHEMISTRY FO	129	1412
VIBRATIONAL SPECTROSCOPIC DETERMINATION OF STRUCTURE AND	**ION** PAIRING IN COMPLEXES OF POLY(ETHYLENE OXIDE) W	129	1434
THE SUSPENDED MESH	**ION** SELECTIVE FIELD EFFECT TRANSISTOR	129	2580
EQUILIBRIUM NOISE IN	**ION** SELECTIVE FIELD EFFECT TRANSISTORS	129	2306
IVE ION BEAM ETCHING WITH CF4: CHARACTERIZATION OF A KAUFMAN	**ION** SOURCE AND DETAILS OF SIO2 ETCHING REACT	129	585
ALTERATION OF CORRODENT	**ION** SPECIES WITHIN STRESS CORROSION CRACKS	129	780
RON-CHROMIUM ALLOYS ELECTRON AND	**ION** SPECTROSCOPIC STUDIES OF THE PASSIVE FILM ON I	129	1662
THEORETICAL ANALYSIS OF ELECTROSTATIC EFFECTS ON	**ION** TRANSPORT IN ULTRATHIN MEMBRANES	129	958
UM HIGH RESOLUTION PHOTOMASKS WITH	**ION-BOMBARDED** POLYMETHYL METHACRYLATE MASKING MEDI	129	827
IN WO3-BASED ELECTROCHROMIC DEVICES	**ION-CONTAINING** POLYMERS AS SEMISOLID ELECTROLYTES	129	1215
N OF NICOTINAMIDE ADENINE DINUCLEOTIDE IN DIMETHYLSULFOXIDE:	**ION-PAIR**, PROTONATION, AND ADSORPTION EFFECTS ELEC	129	1960
ONDUCTIVITY IN COMPLEXES OF POLYETHERS W CONFORMATION AND	**ION-TRANSPORT** MODELS FOR THE STRUCTURE AND IONIC C	129	1694
S USING THE STEPPED CURREN AN INVESTIGATION OF HIGH FIELD	**IONIC** CONDUCTION IN ANODIC TANTALUM PENTOXIDE FILM	129	2518
S USING THE O AN EXPERIMENTAL INVESTIGATION OF HIGH FIELD	**IONIC** CONDUCTION IN ANODIC TANTALUM PENTOXIDE FILM	129	2513

		Vol	Page
CONFORMATION AND ION-TRANSPORT MODELS FOR THE STRUCTURE AND	**IONIC** CONDUCTIVITY IN COMPLEXES OF POLYETHERS WITH	129	1694
OF CHLORANIL IN N-BUTYLPYRIDINIUM CHLORIDE:ALUMINUM CHLORIDE	**IONIC** LIQUID AN ELECTROCHEMICAL AND INFRARED STUDY	129	2739
AND FE(III) IN AN ALUMINUM CHLORIDE-BUTYLPYRIDINIUM CHLORIDE	**IONIC** LIQUID ELECTROCHEMICAL STUDIES OF FE(II)	129	2474
ROSCOPIC STUDY OF THE CORROSION INHIBITION OF ZINC BY COBALT	**IONS** MOSSBAUER SPECT	129	1658
BEHAVIOR OF SOME METALS IN MOLTEN LICL-KCL CONTAINING OXIDE	**IONS** ANODIC CORROSION AND PASSIVATION	129	1245
COMPLEXING OF AL(+3) BY S(-2)	**IONS** IN ALKALI HALIDE MELTS	129	2034
URE AT 25 ELECTROCHEMICAL BEHAVIOR OF NITRATE AND NITRITE	**IONS** IN THE MOLTEN NAOH-KOH (49 M/O) EUTECTIC MIXT	129	123
AN ELLIPSOMETRIC STUDY OF ELECTROCHROMISM IN	**IRIDIUM** OXIDE	129	335
TRODEPOSITION AND HYDROGEN CHARGING OF SN AND CD COATINGS ON	**IRON** HYDROGEN ABSORPTION DURING ELEC	129	284
VICE CORROSION I. EXPERIMENTAL INNVESTIGATIONS ALUMINUM AND	**IRON** INITIATION OF CRE	129	481
ELECTRON DIFFRACTION STUDY OF THE PASSIVE FILM ON	**IRON**	129	2163
FORMATION OF SALT FILMS DURING PASSIVATION OF	**IRON**	129	2412
MPACT ON CIRCUIT YIELD A SURVEY OF	**IRON** CONTAMINATION IN SILICON SUBSTRATES AND ITS I	129	2573
A STUDY OF THE	**IRON** ELECTRODE STRUCTURE OF NI-FE CELL	129	1173
ES THE NATURE OF THE PASSIVE FILM ON	**IRON** I. AUTOMATIC ELLIPSOMETRIC SPECTROSCOPY STUDI	129	17
THE NATURE OF THE PASSIVE FILM ON	**IRON** II. A-C IMPEDANCE STUDIES	129	474
PPORTING EVIDENCE THE NATURE OF THE PASSIVE FILM ON	**IRON** III. THE CHEMI-CONDUCTOR MODEL AND FURTHER SU	129	921
LUTIONS ON THE NATURE OF SURFACE FILMS FORMED ON	**IRON** IN AGGRESSIVE AND INHIBITING POLYPHOSPHATE SO	129	1186
T AT 470DEGREE C REACTIONS OF FORMATION AND STABILITY OF	**IRON**(II) AND (III) OXIDES IN LICL-KCL EUTECTIC MEL	129	1450
IN ON CATALYSIS OF OXYGEN CATHODIC REDUCTION BY ADSORBED	**IRON**(111)-**TETRA** (N,N,N-TRIMETHYLANILINIUM) PORPHYR	129	2247
HE PROCESSING PARAMETERS ON THE ELECTROCHEMICAL CORROSION OF	**IRON-BORON** METALLIC GLASSES EFFECT OF COMPOSITION	129	695
LECTRON AND ION SPECTROSCOPIC STUDIES OF THE PASSIVE FILM ON	**IRON-CHROMIUM** ALLOYS E	129	1662
ALLIZATION OF VACUUM-DEPOSITED AMORPHOUS SILICON BY CW LASER	**IRRADIATION** ANOMALOUS LOCAL OXIDATION AND RECRYST	129	888
IZATION I. GENERAL EXPRESSION FOR THE GROWTH MODE OF SURFACE	**IRREGULARITIES** IMAGE ANALYSIS OF MORPHOLOGICAL INS	129	2442
THE CATION CONCENTRATION RESPONSE OF POLYMER GATE	**ISFET**	129	141
IDE FILMS DEPOSITED BY SPUTTERING AND BY COEVAPORATION AFTER	**ISOCHRONAL** ANNEALING CRYSTALLINE STRUCTURE CHANGES	129	1527
OPTIMIZATION OF	**ISOTHERMAL** GROWTH OF HGCDTE LAYERS	129	1103
POR PRESSURE	**ISOTHERMAL** GROWTH OF HGCDTE UNDER CONTROLLED HG VA	129	2855
SELECTIVE	**ISOTROPIC** DRY ETCHING OF SI3N4 OVER SIO2	129	2559
SELECTIVE ELECTROSYNTHESES ON CHEMICALLY MODIFIED ELECTRODE	**IV.** SELECTIVE REDUCTION OF O-NITROPHENOL IN THE PR	129	1681

— J —

HIGH-SPEED SELECTIVE ELECTROPLATING WITH SINGLE CIRCULAR	**JETS**	129	2424
MROCK ELECTROCHEMICAL ENGINEERING AND TECHNOLOGY MEDALIST	**JOSEPH** C. SCHUMACHER--VITTORIO DE NORA-DIAMOND SHA	129	395C
ER TRANSFORM INFRARED STUDIES OF CHEMICALLY MODIFIED THE	**JOSEPH** W. RICHARDS SUMMER FELLOWSHIP REPORT--FOURI	129	300C
CONTROLLED COLLAPSE REFLOW FOR	**JOSEPHSON** CHIP BONDING	129	859
P-TYPE AMORPHOUS SILICON/LIQUID	**JUNCTION** SOLAR CELL	129	1644
BI2S3 THIN FILM AND SOME SEMICONDUCT SEMICONDUCTOR LIQUID	**JUNCTION** SOLAR CELL BASED ON CHEMICALLY DEPOSITED	129	332
ERTIES, AND PERFORMANCE OF ELECTRODEPOSITED N-CDSE IN LIQUID	**JUNCTION** SOLAR CELLS MORPHOLOGY, PROP	129	2016
AL-0.9PERCENT SI/SI OHMIC CONTACTS TO SHALLOW	**JUNCTIONS**	129	1335
SPUTTER ETCHING EFFECTS ON GAAS SCHOTTKY	**JUNCTIONS**	129	2760
TEMPERATURE DEPENDENCE OF THE SENSITIVITIES OF METAL-TIO2	**JUNCTIONS** TO VARIOUS REDUCING GASES	129	444

— K —

AMBIENT TEMPERATURE	**K-TIS2** CELL	129	230
REACTIVE ION BEAM ETCHING WITH CF4: CHARACTERIZATION OF A	**KAUFMAN** ION SOURCE AND DETAILS OF SIO2 ETCHING	129	585
THE CONSTANT HELPER: STEADFASTNESS AS A	**KEY** INGREDIENT OF R&D	129	393C
DESIGN OF A CELL FOR ELECTRODE	**KINETIC** INVESTIGATIONS OF FUEL CELL REACTIONS	129	135
IDIFICATION STRIATIONS OF	**KINETIC** ORIGIN INDUCED DURING NON-STEADY-STATE SOL	129	2355
MIP REPORT--DETERMINATION OF HETEROGENEOUS ELECTRON TRANSFER	**KINETIC** PARAMETERS BY DERIVATIVE CYCLIC VOLTABSORP	129	298C
TRANSIENT IMPEDANCE APPROACH TO NONFARADAIC ELECTROCHEMICAL	**KINETICS** AT LIVING CELL MEMBRANES A	129	526
E INTERFACE ELECTRODE	**KINETICS** AT THE PALLADIUM/CERAMIC OXIDE ELECTROLYT	129	1921
INTERFACE TRAPPED CHARGE GENERATION AND ELECTRON TRAPPING	**KINETICS** IN MOSFET'S DUE TO SUBSTRATE HOT-ELECTRON	129	1760
SURFACE STRUCTURE OF RUTHENIUM DIOXIDE ELECTRODES AND	**KINETICS** OF CHLORINE EVOLUTION	129	1689
ND VOLTAGE STEP RELAXATION TECHNIQUES FOR THE MEASUREMENT OF	**KINETICS** OF ELECTRODE REACTIONS ERROR ANALYSIS OF	129	1943
ION BY ADSORPTION OF LIGAND	**KINETICS** OF ELECTROLESS COPPER PLATING VI. INHIBIT	129	717
S THERMODYNAMICS AND	**KINETICS** OF IODINE CHEMICAL VAPOR TRANSPORT OF GEA	129	1343
IMPEDANCE AND MASS TRANSPORT	**KINETICS** OF NICKEL CADMIUM CELLS	129	289
QUESTIONS ON THE	**KINETICS** OF O2 EVOLUTION ON OXIDE-COVERED METALS	129	700
THE PHOTOELECTROCHEMICAL	**KINETICS** OF P-TYPE GAP	129	2254
GROWTH	**KINETICS** OF SILICON THERMAL NITRIDATION	129	1559
	KINETICS OF THE F,F2/B4C GASIFICATION REACTIONS	129	1105
D STEEL AND NICKEL CATHODES IN CONCENTRATED SODIUM HYDROXIDE	**KINETICS** OF THE HYDROGEN EVOLUTION REACTION ON MIL	129	2481
ARGE OF LI/SOCL2 CELLS THE	**KINETICS** OF THE LITHIUM ELECTRODE DURING THE DISCH	129	2649
A TRANSITION IN THE	**KINETICS** OF THE NI(OH)2/NIOOH ELECTRODE REACTION	129	983
R-DEPOSITED ALUMINUM NITRIDE FILMS COMPOSITION,	**KINETICS,** AND MECHANISM OF GROWTH OF CHEMICAL VAPO	129	1045
PIES OF FORMATION OF NIOBIUM ALUMINIDES AS DETERMINED BY THE	**KNUDSEN** EFFUSION METHOD ENTHAL	129	1608
GALVANOSTATIC ANODIZATION OF GAAS IN METHANOLIC	**KOH**	129	1016
CTANCE AND CURRENT DISTRIBUTION IN POROUS ZINC ELECTRODES IN	**KOH** ELECTROLYTE THE RELATIONSHIP BETWEEN ELECTROLY	129	1390
TRANSIENT CURRENT DISTRIBUTIONS IN POROUS ZINC ELECTRODES IN	**KOH** ELECTROLYTE	129	239

— L —

MASS TRANSFER IN	**LAMINAR** FLOW CHANNEL WITH POROUS WALL	129	1727
LUTION	**LANTHANUM** NICKELATE AS ELECTROCATALYST: OXYGEN EVO	129	2391
ELECTRICAL CONDUCTIVITY IN	**LANTHANUM-DOPED** STRONTIUM TITANATE	129	1021
E STATE ENERGIES AT A SEMICONDUCTOR/ELECTROLYTE INTERFACE BY	**LAPLACE** DOMAIN IMPEDANCE ANALYSIS THE DETERMINATIO	129	2147
SULATORS: GROWTH BY LATERAL NUCLEATED EPITAXY USING SCANNING	**LASER** AND ELECTRON BEAMS AND EVALUATION BY ELECTRO	129	2802
LY DOPED WITH ARSE ELECTRICAL PROPERTIES OF THERMALLY AND	**LASER** ANNEALED POLYCRYSTALLINE SILICON FILMS HEAVI	129	1811
CONFORMAL STEP COVERAGE OF	**LASER** DEPOSITED SILICON DIOXIDE FILMS	129	2155
USE OF HBR-CH3COOH-K2CR207 ETCHANT TO ETCHED-MIRROR	**LASER** FABRICATION	129	1524
ECRYSTALLIZATION OF VACUUM-DEPOSITED AMORPHOUS SILICON BY CW	**LASER** IRRADIATION ANOMALOUS LOCAL OXIDATION AND R	129	888
IOR OF AN AL-1 PERCENT MN ALLOY EFFECT OF	**LASER-SURFACE** MELTING ON THE ELECTROCHEMICAL BEHAV	129	9
INGAASP/INP PLANAR-STRIPE	**LASERS** WITH CHEMICALLY ETCHED MIRRORS	129	883
N A NOVEL METHOD TO MEASURE	**LATERAL** DIFFUSION LENGTH IN POLYCRYSTALLINE SILICO	129	1635
	LATERAL EPITAXIAL OVERGROWTH OF SILICON ON SIO2	129	2303
GLE CRYSTAL SILICON FILMS ON AMORPHOUS INSULATORS: GROWTH BY	**LATERAL** NUCLEATED EPITAXY USING SCANNING LASER AND	129	2802
NAFION MEMBRANE IN CHLOR-ALKALI CE THE ANOLYTE DIFFUSION	**LAYER** AND ITS EFFECT ON HYDROXYL TRANSPORT THROUGH	129	722
ION MAGNETIC FIELD EFFECTS ON THE GROWTH OF THE DIFFUSION	**LAYER** AT VERTICAL ELECTRODES DURING ELECTRODEPOSIT	129	1266
AN ELECTROCHEMICALLY SEALED AL203 PASSIVATION	**LAYER** FOR ALUMINUM ALLOYS	129	1865

		Vol	Page
SPIN-ON GLASS AS AN INTERMEDIATE	**LAYER** IN A TRI-LAYER RESIST PROCESS	129	2152
FFICIENT INSOLUBLE ANODE FOR NICKEL ELECTROWINNING I. SINGLE	**LAYER** PRECIOUS METAL COATINGS THE DEVELOPMENT OF A	129	515
EXPERIMENT SIMULATIONS: EFFECTS OF PROBE-CURRENT DENSITY AND	**LAYER** THICKNESS SPREADING RESISTANCE PROBE-SPACING	129	2788
OLYTE CELLS ELECTROCHEMICAL SOLAR CELLS WITH	**LAYER-TYPE** SEMICONDUCTOR ANODES. NONAQUEOUS ELECTR	129	1155
PHOTOELECTROCHEMICAL RESPONSE OF SOME	**LAYERED** CHALCOGENOPHOSPHATE COMPOUNDS (MPX3)	129	237
OPTIMIZATION OF ISOTHERMAL GROWTH OF HGCDTE	**LAYERS**	129	1103
SIMS EVIDENCE CONCERNING WATER IN PASSIVE	**LAYERS**	129	2149
OF SILICON DAMAGE GENERATED BY ION IMPLANTATION THROUGH SIO2	**LAYERS** IMPURITY GETTERING	129	2527
PHOTOELECTROCHEMICAL CELLS BY FORMATION OF PLATINUM SILICIDE	**LAYERS** SEMICONDUCTOR ELECTRODES XLVI. STABILIZATIO	129	1647
R DEFECT EVALUATION OF THIN (100) ORIENTED SILICON EPITAXIAL	**LAYERS** USING A WET CHEMICAL ETCH METHODS FO	129	2074
ELECTROCHEMICAL TEST TO EVALUATE PASSIVATION	**LAYERS**: OVERCOATS OF SI IN INK	129	2174
ANCE OF AN FE-TI STATIONARY REDOX BATTERY IN THE PRESENCE OF	**LEAD** OPERATING PERFORM	129	2502
IOMETRIC DETERMINATION OF THE GIBBS ENERGIES OF FORMATION OF	**LEAD** ALUMINATES POTENT	129	1116
ALUMINA "FIBER FP" REINFORCED PURE	**LEAD** COMPOSITES FOR BATTERY ELECTRODES	129	1749
ECTRODE BETA-PBO2	**LEAD** DEFICIENCY AND HYDROGEN CONTENT IN BATTERY EL	129	1678
A SEMICONDUCTOR MODEL FOR THE CATHODIC PASSIVATION OF	**LEAD** DIOXIDE	129	1880
THE DEFECT STRUCTURE OF	**LEAD** DIOXIDE	129	876
UTION IN STRONG AC THE MECHANISM OF THE DISINTEGRATION OF	**LEAD** DIOXIDE ANODES UNDER CONDITIONS OF OZONE EVOL	129	567
CVD HYDROPHOBIC	**LEAD** SILICATE FILMS	129	165
ORIC ACID THE NATURE OF PASSIVATION OF	**LEAD** SULFIDE DURING ANODIC DISSOLUTION IN HYDROCHL	129	271
SELF-DISCHARGE IN ACID-STARVED	**LEAD-ACID** BATTERIES	129	1393
STATE-OF-CHARGE INDICATOR FOR	**LEAD-ACID** BATTERIES	129	2409
SELF-DISCHARGE AND PASSIVATION PHENOMENA IN	**LEAD-ACID** BATTERIES DURING STORAGE	129	458
EFFECT OF MELT STOICHIOMETRY ON TWIN FORMATION IN	**LEC** GAAS	129	2382
EP LEVEL TRANSIENT SPECTROSCOPY OF SILVER AND GOLD LEVELS IN	**LEC** GROWN GALLIUM ARSENIDE DE	129	1353
N P-WSE2: RECOMBINATION SITES AND MINORITY CARRIER DIFFUSION	**LENGTH** CHARGE COLLECTION MICROSCOPY O	129	418
A NOVEL METHOD TO MEASURE LATERAL DIFFUSION	**LENGTH** IN POLYCRYSTALLINE SILICON	129	1635
A NOVEL METHOD FOR MEASUREMENT OF THE CHANNEL	**LENGTH** OF SHORT CHANNEL MOSFET'S	129	1338
CTERIZATION OF SEMICONDUCTOR ELECTRODES WITH A DEEP IMPURITY	**LEVEL** CHARA	129	2219
L OF P- SEMICONDUCTOR ELECTRODES XLII. EVIDENCE FOR FERMI	**LEVEL** PINNING FROM SHIFTS IN THE FLATBAND POTENTIA	129	1742
RACTERIZATION OF REACTIVE ION ETCHED SILICON SURFACE BY DEEP	**LEVEL** TRANSIENT SPECTROSCOPY CHA	129	2823
VELS IN LEC GROWN GALLIUM ARSENIDE DEEP	**LEVEL** TRANSIENT SPECTROSCOPY OF SILVER AND GOLD LE	129	1353
RIBUTION CONDITIONS ANODIC	**LEVELING** UNDER SECONDARY AND TERTIARY CURRENT DIST	129	946
DEEP LEVEL TRANSIENT SPECTROSCOPY OF SILVER AND GOLD	**LEVELS** IN LEC GROWN GALLIUM ARSENIDE	129	1353
ANCE SPECTROSCOPY: A NEW METHOD FOR CHARACTERIZATION OF DEEP	**LEVELS** IN SEMICONDUCTORS ELECTROCHEMICAL PHOTOCAPA	129	891
PITATION TECHNIQUE THE MEASUREMENT OF LOW	**LEVELS** OF OXYGEN IN GERMANIUM BY THE LITHIUM PRECI	129	226
SOME RESTATEMENTS ON THE NATURE AND BEHAVIOR OF MNO2 FOR	**LI** BATTERIES	129	1861
ICAL CHARACTERISTICS OF WO3 ELECTROCHROMIC CELLS UNDER HEAVY	**LI** ION INJECTION OPT	129	2633
ERMOMECHANICAL BEHAVIOR OF SIMULATED NEGATIVE ELECTRODES FOR	**LI-AL/FES** BATTERY CELLS TH	129	2265
EVALUATION OF NICKEL FOR POSITIVE ELECTRODE COMPONENTS IN	**LI-AL/FES** CELLS	129	496
CERAMIC SEPARATORS FOR	**LI-AL/IRON** SULFIDE BATTERIES	129	2187
ASE RELATIONSHIPS IN POSITIVE ELECTRODES OF HIGH TEMPERATURE	**LI-AL/LICL-KCL/FES2** CELLS PH	129	925
OR MOLTEN SALT BATTERIES THERMODYNAMIC STUDIES OF	**LI-GE** ALLOYS: APPLICATION TO NEGATIVE ELECTRODES F	129	246
NO3-NANO3: A MODEL SYSTEM FOR THE LICL-KCL ELECTROLYTE OF AN	**LI/S** BATTERY CURRENT-INDUCED COMPOSITION GRADIENTS	129	49
SAL SPECTROSCOPIC STUDIES OF THE HAZARDS OF	**LI/SOCL2** BATTERIES DURING ANODE-LIMITED CELL REVER	129	2496
HE KINETICS OF THE LITHIUM ELECTRODE DURING THE DISCHARGE OF	**LI/SOCL2** CELLS T	129	2649
NS AND PRODUCTS OF THE DISCHARGE AND FORCED OVERDISCHARGE OF	**LI/SO2** CELLS CHARACTERIZATION OF REACTIO	129	1857
ANCE REPRODUCIBILITY, CAPACITY RETENTION, AND CYCLE LIFE FOR	**LIAL/FES** CELLS STATUS CELLS: A DEMONSTRATION OF PE	129	2701
ANALYSIS OF THE COMPRESSIVE STRENGTH OF	**LIALO2/MOLTEN** CARBONATE STRUCTURES	129	216
CORROSION AND PASSIVATION BEHAVIOR OF SOME METALS IN MOLTEN	**LICL-KCL** CONTAINING OXIDE IONS ANODIC	129	1245
TION GRADIENTS IN MOLTEN AGNO3-NANO3: A MODEL SYSTEM FOR THE	**LICL-KCL** ELECTROLYTE OF AN LI/S BATTERY CURRENT-IN	129	49
S OF FORMATION AND STABILITY OF IRON(II) AND (III) OXIDES IN	**LICL-KCL** EUTECTIC MELT AT 470DEGREE C REACTION	129	1450
F PERFORMANCE REPRODUCIBILITY, CAPACITY RETENTION, AND CYCLE	**LIFE** FOR LIAL/FES CELLS STATUS CELLS: A DEMONSTRAT	129	2701
THE EFFECT OF PROCESSING PARAMETERS ON THE	**LIFETIME** OF (HG,CD)TE MATERIAL	129	656
HIGH	**LIFETIME** SILICON LIQUID PHASE EPITAXY	129	665
F ELECTROLESS COPPER PLATING VI. INHIBITION BY ADSORPTION OF	**LIGAND** KINETICS O	129	717
DIFIED ELECTRODES II. SPECTROELECTROCHEMICAL PROPERTIES OF A	**LIGAND** (BATHOPHENANTHROLINE DISULFONIC ACIDD) BOUN	129	762
(III)-COBALT(II) COMPLEXES WITH O-PHENANTHROLINE AND RELATED	**LIGANDS** SOLUTION REDOOX COUPLES FOR EELECTROCHEMIC	129	61
ENE COMPLEX ELECTRODE VISIBLE	**LIGHT** CONVERSION AT ONE-DIMENSIONAL NICKEL DITHIOL	129	2378
OLTAGE ANALYSIS OF PHOTOELECTROCHEMICAL CELLS UNDER MASS AND	**LIGHT** FLUX VARIATION CURRENT-V	129	2029
N FILM SUBSTRATE RESOLUTION	**LIMIT** OF NEGATIVE ELECTRON RESIST EXPOSED ON A THI	129	1831
RATION, OPTIMIZATION, AND CATHODOLUMINESCENT PROPERTIES OF A	**LINE** EMISSION PENETRATION PHOSPHOR PREPA	129	1540
OGRAPHY A CROSS-BRIDGE TEST STRUCTURE FOR EVALUATING THE	**LINEWIDTH** UNIFORMITY OF AN INTEGRATED CIRCUIT LITH	129	2313
ORANIL IN N-BUTYLPYRIDINIUM CHLORIDE:ALUMINUM CHLORIDE IONIC	**LIQUID** AN ELECTROCHEMICAL AND INFRARED STUDY OF CH	129	2739
(III) IN AN ALUMINUM CHLORIDE-BUTYLPYRIDINIUM CHLORIDE IONIC	**LIQUID** ELECTROCHEMICAL STUDIES OF FE(II) AND FE	129	2474
ACTIVITIES AND SURFACE TENSION OF	**LIQUID** AGCL-LICL SOLUTIONS	129	502
HOTOELECTROCHEMICAL BEHAVIOR OF P-TYPE SI SINGLE CRYSTALS IN	**LIQUID** AMMONIA AND IN LIQUID AMMONIATE OF SODIUM I	129	1998
HAVIOR OF P-TYPE SI SINGLE CRYSTALS IN LIQUID AMMONIA AND IN	**LIQUID** AMMONIATE OF SODIUM IODIDE PHOTOELECTROCHEM	129	1998
PERTIES OF INORGANIC SOLUTES RELEVANT TO REVERSE O USE OF	**LIQUID** CHROMATOGRAPHY FOR STUDYING INTERFACIAL PRO	129	1485
MODELING OF POROUS INSERTION ELECTRODES WITH	**LIQUID** ELECTROLYTE	129	1480
RIC DETERMINATION OF MASS AND CHARGE TRANSPORT PROPERTIES OF	**LIQUID** ELECTROLYTE SYSTEMS ELECTROCHEMICAL INVESTI	129	682
EACTIONS IN TIS2: CYCLIC VOLTAMMETRY AND CHRONOCOULOMETRY OF	**LIQUID** ELECTROLYTE SYSTEMS ELECTROCHEMICAL INVESTI	129	677
ON THE DIFFUSIVITY AND THERMODYNAMIC PROPERTIES OF OXYGEN IN	**LIQUID** INDIUM THE INFLUENCE OF SOLUTE ADDITIONS OF	129	430
OSITED BI2S3 THIN FILM AND SOME SEMICONDUCT SEMICONDUCTOR	**LIQUID** JUNCTION SOLAR CELL BASED ON CHEMICALLY DEP	129	332
Y, PROPERTIES, AND PERFORMANCE OF ELECTRODEPOSITED N-CDSE IN	**LIQUID** JUNCTION SOLAR CELLS MORPHOLOG	129	2016
IN SITU MONITORING OF	**LIQUID** PHASE ELECTROEPITAXIAL GROWTH	129	2095
SELECTIVE EPITAXIAL GROWTH OF GAAS BY	**LIQUID** PHASE ELECTROEPITAXY	129	194
HIGH LIFETIME SILICON	**LIQUID** PHASE EPITAXY	129	665
ORIENTATION DEPENDENCE OF GROWTH RATE OF INGAAS/INP GROWN BY	**LIQUID** PHASE EPITAXY SUBSTRATE	129	2603
REFILLING SILICON GROOVES BY	**LIQUID** PHASE EPITAXY	129	2819
PROPERTIES OF VAPOR GROWN III-V COMPOUNDS BY COOLING THE HCL	**LIQUID** SOURCE IMPROVING THE ELECTRICAL	129	2566
CHARACTERIZATION OF ETHER ELECTROLYTES FOR RECHARGEABLE	**LITHIUM** CELLS	129	2404
PHTHALOCYANINE CATHODE MATERIALS FOR SECONDARY	**LITHIUM** CELLS	129	5
AND CHARACTERIZATION	**LITHIUM** CLOSOBORANE ELECTROLYTES III. PREPARATION	129	2213
IETHYL ETHER ELECTROLYTES SPECULAR	**LITHIUM** DEPOSITS FROM LITHIUM HEXAFLUOROARSENATE/D	129	1
CELLS THE KINETICS OF THE	**LITHIUM** ELECTRODE DURING THE DISCHARGE OF LI/SOCL2	129	2649
TES SPECULAR LITHIUM DEPOSITS FROM	**LITHIUM** HEXAFLUOROARSENATE/DIETHYL ETHER ELECTROLY	129	1
N-CIRCUI ELECTROCHEMICAL STUDIES OF THE FILM FORMATION ON	**LITHIUM** IN PROPYLENE CARBONATE SOLUTIONS UNDER OPE	129	1422
ELECTROCHEMICAL STUDIES ON	**LITHIUM** INTERCALATION MATERIALS IN MOLTEN SALTS	129	970

		Vol	Page
THE MEASUREMENT OF LOW LEVELS OF OXYGEN IN GERMANIUM BY THE	**LITHIUM** PRECIPITATION TECHNIQUE	129	226
RE AND ION PAIRING IN COMPLEXES OF POLY(ETHYLENE OXIDE) WITH	**LITHIUM** SALTS VIBRATIONAL SPECTROSCOPIC DETERMINAT	129	1434
SOURCES OF PRESSURE IN	**LITHIUM** THIONYL CHLORIDE BATTERIES	129	2453
URANIUM-ACTIVATED	**LITHIUM** TUNGSTATE PHOSPHORS	129	887
DEFECTS AND DISORDER IN THE FAST-ION ELECTRODE	**LITHIUM-ALUMINUM**	129	2509
N PROPYLENE CARBONATE THE FORMATION OF	**LITHIUM-ALUMINUM** ALLOYS AT AN ALUMINUM ELECTRODE I	129	901
S	**LITHIUM-ALUMINUM** ELECTRODES AT AMBIENT TEMPERATURE	129	1429
ELLS DISCHARGE CHARACTERISTICS OF	**LITHIUM-BORON** ALLOY ANODE IN MOLTEN SALT THERMAL C	129	1168
DSC STUDY OF TWO REACTIONS IN THE	**LITHIUM-BORON** ALLOY SYSTEM	129	1513
IMPEDANCE MEASUREMENTS ON	**LITHIUM-ELECTROLYZED** BOROSILICATE GLASS	129	2617
CTION PATTERN AND DSC CURVES OF THE DISCHARGE PRODUCT OF THE	**LITHIUM/SULFUR** DIOXIDE BATTERY X-RAY DIFFRA	129	565
BASED DEEP U.V. RESIST SYSTEM	**LITHOGRAPHIC** EVALUATION OF AN O-NITROBENZYL ESTER	129	2552
ION OF PURE NOVOLAK CRESOL-FORMALDEHYDE RESINS FOR DEEP U.V.	**LITHOGRAPHY** EVALUAT	129	201
EVALUATING THE LINEWIDTH UNIFORMITY OF AN INTEGRATED CIRCUIT	**LITHOGRAPHY** SYSTEM A CROSS-BRIDGE TEST STRUCTURE F	129	2313
MPEDANCE APPROACH TO NONFARADAIC ELECTROCHEMICAL KINETICS AT	**LIVING** CELL MEMBRANES A TRANSIENT I	129	526
SOLUBILITIES OF OXYGEN IN FUSED	**LI2CO3-K2CO3**	129	1668
THE EFFECT OF SULFUR ON THE ANODIC H2(NI) ELECTRODE IN FUSED	**LI2CO3-K2CO3** AT 650DEGREE C	129	1441
ATED MIXTURES MULTIPLE-ETCHANT	**LOADING** EFFECT AND SILICON ETCHING IN CIF3 AND REL	129	2755
LATED TO TREATMENT OF SILICON NITRIDE COATED WAFERS PRIOR TO	**LOCAL** OXIDATION MOS GATE OXIDE DEFECTS RE	129	1066
POSITED AMORPHOUS SILICON BY CW LASER IRRADIATI ANOMALOUS	**LOCAL** OXIDATION AND RECRYSTALLIZATION OF VACUUM-DE	129	888
TION PROFILES OF ANTIMONY ATOMS DIFFUSED INTO SILICON DUE TO	**LOCAL** PRECIPITATION OBSERVATION OF THE ANOMALOUS C	129	841
LCOGENIDES IN PHOTOELECTROCHEMICAL CELLS	**LOCAL** SPECTRAL RESPONSES OF TRANSITION METAL DICHA	129	1237
GAAS AND OTHER III-V SEMICONDUCTOR DEVICES, INCLUDING INGAAS	**LONG** WAVELENGTH PHOTODETECTORS A PROPOSED HYDROGEN	129	821
MASS TRANSFER AT	**LONGITUDINALLY** VIBRATING VERTICAL ELECTRODES	129	1955
MBIENT DIFFUSION AND SEGREGATION OF	**LOW-DOSE** IMPLANTED BORON IN SILICON UNDER DRY O2 A	129	1097
MODELING OF	**LOW-PRESSURE** CVD PROCESSES	129	2288
NDUSTRIAL PROCESS THE	**LPCVD** POLYSILICON PHOSPHORUS DOPED IN SITU AS AN I	129	1109
AND MAGNESIUM-DOPED P(+)-N INGAAsP/INP HETEROJUNCTIONS	**LPE** GROWTH TECHNIQUES FOR FABRICATING ABRUPT ZINC-	129	2085
DOPING OF GA(1-X)AL(X)AS GROWN BY	**LPE** WITH SI AND GE	129	1563
NEW COUPLING METHOD FOR POLYIMIDE ADHESION TO	**LST** SURFACE	129	2278
A RED PHOSPHOR OF HIGH	**LUMEN** EQUIVALENT, Y2W3012:EU(3+)	129	2296
HOST SENSITIZATION MECHANISM OF EU(3+)	**LUMINESCENCE** IN (Y, IN)203	129	2069
ALIDE PHOSPHORS	**LUMINESCENCE** OF RARE EARTH ACTIVATED LUTETIUM OXYH	129	1552
CONDUCTIVITY, PHOTOCONDUCTIVITY, AND	**LUMINESCENCE** STUDIES ON SOME SILVERSULFAMIDES	129	365
UMINESCENT AND ELECTROLUMINESCENT PROPERTIES OF CADMIUM SULF	**LUMINESCENT** PHOTOELECTROCHEMICAL CELLS VII. PHOTOL	129	772
WHITLOCKITE PHASE IN THE	**LUMINESCENT** SYSTEM SRO-LI2O5-P2O5:MN, CE	129	1373
LUMINESCENCE OF RARE EARTH ACTIVATED	**LUTETIUM** OXYHALIDE PHOSPHORS	129	1552

— M —

AVIOR OF NITRATE AND NITRITE IONS IN THE MOLTEN NAOH-KOH (49	**M/O)** EUTECTIC MIXTURE AT 250 DEGREE C ELECTROCHEMI	129	123
SOLUBILITIES OF	**MAGNESIUM** AND CALCIUM IN SILICON	129	2809
LPE GROWTH TECHNIQUES FOR FABRICATING ABRUPT ZINC- AND	**MAGNESIUM-DOPED** P(+)-N INGAASP/INP HETEROJUNCTIONS	129	2085
PROPERTIES OF GARNET MATERIALS FOR CONTIGUOUS DISK	**MAGNETIC** BUBBLE MEMORY DEVICES	129	423
SUPPRESSION OF THERMAL CONVECTION BY TRANSVERSE	**MAGNETIC** FIELD	129	427
ION LAYER AT VERTICAL ELECTRODES DURING ELECTRODEPOSITION	**MAGNETIC** FIELD EFFECTS ON THE GROWTH OF THE DIFFUS	129	1266
ETCHING EFFECT ON AC POWDER EL PHOSPHOR BRIGHTNESS AND	**MAINTENANCE**	129	2059
E ELECTRICAL MEASUREMENT OF PATTERN PLACEMENT ERRORS OF MASK	**MAKERS** TH	129	1800
ELECTROCHEMICAL PRODUCTION OF	**MANGANIC** SULFATE IN CONCENTRATED H2SO4	129	749
	MARTENSITIC TRANSFORMATION OF GD	129	1145
THE ELECTRICAL MEASUREMENT OF PATTERN PLACEMENT ERRORS OF	**MASK** MAKERS	129	1800
T OF BACK-SIDE OXIDATION ON B AND P DIFFUSION IN SI DIRECTLY	**MASKED** WITH SI3N4 FILMS EFFEC	129	2292
LUTION PHOTOMASKS WITH ION-BOMBARDED POLYMETHYL METHACRYLATE	**MASKING** MEDIUM HIGH RESO	129	827
ATION REACTIONS IN TIS2: CHRONOAMPEROMETRIC DETERMINATION OF	**MASS** AND CHARGE TRANSPORT PROPERTIES OF LIQUID ELE	129	682
CURRENT-VOLTAGE ANALYSIS OF PHOTOELECTROCHEMICAL CELLS UNDER	**MASS** AND LIGHT FLUX VARIATION	129	2029
E COMPOSITION OF BOROSILICATE GLASSES (BSG) BY SECONDARY ION	**MASS** SPECTROMETRY (SIMS) CHARACTERIZATION OF NEAR	129	1819
ON RELATION BETWEEN	**MASS** TRANSFER AND CORROSION IN A TURBULENT PIPE FL	129	276
ELECTRODES	**MASS** TRANSFER AT LONGITUDINALLY VIBRATING VERTICAL	129	1955
WALL	**MASS** TRANSFER IN LAMINAR FLOW CHANNEL WITH POROUS	129	1727
ACK ELECTROCHEMISTRY FOR STEELS IN THE ACTIVE STATE BASED ON IMPEDANCE AND	**MASS** TRANSPORT BY DIFFUSION AND ION MIGRATION A MO	129	1412
	MASS TRANSPORT KINETICS OF NICKEL CADMIUM CELLS	129	289
LECTRODE	**MASS-TRANSFER** STUDY OF CARBON FELT, FLOW-THROUGH E	129	1993
EFFECT OF PROCESSING PARAMETERS ON THE LIFETIME OF (HG,CD)TE	**MATERIAL** THE	129	656
HYDROGENATED A-SI(X)GE(1-X): A POTENTIAL SOLAR CELL	**MATERIAL**	129	2850
ECTRIC LOW ENERGY NITROGEN IMPLANTATION INTO SILICON: ITS	**MATERIAL** COMPOSITION, OXIDATION RESISTANCE, AND EL	129	408
E STRUCTURES ALTERNATE MATRIX	**MATERIAL** FOR MOLTEN CARBONATE FUEL CELL ELECTROLYT	129	979
CAL BEHAVIOR OF GOLD-BASED OHMIC CONTACTS TO THE INP/INGAASP	**MATERIAL** SYSTEM METALLURGI	129	2585
IA ELECTROLYTE COMPARISON OF	**MATERIALS** AS OXYGEN CATALYTIC ELECTRODES ON ZIRCON	129	436
RY DEVICES PROPERTIES OF GARNET	**MATERIALS** FOR CONTIGUOUS DISK MAGNETIC BUBBLE MEMO	129	423
EET CRYSTALS FILAMENT	**MATERIALS** FOR EDGE-SUPPORTED PULLING OF SILICON SH	129	2838
PHTHALOCYANINE CATHODE	**MATERIALS** FOR SECONDARY LITHIUM CELLS	129	5
ELECTROCHEMICAL STUDIES ON LITHIUM INTERCALATION	**MATERIALS** IN MOLTEN SALTS	129	970
SOLUTIONS INITIATION OF CREVICE CORROSION II.	**MATHEMATICAL** MODEL FOR ALUMINUM IN SODIUM CHLORIDE	129	488
S I. POTENTIAL DISTRIBUTION	**MATHEMATICAL** MODEL FOR DESIGN OF BATTERY ELECTRODE	129	688
ANCE CHARACTERISTICS OF THE MOS STRUCTURE WITH VERY THIN SUB	**MATHEMATICAL** MODELING OF THE LOW FREQUENCY CAPACIT	129	2547
CAL STUDIES OF A DEPLETED URANIUM ALLOY TUNGSTEN FIBER METAL	**MATRIX** COMPOSITE CORROSION RATES AND ELECTROCHEMI	129	1398
CTROLYTE STRUCTURES ALTERNATE	**MATRIX** MATERIAL FOR MOLTEN CARBONATE FUEL CELL ELE	129	979
HETEROEPITAXIAL SILICON ON SAPPHIRE BY SCANNING PHOTOVOLTAGE	**MEASUREMENTS** MICROSCALE CHARACTERIZATION OF	129	2609
S OF MOLTEN POTASSIUM POLYSULFIDES FROM OPEN-CIRCUIT VOLTAGE	**MEASUREMENTS** THERMODYNAMIC AND PHYSICAL PROPERTIE	129	2707
OPERTIES OF Y-DOPED CEO2 CERAMICS: COMPARISON OF A-C AND D-C	**MEASUREMENTS** INHOMOGENEITY CONTRIBUTION TO THE ELE	129	2113
E CORROSION IN HIGH-TEMPERATURE AQUEOUS SYSTEMS POTENTIAL/PH	**MEASUREMENTS** IN ALLOY 600 CREVICES AT 288DEGREE C	129	2458
NTS. MOLTEN NANO3-AGNO3 IN POROUS YTTRIA SEM/EDX AND AA	**MEASUREMENTS** OF CURRENT-INDUCED COMPOSITION GRADIE	129	931
PHOTOELECTROCHEMICAL	**MEASUREMENTS** OF H- AND HE-IMPLANTED GAP	129	2735
ELLIPSOMETRIC THICKNESS	**MEASUREMENTS** OF PMMA ON GAAS	129	2273
ELLIPSOMETRY	**MEASUREMENTS** OF POLYCRYSTALLINE SILICON FILMS	129	1347
DETAILED CONTRAST (GAMMA-VALUE)	**MEASUREMENTS** OF POSITIVE ELECTRON RESISTS	129	2576
IMPEDANCE	**MEASUREMENTS** ON LITHIUM-ELECTROLYZED BOROSILICATE	129	2617
GLASS	**MECHANICS** OF ELECTROCHEMICALLY COPRECIPITATED COBA	129	118
LT HYDROXIDE IN NICKEL HYDROXIDE ELECTRODES THE	**MECHANICS** STUDY OF CAUSTIC CRACKING OF MILD STEEL	129	2669
IN HOT NAOH/NA2S SOLUTIONS A FRACTURE	**MECHANISM** A STUDY BY NUCLEAR MICROANALYSIS AND 18O	129	1905
E GROWTH OF ANODIC OXIDE FILMS ON ZIRCONIUM II. OXIDE GROWTH			

		Vol	Page
EVICES A PROPOSED HYDROGENATION/NITRIDIZATION PASSIVATION	**MECHANISM** FOR GAAS AND OTHER III-V SEMICONDUCTOR D	129	821
STUDY OF THE ETCH-STOP	**MECHANISM** IN SILICON	129	2051
HOST SENSITIZATION	**MECHANISM** OF EU(3+) LUMINESCENCE IN (Y, IN)203	129	2069
UMINUM NITRIDE FILMS COMPOSITION, KINETICS, AND	**MECHANISM** OF GROWTH OF CHEMICAL VAPOR-DEPOSITED AL	129	1045
THE	**MECHANISM** OF OXYGEN DIFFUSION IN VITREOUS SIO2	129	357
ODES UNDER CONDITIONS OF OZONE EVOLUTION IN STRONG AC THE	**MECHANISM** OF THE DISINTEGRATION OF LEAD DIOXIDE AN	129	567
ON THE	**MECHANISM** OF THIONYL CHLORIDE REDUCTION	129	1853
ELECTROCHEMICAL STUDIES OF COAL SLURRY OXIDATION	**MECHANISMS**	129	1719
LIZATION AND SURFACE RECOMBINATION ON N-GAP PHOTOELECTRODES:	**MECHANISMS** AND INTERRELATION STUDY OF STABI	129	546
GRAIN-GROWTH	**MECHANISMS** IN POLYSILICON	129	1791
"CA THE ELECTROCHEMISTRY OF HYDROCARBONS IN HF/SBF5: SOME	**MECHANISTIC** CONCLUSIONS CONCERNING THE SUPER ACID	129	1950
FORMATION OF HIGHER OXIDES A	**MECHANISTIC** STUDY OF OXYGEN EVOLUTION ON NICO2O4 I	129	1724
THIS CENTURY OLIN PALLADIUM	**MEDAL** ADDRESS--ELECTRO(ANALYTICAL) CHEMISTRY EARLY	129	59C
-DIAMOND SHAMROCK ELECTROCHEMICAL ENGINEERING AND TECHNOLOGY	**MEDALIST** JOSEPH C. SCHUMACHER--VITTORIO DE NORA	129	395C
THE ELECTROCRYSTALLIZATION OF ZINC FROM ALKALINE	**MEDIA**	129	2654
HOTOMASKS WITH ION-BOMBARDED POLYMETHYL METHACRYLATE MASKING	**MEDIUM** HIGH RESOLUTION P	129	827
HE CU,IN,S SYSTEM AND THE GROWTH OF CUINS2 CRYSTALS FROM THE	**MELT** THE PHASE RELATIONS IN T	129	1570
STABILITY OF IRON(II) AND (III) OXIDES IN LICL-KCL EUTECTIC	**MELT** AT 470DEGREE C REACTIONS OF FORMATION AND	129	1450
N TRANSPORT IN EFG OF SILICO MODELING OF AMBIENT-MENISCUS	**MELT** INTERACTIONS ASSOCIATED WITH CARBON AND OXYGE	129	1356
EFFECT OF	**MELT** STOICHIOMETRY ON TWIN FORMATION IN LEC GAAS	129	2382
PERCENT MN ALLOY EFFECT OF LASER-SURFACE	**MELTING** ON THE ELECTROCHEMICAL BEHAVIOR OF AN AL-1	129	9
SOLUBILITY OF YTTRIUM OXIDE IN NA2SO4 AND NACL	**MELTS**	129	2228
COMPLEXING OF AL(+3) BY S(-2) IONS IN ALKALI HALIDE	**MELTS**	129	2034
HNIQUE DYNAMIC OXYGEN EQUILIBRIUM IN SILICON	**MELTS** DURING CRYSTAL GROWTH BY THE CZOCHRALSKI TEC	129	189
OXIDATION OF SULFUR IN CHLOROALUMINATE	**MELTS** OF INTERMEDIATE PCL	129	2237
LEVATED TEMPERATURES STABILIZED CERAMIC	**MEMBRANE** ELECTRODES FOR THE MEASUREMENT OF PH AT E	129	1221
ON LAYER AND ITS EFFECT ON HYDROXYL TRANSPORT THROUGH NAFION	**MEMBRANE** IN CHLOR-ALKALI CELL THE ANOLYTE DIFFUSI	129	722
LYSIS OF ELECTROSTATIC EFFECTS ON ION TRANSPORT IN ULTRATHIN	**MEMBRANES** THEORETICAL ANA	129	958
ROACH TO NONFARADAIC ELECTROCHEMICAL KINETICS AT LIVING CELL	**MEMBRANES** A TRANSIENT IMPEDANCE APP	129	526
HEMICAL STORAGE CELLS TRANSPORT PROPERTIES OF NAFION	**MEMBRANES** FOR USE IN THREE-ELECTRODE PHOTOELECTROC	129	2469
TRANSPORT PROPERTIES OF NAFION(R)	**MEMBRANES** IN CONCENTRATED SOLUTION ENVIRONMENTS	129	85
TIES OF GARNET MATERIALS FOR CONTIGUOUS DISK MAGNETIC BUBBLE	**MEMORY** DEVICES PROPER	129	423
SCHOTTKY CONTACT FABRICATION FOR GAAS	**MESFET'S**	129	1795
THE SUSPENDED	**MESH** ION SELECTIVE FIELD EFFECT TRANSISTOR	129	2580
UBLE ANODE FOR NICKEL ELECTROWINNING II. MULTILAYER PRECIOUS	**METAL** COATINGS THE DEVELOPMENT OF AN ENERGY-EFFICI	129	522
BLE ANODE FOR NICKEL ELECTROWINNING I. SINGLE LAYER PRECIOUS	**METAL** COATINGS THE DEVELOPMENT OF AN ENERGY-EFFICI	129	515
FERS	**METAL** DECORATED DEFECTS IN HEAT-TREATED SILICON WA	129	1128
S LOCAL SPECTRAL RESPONSES OF TRANSITION	**METAL** DICHALCOGENIDES IN PHOTOELECTROCHEMICAL CELL	129	1237
OCHEMICAL STUDIES OF A DEPLETED URANIUM ALLOY TUNGSTEN FIBER	**METAL** MATRIX COMPOSITE CORROSION RATES AND ELECTR	129	1398
ND IONIC CONDUCTIVITY IN COMPLEXES OF POLYETHERS WITH ALKALI	**METAL** SALTS CONFORMATION AND ION-TRANSPORT MODELS	129	1694
RESISTIVITIES OF THIN FILM TRANSITION	**METAL** SILICIDES	129	293
HYDROGEN ANNEAL EFFECTS ON	**METAL-SEMICONDUCTOR** WORK FUNCTION DIFFERENCE	129	806
TEMPERATURE DEPENDENCE OF THE SENSITIVITIES OF	**METAL-TIO2** JUNCTIONS TO VARIOUS REDUCING GASES	129	444
NG PARAMETERS ON THE ELECTROCHEMICAL CORROSION OF IRON-BORON	**METALLIC** GLASSES EFFECT OF COMPOSITION AND THE PRO	129	695
S TO THE INP/INGAASP MATERIAL SYSTEM	**METALLURGICAL** BEHAVIOR OF GOLD-BASED OHMIC CONTACT	129	2585
ELECTRICAL PROPERTIES OF AL/TI CONTACT	**METALLURGY** FOR VLSI APPLICATION	129	2590
ING THE GROWTH OF GA0.47IN0.53AS ON INP SUBSTRATES USING THE	**METALORGANIC** PROCESS FACTORS INFLUENC	129	383
ANODIC BREAKDOWN OF PASSIVE FILMS ON	**METALS**	129	255
QUESTIONS ON THE KINETICS OF O2 EVOLUTION ON OXIDE-COVERED	**METALS**	129	700
THE STABILITY OF PITTING DISSOLUTION OF	**METALS** IN AQUEOUS SOLUTION	129	260
ANODIC CORROSION AND PASSIVATION BEHAVIOR OF SOME	**METALS** IN MOLTEN LICL-KCL CONTAINING OXIDE IONS	129	1245
EDUCTION OF OXYGEN IN THE DIMINUTION OF ADSORBED BACTERIA ON	**METALS** IN SEAWATER THE USE OF IN SITU ELECTROCHEMI	129	2178
CALIBRATION TESTS OF AN ELECTROCHEMICAL CARBON	**METER**	129	2746
TIVE RESI STUDIES OF METHACRYLONITRILE AND TRICHLOROETHYL	**METHACRYLATE** COPOLYMERS AS ELECTRON SENSITIVE POSI	129	1596
HIGH RESOLUTION PHOTOMASKS WITH ION-BOMBARDED POLYMETHYL	**METHACRYLATE** MASKING MEDIUM	129	827
COPOLYMERS AS ELECTRON SENSITIVE POSITIVE RESI STUDIES OF	**METHACRYLONITRILE** AND TRICHLOROETHYL METHACRYLATE	129	1596
POLAROGRAPHY OF O-MERCAPTOBENZOIC ACID IN AQUEOUS	**METHANOL** AND DIOXANE	129	90
ANODIC OXIDATION OF P-TYPE SILICON IN	**METHANOL** AS COMPARED TO GLYCOL	129	2749
GALVANOSTATIC ANODIZATION OF GAAS IN	**METHANOLIC** KOH	129	1016
ETERS THE GALVANOSTATIC	**METHOD**: ANALYSIS OF ERROR AND COMPUTATION OF PARAM	129	1473
ENCE DISTRIBUTION IN SEMI-INSULATING GAAS GROWN BY CZ AND HB	**METHODS** ONE-DIMENSIONAL PHOTOLUMINESC	129	880
ANALYSIS OF INP SURFACE PREPARED BY VARIOUS CLEANING	**METHODS**	129	447
BLEMS A SURVEY OF NUMERICAL	**METHODS** AND SOLUTIONS FOR CURRENT DISTRIBUTION PRO	129	72
ED SILICON EPITAXIAL LAYERS USING A WET CHEMICAL ETCH	**METHODS** FOR DEFECT EVALUATION OF THIN (100) ORIENT	129	2074
AN AES EVALUATION OF CLEANING AND ETCHING	**METHODS** FOR INSB	129	2752
AND SB203 CHEMICAL	**METHODS** FOR THE DEPOSITION OF THIN FILMS OF SB2SE3	129	1642
SIMS STUDIES OF SEMI-INSULATING INP AMORPHIZED BY	**MG** AND SI	129	1320
VAPOR PHASE EPITAXIAL GROWTH OF	**MGO.AL203**	129	2569
OXIDE	**MICRO-PRECIPITATES** IN AS-GROWN CZ SILICON	129	2780
DIC OXIDE FILMS ON ZIRCONIUM I. INFLUE A STUDY BY NUCLEAR	**MICROANALYSIS** AND 18O TRACING OF THE GROWTH OF ANO	129	1895
DIC OXIDE FILMS ON ZIRCONIUM II. OXIDE A STUDY BY NUCLEAR	**MICROANALYSIS** AND 18O TRACING OF THE GROWTH OF ANO	129	1905
CORROSION RESISTANCE OF	**MICROCRYSTALLINE** STAINLESS STEELS	129	1402
	MICRODEFECTS DURING PHOSPHORUS DIFFUSION	129	667
A METHOD FOR OBSERVING	**MICROMETER-SIZE** DEFECTS IN RESISTS	129	2384
ICON ON SAPPHIRE BY SCANNING PHOTOVOLTAGE MEASUREMENTS	**MICROSCALE** CHARACTERIZATION OF HETEROEPITAXIAL SIL	129	2609
NCLUSIONS IN ELECTRODEPOSITED FILMS BY TRANSMISSION ELECTRON	**MICROSCOPY** DIRECT OBSERVATIONS OF I	129	201C
ELECTRON	**MICROSCOPY** OF WEB-DENDRITIC SILICON	129	1089
RITY CARRIER DIFFUSION LENGTH CHARGE COLLECTION	**MICROSCOPY** ON P-WSE2: RECOMBINATION SITES AND MINO	129	418
POLYSILICON/SIO2 INTERFACE	**MICROTEXTURE** AND DIELECTRIC BREAKDOWN	129	1282
S	**MICROWAVE** PLASMA ETCHING OF SI WITH CF4 AND SF6 GA	129	2764
DECAPSULATION AND PHOTORESIST STRIPPING IN OXYGEN	**MICROWAVE** PLASMAS	129	2537
HE ACTIVE STATE BASED ON MASS TRANSPORT BY DIFFUSION AND ION	**MIGRATION** A MODEL OF CRACK ELECTROCHEMISTRY FOR ST	129	1412
IUM HYDROX KINETICS OF THE HYDROGEN EVOLUTION REACTION ON	**MILD** STEEL AND NICKEL CATHODES IN CONCENTRATED SOD	129	2481
A FRACTURE MECHANICS STUDY OF CAUSTIC CRACKING OF	**MILD** STEEL IN HOT NAOH/NA2S SOLUTIONS	129	2669
THE PREPARATION OF TIO2 ELECTRODES WITH	**MINIMUM** MOTT-SCHOTTKY FREQUENCY DISPERSION	129	2003
	MINIMUM SILICON WAFER THICKNESS FOR ID WAFERING	129	2835
RGE COLLECTION MICROSCOPY ON P-WSE2: RECOMBINATION SITES AND	**MINORITY** CARRIER DIFFUSION LENGTH CHA	129	418
INGAASP/INP PLANAR-STRIPE LASERS WITH CHEMICALLY ETCHED	**MIRRORS**	129	883
CHARACTERISTICS OF INP	**MIS** SCHOTTKY DIODES PREPARED BY PLASMA OXIDATION	129	221

		Vol	Page
TO THE ELECTROCATALYSIS OF OXYG	EPR INVESTIGATION OF FE,	**MIXED** FE-MO, AND MO NAPHTHALOCYANINES. APPLICATION	129	1409
RR	REACTIONS OF SO2(SO3) WITH NIO-NA2SO4 IN NICKEL-SODIUM	**MIXED** SULFATE FORMATION AND LOW TEMPERATURE HOT CO	129	1613
	THE EFFECTS OF	**MIXING** N2 IN CCL4 ON ALUMINUM REACTIVE ION ETCHING	129	2522
TE AND NITRITE IONS IN THE MOLTEN NAOH-KOH (49 M/O) EUTECTIC		**MIXTURE** AT 250 DEGREE C ELECTROCHEMICAL BEHAVIOR O	129	123
CHANT LOADING EFFECT AND SILICON ETCHING IN CIF3 AND RELATED		**MIXTURES** MULTIPLE-ET	129	2755
TCHING OF SILICON AND SILICON DIOXIDE WITH HYDROGEN FLUORIDE		**MIXTURES** PLASMA E	129	1770
	THERMODYNAMICS OF MOLTEN SULFATE	**MIXTURES**	129	1840
ICAL VAPOR DEPOSITION OF ALUMINA FROM ALCL3-H2-CO2 GAS PHASE		**MIXTURES** THERMODYNAMIC AND EXPERIMENTAL ANALYSIS O	129	1367
E MELTING ON THE ELECTROCHEMICAL BEHAVIOR OF AN AL-1 PERCENT		**MN** ALLOY EFFECT OF LASER-SURFAC	129	9
NCL2 BATTERIES	THE SYNTHESIS OF DENSIFIED CMD FROM	**MN-NH4-CARBAMATE** AND ITS DISCHARGE PROPERTIES IN Z	129	2372
	SOME RESTATEMENTS ON THE NATURE AND BEHAVIOR OF	**MNO2** FOR LI BATTERIES	129	1861
	THE CONGRUENT VAPORIZATION OF	**MN2P(S)**	129	2343
TALYSIS OF OXYG	EPR INVESTIGATION OF FE, MIXED FE-MO, AND	**MO** NAPHTHALOCYANINES. APPLICATION TO THE ELECTROCA	129	1409
RE THERMODYNAMIC STUDY OF THE MOLYBDENUM-RICH REGIONS OF THE		**MO-AL** SYSTEM HIGH TEMPERATU	129	2613
TED AMORPHOUS SILICON FIELD EFF	DETERMINATION OF POSITIVE	**MOBILE** ION DENSITY IN SILICON DIOXIDE BY HYDROGENA	129	2770
ELECTROCRYSTALLIZATION I. GENERAL EXPRESSION FOR THE GROWTH		**MODE** OF SURFACE IRREGULARITIES IMAGE ANALYSIS OF M	129	2442
SILICON DETERMINED BY A FOUR-PHASE COMPLEX REFRACTIVE INDEX		**MODEL** OPTICAL CONSTANTS OF ARSENIC AND BORON IMPLA	129	606
N PHOTOELECTROCHEMICAL DEVICES VIA INTERFACE STATES: UNIFIED		**MODEL** AND COMPARISON WITH EXPERIMENTAL DATA CHARGE	129	1003
NATURE OF THE PASSIVE FILM ON IRON III. THE CHEMI-CONDUCTOR		**MODEL** AND FURTHER SUPPORTING EVIDENCE THE	129	921
	A DRY DEVELOPMENT	**MODEL** FOR A POSITIVE ELECTRON BEAM RESIST	129	2598
	INITIATION OF CREVICE CORROSION II. MATHEMATICAL	**MODEL** FOR ALUMINUM IN SODIUM CHLORIDE SOLUTIONS	129	488
ONSE	A POINT DEFECT	**MODEL** FOR ANODIC PASSIVE FILMS III. IMPEDANCE RESP	129	1874
SOURCE	A	**MODEL** FOR BORON DEPOSITION IN SILICON USING A BBR3	129	1592
L DISTRIBUTION	MATHEMATICAL	**MODEL** FOR DESIGN OF BATTERY ELECTRODES I. POTENTIA	129	688
	A SEMICONDUCTOR	**MODEL** FOR THE CATHODIC PASSIVATION OF LEAD DIOXIDE	129	1880
	GENERALIZED	**MODEL** FOR THE CLUSTERING OF AS DOPANTS IN SI	129	1826
ACTIVE STATE BASED ON MASS TRANSPORT BY DIFFUSION AND I	A	**MODEL** OF CRACK ELECTROCHEMISTRY FOR STEELS IN THE	129	1412
	PHENOMENOLOGICAL	**MODEL** OF THE CVD EPITAXIAL REACTOR	129	1627
RRENT-INDUCED COMPOSITION GRADIENTS IN MOLTEN AGNO3-NANO3: A		**MODEL** SYSTEM FOR THE LICL-KCL ELECTROLYTE OF AN LI	129	49
ERMAL SIO2 AT LOW OXIDATION TEMPERATURES	A VISCOUS FLOW	**MODEL** TO EXPLAIN THE APPEARANCE OF HIGH DENSITY TH	129	2594
	APPLICATION OF THE REGULAR ASSOCIATED SOLUTION	**MODEL** TO THE CD-TE AND HG-TE BINARY SYSTEMS	129	2360
OCIATED WITH CARBON AND OXYGEN TRANSPORT IN EFG OF SILICON R		**MODELING** OF AMBIENT-MENISCUS MELT INTERACTIONS ASS	129	1356
		MODELING OF LOW-PRESSURE CVD PROCESSES	129	2288
D ELECTROLYTE		**MODELING** OF POROUS INSERTION ELECTRODES WITH LIQUI	129	1480
RISTICS OF THE MOS STRUCTURE WITH VERY THIN	MATHEMATICAL	**MODELING** OF THE LOW FREQUENCY CAPACITANCE CHARACTE	129	2547
COMPLEXES OF POLYETHERS W	CONFORMATION AND ION-TRANSPORT	**MODELS** FOR THE STRUCTURE AND IONIC CONDUCTIVITY IN	129	1694
	CHEMICAL	**MODIFICATION** OF RETICULATED VITREOUS CARBON	129	2505
TROPHENOL IN THE	SELECTIVE ELECTROSYNTHESES ON CHEMICALLY	**MODIFIED** ELECTRODE IV. SELECTIVE REDUCTION OF O-NI	129	1681
HIP REPORT--FOURIER TRANSFORM INFRARED STUDIES OF CHEMICALLY		**MODIFIED** ELECTRODE SURFACES THE JOSEPH W. RICHARDS	129	300C
) BOUND TO POLYELECTROLYTES ON ELECTRODES AND THE USE OF THE		**MODIFIED** ELECTRODES FOR AN ELECTROCHROMIC DISPLAY	129	762
N METHOD	ELECTROCHEMISTRY OF PRUSSIAN BLUE	**MODIFIED** ELECTRODES: AN ELECTROCHEMICAL PREPARATIO	129	1498
PHOTOELECTROCHEMICAL GENERATION OF CHLORINE ON CATALYTICALLY		**MODIFIED** N-SILICON/INDIUM TIN OXIDE ANODES	129	1934
HOLOGY IN ALKALINE SOLUTIONS I. STUDY OF ALTERNATING VOLTAGE		**MODULATION** ON A ROTATIING DISK ELECTRODE ZINC ELEC	129	2677
ATE TEMPERATURE ON THE MORPHOLOGY OF AL(X)GA(1-X)AS GROWN BY		**MOLECULAR** BEAM EPITAXY INFLUENCE OF SUBSTR	129	824
	GE INCORPORATION IN GAAS GROWN BY	**MOLECULAR** BEAM EPITAXY: A THERMODYNAMIC STUDY	129	2108
SPECTRA OF FERROUS AND FERRIC OXIDES AND THE PASSIVE FILM: A		**MOLECULAR** ORBITAL STUDY OPTICAL	129	2169
GH RESOLUTION ELECTRON BEAM NEGATIVE RESIST WITH VERY NARROW		**MOLECULAR** WEIGHT DISTRIBUTIONS HI	129	663
L ELECTROLYTE OF	CURRENT-INDUCED COMPOSITION GRADIENTS IN	**MOLTEN** AGNO3-NANO3: A MODEL SYSTEM FOR THE LICL-KC	129	49
	THE EFFECT OF THICKNESS ON THE PERFORMANCE OF	**MOLTEN** CARBONATE FUEL CELL CATHODES	129	2711
	ALTERNATE MATRIX MATERIAL FOR	**MOLTEN** CARBONATE FUEL CELL ELECTROLYTE STRUCTURES	129	979
	THE SPECIFIC CONDUCTANCE OF	**MOLTEN** CARBONATE FUEL CELL TILES	129	1745
	THE THERMODYNAMICS OF ELECTROLYTE DISTRIBUTION IN	**MOLTEN** CARBONATE FUEL CELLS	129	942
ANODIC CORROSION AND PASSIVATION BEHAVIOR OF SOME METALS IN		**MOLTEN** LICL-KCL CONTAINING OXIDE IONS	129	1245
ND AA MEASUREMENTS OF CURRENT-INDUCED COMPOSITION GRADIENTS.		**MOLTEN** NANO3-AGNO3 IN POROUS YTTRIA SEM/EDX A	129	931
ELECTROCHEMICAL BEHAVIOR OF NITRATE AND NITRITE IONS IN THE		**MOLTEN** NAOH-KOH (49 M/O) EUTECTIC MIXTURE AT 250 D	129	123
LTAGE MEASUREMEN	THERMODYNAMIC AND PHYSICAL PROPERTIES OF	**MOLTEN** POTASSIUM POLYSULFIDES FROM OPEN-CIRCUIT VO	129	2707
ROSCOPIC STUDIES OF 9,10-ANTHRAQUINONE IN A ROOM-TEMPERATURE		**MOLTEN** SALT ELECTROCHEMICAL AND SPECT	129	2488
DIES OF LI-GE ALLOYS: APPLICATION TO NEGATIVE ELECTRODES FOR		**MOLTEN** SALT BATTERIES THERMODYNAMIC STU	129	246
BONS AND DECAMETHYL FERROCENE AT THE N-GAAS/ROOM TEMPERATURE		**MOLTEN** SALT ELECTROLYTE INTERFACE PHOTOELECTROCHEM	129	560
ECTROCHEMICAL CHARACTERIZATION OF THE N-INP/ROOM TEMPERATURE		**MOLTEN** SALT ELECTROLYTE INTERFACE PHOTOEL	129	2009
DISCHARGE CHARACTERISTICS OF LITHIUM-BORON ALLOY ANODE IN		**MOLTEN** SALT THERMAL CELLS	129	1168
LECTROCHEMICAL STUDIES ON LITHIUM INTERCALATION MATERIALS IN		**MOLTEN** SALTS E	129	970
EXPLORATORY STUDIES ON ELECTROLYSIS OF AIN DISSOLVED IN		**MOLTEN** SALTS	129	102
	THERMODYNAMICS OF	**MOLTEN** SULFATE MIXTURES	129	1840
AND BY COEVAPORATION AFT	CRYSTALLINE STRUCTURE CHANGES OF	**MOLYBDENUM** SILICIDE FILMS DEPOSITED BY SPUTTERING	129	1527
	HIGH TEMPERATURE THERMODYNAMIC STUDY OF THE	**MOLYBDENUM-RICH** REGIONS OF THE MO-AL SYSTEM	129	2613
MPERATURE PH SENSOR AS A "PSEUDO-REFERENCE ELECTRODE" IN THE		**MONITORING** OF CORROSION AND REDOX POTENTIALS AT 28	129	1445
	IN SITU	**MONITORING** OF LIQUID PHASE ELECTROEPITAXIAL GROWTH	129	2095
SEMI-INFINITE DIFFUSION TO ELECTRODES CONSISTING OF TWO OR		**MORE** INTERSECTING PLANES	129	128
CRYSTALLIZATION II. EXPERIMENTAL DEMONS	IMAGE ANALYSIS OF	**MORPHOLOGICAL** INSTABILITY IN GALVANOSTATIC ELECTRO	129	2447
CRYSTALLIZATION I. GENERAL EXPRESSION F	IMAGE ANALYSIS OF	**MORPHOLOGICAL** INSTABILITY IN GALVANOSTATIC ELECTRO	129	2442
TING OF DILUTE ALUMINUM ALLOYS IN SEAWATER		**MORPHOLOGICAL** STUDIES OF OCCLUDED CELLS IN THE PIT	129	137
NATING VOLTAGE MODULATION ON A ROTATIING D	ZINC ELECTRODE	**MORPHOLOGY** IN ALKALINE SOLUTIONS I. STUDY OF ALTER	129	2677
AM EPITAXY	INFLUENCE OF SUBSTRATE TEMPERATURE ON THE	**MORPHOLOGY** OF AL(X)GA(1-X)AS GROWN BY MOLECULAR BE	129	824
DEPOSITED N-CDSE IN LIQUID JUNCTION SOLAR CELLS		**MORPHOLOGY**, PROPERTIES, AND PERFORMANCE OF ELECTRO	129	2016
	EFFECT OF THERMALLY NITRIDED SIO2 (NITROXIDE) ON	**MOS** CHARACTERISTICS	129	184
	NUMERICAL SIMULATION OF GATE OXIDE THINNING IN	**MOS** DEVICES	129	831
ICON NITRIDE COATED WAFERS PRIOR TO LOCAL OXIDATION		**MOS** GATE OXIDE DEFECTS RELATED TO TREATMENT OF SIL	129	1066
LING OF THE LOW FREQUENCY CAPACITANCE CHARACTERISTICS OF THE		**MOS** STRUCTURE WITH VERY THIN SUBSTRATE MATHEMATICA	129	2547
ETHOD FOR MEASUREMENT OF THE CHANNEL LENGTH OF SHORT CHANNEL		**MOSFET'S** A NOVEL M	129	1338
TRAPPED CHARGE GENERATION AND ELECTRON TRAPPING KINETICS IN		**MOSFET'S** DUE TO SUBSTRATE HOT-ELECTRON INJECTION I	129	1760
IBITION OF ZINC BY COBALT IONS		**MOSSBAUER** SPECTROSCOPIC STUDY OF THE CORROSION INH	129	1658
UCTOR ELECTRODES XLV. PHOTOELECTROCHEMISTRY OF N- AND P-TYPE		**MOTE2** IN AQUEOUS SOLUTIONS SEMICOND	129	2224
REVEALED BY CATHODOLUMINESCENCE	AN EXPERIMENTAL STUDY OF	**MOTION** OF ELECTRONS AND HOLES IN Y2O2S CRYSTAL AS	129	1535
	THE PREPARATION OF TIO2 ELECTRODES WITH MINIMUM	**MOTT-SCHOTTKY** FREQUENCY DISPERSION	129	2003
NGLE CRYSTAL RUTILE ELECTRODES		**MOTT-SCHOTTKY** PLOTS AND FLATBAND POTENTIALS FOR SI	129	1973
	ZONE-MELTING RECRYSTALLIZATION OF SI FILMS WITH A	**MOVEABLE-STRIP-HEATER** OVEN	129	2812
MICAL RESPONSE OF SOME LAYERED CHALCOGENOPHOSPHATE COMPOUNDS		**(MPX3)** PHOTOELECTROCHE	129	237
ERGY-EFFICIENT INSOLUBLE ANODE FOR NICKEL ELECTROWINNING II.		**MULTILAYER** PRECIOUS METAL COATINGS THE DEVELOPMENT	129	522

		Vol	Page
REE GROOVING METHOD FOR REVEALING THE QUALITY OF INP/INGAASP	**MULTILAYER** STRUCTURE A SIMPLE DAMAGE-F	129	2082
FLOW-THROUGH POROUS ELECTRODES THE EFFECT OF	**MULTIPLE** CURRENT COLLECTORS ON THE PERFORMANCE OF	129	991
G IN CIF3 AND RELATED MIXTURES	**MULTIPLE-ETCHANT** LOADING EFFECT AND SILICON ETCHIN	129	2755
: OXYGEN AND INDUCED DEFECT BEHAVIOR	**MULTISTEP** REPEATED ANNEALING FOR CZ-SILICON WAFERS	129	2089

— N —

SEMICONDUCTOR ELECTRODES XLV. PHOTOELECTROCHEMISTRY OF	**N-** AND P-TYPE MOTE2 IN AQUEOUS SOLUTIONS	129	2224
PHOTOELECTROCHEMISTRY OF	**N-** AND P-TYPE SILICON IN ACETONITRILE	129	1982
LT AN ELECTROCHEMICAL AND INFRARED STUDY OF CHLORANIL IN	**N-BUTYLPYRIDINIUM** CHLORIDE:ALUMINUM CHLORIDE IONIC	129	2739
ERNARY CHALCOGENIDE-BASED PHOTOELECTROCHEMICAL CELLS II. THE	**N-CDIN2SE4/AQUEOUS** POLYSULFIDE SYSTEM T	129	1506
PHOTOANODIC DISSOLUTION OF	**N-CDS** STUDIED BY ROTATING RING-DISK ELECTRODES	129	149
MORPHOLOGY, PROPERTIES, AND PERFORMANCE OF ELECTRODEPOSITED	**N-CDSE** IN LIQUID JUNCTION SOLAR CELLS	129	2016
ETONITRILE ELECTROCHEMICAL PHOTOVOLTAIC CELLS BASED ON	**N-GAAS** AND THE TRIIODIDE/IODIDE REDOX COUPLE IN AC	129	1705
ION OF AROMATIC HYDROCARBONS AND DECAMETHYL FERROCENE AT THE	**N-GAAS/ROOM** TEMPERATURE MOLTEN SALT ELECTROLYTE IN	129	560
N STUDY OF STABILIZATION AND SURFACE RECOMBINATION ON	**N-GAP** PHOTOELECTRODES: MECHANISMS AND INTERRELATIO	129	546
ERROCENE/FERRICENIUM REDOX COUPLE AT PLATINUM, N-SILICON AND	**N-INDIUM** PHOSPHIDE ELECTRODES THE ELECTROCHEMISTRY	129	1987
ERFACE PHOTOELECTROCHEMICAL CHARACTERIZATION OF THE	**N-INP/ROOM** TEMPERATURE MOLTEN SALT ELECTROLYTE INT	129	2009
	N-MOSE2 PHOTOELECTROCHEMICAL HALOGEN STORAGE CELL	129	233
PHOTOELECTROCHEMICAL BEHAVIOR OF	**N-SI** ELECTRODES PROTECTED WITH PT-POLYPYRROLE	129	1737
F AN AQUEOUS FERROCENE/FERRICENIUM REDOX COUPLE AT PLATINUM,	**N-SILICON** AND N-INDIUM PHOSPHIDE ELECTRODES THE EL	129	1987
TROCHEMIC SEMICONDUCTOR ELECTRODES XLVI. STABILIZATION OF	**N-SILICON** ELECTRODES IN AQUEOUS SOLUTION PHOTOELEC	129	1647
TROCHEMICAL GENERATION OF CHLORINE ON CATALYTICALLY MODIFIED	**N-SILICON/INDIUM** TIN OXIDE ANODES PHOTOELEC	129	1934
THERMODYNAMIC AND PHOTOELECTROCHEMICAL BEHAVIOR OF THE	**N-TIO2** ELECTRODE IN FLUORIDE-CONTAINING SOLUTIONS	129	2132
ACTIONS BETWEEN PHOTOINDUCED AND DARK CHARGE TRANSFER ACROSS	**N-TIO2-AQUEOUS** ELECTROLYTE INTERFACE INTER	129	1240
ES IN AQUEOUS AND NONAQUEOUS ELECTROL CHARACTERIZATION OF	**N-TYPE** SEMICONDUCTING TUNGSTEN DISULFIDE PHOTOANOD	129	1461
SEMICONDUCTOR ELECTRODES XLI. IMPROVEMENT OF PERFORMANCE OF	**N-WSE2** ELECTRODES BY ELECTROCHEMICAL POLYMERIZATIO	129	265
SIS OF OXYGEN CATHODIC REDUCTION BY ADSORBED IRON(111)-TETRA	**(N,N,N-TRIMETHYLANILINIUM)** PORPHYRIN ON GLASSY CAR	129	2247
SOLUBILITY OF YTTRIUM OXIDE IN NA2SO4 AND	**NACL** MELTS	129	2228
DIFFUSION LAYER AND ITS EFFECT ON HYDROXYL TRANSPORT THROUGH	**NAFION** MEMBRANE IN CHLOR-ALKALI CELL THE ANOLYTE	129	722
LECTROCHEMICAL STORAGE CELLS TRANSPORT PROPERTIES OF	**NAFION** MEMBRANES FOR USE IN THREE-ELECTRODE PHOTOE	129	2469
ONMENTS TRANSPORT PROPERTIES OF	**NAFION(R)** MEMBRANES IN CONCENTRATED SOLUTION ENVIR	129	85
EASUREMENTS OF CURRENT-INDUCED COMPOSITION GRADIENTS. MOLTEN	**NANO3-AGNO3** IN POROUS YTTRIA SEM/EDX AND AA M	129	931
OCHEMICAL BEHAVIOR OF NITRATE AND NITRITE IONS IN THE MOLTEN	**NAOH-KOH** (49 M/O) EUTECTIC MIXTURE AT 250 DEGREE C	129	123
URE MECHANICS STUDY OF CAUSTIC CRACKING OF MILD STEEL IN HOT	**NAOH/NA2S** SOLUTIONS A FRACT	129	2669
YSIS OF OXYG EPR INVESTIGATION OF FE, MIXED FE-MO, AND MO	**NAPHTHALOCYANINES.** APPLICATION TO THE ELECTROCATAL	129	1409
HIGH RESOLUTION ELECTRON BEAM NEGATIVE RESIST WITH VERY	**NARROW** MOLECULAR WEIGHT DISTRIBUTIONS	129	663
NS INVOLVED IN THE INITIATION OF HOT CORROSION OF B-1900 AND	**NASA-TRW** VIA CHEMICAL REACTIO	129	571
INTERFEROMETRIC STUDY OF COMBINED FORCED AND	**NATURAL** CONVECTION	129	2201
SOLUBILITY OF YTTRIUM OXIDE IN	**NA2SO4** AND NACL MELTS	129	2228
BSG) BY SECONDARY ION MASS SPECTROMET CHARACTERIZATION OF	**NEAR** SURFACE COMPOSITION OF BOROSILICATE GLASSES (	129	1819
THERMOMECHANICAL BEHAVIOR OF SIMULATED	**NEGATIVE** ELECTRODES FOR LI-AL/FES BATTERY CELLS	129	2265
THERMODYNAMIC STUDIES OF LI-GE ALLOYS: APPLICATION TO	**NEGATIVE** ELECTRODES FOR MOLTEN SALT BATTERIES	129	246
BSTRATE RESOLUTION LIMIT OF	**NEGATIVE** ELECTRON RESIST EXPOSED ON A THIN FILM SU	129	1831
ESR STUDIES OF	**NEGATIVE** ELECTRON RESISTS PGMA AND PST	129	1070
DISTRIBUTIONS HIGH RESOLUTION ELECTRON BEAM	**NEGATIVE** RESIST WITH VERY NARROW MOLECULAR WEIGHT	129	663
INITIAL OXIDE GROWTH RATE ON	**NEWLY** GENERATED SURFACES	129	2500
PLANAR PLASMA ETCHING OF POLYSILICON USING CCL4 AND	**NF3**	129	795
A TRANSITION IN THE KINETICS OF THE	**NI(OH)2/NIOOH** ELECTRODE REACTION	129	983
A STUDY OF THE IRON ELECTRODE STRUCTURE OF	**NI-FE** CELL	129	1173
VIBRATING ZINC ELECTRODES IN	**NI/ZN** BATTERIES	129	913
IT AND FLOW STREAK FORMATION DURING HIGH RATE DISSOLUTION OF	**NICKEL** P	129	1889
MEASUREMENT OF ELECTROLESS PLATING RATE FOR COPPER AND	**NICKEL** BATHS BY COULOSTATIC METHOD	129	2183
IMPEDANCE AND MASS TRANSPORT KINETICS OF	**NICKEL** CADMIUM CELLS	129	289
INETICS OF THE HYDROGEN EVOLUTION REACTION ON MILD STEEL AND	**NICKEL** CATHODES IN CONCENTRATED SODIUM HYDROXIDE S	129	2481
VISIBLE LIGHT CONVERSION AT ONE-DIMENSIONAL	**NICKEL** DITHIOLENE COMPLEX ELECTRODE	129	2378
DEFECT STRUCTURE IN	**NICKEL** ELECTRODEPOSITS	129	45
THE DEVELOPMENT OF AN ENERGY-EFFICIENT INSOLUBLE ANODE FOR	**NICKEL** ELECTROWINNING I. SINGLE LAYER PRECIOUS MET	129	515
THE DEVELOPMENT OF AN ENERGY-EFFICIENT INSOLUBLE ANODE FOR	**NICKEL** ELECTROWINNING II. MULTILAYER PRECIOUS META	129	522
FES CELLS EVALUATION OF	**NICKEL** FOR POSITIVE ELECTRODE COMPONENTS IN LI-AL/	129	496
NICS OF ELECTROCHEMICALLY COPRECIPITATED COBALT HYDROXIDE IN	**NICKEL** HYDROXIDE ELECTRODES THE MECHA	129	118
ON DIFFERENT CONDUCTING THE ELECTROCHEMICAL RESPONSE OF	**NICKEL** HYDROXIDE FORMED BY COLLOIDAL PRECIPITATION	129	301
THE A-C RESPONSE OF	**NICKEL** OXIDE ELECTRODE FILMS	129	535
TROLYSIS: CORROSION RESISTANCE POROUS	**NICKEL-COATED** STEEL ANODES FOR ALKALINE WATER ELEC	129	310
ERATURE HOT CORR REACTIONS OF SO2(SO3) WITH NIO-NA2SO4 IN	**NICKEL-SODIUM** MIXED SULFATE FORMATION AND LOW TEMP	129	1613
LANTHANUM	**NICKELATE** AS ELECTROCATALYST: OXYGEN EVOLUTION	129	2391
XIDE: ION-PAIR, PROTONATION, ELECTROCHEMICAL REDUCTION OF	**NICOTINAMIDE** ADENINE DINUCLEOTIDE IN DIMETHYLSULFO	129	1960
A MECHANISTIC STUDY OF OXYGEN EVOLUTION ON	**NICO2O4** I. FORMATION OF HIGHER OXIDES	129	1724
N AND LOW TEMPERATURE HOT CORR REACTIONS OF SO2(SO3) WITH	**NIO-NA2SO4** IN NICKEL-SODIUM MIXED SULFATE FORMATIO	129	1613
FUSION METHOD ENTHALPIES OF FORMATION OF	**NIOBIUM** ALUMINIDES AS DETERMINED BY THE KNUDSEN EF	129	1608
9 M/O) EUTECTIC MIXTURE AT 25 ELECTROCHEMICAL BEHAVIOR OF	**NITRATE** AND NITRITE IONS IN THE MOLTEN NAOH-KOH (4	129	123
CORROSION CHARACTERISTICS OF SOME ALUMINUM ALLOYS IN	**NITRIC** ACID	129	1869
GROWTH KINETICS OF SILICON THERMAL	**NITRIDATION**	129	1559
	NITRIDATION OF SILICON AND OXIDIZED-SILICON	129	2102
HYDROGEN-IMPLANTED SILICON	**NITRIDE**	129	1786
MOS GATE OXIDE DEFECTS RELATED TO TREATMENT OF SILICON	**NITRIDE** COATED WAFERS PRIOR TO LOCAL OXIDATION	129	1066
AND MECHANISM OF GROWTH OF CHEMICAL VAPOR-DEPOSITED ALUMINUM	**NITRIDE** FILMS COMPOSITION, KINETICS,	129	1045
EFFECT OF THERMALLY	**NITRIDED** SIO2 (NITROXIDE) ON MOS CHARACTERISTICS	129	184
TIC MIXTURE AT 25 ELECTROCHEMICAL BEHAVIOR OF NITRATE AND	**NITRITE** IONS IN THE MOLTEN NAOH-KOH (49 M/O) EUTEC	129	123
OF THE DIFFUSION CURRENT ON THE DEGREE OF POLYMERIZATION OF	**NITROCELLULOSE** IN ACETONE-ISOPROPYL ALCOHOL DEPEND	129	1520
OMPOSITION, OXIDATION RESISTANCE, AND ELECTRIC LOW ENERGY	**NITROGEN** IMPLANTATION INTO SILICON: ITS MATERIAL C	129	408
ILICON OXIDES WITH AMMONIA AND TRIFLUOROMETHANE. THE ROLE OF	**NITROGEN** IN THE DISCHARGE REACTIVE ION ETCHING OF	129	1036
ROOM TEMPERATURE FORMATION OF SI-NITRIDE FILMS BY LOW ENERGY	**NITROGEN** ION IMPLANTATION INTO SILICON	129	379
THE OXIDATION INHIBITION IN	**NITROGEN-IMPLANTED** SILICON	129	1803
EFFECT OF THERMALLY NITRIDED SIO2	**(NITROXIDE)** ON MOS CHARACTERISTICS	129	184
EQUILIBRIUM	**NOISE** IN ION SELECTIVE FIELD EFFECT TRANSISTORS	129	2306
STRIATIONS OF KINETIC ORIGIN INDUCED DURING	**NON-STEADY-STATE** SOLIDIFICATION	129	2355
ROCHEMICAL SOLAR CELLS WITH LAYER-TYPE SEMICONDUCTOR ANODES.	**NONAQUEOUS** ELECTROLYTE CELLS ELECT	129	1155
SEMICONDUCTING TUNGSTEN DISULFIDE PHOTOANODES IN AQUEOUS AND	**NONAQUEOUS** ELECTROLYTE SOLUTIONS. PHOTO-OXIDATION	129	1461
L MEMBRANES A TRANSIENT IMPEDANCE APPROACH TO	**NONFARADAIC** ELECTROCHEMICAL KINETICS AT LIVING CEL	129	526

		Vol	Page
OF HYDRATED ALUMINUM OXIDE BY STAINING WITH FLUORESCING AND	**NONFLUORESCING** DYES VISUAL DETECTION	129	1517
PURITIES ON DILUTE ALLOYS PARABOLIC GROWTH OF	**NONUNIFORMLY** DOPED OXIDES CONTAINING ALIOVALENT IM	129	622
AND TECHNOLOGY MEDALIST JOSEPH C. SCHUMACHER--VITTORIO DE	**NORA-DIAMOND** SHAMROCK ELECTROCHEMICAL ENGINEERING	129	395C
ITHOGRAPHY EVALUATION OF PURE	**NOVOLAK** CRESOL-FORMALDEHYDE RESINS FOR DEEP U.V. L	129	201
H OF ANODIC OXIDE FILMS ON ZIRCONIUM I. INFLUE A STUDY BY	**NUCLEAR** MICROANALYSIS AND 18O TRACING OF THE GROWT	129	1895
H OF ANODIC OXIDE FILMS ON ZIRCONIUM II. OXIDE A STUDY BY	**NUCLEAR** MICROANALYSIS AND 18O TRACING OF THE GROWT	129	1905
TAL SILICON FILMS ON AMORPHOUS INSULATORS: GROWTH BY LATERAL	**NUCLEATED** EPITAXY USING SCANNING LASER AND ELECTRO	129	2802
TRANSPORT	**NUMBER** GRADIENTS AND SOLID ELECTROLYTE DEGRADATION	129	752
OPTIMIZATION OF ELECTROLYTIC CELLS HAVING LARGE	**NUMBERS** OF VARIABLES	129	1225
TES TRANSFERENCE	**NUMBERS** OF ZINC IN ZINC-CHLORIDE BATTERY ELECTROLY	129	907
BUTION PROBLEMS A SURVEY OF	**NUMERICAL** METHODS AND SOLUTIONS FOR CURRENT DISTRI	129	72
DEVICES	**NUMERICAL** SIMULATION OF GATE OXIDE THINNING IN MOS	129	831
THE EFFECTS OF MIXING	**N2** IN CCL4 ON ALUMINUM REACTIVE ION ETCHING	129	2522

— O —

XANE POLAROGRAPHY OF	**O-MERCAPTOBENZOIC** ACID IN AQUEOUS METHANOL AND DIO	129	90
LITHOGRAPHIC EVALUATION OF AN	**O-NITROBENZYL** ESTER BASED DEEP U.V. RESIST SYSTEM	129	2552
ON CHEMICALLY MODIFIED ELECTRODE IV. SELECTIVE REDUCTION OF	**O-NITROPHENOL** IN THE PRESENCE OF P-NITROPHENOL WIT	129	1681
CAL ENERGY STORAGE II. COBALT(III)-COBALT(II) COMPLEXES WITH	**O-PHENANTHROLINE** AND RELATED LIGANDS SOLUTION REDO	129	61
CE OF N-WSE2 ELECTRODES BY ELECTROCHEMICAL POLYMERIZATION OF	**O-PHENYLENEDIAMINE** AT SURFACE IMPERFECTIONS SEMICO	129	265
URFACES	**OBSERVATIONS** OF FLAWS ON PRECONDITIONED ALUMINUM S	129	1515
MS BY TRANSMISSION ELECTRON MICROSCOPY DIRECT	**OBSERVATIONS** OF INCLUSIONS IN ELECTRODEPOSITED FIL	129	201C
LLOYS IN SEAWATER MORPHOLOGICAL STUDIES OF	**OCCLUDED** CELLS IN THE PITTING OF DILUTE ALUMINUM A	129	137
AL-0.9PERCENT SI/SI	**OHMIC** CONTACTS TO SHALLOW JUNCTIONS	129	1335
METALLURGICAL BEHAVIOR OF GOLD-BASED	**OHMIC** CONTACTS TO THE INP/INGAASP MATERIAL SYSTEM	129	2585
CHEMISTRY EARLY THIS CENTURY	**OLIN** PALLADIUM MEDAL ADDRESS--ELECTRO(ANALYTICAL)	129	59C
IDATION OF GERMANIUM SURFACES AT PRESSURES MUCH GREATER THAN	**ONE** ATMOSPHERE THE OX	129	1845
E VISIBLE LIGHT CONVERSION AT	**ONE-DIMENSIONAL** NICKEL DITHIOLENE COMPLEX ELECTROD	129	2378
SEMI-INSULATING GAAS GROWN BY CZ AND HB METHODS	**ONE-DIMENSIONAL** PHOTOLUMINESCENCE DISTRIBUTION IN	129	880
FORMATION ON LITHIUM IN PROPYLENE CARBONATE SOLUTIONS UNDER	**OPEN-CIRCUIT** CONDITIONS ELECTROCHEMICAL STUDIES OF	129	1422
ONIC CONDUCTION IN ANODIC TANTALUM PENTOXIDE FILMS USING THE	**OPEN-CIRCUIT** TRANSIENT METHOD AN EXPERIMENTAL INVE	129	2513
ND PHYSICAL PROPERTIES OF MOLTEN POTASSIUM POLYSULFIDES FROM	**OPEN-CIRCUIT** VOLTAGE MEASUREMENTS THERMODYNAMIC A	129	2707
AN	**OPEN-TUBE** METHOD FOR DIFFUSION OF ZINC INTO GAAS	129	1567
BATTERY IN THE PRESENCE OF LEAD	**OPERATING** PERFORMANCE OF AN FE-TI STATIONARY REDOX	129	2502
	OPTICAL ABSORPTION OF THIN SIPOS FILMS	129	197
S UNDER HEAVY LI ION INJECTION	**OPTICAL** CHARACTERISTICS OF WO3 ELECTROCHROMIC CELL	129	2633
SILICON DETERMINED BY A FOUR-PHASE COMPLEX REFRACTIVE INDEX	**OPTICAL** CONSTANTS OF ARSENIC AND BORON IMPLANTS IN	129	606
THE RELATION BETWEEN ETCH RATE AND	**OPTICAL** EMISSION INTENSITY IN PLASMA ETCHING	129	1325
FILMS STRUCTURAL AND	**OPTICAL** PROPERTIES OF SOLUTION GROWN CDSE(1-X)S(X)	129	99
HE PASSIVE FILM: A MOLECULAR ORBITAL STUDY	**OPTICAL** SPECTRA OF FERROUS AND FERRIC OXIDES AND T	129	2169
	OPTICAL STUDIES OF THE ANODIC PASSIVATION OF TIN	129	1886
MBERS OF VARIABLES	**OPTIMIZATION** OF ELECTROLYTIC CELLS HAVING LARGE NU	129	1225
	OPTIMIZATION OF ISOTHERMAL GROWTH OF HGCDTE LAYERS	129	1103
A LINE EMISSION PENETRATION PHOSPHOR PREPARATION,	**OPTIMIZATION,** AND CATHODOLUMINESCENT PROPERTIES OF	129	1540
FERROUS AND FERRIC OXIDES AND THE PASSIVE FILM: A MOLECULAR	**ORBITAL** STUDY OPTICAL SPECTRA OF	129	2169
PHOTOELECTROCHEMICAL PROPERTIES OF SNO2 FILMS PREPARED FROM	**ORGANIC** RESINATE SOLUTION STUDIES ON	129	1501
ICS TARNISHING OF SILVER BY	**ORGANIC** SULFUR VAPORS: RATES AND FILM CHARACTERIST	129	33
THE USE OF S2CL2 FOR DOPING POLY-GAAS FILMS GROWN BY THE	**ORGANOMETALLIC** PROCESS	129	2778
P GROWN BY LIQUID PHASE EPITAXY SUBSTRATE	**ORIENTATION** DEPENDENCE OF GROWTH RATE OF INGAAS/IN	129	2603
AN ETCH PIT TECHNIQUE FOR ANALYZING CRYSTALLOGRAPHIC	**ORIENTATION** IN SI FILMS	129	1848
ICAL ETCH METHODS FOR DEFECT EVALUATION OF THIN (100)	**ORIENTED** SILICON EPITAXIAL LAYERS USING A WET CHEM	129	2074
ION STRIATIONS OF KINETIC	**ORIGIN** INDUCED DURING NON-STEADY-STATE SOLIDIFICAT	129	2355
IDENTIFICATION AND ELIMINATION OF GATE OXIDE DEFECT	**ORIGIN** PRODUCED DURING SELECTIVE FIELD OXIDATION	129	800
ERFACIAL PROPERTIES OF INORGANIC SOLUTES RELEVANT TO REVERSE	**OSMOSIS** SEPARATIONS USE OF LIQUID CHROMATOGRAPHY F	129	1485
DROGENATION/NITRIDIZATION PASSIVATION MECHANISM FOR GAAS AND	**OTHER** III-V SEMICONDUCTOR DEVICES, INCLUDING INGAA	129	821
G RECRYSTALLIZATION OF SI FILMS WITH A MOVEABLE-STRIP-HEATER	**OVEN** ZONE-MELTIN	129	2812
ELECTROCHEMICAL TEST TO EVALUATE PASSIVATION LAYERS:	**OVERCOATS** OF SI IN INK	129	2174
ZATION OF REACTIONS AND PRODUCTS OF THE DISCHARGE AND FORCED	**OVERDISCHARGE** OF LI/SO2 CELLS CHARACTERI	129	1857
LATERAL EPITAXIAL	**OVERGROWTH** OF SILICON ON SIO2	129	2303
CDS ELECTRODES THE EFFECT OF SPUTTERED RUO2	**OVERLAYERS** ON THE PHOTOELECTROCHEMICAL BEHAVIOR OF	129	1733
SILICON OXIDATION STUDIES: MEASUREMENT OF THE DIFFUSION OF	**OXIDANT** IN SIO2 FILMS	129	413
HARACTERISTICS OF INP MIS SCHOTTKY DIODES PREPARED BY PLASMA	**OXIDATION** C	129	221
ED DIFFUSION OF ARSENIC AND PHOSPHORUS IN SILICON BY THERMAL	**OXIDATION** THE ENHANC	129	644
DEFORMATION OF SILICON WAFERS BY THERMAL	**OXIDATION**	129	2076
OF GATE OXIDE DEFECT ORIGIN PRODUCED DURING SELECTIVE FIELD	**OXIDATION** IDENTIFICATION AND ELIMINATION	129	800
TO TREATMENT OF SILICON NITRIDE COATED WAFERS PRIOR TO LOCAL	**OXIDATION** MOS GATE OXIDE DEFECTS RELATED	129	1066
D AMORPHOUS SILICON BY CW LASER IRRADIATI ANOMALOUS LOCAL	**OXIDATION** AND RECRYSTALLIZATION OF VACUUM-DEPOSITE	129	888
THE	**OXIDATION** INHIBITION IN NITROGEN-IMPLANTED SILICON	129	1803
ELECTROCHEMICAL STUDIES OF COAL SLURRY	**OXIDATION** MECHANISMS	129	1719
II.	**OXIDATION** OF AL FILMS	129	2369
FERROCENE AT THE N-GAAS/ROOM TEMPERA PHOTOELECTROCHEMICAL	**OXIDATION** OF AROMATIC HYDROCARBONS AND DECAMETHYL	129	560
GREATER THAN ONE ATMOSPHERE THE	**OXIDATION** OF GERMANIUM SURFACES AT PRESSURES MUCH	129	1845
F POLYCRYSTALLINE SILICON THERMAL	**OXIDATION** OF HEAVILY PHOSPHORUS-DOPED THIN FILMS O	129	2321
O4 AND HBR	**OXIDATION** OF H2 AT GAS DIFFUSION ELECTRODES IN H2S	129	2464
D TO GLYCOL ANODIC	**OXIDATION** OF P-TYPE SILICON IN METHANOL AS COMPARE	129	2749
ELECTROCHEMICAL	**OXIDATION** OF POLYHEDRAL BORON HALIDE ANIONS	129	1249
THE	**OXIDATION** OF SHAPED SILICON SURFACES	129	1278
HIGH PRESSURE	**OXIDATION** OF SILICON IN DRY OXYGEN	129	2828
TERMEDIATE PCL	**OXIDATION** OF SULFUR IN CHLOROALUMINATE MELTS OF IN	129	2237
ANTIMONY-DOPED TIN OXIDE FILMS DEPOSITED BY THE	**OXIDATION** OF TETRAMETHYLTIN AND TRIMETHYLANTIMONY	129	1040
ED WITH SI3N4 FILMS EFFECT OF BACK-SIDE	**OXIDATION** ON B AND P DIFFUSION IN SI DIRECTLY MASK	129	2292
DUAL HCL THIN GATE	**OXIDATION** PROCESS	129	1778
ITROGEN IMPLANTATION INTO SILICON: ITS MATERIAL COMPOSITION,	**OXIDATION** RESISTANCE, AND ELECTRICAL CHARACTERISTI	129	408
OXIDANT IN SIO2 FILMS SILICON	**OXIDATION** STUDIES: MEASUREMENT OF THE DIFFUSION OF	129	413
O EXPLAIN THE APPEARANCE OF HIGH DENSITY THERMAL SIO2 AT LOW	**OXIDATION** TEMPERATURES A VISCOUS FLOW MODEL T	129	2594
	OXIDATION-INDUCED POINT DEFECTS IN SILICON	129	1093
CON ON THE DOPING DEPENDENCE OF	**OXIDATION-INDUCED** STACKING FAULT SHRINKAGE IN SILI	129	2319
AN ELLIPSOMETRIC STUDY OF ELECTROCHROMISM IN TUNGSTEN	**OXIDE**	129	767
AN ELLIPSOMETRIC STUDY OF ELECTROCHROMISM IN IRIDIUM	**OXIDE**	129	335

		Vol	Page
N OF CHLORINE ON CATALYTICALLY MODIFIED N-SILICON/INDIUM TIN	**OXIDE** ANODES PHOTOELECTROCHEMICAL GENERATIO	129	1934
POROUS SILICON	**OXIDE** ANTI-REFLECTION COATING FOR SOLAR CELLS	129	596
ING DYES VISUAL DETECTION OF HYDRATED ALUMINUM	**OXIDE** BY STAINING WITH FLUORESCING AND NONFLUORESC	129	1517
D OXIDATION IDENTIFICATION AND ELIMINATION OF GATE	**OXIDE** DEFECT ORIGIN PRODUCED DURING SELECTIVE FIEL	129	800
IDE COATED WAFERS PRIOR TO LOCAL OXIDATION MOS GATE	**OXIDE** DEFECTS RELATED TO TREATMENT OF SILICON NITR	129	1066
MATION BY SHORT-CIRCUIT DIFFUSION IN AL2O3 SCALES CONTAINING	**OXIDE** DISPERSIONS PEG FOR	129	1147
THE A-C RESPONSE OF NICKEL	**OXIDE** ELECTRODE FILMS	129	535
ELECTRODE KINETICS AT THE PALLADIUM/CERAMIC	**OXIDE** ELECTROLYTE INTERFACE	129	1921
OSION CRACKING IN ALUMINUM	**OXIDE** FILM RUPTURE, REANODIZATION, AND STRESS CORR	129	2660
VOIDS IN ANODIC ALUMINUM	**OXIDE** FILMS	129	711
HG0.8TE ANODIC	**OXIDE** FILMS AND ELECTROCHEMICAL REACTIONS ON CD0.2	129	1710
ANODIC	**OXIDE** FILMS AND ELECTROCHEMICAL REACTIONS ON HGTE	129	739
NS III. PH DEPENDENCE FORMATION OF THIN	**OXIDE** FILMS AT PLATINUM ANODES IN ALKALINE SOLUTIO	129	55
HYLTIN AND TRIMETHYLANTIMONY ANTIMONY-DOPED TIN	**OXIDE** FILMS DEPOSITED BY THE OXIDATION OF TETRAMET	129	1040
INSTABILITY OF ANODIC	**OXIDE** FILMS ON TITANIUM	129	1252
UCLEAR MICROANALYSIS AND 18O TRACING OF THE GROWTH OF ANODIC	**OXIDE** FILMS ON ZIRCONIUM I. INFLUENCE OF FORMATION	129	1895
UCLEAR MICROANALYSIS AND 18O TRACING OF THE GROWTH OF ANODIC	**OXIDE** FILMS ON ZIRCONIUM II. OXIDE GROWTH MECHANIS	129	1905
TRACING OF THE GROWTH OF ANODIC OXIDE FILMS ON ZIRCONIUM II.	**OXIDE** GROWTH MECHANISM A STUDY BY NUCLEAR MICROANA	129	1905
INITIAL	**OXIDE** GROWTH RATE ON NEWLY GENERATED SURFACES	129	2500
SOLUBILITY OF YTTRIUM	**OXIDE** IN NA2SO4 AND NACL MELTS	129	2228
VATION BEHAVIOR OF SOME METALS IN MOLTEN LICL-KCL CONTAINING	**OXIDE** IONS ANODIC CORROSION AND PASSI	129	1245
	OXIDE MICRO-PRECIPITATES IN AS-GROWN CZ SILICON	129	2780
PREPARATION AND ELECTRICAL PROPERTIES OF AN ANODIC	**OXIDE** OF INP	129	2795
PARAMETER AND REACTOR DEPENDENCE OF SELECTIVE	**OXIDE** RIE IN CF4 + H2	129	2282
COMPUTER SIMULATION OF THE DIFFUSIONAL GROWTH OF TERNARY	**OXIDE** SCALES ON BINARY ALLOYS	129	209
DIFFUSION IN SILICON FROM A SPIN-ON HEAVILY PHOSPHORUS-DOPED	**OXIDE** SOURCE	129	2299
NUMERICAL SIMULATION OF GATE	**OXIDE** THINNING IN MOS DEVICES	129	831
ELECTROSYNTHESIS OF PROPYLENE	**OXIDE** WITH ALTERNATING CURRENT	129	1157
N OF STRUCTURE AND ION PAIRING IN COMPLEXES OF POLY(ETHYLENE	**OXIDE**) WITH LITHIUM SALTS VIBRATIONAL SPECTROSCOPI	129	1434
QUESTIONS ON THE KINETICS OF O2 EVOLUTION ON	**OXIDE-COVERED** METALS	129	700
UE FOR STUDYING DIELECTRIC CONSTANT VARIATION IN VALVE-METAL	**OXIDES** A GALVANOSTATIC TECHNIQ	129	2038
STUDY OF OXYGEN EVOLUTION ON NICO2O4 I. FORMATION OF HIGHER	**OXIDES** A MECHANISTIC	129	1724
FIXED CHARGE DENSITY (QSS) AT THE SI-SIO2 INTERFACE FOR THIN	**OXIDES**	129	1757
TUDY OPTICAL SPECTRA OF FERROUS AND FERRIC	**OXIDES** AND THE PASSIVE FILM: A MOLECULAR ORBITAL S	129	2169
ALLOYS PARABOLIC GROWTH OF NONUNIFORMLY DOPED	**OXIDES** CONTAINING ALIOVALENT IMPURITIES ON DILUTE	129	622
FLAWS IN SIDEWALL	**OXIDES** GROWN ON POLYSILICON GATE	129	1084
REACTIONS OF FORMATION AND STABILITY OF IRON(II) AND (III)	**OXIDES** IN LICL-KCL EUTECTIC MELT AT 470DEGREE C	129	1450
OF NITROGEN IN THE DISCH REACTIVE ION ETCHING OF SILICON	**OXIDES** WITH AMMONIA AND TRIFLUOROMETHANE. THE ROLE	129	1036
INTERFACE COMPOSITION STUDIES OF THERMALLY	**OXIDIZED** GAAS USING AUGER DEPTH PROFILING	129	851
NITRIDATION OF SILICON AND	**OXIDIZED-SILICON**	129	2102
HIGH PRESSURE OXIDATION OF SILICON IN DRY	**OXYGEN**	129	2828
MULTISTEP REPEATED ANNEALING FOR CZ-SILICON WAFERS:	**OXYGEN** AND INDUCED DEFECT BEHAVIOR	129	2089
E COMPARISON OF MATERIALS AS	**OXYGEN** CATALYTIC ELECTRODES ON ZIRCONIA ELECTROLYT	129	436
TRA (N,N,N-TRIMETHYLANILINIUM) PORPHYRIN ON CATALYSIS OF	**OXYGEN** CATHODIC REDUCTION BY ADSORBED IRON(111)-TE	129	2247
METHOD TO MEASURE THE PRECIPITATED AND TOTAL	**OXYGEN** CONCENTRATION IN SILICON	129	1638
THE MECHANISM OF	**OXYGEN** DIFFUSION IN VITREOUS SIO2	129	357
THERMALLY ACTIVATED	**OXYGEN** DONORS IN SI	129	2844
THE EFFECT OF ELECTRODE SURFACE IMPURITIES ON THE	**OXYGEN** ELECTRODE REACTION AT ZIRCONIA ELECTROLYTES	129	345
GROWTH BY THE CZOCHRALSKI TECHNIQUE DYNAMIC	**OXYGEN** EQUILIBRIUM IN SILICON MELTS DURING CRYSTAL	129	189
LANTHANUM NICKELATE AS ELECTROCATALYST:	**OXYGEN** EVOLUTION	129	2391
OXIDES A MECHANISTIC STUDY OF	**OXYGEN** EVOLUTION ON NICO2O4 I. FORMATION OF HIGHER	129	1724
SOLUBILITIES OF	**OXYGEN** IN FUSED LI2CO3-K2CO3	129	1668
ECHNIQUE THE MEASUREMENT OF LOW LEVELS OF	**OXYGEN** IN GERMANIUM BY THE LITHIUM PRECIPITATION T	129	226
ND SILVER ON THE DIFFUSIVITY AND THERMODYNAMIC PROPERTIES OF	**OXYGEN** IN LIQUID INDIUM THE INFLUENCE OF SOLUTE AD	129	430
ETALS IN THE USE OF IN SITU ELECTROCHEMICAL REDUCTION OF	**OXYGEN** IN THE DIMINUTION OF ADSORBED BACTERIA ON M	129	2178
DECAPSULATION AND PHOTORESIST STRIPPING IN	**OXYGEN** MICROWAVE PLASMAS	129	2537
	OXYGEN PRECIPITATION FACTORS IN SILICON	129	1062
MO NAPHTHALOCYANINES. APPLICATION TO THE ELECTROCATALYSIS OF	**OXYGEN** REACTION EPR INVESTIGATION OF FE, MIXED FE-	129	1409
MBIENT-MENISCUS MELT INTERACTIONS ASSOCIATED WITH CARBON AND	**OXYGEN** TRANSPORT IN EFG OF SILICON RIBBON MODELING	129	1356
FOR THE GROWTH OF SIO2 REACTION OF	**OXYGEN** WITH SI(111) AND (100): CRITICAL CONDITIONS	129	1300
HEAT-TREATMENT STUDIES OF	**OXYGEN-DEFECT-IMPURITY** INTERACTIONS IN SILICON	129	2127
LUMINESCENCE OF RARE EARTH ACTIVATED LUTETIUM	**OXYHALIDE** PHOSPHORS	129	1552
THE ANODIC EVOLUTION OF	**OZONE**	129	506
HE DISINTEGRATION OF LEAD DIOXIDE ANODES UNDER CONDITIONS OF	**OZONE** EVOLUTION IN STRONG ACID ELECTROLYTES THE ME	129	567
PLASMA ETCHING OF III-V SEMICONDUCTORS AND THE ROLE OF ADDED	**O2** CCL4 AND CL2	129	1599
SEGREGATION OF LOW-DOSE IMPLANTED BORON IN SILICON UNDER DRY	**O2** AMBIENT DIFFUSION AND	129	1097
I. INTERACTION OF AL FILMS WITH	**O2** AT LOW PRESSURES	129	2366
QUESTIONS ON THE KINETICS OF	**O2** EVOLUTION ON OXIDE-COVERED METALS	129	700

— P —

EFFECT OF BACK-SIDE OXIDATION ON B AND	**P** DIFFUSION IN SI DIRECTLY MASKED WITH SI3N4 FILMS	129	2292
TECHNIQUES FOR FABRICATING ABRUPT ZINC- AND MAGNESIUM-DOPED	**P(+)-N** INGAASP/INP HETEROJUNCTIONS LPE GROWTH	129	2085
	P-DOPED POLYSILICON FILM GROWTH TECHNOLOGY	129	2620
INTERFACIAL CHEMISTRY AT	**P-GAP** PHOTOELECTRODES	129	2141
LYTE SURFACE-MODIFIED	**P-INP** PHOTOCATHODES IN SULFIDE/POLYSULFIDE ELECTRO	129	1387
IV. SELECTIVE REDUCTION OF O-NITROPHENOL IN THE PRESENCE OF	**P-NITROPHENOL** WITH ALPHA-CYCLODEXTRIN IN SOLUTION	129	1681
L	**P-TYPE** AMORPHOUS SILICON/LIQUID JUNCTION SOLAR CEL	129	1644
THE PHOTOELECTROCHEMICAL KINETICS OF	**P-TYPE** GAP	129	2254
E RECOMBINATION AND TRAPPING ON THE CATHODIC PHOTOCURRENT AT	**P-TYPE** III-V ELECTRODES THE INFLUENCE OF SURFAC	129	730
EMICONDUCTOR ELECTRODES XLV. PHOTOELECTROCHEMISTRY OF N- AND	**P-TYPE** MOTE2 IN AQUEOUS SOLUTIONS S	129	2224
LIQUID AMMONIATE OF SOD PHOTOELECTROCHEMICAL BEHAVIOR OF	**P-TYPE** SI SINGLE CRYSTALS IN LIQUID AMMONIA AND IN	129	1998
PHOTOELECTROCHEMISTRY OF N- AND	**P-TYPE** SILICON IN ACETONITRILE	129	1982
ANODIC OXIDATION OF	**P-TYPE** SILICON IN METHANOL AS COMPARED TO GLYCOL	129	2749
CTOR ELECTRODES 44. PHOTOELECTROCHEMISTRY AT POLYCRYSTALLINE	**P-TYPE** WSE2 FILMS SEMICONDU	129	673
FERMI LEVEL PINNING FROM SHIFTS IN THE FLATBAND POTENTIAL OF	**P-TYPPE** SILICON IN ACETONITRILE SOLUTIONS WITH DIF	129	1742
IFFUSION LENGTH CHARGE COLLECTION MICROSCOPY ON	**P-WSE2**: RECOMBINATION SITES AND MINORITY CARRIER D	129	418
AN EXPERIMENTAL STUDY OF A	**PACKED** BED ELECTRODE WITH COPPER PARTICLES	129	347
VIBRATIONAL SPECTROSCOPIC DETERMINATION OF STRUCTURE AND ION	**PAIRING** IN COMPLEXES OF POLY(ETHYLENE OXIDE) WITH	129	1434
THIN	**PALLADIUM** FILMS ON SILICON AND TITANIUM	129	2689

	Vol	Page
STRY EARLY THIS CENTURY OLIN	129	59C
ELECTRODE KINETICS AT THE	129	1921
AINING ALIOVALENT IMPURITIES ON DILUTE ALLOYS	129	622
CTS OF SEPARATOR AND TERMINAL ON THE CURRENT DISTRIBUTION IN	129	1670
E GALVANOSTATIC METHOD: ANALYSIS OF ERROR AND COMPUTATION OF	129	1473
WESTON SUMMER FELLOWSHIP REPORT--QUANTITATION OF ADSORPTION	129	295C
RT--DETERMINATION OF HETEROGENEOUS ELECTRON TRANSFER KINETIC	129	298C
IN INTEGRATED CIRCUITS EFFECTS OF SEVERAL	129	2270
N-BORON METALLIC EFFECT OF COMPOSITION AND THE PROCESSING	129	695
THE EFFECT OF PROCESSING	129	656
REACTOR DETERMINATION OF TEMPERATURE AND	129	2338
AN EXPERIMENTAL STUDY OF A PACKED BED ELECTRODE WITH COPPER	129	347
PHOTOPOTENTIAL BEHAVIOR OF PLATINIZED TIO2	129	1752
HE BINDER PHASE ALLOY (CO-W) FROM WC-CO CEMENTED CARBIDES IN	129	2666
-KCL CONTAINING OXIDE IONS ANODIC CORROSION AND	129	1245
AN ELECTROCHEMICALLY SEALED AL203	129	1865
ELECTROCHEMICAL TEST TO EVALUATE	129	2174
ICONDUCTOR DEVICES A PROPOSED HYDROGENATION/NITRIDIZATION	129	821
FORMATION OF SALT FILMS DURING	129	2412
A SEMICONDUCTOR MODEL FOR THE CATHODIC	129	1880
ION IN HYDROCHLORIC ACID THE NATURE OF	129	271
OPTICAL STUDIES OF THE ANODIC	129	1886
G STORAGE SELF-DISCHARGE AND	129	458
CHARACTERIZATION OF FUSED GLASS	129	154
ELECTRON DIFFRACTION STUDY OF THE	129	2163
ECTROSCOPY STUDIES THE NATURE OF THE	129	17
THE NATURE OF THE	129	474
L AND FURTHER SUPPORTING EVIDENCE THE NATURE OF THE	129	921
ELECTRON AND ION SPECTROSCOPIC STUDIES OF THE	129	1662
OPTICAL SPECTRA OF FERROUS AND FERRIC OXIDES AND THE	129	2169
TE BUFFER SOLUTION AN ELLIPSOMETRIC INVESTIGATION OF	129	2419
A POINT DEFECT MODEL FOR ANODIC	129	1874
ANODIC BREAKDOWN OF	129	255
SIMS EVIDENCE CONCERNING WATER IN	129	2149
THE LITHIUM/SULFUR DIOXIDE BATTERY X-RAY DIFFRACTION	129	565
THE ELECTRICAL MEASUREMENT OF	129	1800
A NEW DOPING TECHNIQUE WITHOUT SIO2	129	1074
DEEP U.V. HARDENING OF POSITIVE PHOTORESIST	129	1379
ERVED BY INTERFERENCE HOLOGRAPHY GAS FLOW	129	634
ELECTROLYTIC POLISH FOR	129	2145
OXIDATION OF SULFUR IN CHLOROALUMINATE MELTS OF INTERMEDIATE	129	2237
E CORRELATIONS BETWEEN PHYSICAL AND ELECTRICAL PROPERTIES OF	129	1773
SCALES CONTAINING OXIDE DISPERSIONS	129	1147
ZATION, AND CATHODOLUMINESCENT PROPERTIES OF A LINE EMISSION	129	1540
ESTIGATION OF HIGH FIELD IONIC CONDUCTION IN ANODIC TANTALUM	129	2513
ESTIGATION OF HIGH FIELD IONIC CONDUCTION IN ANODIC TANTALUM	129	2518
NGE POLYMERS II. SORPTION AND TRANSPORT P A COMPARISON OF	129	328
NGE POLYMERS I. DIFFUSION AND WATER SORPT A COMPARISON OF	129	324
AND VISSCHER METHOD TO EVALUATE RATE CONSTANTS FOR HYDROGEN	129	2268
.16GA0.84AS SELECTIVE ETCHING CHARACTERISTICS OF	129	2380
ESR STUDIES OF NEGATIVE ELECTRON RESISTS	129	1070
TABILIZED CERAMIC MEMBRANE ELECTRODES FOR THE MEASUREMENT OF	129	1221
IN OXIDE FILMS AT PLATINUM ANODES IN ALKALINE SOLUTIONS III.	129	55
ALLOY 600 EFFECT OF SO2 AND	129	2194
MONITORING OF CORROSION AND RE USE OF A HIGH TEMPERATURE	129	1445
PARTICULATE BED ELEC SELECTIVE DISSOLUTION OF THE BINDER	129	2666
THE IN-P-O	129	1361
IN SITU MONITORING OF LIQUID	129	2095
SELECTIVE EPITAXIAL GROWTH OF GAAS BY LIQUID	129	194
VAPOR	129	2569
TION DEPENDENCE OF GROWTH RATE OF INGAAS/INP GROWN BY LIQUID	129	2603
REFILLING SILICON GROOVES BY LIQUID	129	2819
HIGH LIFETIME SILICON LIQUID	129	665
CE WHITLOCKITE	129	1373
F CHEMICAL VAPOR DEPOSITION OF ALUMINA FROM ALCL3-H2-CO2 GAS	129	1367
TH OF CUINS2 CRYSTALS FROM THE MELT THE	129	1570
TEMPERATURE LI-AL/LICL-KCL/FES2 CELLS	129	925
PULSE PLATING OF CHROMIUM--COBALT ALLOYS CONTAINING A	129	2433
M. BECKET AWARD REPORT--AN X-RAY POWDER DIFFRACTION STUDY OF	129	31C
R	129	1627
A STUDY OF INCLUSIONS IN INDIUM	129	614
FERRICENIUM REDOX COUPLE AT PLATINUM, N-SILICON AND N-INDIUM	129	1987
CATHODOLUMINESCENT PROPERTIES OF A LINE EMISSION PENETRATION	129	1540
THE ELECTROLUMINESCENCE OF ZNS:CU, BR	129	813
ETCHING EFFECT ON AC POWDER EL	129	2059
A RED	129	2296
SINGLE CRYSTAL Y3AL5O12:TB	129	816
EFFECT OF V203 ADDITION ON THE THERMOLUMINESCENCE AND	129	2638
HERMOLUMINESCENCE AND PHOSPHORESCENCE OF TB-ACTIVATED GARNET	129	2638
URANIUM-ACTIVATED LITHIUM TUNGSTATE	129	887
LUMINESCENCE OF RARE EARTH ACTIVATED LUTETIUM OXYHALIDE	129	1552
L PHENO SATURATION OF (ZN, CD)S:CU, AL CATHODOLUMINESCENT	129	1546
POLYCRYSTALLINE SILICON FILMS HEAVILY DOPED WITH ARSENIC AND	129	1811
MICRODEFECTS DURING	129	667
THE LPCVD POLYSILICON	129	1109
THE ENHANCED DIFFUSION OF ARSENIC AND	129	644
GROWTH IN A CVD REACTOR	129	1122
DIFFUSION IN SILICON FROM A SPIN-ON HEAVILY	129	2299
ICON THERMAL OXIDATION OF HEAVILY	129	2321

	Vol	Page
PALLADIUM MEDAL ADDRESS--ELECTRO(ANALYTICAL) CHEMI	129	59C
PALLADIUM/CERAMIC OXIDE ELECTROLYTE INTERFACE	129	1921
PARABOLIC GROWTH OF NONUNIFORMLY DOPED OXIDES CONT	129	622
PARALLEL-PLATE ELECTROCHEMICAL FLOW REACTORS EFFE	129	1670
PARAMETERS TH	129	1473
PARAMETERS AND ADSORPTION RATES FOR DITHIOZONE ANI	129	295C
PARAMETERS BY DERIVATIVE CYCLIC VOLTABSORPTOMETRY	129	298C
PARAMETERS ON THE CORROSION RATES OF AL CONDUCTORS	129	2270
PARAMETERS ON THE ELECTROCHEMICAL CORROSION OF IRO	129	695
PARAMETERS ON THE LIFETIME OF (HG,CD)TE MATERIAL	129	656
PARTIAL PRESSURE BY RAMAN SCATTERING INSIDE A CVD	129	2338
PARTICLES	129	347
PARTICLES	129	1752
PARTICULATE BED ELECTRODE SYSTEMS SELECTIVE DISSOL	129	2666
PASSIVATION BEHAVIOR OF SOME METALS IN MOLTEN LICL	129	1245
PASSIVATION LAYER FOR ALUMINUM ALLOYS	129	1865
PASSIVATION LAYERS: OVERCOATS OF SI IN INK	129	2174
PASSIVATION MECHANISM FOR GAAS AND OTHER III-V SEM	129	821
PASSIVATION OF IRON	129	2412
PASSIVATION OF LEAD DIOXIDE	129	1880
PASSIVATION OF LEAD SULFIDE DURING ANODIC DISSOLUT	129	271
PASSIVATION OF TIN	129	1886
PASSIVATION PHENOMENA IN LEAD-ACID BATTERIES DURIN	129	458
PASSIVATION WITH SELECTED DIODE STRUCTURES	129	154
PASSIVE FILM ON IRON	129	2163
PASSIVE FILM ON IRON I. AUTOMATIC ELLIPSOMETRIC SP	129	17
PASSIVE FILM ON IRON II. A-C IMPEDANCE STUDIES	129	474
PASSIVE FILM ON IRON III. THE CHEMI-CONDUCTOR MODE	129	921
PASSIVE FILM ON IRON-CHROMIUM ALLOYS	129	1662
PASSIVE FILM: A MOLECULAR ORBITAL STUDY	129	2169
PASSIVE FILMS FORMED ON FE-25NI-XCR ALLOYS IN BORA	129	2419
PASSIVE FILMS III. IMPEDANCE RESPONSE	129	1874
PASSIVE FILMS ON METALS	129	255
PASSIVE LAYERS	129	2149
PATTERN AND DSC CURVES OF THE DISCHARGE PRODUCT OF	129	565
PATTERN PLACEMENT ERRORS OF MASK MAKERS	129	1800
PATTERNING USING AN INORGANIC PHOTORESIST	129	1074
PATTERNS	129	1379
PATTERNS IN HORIZONTAL EPITAXIAL REACTOR CELLS OBS	129	634
PB(1-X)SN(X)SE	129	2145
PCL	129	2237
PECVD SIN WITH THEIR COMPOSITION RATIOS TH	129	1773
PEG FORMATION BY SHORT-CIRCUIT DIFFUSION IN AL2O3	129	1147
PENETRATION PHOSPHOR PREPARATION, OPTIMI	129	1540
PENTOXIDE FILMS USING THE OPEN-CIRCUIT TRANSIENT M	129	2513
PENTOXIDE FILMS USING THE STEPPED CURRENT METHOD A	129	2518
PERFLUORINATED CARBOXYLATE AND SULFONATE ION EXCHA	129	328
PERFLUORINATED CARBOXYLATE AND SULFONATE ION EXCHA	129	324
PEROXIDE DECOMPOSITION AT ROTATING DISK ELECTRODES	129	2268
PEROXIDE/AMMONIUM-HYDROXIDE SOLUTIONS FOR GAAS/ALO	129	2380
PGMA AND PST	129	1070
PH AT ELEVATED TEMPERATURES S	129	1221
PH DEPENDENCE FORMATION OF TH	129	55
PH ON THE ANODIC BEHAVIOR AND PITTING CORROSION OF	129	2194
PH SENSOR AS A "PSEUDO-REFERENCE ELECTRODE" IN THE	129	1445
PHASE ALLOY (CO-W) FROM WC-CO CEMENTED CARBIDES IN	129	2666
PHASE DIAGRAM: CONSTRUCTION AND APPLICATIONS	129	1361
PHASE ELECTROEPITAXIAL GROWTH	129	2095
PHASE ELECTROEPITAXY	129	194
PHASE EPITAXIAL GROWTH OF MGO.AL2O3	129	2569
PHASE EPITAXY SUBSTRATE ORIENTA	129	2603
PHASE EPITAXY	129	2819
PHASE EPITAXY	129	665
PHASE IN THE LUMINESCENT SYSTEM SRO-LI2O5-P2O5:MN,	129	1373
PHASE MIXTURES THERMODYNAMIC AND EXPERIMENTAL ANAL	129	1367
PHASE RELATIONS IN THE CU,IN,S SYSTEM AND THE GROW	129	1570
PHASE RELATIONSHIPS IN POSITIVE ELECTRODES OF HIGH	129	925
PHASE WITH THE A--15 STRUCTURE	129	2433
PHASES IN THE SYSTEM CUO-NIO-MGO AT 1000 DEGREE C	129	31C
PHENOMENOLOGICAL MODEL OF THE CVD EPITAXIAL REACTO	129	1627
PHOSPHIDE	129	614
PHOSPHIDE ELECTRODES THE ELECTROCHEMISTRY AND PHOT	129	1987
PHOSPHOR PREPARATION, OPTIMIZATION, AND	129	1540
PHOSPHOR	129	813
PHOSPHOR BRIGHTNESS AND MAINTENANCE	129	2059
PHOSPHOR OF HIGH LUMEN EQUIVALENT, Y2W3O12:EU(3+)	129	2296
PHOSPHOR PRODUCED BY ION IMPLANTATION	129	816
PHOSPHORESCENCE OF TB-ACTIVATED GARNET PHOSPHORS	129	2638
PHOSPHORS EFFECT OF V2O3 ADDITION ON THE T	129	2638
PHOSPHORS	129	887
PHOSPHORS	129	1552
PHOSPHORS AT HIGH CURRENT DENSITIES I. EXPERIMENTA	129	1546
PHOSPHORUS ELECTRICAL PROPERTIES OF THERMALLY AND	129	1811
PHOSPHORUS DIFFUSION	129	667
PHOSPHORUS DOPED IN SITU AS AN INDUSTRIAL PROCESS	129	1109
PHOSPHORUS IN SILICON BY THERMAL OXIDATION	129	644
PHOSPHORUS INCORPORATION DURING SILICON EPITAXIAL	129	1122
PHOSPHORUS-DOPED OXIDE SOURCE	129	2299
PHOSPHORUS-DOPED THIN FILMS OF POLYCRYSTALLINE SIL	129	2321

		Vol	Page
WATER ABSORPTION AND DENSIFICATION OF	**PHOSPHOSILICATE** GLASS FILMS	129	1765
LOW PRESSURE DEPOSITION OF	**PHOSPHOSILICATE** GLASS FILMS	129	1588
-DOPED THIOGALLATES	**PHOTO-** AND CATHODOLUMINESCENT PROPERTIES OF ERBIUM	129	2063
PHOTOANODES IN AQUEOUS AND NONAQUEOUS ELECTROLYTE SOLUTIONS.	**PHOTO-OXIDATION** OF HALIDES WITH HIGH EFFICIENCY CH	129	1461
RY OF THE THALLIC/THALLOUS COUPLE. THE THALLIC ION CATALYZED	**PHOTO-OXIDATION** OF PROPYLENE PHOTOELECTROCHEMIST	129	2232
ONCENTRATION GRADIENT AND ASSOCIATED ELECTRIC FIELDS IN TIO2	**PHOTOANODES** HYDROGEN C	129	1851
CHARACTERIZATION OF N-TYPE SEMICONDUCTING TUNGSTEN DISULFIDE	**PHOTOANODES** IN AQUEOUS AND NONAQUEOUS ELECTROLYTE	129	1461
LYTES INP AND CDS	**PHOTOANODES** IN CONCENTRATED AQUEOUS IODIDE ELECTRO	129	1977
NG RING-DISK ELECTRODES	**PHOTOANODIC** DISSOLUTION OF N-CDS STUDIED BY ROTATI	129	149
ARACTERIZATION OF DEEP LEVELS IN SEMICOND ELECTROCHEMICAL	**PHOTOCAPACITANCE** SPECTROSCOPY: A NEW METHOD FOR CH	129	891
SURFACE-MODIFIED P-INP	**PHOTOCATHODES** IN SULFIDE/POLYSULFIDE ELECTROLYTE	129	1387
ND CHEMICAL REACTIONS OF TRICHLOROSILANOL IN SILICON TETRACH	**PHOTOCHEMICAL** PRODUCTION, INFRARED ABSORPTIVITY, A	129	1619
E SILVERSULFAMIDES CONDUCTIVITY,	**PHOTOCONDUCTIVITY,** AND LUMINESCENCE STUDIES ON SOM	129	365
Y PHOTOTHERMAL DEFLECTION SPECTROSCOPY STUDIES OF	**PHOTOCORROSION** AT THE ZNSE-ELECTROLYTE INTERFACE B	129	2393
LUENCE OF SURFACE RECOMBINATION AND TRAPPING ON THE CATHODIC	**PHOTOCURRENT** AT P-TYPE III-V ELECTRODES THE INF	129	730
PROCESS FOR HIGH	**PHOTOCURRENT** IN IBC SOLAR CELLS	129	2624
II-V SEMICONDUCTOR DEVICES, INCLUDING INGAAS LONG WAVELENGTH	**PHOTODETECTORS** A PROPOSED HYDROGENATION/NITRIDIZAT	129	821
THE EFFECT OF SPUTTERED RUO2 OVERLAYERS ON THE	**PHOTOELECTROCHEMICAL** BEHAVIOR OF CDS ELECTRODES	129	1733
ROTECTED WITH PT-POLYPYRROLE	**PHOTOELECTROCHEMICAL** BEHAVIOR OF N-SI ELECTRODES P	129	1737
CRYSTALS IN LIQUID AMMONIA AND IN LIQUID AMMONIATE OF SODIUM	**PHOTOELECTROCHEMICAL** BEHAVIOR OF P-TYPE SI SINGLE	129	1998
ODE IN FLUORIDE-CONTAINING SOLUTIONS THERMODYNAMIC AND	**PHOTOELECTROCHEMICAL** BEHAVIOR OF THE N-TIO2 ELECTR	129	2132
SPRAY-PYROLYZED THIN FILM CDSE	**PHOTOELECTROCHEMICAL** CELLS	129	719
AL SPECTRAL RESPONSES OF TRANSITION METAL DICHALCOGENIDES IN	**PHOTOELECTROCHEMICAL** CELLS LOC	129	1237
ADDED SALTS ON THE STABILITY OF CD-CHALCOGENIDE/POLYSULFIDE	**PHOTOELECTROCHEMICAL** CELLS THE EFFECT OF	129	143
I. STABILIZATION OF N-SILICON ELECTRODES IN AQUEOUS SOLUTION	**PHOTOELECTROCHEMICAL** CELLS BY FORMATION OF PLATINU	129	1647
OUS POLYSULFIDE SYSTEM TERNARY CHALCOGENIDE-BASED	**PHOTOELECTROCHEMICAL** CELLS II. THE N-CDIN2SE4/AQUE	129	1506
UX VARIATION CURRENT-VOLTAGE ANALYSIS OF	**PHOTOELECTROCHEMICAL** CELLS UNDER MASS AND LIGHT FL	129	2029
ND ELECTROLUMINESCENT PROPERTIES OF CADMIUM S LUMINESCENT	**PHOTOELECTROCHEMICAL** CELLS VII. PHOTOLUMINESCENT A	129	772
/ROOM TEMPERATURE MOLTEN SALT ELECTROLYTE INTERFACE	**PHOTOELECTROCHEMICAL** CHARACTERIZATION OF THE N-INP	129	2009
UNIFIED MODEL AND COMPARISON WITH EXP CHARGE TRANSFER IN	**PHOTOELECTROCHEMICAL** DEVICES VIA INTERFACE STATES:	129	1003
ALYTICALLY MODIFIED N-SILICON/INDIUM TIN OXIDE ANODES	**PHOTOELECTROCHEMICAL** GENERATION OF CHLORINE ON CAT	129	1934
N-MOSE2	**PHOTOELECTROCHEMICAL** HALOGEN STORAGE CELL	129	233
THE	**PHOTOELECTROCHEMICAL** KINETICS OF P-TYPE GAP	129	2254
LANTED GAP	**PHOTOELECTROCHEMICAL** MEASUREMENTS OF H- AND HE-IMP	129	2735
RBONS AND DECAMETHYL FERROCENE AT THE N-GAAS/ROOM TEMPERATUR	**PHOTOELECTROCHEMICAL** OXIDATION OF AROMATIC HYDROCA	129	560
FILM ELECTRODES IN AQUEOUS POLYSULFIDE ELECTROLYTE	**PHOTOELECTROCHEMICAL** PERFORMANCE OF ZNSE/CDSE THIN	129	542
ARED FROM ORGANIC RESINATE SOLUTION STUDIES ON	**PHOTOELECTROCHEMICAL** PROPERTIES OF SNO2 FILMS PREP	129	1501
FILMS EFFECT OF HYDROGEN ON THE DIELECTRIC AND	**PHOTOELECTROCHEMICAL** PROPERTIES OF SPUTTERED TIO2	129	2022
COGENOPHOSPHATE COMPOUNDS (MPX3)	**PHOTOELECTROCHEMICAL** RESPONSE OF SOME LAYERED CHAL	129	237
RT PROPERTIES OF NAFION MEMBRANES FOR USE IN THREE-ELECTRODE	**PHOTOELECTROCHEMICAL** STORAGE CELLS TRANSPO	129	2469
E2 FILMS SEMICONDUCTOR ELECTRODES 44.	**PHOTOELECTROCHEMISTRY** AT POLYCRYSTALLINE P-TYPE WS	129	673
ICENIUM REDOX COUPLE AT PLATINUM THE ELECTROCHEMISTRY AND	**PHOTOELECTROCHEMISTRY** OF AN AQUEOUS FERROCENE/FERR	129	1987
THE	**PHOTOELECTROCHEMISTRY** OF CDIN2S4	129	2628
UEOUS SOLUTIONS SEMICONDUCTOR ELECTRODES XLV.	**PHOTOELECTROCHEMISTRY** OF N- AND P-TYPE MOTE2 IN AQ	129	2224
ACETONITRILE	**PHOTOELECTROCHEMISTRY** OF N- AND P-TYPE SILICON IN	129	1982
LE. THE THALLIC ION CATALYZED PHOTO-OXIDATION OF PROPYLENE	**PHOTOELECTROCHEMISTRY** OF THE THALLIC/THALLOUS COUP	129	2232
INTERFACIAL CHEMISTRY AT P-GAP	**PHOTOELECTRODES**	129	2141
POLYCRYSTALLINE WSE2	**PHOTOELECTRODES**	129	145
FILMS ENHANCED STABILITY OF	**PHOTOELECTRODES** WITH ELECTROGENERATED POLYANILINE	129	2261
STUDY OF STABILIZATION AND SURFACE RECOMBINATION ON N-GAP	**PHOTOELECTRODES:** MECHANISMS AND INTERRELATION	129	546
CTRODE	**PHOTOELECTROLYSIS** AT FE203/TIO2 HETEROJUNCTION ELE	129	342
SPONTANEOUS	**PHOTOELECTROLYSIS** OF HBR AND HL	129	1701
TIO2-VO2 ALLOYS--REDUCED BANDGAP EFFECTS IN THE	**PHOTOELECTROLYSIS** OF WATER	129	1210
NG SURFACE STATES ON PHOTOGRAPHIC AGBR GRAINS: ROLES BESIDES	**PHOTOELECTRON-TRAPPING** GOLD-CONTAINI	129	591
RON-TRAPPING GOLD-CONTAINING SURFACE STATES ON	**PHOTOGRAPHIC** AGBR GRAINS: ROLES BESIDES PHOTOELECT	129	591
2-AQUEOUS ELECTROLYTE INTERFACE INTERACTIONS BETWEEN	**PHOTOINDUCED** AND DARK CHARGE TRANSFER ACROSS N-TIO	129	1240
GAAS GROWN BY CZ AND HB METHODS ONE-DIMENSIONAL	**PHOTOLUMINESCENCE** DISTRIBUTION IN SEMI-INSULATING	129	880
OF CADMIUM S LUMINESCENT PHOTOELECTROCHEMICAL CELLS VII.	**PHOTOLUMINESCENT** AND ELECTROLUMINESCENT PROPERTIES	129	772
ATE MASKING MEDIUM HIGH RESOLUTION	**PHOTOMASKS** WITH ION-BOMBARDED POLYMETHYL METHACRYL	129	827
ES	**PHOTOPOTENTIAL** BEHAVIOR OF PLATINIZED TIO2 PARTICL	129	1752
DOPING TECHNIQUE WITHOUT SIO2 PATTERNING USING AN INORGANIC	**PHOTORESIST** A NEW	129	1074
TITANIUM DIOXIDE FILMS TO IMPROVE	**PHOTORESIST** ADHESION	129	2389
DEEP U.V. HARDENING OF POSITIVE	**PHOTORESIST** PATTERNS	129	1379
DECAPSULATION AND	**PHOTORESIST** STRIPPING IN OXYGEN MICROWAVE PLASMAS	129	2537
UDIES OF PHOTOCORROSION AT THE ZNSE-ELECTROLYTE INTERFACE BY	**PHOTOTHERMAL** DEFLECTION SPECTROSCOPY ST	129	2393
ERIZATION OF HETEROEPITAXIAL SILICON ON SAPPHIRE BY SCANNING	**PHOTOVOLTAGE** MEASUREMENTS MICROSCALE CHARACT	129	2609
SOLID POLYMER ELECTROLYTE	**PHOTOVOLTAIC** CELL	129	894
DE/IODIDE REDOX COUPLE IN ACETONITRILE ELECTROCHEMICAL	**PHOTOVOLTAIC** CELLS BASED ON N-GAAS AND THE TRIIODI	129	1705
BATTERY STATE OF CHARGE DETERMINATION IN	**PHOTOVOLTAIC** SYSTEMS	129	1928
HIUM CELLS	**PHTHALOCYANINE** CATHODE MATERIALS FOR SECONDARY LIT	129	5
ELECTRO-OXIDATION OF HYDRAZINE CATALYZED BY SULFONATED	**PHTHALOCYANINES** ADSORBED ON A GRAPHITE ELECTRODE	129	2242
TH THEIR COMPOSITION RATIOS THE CORRELATIONS BETWEEN	**PHYSICAL** AND ELECTRICAL PROPERTIES OF PECVD SIN WI	129	1773
ES FROM OPEN-CIRCUIT VOLTAGE MEASUREMEN THERMODYNAMIC AND	**PHYSICAL** PROPERTIES OF MOLTEN POTASSIUM POLYSULFID	129	2707
- SEMICONDUCTOR ELECTRODES XLII. EVIDENCE FOR FERMI LEVEL	**PINNING** FROM SHIFTS IN THE FLATBAND POTENTIAL OF P	129	1742
RELATION BETWEEN MASS TRANSFER AND CORROSION IN A TURBULENT	**PIPE** FLOW	129	276
	PIPED EMITTER DELINEATION USING THE WRIGHT ETCH	129	354
SOLUTION OF NICKEL	**PIT** AND FLOW STREAK FORMATION DURING HIGH RATE DIS	129	1889
TATION IN SI FILMS AN ETCH	**PIT** TECHNIQUE FOR ANALYZING CRYSTALLOGRAPHIC ORIEN	129	1848
DESIGN FOR DUAL MEASUREMENT OF POTENTIALS INSIDE ARTIFICIAL	**PITS** AND ON POLARIZED SURFACES AN ELECTRODE	129	669
EFFECT OF SO2 AND PH ON THE ANODIC BEHAVIOR AND	**PITTING** CORROSION OF ALLOY 600	129	2194
A SIGNATURE IN THE CURRENT DURING EARLY EVENTS IN THE	**PITTING** CORROSION OF ALUMINUM	129	340
THE STABILITY OF	**PITTING** DISSOLUTION OF METALS IN AQUEOUS SOLUTION	129	260
MORPHOLOGICAL STUDIES OF OCCLUDED CELLS IN THE	**PITTING** OF DILUTE ALUMINUM ALLOYS IN SEAWATER	129	137
THE ELECTRICAL MEASUREMENT OF PATTERN	**PLACEMENT** ERRORS OF MASK MAKERS	129	1800
DE RESISTANCE OF A	**PLANAR** ARRAY OF SPHERES: GAS BUBBLES ON AN ELECTRO	129	2715
D NF3	**PLANAR** PLASMA ETCHING OF POLYSILICON USING CCL4 AN	129	795
S INGAASP/INP	**PLANAR-STRIPE** LASERS WITH CHEMICALLY ETCHED MIRROR	129	883
FFUSION TO ELECTRODES CONSISTING OF TWO OR MORE INTERSECTING	**PLANES** SEMI-INFINITE DI	129	128
TEMPERATURE DEPENDENCE OF INP AND GAAS ETCHING IN A CHLORINE	**PLASMA**	129	2533

		Vol	Page
SI AND AL ETCHING AND PRODUCT DETECTION IN A	**PLASMA** BEAM UNDER ULTRAHIGH VACUUM	129	2045
2 FILM ON SI EFFECTS OF	**PLASMA** CLEANING ON THE DIELECTRIC BREAKDOWN IN SIO	129	224
STRUCTURAL COMPOSITION OF POLYMERS RELATIVE TO THEIR	**PLASMA** ETCH CHARACTERISTICS	129	205
IELD AND RF POWER DENSITY CONTROL OF	**PLASMA** ETCH PROFILES WITH PLASMA SHEATH ELECTRIC F	129	2541
PROFILE CONTROL WITH D-C BIAS IN	**PLASMA** ETCHING	129	393
RELATION BETWEEN ETCH RATE AND OPTICAL EMISSION INTENSITY IN	**PLASMA** ETCHING THE	129	1325
ES	**PLASMA** ETCHING OF COMPOSITE SILICIDE GATE ELECTROD	129	1330
E OF ADDED O2 CCL4 AND CL2	**PLASMA** ETCHING OF III-V SEMICONDUCTORS AND THE ROL	129	1599
PLANAR	**PLASMA** ETCHING OF POLYSILICON USING CCL4 AND NF3	129	795
MICROWAVE	**PLASMA** ETCHING OF SI WITH CF4 AND SF6 GAS	129	2764
HYDROGEN FLUORIDE MIXTURES	**PLASMA** ETCHING OF SILICON AND SILICON DIOXIDE WITH	129	1770
CHARACTERISTICS OF INP MIS SCHOTTKY DIODES PREPARED BY	**PLASMA** OXIDATION	129	221
CONTROL OF PLASMA ETCH PROFILES WITH	**PLASMA** SHEATH ELECTRIC FIELD AND RF POWER DENSITY	129	2541
DEPOSITED FROM 525 DEGREE TO 725 DEGREE C PROPERTIES OF	**PLASMA-ENHANCED** CVD SILICON FILMS I. UNDOPED FILMS	129	2326
DURING DEPOSITION PROPERTIES OF	**PLASMA-ENHANCED** CVD SILICON FILMS II. FILMS DOPED	129	2331
POLYMER FILMS FORMED DURING THE ETCHING OF ALUMINUM IN CCL4	**PLASMAS** CHEMICAL PROPERTIES OF	129	2530
DECAPSULATION AND PHOTORESIST STRIPPING IN OXYGEN MICROWAVE	**PLASMAS**	129	2537
POLYMERIZATION OF AROMATIC SILANES IN RF	**PLASMAS**	129	180
ER FOR DIFLUOROCARBENE EMISSION SPECTRA FROM FLUOROCARBON	**PLASMAS** AND ITS RELATIONSHIP TO FLUOROCARBON POLYM	129	160
ASE WITH THE A--15 STRUCTURE PULSE	**PLATING** OF CHROMIUM--COBALT ALLOYS CONTAINING A PH	129	2433
TATIC METHOD MEASUREMENT OF ELECTROLESS	**PLATING** RATE FOR COPPER AND NICKEL BATHS BY COULOS	129	2183
KINETICS OF ELECTROLESS COPPER	**PLATING** VI. INHIBITION BY ADSORPTION OF LIGAND	129	717
ON AND THE POTENTIODYNAMIC ELECTRO-OXIDATION OF ACETYLENE ON	**PLATINIZED** PLATINUM THE ADSORPTI	129	1493
PHOTOPOTENTIAL BEHAVIOR OF	**PLATINIZED** TIO2 PARTICLES	129	1752
POTENTIODYNAMIC ELECTRO-OXIDATION OF ACETYLENE ON PLATINIZED	**PLATINUM** THE ADSORPTION AND THE	129	1493
ATE OF THE HEAT OF ADSORPTION OF THE HYDROPEROXYL RADICAL ON	**PLATINUM** AN ESTIM	129	1438
ECTRODES VII. ELECTROCHEMICAL BEHAVIOR AT POLYPYRROLE-COATED	**PLATINUM** AND TANTALUM ELECTRODES POLYMER FILMS ON	129	1009
NDENCE FORMATION OF THIN OXIDE FILMS AT	**PLATINUM** ANODES IN ALKALINE SOLUTIONS III. PH DEPE	129	55
A SCAN RATE DEPENDENT DETERMINATION OF	**PLATINUM** AREAS	129	746
POTENTIODYNAMIC STUDY OF GLUCOSE ELECTRO-OXIDATION AT BRIGHT	**PLATINUM** ELECTRODES	129	2207
AQUEOUS SOLUTION PHOTOELECTROCHEMICAL CELLS BY FORMATION OF	**PLATINUM** SILICIDE LAYERS SEMICONDUCTOR ELECTRODES	129	1647
HEMISTRY OF AN AQUEOUS FERROCENE/FERRICENIUM REDOX COUPLE AT	**PLATINUM**, N-SILICON AND N-INDIUM PHOSPHIDE ELECTRO	129	1987
UTILE ELECTRODES MOTT-SCHOTTKY	**PLOTS** AND FLATBAND POTENTIALS FOR SINGLE CRYSTAL R	129	1973
PREPARATION OF THE FIRST ELECTROLYTIC	**PLUTONIUM** AND OF URANIUM FROM FUSED CHLORIDES	129	2438
ELLIPSOMETRIC THICKNESS MEASUREMENTS OF	**PMMA** ON GAAS	129	2273
MPEDANCE RESPONSE A	**POINT** DEFECT MODEL FOR ANODIC PASSIVE FILMS III. I	129	1874
OXIDATION-INDUCED	**POINT** DEFECTS IN SILICON	129	1093
THE EFFECT OF CATHODIC	**POLARIZATION** ON THE CREEP RATE OF GOLD	129	706
DUAL MEASUREMENT OF POTENTIALS INSIDE ARTIFICIAL PITS AND ON	**POLARIZED** SURFACES AN ELECTRODE DESIGN FOR	129	669
METHANOL AND DIOXANE	**POLAROGRAPHY** OF O-MERCAPTOBENZOIC ACID IN AQUEOUS	129	90
ACETONITRILE	**POLAROGRAPHY** OF 4-CYANO-1-METHYLPYRIDINIUM ION IN	129	2725
ELECTROLYTIC	**POLISH** FOR PB(1-X)SN(X)SE	129	2145
C DETERMINATION OF STRUCTURE AND ION PAIRING IN COMPLEXES OF	**POLY(ETHYLENE** OXIDE) WITH LITHIUM SALTS VIBRATIONA	129	1434
S THE USE OF S2CL2 FOR DOPING	**POLY-GAAS** FILMS GROWN BY THE ORGANOMETALLIC PROCES	129	2778
ENHANCED STABILITY OF PHOTOELECTRODES WITH ELECTROGENERATED	**POLYANILINE** FILMS	129	2261
SESSILE DROP STUDIES ON	**POLYBROMIDE/ZINC-BROMINE** BATTERY ELECTROLYTE	129	1747
EPTOR STATE DENSI CALCULATION OF CARRIER CONCENTRATION IN	**POLYCRYSTALLINE** FILMS AS A FUNCTION OF SURFACE ACC	129	1382
SEMICONDUCTOR ELECTRODES 44. PHOTOELECTROCHEMISTRY AT	**POLYCRYSTALLINE** P-TYPE WSE2 FILMS	129	673
SELECTIVE REACTIVE ION BEAM ETCHING OF SIO2 OVER	**POLYCRYSTALLINE** SI	129	396
HEAT-TREATMENT EFFECT ON BORON IMPLANTATION IN	**POLYCRYSTALLINE** SILICON	129	1604
A NOVEL METHOD TO MEASURE LATERAL DIFFUSION LENGTH IN	**POLYCRYSTALLINE** SILICON	129	1635
THERMAL OXIDATION OF HEAVILY PHOSPHORUS-DOPED THIN FILMS OF	**POLYCRYSTALLINE** SILICON	129	2321
ELLIPSOMETRY MEASUREMENTS OF	**POLYCRYSTALLINE** SILICON FILMS	129	1347
RSE ELECTRICAL PROPERTIES OF THERMALLY AND LASER ANNEALED	**POLYCRYSTALLINE** SILICON FILMS HEAVILY DOPED WITH A	129	1811
	POLYCRYSTALLINE WSE2 PHOTOELECTRODES	129	145
OF A LIGAND (BATHOPHENANTHROLINE DISULFONIC ACIDD) BOUND TO	**POLYELECTROLYTES** ON ELECTRODES AND THE USE OF THE	129	762
ELS FOR THE STRUCTURE AND IONIC CONDUCTIVITY IN COMPLEXES OF	**POLYETHERS** WITH ALKALI METAL SALTS CONFORMATION AN	129	1694
ELECTROCHEMICAL OXIDATION OF	**POLYHEDRAL** BORON HALIDE ANIONS	129	1249
NEW COUPLING METHOD FOR	**POLYIMIDE** ADHESION TO LSI SURFACE	129	2278
SOLID	**POLYMER** ELECTROLYTE PHOTOVOLTAIC CELL	129	894
M IN CCL4 PLASMAS CHEMICAL PROPERTIES OF	**POLYMER** FILMS FORMED DURING THE ETCHING OF ALUMINU	129	2530
EHAVIOR AT POLYPYRROLE-COATED PLATINUM AND TANTALUM ELECTROD	**POLYMER** FILMS ON ELECTRODES VII. ELECTROCHEMICAL B	129	1009
OM FLUOROCARBON PLASMAS AND ITS RELATIONSHIP TO FLUOROCARBON	**POLYMER** FORMATION DIFLUOROCARBENE EMISSION SPECTRA	129	160
THE CATION CONCENTRATION RESPONSE OF	**POLYMER** GATE ISFET	129	141
ICAL PROPERTIES OF A LIGAND (BATHOPHENANTHROLINE DISULFONIC	**POLYMER-MODIFIED** ELECTRODES II. SPECTROELECTROCHEM	129	762
ERS INEXPENSIVE CROSS-LINKED	**POLYMERIC** SEPARATORS MADE FROM WATER-SOLUBLE POLYM	129	251
	POLYMERIZATION OF AROMATIC SILANES IN RF PLASMAS	129	180
PYL DEPENDENCE OF THE DIFFUSION CURRENT ON THE DEGREE OF	**POLYMERIZATION** OF NITROCELLULOSE IN ACETONE-ISOPRO	129	1520
EMENT OF PERFORMANCE OF N-WSE2 ELECTRODES BY ELECTROCHEMICAL	**POLYMERIZATION** OF O-PHENYLENEDIAMINE AT SURFACE IM	129	265
VE CROSS-LINKED POLYMERIC SEPARATORS MADE FROM WATER-SOLUBLE	**POLYMERS** INEXPENSI	129	251
PREDICTING RADIATION SENSITIVITY OF	**POLYMERS**	129	811
ECTROCHROMIC DEVICES ION-CONTAINING	**POLYMERS** AS SEMISOLID ELECTROLYTES IN WO3-BASED EL	129	1215
SON OF PERFLUORINATED CARBOXYLATE AND SULFONATE ION EXCHANGE	**POLYMERS** I. DIFFUSION AND WATER SORPTION A COMPARI	129	324
SON OF PERFLUORINATED CARBOXYLATE AND SULFONATE ION EXCHANGE	**POLYMERS** II. SORPTION AND TRANSPORT PROPERTIES IN	129	328
TICS STRUCTURAL COMPOSITION OF	**POLYMERS** RELATIVE TO THEIR PLASMA ETCH CHARACTERIS	129	205
HIGH RESOLUTION PHOTOMASKS WITH ION-BOMBARDED	**POLYMETHYL** METHACRYLATE MASKING MEDIUM	129	827
OF SURFACE FILMS FORMED ON IRON IN AGGRESSIVE AND INHIBITING	**POLYPHOSPHATE** SOLUTIONS ON THE NATURE	129	1186
POLYMER FILMS ON ELECTRODES VII. ELECTROCHEMICAL BEHAVIOR AT	**POLYPYRROLE-COATED** PLATINUM AND TANTALUM ELECTRODE	129	1009
GRAIN-GROWTH MECHANISMS IN	**POLYSILICON**	129	1791
POST-EPITAXIAL	**POLYSILICON** AND SI3N4 GETTERING IN SILICON	129	1294
P-DOPED	**POLYSILICON** FILM GROWTH TECHNOLOGY	129	2620
FLAWS IN SIDEWALL OXIDES GROWN ON	**POLYSILICON** GATE	129	1084
IAL PROCESS THE LPCVD	**POLYSILICON** PHOSPHORUS DOPED IN SITU AS AN INDUSTR	129	1109
PLANAR PLASMA ETCHING OF	**POLYSILICON** USING CCL4 AND NF3	129	795
TRIC BREAKDOWN	**POLYSILICON/SIO2** INTERFACE MICROTEXTURE AND DIELEC	129	1282
CAL PERFORMANCE OF ZNSE/CDSE THIN FILM ELECTRODES IN AQUEOUS	**POLYSULFIDE** ELECTROLYTE PHOTOELECTROCHEMI	129	542
-BASED PHOTOELECTROCHEMICAL CELLS II. THE N-CDIN2SE4/AQUEOUS	**POLYSULFIDE** SYSTEM TERNARY CHALCOGENIDE	129	1506
THERMODYNAMIC AND PHYSICAL PROPERTIES OF MOLTEN POTASSIUM	**POLYSULFIDES** FROM OPEN-CIRCUIT VOLTAGE MEASUREMENT	129	2707
DEPOSITION TECHNIQUES AND HEAT TRANSFER PROPERTIES OF	**POROUS** ALUMINUM	129	1029

		Vol	Page
LTIPLE CURRENT COLLECTORS ON THE PERFORMANCE OF FLOW-THROUGH	**POROUS** ELECTRODES THE EFFECT OF MU	129	991
E MODELING OF	**POROUS** INSERTION ELECTRODES WITH LIQUID ELECTROLYT	129	1480
ER ELECTROLYSIS: CORROSION RESISTANCE	**POROUS** NICKEL-COATED STEEL ANODES FOR ALKALINE WAT	129	310
OLAR CELLS	**POROUS** SILICON OXIDE ANTI-REFLECTION COATING FOR S	129	596
MASS TRANSFER IN LAMINAR FLOW CHANNEL WITH	**POROUS** WALL	129	1727
CURRENT-INDUCED COMPOSITION GRADIENTS. MOLTEN NANO3-AGNO3 IN	**POROUS** YTTRIA SEM/EDX AND AA MEASUREMENTS OF	129	931
BETWEEN ELECTROLYTE CONDUCTANCE AND CURRENT DISTRIBUTION IN	**POROUS** ZINC ELECTRODES IN KOH ELECTROLYTE THE RELA	129	1390
TRANSIENT CURRENT DISTRIBUTIONS IN	**POROUS** ZINC ELECTRODES IN KOH ELECTROLYTE	129	239
CTION BY ADSORBED IRON(111)-TETRA (N,N,N-TRIMETHYLANILINIUM)	**PORPHYRIN** ON GLASSY CARBON ELECTRODES CATALYSIS OF	129	2247
EVALUATION OF NICKEL FOR	**POSITIVE** ELECTRODE COMPONENTS IN LI-AL/FES CELLS	129	496
-KCL/FES2 CELLS PHASE RELATIONSHIPS IN	**POSITIVE** ELECTRODES OF HIGH TEMPERATURE LI-AL/LICL	129	925
A DRY DEVELOPMENT MODEL FOR A	**POSITIVE** ELECTRON BEAM RESIST	129	2598
DETAILED CONTRAST (GAMMA-VALUE) MEASUREMENTS OF	**POSITIVE** ELECTRON RESISTS	129	2576
HYDROGENATED AMORPHOUS SILICON FIELD EFF DETERMINATION OF	**POSITIVE** MOBILE ION DENSITY IN SILICON DIOXIDE BY	129	2770
DEEP U.V. HARDENING OF	**POSITIVE** PHOTORESIST PATTERNS	129	1379
FACTORS AFFECTING THE SENSITIVITY OF CROSS-LINKED	**POSITIVE** RESISTS	129	402
TRICHLOROETHYL METHACRYLATE COPOLYMERS AS ELECTRON SENSITIVE	**POSITIVE** RESISTS STUDIES OF METHACRYLONITRILE AND	129	1596
SILICON	**POST-EPITAXIAL** POLYSILICON AND SI3N4 GETTERING IN	129	1294
EASUREMEN THERMODYNAMIC AND PHYSICAL PROPERTIES OF MOLTEN	**POTASSIUM** POLYSULFIDES FROM OPEN-CIRCUIT VOLTAGE M	129	2707
OR THE MEASUREMENT OF KINETICS OF E ERROR ANALYSIS OF THE	**POTENTIAL** AND VOLTAGE STEP RELAXATION TECHNIQUES F	129	1943
ION IN ACETONITRILE CONTROLLED	**POTENTIAL** COULOMETRY OF 4-CYANO-1-METHYLPYRIDINIUM	129	2731
MATHEMATICAL MODEL FOR DESIGN OF BATTERY ELECTRODES I.	**POTENTIAL** DISTRIBUTION	129	688
NAL AIR ELECTRODE	**POTENTIAL** DISTRIBUTION ON A CARBON-BASED BIFUNCTIO	129	1159
HAZARD	**POTENTIAL** OF DICHLOROSILANE	129	2346
EVIDENCE FOR FERMI LEVEL PINNING FROM SHIFTS IN THE FLATBAND	**POTENTIAL** OF P-TYPPE SILICON IN ACETONITRILE SOLUT	129	1742
HYDROGENATED A-SI(X)GE(1-X): A	**POTENTIAL** SOLAR CELL MATERIAL	129	2850
28 CREVICE CORROSION IN HIGH-TEMPERATURE AQUEOUS SYSTEMS	**POTENTIAL/PH** MEASUREMENTS IN ALLOY 600 CREVICES AT	129	2458
EFERENCE ELECTRODE" IN THE MONITORING OF CORROSION AND REDOX	**POTENTIALS** AT 285DEGREE C USE OF A HIGH TEMPERATUR	129	1445
MOTT-SCHOTTKY PLOTS AND FLATBAND	**POTENTIALS** FOR SINGLE CRYSTAL RUTILE ELECTRODES	129	1973
SURFACES AN ELECTRODE DESIGN FOR DUAL MEASUREMENT OF	**POTENTIALS** INSIDE ARTIFICIAL PITS AND ON POLARIZED	129	669
PLATINIZED PLATINUM THE ADSORPTION AND THE	**POTENTIODYNAMIC** ELECTRO-OXIDATION OF ACETYLENE ON	129	1493
AT BRIGHT PLATINUM ELECTRODES	**POTENTIODYNAMIC** STUDY OF GLUCOSE ELECTRO-OXIDATION	129	2207
OF FORMATION OF LEAD ALUMINATES	**POTENTIOMETRIC** DETERMINATION OF THE GIBBS ENERGIES	129	1116
POTENTIAL DEPOSITION OF SILVER ON GOLD INTERPRETATION OF	**POTENTIOSTATIC** TRANSIENT BEHAVIOR DURING THE UNDER	129	1202
UO-NIO-MGO AT 1000 DEG F.M. BECKET AWARD REPORT--AN X-RAY	**POWDER** DIFFRACTION STUDY OF PHASES IN THE SYSTEM C	129	31C
DETERIORATED A-C	**POWDER** EL CELL BRIGHTNESS RECOVERY	129	362
ETCHING EFFECT ON AC	**POWDER** EL PHOSPHOR BRIGHTNESS AND MAINTENANCE	129	2059
LASMA ETCH PROFILES WITH PLASMA SHEATH ELECTRIC FIELD AND RF	**POWER** DENSITY CONTROL OF P	129	2541
S FOR HYDROGEN PRODUCTION BY WATER SPLITTING: FROM THEORY TO	**PRACTICE** THERMOCHEMICAL PROCESSE	129	67
NT INSOLUBLE ANODE FOR NICKEL ELECTROWINNING I. SINGLE LAYER	**PRECIOUS** METAL COATINGS THE DEVELOPMENT OF AN ENER	129	515
ENT INSOLUBLE ANODE FOR NICKEL ELECTROWINNING II. MULTILAYER	**PRECIOUS** METAL COATINGS THE DEVELOPMENT OF AN ENER	129	522
ICON METHOD TO MEASURE THE	**PRECIPITATED** AND TOTAL OXYGEN CONCENTRATION IN SIL	129	1638
EUTECTIC	**PRECIPITATES** IN FE-DOPED INP	129	2335
ROFILES OF ANTIMONY ATOMS DIFFUSED INTO SILICON DUE TO LOCAL	**PRECIPITATION** OBSERVATION OF THE ANOMALOUS CONCENT	129	841
OXYGEN	**PRECIPITATION** FACTORS IN SILICON	129	1062
TROCHEMICAL RESPONSE OF NICKEL HYDROXIDE FORMED BY COLLOIDAL	**PRECIPITATION** ON DIFFERENT CONDUCTING SUBSTRATES T	129	301
SUREMENT OF LOW LEVELS OF OXYGEN IN GERMANIUM BY THE LITHIUM	**PRECIPITATION** TECHNIQUE THE MEA	129	226
OBSERVATIONS OF FLAWS ON	**PRECONDITIONED** ALUMINUM SURFACES	129	1515
	PREDICTING RADIATION SENSITIVITY OF POLYMERS	129	811
PROPERTIES OF A LINE EMISSION PENETRATION PHOSPHOR	**PREPARATION,** OPTIMIZATION, AND CATHODOLUMINESCENT	129	1540
ISOTHERMAL GROWTH OF HGCDTE UNDER CONTROLLED HG VAPOR	**PRESSURE**	129	2855
DETERMINATION OF TEMPERATURE AND PARTIAL	**PRESSURE** BY RAMAN SCATTERING INSIDE A CVD REACTOR	129	2338
LOW	**PRESSURE** DEPOSITION OF PHOSPHOSILICATE GLASS FILMS	129	1588
SOURCES OF	**PRESSURE** IN LITHIUM THIONYL CHLORIDE BATTERIES	129	2453
HIGH	**PRESSURE** OXIDATION OF SILICON IN DRY OXYGEN	129	2828
OR THE STUDY OF GROWTH-PROPERTY RELATIONSHIPS: ARSENIC VAPOR	**PRESSURE-GAAS** PROPERTY RELATIONSHIP BRIDGMAN-TYPE	129	388
I. INTERACTION OF AL FILMS WITH O2 AT LOW	**PRESSURES**	129	2366
THE OXIDATION OF GERMANIUM SURFACES AT	**PRESSURES** MUCH GREATER THAN ONE ATMOSPHERE	129	1845
NE COMBI VOLATILIZATION/CONDENSATION OF ALKALI SALTS IN A	**PRESSURIZED** FLUIDIZED BED COAL COMBUSTOR/GAS TURBI	129	2119
CALCIUM-SULFURYL CHLORIDE	**PRIMARY** CELL	129	897
EFECTS RELATED TO TREATMENT OF SILICON NITRIDE COATED WAFERS	**PRIOR** TO LOCAL OXIDATION MOS GATE OXIDE D	129	1066
RESISTANCE PROBE-SPACING EXPERIMENT SIMULATIONS: EFFECTS OF	**PROBE-CURRENT** DENSITY AND LAYER THICKNESS SPREADIN	129	2788
ON BETWEEN SPREADING RESISTANCE AND SHEET RESISTANCE	**PROBE-SPACING** EXPERIMENT SIMULATION AND THE RELATI	129	599
ROBE-CURRENT DENSITY AND LAYER THICK SPREADING RESISTANCE	**PROBE-SPACING** EXPERIMENT SIMULATIONS: EFFECTS OF P	129	2788
OF NUMERICAL METHODS AND SOLUTIONS FOR CURRENT DISTRIBUTION	**PROBLEMS** A SURVEY	129	72
AUGER ELECTRON SPECTROSCOPY STUDY OF GAAS SUBSTRATE CLEANING	**PROCEDURES**	129	406
ERS THE INFLUENCE OF INTERMITTENT GROWTH	**PROCEDURES** ON DISLOCATION DENSITIES IN INP EPI-LAY	129	1556
VACUUM SI AND AL ETCHING AND	**PRODUCT** DETECTION IN A PLASMA BEAM UNDER ULTRAHIGH	129	2045
X-RAY DIFFRACTION PATTERN AND DSC CURVES OF THE DISCHARGE	**PRODUCT** OF THE LITHIUM/SULFUR DIOXIDE BATTERY	129	565
ACTIONS OF TRICHLOROSILANOL IN SILICON TETR PHOTOCHEMICAL	**PRODUCTION,** INFRARED ABSORPTIVITY, AND CHEMICAL RE	129	1619
OF LI/SO2 CELLS CHARACTERIZATION OF REACTIONS AND	**PRODUCTS** OF THE DISCHARGE AND FORCED OVERDISCHARGE	129	1857
	PROFILE CONTROL WITH D-C BIAS IN PLASMA ETCHING	129	393
SIMULATION OF CHANGING ELECTRODE	**PROFILES**	129	78
UE TO LOCAL PR OBSERVATION OF THE ANOMALOUS CONCENTRATION	**PROFILES** OF ANTIMONY ATOMS DIFFUSED INTO SILICON D	129	841
POWER DENSITY CONTROL OF PLASMA ETCH	**PROFILES** WITH PLASMA SHEATH ELECTRIC FIELD AND RF	129	2541
OSITION STUDIES OF THERMALLY OXIDIZED GAAS USING AUGER DEPTH	**PROFILING** INTERFACE COMP	129	851
D SULFONATE ION EXCHANGE POLYMERS II. SORPTION AND TRANSPORT	**PROPERTIES** IN CONCENTRATED SOLUTION ENVIRONMENTS A	129	328
SIS OF DENSIFIED CMD FROM MN-NH4-CARBAMATE AND ITS DISCHARGE	**PROPERTIES** IN ZNCL2 BATTERIES THE SYNTHE	129	2372
ON POLYMER-MODIFIED ELECTRODES II. SPECTROELECTROCHEMICAL	**PROPERTIES** OF A LIGAND (BATHOPHENANTHROLINE DISULF	129	762
PREPARATION, OPTIMIZATION, AND CATHODOLUMINESCENT	**PROPERTIES** OF A LINE EMISSION PENETRATION PHOSPHOR	129	1540
PLICATION ELECTRICAL	**PROPERTIES** OF AL/TI CONTACT METALLURGY FOR VLSI AP	129	2590
PREPARATION AND ELECTRICAL	**PROPERTIES** OF AN ANODIC OXIDE OF INP	129	2795
CHEMICALLY DEPOSITED BI2S3 THIN FILM AND SOME SEMICONDUCTING	**PROPERTIES** OF BISMUTH CHALCOGENIDES SEMICONDUCTOR	129	332
OCHEMICAL CELLS VII. PHOTOLUMINESCENT AND ELECTROLUMINESCENT	**PROPERTIES** OF CADMIUM SULFO-SELENIDE ELECTRODES LU	129	772
PREPARATION AND	**PROPERTIES** OF CA2V2O7 SINGLE CRYSTALS	129	2562
LICON ELECTRODES ELECTRICAL	**PROPERTIES** OF COMPOSITE EVAPORATED SILICIDE/POLYSI	129	1307
PHOTO- AND CATHODOLUMINESCENT	**PROPERTIES** OF ERBIUM-DOPED THIOGALLATES	129	2063
MAGNETIC BUBBLE MEMORY DEVICES	**PROPERTIES** OF GARNET MATERIALS FOR CONTIGUOUS DISK	129	423
E O USE OF LIQUID CHROMATOGRAPHY FOR STUDYING INTERFACIAL	**PROPERTIES** OF INORGANIC SOLUTES RELEVANT TO REVERS	129	1485

		Vol	Page
HRONOAMPEROMETRIC DETERMINATION OF MASS AND CHARGE TRANSPORT	**PROPERTIES** OF LIQUID ELECTROLYTE SYSTEMS ELECTROCH	129	682
PEN-CIRCUIT VOLTAGE MEASUREMEN THERMODYNAMIC AND PHYSICAL	**PROPERTIES** OF MOLTEN POTASSIUM POLYSULFIDES FROM O	129	2707
ECTRODE PHOTOELECTROCHEMICAL STORAGE CELLS . TRANSPORT	**PROPERTIES** OF NAFION MEMBRANES FOR USE IN THREE-EL	129	2469
SOLUTION ENVIRONMENTS TRANSPORT	**PROPERTIES** OF NAFION(R) MEMBRANES IN CONCENTRATED	129	85
NS OF COPPER AND SILVER ON THE DIFFUSIVITY AND THERMODYNAMIC	**PROPERTIES** OF OXYGEN IN LIQUID INDIUM THE INFLUENC	129	430
IOS THE CORRELATIONS BETWEEN PHYSICAL AND ELECTRICAL	**PROPERTIES** OF PECVD SIN WITH THEIR COMPOSITION RAT	129	1773
UNDOPED FILMS DEPOSITED FROM 525 DEGREE TO 725 DEGREE C	**PROPERTIES** OF PLASMA-ENHANCED CVD SILICON FILMS I.	129	2326
. FILMS DOPED DURING DEPOSITION	**PROPERTIES** OF PLASMA-ENHANCED CVD SILICON FILMS II	129	2331
ING OF ALUMINUM IN CCL4 PLASMAS CHEMICAL	**PROPERTIES** OF POLYMER FILMS FORMED DURING THE ETCH	129	2530
DEPOSITION TECHNIQUES AND HEAT TRANSFER	**PROPERTIES** OF POROUS ALUMINUM	129	1029
INATE SOLUTION STUDIES ON PHOTOELECTROCHEMICAL	**PROPERTIES** OF SNO2 FILMS PREPARED FROM ORGANIC RES	129	1501
STRUCTURAL AND OPTICAL	**PROPERTIES** OF SOLUTION GROWN CDSE(1-X)S(X) FILMS	129	99
FFECT OF HYDROGEN ON THE DIELECTRIC AND PHOTOELECTROCHEMICAL	**PROPERTIES** OF SPUTTERED TIO2 FILMS E	129	2022
STALLINE SILICON FILMS HEAVILY DOPED WITH ARSE ELECTRICAL	**PROPERTIES** OF THERMALLY AND LASER ANNEALED POLYCRY	129	1811
NG THE HCL LIQUID SOURCE IMPROVING THE ELECTRICAL	**PROPERTIES** OF VAPOR GROWN III-V COMPOUNDS BY COOLI	129	2566
A-C AND D-C INHOMOGENEITY CONTRIBUTION TO THE ELECTRICAL	**PROPERTIES** OF Y-DOPED CEO2 CERAMICS: COMPARISON OF	129	2113
CDSE IN LIQUID JUNCTION SOLAR CELLS MORPHOLOGY,	**PROPERTIES**, AND PERFORMANCE OF ELECTRODEPOSITED N-	129	2016
F GROWTH-PROPERTY RELATIONSHIPS: ARSENIC VAPOR PRESSURE-GAAS	**PROPERTY** RELATIONSHIP BRIDGMAN-TYPE APPARATUS FOR	129	388
ECHANISM FOR GAAS AND OTHER III-V SEMICONDUCTOR DEVICES A	**PROPOSED** HYDROGENATION/NITRIDIZATION PASSIVATION M	129	821
HALLOUS COUPLE. THE THALLIC ION CATALYZED PHOTO-OXIDATION OF	**PROPYLENE** PHOTOELECTROCHEMISTRY OF THE THALLIC/T	129	2232
ATION OF LITHIUM-ALUMINUM ALLOYS AT AN ALUMINUM ELECTRODE IN	**PROPYLENE** CARBONATE THE FORM	129	901
ELECTROCHEMICAL STUDIES OF THE FILM FORMATION ON LITHIUM IN	**PROPYLENE** CARBONATE SOLUTIONS UNDER OPEN-CIRCUIT C	129	1422
ELECTROSYNTHESIS OF	**PROPYLENE** OXIDE WITH ALTERNATING CURRENT	129	1157
PHOTOELECTROCHEMICAL BEHAVIOR OF N-SI ELECTRODES	**PROTECTED** WITH PT-POLYPYRROLE	129	1737
	PROTON DIFFUSION IN TUNGSTEN TRIOXIDE THIN FILMS	129	2349
INAMIDE ADENINE DINUCLEOTIDE IN DIMETHYLSULFOXIDE: ION-PAIR,	**PROTONATION**, AND ADSORPTION EFFECTS ELECTROCHEMICA	129	1960
CAL PREPARATION METHOD ELECTROCHEMISTRY OF	**PRUSSIAN** BLUE MODIFIED ELECTRODES: AN ELECTROCHEMI	129	1498
CORROSION AND RE USE OF A HIGH TEMPERATURE PH SENSOR AS A	**"PSEUDO-REFERENCE** ELECTRODE" IN THE MONITORING OF	129	1445
ESR STUDIES OF NEGATIVE ELECTRON RESISTS PGMA AND	**PST**	129	1070
TOELECTROCHEMICAL BEHAVIOR OF N-SI ELECTRODES PROTECTED WITH	**PT-POLYPYRROLE** PHO	129	1737
S USING THIONYL CHLORIDE ACTIVATION OF RUO2 AND	**PTO** ELECTRODE SURFACES FOR IMMOBILIZATION REACTION	129	756
FILAMENT MATERIALS FOR EDGE-SUPPORTED	**PULLING** OF SILICON SHEET CRYSTALS	129	2838
G A PHASE WITH THE A--15 STRUCTURE	**PULSE** PLATING OF CHROMIUM--COBALT ALLOYS CONTAININ	129	2433
ALUMINA "FIBER FP" REINFORCED	**PURE** LEAD COMPOSITES FOR BATTERY ELECTRODES	129	1749
.V. LITHOGRAPHY EVALUATION OF	**PURE** NOVOLAK CRESOL-FORMALDEHYDE RESINS FOR DEEP U	129	201
ADE SILICON FOR SOLAR CELLS	**PURIFICATION** OF RICE HULLS AS A SOURCE OF SOLAR GR	129	864
ELECTROPOLYMERIZATION OF	**PYRROLE** IN THE PRESENCE OF FLUOBORATE	129	1685

— Q —

FIXED CHARGE DENSITY	**(QSS)** AT THE SI-SIO2 INTERFACE FOR THIN OXIDES	129	1757
A SIMPLE DAMAGE-FREE GROOVING METHOD FOR REVEALING THE	**QUALITY** OF INP/INGAASP MULTILAYER STRUCTURE	129	2082
-COVERED METALS	**QUESTIONS** ON THE KINETICS OF O2 EVOLUTION ON OXIDE	129	700

— R —

THE CONSTANT HELPER: STEADFASTNESS AS A KEY INGREDIENT OF	**R&D**	129	393C
PREDICTING	**RADIATION** SENSITIVITY OF POLYMERS	129	811
AN ESTIMATE OF THE HEAT OF ADSORPTION OF THE HYDROPEROXYL	**RADICAL** ON PLATINUM	129	1438
LE ON COPPER SURFACE ENHANCED	**RAMAN** SCATTERING IN CORROSION SCIENCE: BENZOTRIAZO	129	1716
DETERMINATION OF TEMPERATURE AND PARTIAL PRESSURE BY	**RAMAN** SCATTERING INSIDE A CVD REACTOR	129	2338
SORPTION AT AG USING SURFACE ENHANCED AND RESONANCE ENHANCED	**RAMAN** SPECTROSCOPY THE EDWARD WESTON SUMMER FELLOW	129	295C
LUMINESCENCE OF	**RARE** EARTH ACTIVATED LUTETIUM OXYHALIDE PHOSPHORS	129	1552
ING THE RELATION BETWEEN ETCH	**RATE** AND OPTICAL EMISSION INTENSITY IN PLASMA ETCH	129	1325
VAN DER BRINK, BARENDRECHT, AND VISSCHER METHOD TO EVALUATE	**RATE** CONSTANTS FOR HYDROGEN PEROXIDE DECOMPOSITION	129	2268
A SCAN	**RATE** DEPENDENT DETERMINATION OF PLATINUM AREAS	129	746
PIT AND FLOW STREAK FORMATION DURING HIGH	**RATE** DISSOLUTION OF NICKEL	129	1889
THOD MEASUREMENT OF ELECTROLESS PLATING	**RATE** FOR COPPER AND NICKEL BATHS BY COULOSTATIC ME	129	2183
THE EFFECT OF CATHODIC POLARIZATION ON THE CREEP	**RATE** OF GOLD	129	706
SUBSTRATE ORIENTATION DEPENDENCE OF GROWTH	**RATE** OF INGAAS/INP GROWN BY LIQUID PHASE EPITAXY	129	2603
INITIAL OXIDE GROWTH	**RATE** ON NEWLY GENERATED SURFACES	129	2500
ANIUM ALLOY TUNGSTEN FIBER METAL MATRIX COMPOSI CORROSION	**RATES** AND ELECTROCHEMICAL STUDIES OF A DEPLETED UR	129	1398
TARNISHING OF SILVER BY ORGANIC SULFUR VAPORS:	**RATES** AND FILM CHARACTERISTICS	129	33
REPORT--QUANTITATION OF ADSORPTION PARAMETERS AND ADSORPTION	**RATES** FOR DITHIOZONE ANION ADSORPTION AT AG USING	129	295C
EFFECTS OF SEVERAL PARAMETERS ON THE CORROSION	**RATES** OF AL CONDUCTORS IN INTEGRATED CIRCUITS	129	2270
ND ELECTRICAL PROPERTIES OF PECVD SIN WITH THEIR COMPOSITION	**RATIOS** THE CORRELATIONS BETWEEN PHYSICAL A	129	1773
TION TECHNIQUES FOR THE MEASUREMENT OF KINETICS OF ELECTRODE	**REACTIONS** ERROR ANALYSIS OF THE POTENTIAL AND VOLT	129	1943
OF A CELL FOR ELECTRODE KINETIC INVESTIGATIONS OF FUEL CELL	**REACTIONS** DESIGN	129	135
KINETICS OF THE F,F2/B4C GASIFICATION	**REACTIONS**	129	1105
OVERDISCHARGE OF LI/SO2 CELLS CHARACTERIZATION OF	**REACTIONS** AND PRODUCTS OF THE DISCHARGE AND FORCED	129	1857
DSC STUDY OF TWO	**REACTIONS** IN THE LITHIUM-BORON ALLOY SYSTEM	129	1513
ELECTROCHEMICAL INVESTIGATIONS OF ALKALI-METAL INTERCALATION	**REACTIONS** IN TIS2: CHRONOAMPEROMETRIC DETERMINATIO	129	682
ELECTROCHEMICAL INVESTIGATIONS OF ALKALI-METAL INTERCALATION	**REACTIONS** IN TIS2: CYCLIC VOLTAMMETRY AND CHRONOCO	129	677
ION OF B-1900 AND NASA-TRW VIA CHEMICAL	**REACTIONS** INVOLVED IN THE INITIATION OF HOT CORROS	129	571
ND (III) OXIDES IN LICL-KCL EUTECTIC MELT AT 470DEGREE C	**REACTIONS** OF FORMATION AND STABILITY OF IRON(II) A	129	1450
DIUM MIXED SULFATE FORMATION AND LOW TEMPERATURE HOT CORROSI	**REACTIONS** OF SO2(SO3) WITH NIO-NA2SO4 IN NICKEL-SO	129	1613
HOTOCHEMICAL PRODUCTION, INFRARED ABSORPTIVITY, AND CHEMICAL	**REACTIONS** OF TRICHLOROSILANOL IN SILICON TETRACHLO	129	1619
ANODIC OXIDE FILMS AND ELECTROCHEMICAL	**REACTIONS** ON CDO.2HGO.8TE	129	1710
ANODIC OXIDE FILMS AND ELECTROCHEMICAL	**REACTIONS** ON HGTE	129	739
VATION OF RUO2 AND PTO ELECTRODE SURFACES FOR IMMOBILIZATION	**REACTIONS** USING THIONYL CHLORIDE ACTI	129	756
LINE SI SELECTIVE	**REACTIVE** ION BEAM ETCHING OF SIO2 OVER POLYCRYSTAL	129	396
ON OF A KAUFMAN ION SOURCE AND DETAILS OF SIO2 ETCHING	**REACTIVE** ION BEAM ETCHING WITH CF4: CHARACTERIZATI	129	585
TRANSIENT SPECTROSCOPY CHARACTERIZATION OF	**REACTIVE** ION ETCHED SILICON SURFACE BY DEEP LEVEL	129	2823
THE EFFECTS OF MIXING N2 IN CCL4 ON ALUMINUM	**REACTIVE** ION ETCHING	129	2522
	REACTIVE ION ETCHING OF SILICON DIOXIDE	129	1152
A AND TRIFLUOROMETHANE. THE ROLE OF NITROGEN IN THE DISCHARG	**REACTIVE** ION ETCHING OF SILICON OXIDES WITH AMMONI	129	1036
HORUS INCORPORATION DURING SILICON EPITAXIAL GROWTH IN A CVD	**REACTOR** PHOSP	129	1122
HETEROGENEOUS DECOMPOSITION OF SILANE IN A FIXED BED	**REACTOR**	129	1531
RATURE AND PARTIAL PRESSURE BY RAMAN SCATTERING INSIDE A CVD	**REACTOR** DETERMINATION OF TEMPE	129	2338
PHENOMENOLOGICAL MODEL OF THE CVD EPITAXIAL	**REACTOR**	129	1627
ENERGY ANALYSIS OF A STEADY-STATE ELECTROCHEMICAL	**REACTOR**	129	1936

GAS FLOW PATTERNS IN HORIZONTAL EPITAXIAL
H2 PARAMETER AND
CURRENT DISTRIBUTION IN PARALLEL-PLATE ELECTROCHEMICAL FLOW
UMINUM OXIDE FILM RUPTURE,
CHARACTERIZATION OF ETHER ELECTROLYTES FOR
RRENT AT P-TYPE III-V ELECTRODES THE INFLUENCE OF SURFACE
ISTICS OF ILLUMINATED SURFACE BARRIER CELLS
AND INTERRELATION STUDY OF STABILIZATION AND SURFACE
LENGTH CHARGE COLLECTION MICROSCOPY ON P-WSE2:
DETERIORATED A-C POWDER EL CELL BRIGHTNESS
P-HEATER OVEN ZONE-MELTING
LICON BY CW LASER IRRADIATI ANOMALOUS LOCAL OXIDATION AND
3+) A
II. COBALT(III)-COBALT(II) COMPLEXES WITH O-PHE SOLUTION
OPERATING PERFORMANCE OF AN FE-TI STATIONARY
ND PHOTOELECTROCHEMISTRY OF AN AQUEOUS FERROCENE/FERRICENIUM
PHOTOVOLTAIC CELLS BASED ON N-GAAS AND THE TRIIODIDE/IODIDE
OF P-TYPPE SILICON IN ACETONITRILE SOLUTIONS WITH DIFFERENT
EUDO-REFERENCE ELECTRODE" IN THE MONITORING OF CORROSION AND
CTROHYDRODYNAMICAL IMPEDANCE ON A ROTATING DISK ELECTRODE I.
ENCE OF THE SENSITIVITIES OF METAL-TIO2 JUNCTIONS TO VARIOUS
ON THE MECHANISM OF THIONYL CHLORIDE
THYLANILINIUM) PORPHYRIN ON CATALYSIS OF OXYGEN CATHODIC
BROMINE
DIMETHYLSULFOXIDE: ION-PAIR, PROTONATION, ELECTROCHEMICAL
CTROSYNTHESES ON CHEMICALLY MODIFIED ELECTRODE IV. SELECTIVE
BACTERIA ON METALS IN THE USE OF IN SITU ELECTROCHEMICAL
ES THE ELECTROCHEMICAL
ELECTROCHEMICAL
S ELECTROCHEMICAL BEHAVIOR OF SELECTED IMINE DERIVATIVES,
CONTROLLED COLLAPSE
BORON IMPLANTS IN SILICON DETERMINED BY A FOUR-PHASE COMPLEX
HIGH TEMPERATURE THERMODYNAMIC STUDY OF THE MOLYBDENUM-RICH
HG-TE BINARY SYSTEMS APPLICATION OF THE
ODES ALUMINA "FIBER FP"
LMS ON ZIRCONIUM I. INFLUENCE OF FORMATION CONDITIONS ON E-I
CUINS2 CRYSTALS FROM THE MELT THE PHASE
RATURE LI-AL/LICL-KCL/FES2 CELLS PHASE
BRIDGMAN-TYPE APPARATUS FOR THE STUDY OF GROWTH-PROPERTY
STRUCTURAL COMPOSITION OF POLYMERS
ICS OF E ERROR ANALYSIS OF THE POTENTIAL AND VOLTAGE STEP
ND INDUCED DEFECT BEHAVIOR MULTISTEP
S IN THE SYSTEM CUO-NIO-MGO AT 1000 DEG F.M. BECKET AWARD
ANSFER KINETIC THE COLIN GARFIELD FINK SUMMER FELLOWSHIP
ICALLY MODIFIED THE JOSEPH W. RICHARDS SUMMER FELLOWSHIP
ADSORPTION RATES FOR THE EDWARD WESTON SUMMER FELLOWSHIP
E FOR LIAL/F STATUS CELLS: A DEMONSTRATION OF PERFORMANCE
ECTROCHEMICAL PROPERTIES OF SNO2 FILMS PREPARED FROM ORGANIC
EVALUATION OF PURE NOVOLAK CRESOL-FORMALDEHYDE
A DRY DEVELOPMENT MODEL FOR A POSITIVE ELECTRON BEAM
IMPROVED DRY ETCHING RESISTANCE OF ELECTRON-BEAM
RESOLUTION LIMIT OF NEGATIVE ELECTRON
SPIN-ON GLASS AS AN INTERMEDIATE LAYER IN A TRI-LAYER
GRAPHIC EVALUATION OF AN O-NITROBENZYL ESTER BASED DEEP U.V.
IONS HIGH RESOLUTION ELECTRON BEAM NEGATIVE
TION AND THE RELATION BETWEEN SPREADING RESISTANCE AND SHEET
ATED STEEL ANODES FOR ALKALINE WATER ELECTROLYSIS: CORROSION
ING EXPERIMENT SIMULATION AND THE RELATION BETWEEN SPREADING
ES ON AN ELECTRODE
ICATION ATMOSPHERES THE ROLE OF CHROMIUM IN THE CORROSION
ICATION AT THE ROLE OF SILICON ADDITIONS IN THE CORROSION
PROCESS IMPROVED DRY ETCHING
CORROSION
FFECTS OF PROBE-CURRENT DENSITY AND LAYER THICK SPREADING
PLANTATION INTO SILICON: ITS MATERIAL COMPOSITION, OXIDATION
DES
FACTORS AFFECTING THE SENSITIVITY OF CROSS-LINKED POSITIVE
LED CONTRAST (GAMMA-VALUE) MEASUREMENTS OF POSITIVE ELECTRON
A METHOD FOR OBSERVING MICROMETER-SIZE DEFECTS IN
ETHYL METHACRYLATE COPOLYMERS AS ELECTRON SENSITIVE POSITIVE
ESR STUDIES OF NEGATIVE ELECTRON
NARROW MOLECULAR WEIGHT DISTRIBUTIONS HIGH
ED ON A THIN FILM SUBSTRATE
L METHACRYLATE MASKING MEDIUM HIGH
ING GAAS SUBSTRATES SPATIALLY
DITHIOZONE ANION ADSORPTION AT AG USING SURFACE ENHANCED AND
A POINT DEFECT MODEL FOR ANODIC PASSIVE FILMS III. IMPEDANCE
RECIPITATION ON DIFFERENT CONDUCTING THE ELECTROCHEMICAL
THE A-C
THE CATION CONCENTRATION
RODE CELLS EQUIVALENT CIRCUIT ANALYSIS OF THE IMPEDANCE
UNDS (MPX3) PHOTOELECTROCHEMICAL
SMALL-SIGNAL A-C
ISPLAYS EFFECT OF ACTIVE SURFACE AREA ON THE
HOTOELECTROCHEMICAL CELLS LOCAL SPECTRAL
R LI BATTERIES SOME
LS: A DEMONSTRATION OF PERFORMANCE REPRODUCIBILITY, CAPACITY
CHEMICAL MODIFICATION OF

	Vol	Page
REACTOR CELLS OBSERVED BY INTERFERENCE HOLOGRAPHY	129	634
REACTOR DEPENDENCE OF SELECTIVE OXIDE RIE IN CF4 +	129	2282
REACTORS EFFECTS OF SEPARATOR AND TERMINAL ON THE	129	1670
REANODIZATION, AND STRESS CORROSION CRACKING IN AL	129	2660
RECHARGEABLE LITHIUM CELLS	129	2404
RECOMBINATION AND TRAPPING ON THE CATHODIC PHOTOCU	129	730
RECOMBINATION EFFECTS ON CURRENT-VOLTAGE CHARACTER	129	1134
RECOMBINATION ON N-GAP PHOTOELECTRODES: MECHANISMS	129	546
RECOMBINATION SITES AND MINORITY CARRIER DIFFUSION	129	418
RECOVERY	129	362
RECRYSTALLIZATION OF SI FILMS WITH A MOVEABLE-STRI	129	2812
RECRYSTALLIZATION OF VACUUM-DEPOSITED AMORPHOUS SI	129	888
RED PHOSPHOR OF HIGH LUMEN EQUIVALENT, Y2W3O12:EU(	129	2296
REDOOX COUPLES FOR EELECTROCHEMICAL ENERGY STORAGE	129	61
REDOX BATTERY IN THE PRESENCE OF LEAD	129	2502
REDOX COUPLE AT PLATINUM, N-SILICON AND N-INDIUM P	129	1987
REDOX COUPLE IN ACETONITRILE ELECTROCHEMICAL	129	1705
REDOX COUPLES SEMICONDUCTOR ELECTRODES XLII. EVIDE	129	1742
REDOX POTENTIALS AT 285DEGREE C USE OF A HIGH TEMP	129	1445
REDOX SYSTEM ELE	129	107
REDUCING GASES TEMPERATURE DEPEND	129	444
REDUCTION	129	1853
REDUCTION BY ADSORBED IRON(111)-TETRA (N,N,N-TRIME	129	2247
REDUCTION IN A TWO-PHASE ELECTROLYTE	129	2397
REDUCTION OF NICOTINAMIDE ADENINE DINUCLEOTIDE IN	129	1960
REDUCTION OF O-NITROPHENOL IN THE PRESENCE OF P-NI	129	1681
REDUCTION OF OXYGEN IN THE DIMINUTION OF ADSORBED	129	2178
REDUCTION OF RUST FILMS ON WEATHERING STEEL SURFAC	129	2686
REDUCTION OF THIOPHOSGENE IN ACETONITRILE	129	529
REDUCTIVE CARBOXYLATION, ALPHA-AMINO ACID SYNTHESI	129	1231
REFILLING SILICON GROOVES BY LIQUID PHASE EPITAXY	129	2819
REFLOW FOR JOSEPHSON CHIP BONDING	129	859
REFRACTIVE INDEX MODEL OPTICAL CONSTANTS OF ARSENI	129	606
REGIONS OF THE MO-AL SYSTEM	129	2613
REGULAR ASSOCIATED SOLUTION MODEL TO THE CD-TE AND	129	2360
REINFORCED PURE LEAD COMPOSITES FOR BATTERY ELECTR	129	1749
RELATIONS A STUDY BY NUCLEAR MICROANALYSIS AND 180	129	1895
RELATIONS IN THE CU,IN,S SYSTEM AND THE GROWTH OF	129	1570
RELATIONSHIPS IN POSITIVE ELECTRODES OF HIGH TEMPE	129	925
RELATIONSHIPS: ARSENIC VAPOR PRESSURE-GAAS PROPERT	129	388
RELATIVE TO THEIR PLASMA ETCH CHARACTERISTICS	129	205
RELAXATION TECHNIQUES FOR THE MEASUREMENT OF KINET	129	1943
REPEATED ANNEALING FOR CZ-SILICON WAFERS: OXYGEN A	129	2089
REPORT--AN X-RAY POWDER DIFFRACTION STUDY OF PHASE	129	31C
REPORT--DETERMINATION OF HETEROGENEOUS ELECTRON TR	129	298C
REPORT--FOURIER TRANSFORM INFRARED STUDIES OF CHEM	129	300C
REPORT--QUANTITATION OF ADSORPTION PARAMETERS AND	129	295C
REPRODUCIBILITY, CAPACITY RETENTION, AND CYCLE LIF	129	2701
RESINATE SOLUTION STUDIES ON PHOTOEL	129	1501
RESINS FOR DEEP U.V. LITHOGRAPHY	129	201
RESIST	129	2598
RESIST BY ION EXPOSURE PROCESS	129	2556
RESIST EXPOSED ON A THIN FILM SUBSTRATE	129	1831
RESIST PROCESS	129	2152
RESIST SYSTEM LITHO	129	2552
RESIST WITH VERY NARROW MOLECULAR WEIGHT DISTRIBUT	129	663
RESISTANCE PROBE-SPACING EXPERIMENT SIMULA	129	599
RESISTANCE POROUS NICKEL-CO	129	310
RESISTANCE AND SHEET RESISTANCE PROBE-SPAC	129	599
RESISTANCE OF A PLANAR ARRAY OF SPHERES: GAS BUBBL	129	2715
RESISTANCE OF ALUMINA-FORMING ALLOYS IN COAL GASIF	129	789
RESISTANCE OF CHROMIA-FORMING ALLOYS IN COAL GASIF	129	782
RESISTANCE OF ELECTRON-BEAM RESIST BY ION EXPOSURE	129	2556
RESISTANCE OF MICROCRYSTALLINE STAINLESS STEELS	129	1402
RESISTANCE PROBE-SPACING EXPERIMENT SIMULATIONS: E	129	2788
RESISTANCE, AND ELECTRICAL CHARACTERISTICS LOW ENE	129	408
RESISTIVITIES OF THIN FILM TRANSITION METAL SILICI	129	293
RESISTS	129	402
RESISTS DETAI	129	2576
RESISTS	129	2384
RESISTS STUDIES OF METHACRYLONITRILE AND TRICHLORO	129	1596
RESISTS PGMA AND PST	129	1070
RESOLUTION ELECTRON BEAM NEGATIVE RESIST WITH VERY	129	663
RESOLUTION LIMIT OF NEGATIVE ELECTRON RESIST EXPOS	129	1831
RESOLUTION PHOTOMASKS WITH ION-BOMBARDED POLYMETHY	129	827
RESOLVED CATHODOLUMINESCENCE STUDY OF SEMI-INSULAT	129	2386
RESONANCE ENHANCED RAMAN SPECTROSCOPY THE EDWARD W	129	295C
RESPONSE	129	1874
RESPONSE OF NICKEL HYDROXIDE FORMED BY COLLOIDAL P	129	301
RESPONSE OF NICKEL OXIDE ELECTRODE FILMS	129	535
RESPONSE OF POLYMER GATE ISFET	129	141
RESPONSE OF SEMICONDUCTOR/ELECTROLYTE/COUNTERELECT	129	551
RESPONSE OF SOME LAYERED CHALCOGENOPHOSPHATE COMPO	129	237
RESPONSE THEORY FOR ELECTROCHROMIC THIN FILMS	129	1754
RESPONSE TIME OF ELECTROCHROMIC AND ELECTROLYTIC D	129	2451
RESPONSES OF TRANSITION METAL DICHALCOGENIDES IN P	129	1237
RESTATEMENTS ON THE NATURE AND BEHAVIOR OF MNO2 FO	129	1861
RETENTION, AND CYCLE LIFE FOR LIAL/FES CELLS STATU	129	2701
RETICULATED VITREOUS CARBON	129	2505

	Vol	Page
L STUDY OF MOTION OF ELECTRONS AND HOLES IN Y2O2S CRYSTAL AS	129	1535
RUCTURE A SIMPLE DAMAGE-FREE GROOVING METHOD FOR	129	2082
THE HAZARDS OF LI/SOCL2 BATTERIES DURING ANODE-LIMITED CELL	129	2496
YING INTERFACIAL PROPERTIES OF INORGANIC SOLUTES RELEVANT TO	129	1485
EDANCE TECHNIQUE STUDY OF AGF-LAF3	129	660
DRY ETCHING FOR VLSI--A	129	62C
POLYMERIZATION OF AROMATIC SILANES IN	129	180
F PLASMA ETCH PROFILES WITH PLASMA SHEATH ELECTRIC FIELD AND	129	2541
LOW DISLOCATION DENSITY	129	2858
SSOCIATED WITH CARBON AND OXYGEN TRANSPORT IN EFG OF SILICON	129	1356
SOLAR CELLS PURIFICATION OF	129	864
RM INFRARED STUDIES OF CHEMICALLY MODIFIED THE JOSEPH W.	129	300C
	129	1822
PARAMETER AND REACTOR DEPENDENCE OF SELECTIVE OXIDE	129	2282
DERPOTENTIAL DEPOSITION OF SILVER ON GOLD USING THE ROTATING	129	1202
PHOTOANODIC DISSOLUTION OF N-CDS STUDIED BY ROTATING	129	149
IMPACT OF DEIONIZED WATER	129	1027
GOLD-CONTAINING SURFACE STATES ON PHOTOGRAPHIC AGBR GRAINS:	129	591
LOW ENERGY NITROGEN ION IMPLANTATION INTO SILICON	129	379
HEMICAL AND SPECTROSCOPIC STUDIES OF 9,10-ANTHRAQUINONE IN A	129	2488
NE SOLUTIONS I. STUDY OF ALTERNATING VOLTAGE MODULATION ON A	129	2677
ELECTROHYRODYNAMICAL IMPEDANCE ON A	129	107
ALUATE RATE CONSTANTS FOR HYDROGEN PEROXIDE DECOMPOSITION AT	129	2268
NG THE UNDERPOTENTIAL DEPOSITION OF SILVER ON GOLD USING THE	129	1202
PHOTOANODIC DISSOLUTION OF N-CDS STUDIED BY	129	149
REACTIONS USING THIONYL CHLORIDE ACTIVATION OF	129	756
OR OF CDS ELECTRODES THE EFFECT OF SPUTTERED	129	1733
ING IN ALUMINUM OXIDE FILM	129	2660
THE ELECTROCHEMICAL REDUCTION OF	129	2686
INE EVOLUTION SURFACE STRUCTURE OF	129	1689
TT-SCHOTTKY PLOTS AND FLATBAND POTENTIALS FOR SINGLE CRYSTAL	129	1973

— S —

COMPLEXING OF AL(+3) BY	129	2034
CALCIUM-CA(ALCL4)2-THIONYL CHLORIDE CELL: PERFORMANCE AND	129	451
C STUDIES OF 9,10-ANTHRAQUINONE IN A ROOM-TEMPERATURE MOLTEN	129	2488
LI-GE ALLOYS: APPLICATION TO NEGATIVE ELECTRODES FOR MOLTEN	129	246
D DECAMETHYL FERROCENE AT THE N-GAAS/ROOM TEMPERATURE MOLTEN	129	560
EMICAL CHARACTERIZATION OF THE N-INP/ROOM TEMPERATURE MOLTEN	129	2009
FORMATION OF	129	2412
HARGE CHARACTERISTICS OF LITHIUM-BORON ALLOY ANODE IN MOLTEN	129	1168
HEMICAL STUDIES ON LITHIUM INTERCALATION MATERIALS IN MOLTEN	129	970
ON PAIRING IN COMPLEXES OF POLY(ETHYLENE OXIDE) WITH LITHIUM	129	1434
IC CONDUCTIVITY IN COMPLEXES OF POLYETHERS WITH ALKALI METAL	129	1694
PLORATORY STUDIES ON ELECTROLYSIS OF AIN DISSOLVED IN MOLTEN	129	102
R/GAS TURBINE COMBI VOLATILIZATION/CONDENSATION OF ALKALI	129	2119
IDE PHOTOELECTROCHEMICAL CELLS THE EFFECT OF ADDED	129	143
A SECTIONING TECHNIQUE FOR DEMOUNTABLE SEMICONDUCTOR	129	448
MICROSCALE CHARACTERIZATION OF HETEROEPITAXIAL SILICON ON	129	2609
PHOSPHORS AT HIGH CURRENT DENSITIES I. EXPERIMENTAL PHENOMEN	129	1546
MICAL METHODS FOR THE DEPOSITION OF THIN FILMS OF SB2SE3 AND	129	1642
CHEMICAL METHODS FOR THE DEPOSITION OF THIN FILMS OF	129	1642
PEG FORMATION BY SHORT-CIRCUIT DIFFUSION IN AL2O3	129	1147
MPUTER SIMULATION OF THE DIFFUSIONAL GROWTH OF TERNARY OXIDE	129	209
S A	129	746
RPHOUS INSULATORS: GROWTH BY LATERAL NUCLEATED EPITAXY USING	129	2802
E CHARACTERIZATION OF HETEROEPITAXIAL SILICON ON SAPPHIRE BY	129	2609
COPPER SURFACE ENHANCED RAMAN	129	1716
DETERMINATION OF TEMPERATURE AND PARTIAL PRESSURE BY RAMAN	129	2338
	129	1795
CHARACTERISTICS OF INP MIS	129	221
SPUTTER ETCHING EFFECTS ON GAAS	129	2760
TROCHEMICAL ENGINEERING AND TECHNOLOGY MEDALIST JOSEPH C.	129	395C
SURFACE ENHANCED RAMAN SCATTERING IN CORROSION	129	1716
AN ELECTROCHEMICALLY	129	1865
F OXYGEN IN THE DIMINUTION OF ADSORBED BACTERIA ON METALS IN	129	2178
F OCCLUDED CELLS IN THE PITTING OF DILUTE ALUMINUM ALLOYS IN	129	137
IONS ANODIC LEVELING UNDER	129	946
OF NEAR SURFACE COMPOSITION OF BOROSILICATE GLASSES (BSG) BY	129	1819
PHTHALOCYANINE CATHODE MATERIALS FOR	129	5
A	129	448
DIFFUSION AND	129	1097
O-W) FROM WC-CO CEMENTED CARBIDES IN PARTICULATE BED ELECTRO	129	2666
HIGH-SPEED	129	2424
ELECTRODE IV. SELECTIVE REDUCTION OF O-NITROPHENOL IN THE PR	129	1681
	129	194
	129	2380
THE SUSPENDED MESH ION	129	2580
EQUILIBRIUM NOISE IN ION	129	2306
AND ELIMINATION OF GATE OXIDE DEFECT ORIGIN PRODUCED DURING	129	800
	129	2559
PARAMETER AND REACTOR DEPENDENCE OF	129	2282
	129	396
ECTIVE ELECTROSYNTHESES ON CHEMICALLY MODIFIED ELECTRODE IV.	129	1681
CID BATTERIES DURING STORAGE	129	458
	129	1393
POSITION GRADIENTS. MOLTEN NANO3-AGNO3 IN POROUS YTTRIA	129	931
F TWO OR MORE INTERSECTING PLANES	129	128
ONE-DIMENSIONAL PHOTOLUMINESCENCE DISTRIBUTION IN	129	880

	Vol	Page
REVEALED BY CATHODOLUMINESCENCE AN EXPERIMENTA	129	1535
REVEALING THE QUALITY OF INP/INGAASP MULTILAYER ST	129	2082
REVERSAL SPECTROSCOPIC STUDIES OF	129	2496
REVERSE OSMOSIS SEPARATIONS USE OF LIQUID CHROMATO	129	1485
REVERSIBLE INTERFACE BY AUGER SPECTROSCOPY AND IMP	129	660
REVIEW	129	62C
RF PLASMAS	129	180
RF POWER DENSITY CONTROL O	129	2541
RF-HEATED EPITAXIAL SILICON	129	2858
RIBBON MODELING OF AMBIENT-MENISCUS MELT INTERACTI	129	1356
RICE HULLS AS A SOURCE OF SOLAR GRADE SILICON FOR	129	864
RICHARDS SUMMER FELLOWSHIP REPORT--FOURIER TRANSFO	129	300C
RIE CONTAMINATION OF ETCHED SILICON SURFACES	129	1822
RIE IN CF4 + H2	129	2282
RING-DISK ELECTRODE INTERPRETATION OF POTENTIOSTAT	129	1202
RING-DISK ELECTRODES	129	149
RINSES ON SILICON SURFACE CLEANING	129	1027
ROLES BESIDES PHOTOELECTRON-TRAPPING	129	591
ROOM TEMPERATURE FORMATION OF SI-NITRIDE FILMS BY	129	379
ROOM-TEMPERATURE MOLTEN SALT ELECTROC	129	2488
ROTATIING DISK ELECTRO"_ ZINC ELECTRODE MORPHOLOGY	129	2677
ROTATING DISK ELECTRODE I. REDOX SYSTEM	129	107
ROTATING DISK ELECTRODES COMMENTS ON THE VAN DER B	129	2268
ROTATING RING-DISK ELECTRODE INTERPRETATION OF POT	129	1202
ROTATING RING-DISK ELECTRODES	129	149
RUO2 AND PTO ELECTRODE SURFACES FOR IMMOBILIZATION	129	756
RUO2 OVERLAYERS ON THE PHOTOELECTROCHEMICAL BEHAVI	129	1733
RUPTURE, REANODIZATION, AND STRESS CORROSION CRACK	129	2660
RUST FILMS ON WEATHERING STEEL SURFACES	129	2686
RUTHENIUM DIOXIDE ELECTRODES AND KINETICS OF CHLOR	129	1689
RUTILE ELECTRODES MO	129	1973

	Vol	Page
S(-2) IONS IN ALKALI HALIDE MELTS	129	2034
SAFETY	129	451
SALT ELECTROCHEMICAL AND SPECTROSCOPI	129	2488
SALT BATTERIES THERMODYNAMIC STUDIES OF	129	246
SALT ELECTROLYTE INTERFACE PHOTOELECTROCHEMICAL OX	129	560
SALT ELECTROLYTE INTERFACE PHOTOELECTROCH	129	2009
SALT FILMS DURING PASSIVATION OF IRON	129	2412
SALT THERMAL CELLS DISC	129	1168
SALTS ELECTROC	129	970
SALTS VIBRATIONAL SPECTROSCOPIC DETERMINATION OF S	129	1434
SALTS CONFORMATION AND ION-TRANSPORT MODELS FOR TH	129	1694
SALTS EX	129	102
SALTS IN A PRESSURIZED FLUIDIZED BED COAL COMBUSTO	129	2119
SALTS ON THE STABILITY OF CD-CHALCOGENIDE/POLYSULF	129	143
SAMPLES	129	448
SAPPHIRE BY SCANNING PHOTOVOLTAGE MEASUREMENTS	129	2609
SATURATION OF (ZN, CD)S:CU, AL CATHODOLUMINESCENT	129	1546
SB2O3 CHE	129	1642
SB2SE3 AND SB2O3	129	1642
SCALES CONTAINING OXIDE DISPERSIONS	129	1147
SCALES ON BINARY ALLOYS CO	129	209
SCAN RATE DEPENDENT DETERMINATION OF PLATINUM AREA	129	746
SCANNING LASER AND ELECTRON BEAMS AND EVALUATION B	129	2802
SCANNING PHOTOVOLTAGE MEASUREMENTS MICROSCAL	129	2609
SCATTERING IN CORROSION SCIENCE: BENZOTRIAZOLE ON	129	1716
SCATTERING INSIDE A CVD REACTOR	129	2338
SCHOTTKY CONTACT FABRICATION FOR GAAS MESFET'S	129	1795
SCHOTTKY DIODES PREPARED BY PLASMA OXIDATION	129	221
SCHOTTKY JUNCTIONS	129	2760
SCHUMACHER--VITTORIO DE NORA-DIAMOND SHAMROCK ELEC	129	395C
SCIENCE: BENZOTRIAZOLE ON COPPER	129	1716
SEALED AL2O3 PASSIVATION LAYER FOR ALUMINUM ALLOYS	129	1865
SEAWATER THE USE OF IN SITU ELECTROCHEMICAL REDUCT	129	2178
SEAWATER MORPHOLOGICAL STUDIES O	129	137
SECONDARY AND TERTIARY CURRENT DISTRIBUTION CONDIT	129	946
SECONDARY ION MASS SPECTROMETRY (SIMS) CHARACTERIZ	129	1819
SECONDARY LITHIUM CELLS	129	5
SECTIONING TECHNIQUE FOR DEMOUNTABLE SEMICONDUCTOR	129	448
SEGREGATION OF LOW-DOSE IMPLANTED BORON IN SILICON	129	1097
SELECTIVE DISSOLUTION OF THE BINDER PHASE ALLOY (C	129	2666
SELECTIVE ELECTROPLATING WITH SINGLE CIRCULAR JETS	129	2424
SELECTIVE ELECTROSYNTHESES ON CHEMICALLY MODIFIED	129	1681
SELECTIVE EPITAXIAL GROWTH OF GAAS BY LIQUID PHASE	129	194
SELECTIVE ETCHING CHARACTERISTICS OF PEROXIDE/AMMO	129	2380
SELECTIVE FIELD EFFECT TRANSISTOR	129	2580
SELECTIVE FIELD EFFECT TRANSISTORS	129	2306
SELECTIVE FIELD OXIDATION IDENTIFICATION	129	800
SELECTIVE ISOTROPIC DRY ETCHING OF SI3N4 OVER SIO2	129	2559
SELECTIVE OXIDE RIE IN CF4 + H2	129	2282
SELECTIVE REACTIVE ION BEAM ETCHING OF SIO2 OVER P	129	396
SELECTIVE REDUCTION OF O-NITROPHENOL IN THE PRESEN	129	1681
SELF-DISCHARGE AND PASSIVATION PHENOMENA IN LEAD-A	129	458
SELF-DISCHARGE IN ACID-STARVED LEAD-ACID BATTERIES	129	1393
SEM/EDX AND AA MEASUREMENTS OF CURRENT-INDUCED COM	129	931
SEMI-INFINITE DIFFUSION TO ELECTRODES CONSISTING O	129	128
SEMI-INSULATING GAAS GROWN BY CZ AND HB METHODS	129	880

		Vol	Page
SPATIALLY RESOLVED CATHODOLUMINESCENCE STUDY OF	**SEMI-INSULATING** GAAS SUBSTRATES	129	2386
SIMS STUDIES OF 9BE IMPLANTS IN	**SEMI-INSULATING** INP	129	1312
SIMS STUDIES OF	**SEMI-INSULATING** INP AMORPHIZED BY MG AND SI	129	1320
CELL BASED ON CHEMICALLY DEPOSITED BI2S3 THIN FILM AND SOME	**SEMICONDUCTING** PROPERTIES OF BISMUTH CHALCOGENIDES	129	332
QUEOUS AND NONAQUEOUS ELECTROL CHARACTERIZATION OF N-TYPE	**SEMICONDUCTING** TUNGSTEN DISULFIDE PHOTOANODES IN A	129	1461
ELECTROCHEMICAL SOLAR CELLS WITH LAYER-TYPE	**SEMICONDUCTOR** ANODES. NONAQUEOUS ELECTROLYTE CELLS	129	1155
THE FEATHERING OF DOPING STRIATIONS IN	**SEMICONDUCTOR** CRYSTALS	129	1782
NITRIDIZATION PASSIVATION MECHANISM FOR GAAS AND OTHER III-V	**SEMICONDUCTOR** DEVICES, INCLUDING INGAAS LONG WAVEL	129	821
L CHARACTERIZATION OF	**SEMICONDUCTOR** ELECTRODES WITH A DEEP IMPURITY LEVE	129	2219
RMANCE OF N-WSE2 ELECTRODES BY ELECTROCHEMICAL POLYMERIZATIO	**SEMICONDUCTOR** ELECTRODES XLII. IMPROVEMENT OF PERFO	129	265
LEVEL PINNING FROM SHIFTS IN THE FLATBAND POTENTIAL OF P-TYP	**SEMICONDUCTOR** ELECTRODES XLII. EVIDENCE FOR FERMI	129	1742
Y OF N- AND P-TYPE MOTE2 IN AQUEOUS SOLUTIONS	**SEMICONDUCTOR** ELECTRODES XLV. PHOTOELECTROCHEMISTR	129	2224
SILICON ELECTRODES IN AQUEOUS SOLUTION PHOTOELECTROCHEMICAL	**SEMICONDUCTOR** ELECTRODES XLVI. STABILIZATION OF N-	129	1647
AT POLYCRYSTALLINE P-TYPE WSE2 FILMS	**SEMICONDUCTOR** ELECTRODES 44. PHOTOELECTROCHEMISTRY	129	673
VARIATION OF SPUN-ON THIN FILMS COMMONLY ASSOCIATED WITH THE	**SEMICONDUCTOR** INDUSTRY AN INVESTIGATION OF THE THI	129	173
CHEMICALLY DEPOSITED BI2S3 THIN FILM AND SOME SEMICONDUCTING	**SEMICONDUCTOR** LIQUID JUNCTION SOLAR CELL BASED ON	129	332
F LEAD DIOXIDE A	**SEMICONDUCTOR** MODEL FOR THE CATHODIC PASSIVATION O	129	1880
A SECTIONING TECHNIQUE FOR DEMOUNTABLE	**SEMICONDUCTOR** SAMPLES	129	448
MICAL TRANSFER VIA SURFACE STATES: A NEW FORMULATION FOR THE	**SEMICONDUCTOR/ELECTROLYTE** INTERFACE ELECTROCHE	129	963
AIN IMPE THE DETERMINATION OF SURFACE STATE ENERGIES AT A	**SEMICONDUCTOR/ELECTROLYTE** INTERFACE BY LAPLACE DOM	129	2147
EQUIVALENT CIRCUIT ANALYSIS OF THE IMPEDANCE RESPONSE OF	**SEMICONDUCTOR/ELECTROLYTE/COUNTERELECTRO** CELLS	129	551
ROSCOPY: A NEW METHOD FOR CHARACTERIZATION OF DEEP LEVELS IN	**SEMICONDUCTORS** ELECTROCHEMICAL PHOTOCAPACITANCE SP	129	891
LOW TEMPERATURE DOUBLE-PLASMA PROCESS FOR BN FILMS ON	**SEMICONDUCTORS**	129	2636
CCL4 AND CL2 PLASMA ETCHING OF III-V	**SEMICONDUCTORS** AND THE ROLE OF ADDED O2	129	1599
DEVICES ION-CONTAINING POLYMERS AS	**SEMISOLID** ELECTROLYTES IN WO3-BASED ELECTROCHROMIC	129	1215
TRILE AND TRICHLOROETHYL METHACRYLATE COPOLYMERS AS ELECTRON	**SENSITIVE** POSITIVE RESISTS STUDIES OF METHACRYLONI	129	1596
EDUCING GASES TEMPERATURE DEPENDENCE OF THE	**SENSITIVITIES** OF METAL-TIO2 JUNCTIONS TO VARIOUS R	129	444
FACTORS AFFECTING THE	**SENSITIVITY** OF CROSS-LINKED POSITIVE RESISTS	129	402
PREDICTING RADIATION	**SENSITIVITY** OF POLYMERS	129	811
(Y, IN)2O3 HOST	**SENSITIZATION** MECHANISM OF EU(3+) LUMINESCENCE IN	129	2069
NITORING OF CORROSION AND RE USE OF A HIGH TEMPERATURE PH	**SENSOR** AS A "PSEUDO-REFERENCE ELECTRODE" IN THE MO	129	1445
N OF SURFACE ACCEPTOR STATE DENSITY: APPLICATION FOR ZNO GAS	**SENSORS** CALCULATION OF CARRIER CONCENTRATION IN PO	129	1382
PROPERTIES OF INORGANIC SOLUTES RELEVANT TO REVERSE OSMOSIS	**SEPARATIONS** USE OF LIQUID CHROMATOGRAPHY FOR STUDY	129	1485
IN PARALLEL-PLATE ELECTROCHEMICAL FLOW REACTO EFFECTS OF	**SEPARATOR** AND TERMINAL ON THE CURRENT DISTRIBUTION	129	1670
CERAMIC	**SEPARATORS** FOR LI-AL/IRON SULFIDE BATTERIES	129	2187
INEXPENSIVE CROSS-LINKED POLYMERIC	**SEPARATORS** MADE FROM WATER-SOLUBLE POLYMERS	129	251
ATTERY ELECTROLYTE	**SESSILE** DROP STUDIES ON POLYBROMIDE/ZINC-BROMINE B	129	1747
NDUCTORS IN INTEGRATED CIRCUITS EFFECTS OF	**SEVERAL** PARAMETERS ON THE CORROSION RATES OF AL CO	129	2270
MICROWAVE PLASMA ETCHING OF SI WITH CF4 AND	**SF6** GAS	129	2764
"AL-0.9PERCENT SI/SI OHMIC CONTACTS TO	**SHALLOW** JUNCTIONS	129	1335
Y MEDALIST JOSEPH C. SCHUMACHER--VITTORIO DE NORA-DIAMOND	**SHAMROCK** ELECTROCHEMICAL ENGINEERING AND TECHNOLOG	129	395C
THE OXIDATION OF	**SHAPED** SILICON SURFACES	129	1278
CONTROL OF PLASMA ETCH PROFILES WITH PLASMA	**SHEATH** ELECTRIC FIELD AND RF POWER DENSITY	129	2541
FILAMENT MATERIALS FOR EDGE-SUPPORTED PULLING OF SILICON	**SHEET** CRYSTALS	129	2838
SIMULATION AND THE RELATION BETWEEN SPREADING RESISTANCE AND	**SHEET** RESISTANCE PROBE-SPACING EXPERIMENT	129	599
UCTOR ELECTRODES XLII. EVIDENCE FOR FERMI LEVEL PINNING FROM	**SHIFTS** IN THE FLATBAND POTENTIAL OF P-TYPPE SILICO	129	1742
A NOVEL METHOD FOR MEASUREMENT OF THE CHANNEL LENGTH OF	**SHORT** CHANNEL MOSFET'S	129	1338
OXIDE DISPERSIONS PEG FORMATION BY	**SHORT-CIRCUIT** DIFFUSION IN AL2O3 SCALES CONTAINING	129	1147
ON THE DOPING DEPENDENCE OF OXIDATION-INDUCED STACKING FAULT	**SHRINKAGE** IN SILICON	129	2319
GENERALIZED MODEL FOR THE CLUSTERING OF AS DOPANTS IN	**SI**	129	1826
SIMS STUDIES OF SEMI-INSULATING INP AMORPHIZED BY MG AND	**SI**	129	1320
PLASMA CLEANING ON THE DIELECTRIC BREAKDOWN IN SIO2 FILM ON	**SI** EFFECTS OF	129	224
CTIVE REACTIVE ION BEAM ETCHING OF SIO2 OVER POLYCRYSTALLINE	**SI** SELE	129	396
THERMALLY ACTIVATED OXYGEN DONORS IN	**SI**	129	2844
A BEAM UNDER ULTRAHIGH VACUUM	**SI** AND AL ETCHING AND PRODUCT DETECTION IN A PLASM	129	2045
DOPING OF GA(1-X)AL(X)AS GROWN BY LPE WITH	**SI** AND GE	129	1563
EFFECT OF BACK-SIDE OXIDATION ON B AND P DIFFUSION IN	**SI** DIRECTLY MASKED WITH SI3N4 FILMS	129	2292
PIT TECHNIQUE FOR ANALYZING CRYSTALLOGRAPHIC ORIENTATION IN	**SI** FILMS AN ETCH	129	1848
ZONE-MELTING RECRYSTALLIZATION OF	**SI** FILMS WITH A MOVEABLE-STRIP-HEATER OVEN	129	2812
ROCHEMICAL TEST TO EVALUATE PASSIVATION LAYERS: OVERCOATS OF	**SI** IN INK ELECT	129	2174
AMMONIATE OF SOD PHOTOELECTROCHEMICAL BEHAVIOR OF P-TYPE	**SI** SINGLE CRYSTALS IN LIQUID AMMONIA AND IN LIQUID	129	1998
MICROWAVE PLASMA ETCHING OF	**SI** WITH CF4 AND SF6 GAS	129	2764
WTH OF SIO2 REACTION OF OXYGEN WITH	**SI**(111) AND (100): CRITICAL CONDITIONS FOR THE GRO	129	1300
STUDY OF ENCAPSULANTS FOR ANNEALING	**SI-IMPLANTED** GAAS	129	837
TATION INTO SILICON ROOM TEMPERATURE FORMATION OF	**SI-NITRIDE** FILMS BY LOW ENERGY NITROGEN ION IMPLAN	129	379
FIXED CHARGE DENSITY (QSS) AT THE	**SI-SIO2** INTERFACE FOR THIN OXIDES	129	1757
AL-0.9PERCENT	**SI/SI** OHMIC CONTACTS TO SHALLOW JUNCTIONS	129	1335
ALUMINUM SPUTTER ETCHING USING	**SICL4**	129	1150
FLAWS IN	**SIDEWALL** OXIDES GROWN ON POLYSILICON GATE	129	1084
E PITTING CORROSION OF ALUMINUM A	**SIGNATURE** IN THE CURRENT DURING EARLY EVENTS IN TH	129	340
HETEROGENEOUS DECOMPOSITION OF	**SILANE** IN A FIXED BED REACTOR	129	1531
POLYMERIZATION OF AROMATIC	**SILANES** IN RF PLASMAS	129	180
DIFFUSION AND CHEMICAL REACTION DURING THERMAL TREATMENTS OF	**SILICA** FILMS IN WATER VAPOR AN 18O STUDY OF COOPER	129	867
CVD HYDROPHOBIC LEAD	**SILICATE** FILMS	129	165
APORATION AFT CRYSTALLINE STRUCTURE CHANGES OF MOLYBDENUM	**SILICIDE** FILMS DEPOSITED BY SPUTTERING AND BY COEV	129	1527
PLASMA ETCHING OF COMPOSITE	**SILICIDE** GATE ELECTRODES	129	1330
SOLUTION PHOTOELECTROCHEMICAL CELLS BY FORMATION OF PLATINUM	**SILICIDE** LAYERS SEMICONDUCTOR ELECTRODES XLVI. STA	129	1647
ELECTRICAL PROPERTIES OF COMPOSITE EVAPORATED	**SILICIDE/POLYSILICON** ELECTRODES	129	1307
RESISTIVITIES OF THIN FILM TRANSITION METAL	**SILICIDES**	129	293
I-NITRIDE FILMS BY LOW ENERGY NITROGEN ION IMPLANTATION INTO	**SILICON** ROOM TEMPERATURE FORMATION OF S	129	379
OXYGEN PRECIPITATION FACTORS IN	**SILICON**	129	1062
AT-TREATMENT EFFECT ON BORON IMPLANTATION IN POLYCRYSTALLINE	**SILICON** HE	129	1604
OXIDATION-INDUCED POINT DEFECTS IN	**SILICON**	129	1093
POST-EPITAXIAL POLYSILICON AND SI3N4 GETTERING IN	**SILICON**	129	1294
DIFFUSION OF GOLD IN	**SILICON**	129	1579
ELECTRON MICROSCOPY OF WEB-DENDRITIC	**SILICON**	129	1089
DEPENDENCE OF OXIDATION-INDUCED STACKING FAULT SHRINKAGE IN	**SILICON** ON THE DOPING	129	2319
ON OF HEAVILY PHOSPHORUS-DOPED THIN FILMS OF POLYCRYSTALLINE	**SILICON** THERMAL OXIDATI	129	2321
ETHOD TO MEASURE LATERAL DIFFUSION LENGTH IN POLYCRYSTALLINE	**SILICON** A NOVEL M	129	1635

		Vol	Page
O MEASURE THE PRECIPITATED AND TOTAL OXYGEN CONCENTRATION IN	SILICON	129	1638
THE OXIDATION INHIBITION IN NITROGEN-IMPLANTED	SILICON	129	1803
-TREATMENT STUDIES OF OXYGEN-DEFECT-IMPURITY INTERACTIONS IN	SILICON	129	2127
STUDY OF THE ETCH-STOP MECHANISM IN	SILICON	129	2051
CAPACITANCE TRANSIENT SPECTROSCOPY OF TRACE CONTAMINATION IN	SILICON	129	2098
LOW DISLOCATION DENSITY RF-HEATED EPITAXIAL	SILICON	129	2858
OXIDE MICRO-PRECIPITATES IN AS-GROWN CZ	SILICON	129	2780
SOLUBILITIES OF MAGNESIUM AND CALCIUM IN	SILICON	129	2809
HROMIA-FORMING ALLOYS IN COAL GASIFICATION AT THE ROLE OF	SILICON	129	782
NITRIDATION OF	SILICON	129	2102
MIXTURES PLASMA ETCHING OF	SILICON	129	1770
THIN PALLADIUM FILMS ON	SILICON	129	2689
XIDATION AND RECRYSTALLIZATION OF VACUUM-DEPOSITED AMORPHOUS	SILICON	129	888
THE ENHANCED DIFFUSION OF ARSENIC AND PHOSPHORUS IN	SILICON	129	644
NDENCE, AND ENHANCEM A STUDY ON INTRINSIC GETTERING IN CZ	SILICON	129	374
GH SIO2 LAYERS IMPURITY GETTERING OF	SILICON	129	2527
IVE IN OPTICAL CONSTANTS OF ARSENIC AND BORON IMPLANTS IN	SILICON	129	606
REACTIVE ION ETCHING OF	SILICON	129	1152
EFFECTS OF AMMONIA ANNEAL ON ELECTRON TRAPPINGS IN	SILICON	129	2042
FIELD EFF DETERMINATION OF POSITIVE MOBILE ION DENSITY IN	SILICON	129	2770
CONFORMAL STEP COVERAGE OF LASER DEPOSITED	SILICON	129	2155
PLASMA ETCHING OF SILICON AND	SILICON	129	1770
ALOUS CONCENTRATION PROFILES OF ANTIMONY ATOMS DIFFUSED INTO	SILICON	129	841
PHOSPHORUS INCORPORATION DURING	SILICON	129	1122
DEFECT CONTROL DURING	SILICON	129	1078
METHODS FOR DEFECT EVALUATION OF THIN (100) ORIENTED	SILICON	129	2074
MULTIPLE-ETCHANT LOADING EFFECT AND	SILICON	129	2755
ILE ION DENSITY IN SILICON DIOXIDE BY HYDROGENATED AMORPHOUS	SILICON	129	2770
ELLIPSOMETRY MEASUREMENTS OF POLYCRYSTALLINE	SILICON	129	1347
L PROPERTIES OF THERMALLY AND LASER ANNEALED POLYCRYSTALLINE	SILICON	129	1811
DEGREE TO 725 DEGREE C PROPERTIES OF PLASMA-ENHANCED CVD	SILICON	129	2326
PROPERTIES OF PLASMA-ENHANCED CVD	SILICON	129	2331
ATERAL NUCLEATED EPITAXY USING SCANNING LA SINGLE CRYSTAL	SILICON	129	2802
PURIFICATION OF RICE HULLS AS A SOURCE OF SOLAR GRADE	SILICON	129	864
IDE SOURCE DIFFUSION IN	SILICON	129	2299
REFILLING	SILICON	129	2819
PHOTOELECTROCHEMISTRY OF N- AND P-TYPE	SILICON	129	1982
VEL PINNING FROM SHIFTS IN THE FLATBAND POTENTIAL OF P-TYPPE	SILICON	129	1742
HIGH PRESSURE OXIDATION OF	SILICON	129	2828
ANODIC OXIDATION OF P-TYPE	SILICON	129	2749
HIGH LIFETIME	SILICON	129	665
LSKI TECHNIQUE DYNAMIC OXYGEN EQUILIBRIUM IN	SILICON	129	189
HYDROGEN-IMPLANTED	SILICON	129	1786
TION MOS GATE OXIDE DEFECTS RELATED TO TREATMENT OF	SILICON	129	1066
REMENTS MICROSCALE CHARACTERIZATION OF HETEROEPITAXIAL	SILICON	129	2609
LATERAL EPITAXIAL OVERGROWTH OF	SILICON	129	2303
USION OF OXIDANT IN SIO2 FILMS	SILICON	129	413
LLS POROUS	SILICON	129	596
THE ROLE OF NITROGEN IN THE DISCH REACTIVE ION ETCHING OF	SILICON	129	1036
CTIONS ASSOCIATED WITH CARBON AND OXYGEN TRANSPORT IN EFG OF	SILICON	129	1356
FILAMENT MATERIALS FOR EDGE-SUPPORTED PULLING OF	SILICON	129	2838
A SURVEY OF IRON CONTAMINATION IN	SILICON	129	2573
PY CHARACTERIZATION OF REACTIVE ION ETCHED	SILICON	129	2823
IMPACT OF DEIONIZED WATER RINSES ON	SILICON	129	1027
THE OXIDATION OF SHAPED	SILICON	129	1278
RIE CONTAMINATION OF ETCHED	SILICON	129	1822
ABSORPTIVITY, AND CHEMICAL REACTIONS OF TRICHLOROSILANOL IN	SILICON	129	1619
GROWTH KINETICS OF	SILICON	129	1559
DIFFUSION AND SEGREGATION OF LOW-DOSE IMPLANTED BORON IN	SILICON	129	1097
A MODEL FOR BORON DEPOSITION IN	SILICON	129	1592
MINIMUM	SILICON	129	2835
METAL DECORATED DEFECTS IN HEAT-TREATED	SILICON	129	1128
DEFORMATION OF	SILICON	129	2076
P-TYPE AMORPHOUS	SILICON/LIQUID	129	1644
CATHODIC DEPOSITION OF AMORPHOUS ALLOYS OF	SILICON, CARBON, AND FLUORINE	129	936
TANCE, AND ELECTRIC LOW ENERGY NITROGEN IMPLANTATION INTO	SILICON: ITS MATERIAL COMPOSITION, OXIDATION RESIS	129	408
DE DEEP LEVEL TRANSIENT SPECTROSCOPY OF	SILVER AND GOLD LEVELS IN LEC GROWN GALLIUM ARSENI	129	1353
ARACTERISTICS TARNISHING OF	SILVER BY ORGANIC SULFUR VAPORS: RATES AND FILM CH	129	33
C TRANSIENT BEHAVIOR DURING THE UNDERPOTENTIAL DEPOSITION OF	SILVER ON GOLD USING THE ROTATING RING-DISK ELECTR	129	1202
TIES OF O THE INFLUENCE OF SOLUTE ADDITIONS OF COPPER AND	SILVER ON THE DIFFUSIVITY AND THERMODYNAMIC PROPER	129	430
CTIVITY, PHOTOCONDUCTIVITY, AND LUMINESCENCE STUDIES ON SOME	SILVERSULFAMIDES CONDU	129	365
	SIMS AND AES ANALYSIS OF H:TIO2 ELECTRODES	129	94
	SIMS EVIDENCE CONCERNING WATER IN PASSIVE LAYERS	129	2149
MG AND SI	SIMS STUDIES OF SEMI-INSULATING INP AMORPHIZED BY	129	1320
P	SIMS STUDIES OF 9BE IMPLANTS IN SEMI-INSULATING IN	129	1312
OROSILICATE GLASSES (BSG) BY SECONDARY ION MASS SPECTROMETRY	(SIMS) CHARACTERIZATION OF NEAR SURFACE COMPOSITIO	129	1819
Y CELLS THERMOMECHANICAL BEHAVIOR OF	SIMULATED NEGATIVE ELECTRODES FOR LI-AL/FES BATTER	129	2265
STANCE AND SHEET RESISTANCE PROBE-SPACING EXPERIMENT	SIMULATION AND THE RELATION BETWEEN SPREADING RESI	129	599
	SIMULATION OF CHANGING ELECTRODE PROFILES	129	78
NUMERICAL	SIMULATION OF GATE OXIDE THINNING IN MOS DEVICES	129	831
IDE SCALES ON BINARY ALLOYS COMPUTER	SIMULATION OF THE DIFFUSIONAL GROWTH OF TERNARY OX	129	209
LAYER THICK SPREADING RESISTANCE PROBE-SPACING EXPERIMENT	SIMULATIONS: EFFECTS OF PROBE-CURRENT DENSITY AND	129	2788
ELATIONS BETWEEN PHYSICAL AND ELECTRICAL PROPERTIES OF PECVD	SIN WITH THEIR COMPOSITION RATIOS THE CORR	129	1773
HIGH-SPEED SELECTIVE ELECTROPLATING WITH	SINGLE CIRCULAR JETS	129	2424
MOTT-SCHOTTKY PLOTS AND FLATBAND POTENTIALS FOR	SINGLE CRYSTAL RUTILE ELECTRODES	129	1973
RS: GROWTH BY LATERAL NUCLEATED EPITAXY USING SCANNING LASER	SINGLE CRYSTAL SILICON FILMS ON AMORPHOUS INSULATO	129	2802
N IMPLANTATION	SINGLE CRYSTAL Y3AL5O12:TB PHOSPHOR PRODUCED BY IO	129	816
PREPARATION AND PROPERTIES OF CA2V2O7	SINGLE CRYSTALS	129	2562
MONIATE OF SOD PHOTOELECTROCHEMICAL BEHAVIOR OF P-TYPE SI	SINGLE CRYSTALS IN LIQUID AMMONIA AND IN LIQUID AM	129	1998

		Vol	Page
NERGY-EFFICIENT INSOLUBLE ANODE FOR NICKEL ELECTROWINNING I.	SINGLE LAYER PRECIOUS METAL COATINGS THE DEVELOPME	129	515
DEPOSITION AND DISSOLUTION ON	SINUSOIDAL ELECTRODES	129	316
THE MECHANISM OF OXYGEN DIFFUSION IN VITREOUS	SIO2	129	357
N MOSFET'S DUE TO SUBSTRATE HOT-ELECTRON INJECTION INTO GATE	SIO2 INTERFACE TRAPPED CHARGE GENERATION AND ELECT	129	1760
LATERAL EPITAXIAL OVERGROWTH OF SILICON ON	SIO2	129	2303
SELECTIVE ISOTROPIC DRY ETCHING OF SI3N4 OVER	SIO2	129	2559
ITH SI(111) AND (100): CRITICAL CONDITIONS FOR THE GROWTH OF	SIO2 REACTION OF OXYGEN W	129	1300
EFFECT OF THERMALLY NITRIDED	SIO2 (NITROXIDE) ON MOS CHARACTERISTICS	129	184
FLOW MODEL TO EXPLAIN THE APPEARANCE OF HIGH DENSITY THERMAL	SIO2 AT LOW OXIDATION TEMPERATURES A VISCOUS	129	2594
CF4: CHARACTERIZATION OF A KAUFMAN ION SOURCE AND DETAILS OF	SIO2 ETCHING REACTIVE ION BEAM ETCHING WITH	129	585
EFFECTS OF PLASMA CLEANING ON THE DIELECTRIC BREAKDOWN IN	SIO2 FILM ON SI	129	224
XIDATION STUDIES: MEASUREMENT OF THE DIFFUSION OF OXIDANT IN	SIO2 FILMS SILICON O	129	413
ELECTRON TRAPS IN	SIO2 GROWN IN PRESENCE OF TRICHLOROETHYLENE	129	2772
RING OF SILICON DAMAGE GENERATED BY ION IMPLANTATION THROUGH	SIO2 LAYERS IMPURITY GETTE	129	2527
SELECTIVE REACTIVE ION BEAM ETCHING OF	SIO2 OVER POLYCRYSTALLINE SI	129	396
A NEW DOPING TECHNIQUE WITHOUT	SIO2 PATTERNING USING AN INORGANIC PHOTORESIST	129	1074
OPTICAL ABSORPTION OF THIN	SIPOS FILMS	129	197
CHARGE COLLECTION MICROSCOPY ON P-WSE2: RECOMBINATION	SITES AND MINORITY CARRIER DIFFUSION LENGTH	129	418
THE LPCVD POLYSILICON PHOSPHORUS DOPED IN	SITU AS AN INDUSTRIAL PROCESS	129	1109
MINUTION OF ADSORBED BACTERIA ON METALS IN THE USE OF IN	SITU ELECTROCHEMICAL REDUCTION OF OXYGEN IN THE DI	129	2178
ROWTH IN	SITU MONITORING OF LIQUID PHASE ELECTROEPITAXIAL G	129	2095
DE OXIDATION ON B AND P DIFFUSION IN SI DIRECTLY MASKED WITH	SI3N4 FILMS EFFECT OF BACK-SI	129	2292
POST-EPITAXIAL POLYSILICON AND	SI3N4 GETTERING IN SILICON	129	1294
SELECTIVE ISOTROPIC DRY ETCHING OF	SI3N4 OVER SIO2	129	2559
ELECTROCHEMICAL STUDIES OF COAL	SLURRY OXIDATION MECHANISMS	129	1719
C THIN FILMS	SMALL-SIGNAL A-C RESPONSE THEORY FOR ELECTROCHROMI	129	1754
ABSORPTION DURING ELECTRODEPOSITION AND HYDROGEN CHARGING OF	SN AND CD COATINGS ON IRON HYDROGEN	129	284
THE HIGH SPEED ELECTRODEPOSITION OF	SN/PB ALLOYS	129	1196
STUDIES ON PHOTOELECTROCHEMICAL PROPERTIES OF	SNO2 FILMS PREPARED FROM ORGANIC RESINATE SOLUTION	129	1501
IMPURITY DEPOSITS IN GAS TURBINES FROM FUELS CONTAINING	SODIUM AND VANADIUM	129	649
OF CREVICE CORROSION II. MATHEMATICAL MODEL FOR ALUMINUM IN	SODIUM CHLORIDE SOLUTIONS INITIATION	129	488
N REACTION ON MILD STEEL AND NICKEL CATHODES IN CONCENTRATED	SODIUM HYDROXIDE SOLUTIONS KINETICS OF THE HYDROGE	129	2481
SINGLE CRYSTALS IN LIQUID AMMONIA AND IN LIQUID AMMONIATE OF	SODIUM IODIDE PHOTOELECTROCHEMICAL BEHAVIOR OF P-T	129	1998
P-TYPE AMORPHOUS SILICON/LIQUID JUNCTION	SOLAR CELL	129	1644
N FILM AND SOME SEMICONDUCT SEMICONDUCTOR LIQUID JUNCTION	SOLAR CELL BASED ON CHEMICALLY DEPOSITED BI2S3 THI	129	332
HYDROGENATED A-SI(X)GE(1-X): A POTENTIAL	SOLAR CELL MATERIAL	129	2850
PROCESS FOR HIGH PHOTOCURRENT IN IBC	SOLAR CELLS	129	2624
POROUS SILICON OXIDE ANTI-REFLECTION COATING FOR	SOLAR CELLS	129	596
ICATION OF RICE HULLS AS A SOURCE OF SOLAR GRADE SILICON FOR	SOLAR CELLS PURIF	129	864
THE ROLE OF BE IN (GAAL)AS/GAAS	SOLAR CELLS	129	1623
ND PERFORMANCE OF ELECTRODEPOSITED N-CDSE IN LIQUID JUNCTION	SOLAR CELLS MORPHOLOGY, PROPERTIES, A	129	2016
NONAQUEOUS ELECTROLYTE CELLS ELECTROCHEMICAL	SOLAR CELLS WITH LAYER-TYPE SEMICONDUCTOR ANODES.	129	1155
PURIFICATION OF RICE HULLS AS A SOURCE OF	SOLAR GRADE SILICON FOR SOLAR CELLS	129	864
TRANSPORT NUMBER GRADIENTS AND	SOLID ELECTROLYTE DEGRADATION	129	752
NEW	SOLID ELECTROLYTES BASED ON CUBIC ZRP207	129	726
	SOLID POLYMER ELECTROLYTE PHOTOVOLTAIC CELL	129	894
IUM-SULFIDE VAPORIZATION CHEMISTRY AND THERMODYNAMICS OF	SOLID SOLUTIONS IN THE CADMIUM-INDIUM-SULFIDE, IND	129	1835
STRIATIONS OF KINETIC ORIGIN INDUCED DURING NON-STEADY-STATE	SOLIDIFICATION	129	2355
	SOLUBILITIES OF MAGNESIUM AND CALCIUM IN SILICON	129	2809
	SOLUBILITIES OF OXYGEN IN FUSED LI2CO3-K2CO3	129	1668
TS	SOLUBILITY OF YTTRIUM OXIDE IN NA2SO4 AND NACL MEL	129	2228
SIVITY AND THERMODYNAMIC PROPERTIES OF C THE INFLUENCE OF	SOLUTE ADDITIONS OF COPPER AND SILVER ON THE DIFFU	129	430
OMATOGRAPHY FOR STUDYING INTERFACIAL PROPERTIES OF INORGANIC	SOLUTES RELEVANT TO REVERSE OSMOSIS SEPARATIONS US	129	1485
ICAL PROPERTIES OF SNO2 FILMS PREPARED FROM ORGANIC RESINATE	SOLUTION STUDIES ON PHOTOELECTROCHEM	129	1501
THE STABILITY OF PITTING DISSOLUTION OF METALS IN AQUEOUS	SOLUTION	129	260
PASSIVE FILMS FORMED ON FE-25NI-XCR ALLOYS IN BORATE BUFFER	SOLUTION AN ELLIPSOMETRIC INVESTIGATION OF	129	2419
IN THE PRESENCE OF P-NITROPHENOL WITH ALPHA-CYCLODEXTRIN IN	SOLUTION AND ON ELECTRODE SURFACES SELECTIVE ELECT	129	1681
LYMERS II. SORPTION AND TRANSPORT PROPERTIES IN CONCENTRATED	SOLUTION ENVIRONMENTS A COMPARISON OF PERFLUORINAT	129	328
TRANSPORT PROPERTIES OF NAFION(R) MEMBRANES IN CONCENTRATED	SOLUTION ENVIRONMENTS	129	85
STRUCTURAL AND OPTICAL PROPERTIES OF	SOLUTION GROWN CDSE(1-X)S(X) FILMS	129	99
MS APPLICATION OF THE REGULAR ASSOCIATED	SOLUTION MODEL TO THE CD-TE AND HG-TE BINARY SYSTE	129	2360
RODES XLVI. STABILIZATION OF N-SILICON ELECTRODES IN AQUEOUS	SOLUTION PHOTOELECTROCHEMICAL CELLS BY FORMATION O	129	1647
Y STORAGE II. COBALT(III)-COBALT(II) COMPLEXES WITH O-PHENAN	SOLUTION REDOOX COUPLES FOR EELECTROCHEMICAL ENERG	129	61
OSION II. MATHEMATICAL MODEL FOR ALUMINUM IN SODIUM CHLORIDE	SOLUTIONS INITIATION OF CREVICE CORR	129	488
ACTIVITIES AND SURFACE TENSION OF LIQUID AGCL-LICL	SOLUTIONS	129	502
MS FORMED ON IRON IN AGGRESSIVE AND INHIBITING POLYPHOSPHATE	SOLUTIONS ON THE NATURE OF SURFACE FIL	129	1186
THE ANODIC CORROSION OF GOLD IN CONCENTRATED CHLORIDE	SOLUTIONS	129	1192
XLV. PHOTOELECTROCHEMISTRY OF N- AND P-TYPE MOTE2 IN AQUEOUS	SOLUTIONS SEMICONDUCTOR ELECTRODES	129	2224
ICAL BEHAVIOR OF THE N-TIO2 ELECTRODE IN FLUORIDE-CONTAINING	SOLUTIONS THERMODYNAMIC AND PHOTOELECTROCHEM	129	2132
D STEEL AND NICKEL CATHODES IN CONCENTRATED SODIUM HYDROXIDE	SOLUTIONS KINETICS OF THE HYDROGEN EVOLUTION REACT	129	2481
ICS STUDY OF CAUSTIC CRACKING OF MILD STEEL IN HOT NAOH/NA2S	SOLUTIONS A FRACTURE MECHAN	129	2669
A SURVEY OF NUMERICAL METHODS AND	SOLUTIONS FOR CURRENT DISTRIBUTION PROBLEMS	129	72
CTIVE ETCHING CHARACTERISTICS OF PEROXIDE/AMMONIUM-HYDROXIDE	SOLUTIONS FOR GAAS/AL0.16GA0.84AS SELE	129	2380
ON ON A ROTATIING D ZINC ELECTRODE MORPHOLOGY IN ALKALINE	SOLUTIONS I. STUDY OF ALTERNATING VOLTAGE MODULATI	129	2677
FORMATION OF THIN OXIDE FILMS AT PLATINUM ANODES IN ALKALINE	SOLUTIONS III. PH DEPENDENCE	129	55
LFIDE VAPORIZATION CHEMISTRY AND THERMODYNAMICS OF SOLID	SOLUTIONS IN THE CADMIUM-INDIUM-SULFIDE, INDIUM-SU	129	1835
DIES OF THE FILM FORMATION ON LITHIUM IN PROPYLENE CARBONATE	SOLUTIONS UNDER OPEN-CIRCUIT CONDITIONS ELECTROCHE	129	1422
IN THE FLATBAND POTENTIAL OF P-TYPPE SILICON IN ACETONITRILE	SOLUTIONS WITH DIFFERENT REDOX COUPLES SEMICONDUCT	129	1742
DISULFIDE PHOTOANODES IN AQUEOUS AND NONAQUEOUS ELECTROLYTE	SOLUTIONS. PHOTO-OXIDATION OF HALIDES WITH HIGH EF	129	1461
E AND SULFONATE ION EXCHANGE POLYMERS I. DIFFUSION AND WATER	SORPTION A COMPARISON OF PERFLUORINATED CARBOXYLAT	129	324
ORINATED CARBOXYLATE AND SULFONATE ION EXCHANGE POLYMERS II.	SORPTION AND TRANSPORT PROPERTIES IN CONCENTRATED	129	328
A MODEL FOR BORON DEPOSITION IN SILICON USING A BBR3	SOURCE	129	1592
ION IN SILICON FROM A SPIN-ON HEAVILY PHOSPHORUS-DOPED OXIDE	SOURCE DIFFUS	129	2299
IES OF VAPOR GROWN III-V COMPOUNDS BY COOLING THE HCL LIQUID	SOURCE IMPROVING THE ELECTRICAL PROPERT	129	2566
ION BEAM ETCHING WITH CF4: CHARACTERIZATION OF A KAUFMAN ION	SOURCE AND DETAILS OF SIO2 ETCHING REACTIVE	129	585
PURIFICATION OF RICE HULLS AS A	SOURCE OF SOLAR GRADE SILICON FOR SOLAR CELLS	129	864
TTERIES	SOURCES OF PRESSURE IN LITHIUM THIONYL CHLORIDE BA	129	2453
OSION OF ALLOY 600 EFFECT OF	SO2 AND PH ON THE ANODIC BEHAVIOR AND PITTING CORR	129	2194
LFATE FORMATION AND LOW TEMPERATURE HOT CORR REACTIONS OF	SO2(SO3) WITH NIO-NA2SO4 IN NICKEL-SODIUM MIXED SU	129	1613

	Vol	Page
MI-INSULATING GAAS SUBSTRATES		
ALTERATION OF CORRODENT ION		
TILES		
THE		
SHIP TO FLUOROCARBON POLYMER FOR		
DIFLUOROCARBENE EMISSION		
VE FILM: A MOLECULAR ORBITAL STUDY		
OPTICAL		
IDES IN PHOTOELECTROCHEMICAL CELLS		
LOCAL		
HOPHENANTHROLINE DISULFON		
POLYMER-MODIFIED ELECTRODES II.		
POSITION OF BOROSILICATE GLASSES (BSG) BY SECONDARY ION MASS		
AIRING IN COMPLEXES OF POLY(ETHYLENE OXIDE) W		
VIBRATIONAL		
ATTERIES DURING ANODE-LIMITED CELL REVERSAL		
CHROMIUM ALLOYS		
ELECTRON AND ION		
OOM-TEMPERATURE MOLTEN SALT		
ELECTROCHEMICAL AND		
ZINC BY COBALT IONS		
MOSSBAUER		
AT THE ZNSE-ELECTROLYTE INTERFACE BY PHOTOTHERMAL DEFLECTION		
ON AT AG USING SURFACE ENHANCED AND RESONANCE ENHANCED RAMAN		
REACTIVE ION ETCHED SILICON SURFACE BY DEEP LEVEL TRANSIENT		
STUDY OF AGF-LAF3 REVERSIBLE INTERFACE BY AUGER		
N GALLIUM ARSENIDE		
DEEP LEVEL TRANSIENT		
CAPACITANCE TRANSIENT		
ATURE OF THE PASSIVE FILM ON IRON I. AUTOMATIC ELLIPSOMETRIC		
EDURES		
AUGER ELECTRON		
DEEP LEVELS IN SEMICOND		
ELECTROCHEMICAL PHOTOCAPACITANCE		
RSENATE/DIETHYL ETHER ELECTROLYTES		
THE HIGH		
RESISTANCE OF A PLANAR ARRAY OF		
YER RESIST PROCESS		
DIFFUSION IN SILICON FROM A		
THERMOCHEMICAL PROCESSES FOR HYDROGEN PRODUCTION BY WATER		
L CELLS		
PROBE-SPACING EXPERIMENT SIMULATION AND THE RELATION BETWEEN		
LATIONS: EFFECTS OF PROBE-CURRENT DENSITY AND LAYER THICKNES		
MICONDUCTO		
AN INVESTIGATION OF THE THICKNESS VARIATION OF		
ALUMINUM		
CAL BEHAVIOR OF CDS ELECTRODES		
THE EFFECT OF		
GEN ON THE DIELECTRIC AND PHOTOELECTROCHEMICAL PROPERTIES OF		
STRUCTURE CHANGES OF MOLYBDENUM SILICIDE FILMS DEPOSITED BY		
WHITLOCKITE PHASE IN THE LUMINESCENT SYSTEM		
TROCHEMICAL CELLS		
THE EFFECT OF ADDED SALTS ON THE		
EUTECTIC MELT AT 470DEGREE C		
REACTIONS OF FORMATION AND		
POLYANILINE FILMS		
ENHANCED		
OUS SOLUTION		
THE		
HOTOELECTRODES: MECHANISMS AND INTERRELATION		
STUDY OF		
OLUTION PHOTOELECTROCHEMIC		
SEMICONDUCTOR ELECTRODES XLVI.		
SUREMENT OF PH AT ELEVATED TEMPERATURES		
ON THE DOPING DEPENDENCE OF OXIDATION-INDUCED		
VISUAL DETECTION OF HYDRATED ALUMINUM OXIDE BY		
CORROSION RESISTANCE OF MICROCRYSTALLINE		
A MODEL OF CRACK ELECTROCHEMISTRY FOR STEELS IN THE ACTIVE		
N IN POLYCRYSTALLINE FILMS AS A FUNCTION OF SURFACE ACCEPTOR		
RFACE BY LAPLACE DOMAIN IMPE		
THE DETERMINATION OF SURFACE		
EMS		
BATTERY		
PHOTOELECTRON-TRAPPING		
GOLD-CONTAINING SURFACE		
ECTROLYTE INTERFACE		
ELECTROCHEMICAL TRANSFER VIA SURFACE		
HARGE TRANSFER IN PHOTOELECTROCHEMICAL DEVICES VIA INTERFACE		
OPERATING PERFORMANCE OF AN FE-TI		
DUCIBILITY, CAPACITY RETENTION, AND CYCLE LIFE FOR LIAL/FES		
THE CONSTANT HELPER:		
ENERGY ANALYSIS OF A		
CHELATING-POLYMER ADSORPTION EFFECTS ON CORROSION OF		
E ROLE OF H2S IN THE CORROSION AND HYDROGEN EMBRITTLEMENT OF		
YDROX		
KINETICS OF THE HYDROGEN EVOLUTION REACTION ON MILD		
OSION RESISTANCE		
POROUS NICKEL-COATED		
A FRACTURE MECHANICS STUDY OF CAUSTIC CRACKING OF MILD		
THE ELECTROCHEMICAL REDUCTION OF RUST FILMS ON WEATHERING		
CORROSION RESISTANCE OF MICROCRYSTALLINE STAINLESS		
BY DIFFUSION AND I		
A MODEL OF CRACK ELECTROCHEMISTRY FOR		
CAL NATURE OF ALUMINUM CORROSION II. THE INITIAL DISSOLUTION		
ILMS		
CONFORMAL		
KINETICS OF E		
ERROR ANALYSIS OF THE POTENTIAL AND VOLTAGE		
ONIC CONDUCTION IN ANODIC TANTALUM PENTOXIDE FILMS USING THE		
EFFECT OF MELT		
ARGE AND PASSIVATION PHENOMENA IN LEAD-ACID BATTERIES DURING		
N-MOSE2 PHOTOELECTROCHEMICAL HALOGEN		
ON MEMBRANES FOR USE IN THREE-ELECTRODE PHOTOELECTROCHEMICAL		
O-PHE		
SOLUTION REDOOX COUPLES FOR EELECTROCHEMICAL ENERGY		
ICKEL		
PIT AND FLOW		
ANALYSIS OF THE COMPRESSIVE		
OXIDE FILM RUPTURE, REANODIZATION, AND		
ALTERATION OF CORRODENT ION SPECIES WITHIN		
THE FEATHERING OF DOPING		
EADY-STATE SOLIDIFICATION		
DECAPSULATION AND PHOTORESIST		
F LEAD DIOXIDE ANODES UNDER CONDITIONS OF OZONE EVOLUTION IN		
ELECTRICAL CONDUCTIVITY IN LANTHANUM-DOPED		
N CDSE(1-X)S(X) FILMS		
IR PLASMA ETCH CHARACTERISTICS		
SPATIALLY RESOLVED CATHODOLUMINESCENCE STUDY OF SE	129	2386
SPECIES WITHIN STRESS CORROSION CRACKS	129	780
SPECIFIC CONDUCTANCE OF MOLTEN CARBONATE FUEL CELL	129	1745
SPECTRA FROM FLUOROCARBON PLASMAS AND ITS RELATION	129	160
SPECTRA OF FERROUS AND FERRIC OXIDES AND THE PASSI	129	2169
SPECTRAL RESPONSES OF TRANSITION METAL DICHALCOGEN	129	1237
SPECTROELECTROCHEMICAL PROPERTIES OF A LIGAND (BAT	129	762
SPECTROMETRY (SIMS) CHARACTERIZATION OF NEAR SURFA	129	1819
SPECTROSCOPIC DETERMINATION OF STRUCTURE AND ION P	129	1434
SPECTROSCOPIC STUDIES OF THE HAZARDS OF LI/SOCL2 B	129	2496
SPECTROSCOPIC STUDIES OF THE PASSIVE FILM ON IRON-	129	1662
SPECTROSCOPIC STUDIES OF 9,10-ANTHRAQUINONE IN A R	129	2488
SPECTROSCOPIC STUDY OF THE CORROSION INHIBITION OF	129	1658
SPECTROSCOPY STUDIES OF PHOTOCORROSION	129	2393
SPECTROSCOPY THE EDWARD WESTON SUMMER FELLOWSHIP R	129	295C
SPECTROSCOPY CHARACTERIZATION OF	129	2823
SPECTROSCOPY AND IMPEDANCE TECHNIQUE	129	660
SPECTROSCOPY OF SILVER AND GOLD LEVELS IN LEC GROW	129	1353
SPECTROSCOPY OF TRACE CONTAMINATION IN SILICON	129	2098
SPECTROSCOPY STUDIES THE N	129	17
SPECTROSCOPY STUDY OF GAAS SUBSTRATE CLEANING PROC	129	406
SPECTROSCOPY: A NEW METHOD FOR CHARACTERIZATION OF	129	891
SPECULAR LITHIUM DEPOSITS FROM LITHIUM HEXAFLUOROA	129	1
SPEED ELECTRODEPOSITION OF SN/PB ALLOYS	129	1196
SPHERES: GAS BUBBLES ON AN ELECTRODE	129	2715
SPIN-ON GLASS AS AN INTERMEDIATE LAYER IN A TRI-LA	129	2152
SPIN-ON HEAVILY PHOSPHORUS-DOPED OXIDE SOURCE	129	2299
SPLITTING: FROM THEORY TO PRACTICE	129	67
SPONTANEOUS PHOTOELECTROLYSIS OF HBR AND HL	129	1701
SPRAY-PYROLYZED THIN FILM CDSE PHOTOELECTROCHEMICA	129	719
SPREADING RESISTANCE AND SHEET RESISTANCE	129	599
SPREADING RESISTANCE PROBE-SPACING EXPERIMENT SIMU	129	2788
SPUN-ON THIN FILMS COMMONLY ASSOCIATED WITH THE SE	129	173
SPUTTER ETCHING EFFECTS ON GAAS SCHOTTKY JUNCTIONS	129	2760
SPUTTER ETCHING USING SICL4	129	1150
SPUTTERED RUO2 OVERLAYERS ON THE PHOTOELECTROCHEMI	129	1733
SPUTTERED TIO2 FILMS EFFECT OF HYDRO	129	2022
SPUTTERING AND BY COEVAPORATION AFTER ISOCHRONAL A	129	1527
SRO-LI2O5-P2O5:MN, CE	129	1373
STABILITY OF CD-CHALCOGENIDE/POLYSULFIDE PHOTOELEC	129	143
STABILITY OF IRON(II) AND (III) OXIDES IN LICL-KCL	129	1450
STABILITY OF PHOTOELECTRODES WITH ELECTROGENERATED	129	2261
STABILITY OF PITTING DISSOLUTION OF METALS IN AQUE	129	260
STABILIZATION AND SURFACE RECOMBINATION ON N-GAP P	129	546
STABILIZATION OF N-SILICON ELECTRODES IN AQUEOUS S	129	1647
STABILIZED CERAMIC MEMBRANE ELECTRODES FOR THE MEA	129	1221
STACKING FAULT SHRINKAGE IN SILICON	129	2319
STAINING WITH FLUORESCING AND NONFLUORESCING DYES	129	1517
STAINLESS STEELS	129	1402
STATE BASED ON MASS TRANSPORT BY DIFFUSION AND ION	129	1412
STATE DENSITY: APPLICATION FOR ZNO GAS SENSORS CAL	129	1382
STATE ENERGIES AT A SEMICONDUCTOR/ELECTROLYTE INTE	129	2147
STATE OF CHARGE DETERMINATION IN PHOTOVOLTAIC SYST	129	1928
STATE-OF-CHARGE INDICATOR FOR LEAD-ACID BATTERIES	129	2409
STATES ON PHOTOGRAPHIC AGBR GRAINS: ROLES BESIDES	129	591
STATES: A NEW FORMULATION FOR THE SEMICONDUCTOR/EL	129	963
STATES: UNIFIED MODEL AND COMPARISON WITH EXPERIME	129	1003
STATIONARY REDOX BATTERY IN THE PRESENCE OF LEAD	129	2502
STATUS CELLS: A DEMONSTRATION OF PERFORMANCE REPRO	129	2701
STEADFASTNESS AS A KEY INGREDIENT OF R&D	129	393C
STEADY-STATE ELECTROCHEMICAL REACTOR	129	1936
STEEL	129	2673
STEEL TH	129	468
STEEL AND NICKEL CATHODES IN CONCENTRATED SODIUM H	129	2481
STEEL ANODES FOR ALKALINE WATER ELECTROLYSIS: CORR	129	310
STEEL IN HOT NAOH/NA2S SOLUTIONS	129	2669
STEEL SURFACES	129	2686
STEELS	129	1402
STEELS IN THE ACTIVE STATE BASED ON MASS TRANSPORT	129	1412
STEP THE CHEMI	129	27
STEP COVERAGE OF LASER DEPOSITED SILICON DIOXIDE F	129	2155
STEP RELAXATION TECHNIQUES FOR THE MEASUREMENT OF	129	1943
STEPPED CURRENT METHOD AN INVESTIGATION OF HIGH FI	129	2518
STOICHIOMETRY ON TWIN FORMATION IN LEC GAAS	129	2382
STORAGE SELF-DISCH	129	458
STORAGE CELL	129	233
STORAGE CELLS TRANSPORT PROPERTIES OF NAFI-	129	2469
STORAGE II. COBALT(III)-COBALT(II) COMPLEXES WITH	129	61
STREAK FORMATION DURING HIGH RATE DISSOLUTION OF N	129	1889
STRENGTH OF LIALO2/MOLTEN CARBONATE STRUCTURES	129	216
STRESS CORROSION CRACKING IN ALUMINUM	129	2660
STRESS CORROSION CRACKS	129	780
STRIATIONS IN SEMICONDUCTOR CRYSTALS	129	1782
STRIATIONS OF KINETIC ORIGIN INDUCED DURING NON-ST	129	2355
STRIPPING IN OXYGEN MICROWAVE PLASMAS	129	2537
STRONG ACID ELECTROLYTES THE MECHANISM OF THE DISI	129	567
STRONTIUM TITANATE	129	1021
STRUCTURAL AND OPTICAL PROPERTIES OF SOLUTION GROW	129	99
STRUCTURAL COMPOSITION OF POLYMERS RELATIVE TO THE	129	205

		Vol	Page
OF CHROMIUM--COBALT ALLOYS CONTAINING A PHASE WITH THE A--15	**STRUCTURE** PULSE PLATING	129	2433
G METHOD FOR REVEALING THE QUALITY OF INP/INGAASP MULTILAYER	**STRUCTURE** A SIMPLE DAMAGE-FREE GROOVIN	129	2082
YLENE OXIDE) W VIBRATIONAL SPECTROSCOPIC DETERMINATION OF	**STRUCTURE** AND ION PAIRING IN COMPLEXES OF POLY(ETH	129	1434
OLYETHERS W CONFORMATION AND ION-TRANSPORT MODELS FOR THE	**STRUCTURE** AND IONIC CONDUCTIVITY IN COMPLEXES OF P	129	1694
OSITED BY SPUTTERING AND BY COEVAPORATION AFT CRYSTALLINE	**STRUCTURE** CHANGES OF MOLYBDENUM SILICIDE FILMS DEP	129	1527
OF AN INTEGRATED CIRCUIT LITHOGRAPHY A CROSS-BRIDGE TEST	**STRUCTURE** FOR EVALUATING THE LINEWIDTH UNIFORMITY	129	2313
DEFECT	**STRUCTURE** IN NICKEL ELECTRODEPOSITS	129	45
THE DEFECT	**STRUCTURE** OF LEAD DIOXIDE	129	876
A STUDY OF THE IRON ELECTRODE	**STRUCTURE** OF NI-FE CELL	129	1173
TICS OF CHLORINE EVOLUTION SURFACE	**STRUCTURE** OF RUTHENIUM DIOXIDE ELECTRODES AND KINE	129	1689
OF THE LOW FREQUENCY CAPACITANCE CHARACTERISTICS OF THE MOS	**STRUCTURE** WITH VERY THIN SUBSTRATE MATHEMATICAL MO	129	2547
E MATRIX MATERIAL FOR MOLTEN CARBONATE FUEL CELL ELECTROLYTE	**STRUCTURES** ALTERNAT	129	979
RACTERIZATION OF FUSED GLASS PASSIVATION WITH SELECTED DIODE	**STRUCTURES** CHA	129	154
LYSIS OF THE COMPRESSIVE STRENGTH OF LIALO2/MOLTEN CARBONATE	**STRUCTURES** ANA	129	216
PHOTOANODIC DISSOLUTION OF N-CDS	**STUDIED** BY ROTATING RING-DISK ELECTRODES	129	149
N SIO2 FILMS SILICON OXIDATION	**STUDIES**: MEASUREMENT OF THE DIFFUSION OF OXIDANT I	129	413
ACITANCE CHARACTERISTICS OF THE MOS STRUCTURE WITH VERY THIN	**SUBSTRATE** MATHEMATICAL MODELING OF THE LOW FREQUEN	129	2547
ION LIMIT OF NEGATIVE ELECTRON RESIST EXPOSED ON A THIN FILM	**SUBSTRATE** RESOLUT	129	1831
AUGER ELECTRON SPECTROSCOPY STUDY OF GAAS	**SUBSTRATE** CLEANING PROCEDURES	129	406
GENERATION AND ELECTRON TRAPPING KINETICS IN MOSFET'S DUE TO	**SUBSTRATE** HOT-ELECTRON INJECTION INTO GATE SIO2 IN	129	1760
INGAAS/INP GROWN BY LIQUID PHASE EPITAXY	**SUBSTRATE** ORIENTATION DEPENDENCE OF GROWTH RATE OF	129	2603
(1-X)AS GROWN BY MOLECULAR BEAM EPITAXY INFLUENCE OF	**SUBSTRATE** TEMPERATURE ON THE MORPHOLOGY OF AL(X)GA	129	824
DE FORMED BY COLLOIDAL PRECIPITATION ON DIFFERENT CONDUCTING	**SUBSTRATES** THE ELECTROCHEMICAL RESPONSE OF NICKEL	129	301
Y RESOLVED CATHODOLUMINESCENCE STUDY OF SEMI-INSULATING GAAS	**SUBSTRATES** SPATIALL	129	2386
A SURVEY OF IRON CONTAMINATION IN SILICON	**SUBSTRATES** AND ITS IMPACT ON CIRCUIT YIELD	129	2573
FACTORS INFLUENCING THE GROWTH OF GA0.47IN0.53AS ON INP	**SUBSTRATES** USING THE METALORGANIC PROCESS	129	383
ZINC ELECTROCRYSTALLIZATION FROM IMPURITY-CONTAINING	**SULFATE** BATHS	129	2695
REACTIONS OF SO2(SO3) WITH NIO-NA2SO4 IN NICKEL-SODIUM MIXED	**SULFATE** FORMATION AND LOW TEMPERATURE HOT CORROSIO	129	1613
ELECTROCHEMICAL PRODUCTION OF MANGANIC	**SULFATE** IN CONCENTRATED H2SO4	129	749
THERMODYNAMICS OF MOLTEN	**SULFATE** MIXTURES	129	1840
CERAMIC SEPARATORS FOR LI-AL/IRON	**SULFIDE** BATTERIES	129	2187
ACID THE NATURE OF PASSIVATION OF LEAD	**SULFIDE** DURING ANODIC DISSOLUTION IN HYDROCHLORIC	129	271
SURFACE-MODIFIED P-INP PHOTOCATHODES IN	**SULFIDE/POLYSULFIDE** ELECTROLYTE	129	1387
HOTOLUMINESCENT AND ELECTROLUMINESCENT PROPERTIES OF CADMIUM	**SULFO-SELENIDE** ELECTRODES LUMINESCENT PHOTOELECTRO	129	772
ATER SORPT A COMPARISON OF PERFLUORINATED CARBOXYLATE AND	**SULFONATE** ION EXCHANGE POLYMERS I. DIFFUSION AND W	129	324
RANSPORT P A COMPARISON OF PERFLUORINATED CARBOXYLATE AND	**SULFONATE** ION EXCHANGE POLYMERS II. SORPTION AND T	129	328
ELECTRODE ELECTRO-OXIDATION OF HYDRAZINE CATALYZED BY	**SULFONATED** PHTHALOCYANINES ADSORBED ON A GRAPHITE	129	2242
L OXIDATION OF	**SULFUR** IN CHLOROALUMINATE MELTS OF INTERMEDIATE PC	129	2237
CO3-K2CO3 AT 650DEGREE C THE EFFECT OF	**SULFUR** ON THE ANODIC H2(NI) ELECTRODE IN FUSED LI2	129	1441
TARNISHING OF SILVER BY ORGANIC	**SULFUR** VAPORS: RATES AND FILM CHARACTERISTICS	129	33
ENEOUS ELECTRON TRANSFER KINETIC THE COLIN GARFIELD FINK	**SUMMER** FELLOWSHIP REPORT--DETERMINATION OF HETEROG	129	298C
ED STUDIES OF CHEMICALLY MODIFIED THE JOSEPH W. RICHARDS	**SUMMER** FELLOWSHIP REPORT--FOURIER TRANSFORM INFRAR	129	300C
ON PARAMETERS AND ADSORPTION RATES FOR THE EDWARD WESTON	**SUMMER** FELLOWSHIP REPORT--QUANTITATION OF ADSORPTI	129	295C
BONS IN HF/SBF5: SOME MECHANISTIC CONCLUSIONS CONCERNING THE	**SUPER** ACID "CATALYZED" CONDENSATION OF HYDROCARBON	129	1950
SIVE FILM ON IRON III. THE CHEMI-CONDUCTOR MODEL AND FURTHER	**SUPPORTING** EVIDENCE THE NATURE OF THE PAS	129	921
GNETIC FIELD	**SUPPRESSION** OF THERMAL CONVECTION BY TRANSVERSE MA	129	427
NEW COUPLING METHOD FOR POLYIMIDE ADHESION TO LSI	**SURFACE**	129	2278
RIER CONCENTRATION IN POLYCRYSTALLINE FILMS AS A FUNCTION OF	**SURFACE** ACCEPTOR STATE DENSITY: APPLICATION FOR ZN	129	1382
C AND ELECTROLYTIC DISPLAYS EFFECT OF ACTIVE	**SURFACE** AREA ON THE RESPONSE TIME OF ELECTROCHROMI	129	2451
ON EFFECTS ON CURRENT-VOLTAGE CHARACTERISTICS OF ILLUMINATED	**SURFACE** BARRIER CELLS RECOMBINATI	129	1134
CHARACTERIZATION OF REACTIVE ION ETCHED SILICON	**SURFACE** BY DEEP LEVEL TRANSIENT SPECTROSCOPY	129	2823
IMPACT OF DEIONIZED WATER RINSES ON SILICON	**SURFACE** CLEANING	129	1027
BY SECONDARY ION MASS SPECTROMET CHARACTERIZATION OF NEAR	**SURFACE** COMPOSITION OF BOROSILICATE GLASSES (BSG)	129	1819
ADSORPTION RATES FOR DITHIOZONE ANION ADSORPTION AT AG USING	**SURFACE** ENHANCED AND RESONANCE ENHANCED RAMAN SPEC	129	295C
ENCE: BENZOTRIAZOLE ON COPPER	**SURFACE** ENHANCED RAMAN SCATTERING IN CORROSION SCI	129	1716
IBITING POLYPHOSPHATE SOLUTIONS ON THE NATURE OF	**SURFACE** FILMS FORMED ON IRON IN AGGRESSIVE AND INH	129	1186
S BY ELECTROCHEMICAL POLYMERIZATION OF O-PHENYLENEDIAMINE AT	**SURFACE** IMPERFECTIONS SEMICONDUCTOR ELECTRODES XLI	129	265
N AT ZIRCONIA ELECTROLYTES THE EFFECT OF ELECTRODE	**SURFACE** IMPURITIES ON THE OXYGEN ELECTRODE REACTIO	129	345
CRYSTALLIZATION I. GENERAL EXPRESSION FOR THE GROWTH MODE OF	**SURFACE** IRREGULARITIES IMAGE ANALYSIS OF MORPHOLOG	129	2442
ANALYSIS OF INP	**SURFACE** PREPARED BY VARIOUS CLEANING METHODS	129	447
PHOTOCURRENT AT P-TYPE III-V ELECTRODES THE INFLUENCE OF	**SURFACE** RECOMBINATION AND TRAPPING ON THE CATHODIC	129	730
CHANISMS AND INTERRELATION STUDY OF STABILIZATION AND	**SURFACE** RECOMBINATION ON N-GAP PHOTOELECTRODES: ME	129	546
YTE INTERFACE BY LAPLACE DOMAIN IMPE THE DETERMINATION OF	**SURFACE** STATE ENERGIES AT A SEMICONDUCTOR/ELECTROL	129	2147
BESIDES PHOTOELECTRON-TRAPPING GOLD-CONTAINING	**SURFACE** STATES ON PHOTOGRAPHIC AGBR GRAINS: ROLES	129	591
UCTOR/ELECTROLYTE INTERFACE ELECTROCHEMICAL TRANSFER VIA	**SURFACE** STATES: A NEW FORMULATION FOR THE SEMICOND	129	953
AND KINETICS OF CHLORINE EVOLUTION	**SURFACE** STRUCTURE OF RUTHENIUM DIOXIDE ELECTRODES	129	1689
ACTIVITIES AND	**SURFACE** TENSION OF LIQUID AGCL-LICL SOLUTIONS	129	502
LYSULFIDE ELECTROLYTE	**SURFACE-MODIFIED** P-INP PHOTOCATHODES IN SULFIDE/PO	129	1387
OBSERVATIONS OF FLAWS ON PRECONDITIONED ALUMINUM	**SURFACES**	129	1515
THE OXIDATION OF SHAPED SILICON	**SURFACES**	129	1278
REMENT OF POTENTIALS INSIDE ARTIFICIAL PITS AND ON POLARIZED	**SURFACES** AN ELECTRODE DESIGN FOR DUAL MEASU	129	669
RIE CONTAMINATION OF ETCHED SILICON	**SURFACES**	129	1822
OPHENOL WITH ALPHA-CYCLODEXTRIN IN SOLUTION AND ON ELECTRODE	**SURFACES** SELECTIVE ELECTROSYNTHESES ON CHEMICALLY	129	1681
TRANSFORM INFRARED STUDIES OF CHEMICALLY MODIFIED ELECTRODE	**SURFACES** THE JOSEPH W. RICHARDS SUMMER FELLOWSHIP	129	300C
INITIAL OXIDE GROWTH RATE ON NEWLY GENERATED	**SURFACES**	129	2500
ELECTROCHEMICAL REDUCTION OF RUST FILMS ON WEATHERING STEEL	**SURFACES** THE	129	2686
HERE THE OXIDATION OF GERMANIUM	**SURFACES** AT PRESSURES MUCH GREATER THAN ONE ATMOSP	129	1845
L CHLORIDE ACTIVATION OF RUO2 AND PTO ELECTRODE	**SURFACES** FOR IMMOBILIZATION REACTIONS USING THIONY	129	756
AND ITS IMPACT ON CIRCUIT YIELD A	**SURVEY** OF IRON CONTAMINATION IN SILICON SUBSTRATES	129	2573
ENT DISTRIBUTION PROBLEMS A	**SURVEY** OF NUMERICAL METHODS AND SOLUTIONS FOR CURR	129	72
OR THE	**SUSPENDED** MESH ION SELECTIVE FIELD EFFECT TRANSIST	129	2580
IMINE DERIVATIVES, REDUCTIVE CARBOXYLATION, ALPHA-AMINO ACID	**SYNTHESIS** ELECTROCHEMICAL BEHAVIOR OF SELECTED	129	1231
ND ITS DISCHARGE PROPERTIES IN ZNCL2 BATTERIES THE	**SYNTHESIS** OF DENSIFIED CMD FROM MN-NH4-CARBAMATE A	129	2372
ULAR ASSOCIATED SOLUTION MODEL TO THE CD-TE AND HG-TE BINARY	**SYSTEMS** APPLICATION OF THE REG	129	2360
BATTERY STATE OF CHARGE DETERMINATION IN PHOTOVOLTAIC	**SYSTEMS**	129	1928
W) FROM WC-CO CEMENTED CARBIDES IN PARTICULATE BED ELECTRODE	**SYSTEMS** SELECTIVE DISSOLUTION OF THE BINDER PHASE	129	2666
YCLIC VOLTAMMETRY AND CHRONOCOULOMETRY OF LIQUID ELECTROLYTE	**SYSTEMS** ELECTROCHEMICAL INVESTIGATIONS OF ALKALI-M	129	677
F MASS AND CHARGE TRANSPORT PROPERTIES OF LIQUID ELECTROLYTE	**SYSTEMS** ELECTROCHEMICAL INVESTIGATIONS OF ALKALI-M	129	682
VICES AT 28 CREVICE CORROSION IN HIGH-TEMPERATURE AQUEOUS	**SYSTEMS** POTENTIAL/PH MEASUREMENTS IN ALLOY 600 CRE	129	2458

		Vol	Page
NOMETALLIC PROCESS	THE USE OF S2CL2 FOR DOPING POLY-GAAS FILMS GROWN BY THE ORGA	129	2778

— T —

ELECTROCHEMICAL BEHAVIOR AT POLYPYRROLE-COATED PLATINUM AND	TANTALUM ELECTRODES POLYMER FILMS ON ELECTRODES VI	129	1009
ENTAL INVESTIGATION OF HIGH FIELD IONIC CONDUCTION IN ANODIC	TANTALUM PENTOXIDE FILMS USING THE OPEN-CIRCUIT TR	129	2513
AN INVESTIGATION OF HIGH FIELD IONIC CONDUCTION IN ANODIC	TANTALUM PENTOXIDE FILMS USING THE STEPPED CURRENT	129	2518
ES AND FILM CHARACTERISTICS	TARNISHING OF SILVER BY ORGANIC SULFUR VAPORS: RAT	129	33
O3 ADDITION ON THE THERMOLUMINESCENCE AND PHOSPHORESCENCE OF	TB-ACTIVATED GARNET PHOSPHORS EFFECT OF V2	129	2638
ALUMINUM DEPOSITION	TECHNIQUES AND HEAT TRANSFER PROPERTIES OF POROUS	129	1029
IUM-DOPED P(+)-N INGAASP/INP HETEROJUNCTIONS LPE GROWTH	TECHNIQUES FOR FABRICATING ABRUPT ZINC- AND MAGNES	129	2085
ERROR ANALYSIS OF THE POTENTIAL AND VOLTAGE STEP RELAXATION	TECHNIQUES FOR THE MEASUREMENT OF KINETICS OF ELEC	129	1943
P-DOPED POLYSILICON FILM GROWTH	TECHNOLOGY	129	2620
RIO DE NORA-DIAMOND SHAMROCK ELECTROCHEMICAL ENGINEERING AND	TECHNOLOGY MEDALIST JOSEPH C. SCHUMACHER--VITTO	129	395C
NG INSIDE A CVD REACTOR DETERMINATION OF	TEMPERATURE AND PARTIAL PRESSURE BY RAMAN SCATTERI	129	2338
A CHLORINE PLASMA	TEMPERATURE DEPENDENCE OF INP AND GAAS ETCHING IN	129	2533
AL-TIO2 JUNCTIONS TO VARIOUS REDUCING GASES	TEMPERATURE DEPENDENCE OF THE SENSITIVITIES OF MET	129	444
SEMICONDUCTORS LOW	TEMPERATURE DOUBLE-PLASMA PROCESS FOR BN FILMS ON	129	2636
NERGY NITROGEN ION IMPLANTATION INTO SILICON ROOM	TEMPERATURE FORMATION OF SI-NITRIDE FILMS BY LOW E	129	379
UM-RICH DEPOSIT PREPARED BY CHEMICAL VAPOR DEPOSITION AT LOW	TEMPERATURE FROM TRIS-(2,2'BIPYRIDINE) TITANIUM A	129	854
NIO-NA2SO4 IN NICKEL-SODIUM MIXED SULFATE FORMATION AND LOW	TEMPERATURE HOT CORROSION REACTIONS OF SO2(SO3) WI	129	1613
AMBIENT	TEMPERATURE K-TIS2 CELL	129	230
PHASE RELATIONSHIPS IN POSITIVE ELECTRODES OF HIGH	TEMPERATURE LI-AL/LICL-KCL/FES2 CELLS	129	925
TIC HYDROCARBONS AND DECAMETHYL FERROCENE AT THE N-GAAS/ROOM	TEMPERATURE MOLTEN SALT ELECTROLYTE INTERFACE PHOT	129	560
PHOTOELECTROCHEMICAL CHARACTERIZATION OF THE N-INP/ROOM	TEMPERATURE MOLTEN SALT ELECTROLYTE INTERFACE	129	2009
OWN BY MOLECULAR BEAM EPITAXY INFLUENCE OF SUBSTRATE	TEMPERATURE ON THE MORPHOLOGY OF AL(X)GA(1-X)AS GR	129	824
RODE" IN THE MONITORING OF CORROSION AND RE USE OF A HIGH	TEMPERATURE PH SENSOR AS A "PSEUDO-REFERENCE ELECT	129	1445
RICH REGIONS OF THE MO-AL SYSTEM HIGH	TEMPERATURE THERMODYNAMIC STUDY OF THE MOLYBDENUM-	129	2613
THE APPEARANCE OF HIGH DENSITY THERMAL SIO2 AT LOW OXIDATION	TEMPERATURES A VISCOUS FLOW MODEL TO EXPLAIN	129	2594
LITHIUM-ALUMINUM ELECTRODES AT AMBIENT	TEMPERATURES	129	1429
IC MEMBRANE ELECTRODES FOR THE MEASUREMENT OF PH AT ELEVATED	TEMPERATURES STABILIZED CERAM	129	1221
ACTIVITIES AND SURFACE	TENSION OF LIQUID AGCL-LICL SOLUTIONS	129	502
LATE ELECTROCHEMICAL FLOW REACTO EFFECTS OF SEPARATOR AND	TERMINAL ON THE CURRENT DISTRIBUTION IN PARALLEL-P	129	1670
LLS II. THE N-CDIN2SE4/AQUEOUS POLYSULFIDE SYSTEM	TERNARY CHALCOGENIDE-BASED PHOTOELECTROCHEMICAL CE	129	1506
COMPUTER SIMULATION OF THE DIFFUSIONAL GROWTH OF	TERNARY OXIDE SCALES ON BINARY ALLOYS	129	209
ANODIC LEVELING UNDER SECONDARY AND	TERTIARY CURRENT DISTRIBUTION CONDITIONS	129	946
CALIBRATION	TESTS OF AN ELECTROCHEMICAL CARBON METER	129	2746
IVITY, AND CHEMICAL REACTIONS OF TRICHLOROSILANOL IN SILICON	TETRACHLORIDE PHOTOCHEMICAL PRODUCTION, INFRARED A	129	1619
ANTIMONY-DOPED TIN OXIDE FILMS DEPOSITED BY THE OXIDATION OF	TETRAMETHYLTIN AND TRIMETHYLANTIMONY	129	1040
PHOTOELECTROCHEMISTRY OF THE THALLIC/THALLOUS COUPLE. THE	THALLIC ION CATALYZED PHOTO-OXIDATION OF PROPYLENE	129	2232
PHOTO-OXIDATION OF PROPYLEN PHOTOELECTROCHEMISTRY OF THE	THALLIC/THALLOUS COUPLE. THE THALLIC ION CATALYZED	129	2232
HE OXIDATION OF GERMANIUM SURFACES AT PRESSURES MUCH GREATER	THAN ONE ATMOSPHERE T	129	1845
BETWEEN PHYSICAL AND ELECTRICAL PROPERTIES OF PECVD SIN WITH	THEIR COMPOSITION RATIOS THE CORRELATIONS	129	1773
STRUCTURAL COMPOSITION OF POLYMERS RELATIVE TO	THEIR PLASMA ETCH CHARACTERISTICS	129	205
ON TRANSPORT IN ULTRATHIN MEMBRANES	THEORETICAL ANALYSIS OF ELECTROSTATIC EFFECTS ON I	129	958
SMALL-SIGNAL A-C RESPONSE	THEORY FOR ELECTROCHROMIC THIN FILMS	129	1754
L PROCESSES FOR HYDROGEN PRODUCTION BY WATER SPLITTING: FROM	THEORY TO PRACTICE THERMOCHEMICA	129	67
CHARACTERISTICS OF LITHIUM-BORON ALLOY ANODE IN MOLTEN SALT	THERMAL CELLS DISCHARGE	129	1168
DESIGN OF ELECTROLYSIS UNDER COST-OPTIMAL	THERMAL CONDITIONS	129	953
SUPPRESSION OF	THERMAL CONVECTION BY TRANSVERSE MAGNETIC FIELD	129	427
Y ON INTRINSIC GETTERING IN CZ SILICON CRYSTALS: EVALUATION,	THERMAL HISTORY DEPENDENCE, AND ENHANCEMENT A STUD	129	374
GROWTH KINETICS OF SILICON	THERMAL NITRIDATION	129	1559
E ENHANCED DIFFUSION OF ARSENIC AND PHOSPHORUS IN SILICON BY	THERMAL OXIDATION TH	129	644
DEFORMATION OF SILICON WAFERS BY	THERMAL OXIDATION	129	2076
FILMS OF POLYCRYSTALLINE SILICON	THERMAL OXIDATION OF HEAVILY PHOSPHORUS-DOPED THIN	129	2321
VISCOUS FLOW MODEL TO EXPLAIN THE APPEARANCE OF HIGH DENSITY	THERMAL SIO2 AT LOW OXIDATION TEMPERATURES A	129	2594
STUDY OF COOPERATIVE DIFFUSION AND CHEMICAL REACTION DURING	THERMAL TREATMENTS OF SILICA FILMS IN WATER VAPOR	129	867
	THERMALLY ACTIVATED OXYGEN DONORS IN SI	129	2844
ON FILMS HEAVILY DOPED WITH ARSE ELECTRICAL PROPERTIES OF	THERMALLY AND LASER ANNEALED POLYCRYSTALLINE SILIC	129	1811
ERISTICS EFFECT OF	THERMALLY NITRIDED SIO2 (NITROXIDE) ON MOS CHARACT	129	184
G INTERFACE COMPOSITION STUDIES OF	THERMALLY OXIDIZED GAAS USING AUGER DEPTH PROFILIN	129	851
Y WATER SPLITTING: FROM THEORY TO PRACTICE	THERMOCHEMICAL PROCESSES FOR HYDROGEN PRODUCTION B	129	67
L VAPOR DEPOSITION OF ALUMINA FROM ALCL3-H2-CO2 GAS PHASE MI	THERMODYNAMIC AND EXPERIMENTAL ANALYSIS OF CHEMICA	129	1367
THE N-TIO2 ELECTRODE IN FLUORIDE-CONTAINING SOLUTIONS	THERMODYNAMIC AND PHOTOELECTROCHEMICAL BEHAVIOR OF	129	2132
TASSIUM POLYSULFIDES FROM OPEN-CIRCUIT VOLTAGE MEASUREMENTS	THERMODYNAMIC AND PHYSICAL PROPERTIES OF MOLTEN PO	129	2707
SOLUTE ADDITIONS OF COPPER AND SILVER ON THE DIFFUSIVITY AND	THERMODYNAMIC PROPERTIES OF OXYGEN IN LIQUID INDIU	129	430
TO NEGATIVE ELECTRODES FOR MOLTEN SALT BATTERIES	THERMODYNAMIC STUDIES OF LI-GE ALLOYS: APPLICATION	129	246
GE INCORPORATION IN GAAS GROWN BY MOLECULAR BEAM EPITAXY: A	THERMODYNAMIC STUDY	129	2108
OF THE MO-AL SYSTEM HIGH TEMPERATURE	THERMODYNAMIC STUDY OF THE MOLYBDENUM-RICH REGIONS	129	2613
OR TRANSPORT OF GEAS	THERMODYNAMICS AND KINETICS OF IODINE CHEMICAL VAP	129	1343
EN CARBONATE FUEL CELLS THE	THERMODYNAMICS OF ELECTROLYTE DISTRIBUTION IN MOLT	129	942
	THERMODYNAMICS OF MOLTEN SULFATE MIXTURES	129	1840
NDIUM-SULFIDE, INDIUM-SULFIDE VAPORIZATION CHEMISTRY AND	THERMODYNAMICS OF SOLID SOLUTIONS IN THE CADMIUM-I	129	1835
ATED GARNET PHOSPHORS EFFECT OF V2O3 ADDITION ON THE	THERMOLUMINESCENCE AND PHOSPHORESCENCE OF TB-ACTIV	129	2638
ECTRODES FOR LI-AL/FES BATTERY CELLS	THERMOMECHANICAL BEHAVIOR OF SIMULATED NEGATIVE EL	129	2265
MENT SIMULATIONS: EFFECTS OF PROBE-CURRENT DENSITY AND LAYER	THICKNESS SPREADING RESISTANCE PROBE-SPACING EXPER	129	2788
MINIMUM SILICON WAFER	THICKNESS FOR ID WAFERING	129	2835
ELLIPSOMETRIC	THICKNESS MEASUREMENTS OF PMMA ON GAAS	129	2273
UEL CELL CATHODES THE EFFECT OF	THICKNESS ON THE PERFORMANCE OF MOLTEN CARBONATE F	129	2711
ASSOCIATED WITH THE SEMICONDUCTO AN INVESTIGATION OF THE	THICKNESS VARIATION OF SPUN-ON THIN FILMS COMMONLY	129	173
A WET CHEMICAL ETCH METHODS FOR DEFECT EVALUATION OF	THIN (100) ORIENTED SILICON EPITAXIAL LAYERS USING	129	2074
QUID JUNCTION SOLAR CELL BASED ON CHEMICALLY DEPOSITED BI2S3	THIN FILM AND SOME SEMICONDUCTING PROPERTIES OF BI	129	332
SPRAY-PYROLYZED	THIN FILM CDSE PHOTOELECTROCHEMICAL CELLS	129	719
OLYTE PHOTOELECTROCHEMICAL PERFORMANCE OF ZNSE/CDSE	THIN FILM ELECTRODES IN AQUEOUS POLYSULFIDE ELECTR	129	542
RESOLUTION LIMIT OF NEGATIVE ELECTRON RESIST EXPOSED ON A	THIN FILM SUBSTRATE	129	1831
RESISTIVITIES OF	THIN FILM TRANSITION METAL SILICIDES	129	293
PROTON DIFFUSION IN TUNGSTEN TRIOXIDE	THIN FILMS	129	2349
SMALL-SIGNAL A-C RESPONSE THEORY FOR ELECTROCHROMIC	THIN FILMS	129	1754
TO AN INVESTIGATION OF THE THICKNESS VARIATION OF SPUN-ON	THIN FILMS COMMONLY ASSOCIATED WITH THE SEMICONDUC	129	173
THERMAL OXIDATION OF HEAVILY PHOSPHORUS-DOPED	THIN FILMS OF POLYCRYSTALLINE SILICON	129	2321

		Vol	Page
CHEMICAL METHODS FOR THE DEPOSITION OF	THIN FILMS OF SB2SE3 AND SB203	129	1642
DUAL HCL	THIN GATE OXIDATION PROCESS	129	1778
LUTIONS III. PH DEPENDENCE FORMATION OF	THIN OXIDE FILMS AT PLATINUM ANODES IN ALKALINE SO	129	55
FIXED CHARGE DENSITY (QSS) AT THE SI-SIO2 INTERFACE FOR	THIN OXIDES	129	1757
	THIN PALLADIUM FILMS ON SILICON AND TITANIUM	129	2689
OPTICAL ABSORPTION OF	THIN SIPOS FILMS	129	197
Y CAPACITANCE CHARACTERISTICS OF THE MOS STRUCTURE WITH VERY	THIN SUBSTRATE MATHEMATICAL MODELING OF THE LOW FR	129	2547
NUMERICAL SIMULATION OF GATE OXIDE	THINNING IN MOS DEVICES	129	831
PHOTO- AND CATHODOLUMINESCENT PROPERTIES OF ERBIUM-DOPED	THIOGALLATES	129	2063
ND PTO ELECTRODE SURFACES FOR IMMOBILIZATION REACTIONS USING	THIONYL CHLORIDE ACTIVATION OF RUO2 A	129	756
SOURCES OF PRESSURE IN LITHIUM	THIONYL CHLORIDE BATTERIES	129	2453
ON THE MECHANISM OF	THIONYL CHLORIDE REDUCTION	129	1853
CONDUCTANCE STUDIES IN	THIONYL CHLORIDE: II	129	1165
ELECTROCHEMICAL REDUCTION OF	THIOPHOSGENE IN ACETONITRILE	129	529
PALLADIUM MEDAL ADDRESS--ELECTRO(ANALYTICAL) CHEMISTRY EARLY	THIS CENTURY OLIN	129	59C
TRANSPORT PROPERTIES OF NAFION MEMBRANES FOR USE IN	THREE-ELECTRODE PHOTOELECTROCHEMICAL STORAGE CELLS	129	2469
ANOLYTE DIFFUSION LAYER AND ITS EFFECT ON HYDROXYL TRANSPORT	THROUGH NAFION MEMBRANE IN CHLOR-ALKALI CELL THE	129	722
TY GETTERING OF SILICON DAMAGE GENERATED BY ION IMPLANTATION	THROUGH SIO2 LAYERS IMPURI	129	2527
THE SPECIFIC CONDUCTANCE OF MOLTEN CARBONATE FUEL CELL	TILES	129	1745
EFFECT OF ACTIVE SURFACE AREA ON THE RESPONSE	TIME OF ELECTROCHROMIC AND ELECTROLYTIC DISPLAYS	129	2451
OPTICAL STUDIES OF THE ANODIC PASSIVATION OF	TIN	129	1886
THE EFFECT OF ANTIMONY ON THE CORROSION OF	TIN IN DEAERATED CITRIC ACID	129	1651
ATION OF CHLORINE ON CATALYTICALLY MODIFIED N-SILICON/INDIUM	TIN OXIDE ANODES PHOTOELECTROCHEMICAL GENER	129	1934
AMETHYLTIN AND TRIMETHYLANTIMONY ANTIMONY-DOPED	TIN OXIDE FILMS DEPOSITED BY THE OXIDATION OF TETR	129	1040
CY DISPERSION THE PREPARATION OF	TIO2 ELECTRODES WITH MINIMUM MOTT-SCHOTTKY FREQUEN	129	2003
DIELECTRIC AND PHOTOELECTROCHEMICAL PROPERTIES OF SPUTTERED	TIO2 FILMS EFFECT OF HYDROGEN ON THE	129	2022
PHOTOPOTENTIAL BEHAVIOR OF PLATINIZED	TIO2 PARTICLES	129	1752
GEN CONCENTRATION GRADIENT AND ASSOCIATED ELECTRIC FIELDS IN	TIO2 PHOTOANODES HYDRO	129	1851
OTOELECTROLYSIS OF WATER	TIO2-VO2 ALLOYS--REDUCED BANDGAP EFFECTS IN THE PH	129	1210
AL INVESTIGATIONS OF ALKALI-METAL INTERCALATION REACTIONS IN	TIS2: CHRONOAMPEROMETRIC DETERMINATION OF MASS AND	129	682
AL INVESTIGATIONS OF ALKALI-METAL INTERCALATION REACTIONS IN	TIS2: CYCLIC VOLTAMMETRY AND CHRONOCOULOMETRY OF L	129	677
ELECTRICAL CONDUCTIVITY IN LANTHANUM-DOPED STRONTIUM	TITANATE	129	1021
INSTABILITY OF ANODIC OXIDE FILMS ON	TITANIUM	129	1252
POR DEPOSITION AT LOW TEMPERATURE FROM TRIS-(2,2'BIPYRIDINE)	TITANIUM A CORROSION-RESISTANT TITANIUM-RICH DEPOS	129	854
THIN PALLADIUM FILMS ON SILICON AND	TITANIUM	129	2689
SION	TITANIUM DIOXIDE FILMS TO IMPROVE PHOTORESIST ADHE	129	2389
EPOSITION AT LOW TEMPERATURE FROM T A CORROSION-RESISTANT	TITANIUM-RICH DEPOSIT PREPARED BY CHEMICAL VAPOR D	129	854
WIRE BONDING PROCESS CHARACTERIZATION BY X-RAY DIFFRACTION	TOPOGRAPHY	129	846
METHOD TO MEASURE THE PRECIPITATED AND	TOTAL OXYGEN CONCENTRATION IN SILICON	129	1638
CAPACITANCE TRANSIENT SPECTROSCOPY OF	TRACE CONTAMINATION IN SILICON	129	2098
CONIUM I. INFLUE A STUDY BY NUCLEAR MICROANALYSIS AND 180	TRACING OF THE GROWTH OF ANODIC OXIDE FILMS ON ZIR	129	1895
CONIUM II. OXIDE A STUDY BY NUCLEAR MICROANALYSIS AND 180	TRACING OF THE GROWTH OF ANODIC OXIDE FILMS ON ZIR	129	1905
CE INTERACTIONS BETWEEN PHOTOINDUCED AND DARK CHARGE	TRANSFER ACROSS N-TIO2-AQUEOUS ELECTROLYTE INTERFA	129	1240
RELATION BETWEEN MASS	TRANSFER AND CORROSION IN A TURBULENT PIPE FLOW	129	276
TRODES MASS	TRANSFER AT LONGITUDINALLY VIBRATING VERTICAL ELEC	129	1955
THE CHEMICAL NATURE OF ALUMINUM CORROSION V. ENERGY	TRANSFER IN ALUMINUM DISSOLUTION	129	464
MASS	TRANSFER IN LAMINAR FLOW CHANNEL WITH POROUS WALL	129	1727
FACE STATES: UNIFIED MODEL AND COMPARISON WITH EXP CHARGE	TRANSFER IN PHOTOELECTROCHEMICAL DEVICES VIA INTER	129	1003
R FELLOWSHIP REPORT--DETERMINATION OF HETEROGENEOUS ELECTRON	TRANSFER KINETIC PARAMETERS BY DERIVATIVE CYCLIC V	129	298C
DEPOSITION TECHNIQUES AND HEAT	TRANSFER PROPERTIES OF POROUS ALUMINUM	129	1029
THE SEMICONDUCTOR/ELECTROLYTE INTERFACE ELECTROCHEMICAL	TRANSFER VIA SURFACE STATES: A NEW FORMULATION FOR	129	963
ERY ELECTROLYTES	TRANSFERENCE NUMBERS OF ZINC IN ZINC-CHLORIDE BATT	129	907
THE JOSEPH W. RICHARDS SUMMER FELLOWSHIP REPORT--FOURIER	TRANSFORM INFRARED STUDIES OF CHEMICALLY MODIFIED	129	300C
MARTENSITIC	TRANSFORMATION OF GD	129	1145
ITION OF SILVER ON GOLD INTERPRETATION OF POTENTIOSTATIC	TRANSIENT BEHAVIOR DURING THE UNDERPOTENTIAL DEPOS	129	1202
CTRODES IN KOH ELECTROLYTE	TRANSIENT CURRENT DISTRIBUTIONS IN POROUS ZINC ELE	129	239
OCHEMICAL KINETICS AT LIVING CELL MEMBRANES A	TRANSIENT IMPEDANCE APPROACH TO NONFARADAIC ELECTR	129	526
ON IN ANODIC TANTALUM PENTOXIDE FILMS USING THE OPEN-CIRCUIT	TRANSIENT METHOD AN EXPERIMENTAL INVESTIGATION OF	129	2513
IZATION OF REACTIVE ION ETCHED SILICON SURFACE BY DEEP LEVEL	TRANSIENT SPECTROSCOPY CHARACTER	129	2823
N LEC GROWN GALLIUM ARSENIDE DEEP LEVEL	TRANSIENT SPECTROSCOPY OF SILVER AND GOLD LEVELS I	129	1353
ILICON CAPACITANCE	TRANSIENT SPECTROSCOPY OF TRACE CONTAMINATION IN S	129	2098
THE SUSPENDED MESH ION SELECTIVE FIELD EFFECT	TRANSISTOR	129	2580
EQUILIBRIUM NOISE IN ION SELECTIVE FIELD EFFECT	TRANSISTORS	129	2306
ECTRODE REACTION A	TRANSITION IN THE KINETICS OF THE NI(OH)2/NIOOH EL	129	983
EMICAL CELLS LOCAL SPECTRAL RESPONSES OF	TRANSITION METAL DICHALCOGENIDES IN PHOTOELECTROCH	129	1237
RESISTIVITIES OF THIN FILM	TRANSITION METAL SILICIDES	129	293
RECT OBSERVATIONS OF INCLUSIONS IN ELECTRODEPOSITED FILMS BY	TRANSMISSION ELECTRON MICROSCOPY DI	129	201C
LECTROCHEMISTRY FOR STEELS IN THE ACTIVE STATE BASED ON MASS	TRANSPORT BY DIFFUSION AND ION MIGRATION A MODEL O	129	1412
MENISCUS MELT INTERACTIONS ASSOCIATED WITH CARBON AND OXYGEN	TRANSPORT IN EFG OF SILICON RIBBON MODELING OF AMB	129	1356
THEORETICAL ANALYSIS OF ELECTROSTATIC EFFECTS ON ION	TRANSPORT IN ULTRATHIN MEMBRANES	129	958
IMPEDANCE AND MASS	TRANSPORT KINETICS OF NICKEL CADMIUM CELLS	129	289
EGRADATION	TRANSPORT NUMBER GRADIENTS AND SOLID ELECTROLYTE D	129	752
THERMODYNAMICS AND KINETICS OF IODINE CHEMICAL VAPOR	TRANSPORT OF GEAS	129	1343
OXYLATE AND SULFONATE ION EXCHANGE POLYMERS II. SORPTION AND	TRANSPORT PROPERTIES IN CONCENTRATED SOLUTION ENVI	129	328
IN TIS2: CHRONOAMPEROMETRIC DETERMINATION OF MASS AND CHARGE	TRANSPORT PROPERTIES OF LIQUID ELECTROLYTE SYSTEMS	129	682
N THREE-ELECTRODE PHOTOELECTROCHEMICAL STORAGE CELLS	TRANSPORT PROPERTIES OF NAFION MEMBRANES FOR USE I	129	2469
CENTRATED SOLUTION ENVIRONMENTS	TRANSPORT PROPERTIES OF NAFION(R) MEMBRANES IN CON	129	85
CE THE ANOLYTE DIFFUSION LAYER AND ITS EFFECT ON HYDROXYL	TRANSPORT THROUGH NAFION MEMBRANE IN CHLOR-ALKALI	129	722
SUPPRESSION OF THERMAL CONVECTION BY	TRANSVERSE MAGNETIC FIELD	129	427
NETICS IN MOSFET'S DUE TO SUBSTRATE HOT-ELECTRO INTERFACE	TRAPPED CHARGE GENERATION AND ELECTRON TRAPPING KI	129	1760
-ELECTRO INTERFACE TRAPPED CHARGE GENERATION AND ELECTRON	TRAPPING KINETICS IN MOSFET'S DUE TO SUBSTRATE HOT	129	1760
I-V ELECTRODES THE INFLUENCE OF SURFACE RECOMBINATION AND	TRAPPING ON THE CATHODIC PHOTOCURRENT AT P-TYPE II	129	730
EFFECTS OF AMMONIA ANNEAL ON ELECTRON	TRAPPINGS IN SILICON DIOXIDE	129	2042
NE ELECTRON	TRAPS IN SIO2 GROWN IN PRESENCE OF TRICHLOROETHYLE	129	2772
O LOCAL OXIDATION MOS GATE OXIDE DEFECTS RELATED TO	TREATMENT OF SILICON NITRIDE COATED WAFERS PRIOR T	129	1066
F COOPERATIVE DIFFUSION AND CHEMICAL REACTION DURING THERMAL	TREATMENTS OF SILICA FILMS IN WATER VAPOR AN 180 S	129	867
SPIN-ON GLASS AS AN INTERMEDIATE LAYER IN A	TRI-LAYER RESIST PROCESS	129	2152
SENSITIVE POSITIVE RESI STUDIES OF METHACRYLONITRILE AND	TRICHLOROETHYL METHACRYLATE COPOLYMERS AS ELECTRON	129	1596
EXPERIMENTAL STUDY OF ELECTROCHEMICAL FLUORINATION OF	TRICHLOROETHYLENE	129	2720

		Vol	Page
ELECTRON TRAPS IN SIO2 GROWN IN PRESENCE OF	**TRICHLOROETHYLENE**	129	2772
PRODUCTION, INFRARED ABSORPTIVITY, AND CHEMICAL REACTIONS OF	**TRICHLOROSILANOL** IN SILICON TETRACHLORIDE PHOTOCHE	129	1619
H REACTIVE ION ETCHING OF SILICON OXIDES WITH AMMONIA AND	**TRIFLUOROMETHANE**. THE ROLE OF NITROGEN IN THE DISC	129	1036
ELECTROCHEMICAL PHOTOVOLTAIC CELLS BASED ON N-GAAS AND THE	**TRIIODIDE/IODIDE** REDOX COUPLE IN ACETONITRILE	129	1705
OXIDE FILMS DEPOSITED BY THE OXIDATION OF TETRAMETHYLTIN AND	**TRIMETHYLANTIMONY** ANTIMONY-DOPED TIN	129	1040
PROTON DIFFUSION IN TUNGSTEN	**TRIOXIDE** THIN FILMS	129	2349
REPARED BY CHEMICAL VAPOR DEPOSITION AT LOW TEMPERATURE FROM	**TRIS-(2,2'BIPYRIDINE)** TITANIUM A CORROSION-RESISTA	129	854
URANIUM-ACTIVATED LITHIUM	**TUNGSTATE** PHOSPHORS	129	887
QUEOUS ELECTROL CHARACTERIZATION OF N-TYPE SEMICONDUCTING	**TUNGSTEN** DISULFIDE PHOTOANODES IN AQUEOUS AND NONA	129	1461
ATES AND ELECTROCHEMICAL STUDIES OF A DEPLETED URANIUM ALLOY	**TUNGSTEN** FIBER METAL MATRIX COMPOSITE CORROSION R	129	1398
AN ELLIPSOMETRIC STUDY OF ELECTROCHROMISM IN	**TUNGSTEN** OXIDE	129	767
PROTON DIFFUSION IN	**TUNGSTEN** TRIOXIDE THIN FILMS	129	2349
KALI SALTS IN A PRESSURIZED FLUIDIZED BED COAL COMBUSTOR/GAS	**TURBINE** COMBINED CYCLE VOLATILIZATION/CONDENSATION	129	2119
IMPURITY DEPOSITS IN GAS	**TURBINES** FROM FUELS CONTAINING SODIUM AND VANADIUM	129	649
RELATION BETWEEN MASS TRANSFER AND CORROSION IN A	**TURBULENT** PIPE FLOW	129	276
EFFECT OF MELT STOICHIOMETRY ON	**TWIN** FORMATION IN LEC GAAS	129	2382
SEMI-INFINITE DIFFUSION TO ELECTRODES CONSISTING OF	**TWO** OR MORE INTERSECTING PLANES	129	128
DSC STUDY OF	**TWO** REACTIONS IN THE LITHIUM-BORON ALLOY SYSTEM	129	1513
BROMINE REDUCTION IN A	**TWO-PHASE** ELECTROLYTE	129	2397

— U —

DEEP	**U.V.** HARDENING OF POSITIVE PHOTORESIST PATTERNS	129	1379
ALUATION OF PURE NOVOLAK CRESOL-FORMALDEHYDE RESINS FOR DEEP	**U.V.** LITHOGRAPHY EV	129	201
LITHOGRAPHIC EVALUATION OF AN O-NITROBENZYL ESTER BASED DEEP	**U.V.** RESIST SYSTEM	129	2552
AND AL ETCHING AND PRODUCT DETECTION IN A PLASMA BEAM UNDER	**ULTRAHIGH** VACUUM SI	129	2045
ETICAL ANALYSIS OF ELECTROSTATIC EFFECTS ON ION TRANSPORT IN	**ULTRATHIN** MEMBRANES THEOR	129	958
TERPRETATION OF POTENTIOSTATIC TRANSIENT BEHAVIOR DURING THE	**UNDERPOTENTIAL** DEPOSITION OF SILVER ON GOLD USING	129	1202
REE C PROPERTIES OF PLASMA-ENHANCED CVD SILICON FILMS I.	**UNDOPED** FILMS DEPOSITED FROM 525 DEGREE TO 725 DEG	129	2326
ANSFER IN PHOTOELECTROCHEMICAL DEVICES VIA INTERFACE STATES:	**UNIFIED** MODEL AND COMPARISON WITH EXPERIMENTAL DAT	129	1003
A CROSS-BRIDGE TEST STRUCTURE FOR EVALUATING THE LINEWIDTH	**UNIFORMITY** OF AN INTEGRATED CIRCUIT LITHOGRAPHY SY	129	2313
CORROSION RATES AND ELECTROCHEMICAL STUDIES OF A DEPLETED	**URANIUM** ALLOY TUNGSTEN FIBER METAL MATRIX COMPOSIT	129	1398
PREPARATION OF THE FIRST ELECTROLYTIC PLUTONIUM AND OF	**URANIUM** FROM FUSED CHLORIDES	129	2438
	URANIUM-ACTIVATED LITHIUM TUNGSTATE PHOSPHORS	129	887

— V —

THE CHEMICAL NATURE OF ALUMINUM CORROSION	**V.** ENERGY TRANSFER IN ALUMINUM DISSOLUTION	129	464
CHING AND PRODUCT DETECTION IN A PLASMA BEAM UNDER ULTRAHIGH	**VACUUM** SI AND AL ET	129	2045
ADIATI ANOMALOUS LOCAL OXIDATION AND RECRYSTALLIZATION OF	**VACUUM-DEPOSITED** AMORPHOUS SILICON BY CW LASER IRR	129	888
ATIC TECHNIQUE FOR STUDYING DIELECTRIC CONSTANT VARIATION IN	**VALVE-METAL** OXIDES A GALVANOST	129	2038
EVALUATE RATE CONSTANTS FOR HYDROGEN PER COMMENTS ON THE	**VAN** DER BRINK, BARENDRECHT, AND VISSCHER METHOD TO	129	2268
TY DEPOSITS IN GAS TURBINES FROM FUELS CONTAINING SODIUM AND	**VANADIUM** IMPURI	129	649
REACTION DURING THERMAL TREATMENTS OF SILICA FILMS IN WATER	**VAPOR** AN 18O STUDY OF COOPERATIVE DIFFUSION AND CH	129	867
RROSION-RESISTANT TITANIUM-RICH DEPOSIT PREPARED BY CHEMICAL	**VAPOR** DEPOSITION AT LOW TEMPERATURE FROM TRIS-(2,2	129	854
PHASE THERMODYNAMIC AND EXPERIMENTAL ANALYSIS OF CHEMICAL	**VAPOR** DEPOSITION OF ALUMINA FROM ALCL3-H2-CO2 GAS	129	1367
UID SOURCE IMPROVING THE ELECTRICAL PROPERTIES OF	**VAPOR** GROWN III-V COMPOUNDS BY COOLING THE HCL LIQ	129	2566
	VAPOR PHASE EPITAXIAL GROWTH OF MGO.AL2O3	129	2569
ISOTHERMAL GROWTH OF HGCDTE UNDER CONTROLLED HG	**VAPOR** PRESSURE	129	2855
ATUS FOR THE STUDY OF GROWTH-PROPERTY RELATIONSHIPS: ARSENIC	**VAPOR** PRESSURE-GAAS PROPERTY RELATIONSHIP BRIDGMAN	129	388
THERMODYNAMICS AND KINETICS OF IODINE CHEMICAL	**VAPOR** TRANSPORT OF GEAS	129	1343
COMPOSITION, KINETICS, AND MECHANISM OF GROWTH OF CHEMICAL	**VAPOR-DEPOSITED** ALUMINUM NITRIDE FILMS	129	1045
SOLUTIONS IN THE CADMIUM-INDIUM-SULFIDE, INDIUM-SULFIDE SYS	**VAPORIZATION** CHEMISTRY AND THERMODYNAMICS OF SOLID	129	1835
THE CONGRUENT	**VAPORIZATION** OF MN2P(S)	129	2343
TARNISHING OF SILVER BY ORGANIC SULFUR	**VAPORS**: RATES AND FILM CHARACTERISTICS	129	33
OPTIMIZATION OF ELECTROLYTIC CELLS HAVING LARGE NUMBERS OF	**VARIABLES**	129	1225
YSIS OF PHOTOELECTROCHEMICAL CELLS UNDER MASS AND LIGHT FLUX	**VARIATION** CURRENT-VOLTAGE ANAL	129	2029
A GALVANOSTATIC TECHNIQUE FOR STUDYING DIELECTRIC CONSTANT	**VARIATION** IN VALVE-METAL OXIDES	129	2038
D WITH THE SEMICONDUCTO AN INVESTIGATION OF THE THICKNESS	**VARIATION** OF SPUN-ON THIN FILMS COMMONLY ASSOCIATE	129	173
ANALYSIS OF INP SURFACE PREPARED BY	**VARIOUS** CLEANING METHODS	129	447
E DEPENDENCE OF THE SENSITIVITIES OF METAL-TIO2 JUNCTIONS TO	**VARIOUS** REDUCING GASES TEMPERATUR	129	444
	VENTURES IN ELECTROCHEMICAL INDUSTRY	129	397C
MASS TRANSFER AT LONGITUDINALLY VIBRATING	**VERTICAL** ELECTRODES	129	1955
GNETIC FIELD EFFECTS ON THE GROWTH OF THE DIFFUSION LAYER AT	**VERTICAL** ELECTRODES DURING ELECTRODEPOSITION MA	129	1266
KINETICS OF ELECTROLESS COPPER PLATING	**VI.** INHIBITION BY ADSORPTION OF LIGAND	129	717
ED IN THE INITIATION OF HOT CORROSION OF B-1900 AND NASA-TRW	**VIA** CHEMICAL REACTIONS INVOLV	129	571
WITH EXP CHARGE TRANSFER IN PHOTOELECTROCHEMICAL DEVICES	**VIA** INTERFACE STATES: UNIFIED MODEL AND COMPARISON	129	1003
CONDUCTOR/ELECTROLYTE INTERFACE ELECTROCHEMICAL TRANSFER	**VIA** SURFACE STATES: A NEW FORMULATION FOR THE SEMI	129	963
MASS TRANSFER AT LONGITUDINALLY	**VIBRATING** VERTICAL ELECTRODES	129	1955
	VIBRATING ZINC ELECTRODES IN NI/ZN BATTERIES	129	913
RE AND ION PAIRING IN COMPLEXES OF POLY(ETHYLENE OXIDE) WITH	**VIBRATIONAL** SPECTROSCOPIC DETERMINATION OF STRUCTU	129	1434
D PLATINUM AND TANTALUM ELECT POLYMER FILMS ON ELECTRODES	**VII.** ELECTROCHEMICAL BEHAVIOR AT POLYPYRROLE-COATE	129	1009
RTIES OF CADMIUM S LUMINESCENT PHOTOELECTROCHEMICAL CELLS	**VII.** PHOTOLUMINESCENT AND ELECTROLUMINESCENT PROPE	129	772
GH DENSITY THERMAL SIO2 AT LOW OXIDATION TEMPERATURES A	**VISCOUS** FLOW MODEL TO EXPLAIN THE APPEARANCE OF HI	129	2594
DITHIOLENE COMPLEX ELECTRODE	**VISIBLE** LIGHT CONVERSION AT ONE-DIMENSIONAL NICKEL	129	2378
ROGEN PER COMMENTS ON THE VAN DER BRINK, BARENDRECHT, AND	**VISSCHER** METHOD TO EVALUATE RATE CONSTANTS FOR HYD	129	2268
INING WITH FLUORESCING AND NONFLUORESCING DYES	**VISUAL** DETECTION OF HYDRATED ALUMINUM OXIDE BY STA	129	1517
CHEMICAL MODIFICATION OF RETICULATED	**VITREOUS** CARBON	129	2505
THE MECHANISM OF OXYGEN DIFFUSION IN	**VITREOUS** SIO2	129	357
ELECTRICAL PROPERTIES OF AL/TI CONTACT METALLURGY FOR	**VLSI** APPLICATION	129	2590
DRY ETCHING FOR	**VLSI**--A REVIEW	129	62C
	VOIDS IN ANODIC ALUMINUM OXIDE FILMS	129	711
RESSURIZED FLUIDIZED BED COAL COMBUSTOR/GAS TURBINE COMBINED	**VOLATILIZATION/CONDENSATION** OF ALKALI SALTS IN A P	129	2119
US ELECTRON TRANSFER KINETIC PARAMETERS BY DERIVATIVE CYCLIC	**VOLTABSORPTOMETRY** THE COLIN GARFIELD FINK SUMMER F	129	298C
ROPERTIES OF MOLTEN POTASSIUM POLYSULFIDES FROM OPEN-CIRCUIT	**VOLTAGE** MEASUREMENTS THERMODYNAMIC AND PHYSICAL P	129	2707
ODE MORPHOLOGY IN ALKALINE SOLUTIONS I. STUDY OF ALTERNATING	**VOLTAGE** MODULATION ON A ROTATING DISK ELECTRODE Z	129	2677
MENT OF KINETICS OF E ERROR ANALYSIS OF THE POTENTIAL AND	**VOLTAGE** STEP RELAXATION TECHNIQUES FOR THE MEASURE	129	1943
IONS OF ALKALI-METAL INTERCALATION REACTIONS IN TIS2: CYCLIC	**VOLTAMMETRY** AND CHRONOCOULOMETRY OF LIQUID ELECTRO	129	677
ORESCENCE OF TB-ACTIVATED GARNET PHOSPHORS EFFECT OF	**V2O3** ADDITION ON THE THERMOLUMINESCENCE AND PHOSPH	129	2638

		Vol	Page
	— W —		
SFORM INFRARED STUDIES OF CHEMICALLY MODIFIED THE JOSEPH	**W.** RICHARDS SUMMER FELLOWSHIP REPORT--FOURIER TRAN	129	300C
CHEMICAL ETCHING OF INGAASP/INP DH	**WAFER**	129	1053
MINIMUM SILICON	**WAFER** THICKNESS FOR ID WAFERING	129	2835
MINIMUM SILICON WAFER THICKNESS FOR ID	**WAFERING**	129	2835
METAL DECORATED DEFECTS IN HEAT-TREATED SILICON	**WAFERS**	129	1128
DEFORMATION OF SILICON	**WAFERS** BY THERMAL OXIDATION	129	2076
OXIDE DEFECTS RELATED TO TREATMENT OF SILICON NITRIDE COATED	**WAFERS** PRIOR TO LOCAL OXIDATION MOS GATE	129	1066
MULTISTEP REPEATED ANNEALING FOR CZ-SILICON	**WAFERS:** OXYGEN AND INDUCED DEFECT BEHAVIOR	129	2089
MASS TRANSFER IN LAMINAR FLOW CHANNEL WITH POROUS	**WALL**	129	1727
EXFOLIATION CORROSION OF ALMGSI ALLOYS IN	**WATER**	129	1181
ALLOYS--REDUCED BANDGAP EFFECTS IN THE PHOTOELECTROLYSIS OF	**WATER** TIO2-VO2	129	1210
ATE GLASS FILMS	**WATER** ABSORPTION AND DENSIFICATION OF PHOSPHOSILIC	129	1765
POROUS NICKEL-COATED STEEL ANODES FOR ALKALINE	**WATER** ELECTROLYSIS: CORROSION RESISTANCE	129	310
SIMS EVIDENCE CONCERNING	**WATER** IN PASSIVE LAYERS	129	2149
IMPACT OF DEIONIZED	**WATER** RINSES ON SILICON SURFACE CLEANING	129	1027
OXYLATE AND SULFONATE ION EXCHANGE POLYMERS I. DIFFUSION AND	**WATER** SORPTION A COMPARISON OF PERFLUORINATED CARB	129	324
THERMOCHEMICAL PROCESSES FOR HYDROGEN PRODUCTION BY	**WATER** SPLITTING: FROM THEORY TO PRACTICE	129	67
EMICAL REACTION DURING THERMAL TREATMENTS OF SILICA FILMS IN	**WATER** VAPOR AN 18O STUDY OF COOPERATIVE DIFFUSION	129	867
INEXPENSIVE CROSS-LINKED POLYMERIC SEPARATORS MADE FROM	**WATER-SOLUBLE** POLYMERS	129	251
AND OTHER III-V SEMICONDUCTOR DEVICES, INCLUDING INGAAS LONG	**WAVELENGTH** PHOTODETECTORS A PROPOSED HYDROGENATION	129	821
SELECTIVE DISSOLUTION OF THE BINDER PHASE ALLOY (CO-W) FROM	**WC-CO** CEMENTED CARBIDES IN PARTICULATE BED ELECTRO	129	2666
THE ELECTROCHEMICAL REDUCTION OF RUST FILMS ON	**WEATHERING** STEEL SURFACES	129	2686
ELECTRON MICROSCOPY OF	**WEB-DENDRITIC** SILICON	129	1089
ION ELECTRON BEAM NEGATIVE RESIST WITH VERY NARROW MOLECULAR	**WEIGHT** DISTRIBUTIONS HIGH RESOLUT	129	663
DSORPTION PARAMETERS AND ADSORPTION RATES FOR THE EDWARD	**WESTON** SUMMER FELLOWSHIP REPORT--QUANTITATION OF A	129	295C
TION OF THIN (100) ORIENTED SILICON EPITAXIAL LAYERS USING A	**WET** CHEMICAL ETCH METHODS FOR DEFECT EVALUA	129	2074
2O5-P2O5:MN, CE	**WHITLOCKITE** PHASE IN THE LUMINESCENT SYSTEM SRO-LI	129	1373
FRACTION TOPOGRAPHY	**WIRE** BONDING PROCESS CHARACTERIZATION BY X-RAY DIF	129	846
ALTERATION OF CORRODENT ION SPECIES	**WITHIN** STRESS CORROSION CRACKS	129	780
SIST A NEW DOPING TECHNIQUE	**WITHOUT** SIO2 PATTERNING USING AN INORGANIC PHOTORE	129	1074
HYDROGEN ANNEAL EFFECTS ON METAL-SEMICONDUCTOR	**WORK** FUNCTION DIFFERENCE	129	806
ELECTROCHEMICAL INSERTION OF HYDROGEN IN	**WO3**	129	2276
ION OPTICAL CHARACTERISTICS OF	**WO3** ELECTROCHROMIC CELLS UNDER HEAVY LI ION INJECT	129	2633
ION-CONTAINING POLYMERS AS SEMISOLID ELECTROLYTES IN	**WO3-BASED** ELECTROCHROMIC DEVICES	129	1215
PIPED EMITTER DELINEATION USING THE	**WRIGHT** ETCH	129	354
ECTRODES 44. PHOTOELECTROCHEMISTRY AT POLYCRYSTALLINE P-TYPE	**WSE2** FILMS SEMICONDUCTOR EL	129	673
POLYCRYSTALLINE	**WSE2** PHOTOELECTRODES	129	145
	— X —		
SCHARGE PRODUCT OF THE LITHIUM/SULFUR DIOXIDE BATTERY	**X-RAY** DIFFRACTION PATTERN AND DSC CURVES OF THE DI	129	565
WIRE BONDING PROCESS CHARACTERIZATION BY	**X-RAY** DIFFRACTION TOPOGRAPHY	129	846
STEM CUO-NIO-MGO AT 1000 DEG F.M. BECKET AWARD REPORT--AN	**X-RAY** POWDER DIFFRACTION STUDY OF PHASES IN THE SY	129	31C
ES BY ELECTROCHEMICAL POLYMERIZA SEMICONDUCTOR ELECTRODES	**XLI.** IMPROVEMENT OF PERFORMANCE OF N-WSE2 ELECTROD	129	265
IN THE FLATBAND POTENTIAL OF P- SEMICONDUCTOR ELECTRODES	**XLII.** EVIDENCE FOR FERMI LEVEL PINNING FROM SHIFTS	129	1742
IN AQUEOUS SOLUTIONS SEMICONDUCTOR ELECTRODES	**XLV.**,PHOTOELECTROCHEMISTRY OF N- AND P-TYPE MOTE2	129	2224
EOUS SOLUTION PHOTOELECTROCHEMIC SEMICONDUCTOR ELECTRODES	**XLVI.** STABILIZATION OF N-SILICON ELECTRODES IN AQU	129	1647
	— Y —		
INHOMOGENEITY CONTRIBUTION TO THE ELECTRICAL PROPERTIES OF	**Y-DOPED** CEO2 CERAMICS: COMPARISON OF A-C AND D-C M	129	2113
HOST SENSITIZATION MECHANISM OF EU(3+) LUMINESCENCE IN	**(Y, IN)2O3**	129	2069
REPORT ON THE ELECTROLYTIC INDUSTRIES FOR THE	**YEAR** 1981	129	275C
ONTAMINATION IN SILICON SUBSTRATES AND ITS IMPACT ON CIRCUIT	**YIELD** A SURVEY OF IRON C	129	2573
-INDUCED COMPOSITION GRADIENTS. MOLTEN NANO3-AGNO3 IN POROUS	**YTTRIA** SEM/EDX AND AA MEASUREMENTS OF CURRENT	129	931
SOLUBILITY OF	**YTTRIUM** OXIDE IN NA2SO4 AND NACL MELTS	129	2228
AN EXPERIMENTAL STUDY OF MOTION OF ELECTRONS AND HOLES IN	**Y2O2S** CRYSTAL AS REVEALED BY CATHODOLUMINESCENCE	129	1535
A RED PHOSPHOR OF HIGH LUMEN EQUIVALENT,	**Y2W3O12:EU(3+)**	129	2296
SINGLE CRYSTAL	**Y3AL5O12:TB** PHOSPHOR PRODUCED BY ION IMPLANTATION	129	816
	— Z —		
MOSSBAUER SPECTROSCOPIC STUDY OF THE CORROSION INHIBITION OF	**ZINC** BY COBALT IONS	129	1658
NG SULFATE BATHS	**ZINC** ELECTROCRYSTALLIZATION FROM IMPURITY-CONTAINI	129	2695
STUDY OF ALTERNATING VOLTAGE MODULATION ON A ROTATING DISK	**ZINC** ELECTRODE MORPHOLOGY IN ALKALINE SOLUTIONS I.	129	2677
N ELECTROLYTE CONDUCTANCE AND CURRENT DISTRIBUTION IN POROUS	**ZINC** ELECTRODES IN KOH ELECTROLYTE THE RELATIONSHI	129	1390
TRANSIENT CURRENT DISTRIBUTIONS IN POROUS	**ZINC** ELECTRODES IN KOH ELECTROLYTE	129	239
VIBRATING	**ZINC** ELECTRODES IN NI/ZN BATTERIES	129	913
THE ELECTROCRYSTALLIZATION OF	**ZINC** FROM ALKALINE MEDIA	129	2654
TRANSFERENCE NUMBERS OF	**ZINC** IN ZINC-CHLORIDE BATTERY ELECTROLYTES	129	907
AN OPEN-TUBE METHOD FOR DIFFUSION OF	**ZINC** INTO GAAS	129	1567
OJUNCTIONS LPE GROWTH TECHNIQUES FOR FABRICATING ABRUPT	**ZINC-** AND MAGNESIUM-DOPED P(+)-N INGAASP/INP HETER	129	2085
FLOW DISTRIBUTION IN THE	**ZINC-CHLORIDE** BATTERY	129	2251
TRANSFERENCE NUMBERS OF ZINC IN	**ZINC-CHLORIDE** BATTERY ELECTROLYTES	129	907
COMPARISON OF MATERIALS AS OXYGEN CATALYTIC ELECTRODES ON	**ZIRCONIA** ELECTROLYTE	129	436
TRODE SURFACE IMPURITIES ON THE OXYGEN ELECTRODE REACTION AT	**ZIRCONIA** ELECTROLYTES THE EFFECT OF ELEC	129	345
LYSIS AND 18O TRACING OF THE GROWTH OF ANODIC OXIDE FILMS ON	**ZIRCONIUM** I. INFLUENCE OF FORMATION CONDITIONS ON	129	1895
LYSIS AND 18O TRACING OF THE GROWTH OF ANODIC OXIDE FILMS ON	**ZIRCONIUM** II. OXIDE GROWTH MECHANISM A STUDY BY NU	129	1905
IGH CURRENT DENSITIES I. EXPERIMENTAL PHENO SATURATION OF	**(ZN, CD)S:CU, AL** CATHODOLUMINESCENT PHOSPHORS AT H	129	1546
ED CMD FROM MN-NH4-CARBAMATE AND ITS DISCHARGE PROPERTIES IN	**ZNCL2** BATTERIES THE SYNTHESIS OF DENSIFI	129	2372
FUNCTION OF SURFACE ACCEPTOR STATE DENSITY: APPLICATION FOR	**ZNO** GAS SENSORS CALCULATION OF CARRIER CONCENTRATI	129	1382
THE ELECTROLUMINESCENCE OF	**ZNS:CU, BR** PHOSPHOR	129	813
ION SPECTROSCOPY STUDIES OF PHOTOCORROSION AT THE	**ZNSE-ELECTROLYTE** INTERFACE BY PHOTOTHERMAL DEFLECT	129	2393
IDE ELECTROLYTE PHOTOELECTROCHEMICAL PERFORMANCE OF	**ZNSE/CDSE** THIN FILM ELECTRODES IN AQUEOUS POLYSULF	129	542
MOVEABLE-STRIP-HEATER OVEN	**ZONE-MELTING** RECRYSTALLIZATION OF SI FILMS WITH A	129	2812
NEW SOLID ELECTROLYTES BASED ON CUBIC	**ZRP207**	129	726
	— 1 —		
T CHEMICAL ETCH METHODS FOR DEFECT EVALUATION OF THIN **(100)** ORIENTED SILICON EPITAXIAL LAYERS USING A WE		129	2074

	Vol	Page
REACTION OF OXYGEN WITH SI(111) AND (100): CRITICAL CONDITIONS FOR THE GROWTH OF SIO2	129	1300
DER DIFFRACTION STUDY OF PHASES IN THE SYSTEM CUO-NIO-MGO AT 1000 DEGREE C F.M. BECKET AWARD REPORT--AN X-RAY P	129	31C
ACTION DURING THERMAL TREATMENTS OF SILICA FILMS IN WA AN 180 STUDY OF COOPERATIVE DIFFUSION AND CHEMICAL RE	129	867
ZIRCONIUM I. INFLUE A STUDY BY NUCLEAR MICROANALYSIS AND 180 TRACING OF THE GROWTH OF ANODIC OXIDE FILMS ON	129	1895
ZIRCONIUM II. OXIDE A STUDY BY NUCLEAR MICROANALYSIS AND 180 TRACING OF THE GROWTH OF ANODIC OXIDE FILMS ON	129	1905
REPORT ON THE ELECTROLYTIC INDUSTRIES FOR THE YEAR 1981	129	275C
— 2 —		
'-BIPYRIDINECOBALT ELECTROCHEMISTRY AND ADSORPTION OF BIS 2,2'-BIPYRIDINECOBALT(I) AND BIS 6,6'-DIMETHYL-2,2	129	1260
ITE IONS IN THE MOLTEN NAOH-KOH (49 M/O) EUTECTIC MIXTURE AT 250 DEGREE C ELECTROCHEMICAL BEHAVIOR OF NITRATE A	129	123
RODE" IN THE MONITORING OF CORROSION AND REDOX POTENTIALS AT 285DEGREE C USE OF A HIGH TEMPERATURE PH SENSOR AS	129	1445
S SYSTEMS POTENTIAL/PH MEASUREMENTS IN ALLOY 600 CREVICES AT 288DEGREE C CREVICE CORROSION IN HIGH-TEMPERATURE	129	2458
— 4 —		
CONTROLLED POTENTIAL COULOMETRY OF 4-CYANO-1-METHYLPYRIDINIUM ION IN ACETONITRILE	129	2731
POLAROGRAPHY OF 4-CYANO-1-METHYLPYRIDINIUM ION IN ACETONITRILE	129	2725
E WSE2 FILMS SEMICONDUCTOR ELECTRODES 44. PHOTOELECTROCHEMISTRY AT POLYCRYSTALLINE P-TYP	129	673
TY OF IRON(II) AND (III) OXIDES IN LICL-KCL EUTECTIC MELT AT 470DEGRFE C REACTIONS OF FORMATION AND STABILI	129	1450
BEHAVIOR OF NITRATE AND NITRITE IONS IN THE MOLTEN NAOH-KOH (49 M/O) EUTECTIC MIXTURE AT 250 DEGREE C ELECTROC	129	123
— 5 —		
A-ENHANCED CVD SILICON FILMS I. UNDOPED FILMS DEPOSITED FROM 525 DEGREE TO 725 DEGREE C PROPERTIES OF PLASM	129	2326
— 6 —		
ISTRY AND ADSORPTION OF BIS 2,2'-BIPYRIDINECOBALT(I) AND BIS 6,6'-DIMETHYL-2,2'-BIPYRIDINECOBALT(I) IN ACETONIT	129	1260
AND PH ON THE ANODIC BEHAVIOR AND PITTING CORROSION OF ALLOY 600 EFFECT OF SO2	129	2194
MPERATURE AQUEOUS SYSTEMS POTENTIAL/PH MEASUREMENTS IN ALLOY 600 CREVICES AT 288DEGREE C CREVICE CORROSION IN H	129	2458
LFUR ON THE ANODIC H2(NI) ELECTRODE IN FUSED LI2CO3-K2CO3 AT 650DEGREE C THE EFFECT OF SU	129	1441
— 7 —		
SILICON FILMS I. UNDOPED FILMS DEPOSITED FROM 525 DEGREE TO 725 DEGREE C PROPERTIES OF PLASMA-ENHANCED CVD	129	2326
— 9 —		
LT ELECTROCHEMICAL AND SPECTROSCOPIC STUDIES OF 9,10-ANTHRAQUINONE IN A ROOM-TEMPERATURE MOLTEN SA	129	2488
SIMS STUDIES OF 9BE IMPLANTS IN SEMI-INSULATING INP	129	1312